2003 DATABOOK



# **AMPLIFIERS**

RF Amplifiers: KHz to 2000 MHz
Low Noise Amplifiers: 1 dB Noise Figure
Power Amplifiers: to 2 Watts; IP2 > 70 dBm
Limiting Amplifiers: Gains to +52 dB

\* GUARANTEED LOW PHASE NOISE AMPLIFIERS \*

# VCO's

Hermetic-30 MHz to 5000 MHz

# Attenuators

**Voltage Variable and Digital** 

# **Switches**

SPST to SP8T

# **Detectors**

Threshold and Level

Amplifonix, Inc. 2707 Black Lake Place Philadelphia, PA 19154



Phone: (215) 464-4000 Fax: 215-464-4001 Website: www.amplifonix.com

	•		

# **The Amplifonix Mission**

Amplifonix will strive to provide <u>Total Customer</u> <u>Satisfaction</u> by manufacturing and delivering the industry's highest quality RF products, which consistently meet and exceed our customers' expectations for performance, price and delivery. We will ensure ongoing <u>Total Customer</u> <u>Satisfaction</u> through continuous improvements in our products, processes and people.



Amplifonix is located in a 20,000 square foot modern facility in Northeast Philadelphia, PA. The building was constructed to Amplifonix's specifications which included a 4,000-sq. foot Class 100,000 hybrid manufacturing room. The Amplifonix Engineering group has over 100 years of combined design experience with Amplifiers, VCO's and other Control Devices. Our engineers actively use computer-aided design programs to quickly analyze and design circuits and develop hybrid layouts.

All prototype units are manufactured and tested using production personnel to ensure a smooth and effective transition from development to production. The test facility includes computer automated test sets which allow for rapid testing of devices and S-Parameter data to be supplied as required. Amplifonix manufacturing also operates assembly and test on all three (3) shifts ensuring rapid turn around of all orders.

Amplifonix, Inc. 2707 Black Lake Place Philadelphia, Pa. 19154 Phone: (215)-464-4000 Cage Code 60979

# **Table of Contents**

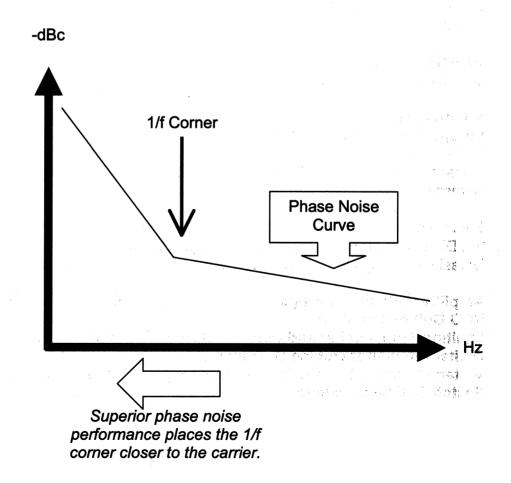
Phase Noise Information	3-11
Application Notes	12-15
Production Process	16
Quality Background	
Cascade Information	19-22
Component Evaluation Board	23
Component Evaluation Board	, <u>2</u> 0
Amplifiers	
Higher Power	24-25
Low Noise	26-28
Higher Gain	
Bi-Polar Designs	33_38
Lower Power	30_44
Lower Yorks as	55 <del>-47</del>
Lower Voltage  Full Datasheets  Amplifier Direct Cross List	40 46 244
Full Datasneets	40-34 1
Amplifier Direct Cross List	342-346
randina di Mariana di Karamatan di Karamatan di Karamatan di Karamatan di Karamatan di Karamatan di Karamatan Karamatan di Karamatan di Karama	
VCO Application Notes	347-348
VCO List of Products  Datasheets	349
Datasheets	350-396
Limiting Amps, Limiters	397
Datasheets	398-406
Detectors	407
Datasheets	408-411
Datasileets	
Attonuatore	
Attenuators	410
Voltage Variable, Digital Attenuators	449 407
Datasheets	
Linearizers, Linearized Attenuators	
Datasheets	429-431
Switches	
Pin Diode and GaAs	432-433
Datasheets	434-460
Amplifier Outline Drawings	461-463
VCO Outline Drawings	
Limiting Amp, Limiter and Detector Outline Drawings	465-466
Digital Attenuator Outline Drawings	467-468
Voltage Variable & Linearized Attenuators & Linearizer Outline Drawings	46Q_470
Switch Outline Drawings	<del>703-7</del> 70
Switch Outline Drawings	4/ 1-4/2

### **A Brief Discussion**

### What is it?

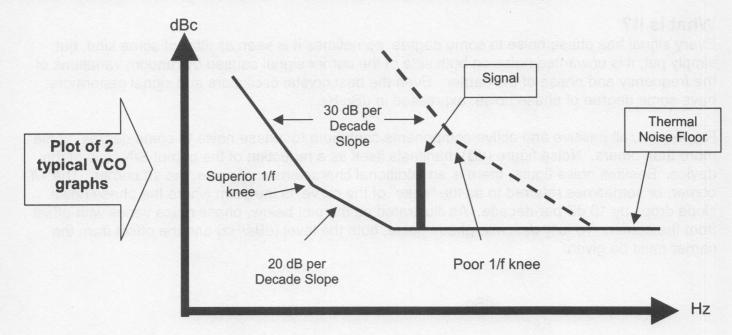
Every signal has phase noise to some degree, sometimes it is seen as jitter of some kind, but simply put, it is unwanted noise on both side of the carrier signal caused by random variations of the frequency and phase of the carrier. Even the best crystal oscillators and signal generators have some degree of phase noise, expressed in dBc/Hz.

Remember, all passive and active components contribute to phase noise to some degree, some more than others. Noise figure (dB) manifests itself as a reduction of the output S/N ratio of the device. Besides noise figure, there is an additional characteristic of noise, the 1/f corner. The 1/f corner, or sometimes referred to as the "knee" of the curve, is the point where the phase noise slope drops by 10 dB per decade. As illustrated on the plot below, phase noise varies with offset from the carrier. To fully describe phase noise, both the level (dBc/Hz) and the offset from the carrier must be given.



### Why is Superior Phase Noise important?

As the graph illustrates, a poor 1/f knee places the signal into the thermal noise region. Moving the 1/f corner closer to the carrier results in removing the noise from the signal.



# How Phase noise effects Doppler Radar, Missile Illuminators, and other Data Transmission Systems.

Low phase noise is a key element in a Missile Illuminator. For example, the objective of the system is to detect and amplify small reflected target signals. Simply put, degraded phase noise can result in the loss of the intended target signal.



Standard Missile



**AMRAAM Missile** 



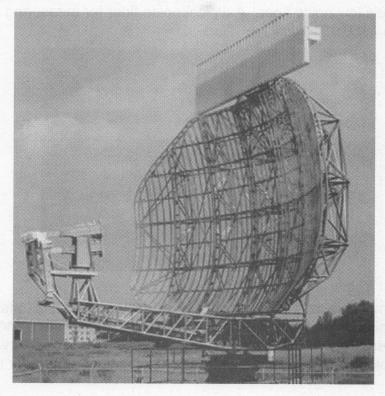
**HARM Missile** 



**Patriot Missile** 

(Active Amplifonix Programs)

Degraded phase noise also impacts the bit error rate (BER) of all data transmission systems. Improving the phase noise results in substantial BER performance improvement by increasing the S/N ratio in the receiver.



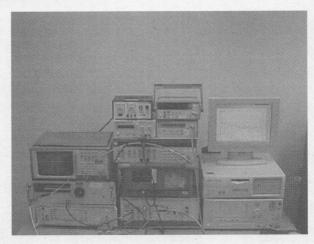
For all Doppler Radar designs, improving the subclutter visibility (SCV) is the bottom line. This allows the radar to see small moving objects on its screen. Excessive phase noise will degrade the SCV of the system. Improving the phase noise however increases the cancelled S/N ratio thereby improving the SCV.





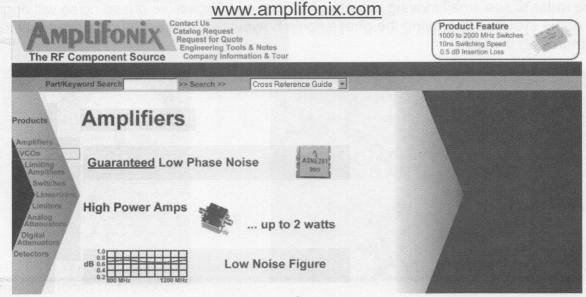
### How is Phase Noise measured?

Unlike measuring phase noise in a VCO, amplifiers require a much more sensitive measuring system with an extremely low noise floor. A typical noise floor for measuring VCO's may only be on the order of –145 to –150 dBc/Hz.



For low phase noise amplifiers, a noise floor of at least –180 @100K Hz (offset from the carrier) is required in order to minimize the noise floor contribution to the amplifier's additive phase noise. Amplifonix accomplishes this feat using an Agilent ES5500 system coupled with an IFR low noise synthesizer. This enables us to meet the required low noise floor criteria for measuring low phase noise amplifiers.

Visit the Amplifonix website for a list of the recent developments in Low Phase Noise Amplifier Technology.



# RF AMPLIFIER MODEL TM5155PM

Available as:

TM5155PM, 4 Pin TO-8 (T4)

TN5155PM, 4 Pin Surface Mount (SM3) FP5155PM, 4 Pin Flatpack (FP4)

BX5155PM, Connectorized Housing (H1)

#### **Features**

Legend

- High 3rd Order Intercept: +37 dBm Typical
- Meduim Gain: 15 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

Isolation (dB) VSWR In Out Noise figure (dB)	<1.75:1 Each "PM"	2.0:1 Ma option datasheet s phase noise
Power @ 1 dB Comp. (dBm) Reverse	>+22 -17	+21 Min.
Gain (dB)	5 - 300 MHz 15.0	5 - 300 MHz 15.0 ± 1.0 Min,
CHARACTERISTIC Frequency	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C

#### Typical Intermodulation Performance at 25 ° C

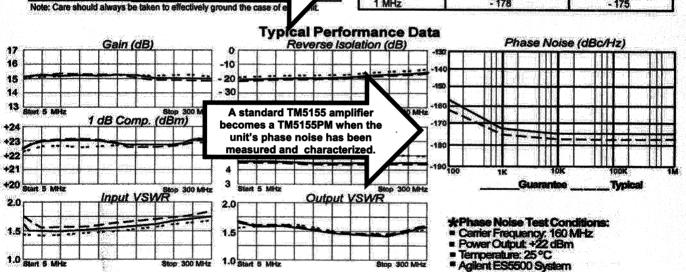
Second Order Harmonic Intercept Point +54	(Typ.)
Second Order Two Tone Intercept Point+48	(Typ.)
Third Order Two Tone Intercept Point	(Tvp.)

#### **Maximum Ratings**

	2 3 3 3 4 A A A A A A A A A A A A A A A A
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 mW (1 Minute Max.)
Maximum Peak Power	. 0.5 Watt (3 цвес Мах.)

#### Guaranteed Phase Noise Performance (dBc/Hz)\*

Frequency	Typical	Guarantee (min.)
100 Hz	-162	- 158
1 KHz	-175	-172
10 KHz	-178	- 175
100 KHz		-175
1 MHz		-175





+ 25 °C --- + 85 °C ---- -55 °C

2707 Black Lake Place, Philadelphia, PA 19154

TEL 215-464-4000 · · · · FAX 215-464-4001

03/11/03

# RF AMPLIFIER MODEL TM6509PM

TM6509PM 4 Pip TO-8 (T4)

If you are using the Avantek UTO-509, our TM6509PM offers Superior Phase Noise performance.

#### **Features**

- Superior Phase Noise Performance
- High Output Power: +23 dBm Typical
- High Dynamic Range: IP3 = +36 dBm Typ.
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

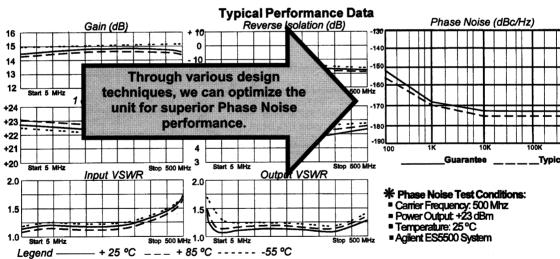
CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	14.5	13.0 Min.
Power @ 1 dB Comp. (dBm)	+23	+20 <b>M</b> in.
Reverse Isolation (dB)	- 18	- 15 Max.
VSWR In Out	<1.4:1 <1.2:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.6	6.0 Max.
Power Vdc mA	+15 88	+15 95 Max.

Note: Care should always be taken to effectively ground the case of each unit.

Intermodulation Performan	ce at 25 °	C
Secon Order Harmonic Intercept Point	+ <b>5</b> 6	(Typ.)
Second Order Two Tone Intercept Point	+50	(Typ.)
Third Order Two Tone Intercept Point	1 <b>3</b> 6	(Typ.)
Maximum Ratings		
Ambient Operating Temperature	55°C to +	100 °C
Storage Temperature	62°C to +	· 125 ℃
Case Temperature	+	125 °C
DC Voltage	+ '	13 Volts
Continuous RF Input Power	+	13 dBm
Short Term RF Input Power 50 n	nW (1 Minut	te Max.)
Maximum Peak Power 0.5	Watt (3 µse	c Max.)

#### Guaranteed Phase Noise Performance (dBc/Hz) \*

Frequency	Typical	Guarantee (min.)
100 Hz	-156	-152
1 KHz	-170	-168
10 KHz	-175	-172
100 KHz	-175	-172
1 MHz	-175	-172



#### Linear S-Parameters

FREQ.	S1L		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.23	-41	5.86	-163	.08	19	.27	86
100	.13	80	5.46	159	.11	3	.05	23
200	.40	24	5.51	137	.12	3	.04	23
300	.58	-31	5.50	114	.14	2	.04	45
400	.10	<del>-9</del> 1	5.53	90	.15	-1	.08	71
500	.20	-137	5.45	64	.17	-9	.17	66



2707 Black Lake Place, Philadelphia, PA 19154

TEL 215-464-4000 · · · · FAX 215-464-4001

03/11/03

### RF AMPLIFIER MODEL TM5125PM

TM5125PM, 4 Pin TO-8 (T4) Available as:

TN5125PM, 4 Pin Surface Mount (SM3) BX5125PM, Connectorized Housing (H1)

#### **Features**

- High Gain: 20.5 dB Typical
- High Power: +24 dBm Typical
- Low Noise: 2.0 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 125 MHz	10 - 100 MHz		
Gain (dB)	20.5	19.5 Min./21 Max.		
Power @ 1 dB Comp. (dBm)	+24.0	+22.5 Min.		
Reverse Isolation (dB)	-24	-23 Mex.		
VSWR In	1.7:1 1.35:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	2.0	3.0 Max.		
Power Vdc mA	+15 80	+15 90 Max.		

Note: Care should always be taken to effectively ground the case of each unit.

### Typical Intermodulation Performance at 25 ° C

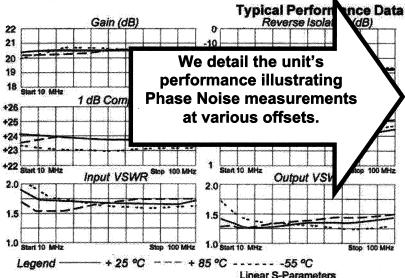
Second Order Harmonic Intercept Point +58	(Typ.)
Second Order Two Tone Intercept Point +52	(Tvn )
	/T.m.\

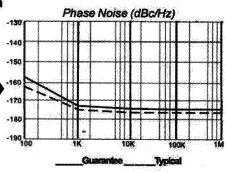
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100°C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
	60 mW (1 Minute Max.)
- 120 Mai - 120	0.5 Watt (3 usec Max.)

#### Guaranteed Phase Noise Performance (dBc/Hz) \*

Frequency	Typical	Guarantee (min.)
100 Hz	- 162	-168
1 KHz	- 175	3172
10 KHz	=1/0	374
100 KHz	- 176	and 2002 (7) (1000 1000 1000 1000 1000 1000 1000 10
1 MHz	-176	





#### **★Phase Noise Test Conditions:**

- Carrier Frequency: 80 mHz
   Power Output: +24 dBm
- Temperature: 25 °C
  Agilent ES5500 System

FREQ.		821	S12	822
Mtz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	00 00 01	9.94 -151.50	.05 -151.80	26 -19.89
10	29 -26.29	10.56 -168.32	.05 -172.06	15 -23.55
20	ACO: "ACO.OO"	10.79 176.24	.05 169,91	.12 8.61
20 50 75	.25 -25.12	10.79 162.45	.05 154.52	.17 18.79
75	.KU ~3%.UG	10.69 150.84	.06 139.83	.20 15.63
100	.27 -46.93	10.52 140.02	.06 126.88	.22 8.47



2707 Black Lake Place, Philadelphia, PA 19154

TEL 215-464-4000 \* \* \* \* FAX 215-464-4001

03/11/03

# RF AMPLIFIER MODEL TM5152PM

Available as: TM5152PM, 4 Pin TO-8 (T4)

TN5152PM, 4 Pin Surface Mount (SM3) FP5152PM, 4 Pin Flatpack (FP4) BX5152PM, Connectorized Housing (H1)

PC PC IS

lm

#### **Features**



■ Operating Temp. - 55 °C to +85 °C ■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 300 MHz	10 - 300 MHz
Gain (dB)	17.0	16.0 Min.
Power @ 1 dB Comp. (dBm)	+20	+17.5 Min.
Reverse Isolation (dB)	- 20	- 19 <b>Ma</b> x.
VSWR In Out	<1.75:1 < 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	3.8 Max.
Power Vdc mA	+15 55	+15 60 Max.

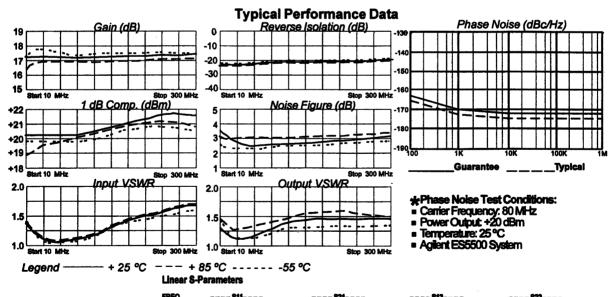
Note: Care should always be taken to effectively ground the case of each unit.

#### 

### Our unit is optimized for Low Phase Noise. Other competitor's units are not!

Guaranteed Phase Noise Performance (dBc/Hz) \*

Frequency	Typical	Guarantee (min.)
100 Hz	- 166	- 164
1 KHz	- 172	- 170
10 KHz	- 174	- 172
100 KHz	- 174	- 172
1 MHz	- 174	- 172







2707 Black Lake Place, Philadelphia, PA 19154

TEL 215-464-4000 · · · · FAX 215-464-4001

#### Even if you are Available as: TN RF AMPLIFIER TN using an (SM3) **Amplifonix** MODEL TM5138PM ВХ ng (H1) custom part, we e Mount (SM11) can optimize it **Features** at 25 ° C Typical Inter for Superior **■ Superior Phase Noise** Second Order +52 (Typ.) **Phase Noise** ■ High Output Power: +24.5 dBm Typical +46 (Typ.) Second Order Low Noise Figure: 2.7 dB Typical Performance Third Order Tw ... +38 (Typ.) ■ Environmental Screening Available Maximum R without changing **Ambient Opera** 5°C to + 100 °C any of the part's **Specifications** 2°C to + 125°C Storage Temp crititcal CHARACTERISTIC **TYPICAL** MIN/MAX . + 125 ℃ Case Tempera Ta = -55 °C to +85 °C Ta= 25 °C parameters. Frequency 5 - 150 MHz 5 - 150 MHz Continue 8 dBm Gain (dB) 14 15 Min. Minute Max.) Short Term R Power @ 1 dB Maximum Peak P Vatt (3 µsec Max.) +24.5 +22.0 Min. Comp. (dBm) **Guaranteed Phase No.** erformance (dBc/Hz) \* Reverse - 20 - 19 Max. Isolation (dB) Guarantee (min.) **VSWR** 2.0:1 Max. <1.75:1 <1.5:1 Typical Frequency 2.0:1 Max. -158 100 Hz -154

1 KHz

10 KHz

100 KHz

1 MHz

-163

-176

-176

-176

2707 Black Lake Place, Philadelphia, PA 19154
TEL 215-464-4000 · · · · FAX 215-464-4001

-160

-174

-174

-174

Noise figure (dB)

Vdc

mA

Power

2.7

+15

**Amplifonix** 

Note: Care should always be taken to effectively ground the case of each unit.

3.5

+15

95

Max.

Max.

**Typical Performance Data** Phase Noise (dBc/Hz) Reverse Isolation (dB) Gain (dB) 17 16 - 10 15 - 20 -150 - 30 14 1 dB Comp. (dBm) 150 MHz Noise Figure (dB) +27 -170 3 -190 L 2 +23 Guarantee Typical Input VSWR Stop Output VSWR 2.0 2.0 \*Phase Noise Test Conditions: Carrier Frequency: 80 MHz Power Output: 24.5 dBm 1.5 1.5 Temperature: 25 °C
Agilent ES5500 System 1.0 Start 5 MHz Stop 150 MHz Legend + 25 ℃ - + 85 °C ------55 °C -S12--Deg -822---Deg - S21---Deg Mag Mag . Deg - 47 - 98 -124 -146 -167 172 50 50 75 100 125 150 -163 168 151 135 119 104 89 .09 .10 .10 .09 .09 -170 168 151 135 120 105 .13 .07 .09 .11 .12 .22 .11 .15 .19 .23 .25 - 92 -116 -120 -125 -130 -135

### **Application Notes**

### **Definitions**

### Gain

Gain is the ratio of the power output to the power input of the amplifier in dB. The gain is specified in the linear operating range of the amplifier where a 1 dB increase in input power gives rise to a 1 dB increase in output power. Gain =  $20 \log(S_{21})$ 

### **Noise Figure / Noise Factor**

The Noise Factor of a transducer at a specified input frequency is the ratio of (a/b) where "a and b" are;

- (a) the available Signal to Noise Ratio (SNR) at the signal generator terminals per unit bandwidth when the temperature of the input termination (generator or source) is 290°K and the bandwidth is limited by the transducer.
- (b) the available SNR per unit bandwidth at the output terminals of the transducer.

Traditionally:

Noise Figure NF = 10 log(noise factor F)

Noise Temperature = To(F - 1)

Where:

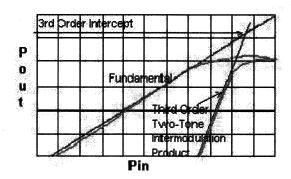
Te is the noise temperature

To is standard temperature 290°K

F is noise factor

### Third Order Intercept

The third order intercept is the intercept point formed by the intersection of the fundamental output and the two-tone third order distortion product, when plotted as a theoretical linear function of input power. The higher the Third Order Intercept, the lower the intermods for the incoming signals.



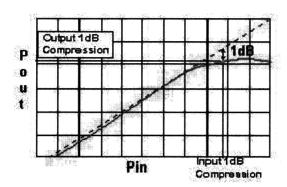
### **Conversion Loss**

The ratio in dB of the IF output of a mixer to the rf input power. All conversion loss measurements and specifications are normally based on the mixer being terminated on all ports and a stated LO signal power level being applied.

### **Application Notes** (continued)

### **1 dB Compression Point**

The 1 dB compression point is the point on a Pout vs. Pin graph, where an increase in input power causes the measured gain to decrease from the linear gain by one dB. Typical, if not explicitly stated, the 1 dB compression point refers to the output power (Pout) at that point.



### **Dynamic Range**

The range, from the minimum, which is at a level 3 dB above the amplifier's internally generated floor, to a maximum input signal level that a component can accept and amplify without distortion.

Dynamic Range = P1dB - Pmds

Where: Pmds = Minimum detectable signal 3 dB above the noise floor.

### **Spurious Free Dynamic Range**

Spurious Free Dynamic Range = 2/3 (Ptoi - Gain - Pmds)

Where:

P1dB = 1 dB Output Compression Point

Ptoi= Third Order Intercept

Pmds = Minimum detectable signal 3 dB above the noise floor.

### **Eutectic Bonding**

The term for properties of an alloy that have the lowest melting point. In eutectic bonding, the ingredient involved goes from completely molten to solid without going through a slushy phase at the eutectic composition. Eutectic bonding also provides superior heat transfer for active devices.

#### **Pulling**

The difference between the maximum and minimum frequency of a VCO when the phase angle of the load reflection coefficient varies through 360 degrees, expressed in MHz, peak to peak.

### **Pushing**

The change in frequency when the supply voltage changes, expressed in MHz/V.

### **Application Notes** (continued)

#### Isolation

The ratio (expressed in dB) of the power level at one port compared to the resulting power level at another port.

### **Limiting Level**

This is the input power level when the output power goes into compression resulting in a non-linear relationship between Pout and Pin.

#### **Noise Floor**

This is defined as the lowest possible input to a chain or a component, that will produce a detectable output.

### **Noise Temperature**

This is the amount of thermal noise in a chain or a component. Noise Factor and Noise Temperature (Te) are related as follows;

Noise Temperature (Te) = (F - 1)To

Where:

Te is the noise temperature

To is standard temperature 290°K

F is noise factor

For example, a noise figure of 2.0 dB is equivalent to a Noise Temperature of 170 degrees.

#### Pin Diode

A diode where a thin layer exists between the N and P regions. Rectification with pin diodes is limited at RF frequencies, they actually behave more like a variable resistor that changes based upon the DC bias current.

### **Scattering Parameters**

Better known as S-Parameters, these 4 values help define the performance of several variables at various frequencies.



S11 (Input Reflection Coefficient ) = b1/a1

S12 (Isolation) = b1/a2

S21 (Forward Transfer Coefficient or Gain /Loss) = b2/a1

S22 (Output Reflection Coefficient) = b2/a2

### **Application Notes** (continued)

#### Loss



Insertion Loss (dB) is defined as the drop in power as a signal traverses an RF component. This value not only includes the reflected incoming signal, but also the attenuation of the component.

Return Loss (dB) is defined as a ratio of the incoming signal to the same reflected signal as it enters a component.

### **VSWR**

Voltage Standing Wave Ratio simply put is the ratio of the maximum to the minimum voltage of a standing wave (which is the instantaneous sum of incident and reflected waves). Ideal is a figure of 1:1 which means that 100% of the incoming signal passed through the component without any reflection. In that case, there would be no "standing wave". A 2:1 VSWR (or mismatch) means that 12% of the incoming signal was reflected.

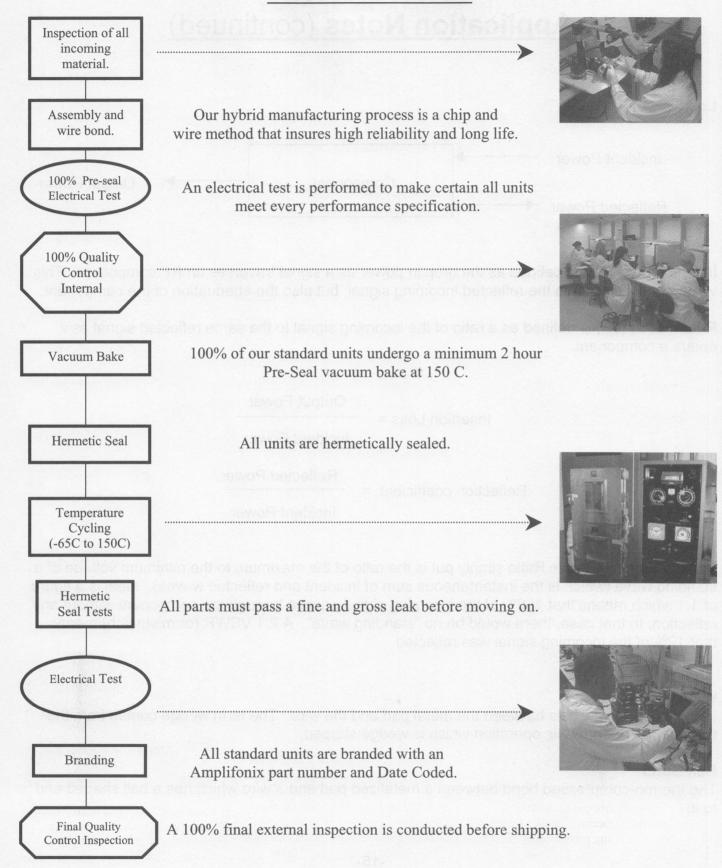
#### **Wedge Bond**

It is the bond that exists between the metal pad and the wire. The term wedge comes from the tool used to perform this operation which is wedge shaped.

#### **Ball Bond**

The thermo-compressed bond between a metalized pad and a wire which has a ball shaped end to it.

### **Production Process**



### **Quality Standards and Screening**

Amplifonix is an ISO 9000 certified company. Amplifonix has the capability to supply units that conform to MIL-PRF-38534 Class H. All screening is performed on site, including Groups A, B C and D.

### **Environmental Screening**

Test	Mil STD 883 Method	<b>Test Conditions/Limits</b>
Internal Visual	2017	_
Stabilization Bake	1008	24 hours @ 150 C
Temperature Cycle	1010	-65 C to 150 C
Constant Acceleration	2001	5000 G y1
Hermetic Seal	1014	A and C
Burn In	1015	168 Hours @85 C
External Visual	2009	

Amplifonix also conducts testing for qualification and high reliability programs per the test methods of Mil-STD-883 and Mil-STD-202 as shown below.

TEST	MIL-STD	Test Method
Thermal Shock	202	107
Mechanical Shock	202	213
Random Vibration	202	214
Sinusoidal Vibration	202	204
External Visual	202	2009
Internal Visual	883	2017
Steady State life	883	1005
Die Shear Strength	883	2019



Amplifonix conducts a 100% internal inspection on all products during production.

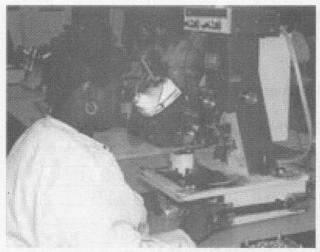


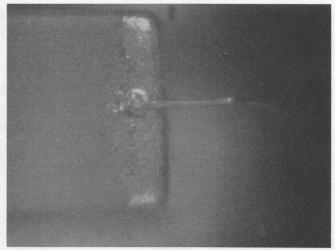
Our quality inspection team inspects all finished products to make certain that the part you ordered is the exact part you ordered. No exceptions.



Each member of our quality team takes pride in their work. Our mission statement is not just a slogan, it's how we work, everyday.

### **Quality Standards and Screening**





In our hybrid manufacturing process, we incorporate a unique "double ball" bonding process that utilizes an additional ball bond on top of the original bond, insuring the highest reliability.

### Other steps we incorporate in our manufacturing process include;



100% Internal Visual Inspection



100% Temperature cycling from -65 to +150 C for 2.5 hours



**Lead Integrity Testing** 



100% Final Electrical Testing

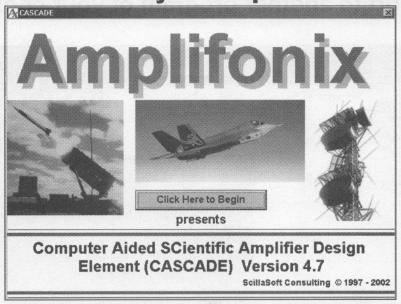


100% Fine and Gross Leak Testing

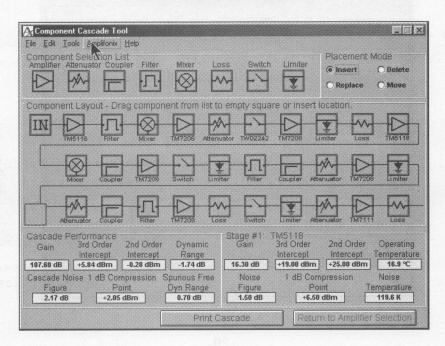


100% Pre-seal Electrical Testing

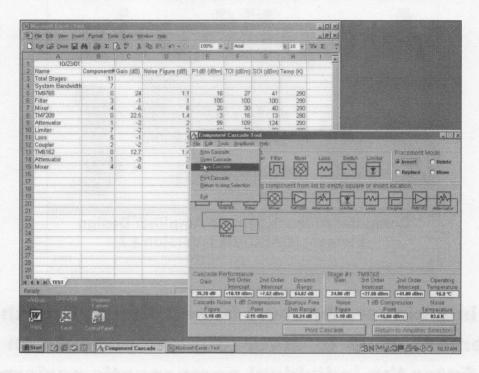
A <u>FREE</u> software tool that a Design Engineer can use to analyze component chains.



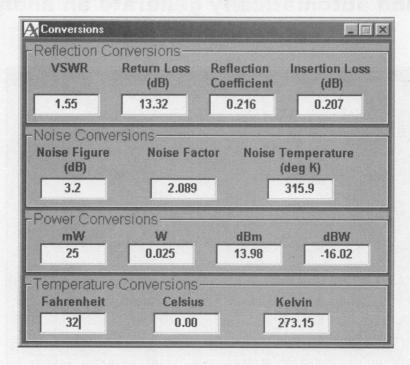
Cascade is a clever Windows based design tool that allows the placement of up to thirty (30) components on a layout area. Enter the individual component's performance parameters and automatically generate an analysis for your cascaded chain.



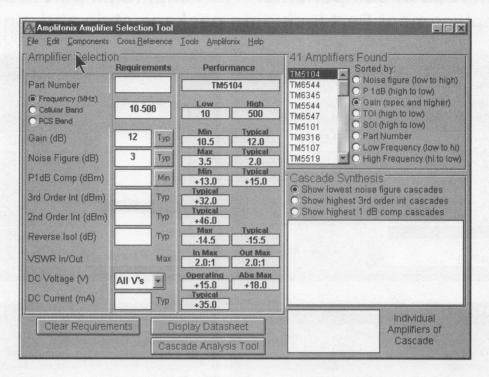
Cascade may even be saved as a spreadsheet file in order to export to another program of your choice.



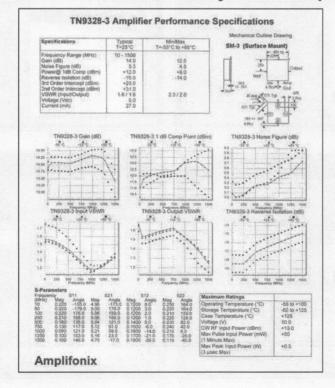
Cascade even includes a handy RF Conversion Calculator.



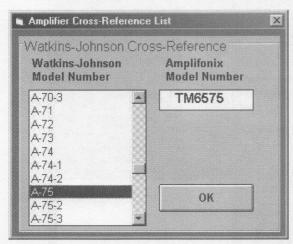
In addition to analyzing component chains, Cascade is also a useful search engine for the entire Amplifonix product line. Simply enter the parameters of interest and select the part that best first your parameters.

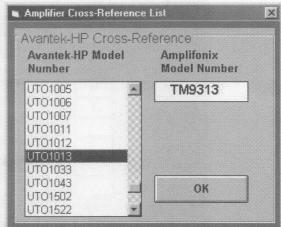


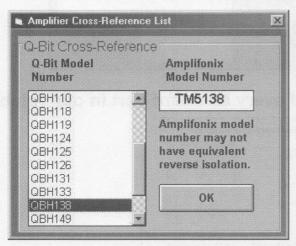
You may even print out a datasheet of every standard part in our database.

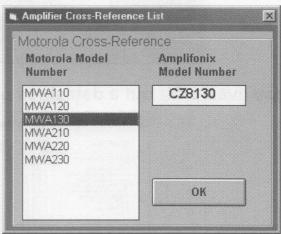


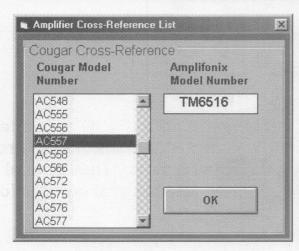
Cascade also offers a handy Direct Replacement guide. This search engine allows you to choose from many other manufacturers and hundreds of components. The Amplifonix part is a Direct Replacement Part including package style and pin-outs.

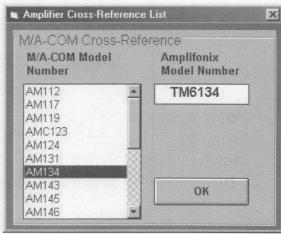






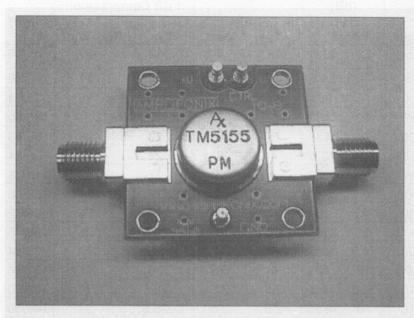


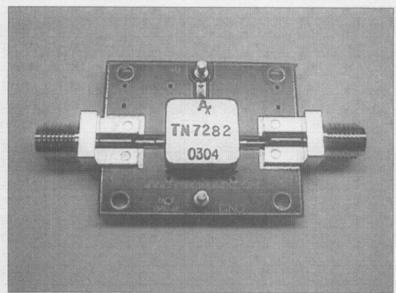




### **Component Evaluation Boards**

Amplifonix offers evaluation boards with Edge Mount SMA Connectors in order to make testing easier on most of our RF components. These boards are available in three styles; TO-8, TO-8B and Surface Mount (.450" Sq.).





These boards can be used with Amplifonix Amplifiers, VCO's, Limiters, Limiting Amplifiers, Detectors and Voltage Variable Attenuators. In order to prevent thermal runaway, we incorporate heat sink rails. These metal rails should be "properly secured" to insure adequate thermal conduction.

## **Higher Power Amplifiers**

This list contains those Higher Power Amplifiers for use where typical output power must be greater than +20 dBm. Models come in standard T0-8 cans ("TM"), TO-8B ("TR"), Surface Mount ("TN or RN"), Flatpack (FP) and SMA Connectorized Housings ("BX").

	Г							<del>                                     </del>				
Model	Ra	uency inge IHz)	(d	ain  B) yp.		ise B)		t Power @ ompression	IP3/IP2 (dBm)	VSWR		Supply
	Low	High		in.	Typ.	Max.	Typ.	(dBm) Min.	Тур.		(DC)	(mA)
BXMP1003	5	35	22	21.5	3.7	4	32	31	+49/56	1.5:1	24	425
BXMP1003	0.5	35	22	21.5	3.7	4	32	31	+49/56	1.5:1	24	425
FPMP1002	10	100	10	8.5	5.5	6	30.5	30	+45/54	2.0:1	15	320
TM3035	80	120	16	15	<3.0	5	28.5	27	+45/50	2.0:1	11	200
TM3072	10	200	14	13	5	6	28	26	+45/60	2.0:1	15	185
TM3040	10	250	14.5	13.5	4	6	27	26	+39/54	2.0:1	15	110
TM9723	10	1000	13	12	4	8	27	26	+40/48	2.0:1	15	185
TM9709	10	2000	10.5	8.5	4.5	6	27	26	+39/48	2.0:1	. 15	180
TM6203	5	500	14.5	13	4	7.5	26.5	25	+36/42	2.0:1	15	125
TM9725	500	2000	11	10	6.5	88	26.5	25	+38/45	2.0:1	15	190
TM6134	20	200	14.3	12.5	4	6	26	23	+39/54	2.5:1	15	90
TM9730	1400	2400	12	10	4	5.5	26	25	+37/46	2.5:1	15	150
TM7194	30	110	20.5	19.8	2.5	3.5	25.5	24	+40/50	2.0:1	15	102
TM3036	25	110	20	19.75	2.5	3.5	25.5	24	+40/50	2.0:1	15	102
TM3020	500	1000	20.5	19	<2.5	3	25	23	+32/42	2.0:1	12	255
TM5338	5	150	15	14	2.7	3.5	25	23	+36/44	2.0:1	12	88
TM6518	5	500	14	12.5	5.2	6.5	25	22.5	+33/40	2.0:1	15	125
TM9715	500	2000	11	10	4.5	. 6	25	24	+40/49	2.3:1	12	180
TM5138	5	150	15	14	2.7	3.5	24.5	22	+38/46	2.0:1	15	88
TM5125	10	100	20.5	19.5	2	3	24	22.5	+40/52	2.2:1	15	80
TM3028	40	100	20.5	19.5	2.2	3	24	23	+38/51	2.0:1	15	82
TM5325	10	100	20.5	19.5	2	3	24	22.5	+40/52	2.2:1	12	85
TM7277	5	250	10.5	9.5	4 .	5	24	20	+41/48	2.0:1	15	70
TM6507	10	500	15.5	14	4	6	24	20	+35/40	2.0:1	15	110
TR9737	100	2000	9.5	8	4.5	6.5	24	22	+38/49	2.0:1	15	140
TM9139	10	2000	8	6	8	9.5	24	22	+35/42	2.0:1	15	90
TM7379	5	200	14	12.5	4.5	6	23	21	+38/47	2.0:1	12	88
TM7370	20	250	8.5	7.3	1.9	3.4	23	20	+40/49	2.0:1	15	45
TM6119	30	250	8	6.5	3	3.5	23	20	+36/45		15	43
TM7279	5	250	14	12.5	4.5	66	23	21	+36/46		15	88
TM5103	5	300	11.5	10	5	6.5	23	21	+36/45	2.0:1	15	85
TM6509	5	500	14.5	13	4.6	6	23	20	+36/50	2.0:1	15	88
TM9705	225	400	15	14	1.5	2	23	22	+34/44	2.0:1	15	90
TM5817	10	1500	14	13	6	7	23	20	+32/44	2.0:1	15	98
TM5137	10	200	12.7	12.2	3.5	4.2	22.5	20.5	+39/53		15	75
TM3033	30	1000	11.5	10	<4.0	6	22	20.5	+36/45		15	90
TM3039	100	220	18	17.5	2.5	3.5	22	19	+38/46	2.0:1	12	80

Datasheets are listed in numerical order starting on page 46.

## **Higher Power Amplifiers**

This list contains those higher power amplifiers for use where output power must be greater than +20 dBm. Models come in standard T0-8 cans ("TM"), TO-8B ("TR"), Surface Mount ("TN or RN"), and SMA Connectorized Housings ("BX").

Madal	Frequency Gain Range (dB)		(d	B)	(d	•	1 dB Com	Power @	IP3/IP2 (dBm)	VSWR		Supply
Model	Low	High	Тур.	Min.	Тур.	Max.		IBm) Min.	Тур.		(DC)	(mA)
TM6212	10	1300	10	8.5	6	8.5	22.5	19.5	+34/42	2.0:1	15	92
TM5136	10	200	20	19	3	4	22	20	+36/46	2.0:1	15	67
TM5155	5	300	15	14	5	6	22	21	+37/48	2.0:1	15	85
TR6535	10	400	32.5	30	1.8	3	22	20	+37/48	2.5:1	15	90
TM6442	20	400	14	12.5	4.5	6	22	19	+37/51	2.0:1	15	62
TR6589	5	500	26.5	25	3.7	5	22	20	+35/55	2.0:1	15	130
TM5102	5	500	12.5	11	5.5	7	22	20	+36/46	2.0:1	15	88
TM6609	5	500	11.5	10	5.5	7	22	20	+36/46	2.0:1	24	88
TM6157	20	500	13	0.5	7.5	8.5	22	18	+33/45	2.0:1	15	75
TM6659	10	700	10.5	9	6.5	8	22	20	+36/46	2.0:1	15	88
TM9319	10	1000	11.5	10	5.5	7.5	22	20	+35/46	2.0:1	15	90
TM9713	500	2000	11	8.5	4.5	6	22	18	+34/44	2.0:1	15	120
TZ9213	5	200	14.5	13	6.8	7.5	22	21	+17/22	2.0:1	15	95
TM7278	5	300	13.5	12.5	4	5.5	21.5	19	+36/49	2.0:1	15	65
TM6191	100	600	23.5	22	2.5	4	21.5	20	+36/52	2.0:1	15	95
TM9740	2000	2500	11	10	4	5.5	21.5	20	+39/51	1.75:1	15	98
TM7282	20	250	23.5	21	4	5	21	18	+34/38	2.3:1	15	45
TM6588	5	450	18.5	17.5	4.5	7	21	19	+35/44	2.0:1	15	80
TM6526	10	500	28	26	3.5	4	21	18.5	+35/50	2.0:1	15	93
TM6582	30	500	23	21.5	3.5	4.5	21	17	+33/43	2.0:1	15	47
TR9604	30	500	23	21	5	6	21	19	+33/40	2.0:1	15	125
TR9169	10	1000	25.5	24	4	5.5	21	19	+33/48	2.0:1	15	125
TM9105	50	1000	11	10.5	4.5	6.5	21	19	+35/45	2.0:1	15	90
TM9119	10	1000	9	7	8.5	11	21	19	+34/40	2.0:1	15	100
TZ9214	5	200	14	12.5	6.5	7.5	21	20	+34/44	2.0:1	- 15	95
CZ8205	5	200	13.5	12	6	7	21	19	+25/30	2.5:1	15	95
TM7222	20	200	29	27.5	2.9	4	20.5	18	+32/38	2.0:1	15	47
TM6545	10	500	11.5	10	4	5.5	20.5	18	+36/48	2.0:1	15	60
TM9129	10	1500	8	6	8	9.5	20.5	19	+34/42	2.0:1	15	95
CZ8405	5	400	16	14.5	5.5	7	20.5	16	+32/35	2.0:1	15	90
TM7211	30	200	8.5	7.5	1.8	3	20	19	+40/55	2.0:1	15	40
TM5124	20	200	20.5	19.5	2.5	3.5	20	18	+34/44	1.6:1	15	53
TM6121	20	200	10	9.4	2.5	4	20	18	+38/55	2.0:1	15	60
TM6670	10	250	8	6	1.8	3	20	18	+36/46	2.5:1	15	25
TM5152	10	300	17	16	3.5	3.8	20	17.5	+33/47	2.0:1	15	55
TR7217	10	400	25.5	24	2.5	3	20	18	+33/44	2.0:1	15	65
TR7216	10	500	25.5	24	2.5	3	20	18	+33/44	2.0:1	12	65

# **Low Noise Amplifiers**

Low Noise Amplifiers are those where the noise figure is no greater than 4 dB (maximum). All amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and Connectorized Housings "BX".

Model	Frequ	ency	Ga		Noi		Outpu	t Power @	IP3/IP2		Power	Supply
	Ran		/all	<b>-</b> \	(d)	٥١	1 dB C	ompression	(dBm)		т,	/p.
	(MF Low	High	(dl Typ.	Min.	(dl Typ.	Max.	Тур.	(dBm) Min.	Typ.	Max.	(DC)	(mA)
TR9771	1200	1700	27	25	<1.0	1.75	14	13	+26/40	2.0:1	15	60
TR9770	1200	1700	27	25	<1.0	1.75	15	14	+26/40	2.0:1	+5	60
TR9770	800	1200	25	25	11	1.75	14	13	+25/40	2.0:1	15	62
TR9770	800	1200	26	24	1	1.75	14	13	+25/40	2.0:1	+5	62
TM7210	10	200	9	8	1.3	2	14	12.5	+31/48	2.0:1	15	15
TM6117	5	250	8.2	7	1.3	2	10	9	+28/43	2.0:1	15	12
TM6162	10	100	12.7	11.5	1.4	2	16	14	+32/46	2.0:1	15	11
TM7111	10	100	12.5	11	1.4	2	17	15.5	+33/47	2.0:1	15	14
TM7208	5	250	22.5	21	1.4	2	3	0	+16/13	2.0:1	15	10
TM7270	10	250	8.3	7	1.4	2.5	13	11	+30/50	1.8:1	15	15
TR9772	1700	1200	23	22	1.5	2.2	15	14	+26/40	2.0:1	15	65
TR9757	1700	1200	23	22	1.5	2.2	15	14	+26/40	2.0:1	+5	60
TM5118	3	100	16.3	15.5	1.5	2	6.5	5.5	+19/25	2.5:1	15	21
TM6118	10	200	10	9.4	1.5	2	18	16.5	+33/55	2.0:1	15	18
TM7271	5	250	18	16	1.5	2.8	0.5	-1	+13/13	2.0:1	15	9
TM7170	10	250	8.5	7.5	1.5	2.5	10	9	+26/38	2.0:1	15	12
TM9705	225	400	15	14	1.5	2	23	22	+34/44	2.0:1	15	90
TM7205	10	200	20	19	1.6	2.2	14	12	+21/26	2.0:1	+5	18
TM6143	5	500	15.7	14.5	1.6	2.5	7.5	5	+20/28	2.5:1	15	15
TM6181	10	400	8.5	7.5	1.7	2.5	8	7	+23/40	2.0:1	15	11
TM6719	5	500	33	31	1.7	2	9	8	+20/36	2.0:1	15	35
TM5107	10	550	15	14	1.75	2.3	2	1	+13/16	2.0:1	15	9
TM7101	10	150	27.5	26	1.8	2.5	16.5	15	+30/35	2.0:1	15	20
TM7211	30	200	8.5	7.5	1.8	3	20	19	+40/55	2.0:1	15	40
TM7371	5	250	18	16	1.8	2.5	2	1	+14/15	2.0:1	15	9
TM7288	5	250	22	21	1.8	2.2	7.5	6.5	+20/23	2.0:1	15	18
TM6670	10	250	8	6	1.8	3	20	18	+36/46	2.5:1	15	25
TR6535	10	400	32.5	30	1.8	3	22	20	+37/48		15	90
TM7104	5	150	24	22.5	1.9	2.5	12	10.5	+25/31	+	+5	20
TM7370	20	250	8.5	7.3	1.9	3.4	23	20	+40/49	2.0:1	15	45
TM3037	1030	1090	13.5	13	<2.0	2.3	19.5	19	+31/45	T	+5	78
TM5125	10	100	20.5	19.5	2	3	24	22.5	+40/52	<del> </del>	15	80
TM5325	10	100	20.5	19.5	2	3	24	22.5	+40/52	<del></del>	12	85
TM7102	20	150	24.5	22.5	2	3	17	16	+29/40	·	15	31
TM6514		200	16.5	15	2	3	-2	-3	+11/11		15	8
TM7221	20	200	28.5	27	2	3	18.5		+33/38	<del>                                     </del>	15	29
TM6683		250	34	32.5	2	3	-1	-3	+10/9	2.0:1	5	14
TM5670	20	250	8.2	7	2	3	15.5	13.5	+28/33	2.0:1	5	25

# **Low Noise Amplifiers**

Low Noise Amplifiers are those where the noise figure is no greater than 4 dB (maximum). All amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and Connectorized Housings "BX".

Model		uency nge	Ga	in	Noi	se	Output P 1 dB Com		IP3/IP2	VSWR	Power Ty	
		Hz)	(dl	В)	(di	3)	l ub com	picaaion	(dBm)		, ,	φ.
-	Low	High	Тур.	Min.	Тур.	Max.	Typ. (dl	Bm) Min.	`Typ.´		(DC)	(mA)
TM3032	100	400	16.5	16	2	3	9.5	8	+22/29	2.0:1	15	16
TM7347	5	300	13.5	12.5	2	3	16	15	+32/44	1.7:1	15	45
TM7207	10	300	18	17	2	3	16	15	+31/42	2.0:1	15	33
TM6457	5	400	15	14	2	3	10	7.5	+24/35	2.0:1	+5	16
TM6210	5	500	15.3	14	2	3	7.5	4.5	+18/26	2.5:1	+5	12
TM5104	10	500	12	10.5	2	3.5	15	13	+32/46	2.0:1	15	35
TM6544	10	500	12	10.5	2	3	15	13	+32/46	2.0:1	15	35
TM3031	100	500	13.5	13	<2.2	2.5	8.5	7	+20/29	2.0:1	+3.3	20
TR3029	100	500	25.5	24	<2.2	2.5	16	 14	+27/41	2.0:1	15	45
TM7380	10	200	27.5	26	2.2	3	17	15	+31/35	2.0:1	15	28
TM7381	20	250	24.5	23	2.2	3	14.5	12.5	+27/32	2.0:1	15 15	18
TM3028	40	100	20.5	19.5	2.2	3	24					
								23	+38/51	2.0:1	15	82
TR6592	100	500	25.5	24	2.2	2.5	16	14	+27/41	2.0:1	15	45
TM9700	200	2000	12	10.5	2.2	4	19	18	+33/43	2.2:1	+6	65
TM9711	1000	2000	12	10	2.2	3	16	15	+29/35	2.0:1	6	62
CZ8451	5	250	17	15.5	2.2	3	2.5	0	+14/15	2.0:2	5	12.5
TM7103	10	150	26.5	25	2.3	2.8	9.5	8	+23/28	2.0:1	5	16
TM7481	10	300	28	27	2.3	3	16.5	15	+29/33	2.0:1	15	27
TM5519	5	500	15	14	2.3	3	14.5	11.5	+29/39	2.2:1	5	30
TM5119	5	500	15.5	14	2.3	3	16	14	+32/44	2.0:1	15	30
TM6171	5	500	15.2	14	2.3	3	0.5	-2	+12/15	2.0:1	15	11
TM6583	10	500	30	28	2.3	3	-1	-4	+10/13	2.0:1	5	13
TM6675	5	500	20.5	19	2.3	3	5	4	+18/21	2.0:1	15	15
TM9511	5	1000	16.5	15	2.3	3	1	-1	+14/16	2.0:1	15	9.5
TM9311	5	1000	16.5	15	2.3	3	2	-1	+14/17	2.0:1	15	10
TM7281	20	250	25.5	23	2.4	3.3	17.5	15.5	+31/35	2.0:1	15	30
TM6517	5	500	22.5	21	2.4	3	10	8	+22/26	2.0:1	15	22
TM9111	5	1000	15	14	2.4	4	1	-2	+12/15	2.0:1	15	9
TM9101	5	1000	15	14	2.4	4	1	-2	+12/15	2.0:1	15	9
TM7194	30	110	20.5	19.8	2.5	3.5	25.5	24	+40/50	2.0:1	15	102
TM7286	10	200	28	26	2.5	3.5	8	7	+20/28	2.0:1	5	21
TM5304	5	200	19.5	18.5	2.5	3	10.5	9.5	+25/33	2.0:1	15	24
TR7215	5	200	31.5	30	2.5	4	13	10	+26/39	1.5:1	15	58
TM5124	20	200	20.5	19.5	2.5	3.5	20	18	+34/44	1.6:1	15	53

Datasheets are listed in numerical order starting on page 46.

### **Low Noise Amplifiers**

This list contains those Low Noise Amplifiers for use where the noise figure (typical) is less than 3.0. Models come in standard T0-8 cans ("TM"), TO-8B ("TR"), Surface Mount ("TN" or "RN"), and SMA Connectorized Housings ("BX").

Model	Frequency Range		Frequency Gain Range		ain	Noi	se	•	t Power @ ompression	IP3/IP2	VSWR	Power	Supply
d,		Hz)	(d	B)	(di	3)			(dBm)		Тур.		
	Low	High	Typ.	Min.	Тур.	Max.	Тур.	(dBm) Min.	Тур.		(DC)	(mA)	
TM9143	10	1000	10.5	9	2.5	4.5	10	8	+27/38	2.0:1	15	25	
TM5138	5	150	15	14	2.7	3.5	24.5	22	+38/46	2.0:1	15	88	
TM5338	5	150	15	14	2.7	3.5	25	23	+36/44	2.0:1	12	88	
TM6121	20	200	10	9.4	2.5	4	20	18	+38/55	2.0:1	15	60	
TM7275	5	250	20.5	19	2.5	3.5	9.5	8	+22/27	2.0:1	15	24	
TM5150	10	300	20	19	2.5	3.5	18	17	+32/43	2.4:1	15	47	
TR7217	10	400	25.5	24	2.5	3	20	18	+33/44	2.0:1	15	65	
TM6674	5	500	28	26	2.5	4	-1	-2	+9/17	2.0:1	5	13	
TR3032	500	1000	20.5	19	<2.5	3	25	23	+32/42	2.0:1	12	255	
TM3039	100	220	18	17.5	2.5	3.5	18	17.7	+38/46	2.0:1	12	80	
TM6511	5	500	16.5	15.5	2.5	3	2	11	+14/16	2.0:1	15	10	
TM6573	5	500	32	29	2.5	3.5	2	-2.5	+14/19	2.0:1	15	20	
TM6501	5	500	16.5	15.5	2.5	3.5	3	1	+15/17	2.0:1	15	10	
TM6510	5	500	16.5	15.5	2.5	3.5	3	1	+15/17	2.0:1	15	10	
TM6512	5	500	21	19	2.5	3.5	10	8	+21/27	2.0:1	15	23	
TM3036	25	110	20.5	19.75	2.5	3.5	25.5	24	+40/50	2.0:1	15	102	
TM5110	10	500	15	14	2.5	3	10.5	9	+25/33	2.0:1	15	25	
TM6654	5	500	29	27.5	2.5	3	11	10	+23/33	2.0:1	+5	40	
TM6543	10	500	11	10	2.5	3	11	9	+24/35	2.0:1	15	25	
TM5544	10	500	12.5	11	2.5	3.5	14.5	11.5	+27/33	2.0:1	+5	35	
TM6570	10	500	8	7	2.5	3	17.5	17	+35/46	2.0:1	15	35	
TR7216	10	500	25.5	24	2.5	3	20	18	+33/44	2.0:1	12	65	

Visit our website at

www.amplifonix.com

for a list of our most recent

developments in

Low Noise Figure Amplifier designs.

### **Higher Gain Amplifiers**

Higher Gain Amplifiers are those amps whose gain is at least +20 dB. Amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and Connectorized Housings "BX".

	Frequency Range		Range (dB)		1	Noise (dB)		Power @ npression	IP3/IP2 (dBm)		Power	Supply
Model	Low	High	Тур.	Min.	Тур.	Max.	Typ. (c	dBm) Min.	Тур.	VSWR	(DC)	(mA)
TM6683	10	250	34	32.5	2	3	-1	-3	+10/13	2.0:1	5	14
TM6719	5	500	33	31	1.7	2	9	8	+20/36	2.0:1	15	35
TR7215	. 5	200	31.5	30	2.5	4	13	10	+26/39	1.5:1	15	58
TM7203	5	250	32	30	3	4	8	6.5	+18/30	2.0:1	15	35
TR6535	10	400	32.5	30	1.8	3	22	20	+37/48	2.5:1	15	90
TZ9212	0.1	200	31.5	30	3.5	4	7	5	+17/33	2.0:1	15	35
TZ9203	5	200	31.5	30	3.5	4	7.5	6	+19/35	2.0:1	15	35
CZ8201	5	200	32	30	3.2	4	5.8	3	+16/38	2.0:1	15	30
CZ8206	5	200	32	30	3.5	4	3.5	1	+15/26	2.0:1	12	30
TM7274	5	300	31	29	3	4	9.5	8	+21/32	2.0:1	15	40
TM6573	5	500	32	29	2.5	3.5	2	-2.5	+14/19	2.0:1	15	20
TM6524	5	500	31	29	3.5	4	15	14	+25/30	2.0:1	15	70
TZ9209	5	200	30.5	29	3.5	4	7	5	+18/28	2.0:1	12	36
LN7253	5	200	32	28	3	4	0	-2	+14/23	2.0:1	5	30
TM6583	10	500	30	28	2.3	3	-1	-4	+10/13	2.0:1	5	13
TM6521	5	500	30	28	3	4	9	7	+22/30	2.0:1	15	36
TM7222	20	200	29	27.5	2.9	4	20.5	18	+32/38	2.0:1	15	47
TM7201	5	250	29	27.5	5	6.5	7	5.5	+19/30	2.0:1	15	35
TM6654	5	500	29	27.5	2.5	3	11	10	+23/33	2.0:1	5	40
TZ9210	0.1	200	29	27.5	4.5	6	7	5	+19/33	2.0:1	15	35
TM7221	20	200	28.5	27	2	3	18.5	15	+33/38	2.0:1	15	29
TM7481	10	300	28	27	2.3	3	16.5	15	+29/33	2.0:1	15	27
TM6421	5	400	30	27	3.5	6	9	7	+22/36	2.0:1	15	37
TM6574	5	500	30	27	3.5	6	9	7	+22/36	2.0:1	15	37
CZ8202	5	200	29	27	5.5	6.5	11.5	9.5	+23/34	2.0:1	15	55
TM7101	10	150	27.5	26	1.8	2.5	16.5	15	+30/35	2.0:1	15	20
TM7380	10	200	27.5	26	2.2	3	17	15	+31/35	2.0:1	15	28
TM7286	10	200	28	26	2.5	3.5	8	7	+20/28	2.0:1	5	21
TM7202	5	250	27	26	5	6.5	16.5	15	+29/38	2.0:1	15	88
TM6674	5	500	28	26	2.5	4	1	-2	+9/17	2.0:1	5	13
TM6526	10	500	28	26	3.5	4	21	18.5	+35/50	2.0:1	15	93
TM6576	5	500	28	26	5	6	16	14	+30/52	2.0:1	15	64
TM9366	10	1000	27.5	25.5	4	5	15	13.5	+25/32	2.0:1	15	63
TR9771	1200	1700	27	25	<1.0	1.75	14	13	+26/40	2.0:1	15	60
TR9770	1200	1700	27	25	<1.0	1.75	15	14	+26/40	2.0:1	+5	60
TM7103	10	150	26.5	25	2.3	2.8	9.5	8	+23/28	2.0:1	5	16
TM6554	5	400	27.5	25	5	6	8	6	+19/32	2.0:1	15	33
TR6589	5	500	26.5	25	3.7	5	22	20	+35/55	2.0:1	15	130
TR9770	800	1200	25	25	1	1.75	14	13	+25/40	2.0:1	15	62
TR9770	800	1200	26	24	1	1.75	14	13	+25/40	2.0:1	+5	62

### **Higher Gain Amplifiers**

Higher Gain Amplifiers are those amps whose gain is at least +20 dB. Amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and SMA Connectorized Housings "BX".

	173			•	TAT	·	Output I	Power @	IP3/IP2	Power	Suppl	
	Range		Frequency Gain Range (dB)		Noise (dB)		Output F 1 dB Com	_	(dBm)		Power Ty	
Model	Low	nge High	Typ.	Min.	Typ.	Max.		Bm) Min.	(цып) Тур.	VSWR	(DC)	(mA)
TR9169	10	1000	25.5	24	4	5.5	21	19	+33/48	2.0:1	15	125
TR3029	100	500	25.5	24	<2.2	2.5	16	14	+27/41	2.0:1	15	45
CZ8251	5	200	26.5	24	4	4.5	3	-1	+14/27	2.0:1	5	30
TM7381	20	250	24.5	23	2.2	3	14.5	12.5	+27/32	2.0:1	15	18
TM7281	20	250	25.5	23	2.4	3.3	17.5	15.5	+31/35	2.0:1	15	30
TM6523	5	500	25.5	23	5.5	7	16	14	+26/35	2.0:1	15	75
TM7104	5	150	24	22.5	1.9	2.5	12	10.5	+25/31	2.0:1	5	20
TM7102	20	150	24.5	22.5	2	3	17	16	+29/40	2.0:1	15	31
TM5149	5	150	23.5	22.5	3	3.2	18	17	+33/37	2.0:1	15	35
TM6191	100	600	23.5	22	2.5	4	21.5	20	+36/52	2.0:1	15	95
TM9166	10	1200	23.5	22	4.5	5.5	15	13.5	+28/46	2.0:1	15	64
TR9772	1700	1200	23	22	1.5	2.2	15	14	+26/40	2.0:1	15	65
TR9757	1700	1200	23	22	1.5	2.2	15	14	+26/40	2.0:1	+5	60
TM6582	30	500	23	21.5	3.5	4.5	21	17	+33/43	2.0:1	15	47
TM7208	5	250	22.5	21	1.4	2	3	0	+16/13	2.0:1	15	10
TM3042	10	1200	23	21	3	4.5	19	18	+32/40	2.0:1	15	75
TM7288	5	250	22	21	1.8	2.2	7.5	6.5	+20/23	2.0:1	15	18
TM7282	20	250	23.5	21	4	5	21	18	+34/38	2.3:1	15	45
TM6517	5	500	22.5	21	2.4	3	10	8	+22/26	2.0:1	15	22
TM6581	20	500	22	21	3.5	4.5	16	13.5	+28/40	2.0:1	15	27
TR9604	30	500	23	21	5	6	21	19	+33/40	2.0:1	15	125
CZ8050	5	1000	22.5	20.5	6	7	10	6	+23/36	2.0:1	15	67
TM9524	10	1500	22	20	4.3	5	13	10	+ 3/31	2.2:1	15	56
CZ8052	5	1000	21.5	20	6	7	8	6	+20/39	2.0:1	15	60
CZ8653	5	250	22	20	3	3.2	5	2.5	+15/17	2.0:1	15	15

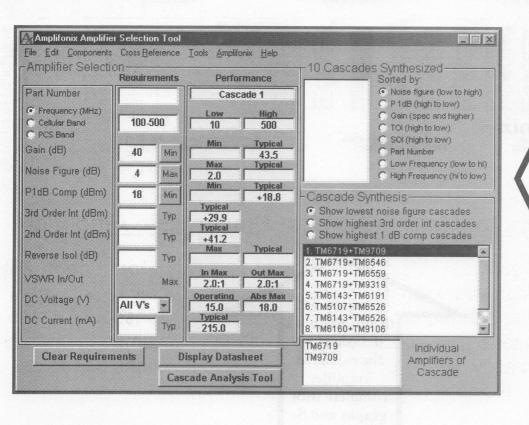
### Using Cascade to design your own Higher Gain Amplifier

Cascade, the free software design tool, available at **Amplifonix.com**, will allow you to design your own High Gain Amplifier. Simply type in the desired parameters, and the program will automatically "Cascade" all the amps in its database to give you a selection of the top 10 amps to choose from. It will even allow you to organize the top 10 selections based on Noise, Power or IP3 performance.



### Cascade to design you own Higher Gain Amps

Cascade will give you 10 selections from it's standard part database and offer you choices of how to sort them.

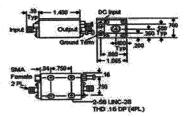


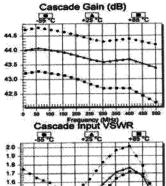
Cascade will allow you to build a cascaded high gain amplifier from our database of over 400 standard parts.

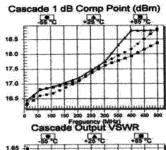
### TM6719+TM6659 Typical Performance

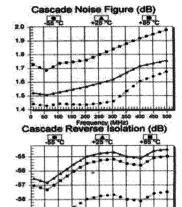
Mechanical Outline Drawing

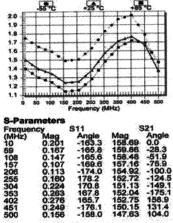
#### H3 Housing (Two Stages)











100 32 24 39			,	**********	,,,,,,,,,,,,		S	********		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,
1.65	·	<b></b>	ģ	<b>ķ</b>	<b></b>		ş	ļ		ģ.
		ت ا	<b></b>	į.,		1	1			1
1.00	~ *		~~		t	<u>*</u>	•	•		•
1.55	8 7					1	i	<b>.</b>	L	Ĺ
******		1	1		<b>X</b> *	L				١.,
1.50	£	<b></b>	į	<b></b>			<b></b>	<b>.</b>	<b></b>	
1,000				8	1		* :	}		7
1.45	£	<b>*</b>	ģ	ļ	ļ	4	****	<b></b>	·····	y-
1.40	₽.	1		ŧ .		1	1	1		
1.40	······	*****	*****	*	******	*****	****	•	7	•
1.36	€	1	l	i	L	1	1	D		L
			1			T			J	
1.30	£	£			line.	łm			S	
	****	فخخخ	ė inimi	90 S	<b>Section</b>	operation.	onnum		,,,,,,,	****
Mag 0.001 0.001 0.001 0.001 0.001 0.001	5 · 6 · 6 · 6 · 6 · 6 · 6 · 6 · 6 · 6 ·	Ang 120 100 170 130 29	1075	000000000	236 223 231 231 210 196 187 157		22 Ang -16 -16 -17 16 17 17 -17	3.2 4.8 5.4 3.7 9 1.5 1.2 1.4 0.5		Mi 0800000000000000000000000000000000000
0.001	) .	39. 41.	4	0.	172 216	2	-15 -14			M: (3

450 500 0 0 100 150 200 250 Frequence	300 320 400 450 500 y (MHz)
Maximum Ratings	
Operating Temperature (°C) Storage Temperature (°C) Case Temperature (°C)	-55 to +100 -62 to +125 +125
Voltage (V) CW RF Input Power (dBm)	18.0 +6.0
Max Pulse Input Power (mW)	+50

#### Amplifonix 2707 Black Lake Place Philadelphia, PA 19154

Phone: (215) 464-4000 FAX: (215) 464-4001 E-mail: info@amplifonix.com WWW: www.amplifonix.com

+0.5

Max Peak Input Power (W)

(3 µвес Мах)

Cascade wil then construct a datasheet on the cascaded amplifier complete with graphs and S-Parameters data.

### **Bi-Polar Amplifiers**

Bipolar Amplifiers are those designs which utilize bi-polar silicon transistors. Amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and Connectorized Housings "BX". Parts are listed from Low to High Frequency

	Ra	uency nge	Ga _ (dl	B)	No (d	B)	1 dB C	t Power @ ompression	IP3/IP2 (dBm)			ower Supply Typ.	
Model	Low	High	Тур.	Min.	Тур.	Max.	Тур.	(dBm) Min.	Тур.	VSWR	(DC)	(mA)	
TM6162	10	100	12.7	11.5	1.4	2	16	14	+32/46	2.0:1	15	11	
TM7111	10	100	12.5	11	1.4	2	17	15.5	+33/47	2.0:1	15	14	
TM5118	3	100	16.3	15.5	1.5	2	6.5	5.5	+19/25	2.5:1	15	21	
TM5125	10	100	20.5	19.5	2	3	24	22.5	+40/52	2.2:1	15	80	
TM5325	10	100	20.5	19.5	2	3	24	22.5	+40/52	2.2:1	12	85	
TM7194	30	110	20.5	19.8	2.5	3.5	25.5	24	+40/50	2.0:1	15	102	
TM5834	10	100	19.7	18.7	3.5	4.5	27.5	26	+40/52	2.0:1	15	135	
TM7101	10	150	27.5	26	1.8	2.5	16.5	15	+30/35	2.0:1	15	20	
TM7104	5	150	24	22.5	1.9	2.5	12	10.5	+25/31	2.0:1	5	20	
TM7102	20	150	24.5	22.5	2	3	17	16	+29/40	2.0:1	15	31	
TM7103	10	150	26.5	25	2.3	2.8	9.5	8	+23/28	2.0:1	5	16	
TM5138	5	150	15	14	2.7	3.5	24.5	22	+38/46	2.0:1	15	88	
TM5338	5	150	15	14	2.7	3.5	25	23	+36/44	2.0:1	12	88	
TM5149	5	150	23.5	22.5	3	3.2	18	17	+33/37	2.0:1	15	35	
LN7253	5	200	32	28	3	4	0	-2	+14/23	2.0:1	5	30	
TM7210	10	200	9	8	1.3	2	14	12.5	+31/48	2.0:1	15	15	
TM6118	10	200	10	9.4	1.5	2	18	16.5	+33/55	2.0:1	15	18	
TM7205	10	200	20	19	1.6	2.2	14	12	+21/26	2.0:1	5	18	
TM7211	30	200	8.5	7.5	1.8	3	20	19	+32/44	2.0:1	15	40	
TM6514	30	200	16.5	15	2	3	-2	-3	+11/11	2.0:1	15	8	
TM7221	20	200	28.5	27	2	3	18.5	15	+33/38	2.0:1	15	29	
TM7380	10	200	27.5	26	2.2	3	17	15	+31/35	2.0:1	15	28	
TM7286	10	200	28	26	2.5	3.5	8	7	+20/28	2.0:1	5	21	
TM5304	5	200	19.5	18.5	2.5	3	10.5	9.5	+25/33	2.0:1	15	24	
TR7215	5	200	31.5	30	2.5	4	13	10	+26/39	1.5:1	15	58	
TM5124	20	200	20.5	19.5	2.5	3.5	20	18	+34/44	1.6:1	15	53	
TM6121	20	200	10	9.4	2.5	4	20	18	+38/55	2.0:1	15	60	
TM7222	20	200	29	27.5	2.9	4	20.5	18	+32/38	2.0:1	15	47	
TM5136	10	200	20	19	3	4	22	20	+36/46	2.0:1	15	67	
TM7272	10	200	14.7	14	3	5	14	12	+29/41	1.3:1	5	35	
TM5137	10	200	12.7	12.2	3.5	4.2	22.5	20.5	+39/53	2.0:1	15	75	
TM6134	20	200	14.3	12.5	4	6	26	23	+39/54	2.5:1	15	90	
TM7379	5	200	14	12.5	4.5	6	23	21	+38/47	2.0:1	12	88	
TM6117	5	250	8.2	7	1.3	2	10	9	+28/43	2.0:1	15	12	
TM7208	5	250	22.5	21	1.4	2	3	0	+16/13	2.0:1	15	10	
TM7270	10	250	8.3	7	1.4	2.5	13	11	+30/50	1.8:1	15	15	
TM7271	5	250	18	16	1.5	2.8	0.5	-1	+13/13	2.0:1	15	9	
TM7170	10	250	8.5	7.5	1.5	2.5	10	9	+26/28	2.0:1	15	12	

### **Bipolar Amplifiers**

Bipolar Amplifiers are those designs which utilize bi-polar silicon transistors. All amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and Connectorized Housings "BX". Parts are listed from Low to High Frequency.

Frequency Model Range (MHz)		Gain (dB)		Noise (dB)		Output Po		IP3/IP2 (dBm)	L L		pply	
Model	Low	High	Tур.	Min.	Typ.	Max.	Typ. (dE		Typ.	VSWR	Typ.	mA)
TM7208	5	250	22.5	21.0	1.4	2.0	+ 3.0		+16/13	2.0:1	+15	10
TM7270	10	250	8.3	7.0	1.4	2.5	+13.0	+11.0	+30/50	1.8:1	+15	15
TM7271	5	250	18.0	16.0	1.5	2.8	+ 0.5	- 1.0	+13/13	2.0:1	+15	9
TM7170	10	250	8.5	7.5	1.5	2.5	+10.0	+ 9.0	+26/38	2.0:1	+15	12
TM7371	5	250	18.0	16.0	1.8	2.5	+ 2.0	+ 1.0	+14/15	2.0:1	+15	9
TM7288	5	250	22.0	21.0	1.8	2.2	+ 7.5	+ 6.5	+20/23	2.0:1	+15	18
TM6670	10	250	8.0	6.0	1.8	3.0	+20.0	+18.0	+36/46	2.5:1	+15	25
TM7370	20	250	8.5	7.3	1.9	3.4	+23.0	+20.0	+40/49	2.0:1	+15	45
TM6683	10	250	34.0	32.5	2.0	3.0	- 1.0	- 3.0	+10/9	2.0:1	+ 5	14
TM5670	20	250	8.2	7.0	2.0	3.0	+15.5	+13.5	+28/33	2.0:1	+ 5	25
TM7381	20	250	24.5	23.0	2.2	3.0	+14.5	+12.5	+27/32	2.0:1	+15	18
TM7281	20	250	25.5	23.0	2.4	3.3	+17.5	+15.5	+31/35	2.0:1	+15	30
TM7275	5	250	20.5	19.0	2.5	3.5	+ 9.5	+ 8.0	+22/27	2.0:1	+15	24
TM7203	5	250	32.0	30.0	3.0	4.0	+ 8.0	+ 6.5	+18/30	2.0:1	+15	35
TM6119	30	250	8.0	6.5	3.0	3.5	+23.0	+20.0	+36/45	2.3:1	+15	43
TM7382	20	250	18.0	16.0	4.0	5.0	+17.5	+16.0	+29/31	2.0:1	+15	45
TM7282	20	250	23.5	21.0	4.0	5.0	+21.0	+18.0	+34/38	2.3:1	+15	45
TM7277	5	250	10.5	9.5	4.0	5.0	+24.0	+20.0	+41/48	2.0:1	+15	70
TM7279	5	250	14.0	12.5	4.5	6.0	+23.0	+21.0	+36/46	2.0:1	+15	88
TM7201	5	250	29.0	27.5	5.0	6.5	+ 7.0	+ 5.5	+19/30	2.0:1	+15	35
TM7347	5	300	13.5	12.5	2.0	3.0	+16.0	+15.0	+32/44	1.7:1	+15	45
TM7207	10	300	18.0	17.0	2.0	3.0	+16.0	+15.0	+31/42	2.0:1	+15	33
TM7481	10	300	28.0	27.0	2.3	3.0	+16.5	+15.0	+29/33	2.0:1	+15	27
TM5150	10	300	20.0	19.0	2.5	3.5	+18.0	+17.0	+32/43	2.4:1	+15	47
TM5105	5	300	12.0	11.0	2.8	4.0	+ 7.0	+ 5.5	+21/29	2.0:1	+15	17
TM7287	10	300	15.5	14.5	2.8	4.0	+10.0	+ 9.0	+24/33	2.0:1	+ 5	15
TM7487	10	300	15.5	14.5	3.0	4.0	+ 8.0	+ 7.0	+22/31	2.0:1	+ 5	13
TM7274	5	300	31.0	29.0	3.0	4.0	+ 9.5	+ 8.0	+21/32	2.0:1	+15	40
TM5152	10	300	17.0	16.0	3.5	3.8	+20.0	+17.5	+33/47	2.0:1	+15	55
TM7278	5	300	13.5	12.5	4.0	5.5	+21.5	+19.0	+36/49	2.0:1	+15	65
TM7297	20	300	10.5	9.5	4.5	6.0	+16.5	+15.0	+29/33	2.0:1	+ 5	43
TM5155	5	300	15.0	14.0	5.0	6.0	+22.0	+21.0	+37/48	2.0:1	+15	85
TM5103	5	300	11.5	10	5	6.5	23.0	21.0	+36/45	2.0:1	15	85
TM6181	10	400	8.5	7.5	1.7	2.5	+ 8.0		+23/40	2.0:1	+15	11
TR6535	10	400	32.5	30.0	1.8	3.0	+22.0		+37/48	2.5:1	+	90
TM6457	5	400	15.0	14.0	2.0	3.0	+10.0	+ 7.5	+24/35	2.0:1	+ 5	16
TR7217	10	400	25.5	24.0	2.5	3.0	+20.0		+33/44	2.0:1	+15	65
TM6487	10	400	15.5	14.0	3.2	5.0	+17.5	+15.0	+32/45	2.0:1	+15	33
TM6443	10	400	13.2	12.0	3.5	5.0	+ 6.5		+19/27	2.0:1	+ 5	10
TM6421	5	400	30.0	27.0	3.5	6.0	+ 9.0	+ 7.0	+22/36	2.0:1	+15	37

## **Bi-Polar Amplifiers**

Bipolar Amplifiers are those designs which utilize bi-polar silicon transistors. All amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and Connectorized Housings "BX". Parts are listed from Low to High Frequency.

		uency (MHz)	Ga (d	in	No (d	ise		Power @	IP3/IP2 (dBm)		Po	wer
Model	Low	High	Typ.	Min.	Typ.	Max.		IBm) Min.	Typ.	VSWR	Su   (DC)	pply (mA)
TM6441	20	400	14.5	13	3.5	5	16	15	+31/48	2.0:1	15	32
TM6440	10	400	13	12	3.6	5	+ 9.0	+ 7.5	+23/33	2.0:1	15	15
TM5441	10	400	14.5	13	3.8	4.5	- 1.0	- 4.0	+25/33	2.0:1	+ 5	33
TM6444	10	400	13	12	4	5.5	11	+ 9.0	+25/37	2.0:1	+ 5	15
TM6587	10	400	13	12	4	5	17	16	+32/47	2.0:1	15	32
TM6442	20	400	14	12.5	4.5	6	22	19	+37/51	2.0:1	15	62
TM6588	5	450	18.5	17.5	4.5	7	21	19	+35/44	2.0:1	15	80
TM6554	5	450	27.5	25	5	6.0	8	6.0	+19/32	2.0:1	15	33
TM6556	5	400	26	24	4.5	6.5	14.0	12.5	+28/47	2.0:1	15	66
TM6143	5	500	15.7	14.5	1.6	2.5	+ 7.5	+ 5.0	+20/28	2.5:1	15	15
TM6719	5	500	33	31	1.7	2	+ 9.0	8	+20/36	2.0:1	15	35
TM6210	5	500	15.3	14	2	3	+ 7.5	4.5	+18/26	2.5:1	+ 5	12
TM5104	10	500	12	10.5	2	3.5	15	13	+32/46	2.0:1	15	35
TM6544	10	500	12	10.5	2	3	15	13	+32/46	2.0:1	15	35
TR6592	100	500	25.5	24	2.2	2.5	16	14	+27/41	2.0:1	15	45
TM5519	5	500	15	14	2.3	3	14.5	11.5	29/39	2.2:1	+ 5	30
TM5119	5	500	15.5	14	2.3	3	16	14	+32/44	2.0:1	15	30
TM6171	5	500	15.2	14	2.3	3	+ 0.5	- 2.0	+12/15	2.0:1	15	11
TM6583	10	500	30	28	2.3	3	- 1.0	- 4.0	+10/13	2.0:1	+ 5	13
TM6675	5	500	20.5	19	2.3	3	+ 5.0	+ 4.0	+18/25	2.0:1	15	15
TM6517	5	500	22.5	21	2.4	3	10	+ 8.0	+22/26	2.0:1	15	22
TM6674	5	500	28	26	2.5	4	- 1.0	- 2.0	+9/17	2.0:1	+ 5	13
TM6511	5	500	16.5	15.5	2.5	3	+ 2.0	+ 1.0	+14/16	2.0:1	15	10
TM6573	5	500	32	29	2.5	3.5	+ 2.0	-2.5	+14/19	2.0:1	15	20
TM6501	5	500	16.5	15.5	2.5	3.5	+ 3.0	+ 1.0	+15/17	2.0:1	15	10
TM6510	5	500	16.5	15.5	2.5	3.5	+ 3.0	+ 1.0	+15/17	2.0:1	15	10
TM6512	5	500	21	19	2.5	3.5	10	+ 8.0	+21/27	2.0:1	15	23
TM5110	10	500	15	14	2.5	3	10.5	+ 9.0	+25/33	2.0:1	15	25
TM6654	5	500	29	27.5	2.5	3	11	10	+23/33	2.0:1	+ 5	40
TM6543	10	500	11	10	2.5	3	11	+ 9.0	+24/35	2.0:1	15	25
TM5544	10	500	12.5	11	2.5	3.5	14.5	11.5	+27/33	2.0:1	+ 5	35
TM6570	10	500	8	7	2.5	3	17.5	17	+35/46	2.0:1	15	35
TR7216	10	500	25.5	24	2.5	3	20	18	+33/44	2.0:1	12	65
TM6575	5	500	21	19	2.7	3.5	9.5	8.5	+21/28	2.0:1	15	23
TM5101	5	500	13	12	2.8	4	7.5	6	+21/31	2.0:1	15	17
TM6521	5	500	30	28	3	4	9	7	+22/30	2.0:1	15	36
TM6681	20	500	17.5	15.5	3	4	9.5	7	+23/28	2.0:1	15	29
TM5126	5	500	15	14	3	3.5	17	16	+16/21	2.0:1	15	50
TM5175	20	500	16.3	15.5	3	3.8	18	16.5	+32/41	2.0:1	15	45
TM6547	10	500	12.5	11	3	4	19	17.5	+35/48	2.0:1	15	55
TM6147	5	500	17	16	3	4.5	20	17.5	+35/44	2.0:1	15	50

Bipolar Amplifiers are those designs which utilize bi-polar silicon transistors. All amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525" Sq.), and Connectorized Housings "BX". Parts are listed from Low to High Frequency.

	Frequ	uency nge	Ga (dl	in	Noi (dl	se	Output P	ower @	IP3/IP2 (dBm)		Pov Sup	
Model	Low	High	Typ.	Min.	Typ.	Max.	Typ. (dl	3m) Min.	Typ.	VSWR		(mA)
TR6689	10	500	30	28	3.2	4	21.5	20	+34/44	2.0:1	15	130
TM6503	5	500	16.5	15.5	3.5	4.5	1.5	0	+14/16	2.0:1	15	10
TM6574	5	500	30	27	3.5	6	9	7	+22/36	2.0:1	15	37
TM6520	5	500	14.5	13.5	3.5	4.5	13	11.5	+27/34	2.0:1	5	33
TM6416	5	500	15	14	3.5	4.5	13.5	12	+27/35	2.0:1	15	35
TM6524	5	500	31	29	3.5	4	15	14	+25/30	2.0:1	15	70
TM6581	20	500	22	21	3.5	4.5	16	13.5	+28/40	2.0:1	15	27
TM6533	5	500	16.5	15	3.5	5.5	17	15	+32/42	2.0:1	15	50
TM6577	5	500	16.5	15	3.5	5.5	17	15	+32/42	2.0:1	15	50
TM6526	10	500	28	26	3.5	4	21	18.5	+35/50	2.0:1	15	93
TM6582	30	500	23	21.5	3.5	4.5	21	17	+33/43	2.0:1	15	47
TM6513	5	500	17	15.5	3.7	5	16.5	15	+29/41	2.0:1	24	50
TR6589	5	500	26.5	25	3.7	5	22	20	+35/55	2.0:1	15	130
TM6505	5	500	15	14	4	5	10	8.5	+23/33	2.0:1	15	24
TM6555	5	500	14.7	13.5	4	6.5	11.5	9	+24/35	2.0:1	15	33
TM5109	10	500	10.5	9.5	4	5	13	12	+28/40	2.0:1	15	35
TM6672	5	500	14.7	13.5	4	5.5	13	11	+27/38	2.0:1	9	30
TM6516	5	500	14.5	13.5	4	4.5	14	12	+28/38	2.0:1	15	35
TM6572	5	500	14.7	13.5	4	5.5	13	11	+27/38	2.0:1	5	30
TM6547	10	500	12.5	11	4	4.5	19	17.5	+35/48	2.0:1	15	55
TM6545	10	500	11.5	10	4	5.5	20.5	18	+36/48	2.0:1	15	60
TM6519	5	500	14.3	12	4.2	5.5	19	17	+34/40	2.0:1	15	70
TM6507	10	500	15.5	14	4	6	24	20	+35/40	2.0:1	15	110
TM6557	10	500	15	13.5	4.5	6.5	15.5	14	+30/38	2.0:1	15	44
TM6515	5	500	12.5	11	4.5	5.5	16.5	15	+31/43	2.0:1	15	50
TM6131	10	500	10.3	9	4.5	6.5	20	18	+37/50	2.0:1	15	62
TM6509	5	500	14.5	13	4.6	6	23	20	+36/50	2.0:1	15	88
TM6558	5	500	12	10.5	4.8	6.5	19	17.5	+36/48	2.0:1	15	65
TM6607	5	500	15	14	5	6	14.5	12.5	+24/34	2.0:1	24	50
TM6149	5	500	15.3	14.5	5	6	16	14.5	+30/41	2.0:1	15	45
TM6576	5	500	28	26	5	6	16	14	+30/52	2.0:1	15	64
TR9604	30	500	23	21	5	6	21	19	+33/40	2.0:1	15	125
TM6518	5	500	14	12.5	5.2	6.5	25	22.5	+33/40	2.0:1	15	125
TM6603	5	500	10	8.5	5.5	7	15.5	14	+30/42	2.0:1	24	50
TM6523	5	500	25.5	23	5.5	7	16	14	+26/35	2.0:1	15	75
TM6519	10	500	14.3	12	5.5	6	19	17	+34/40	2.0:1	15	70
TM5102	5	500	12.5	11	5.5	7	22	20	+36/46	2.0:1	15	88
TM6559	5	500	11.5	10	5.5	7	22	20	+36/46	2.0:1	15	88
TM6705	5	500	10.5	9	6	7.5	20	18	+34/44	2.0:1	15	90
TM6157	20	500	13	0.5	7.5	8:5	22	18	+33/45	2.0:1	15	75
TM5133	<del> </del>	500	10	9	3.3	4.5	16	14.5	+30/45	2.0:1	15	57
TM5107	10	550	15	14	1.75	2.3	2	1	+13/16	2.0:1	15	9

Bipolar Amplifiers

Bipolar Amplifiers are those designs which utilize bi-polar silicon transistors. All amplifiers are available in TO-8 cans "TM" and Surface Mount Packages "TN" for TO-8's (.450" Sq.).

		uency nge	1	ain B)	Noi (dl		Output P		IP3/IP2 (dBm)		Power	Supply
Model	Low	High	Тур.	Min.	Тур.	Max.	Typ. (d	Bm) Min.	Тур.	VSWR	(DC)	(mA)
TM6191	100	600	23.5	22	2.5	4	21.5	20	+36/52	2.0:1	15	95
TM6605	10	600	15.5	14	3	4.5	10	8	+23/32	2.0:1	15	24
TM6667	5	600	14	12.5	4	5.5	15	14	+30/45	2.0:1	15	33
TM6659	10	700	10.5	9	6.5	8	22	20	+36/46	2.0:1	15	88
TM9167	10	800	12.5	11.5	4.5	5.5	15.5	14.5	+30/45	2.0:1	15	32
TM9118	10	800	14.7	13.5	4.5	5.5	16	15	+26/33	2.0:1	15	45
TM9511	5	1000	16.5	15	2.3	3	1	-1	+14/16	2.0:1	15	9.5
TM9311	5	1000	16.5	15	2.3	3	2	-1	+14/17	2.0:1	15	10
TM9111	5	1000	15	14	2.4	4	1	-2	+12/15	2.0:1	15	9
TM9101	5	1000	15	14	2.4	4	1	-2	+12/15	2.0:1	15	9
TM9163	5	1000	16	15	2.5	3.5	5	3	+16/21	2.0:1	15	14
TM9143	10	1000	10.5	9	2.5	4.5	10	8	+27/38	2.0:1	15	25
TM9566	10	1000	26	24.5	3	4	0.1	-0.5	+12/21	2.0:1	15	18
TM9363	5	1000	16.5	15	3	4	6	4	+19/25	2.0:1	15	16
TM9312	5	1000	16.5	15	3	4	7	5	+20/24	2.0:1	15	18
TM9102	5	1000	15	13.5	3	4.5	10	7.5	+23/32	2.0:1	15	23
TM6145	10	1000	10.7	10	3	5	19	16	+35/46	3.0:1	15	50
TM9313	5	1000	16	15	3.5	4.5	12	10	+23/35	2.0:1	15	29
TM9318	10	1000	14.7	13.5	3.7	5.5	16	14.5	+30/42	2.0:1	15	47
TM9107	5	1000	13.5	11.5	3.9	5	13	10	+22/26	2.0:1	5	33
TM9115	5	1000	14.5	13	4	5.5	9.5	8	+23/32	2.0:1	15	24
TM6176	5	1000	13.5	12	4	5	14	12	+27/40	2.0:1	15	38
TM9366	10	1000	27.5	25.5	4	5	15	13.5	+25/32	2.0:1	15	63
TM9117	10	1000	12	10	4	6	15.5	14.5	+28/40	2.0:1	15	46
TM9518	10	1000	14.7	13.5	4	5.5	16	14.5	+29/41	2.0:1	15	44
TM9196	500	1000	11.5	13.5	4	4.5	18	16	+29/48	3.0:1	15	40
TM6155	300	1000	12.5	10.5	4	5.5	19.5	18	+33/45	3.0:1	15	50
TM9165	10	1000	10.5	9	4.5	6	11	9	+24/37	2.0:1	15	30
TM9157	1	1000	10.2	8.5	4.5	6	14	13	+27/37	2.0:1	15	44
TM9106	5	1000	12	10.5	4.8	6	19	16	+27/32	2.0:1	15	70
TM9333	5	1000	11.5	10	5	6.5	16	14	+30/44	2.0:1	15	48
TM6345	10	1100	12.3	10.5	3	4	17	15	+33/46	3.0:1	15	45
TM5147	20	1100	14	13	3.5	4	11	9	+23/33	2.0:1	15	27
TM9316	10	1200	13	12	3	4	6	4.5	+19/28	2.0:1	5	15
TM9193	400	1200	15	14	3	4	9	8.5	+14/20	2.0:1	15	19
TM9164	10	1200	26	24	3.6	4.5	8.5	6.5	+20/33	2.0:1	15	35
TM9166	10	1200	23.5	22	4.5	5.5	15	13.5	+28/46	2.0:1	15	64
TM5131	5	1300	18	17	5	5.5	7.5	6	+20/40	2.0:1	15	40
TM9328	10	1500	14	12.5	3.2	4.5	12	9	+23/31	2.0:1	5	27
TM9325	10	1500	14	13	3.5	4.5	9	7.5	+22/30	2.0:1	15	24
TM9123	10	1500	12	10	4	4.5	4	3	+17/22	2.0:1	15 .	14
TM9114	10	1500	20	18	4	5.5	7	5	+21/42	2.0:1	12	34

**Bipolar Amplifiers** 

Bipolar Amplifiers are those designs which utilize bi-polar silicon transistors. All amplifiers are available in TO-8 cans "TM", TO-8B cans "TR", Surface Mount Packages "TN" for TO-8's (.450" Sq.), "RN" for slightly larger TO-8B's (.525"

Sal	and Connectorized Ho	usings "BX"	Parts are listed for	rom Low to Hi	ah Frequency.

Model		uency nge High	Ga (dl Typ.		No (di Typ.		Output Po 1 dB Comp Typ. (dE	pression	IP3/IP2 (dBm) Typ.	VSWR	Power (DC)	Supply (mA)
TM9124	10	1500	20	18	4	5.5	8	6	+21/42	2.0:1	15	34
TM9502	5	1500	10.5	8.5	4	5.5	9	7	+24/32	2.0:1	15	23
TM9121	10	1500	15	13.5	4	5	13.5	12	+26/34	2.0:1	15	34
TM9524	10	1500	22	20	4.3	5	13	10	+23/31	2.2:1	15	56
TM9125	10	1500	10.5	9	4.5	6	8	7	+21/33	2.0:1	15	24
TM9128	10	1500	11.5	10	4.5	6	15	13.5	+29/43	2.0:1	15	40
TM9522	5	1500	20.5	18.5	5	6	14	10	+25/42	2.0:1	15	64
TM9529	10	1600	9	7.5	6.5	8	19	18	+29/35	2.0:1	12	90
TM9331	10	2000	11.5	10.5	4	4.5	2	0	+14/21	2.0:1	15	11
TM9355	5	2000	10	9	4	6.5	12	10	+24/32	2.0:1	+5	30
TM9133	10	2000	9.5	8	4.5	5.5	3	2	+16/23	2.0:1	15	14
TM9134	100	2000	16.5	14	4.5	6	6	3	+16/33	2.0:1	15	35
TM9324	10	2000	16	14	4.7	6	6.5	4.5	+19/37	2.0:1	15	38
TM9322	10	2000	10	8.5	5	6.5	9	7.5	+23/35	2.0:1	15	25
TM9135	10	2000	10	8.5	5	6.5	9	7.5	+23/35	2.0:1	15	25
FP9130	200	2000	23.5	22	5	6.5	15	13.5	+27/40	2.0:1	15	90
TM9436	10	2000	17	15	5.5	7.5	11	10	+21/27	1.5:1	12	63
TM9136	10	2000	17	15	5.5	7.5	12	11	+22/28	2.0:1	15	63
TM9323	10	2000	8.5	7.5	5.5	7.5	15	14	+30/50	2.0:1	15	50
TM9138	10	2000	7.5	6	6	9.5	19	16.5	+33/46	2.2:1	15	65
TM9137	10	2000	9.5	7	6.5	10	15.5	13	+28/38	2.2:1	15	45
TM9327	10	2000	15	13	6.5	7.5	17.5	16	+29/38	2.0:1	15	108

## Download the latest version of Cascade Software for the most recent selection of

Low Phase Noise Bipolar Amplifiers www.amplifonix.com



This list contains those Lower Power Amplifiers (less than +20 dBm) for use where parameters other than High Power are important. Models come in standard T0-8 cans ("TM"), TO-8B ("TR"), Surface Mount ("TN or RN"), and SMA Connectorized Housings ("BX").

	Frequ	iency	Ga			ise	T	Power @	IP3/IP2	<i>/</i>		
	Range		_ (d			B)	1 dB Con	npression	(dBm)			Supply
Model	Low	High	Тур.	Min.	Тур.	Max.	Тур. (с	Bm) Min.	Тур.	VSWR	(DC)	(mA)
TM9702	500	1500	12	10.5	2.8	4	19.8	19	+31/40	2.0:1	8	107
TM6155	300	1000	12.5	10.5	4	5.5	19.5	18	+33/45	3.0:1	15	50
TM6547	10	500	12.5	11	3	4	19	17.5	+35/48	2.0:1	15	55
TM6547	10	500	12.5	11	4	4.5	19	17.5	+35/48	2.0:1	15	55
TM6519	5	500	14.3	12	4.2	5.5	19	17	+34/40	2.0:1	15	70
TM6558	5	500	12	10.5	4.8	6.5	19	17.5	+36/48	2.0:1	15	65
TM6519	10	500	14.3	12	5.5	6	19	17	+34/40	2.0:1	15	70
TM6145	10	1000	10.7	10	3	5	19	16	+35/46	3.0:1	15	50
TM9106	5	1000	12	10.5	4.8	6	19	16	+27/32	2.0:1	15	70
TM9529	10	1600	9	7.5	6.5	8	19	18	+29/35	2.0:1	12	90
TM9138	10	2000	7.5	6	6	9.5	19	16.5	+33/46	2.2:1	15	65
TM9700	200	2000	12	10.5	2.2	4	19	18	+33/43	2.2:1	6	65
TM7221	20	200	28.5	27	2	3	18.5	15	+33/38	2.0:1	15	29
TM5149	5	150	23.5	22.5	3	3.2	18	17	+33/37	2.0:1	15	35
TM6118	10	200	10	9.4	1.5	2	18	16.5	+33/55	2.0:1	15	18
TM5150	10	300	20	19	2.5	3.5	18	17	+32/43	2.4:1	15	47
TM5175	20	500	16.3	15.5	3	3.8	18	16.5	+32/41	2.0:1	15	45
TM9196	500	1000	11.5	13.5	4	4.5	18	16	+29/48	3.0:1	15	40
CZ8130	kHz	400	14	13	6	7	18	15	+30/40	3.0:1	5.7	60
TM7281	20	250	25.5	23	2.4	3.3	17.5	15.5	+31/35	2.0:1	15	30
TM6487	10	400	15.5	14	3.2	5	17.5	15	+32/45	2.0:1	15	33
TM6570	10	500	8	7	2.5	3	17.5	17	+35/46	2.0:1	15	35
TM9327	10	2000	15	13	6.5	7.5	17.5	16	+29/38	2.0:1	15	108
TM7111	10	100	12.5	11	1.4	2	17	15.5	+33/47	2.0:1	15	14
TM7102	20	150	24.5	22.5	2	3	17	16	+29/40	2.0:1	15	31
TM7380	10	200	27.5	26	2.2	3	17	15	+31/35	2.0:1	15	28
TM6587	10	400	13	12	4	5	17	16	+32/47	2.0:1	15	32
TM5126	5	500	15	14	3	3.5	17	16	+32/42	2.0:1	15	50
TM6533	5	500	16.5	15	3.5	5.5	17	15	+32/42	2.0:1	15	50
TM6577	5	500	16.5	15	3.5	5.5	17	15	+32/42	2.0:1	15	50
TM6345	10	1100	12.3	10.5	3	4	17	15	+33/46	3.0:1	15	45
TZ9404	5	400	11	9.5	6.5	7.5	17	15	+30/38	2.0:1	15	65
CZ8463	kHz	400	10.5	9	6.5	7.5	17	15	+30/36	2.0:1	24	65
CZ8464	kHz	400	10.5	9	6.5	7.5	17	15	+30/39	2.0:1	15	65
CZ8403	5	400	10.5	9	6.8	7.5	17	15	+30/36	2.0:1	24	65
CZ8404	5	400	10.5	9	6.5	7.5	17	15	+30/36	2.0:1	15	65
TM7101	10	150	27.5	26	1.8	2.5	16.5	15	+30/35	2.0:1	15	20

This list contains those Lower Power Amplifiers (less than +20 dBm) for use where parameters other than High Power are important. Models come in standard T0-8 cans ("TM or TZ"), TO-8B ("TR"), Surface Mount ("TN OR RN"), and SMA Connectorized Housings ("BX").

	Freque Range	ency (MHz)	Ga (d	iin B)	No (d	ise B)	1 dB Cor	Power @ mpression	IP3/IP2 (dBm)			Supply
Model	Low	High	Тур.	Min.	Тур.	Max.	Typ. (	dBm) Min.	Тур.	VSWR	(DC)	(mA)
TM7481	10	300	28	27	2.3	3	16.5	15	+29/33	2.0:1	15	27
TM7297	20	300	10.5	9.5	4.5	6	16.5	15	+29/33	2.0:1	5	43
TM6513	5	500	17	15.5	3.7	5	16.5	15	+29/41	2.0:1	24	50
TM6515	5	500	12.5	11	4.5	5.5	16.5	15	+31/43	2.0:1	15	50
TM9718	500	1000	15	13.5	4.5	5.5	16.5	14.5	+28/35	2.0:1	15	47
TZ9202	5	200	28.5	26	5.2	6	16.5	15	+28/44	2.0:1	15	90
TM7347	5	300	13.5	12.5	2	3	16	15	+32/44	1.7:1	15	45
TM7207	10	300	18	17	2	3	16	15	+31/42	2.0:1	15	33
TM6441	20	400	14.5	13	3.5	5	16	15	+31/48	2.0:1	15	32
TR6592	100	500	25.5	24	2.2	2.5	16	14	+27/41	2.0:1	15	45
TM5119	5	500	15.5	14	2.3	3	16	14	+32/44	2.0:1	15	30
TM6581	20	500	22	21	3.5	4.5	16	13.5	+28/40	2.0:1	15	27
TM6149	5	500	15.3	14.5	5	6	16	14.5	+30/41	2.0:1	15	45
TM6576	5	500	28	26	5	6	16	14	+30/42	2.0:1	15	64
TM6523	5	500	25.5	23	5.5	7	16	14	+26/35	2.0:1	15	75
TM9318	10	1000	14.7	13.5	3.7	5.5	16	14.5	+30/42	2.0:1	15	47
TM9518	10	1000	14.7	13.5	4	5.5	16	14.5	+29/41	2.0:1	15	44
TM9333	5	1000	11.5	10	5	6.5	16	14	+30/42	2.0:1	15	48
TR9765	1700	2000	23	20	2	3	16	14.5	+27/41	2.0:1	15	80
TM9712	500	2000	11	9	3	4	16	14	+24/30	2.0:1	15	46
TM9711	1000	2000	12	10	2.2	3	16	15	+29/35	2.0:1	6	62
CZ8230*	kHz	600	10	9	7	8	16	13	+25/32	3.0:1	4.5	60
TM5670	20	250	8.2	7	2	3	15.5	13.5	+28/33	2.0:1	5	25
TM6557	10	500	15	13.5	4.5	6.5	15.5	14	+30/38	2.0:1	15	44
TM6603	5	500	10	8.5	5.5	7	15.5	14	+14/16	2.0:1	24	50
TM9167	10	800	12.5	11.5	4.5	5.5	15.5	14.5	+30/45	2.0:1	15	32
TM9117	10	1000	12	10	4	6	15.5	14.5	+28/40	2.0:1	15	46
TM9137	10	2000	9.5	7	6.5	10	15.5	13	+28/38	2.2:1	15	45
TZ9208	5	200	27.5	26	5	6	15.5	14.5	+28/44	2.0:1	12	90
TZ9216	5	200	12.5	11	5.5	7	15.5	13.5	+30/41	2.0:1	15	50
TM5104	10	500	12	10.5	2	3.5	15	13	+32/46	2.0:1	15	35
TM6544	10	500	12	10.5	2	3	15	13	+32/46	2.0:1	15	35
TM6524	5	500	31	29	3.5	4	15	14	+25/30	2.0:1	15	70
TM6667	5	600	14	12.5	4	5.5	15	14	+30/45	2.0:1	15	33
TM9366	10	1000	27.5	25.5	4	5	15	13.5	+25/32	2.0:1	15	63
TM9166	10	1200	23.5	22	4.5	5.5	15	13.5	+28/46	2.0:1	15	64

<sup>\*</sup>Visit www.amplifonix.com for the largest selection of Full Performance Amplifiers\*

This list contains those Lower Power Amplifiers (less than +20 dBm) for use where parameters other than High Power are important. Models come in standard T0-8 cans ("TM or TZ"), TO-8B ("TR"), Surface Mount ("TN or RN"), and SMA Connectorized Housings ("BX").

	Frequ	ency	Ga	in	No	ise	Output Po	wer @	IP3/IP2	l l	<u>Β</u> Λ ).	
Model	Range		(di		. (d		1 dB Comp		(dBm)	VOMP		Supply
Model	Low	High	Тур.	Min.	Тур.	Max.		m) Min.	Тур.	VSWR	(DC)	(mA)
TM9323	10	2000	8.5	7.5	5.5	7.5	15	14	+30/50	2.0:1	15	50
TM9302	1700	2300	10.5	8.5	5	6.5	15	14	+23/40	2.0:1	15	18
TM7381	20	250	24.5	23	2.2	3	14.5	12.5	+27/32	2.0:1	15	18
TM5519	5	500	15	14	2.3	3	14.5	11.5	+29/39	2.2:1	5	30
TM5544	10	500	12.5	11	2.5	3.5	14.5	11.5	+27/33	2.0:1	5	35
TM6607	5	500	15	14	5	6	14.5	12.5	+24/34	2.0:1	24	50
TZ9205	5	200	20.5	20	6	7	14.5	13	+35/42	2.0:1	15	90
TZ9409	5	400	12.5	11	5.5	6.5	14.5	12.5	+26/38	2.0:1	15	50
TM7210	10	200	9	8	1.3	2	14	12.5	+31/48	2.0:1	15	15
TM7205	10	200	20	19	1.6	2.2	14	12	+21/26	2.0:1	5	18
TM7272	10	200	14.7	14	3	5	14	12	+29/41	1.3:1	5	35
TM6176	5	1000	13.5	12	4	5	14	12	+27/40	2.0:1	15	38
TM9157	1	1000	10.2	8.5	4.5	6	14	13	+27/37	2.0:1	15	44
TM9522	5	1500	20.5	18.5	5	6	14	10	+25/42	2.0:1	15	64
TM9701	200	2000	12	11	3	4	14	13	+25/32	2.0:1	5	48
CZ8330*	kHz	1000	6.2	5	9.5	11	14	10	+25/31	3.0:1	4.5	60
TM6416	5	500	15	14	3.5	4.5	13.5	12	+27/35	2.0:1	15	35
TM9121	10	1500	15	13.5	4	5	13.5	12	+26/34	2.0:1	15	34
TR7215	5	200	31.5	30	2.5	4	13	10	+26/39	1.5:1	15	58
TM7270	10	250	8.3	7	1.4	2.5	13	11	+30/50	1.8:1	15	15
TM6520	5	500	14.5	13.5	3.5	4.5	13	11.5	+27/34	2.0:1	5	33
TM5109	10	500	10.5	9.5	4	5	13	12	+28/40	2.0:1	15	35
TM6672	5	500	14.7	13.5	4	5.5	13	11	+27/38	2.0:1	9	30
TM6572	5	500	14.7	13.5	4	5.5	13	11	+27/38	2.0:1	5	30
TM9107	5	1000	13.5	11.5	3.9	5	13	10	+22/26	2.0:1	5	33
TM9524	10	1500	22	20	4.3	5	13	10	+23/31	2.2:1	15	56
CZ8208	5	200	14.5	13	5	6	12.5	11	+26/34	2.0:1	12	36
TM7104	5	150	24	22.5	1.9	2.5	12	10.5	+25/31	2.0:1	5	20
TM9313	5	1000	16	15	3.5	4.5	12	10	+23/35	2.0:1	15	29
TM9328	10	1500	14	12.5	3.2	4.5	12	9	+23/31	2.0:1	5	27
TM9355	5	2000	10	9	4	6.5	12	10	+24/32	2.0:1	5	30
TM9136	10	2000	17	15	5.5	7.5	12	11	+22/28	2.0:1	15	63
TM9710	1000	2000	12.8	11	3.4	4	12	10.5	+23/33	2.0:1	15	26
CZ8553	5	500	19.5	18	3.5	4.5	12	9	+24/30	2.2:1	15	33
TM6555	5	500	14.7	13.5	4	6.5	11.5	9	+24/35	2.0:1	15	33
CZ8202	5	200	29	27	5.5	6.5	11.5	9.5	+23/34	2.0:1	15	55
TM6444	10	400	13	12	4	5.5	11	9	+25/37	2.0:1	5	15

This list contains those Lower Power Amplifiers (less than +20 dBm) for use where parameters other than High Power are important. Models come in standard T0-8 cans ("TM or TZ"), TO-8B ("TR"). Surface Mount ("TN or RN"), and SMA Connectorized Housings ("BX").

		ı, Suria ıency	Ga	<del>`</del> _	No			it Power @	IP3/IP2		<i>DX                                    </i>	
		(MHz)	(di		(d			ompression	(dBm)		Power	Supply
Model	Low	High	Тур.	Min.	Тур.	Max.	Тур.	(dBm) Min.	Тур.	VSWR	(DC)	(mA)
TM6654	5	500	29	27.5	2.5	3	11	10	+23/33	2.0:1	5	40
TM6543	10	500	11	10	2.5	3	11	9	+24/35	2.0:1	15	25
TM9165	10	1000	10.5	9	4.5	6	11	9	+24/37	2.0:1	15	30
TM5147	20	1100	14	13	3.5	4	11	9	+23/33	2.0:1	15	27
TM9436	10	2000	17	15	5.5	7.5	11	10	+21/27	1.5:1	12	63
TM5304	5	200	19.5	18.5	2.5	3	10.5	9.5	+25/33	2.0:1	15	24
TM5110	10	500	15	14	2.5	3	10.5	9	+25/33	2.0:1	15	25
TZ9408	5	400	28	26	5	6	10.5	9	+22/34	2.0:1	15	45
TM6117	5	250	8.2	7	1.3	2	10	9	+28/43	2.0:1	15	12
TM7170	10	250	8.5	7.5	1.5	2.5	10	9	+26/38	2.0:1	15	12
TM7287	10	300	15.5	14.5	2.8	4	10	9	+24/33	2.0:1	5	15
TM6457	5	400	15	14	2	3	10	7.5	+24/35	2.0:1	5	16
TM6517	5	500	22.5	21	2.4	3	10	8	+22/36	2.0:1	15	22
TM6512	5	500	21	19	2.5	3.5	10	8	+21/27	2.0:1	15	23
TM6505	5	500	15	14	4	5	10	8.5	+23/33	2.0:1	15	24
TM6605	10	600	15.5	14	3	4.5	10	8	+23/32	2.0:1	15	24
TM9143	10	1000	10.5	9	2.5	4.5	10	8	+27/38	2.0:1	15	25
TM9102	5	1000	15	13.5	3	4.5	10	7.5	+23/32	2.0:1	15	23
TM9355	5	2000	10	8.5	5	6.5	10	9	+23/32	2.0:1	5	26
CZ8050*	5	1000	22.5	20.5	6	7	10	6	+23/36	2.0:1	15	67
TM7103	10	150	26.5	25	2.3	2.8	9.5	8	+23/28	2.0:1	5	16
TM7275	5	250	20.5	19	2.5	3.5	9.5	8	+22/27	2.0:1	15	24
TM7274	5	300	31	29	3	4	9.5	8	+21/32	2.0:1	15	40
TM6575	5	500	21	19	2.7	3.5	9.5	8.5	+21/28	2.0:1	15	23
TM6681	20	500	17.5	15.5	3	4	9.5	7	+23/28	2.0:1	15	29
TM9115	5	1000	14.5	13	4	5.5	9.5	8	+23/32	2.0:1	15	24
CZ8040*	kHz	300	19	18	3.8	4.5	9.5	6	+21/26	3.0:1	3.5	25
CZ8203	5	200	20	19	6	7	9.5	8	+21/39	2.0:1	15	62
TM6421	5	400	30	27	3.5	6	9	7	+22/36	2.0:1	15	37
TM6440	10	400	13	12	3.6	5	9	7.5	+23/33	2.0:1	15	15
TM6719	5	500	33	31	1.7	2	9	8	+20/36		15	35
TM6521	5	500	30	28	3	4	9	7	+22/30	2.0:1	15	36
TM6574	5	500	30	27	3.5	6	9	7	+22/30	2.0:1	15	37
TM9193	400	1200	15	14	3	4	9	8.5	+22/36	2.0:1	15	19
TM9325	10	1500	14	13	3.5	4.5	9	7.5	+22/30	2.0:1	15	24
TM9502	5	1500	10.5	8.5	4	5.5	9	7	+24/32	2.0:1	15	23
TM9322	10	2000	10	8.5	5	6.5	9	7.5	+23/35	2.0:1	15	25

This list contains those Lower Power Amplifiers for use where parameters other than High Power (less than +20 dBm) are important. Models come in standard T0-8 cans ("TM or TZ"), TO-8B ("TR"), Surface Mount ("TN or RN"), and SMA Connectorized Housings ("BX").

	Frequ		ace IVIC		No	<del></del>	Output E	Power @	IP3/IP2		("BX").	
	Range		(di		(d			pression	(dBm)		Power	Supply
Model	Low	High	Тур.	Min.	Typ.	Max.		Bm) Min.	Typ.	VSWR	(DC)	(mA)
TM9135	10	2000	10	8.5	5	6.5	9	7.5	+23/35	2.0:1	15	25
CZ8120	KHz	400	15	13	5	6.5	9	7	+21/25	2.5:1	+5	25
CZ8402	5	400	15	13.5	4.7	5.8	9	7	+20/27	2.0:1	15	25
TM9164	10	1200	26	24	3.6	4.5	8.5	6.5	+20/33	2.0:1	15	35
TZ9402	5	400	15	13	5	6	8.5	7	+21/27	2.0:1	15	25
CZ8462	KHz	400	14.5	13	5	7	8.5	7	+20/27	2.2:1	15	25
TM7286	10	200	28	26	2.5	3.5	8	7	+20/29	2.0:1	+5	21
TM7203	5	250	32	30	3	4	8	6.5	+18/30	2.0:1	15	35
TM7487	10	300	15.5	14.5	3	4	8	7	+22/31	2.0:1	+5	13
TM6181	10	400	8.5	7.5	1.7	2.5	8	7	+23/40	2.0:1	15	11
TM6554	5	400	27.5	25	5	6	8	6	+19/32	2.0:1	15	33
TM9124	10	1500	20	18	4	5.5	8	6	+21/42	2.0:1	15	34
TM9125	10	1500	10.5	9	4.5	6	8	7	+21/33	2.0:1	15	24
CZ8220	KHz	600	10	9	6	7.5	8	6	+20/26	2.5:1	+3.2	25
CZ8052	5	1000	21.5	20	6	7	8	6	+20/39	2.0:1	15	60
CZ8320	KHz	1000	9	7	7	8	8	6	+20/27	2.5:1	+2.8	25
TZ9207	5	200	28.5	26	5	6	8	6	+20/33	2.0:1	12	38
TZ9201	5	200	29.5	27	5	6	8	6	+19/34	2.0:1	15	35
TM7288	5	250	22	21	1.8	2.2	7.5	6.5	+20/23	2.0:1	15	18
TM6143	5	500	15.7	14.5	1.6	2.5	7.5	5	+20/28	2.5:1	15	15
TM6210	5	500	15.3	14	2	3	7.5	4.5	+18/26	2.5:1	+5	12
TM5101	5	500	13	12	2.8	4	7.5	6	+21/31	2.0:1	15	17
TM5131	5	1300	18	17	5	5.5	7.5	6	+20/40	2.0:1	15	40
TZ9203	5	200	31.5	30	3.5	4	7.5	6	+19/35	2.0:1	15	35
TZ9206	5	200	24	22	4.5	5.5	7.5	6	+18/38	2.0:1	15	37
TM7201	5	250	29	27.5	5	6.5	7	5.5	+19/30	2.0:1	15	35
TM5105	5	300	12	11	2.8	4	7	5.5	+21/29	2.0:1	15	17
TM9312	5	1000	16.5	15	3	4	7	5	+20/24	2.0:1	15	18
TM9114	10	1500	20	18	4	5.5	7	5	+21/42	2.0:1	12	34
TM6153	300	1800	11.5	10.5	3	4	7	6	+18/22	3.0:1	15	18
TZ9212	0.1	200	31.5	30	3.5	4	7	5	+17/33	2.0:1	15	35
TZ9209	5	200	30.5	29	3.5	4	7	5	+18/28	2.0:1	12	36
TZ9210	0.1	200	29	27.5	4.5	6	7	5	+19/33	2.0:1	15	35
TM5118	3	100	16.3	15.5	1.5	2	6.5	5.5	+19/25	2.5:1	15	21
TM6443	10	400	13.2	12	3.5	5	6.5	5	+19/27	2.0:1	+5	10
TM9324	10	2000	16	14	4.7	6	6.5	4.5	+19/37	2.0:1	15	38
TZ9204	5 ,	200	20.8	20	6	7	6.5	5.5	+18/35	2.0:1	15	37

This list contains those Lower Power Amplifiers (less than +20 dBm) for use where parameters other than High Power are important. Models come in standard T0-8 cans ("TM or TZ"), TO-8B ("TR"), Surface Mount ("TN or RN"), and SMA Connectorized Housings ("BX").

	Frequ Range	-	Ga (di		Noi (dE			Power @	IP3/IP2 (dBm)		Power	Supply
Model	Low	High	Тур.	Min.	Typ.	Max.	Typ. (	dBm) Min.	`Typ.	VSWR	(DC)	(mA)
TM9363	5	1000	16.5	15	3	4	6	4	+19/25	2.0:1	15	16
TM9316	10	1200	13	12	3	4	6	4.5	+19/28	2.0:1	5	15
TM9134	100	2000	16.5	14	4.5	6	6	3	+16/33	2.0:1	15	35
CZ8201	5	200	32	30	3.2	4	5.8	3	+16/38	2.0:1	15	30
TM6675	5	500	20.5	19	2.3	3	5	4	+18/21	2.0:1	15	15
TM9163	5	1000	16	15	2.5	3.5	5	3	+16/21	2.0:1	15	14
CZ8653	5	250	22	20	3	3.2	5	2.5	+15/17	2.0:1	15	15
TM9123	10	1500	12	10	4	4.5	4	3	+17/22	2.0:1	15	14
CZ8207	5	200	18	17	4	5	4	0	+15/17	2.0:1	5	17
CZ8206	5	200	32	30	3.5	4	3.5	1	+15/26	2.0:1	12	30
TM7208	5	250	22.5	21	1.4	2	3	0	+16/13	2.0:1	15	10
TM6501	5	500	16.5	15.5	2.5	3.5	3	11	+15/17	2.0:1	15	10
TM6510	5	500	16.5	15.5	2.5	3.5	3	1	+15/17	2.0:1	15	10
TM9133	10	2000	9.5	8	4.5	5.5	3	2	+16/23	2.0:1	15	14
CZ8251	5	200	26.5	24	4	4.5	3	-1	+14/27	2.0:1	5	30
CZ8453	5	250	21	19.5	3	3.2	3	-1	+15/14	2.3:1	5	16
CZ8451	5	250	17	15.5	2.2	3	2.5	0	+14/15	2.0:1	5	12.5
TM7371	5	250	18	16	1.8	2.5	2	1	+14/15	2.0:1	15	9
TM6511	5	500	16.5	15.5	2.5	3	2	1	+14/16	2.0:1	15	10
TM6573	5	500	32	29	2.5	3.5	2	-2.5	+14/19	2.0:1	15	20
TM5107	10	550	15	14	1.75	2.3	2	1	+13/16	2.0:1	15	9
TM9311	5	1000	16.5	15	2.3	3	2	-1	+14/17	2.0:1	15	10
TM9331	10	2000	11.5	10.5	4	4.5	2	0	+14/21	2.0:1	15	11
TM6503	5	500	16.5	15.5	3.5	4.5	1.5	0	+14/16	2.0:1	15	10
TM9511	5	1000	16.5	15	2.3	3	1	-1	+14/16	2.0:1	15	9.5
TM9111	5	1000	15	14	2.4	4	1	-2	+12/15	2.0:1	15	9
TM9101	5	1000	15	14	2.4	4	1	-2	+12/15	2.0:1	15	9
TM7271	5	250	18	16	1.5	2.8	0.5	-1	+13/13	2.0:1	15	9
TM6171	5	500	15.2	14	2.3	3	0.5	-2	+12/15	2.0:1	15	11
TZ9411	5	400	15	14	4.5	6	0.5	-2	+13/15	2.0:1	12	12
TM9566	10	1000	26	24.5	3	4	0.1	-0.5	+12/21	2.0:1	15	18
LN7253	5	200	32	28	3	4	0	-2	+14/23	2.0:1	5	30
CZ8111	KHz	400	15.8	14	3	4	-0.2	-2	+21/11	3.0:1	2	10
CZ8110	KHz	400	15	13	4	5.5	-0.2	-5	+10/8	2.5:1	3	10
TM6683	10	250	34	32.5	2	3	-1	-3	+10/9	2.0:1	5	14
TM5441	10	400	14.5	13	3.8	4.5	-1	-4	+25/33	2.0:1	5	33
TM6583	10	500	30	28	2.3	3	-1	-4	+10/13	2.0:1	5	13

## **Lower Voltage Amplifiers**

This list contains Lower Voltage Amplifiers for use where a bias supply of less than +10 volts is needed. Models come in standard T0-8 cans ("TM"), TO-8B ("TR"), Surface Mount ("TN OR RN"), and SMA Connectorized Housings ("BX"). Units listed are sorted by Output Power.

Model	Frequ Ran		Ga	in	Noi	ise	Output F	Power @	IP3/IP2		ı	wer oply
	(Mł Low		(dl Typ.	3) Min.	(dl Typ.	B) Max.		Bm) Min.	(dBm) Typ.	Max.	(DC)	/p. (mA)
TM9702	500	1500	12	10.5	2.8	4	19.8	19	+31/40	2.0:1	8	107
TM3037	1030	1090	13.5	13	<2.0	2.3	19.5	19	+31/45	2.0:1	5	78
TM9700	200	2000	12	10.5	2.2	4	19	18	+ 33/43	2.2:1	6	65
TM9700	200	2000	12	10.5	2.2	4	19	18	+33/43	2.2:1	6	65
CZ8130*	kHz	400	14	13	6	7	18	15	+28/36	3.0:1	5.7	60
TM7297	20	300	10.5	9.5	4.5	6	16.5	15	+29/33	2.0:1	5	43
TM9711	1000	2000	12	10	2.2	3	16	15	+29/35	2.0:1	6	62
CZ8230	kHz	600	10	9	7	8	16	13	+25/32	3.0:1	4.5	60
TM9711	1000	2000	12	10	2.2	3	16	15	+29/35	2.0:1	6	62
TM5670	20	250	8.2	7	2	3	15.5	13.5	+28/33	2.0:1	5	25
TR9756	1200	1700	27	25	<1.0	1.75	15	14	+26/40	1.75:1	5	60
TR9756	1700	2400	23	22	1.5	2.2	15	14	+26/40	2.2:1	5	60
TM5519	5	500	15	14	2.3	3	14.5	11.5	+29/39	2.2:1	5	30
TM5544	10	500	12.5	11	2.5	3.5	14.5	11.5	+27/33	2.0:1	5	35
TR9755	800	1200	26	24	1.0	1,75	14	13	+25/40	2.0:1	5	62
TM7205	10	200	20	19	1.6	2.2	14	12	+21/26	2.0:1	5	18
TM7272	10	200	14.7	14	3	5	14	12	+29/41	1.3:1	5	35
TM9701	200	2000	12	11	3	4	14	13	+25/32	2.0:1	5	48
CZ8330	kHz	1000	6.2	5	9.5	11	14	10	+25/31	3.0:1	4.5	60
TM6520	5	500	14.5	13.5	3.5	4.5	13	11.5	+27/34	2.0:1	5	33
TM6572	5	500	14.7	13.5	4	5.5	13	11	+27/38	2.0:1	5	30
TM9107	5	1000	13.5	11.5	3.9	5	13	10	+22/26	2.0:1	5	33
TM6672	5	500	14.7	13.5	4	5.5	13	11	+27/38	2.0:1	9	30
TM7104	5	150	24	22.5	1.9	2.5	12	10.5	+25/31	2.0:1	5	20
TM9328	10	1500	14	12.5	3.2	4.5	12	9	+23/31	2.0:1	5	27
TM9355	5	2000	10	9	4	6.5	12	10	+24/30	2.0:1	5	30
TM6654	5	500	29	27.5	2.5	3	11	10	+23/33	2.0:1	5	40
TM6444	10	400	13	12	4	5.5	11	9	+25/37	2.0:1	5	15
TM7287	10	300	15.5	14.5	2.8	4	10	9	+24/33	2.0:1	5	15
TM6457	5	400	15	14	2	3	10	7.5	+24/35	2.0:1	5	16
TM9355	5	2000	10	8.5	5	6.5	10	9	+23/32	2.0:1	5 5	26
TM7103	10	150	26.5	25	2.3	2.8	9.5	8 6	+23/28	2.0:1		16
CZ8040	KHz	300	19	18	3.8	4.5	9.5 9	<u>6</u>	+21/26	3.0:1	3.5 5	25
CZ8120	KHz	400	15	13	5	6.5 4			+21/25	2.5:1	5	25 19
TM3001	400	1200	15	14	3		>8.5	8.5 7	+21/30	2.0:1	3.3	20
TM3031	100 10	500 200	13 28	12 26	<2.2 2.5	2.5 3.5	8.5 8	7	+2-/29 +15/21	2.0:1	5	21
TM7286 TM7487	10	300	<u>∠</u> 8 15.5	<u>∠o</u> 14.5	3	<u>3.5</u> 4	8	7	+22/31	2.0:1	5	13
CZ8320	KHz	1000	9	14.5 7	7	<del>4</del> 8	8	6	+20/27	2.5:1	2.8	25
CZ8320 CZ8220	KHz	600	<del>9</del>	9	6	<u>o</u> 7.5	8	6	+20/21	2.5:1	3.2	25 25
	<u>N⊓∠_</u> 5	500	15.3	14	2	3	7.5	4.5	+18/26	2.5:1	5	12
TM6210 TM6443	<del>5</del>	400	13.2	12	3.5	<u></u>	6.5	4.5 5	+19/27	2.0:1	5	10

-45-

Available as: Flatpack

#### **Features**

- Wideband Frequency: 100-1000 MHz
   High Output Power: +30 dBm Typical
- Operating Temp. 0 °C to + 70 °C

### **Specifications**

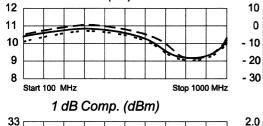
CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = 0 °C to +70 °C
Frequency (MHz)	100 - 1000 MHz	100 - 1000 MHz
Gain (dB)	10	8.5 Min.
Power @ 1 dB Comp. (dBm)	30	29 Min.
Reverse Isolation (dB)	-20	-15 Max.
VSWR In Out	1.8:1 1.8:1	2:0:1 Max. 2:0:1 Max.
Noise figure (dB)	7	11 Max.
Power Vdc mA	+15 350	+15 375 Max.

**Maximum Ratings** 

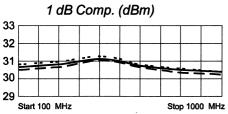
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts

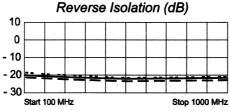
Note: Care should always be taken to effectively ground the case of each unit.

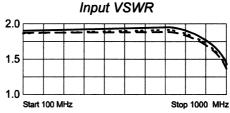
## **Typical Performance Data**

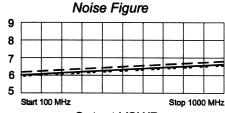


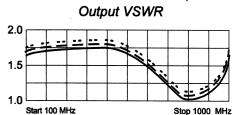
Gain (dB)











# RF AMPLIFIER MODEL BXMP1001

Package:

**Connectorized Housing** 

#### **Features**

- Low Noise Figure: 3.7 dB Typical
- High 3rd Order Intercept: >+49 dBm Typical
- High Power 1 db Comp. +32 dBm

**Specifications** 

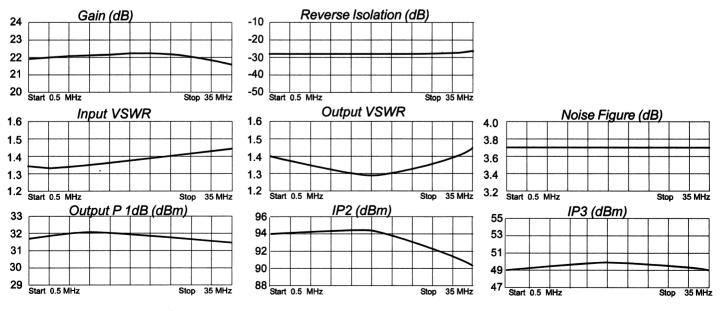
<u>Specifications</u>				
CHARACTERISTIC	TYPICAL	MIN/MAX		
	Ta= 25 °C	Ta = 0 °C to +50 °C		
Frequency	0.5 - 35 MHz	0.5 - 35 MHz		
Gain (dB)	22	22.5 Max.		
Gain Flatness (dB)	0.5	21.5 Min.		
Power @ 1 dB Comp. (dBm)	+32	+31 Min.		
IP2 0.5-25 MHz	95	92 Min.		
25-35 MHz	92	90 Min.		
IP3	49	47 Min.		
Reverse Isolation (dB)	- 27	- 26 Min.		
VSWR In	<1.5:1	1.5:1 Max.		
Out	<1.5:1	1.5:1 Max.		
Noise figure (dB)	3.7	4.0 Max.		
Power Vdc	+24	+24		
mA	425	450 Max.		

Maximum Ratings
Ambient Operating Temps

Ambient Operating Temperature	0°C to + 50 °C
Storage Temperature	55°C to + 85 °C
DC Voltage	+ 25 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	1 Minute Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## Typical Performance Data @25°C





## RF AMPLIFIER **FPMP1002 MODEL**

Package: Available as: **Flatpack** 

Surface Mount - Gullwing

Connectorized Housing

#### **Features**

■ High Power Output: + 30.5 dBm

Medium Gain: 10 dB Typical

Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 100 MHz	10 - 100 MHz
Gain (dB)	10	8.5
Power @ 1 dB Comp. (dBm)	+ 30.5	+ 30 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	1.8:1 1.8:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.5	6.0 Max.
Power Vdc mA	+15 320	+15 365 Max.

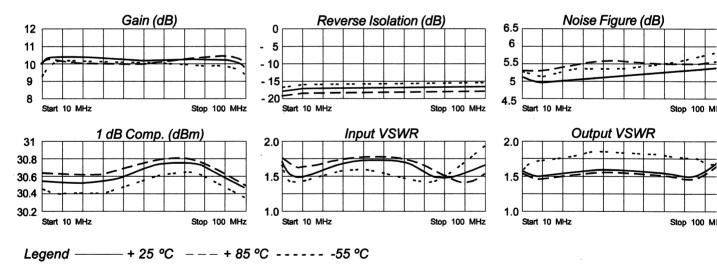
Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+60 (Typ
Second Order Two Tone Intercept Point	+54 (Typ
Third Order Two Tone Intercept Point	+45 (Tvp

Maximum Ratings

waxiiiiuiii izauiiyə	
Ambient Operating Temperature	55°C to + 100°
Storage Temperature	62°C to + 125°
Case Temperature	+ 125 °
DC Voltage	+ 18 Vol
Continuous RF Input Power	+ 27 dB
Short Term RF Input Power	500 Milliwat
	(1 Minute Max
Maximum Peak Power	0.5 Watt
	(3 µsec Max

Note: Care should always be taken to effectively ground the case of each unit.





## RF AMPLIFIER MODEL BXMP1003

Package:

**Connectorized Housing** 

### **Features**

- Low Noise Figure:3.7 dB Typical
- High 3rd Order Intercept: >+49 dBm Typical
- High Power 1 db Comp. +32 dBm

**Specifications** 

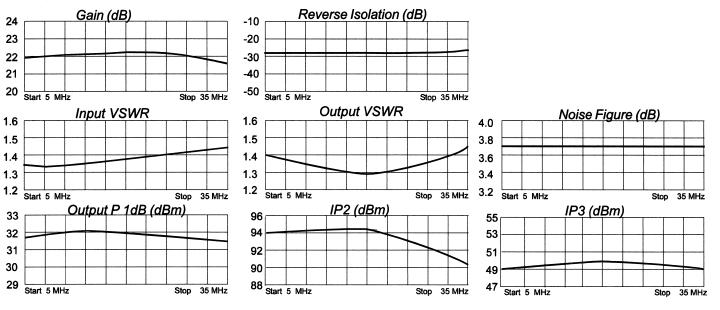
Specifications		
CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = 0 °C to +50 °C
Frequency	5 - 35 MHz	5 - 35 MHz
Gain (dB)	22	22.5 Max.
Gain Flatness (dB)	0.5	21.5 Min.
Power @ 1 dB Comp. (dBm)	+32	+31 Min.
IP2 5-25 MHz	95	92 Min.
25-35 MHz	92	90 Min.
IP3	49	47 Min.
Reverse Isolation (dB)	- 27	- 26 Min.
VSWR In	<1.5:1	1.5:1 Max.
Out	<1.5:1	1.5:1 Max.
Noise figure (dB)	3.7	4.0 Max.
Power Vdc	+24	+24
mA	425	450 Max.

**Maximum Ratings** 

Ambient Operating Temperature	0°C to + 50 °C
Storage Temperature	55°C to + 85 °C
DC Voltage	+ 25 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
•	

Note: Care should always be taken to effectively ground the case of each unit.

## Typical Performance Data @25°C





Available as: TM3001, 4 Pin TO-8 (T4)

TN3001, 4 Pin Surface Mount (SM3) FP3001, 4 Pin Flatpack (FP4) BX3001, Connectrized Housing (H1)

#### **Features**

■ 5 Volt Operation; Medium Gain: 15 ± 1.0 dB

■ Medium Output Power: +10 ± 1.5 dBm

Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	400 - 1200 MHz	400 - 1200 MHz	
Gain (dB)	15	15 ± 1.0	
Power @ 1 dB Comp. (dBm)	>+8.5	+10.0 ± 1.5	
Reverse Isolation (dB)	- 16.5	-16.0 Max.	
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	3	4.0 Max.	
Power Vdc mA	+5 19	+5 25.0 Max.	

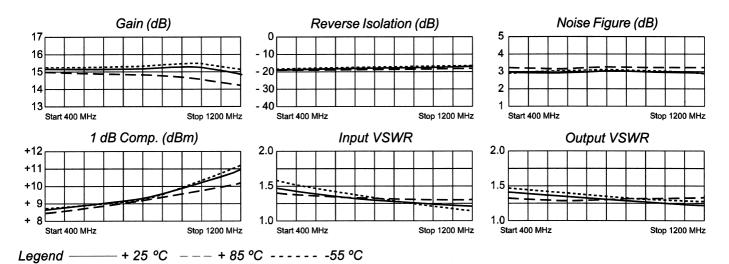
## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+35	(Min.)
Second Order Two Tone Intercept Point	+30	(Min.)
Third Order Two Tone Intercept Point	+21	(Min.)

#### **Maximum Ratings**

maximum ratingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 8 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.1 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Package Style: 4 Pin TO-8B

Also Available in: 4 Pin Flatpack, Surface Mount Flatpack, and Connectorized Housings

#### **Features**

■ High Out put Power: +23 dBm Minimum

■ High Gain: 19 dB Minimum

Operating Case Temp. - 26 °C to +71 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Tc = 25 °C	MIN/MAX Tc = -26 °C to
Frequency	500 - 1000 MHz	500 - 1000 MHz
Gain (dB)	20.5	20.75 ± 1.75
Power @ 1 dB Comp. (dBm)	+25	+23.0 Min.
Reverse Isolation (dB)	- 41	-40.0 Max.
VSWR In Out	<1.8:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.5	3.0 Max.
VSWR Vdc mA	+12 255	+12 270 Max.

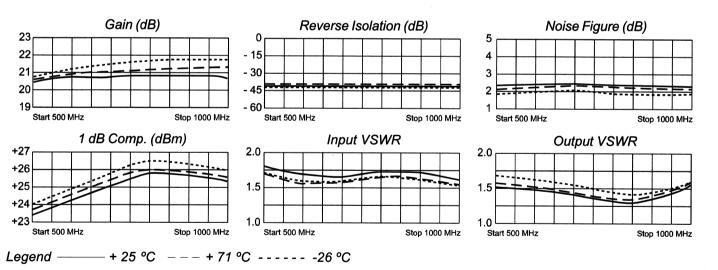
### **Intermodulation Performance**

Second Order Harmonic Intercept Point	+45	(Min.)
Second Order Two Tone Intercept Point	+42	(Min.)
Third Order Two Tone Intercept Point	+32	(Min.)

#### **Maximum Ratings**

gc	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 15 Volts
Continuous RF Input Power	+ 13dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Available as: TM3028, 4 Pin TO-8 (T4)

TN3028, 4 Pin Surface Mount (SM3) FP3028, 4 Pin Flatpack (FP4) BX3028, Connectrized Housing (H1)

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point ...... +57 (Min.)

Second Order Two Tone Intercept Point ...... +51 (Min.)

Third Order Two Tone Intercept Point ...... +38 (Min.)

#### **Features**

■ High Power: +24 dBm Typ.

■ Low Noise: 2.2 dB Typ.

■ Operating Temp. - 55 °C to +85 °C

■ Units are Unconditionally Stable

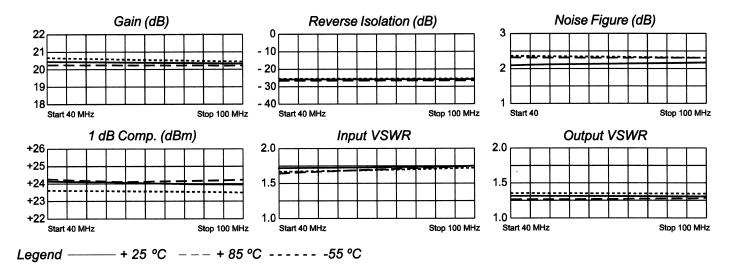
### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	40-100 MHz	40-100 MHz
Gain (dB)	20.5	19.5 Min./21.0 Max.
Power @ 1 dB Comp. (dBm)	+24	+23.0 Min.
Reverse Isolation (dB)	- 25	-24 Max.
VSWR In Out	<1.75:1 <1.45:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.2	3.0 Max.
Power Vdc m A	+15 82	+15 94 Max.

**Maximum Ratings** 

maximum raumge	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Available as: TR3029, 4 Pin TO-8 (T4)

RN3029, 10 Lead Gull-Wing (SG4) BR3029, Connectorized Housing (H2)

#### **Features**

■ Low Noise Figure: 2.5dB Max., Freq. < 400 MHz

■ High Third Order Intercept: +27 dBm Minimum

Operating Temp. - 55 °C to +85 °C

Units are Unconditionally Stable

## **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX	
	Ta= 25 °C	Ta = -55 °C to +85 °C	
Frequency	100 - 500 MHz	100 - 500 MHz	
Gain (dB)	25.5	24	
Power @ 1 dB Comp. (dBm)	+16	+14.0 Min.	
Reverse Isolation (dB)	- 32	-30 Max.	
VSWR In	<1.75:1	2.0:1 Max.	
Out	<1.75:1	2.0:1 Max.	
Noise figure (dB)	<2.2	2.5 * Max.	
Power Vdc	+15	+15	
m A	45	52 Max.	

## Typical Intermodulation Performance at 25 ° C

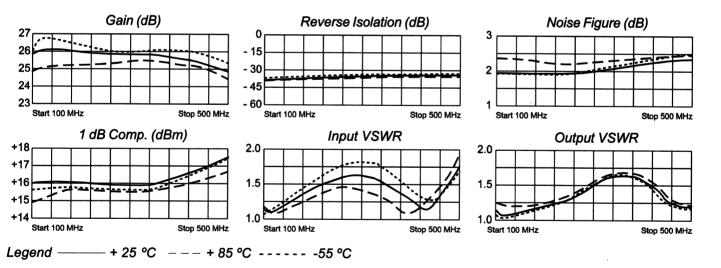
Second Order Harmonic Intercept Point		
Second Order Two Tone Intercept Point	+41	(Min.)
Third Order Two Tone Intercept Point	+27	(Min.)

#### **Maximum Ratings**

maxiiiiuiii i\aliiiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.2 Watt
	(3 µsec Max.)

<sup>\*</sup> Above 400 MHz, Noise Figure = 3.0 dB Maximum

Note: Care should always be taken to effectively ground the case of each unit.





Available as: TM3030, 4 Pin TO-8 (T4)

TN3030, 4 Pin Surface Mount (SM3) FP3030, 4 Pin Flatpack (FP4) BX3030, Connectrized Housing (H1)

#### **Features**

- Medium Output Power: +14.5 dBm Minimum
- Medium Third Order Intercept: +28 dBm Minimum
- Operating Temp. 55 °C to +85 °C
- Units are Unconditionally Stable

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	500 - 1000 MHz	500 - 1000 MHz
Gain (dB)	15	13.5
Power @ 1 dB Comp. (dBm)	+16.5	+14.5 Min.
Reverse Isolation (dB)	- 17	-15.5 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	5.5 Max.
Power Vdc mA	+15 47	+15 52.0 Max.

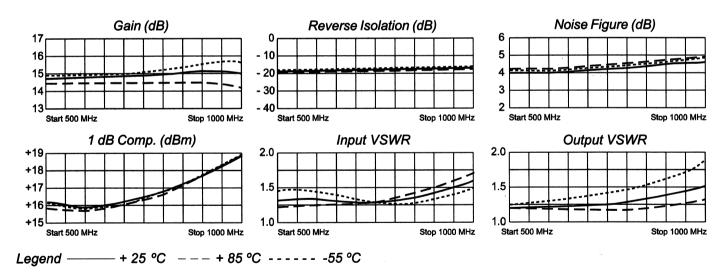
Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+40 (Min.)
Second Order Two Tone Intercept Point	+35 (Min.)
Third Order Two Tone Intercept Point	+28 (Min.)

**Maximum Ratings** 

Maxillulli Katiligs	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Package Style: 4 Pin TO-8

Also Available in: 4 Pin Flatpack, Surface Mount Flatpack, and Connectorized Housings

#### **Features**

- 3.3 Volt Operation
- Low Noise Figure: 2.5 dB Maximum
- Operating Temp. 10 °C to +60 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -10 °C to +60 °C	
Frequency	100 - 500 MHz	100 - 500 MHz	
Gain (dB)	13	13.5 ± 1.5	
Power @ 1 dB Comp. (dBm)	+8.5	+7.0 Min.	
Reverse Isolation (dB)	- 19	-18.0 Max.	
VSWR In Out	<1.85:1 <1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<2.2	2.5 Max.	
VSWR Vdc mA	+3.3 19.2	+3.3 Max. 20	

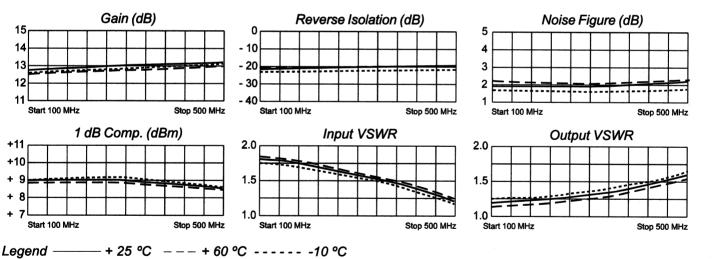
Typical Intermodulation Performance at 25 ° C

Third Order Two Tone Intercept Point ...... +20 (Typ.)

**Maximum Ratings** 

waxiiiiuiii Nauiiys	1.00
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 8 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	20 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.05 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Package Style: 0.45" Sq. Surface Mount Also Available in: 4 Pin Flatpack, TO-8 Package, and Connectorized Housings

#### **Features**

Low Noise Figure: 2 dB Typical
 Medium Gain: 16.5 dB Typical
 Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	100 - 400 MHz	100 - 400 MHz
Gain (dB)	16.5	16.0 Min.
Power @ 1 dB Comp. (dBm)	+9.5	+8.0 Min.
Reverse Isolation (dB)	- 19	-17.0 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.0 Max.
VSWR Vdc mA	+15 16	+15 Max. 18

Typical Intermodulation Performance at 25 ° C

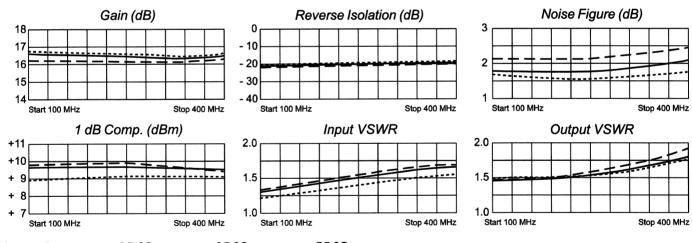
Second Order Harmonic Intercept Point	+34	(Typ.)
Second Order Two Tone Intercept Point	+29	(Typ.)
Third Order Two Tone Intercept Point	+22	(Typ.)

#### **Maximum Ratings**

Maximumitatingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.1 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Leaend ------ + 25 °C --- + 85 °C ----- -55 °C



Package Style: 4 Pin TO-8

Also Available in: 4 Pin Flatpack, Surface Mount Flatpack, and Connectorized Housings

#### **Features**

- High Output Power: +22 dBm Typical
- High IP3: +36 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	30 - 1000 MHz	30 - 1000 MHz
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+22	+20.5 Min.
Reverse Isolation (dB)	- 18	-17.0 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	6.0 Max.
VSWR Vdc mA	+15 90	+15 95 Max.

## Typical Intermodulation Performance at 25 ° C

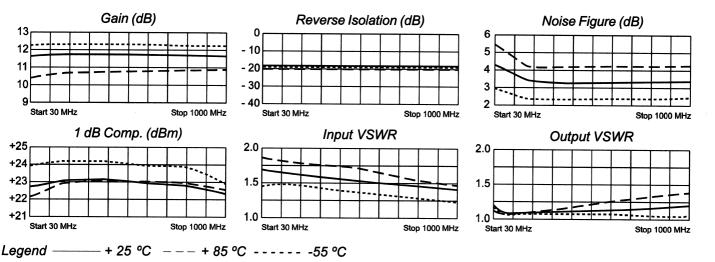
Second Order Harmonic Intercept Point	+50 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	100 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





Available as: TM3035, 4 Pin TO-8 (T4)

TN3035, 4 Pin Surface Mount (SM3) FP3035, 4 Pin Flatpack (FP4) BX3035, Connectorized Housing (H1)

#### **Features**

High Output Power: >+28.5 dBm
 Medium Gain: 16 dB Typical
 Operating Temp. - 55 °C to +100 °C
 Environmental Screening Available

#### **Specifications**

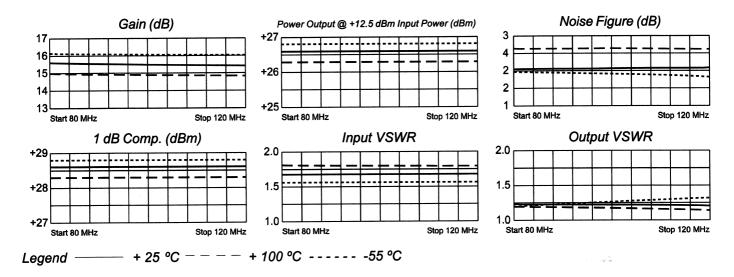
CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +100 °C
Frequency	80 - 120 MHz	80 - 120 MHz
Gain (dB)	16	15
Power @ 1 dB Comp. (dBm)	+28.5	+27 Min.
Reverse Isolation (dB)	- 22.5	-21.5 Max.
VSWR In Out	<1.9 <1.25	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3	5.0 Max.
Power Vdc mA	+11 200	+11 215 Max.

Typical Intermodulation Performance at 25 ° C

**Maximum Ratings** 

waximum kaungs	
Ambient Operating Temperature	55°C to + 110 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	200 Milliwatts
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Available as: TM3036, 4 Pin TO-8 (T4)

TN3036, 4 Pin Surface Mount (SM3) FP3036, 4 Pin Flatpack (FP4) BX3036, Connectorized Housing (H1)

## **Features**

■ High Out put Power: +25.5 dBm Typical

High Third Order Intercept: +40 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	30 - 110 MHz	30 - 110 MHz
Gain (dB)	20.5	20.5 ± 0.75
Power @ 1 dB Comp. (dBm)	+25.5	+24.0 Min.
Reverse Isolation (dB)	- 25	-24.0 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
VSWR Vdc mA	+15 102	+15 ± 0.3 115 Max.

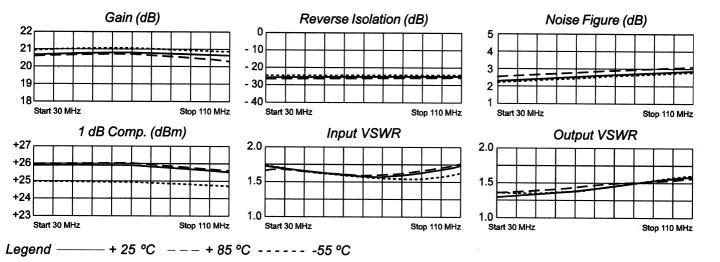
## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+55 (Typ.)
Second Order Two Tone Intercept Point	+50 (Typ.)
Third Order Two Tone Intercept Point	+40 (Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Available as: TM3037, 4 Pin TO-8 (T4)

TN3037, 4 Pin Surface Mount (SM3)

FP3037, 4 Pin Flatpack (FP4)

BX3037, Connectorized Housing (H1)
PN3037, Reduced Size Surface Mount (SM11)

#### **Features**

Low Noise Figure: 2.3 dB MaximumHigh Output Power: +19 dB Minimum

■ Operating Temp. 0 °C to +50 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = 0 °C to +50 °C	
Frequency		1030 -1090 MHz	1030 -1090 MHz	
Gain (dB)		13.5	13.5 ± 0.5	
Power @ 1 dl Comp. (dB		+19.5	+19.0 Min.	
Reverse Isolation (d	B)	- 21.5	-21 Max.	
VSWR	In Out	<1.5:1 <1.95:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)		<2.0	2.3 Max.	
Power	Vdc m A	+5 78	+5 80 Max.	

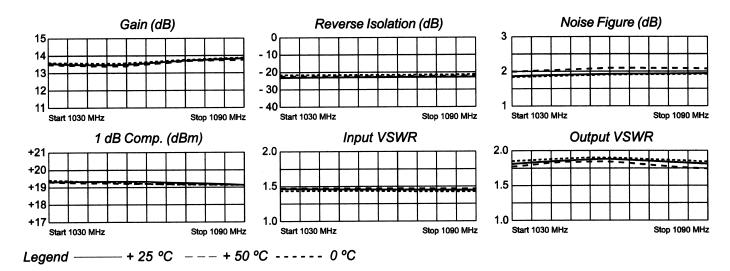
Note: Care should always be taken to effectively ground the case of each unit.

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+51	(Typ.)
Second Order Two Tone Intercept Point	+45	(Typ.)
Third Order Two Tone Intercept Point	+31	(Typ.)

## **Maximum Ratings**

Maxillium Naungs	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 16 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)





Available as:

TM3039, 4 Pin TO-8 (T4)

TN3039, 4 Pin Surface Mount (SM3)

FP3039, 4 Pin Flatpack (FP4) BX3039, Connectorized Housing (H1)

### **Features**

■ Low Noise: 2.5 dB Typical

■ High Output Power: +22 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	100 - 220 MHz	100 - 220 MHz
Gain (dB)	18	17.5 Min.
Power @ 1 dB Comp. (dBm)	+22	+19 <b>M</b> in.
Reverse Isolation (dB)	-19.5	- 19 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+12 80	+12 87 Max.

## Typical Intermodulation Performance at 25 ° C

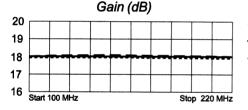
Second Order Harmonic Intercept Point	+50 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+38 (Typ.)

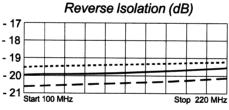
### **Maximum Ratings**

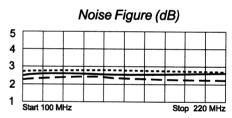
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 15 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

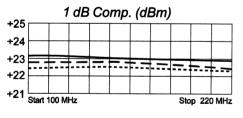
Note: Care should always be taken to effectively ground the case of each unit.

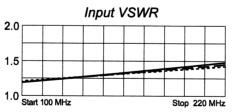
## **Typical Performance Data**

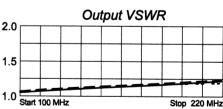












Legend ——— + 25 °C — — + 85 °C ---- 55 °C

#### **Linear S-Parameters**

FREQ.	S11	<b>\$21</b> -	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.12 - 93	7.85 -162	.1005 -161	.09 - 47
10	.07 -110	8.00 -173	.1026 -173	.05 - 59
20	.05 -127	8.01 -180	.1065 180	.03 - 60
50	.04 -138	8.04 171	.1012 169	.03 - 51
100	.07 -119	8.09 158	.1044 156	.06 - 54
150	.13 -129	8.13 145	.1053 143	.07 - 63
200	.19 -150	8.05 132	.1064 131	.09 - 83
250	.24 -167	7.89 119	.1089 118	.10 -109
300	.28 178	7.58 105	1089 107	13 -138



TM3040, 4 Pin TO-8 (T4) Available as:

TN3040, 4 Pin Surface Mount (SM3)

FP3040, 4 Pin Flatpack (FP4)

BX3040, Connectorized Housing (H1) PN3040, Reduced Size Surface Mount (SM11)

#### **Features**

■ High Output Power: +27 dBm Typical

■ High Dynamic Range: IP3 = +39 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	100 - 250 MHz	100 - 250 MHz
Gain (dB)	14.5	13.5 Min.
Power @ 1 dB Comp. (dBm)	27	+26 Min.
Reverse Isolation (dB)	22	- 20 Max.
VSWR In Out	1.6 1.35	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4	6.0 Max.
Power Vdc mA	+15 110	+15 125 Max.

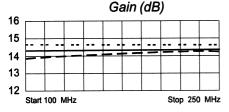
Note: Care should always be taken to effectively ground the case of each unit.

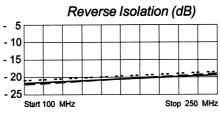
## Typical Intermodulation Performance at 25 ° C

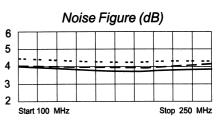
Second Order Harmonic Intercept Point	+58 (Typ.)
Second Order Two Tone Intercept Point	+54 (Typ.)
Third Order Two Tone Intercept Point	+39 (Typ.)

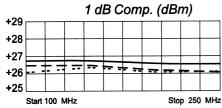
Maximum Ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
•	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 usec Max.)

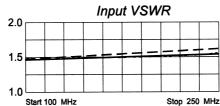
## **Typical Performance Data**

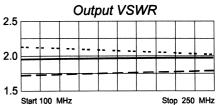












Legend ----- + 25 °C --- + 85 °C ---- -55 °C



Available as: TM3042, 4 Pin TO-8 (T4)

TN3042, 4 Pin Surface Mount (SM3)

FP3042, 4 Pin Flatpack (FP4)

BX3042, Connectorized Housing (H1)

PN3042, Reduced Size Surface Mount (SM11)

### **Features**

■ High Gain: +23 dB Typ.

Low Noise Figure: 3 dB Typ.

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 1200 MHz	10 - 1200 MHz	
Gain (dB)	23	21 Min.	
Power @ 1 dB Comp. (dBm)	19	18 Min.	
Reverse Isolation (dB)	- 30	- 28 Max.	
VSWR In Out	1.2:1 1.5:1	1.7:1 Max. 1.7:1 Max.	
Noise figure (dB)	3.0	4.5 Max.	
Power Vdc mA	+15 75	+15 85 Max.	

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+45	(Typ.)
Second Order Two Tone Intercept Point	+40	(Typ.)
Third Order Two Tone Intercept Point	+32	(Typ.)

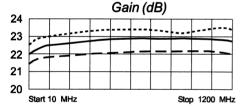
## **Maximum Ratings**

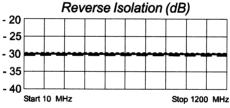
maximam ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 17 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(0 14 )

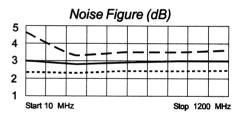
(3 μsec Max.)

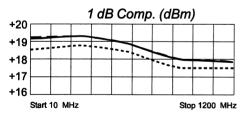
Note: Care should always be taken to effectively ground the case of each unit.

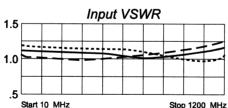
## **Typical Performance Data**

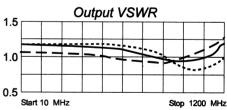












Legend ---- + 25 °C --- + 85 °C ---- -55 °C



Available as: TM3072, 4 Pin TO-8 (T4)

TN3072, 4 PIN Surface Mount (SM3) FP3072, 4 Pin Flatpack (FP4) BX3072, Connectorized Housing (H1)

#### **Features**

■ High Output Power: 27 dBm Typical

■ Low Phase Bipolar Design

■ Operating Temp. - 55 °C to + 85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	10 - 200	10 - 200
Gain (dB)	14	13 Min. 15 Max
Power @ 1 dB Comp. (dBm)	28	+26 Min
Reverse Isolation (dB)	-17	-16 Max.
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5	6 Max.
Power Vdc m A	+15 180	+15 185 Max.

## Typical Intermodulation Performance at 25 ° C

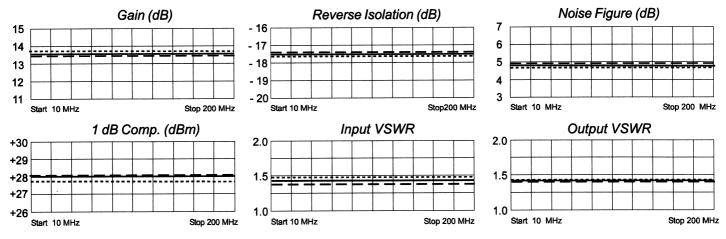
Second Order Harmonic Intercept Point	+65 (Typ.)
Second Order Two Tone Intercept Point	+60 (Typ.)
Third Order Two Tone Intercept Point	+45 (Typ.)

#### **Maximum Ratings**

Maximumitatingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 17 Volts
Continuous RF Input Power	+15 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Legend ---- + 25 °C --- + 85 °C ---- - -55 °C



Available as: TM4002, 4 Pin TO-8 (T4)

TN4002, 4 Pin Surface Mount (SM3) BX4002, Connectorized Housing (H1)

#### **Features**

■ High Gain: 20 dB Typical

■ Medium Power @ 1 dB Comp: 19.5 dBm Typical

■ Operating Temp. -55 °C to +85 °C

Environmental Screening available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	10 -500	10 - 500
Gain (dB)	+20	+19 Min.
Power @ 1 dB Comp. (dBm)	+19.5	+18.5 Min.
Reverse Isolation (dB)	- 23	- 22 Max.
VSWR In Out	1.4:1 1.3:1	1.75:1 Max. 1.75:1 Max.
Noise figure (dB)	4	5 Max.
Power Vdc mA	15 80	15 85 Max.

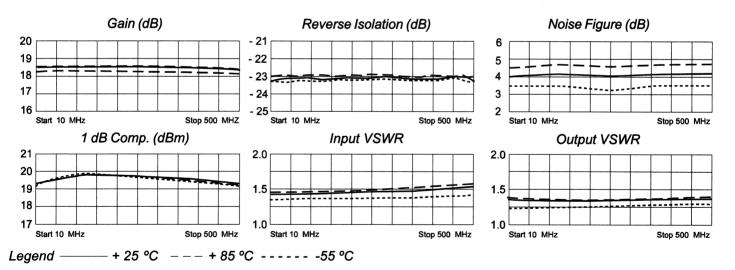
## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+45(Typ.)
Third Order Two Tone Intercept Point	+35(Typ.)

### **Maximum Ratings**

Ambient Operating Temperature .	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 16 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Available as: TM4003, 4 Pin TO-8 (T4)

TN4003, 4 Pin Surface Mount (SM3) BX4003, Connectorized Housing (H1)

### **Features**

■ High Gain: 20 dB Typical

■ Medium Power @ 1 db Comp: + 19.5 dBm Typical

■ Operating Temp. -55 ℃ to +85 ℃

Environmental Screening available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	10 -500	10 - 500
Gain (dB)	+20	+19 Min.
Power @ 1 dB Comp. (dBm)	+19.5	+18.5 Min.
Reverse Isolation (dB)	- 23	- 22 Max.
VSWR In Out	1.4:1 1.3:1	1.75:1 Max. 1.75:1 Max.
Noise figure (dB)	4	5 Max.
Power Vdc mA	6 80	6 85 Max.

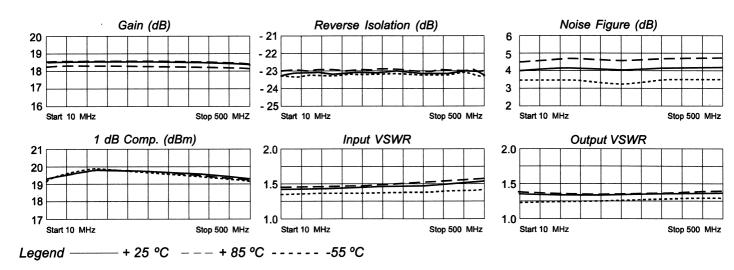
Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+45(Typ.)
Third Order Two Tone Intercept Point	+35(Typ.)

**Maximum Ratings** 

maximum raungs	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 7 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.





Available as: TM4172, 4 Pin TO-8 (T4)

TN4172, 4 Pin Surface Mount (SM3) FP4172, 4 Pin Flatpack (FP4) BX4172, Connectorized Housing (H1) PN4172, Reduced Size Surface Mount (SM11)

#### **Features**

■ Low Noise figure: 3.0 dB Typical
■ High Output Power: +23 dBm Typical
■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 250	10 - 250
Gain (dB)	13.5	12.0 Min.
Power @ 1 dB Comp. (dBm)	+23	+21 Min.
Reverse Isolation (dB)	- 20	Max.
VSWR In Out	1.6:1 1.6:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.0	4.0 Max.
Power Vdc mA	+12 90	+12 95 Max.

## Typical Intermodulation Performance at 25 ° C

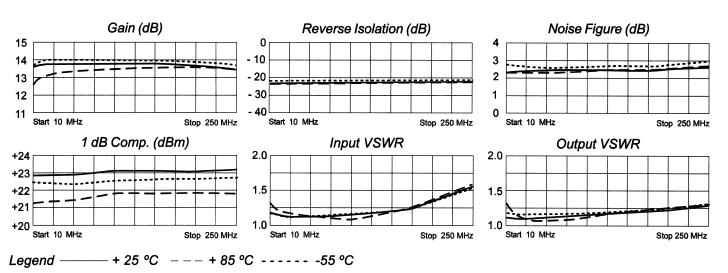
Second Order Harmonic Intercept Point	+50(Typ.)
Second Order Two Tone Intercept Point	+43(Typ.)
Third Order Two Tone Intercept Point	+35(Typ.)

### **Maximum Ratings**

maximamitatings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 15 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.08 -112	4.80 -169	.0725 -171	.07 - 6
50	.05 -159	4.84 168	.0731 165	.06 - 21
100	.04 -139	4.86 151	.0769 149	.06 - 49
150	.07 -114	4.88 135	.0797 132	.06 - 81
200	.14 -120	4.87 118	.0816 114	.06 -127
250	.22 -139	4.76 100	.0854 99	.09 -163



Available as: TM5101, 4 Pin TO-8 (T4)

TN5101, 4 Pin Surface Mount (SM3) FP5101, 4 Pin Flatpack (FP4)

BX5101, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 2.75 dB Typical

■ Medium Gain: 13 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	13 ±0.5	12 Min./14 Max.
Power @ 1 dB Comp. (dBm)	+7.5	+6.0 Min.
Reverse Isolation (dB)	- 15.5	- 15 Max.
VSWR In Out	1.25:1 1.4:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.75	4.0 Max.
Power Vdc mA	+15 17	+15 20 Max.

## Typical Intermodulation Performance at 25 ° C

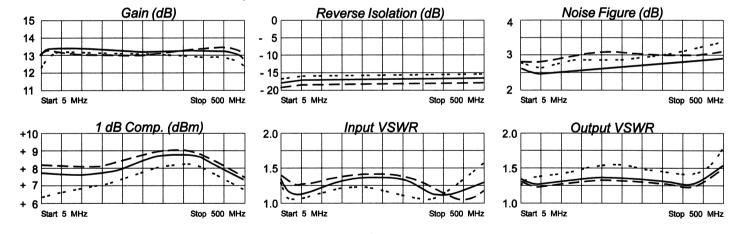
Second Order Harmonic Intercept Point	+36 (Typ.)
Second Order Two Tone Intercept Point	+31 (Typ.)
Third Order Two Tone Intercept Point	+21 (Typ.)

## **Maximum Ratings**

waxiiiuiii itatiiigs	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ. MHz	 Mag	S11 Deg	: Mag	S21 Deg	\$ Mag	612 Deg	5 Mag	522 Deg
5	.13	-48	4.53	-165	.13	-164	.15	-35
50	.08	11	4.64	167	.14	167	.12	5
100	.11	22	4.61	153	.14	150	.14	11
200	.15	8	4.58	126	.14	122	.18	-5
300	.13	-21	4.58	98	.15	94	.16	-42
400	.03	- <del>9</del> 9	4.62	66	.16	66	.12	-121
500	.16	112	4.38	32	.17	36	26	155



Available as: TM5102, 4 Pin TO-8 (T4)

TN5102, 4 Pin Surface Mount (SM3)

FP5102, 4 Pin Flatpack (FP4)

BX5102, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 12.5 dB Typical

High Output Power: +22 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency				
Gain (dB)	5 - 5002M6Hz	51.600 MHz		
Power @ 1 dB Comp. (dBm)	+22	+20.0 Min.		
Reverse Isolation (dB)	- 16	- 15 Max.		
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	5.5	7.0 Max.		
Power Vdc mA	+15 88	+15 95 Max.		

## Typical Intermodulation Performance at 25 ° C

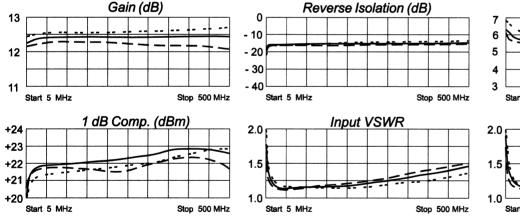
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

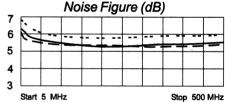
#### **Maximum Ratings**

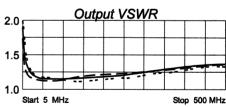
maximam ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**







Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.14 - 82	4.20 -166	.12 11	.15 115
50	.03 95	4.36 175	.13 - 2	.05 85
100	.09 62	4.31 166	.13 - 6	.08 64
200	.16 23	4.24 150	.14 - 14	.13 30
300	.21 - 10	4.23 89	.15 -24	.16 - 4
400	.23 -42	4.27 58	.15 -35	.16 -43
500	17 - 75	4.35 24	.16 -47	13 -94



## RF AMPLIFIER TM5103 **MODEL**

Available as: TM5103, 4 Pin TO-8 (T4)

TN5103, 4 Pin Surface Mount (SM3)

FP5103, 4 Pin Flatpack (FP4)

BX5103, Connectorized Housing (H1)

#### **Features**

- High Third Order Intercept: +36 dBm Typical
- High Output Power: +23 dBm Typical Operating Temp. 55 °C to +85 °C
- **Environmental Screening Available**

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 300 MHz	5 - 300 MHz
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+23	+21.0 Min.
Reverse Isolation (dB)	- 14.5	- 14 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	6.5 Max.
Power Vdc mA	+15 85	+15 92 Max.

## Typical Intermodulation Performance at 25 ° C

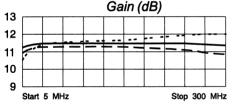
Second Order Harmonic Intercept Point	+51	(Typ.)
Second Order Two Tone Intercept Point	+45	(Typ.)
Third Order Two Tone Intercept Point	+36	(Typ.)

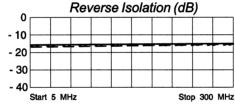
## **Maximum Ratings**

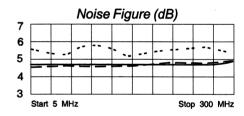
Maximumitatingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

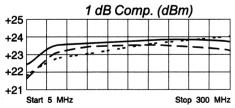
Note: Care should always be taken to effectively ground the case of each unit.

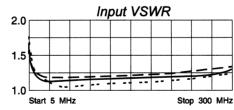
## **Typical Performance Data**

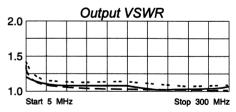












- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.				S21		S1 <u>2</u>		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg	
5 .	.21	-65	3.63	-160	.15	10	.10	81	
10	.12	<b>-6</b> 3	3.73	-171	.15	. 5	.06	61	
25	.06	<del>-4</del> 8	3.78	178	.15	3	.04	29	
50	.04	-26	3.80	169	.15	2	.04	6	
100	.05	-13	3.81	155	.16	3	.04	-23	
150	.07	-20	3.84	141	.16	3	.03	-51	
200	.09	-34	3.85	127	.17	3	.03	-88	
250	.11	-50	3.85	113	.18	2	.03	-88 -147	
300	.13	-68	3.80	97	.19	1	.05	159	
350	.15	-88	3.67	80	.20	-1	.08	126	
400	.15	-108	3.42	63	.20	-5	.12	98	

**Amplifonix** 

# RF AMPLIFIER TM5104 **MODEL**

Available as: TM5104, 4 Pin TO-8 (T4)

> TN5104, 4 Pin Surface Mount (SM3) FP5104, 4 Pin Flatpack (FP4)

BX5104, Connectorized Housing (H1)

## **Features**

Low Noise: 2dB Typical

High Dynamic Range: +32dBm Typical IPs Operating Temp. - 55 °C to +85 °C

Environmental Screening Available

# **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	12.0	10.5 Min.
Power @ 1 dB Comp. (dBm)	+15.0	+13.0 Min.
Reverse Isolation (dB)	- 15.5	- 14.5 Max.
VSWR In Out	1.35:1 1.50:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.5 Max.
Power Vdc m A	+15 35	+15 38 Max.

# Typical Intermodulation Performance at 25 ° C

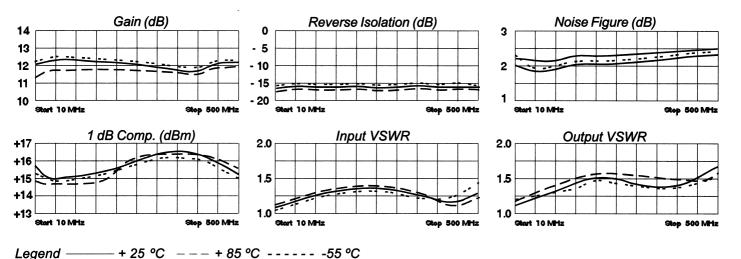
Second Order Harmonic Intercept Point	+52(Typ.)
Second Order Two Tone Intercept Point	+46(Typ.)
Third Order Two Tone Intercept Point	+32(Typ.)

## Maximum Patings

maxiiiuiii i\auiiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



### Linear S-Parameters

FREQ.	8	311		S21	,	S12		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.07	-114	4.04	-161	.16	-160	.06	-115
10	.03	-144	4.18	-171	.17	-171	.03	-152
50	.04	112	4.21	174	.17	173	.04	122
100	.08	89	4.19	165	.17	163	.07	92
200	.16	60	4.17	148	.17	145	.13	56
300	.20	36	4.17	132	.17	129	.18	29
400	.23	15	4.25	116	.17	114	.22	5
500	21	- 5	4 26	98	18	99	25	- 19



Available as: TM5105, 4 Pin TO-8 (T4)

TN5105, 4 Pin Surface Mount (SM3) FP5105, 4 Pin Flatpack (FP4) BX5105, Connectorized Housing (H1)

## **Features**

Low Noise Figure: <2.75 dB Typical</p>

■ Medium Gain: 12 dB Typical
■ Operating Temp. - 55 °C to +85 °C

Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 300 MHz	5 - 300 MHz
Gain (dB)	12	11.0 Min.
Power @ 1 dB Comp. (dBm)	+7	+5.5 Min.
Reverse Isolation (dB)	- 18.5	- 16 Max.
VSWR In Out	<1.5:1 <1.6:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.75	4.0 Max.
Power Vdc mA	+15 17	+15 19 Max.

# Typical Intermodulation Performance at 25 ° C

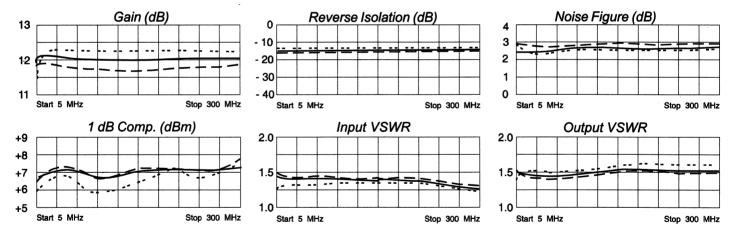
Second Order Harmonic Intercept Point	+35(Typ.)
Second Order Two Tone Intercept Point	+29(Typ.)
Third Order Two Tone Intercept Point	+21(Typ.)

# **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



- + 25 °C --- + 85 °C ---- -55 °C

### Linear S-Parameters

FREQ. MHz	: Mag	S11 Deg	5 Mag	521 Deg	S Mag	612 Deg	: Mag	S22 Deg
5	.19	-15	3.93	-165	.11	-165	.21	-10
10	.18	<del>.</del> 9	4.02	-174	.12	-175	.21	-6
50	.17	<u>.</u>	4.00	168	.12	168	.20	-8
100	.16	-13	3.99	155	.12	154	.20	-14
200	.15	-31	4.00	128	.12	128	.22	-34
300	.12	-66	4.03	101	.12	102	.22	-68
400	10	-145	4 04	72	12	75	23	-116



Available as: TM5107, 4 Pin TO-8 (T4)

TN5107, 4 Pin Surface Mount (SM3)

FP5107, 4 Pin Flatpack (FP4)

BX5107, Connectorized Housing (H1)

# **Features**

■ Low Noise Figure: < 1.75 dB Typical

Medium Gain: 15 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 550 MHz	10 - 550 MHz
Gain (dB)	15.0	14.0 Min.
Power @ 1 dB Comp. (dBm)	>+2	+1.0 Min.
Reverse Isolation (dB)	- 20	- 18 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<1.75	2.3 Max.
Power Vdc mA	+15 9.0	+15 10.0 Max.

# Typical Intermodulation Performance at 25 ° C

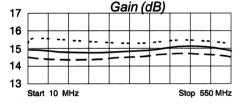
Second Order Harmonic Intercept Point	+22	(Typ.)
Second Order Two Tone Intercept Point	+16	(Typ.)
Third Order Two Tone Intercept Point	+13	(Typ.)

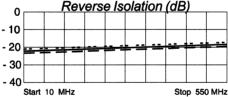
# **Maximum Ratings**

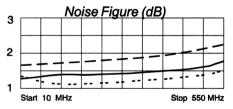
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

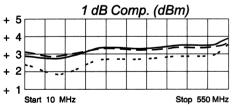
Note: Care should always be taken to effectively ground the case of each unit.

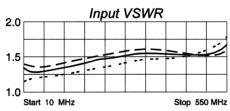
# **Typical Performance Data**

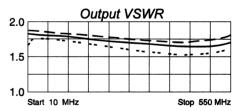












.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

## Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.14 - 29	5.70 -176	.09 -176	.29 - 11
50	.13 - 40	5.63 167	.09 166	.28 - 14
100	.15 - 64	5.59 154	.09 151	.27 - 23
200	.20 -106	5.54 127	.09 124	.26 - 44
300	.24 -143	5.49 101	.09 95	.25 - 67
400	.26 176	5.57 <i>7</i> 2	.10 69	.25 - 92
500	.26 117	5.56 41	.10 40	.26 -125
550	.28 80	5.47 23	.10 <b>27</b>	.27 -146



Available as:

TM5109, 4 Pin TO-8 (T4)

TN5109, 4 Pin Surface Mount (SM3)

FP5109, 4 Pin Flatpack (FP4) BX5109, Connectorized Housing (H1)

## **Features**

■ Medium Gain: 10.6 dB Typical

■ Medium Output Power: +12.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 500 MHz	10 - 500 MHz	
Gain (dB)	10.5	9.5 Min.	
Power @ 1 dB Comp. (dBm)	+13	+12.0 Min.	
Reverse Isolation (dB)	- 24	- 23 Max.	
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<4.0	5.0 Max.	
Power Vdc mA	+15 35	+15 38 Max.	

# Typical Intermodulation Performance at 25 ° C

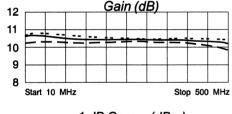
Second Order Harmonic Intercept Point	+45 (Typ.)
Second Order Two Tone Intercept Point	+40 (Typ.)
Third Order Two Tone Intercept Point	+28 (Typ.)

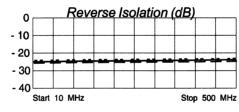
# **Maximum Ratings**

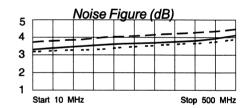
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

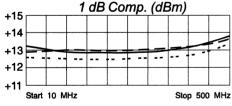
Note: Care should always be taken to effectively ground the case of each unit.

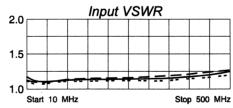
# **Typical Performance Data**

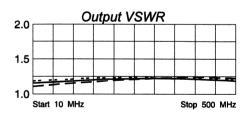












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

### **Linear S-Parameters**

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.11 - 61	3.35 -168	.05 -167	.09 - 22
10	.06 - 54	3.42 -176	.05 -176	.08 - 13
50	.04 - 30	3.39 165	.05 163	.08 - 22
100	.03 - 35	3.39 148	.05 145	.08 - 42
200	.04 - 54	3.40 116	.06 109	.08 - 73
300	.06 - 98	3.49 82	.06 77	.09 -101
400	.08 -146	3.51 44	.06 45	.07 -122
500	.13 162	3.34 3	.06 11	.06 -115
600	.18 104	2.89 - 41	06 - 25	08 - 88



Available as: TM5110, 4 Pin TO-8 (T4)

TN5110, 4 Pin Surface Mount (SM3) FP5110, 4 Pin Flatpack (FP4) BX5110, Connectorized Housing (H1)

## **Features**

■ Low Noise Figure: <2.5 dB Typical

■ Medium Gain: 15 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	10 - 500 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+10.5	+9.0 Min.
Reverse Isolation (dB)	- 21	- 20 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.5	3.0 Max.
Power Vdc mA	+15 25	+15 27 Max.

# Typical Intermodulation Performance at 25 ° C

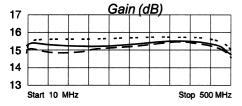
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

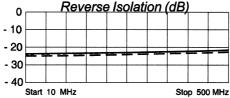
# **Maximum Ratings**

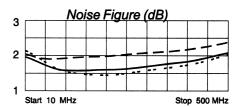
maximumitatings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

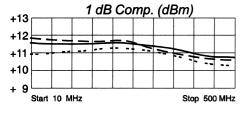
Note: Care should always be taken to effectively ground the case of each unit.

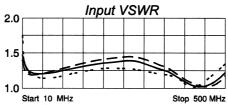
# **Typical Performance Data**

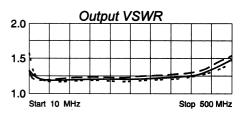












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQS11 MHz Mag Deg	S11	S21	S12	S22	
	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.25 - 51	5.61 -161	.07 -164	.21 - 44	
10	.15 - 41	5.79 -173	.08 -175	.14 - 36	
50	.09 - 26	5.80 163	.08 160	.10 - 17	
100	.11 - 33	5.78 144	.08 140	.10 - 19	
200	.14 - 62	5.81 106	.08 99	.09 - 35	
300	.14 - 97	5.89 66	.08 62	.10 - 71	
400	.06 -125	5.93 22	.09 25	.13 -130	
500	.11 - 11	5.48 - 27	.09 - 13	.21 168	



Available as: TM5118, 4 Pin TO-8 (T4)

TN5118, 4 Pin Surface Mount (SM3) FP5118, 4 Pin Flatpack (FP4)

BX5118, Connectorized Housing (H1)

## **Features**

■ Low Noise Figure: <1.6 dB Typical
■ Medium Gain: 16.5 dB Typical
■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °	
Frequency	3 - 100 MHz	3 - 100 MHz	
Gain (dB)	16.3	15.5 Min.	
Power @ 1 dB Comp. (dBm)	+6.5	+5.5 Min.	
Reverse Isolation (dB)	- 28.5	- 28 Max.	
VSWR In Out	<1.75:1 <1.25:1	2.5:1 Max. 2.0:1 Max.	
Noise figure (dB)	1.5	2.0 Max.	
Power Vdc mA	+15 21	+15 24 Max.	

# Typical Intermodulation Performance at 25 ° C

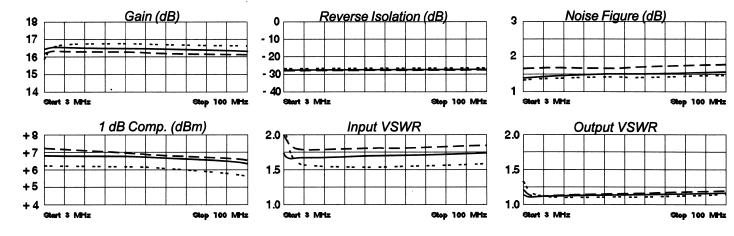
Second Order Harmonic Intercept Point	+31 (Typ.)
Second Order Two Tone Intercept Point	+25 (Typ.)
Third Order Two Tone Intercept Point	+19 (Typ.)

# **Maximum Ratings**

maxiii a taa ii go	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend ------ + 25 °C --- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ MHz	S11	S21	S12	S22	
	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
3	.29 -14	6.47 -173	.03 -173	.05 - 39	
10	.27 - 5	6.56 179	.03 178	.04 - 6	
25	.28 - 6	6.55 172	.03 171	.04 12	
50	.28 - 10	6.48 164	.03 161	.06 24	
100	.28 - 22	6.45 148	.04 143	.08 27	
200	.28 - 65	6.46 113	.04 110	.11 10	



Available as: TM5119, 4 Pin TO-8 (T4)

TN5119, 4 Pin Surface Mount (SM3) FP5119, 4 Pin Flatpack (FP4)

BX5119, Connectorized Housing (H1)

## **Features**

- Low Noise Figure: 2.25 dB Typical
- Medium Output Power: +16 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15.5	14.0 Min.
Power @ 1 dB Comp. (dBm)	+16	+14 Min.
Reverse Isolation (dB)	- 19	- 18 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.25	3.0 Max.
Power Vdc mA	+15 30	+15 35 Max.

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+49 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+32 (Typ.)

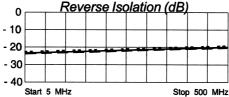
# **Maximum Ratings**

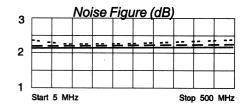
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

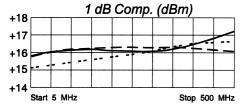
Note: Care should always be taken to effectively ground the case of each unit.

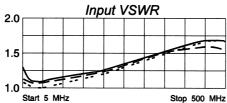
# **Typical Performance Data**

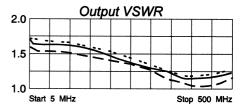












\_egend ------ + 25 °C --- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11	S21	S12	\$22 <u>-</u>	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.11 - 57	5.84 -164	.09 -163	.26 - 14	
50	.05 - <b>29</b>	6.00 169	.09 168	.24 - 12	
100	.06 - 41	6.00 157	.10 151	.23 - 22	
200	.11 - 66	6.04 132	.10 123	.19 - 44	
300	.18 -100	6.13 106	.11 98	.12 - 77	
400	.23 -139	6.12 78	.11 75	.05 -150	
500	.26 178	5.89 48	.11 52	.12 104	



Available as: TM5124, 4 Pin TO-8 (T4)

TN5124, 4 Pin Surface Mount (SM3) FP5124, 4 Pin Flatpack (FP4) BX5124, Connectorized Housing (H1)

## **Features**

High Gain: 20.5 dB Typical

■ High Output Power: +20 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 200 MHz	20 - 200 MHz
Gain (dB)	20.5	19.5 Min.
Power @ 1 dB Comp. (dBm)	+20	+18 Min.
Reverse Isolation (dB)	- 24	- 23.5 Max.
VSWR In Out	1.5:1 1.2:1	1.6:1 Max. 1.6:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 53	+15 58 Max.

# Typical Intermodulation Performance at 25 ° C

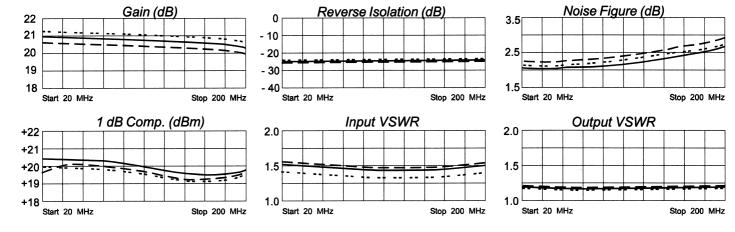
Second Order Harmonic Intercept Point	+49 (Typ.)
Second Order Two Tone Intercept Point	+44 (Typ.)
Third Order Two Tone Intercept Point	+34 (Typ.)

# **Maximum Ratings**

Maximaniiitatiiige	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend ------ + 25 °C --- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11		S11S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
20	.21	- 38	11.43	177	.06	178	.10	- 42
50	.21	- 60	11.40	158	.06	156	.08	- 25
100	.23	-104	11.18	133	.06	131	.08	- 25
150	.25	-150	10.94	109	.06	107	.10	- 36
200	.26	158	10.58	82	.06	83	.13	- 64



Available as: TM5125, 4 Pin TO-8 (T4)

TN5125, 4 Pin Surface Mount (SM3) FP5125, 4 Pin Flatpack (FP4) BX5125, Connectorized Housing (H1)

## **Features**

High Gain: 20.5 dB Typical
 High Power: +24 dBm Typical
 Operating Temp. - 55 °C to +85 °C
 Environmental Screening Available

# **Specifications**

CHARACTERISTIC		TYPICAL Ta= 25 °C	1	I/MAX C to +85 °C
Frequency	1	5 - 125 MHz	10 - 1	00 MHz
Gain (dB)		20.5	19.5 Min	./21 Max.
Power @ Comp.		+24	+22.5	Min.
Reverse Isolation	n (dB)	- 24	- 23	Мах.
VSWR	In Out	1.7:1 1.35:1	2.2:1 2.0:1	Max. Max.
Noise figure (dB)		2.0	3.0	Мах.
Power	Vdc mA	+15 80	+15 90	Max.

# Typical Intermodulation Performance at 25 ° C

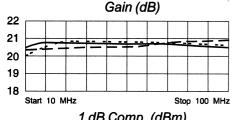
Second Order Harmonic Intercept Point	+58 (Typ.)
Second Order Two Tone Intercept Point	+52 (Typ.)
Third Order Two Tone Intercept Point	±40 (Tvn.)

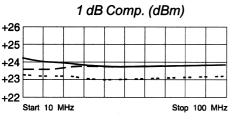
# **Maximum Ratings**

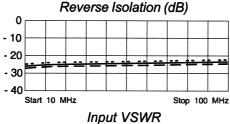
maximum ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

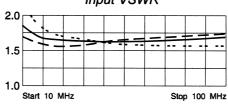
Note: Care should always be taken to effectively ground the case of each unit.

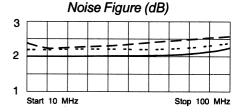
# **Typical Performance Data**

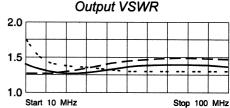












### **Linear S-Parameters**

FREQ.		S11	S21			S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.39	-32.94	9.94	-151.50	.05	-151.80	.26	-19.89
10	.29	-26.29	10.56	-168.32	.05	-172.06	.15	-23.55
25	.26	-20.09	10.79	176.24	.05	169.91	.12	8.61
50	.25	-25.12	10.79	162.45	.05	154.52	.17	18.79
75	.26	-34.68	10.69	150.84	.06	139.83	.20	15.63
100	.27	-46.93	10.52	140.02	.06	126.88	.22	8.47



# RF AMPLIFIER TM5125PM MODEL

TM5125PM, 4 Pin TO-8 (T4) Available as:

TN5125PM, 4 Pin Surface Mount (SM3) BX5125PM, Connectorized Housing (H1)

## **Features**

■ High Gain: 20.5 dB Typical ■ High Power: +24 dBm Typical ■ Low Noise: 2.0 dB Typical ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 125 MHz	10 - 100 MHz
Gain (dB)	20.5	19.5 Min./21 Max.
Power @ 1 dB Comp. (dBm)	+24.0	+22.5 Min.
Reverse Isolation (dB)	- 24	- 23 Max.
VSWR In Out	1.7:1 1.35:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.0 Max.
Power Vdc mA	+15 80	+15 90 Max.

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

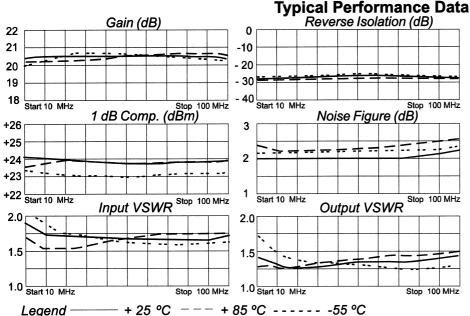
Second Order Harmonic Intercept Point	+58	(Typ.)
Second Order Two Tone Intercept Point	+52	(Typ.)
Third Order Two Tone Intercept Point	+40	(Tvp.)

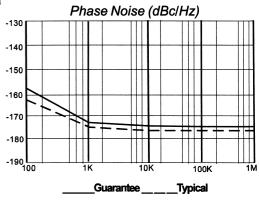
### **Maximum Ratings**

<b>Ambient Operating Temperature</b>	·55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 mW (1 Minute Max.)
Maximum Peak Power	0.5 Watt (3 μsec Max.)

# Guaranteed Phase Noise Performance (dBc/Hz) ★

Frequency	Typical	Guarantee (min.)
100 Hz	- 162	-158
1 KHz	- 175	-172
10 KHz	- 176	-174
100 KHz	- 176	-174
· 1 MHz	- 176	-174





## **★Phase Noise Test Conditions:**

- Carrier Frequency: 80 mHz
- Power Output: +24 dBm
- Temperature: 25°C
- Agilent ES5500 System

linoor	C Dor	ameters
LIIIEai	O-Fair	111161613

FREQ.		S11		321		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.39	-32.94	9.94	-151.50	.05	-151.80	.26	-19.89
10	.29	-26.29	10.56	-168.32	.05	-172.06	.15	-23.55
20	.26	-20.09	10.79	176.24	.05	169.91	.12	8.61
50	.25	-25.12	10.79	162.45	.05	154.52	.17	18.79
75	.26	-34.68	10.69	150.84	.06	139.83	.20	15.63
100	.27	-46.93	10.52	140.02	.06	126.88	.22	8.47



Available as: TM5126, 4 Pin TO-8 (T4)

TN5126, 4 Pin Surface Mount (SM3)

FP5126, 4 Pin Flatpack (FP4)

BX5126, Connectorized Housing (H1)

## **Features**

■ High Gain: 16.5 dB Typical

■ Medium Output Power: +17 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+17	+16.0 Min.
Reverse Isolation (dB)	- 21	- 20 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	3.5 Max.
Power Vdc mA	+15 50	+15 55 Max.

# Typical Intermodulation Performance at 25 ° C

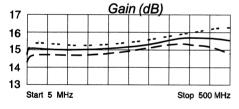
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+32 (Typ.)

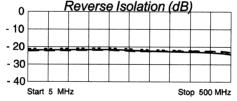
# **Maximum Ratings**

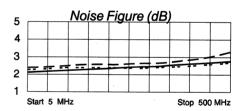
····ax·····a······go	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

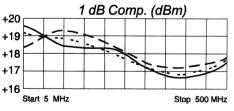
Note: Care should always be taken to effectively ground the case of each unit.

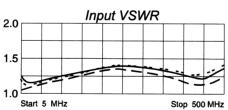
# **Typical Performance Data**

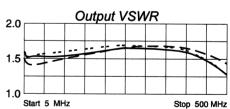












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

## Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.11 - 46	5.48 -166	.09 -165	.22 - 9
10	.08 - 38	5.58 -175	.09 -175	.22 - 9
50	.08 - 60	5.57 164	.09 163	.21 - 25
100	.11 - 93	5.53 146	.08 144	.21 - 48
200	.14 -145	5.54 112	.08 109	.22 - 87
300	.15 1 <b>69</b>	5.78 76	.08 73	.23 -121
400	.12 111	6.08 35	.07 35	.21 -150
500	.15 45	6.08 - 16	.06 - 3	.13 -172
600	.31 - 7	4.83 - 75	.04 - 46	15 - 98



Available as: TM5131, 4 Pin TO-8 (T4)

TN5131, 4 Pin Surface Mount (SM3) FP5131, 4 Pin Flatpack (FP4) BX5131, Connectorized Housing (H1)

### **Features**

■ High Gain: 18 dB Gain Typical

■ Medium Noise Figure: <5 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

# **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1300 MHz	5 - 1300 MHz
Gain (dB)	18	17.0 Min.
Power @ 1 dB Comp. (dBm)	>+7.5	+6.0 Min.
Reverse Isolation (dB)	<- 29	- 27 Max.
VSWR In Out	<1.5:1 <1.6:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	< 5	5.5 Max.
Power Vdc mA	+15 40	+15 44 Max.

Note: Care should always be taken to effectively ground the case of each unit.

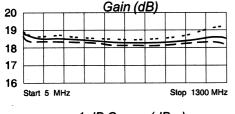
# Typical Intermodulation Performance at 25 ° C

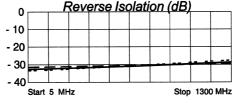
Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	+40 (Typ.)
Third Order Two Tone Intercept Point	+20 (Typ.)

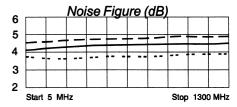
# **Maximum Ratings**

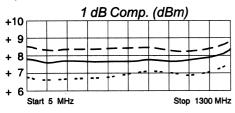
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

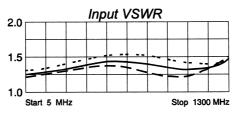
# **Typical Performance Data**

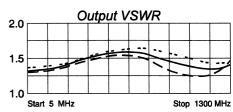












\_egend ------ + 25 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.08 -166	8.72 3	_03 5	.13 -172
10	.08 -171	8.67 - 0	.03 3	.13 -175
50	.08 -171	8.46 - 9	.02 - 4	.14 -174
100	.09 -169	8.48 - 18	.03 - 0	.14 -170
300	.13 -169	8.38 - 54	.02 - 6	.19 -168
500	.16 174	8.24 - 90	.02 - 11	.24 176
700	.16 146	8.17 -125	.03 - 22	.25 153
700 900	.13 108	8.28 -160	.03 - 31	.22 124
1100	.10 38	8.37 163	.03 - 49	.17 74
1300	.16 - 47	8.54 124	.03 - 75	.19 - 4
1500	29 - 96	8.38 84	.04 -103	.30 - 63



Available as: TM5133, 4 Pin TO-8 (T4)

TN5133, 4 Pin Surface Mount (SM3)

FP5133, 4 Pin Flatpack (FP4) BX5133, Connectorized Housing (H1)

## **Features**

■ High Reverse Isolation: 22 dB Typical

■ Medium Output Power: +16 dBm Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	10 - 500 MHz	10 - 500 MHz		
Gain (dB)	10	9.0 Min.		
Power @ 1 dB Comp. (dBm)	+16	+14.5 Min.		
Reverse Isolation (dB)	- 22	- 21 Max.		
VSWR In Out	1.75:1 1.2:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	3.3	4.5 Max.		
Power Vdc mA	+15 57	+15 60 Max.		

# Typical Intermodulation Performance at 25 ° C

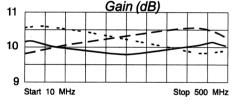
Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+30 (Typ.)

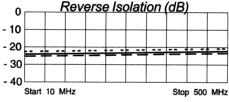
## **Maximum Ratings**

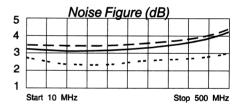
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

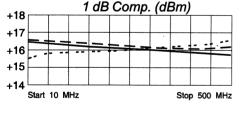
Note: Care should always be taken to effectively ground the case of each unit.

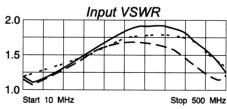
# **Typical Performance Data**

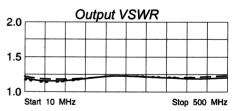












egend ------ + 25 °C --- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.12 - 37	3.33 -173	.07 -175	.10 -160
50	.11 - 51	3.32 165	.07 164	.10 171
100	.16 - 76	3.28 148	.07 145	.09 151
200	.25 -110	3.22 116	.07 110	.09 115
300	.30 -136	3.18 84	.07 78	.06 75
400	.27 -167	3.28 49	.08 42	.03 - 18
500	09 122	3 33 6	00 5	00 145



Available as:

TM5137, 4 Pin TO-8 (T4)

TN5137, 4 Pin Surface Mount (SM3) FP5137, 4 Pin Flatpack (FP4)

BX5137, Connectorized Housing (H1)

## **Features**

- High Out put Power: +22.5 dBm Typical
- High Third Order Intercept: +39
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	10 - 200 MHz	10 - 200 MHz		
Gain (dB)	12.7	12.7 ± 0.5		
Power @ 1 dB Comp. (dBm)	+22.5	+20.5 Min.		
Reverse Isolation (dB)	- 18	-17.0 Max.		
VSWR In Out	<1.6:1 <1.75:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	<3.5	4.2 Max.		
Power Vdc m A	+15 75	+15 80 Max.		

Note: Care should always be taken to effectively ground the case of each unit.

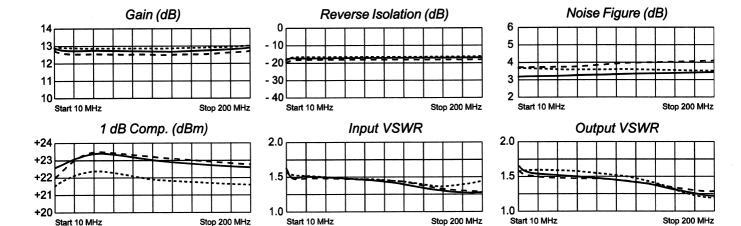
# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+58	(Typ.)
Second Order Two Tone Intercept Point	+53	(Typ.)
Third Order Two Tone Intercept Point	+39	(Typ.)

# **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

# **Typical Performance Data**



\_egend ------ + 25 °C --- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S	11	S2	21	S	12	S2	22
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	.22	-144	4.38	-175	.12	-179	.26	- 12
40	.19	-167	4.33	164	.12	162	.23	- 31
50	.19	-169	4.33	158	.12	157	.23	- 38
100	.17	-169	4.32	135	.12	133	.21	- 68
150	.14	-159	4.37	111	.12	110	.17	- 89
200	.14	-127	4.43	85	.13	86	.12	- 85



Available as: TM5138, 4 Pin TO-8 (T4)

TN5138-3, 4 Pin Surface Mount (SM3) FP5138-4, 4 Pin Flatpack (FP4) BX5138, Connectorized Housing (H1)

## **Features**

- High Output Power: +23.0 dBm Typical
- Low Noise Figure: 3.3 dB Typical
- Operating Temp. 55 °C to + 85 °C
- Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 150 MHz	5 - 150 MHz
Gain (dB)	15.5	14.0 Min.
Power @ 1 dB Comp. (dBm)	+23.0	+21.0 Min.
Reverse Isolation (dB)	- 27	- 26 Max.
VSWR In Out	<1.6:1 <1.6:1	1.9:1 Max. 1.9:1 Max.
Noise figure (dB)	3.3	4.0 Max.
Power Vdc mA	+15 90	+15 95 Max.

# Typical Intermodulation Performance at 25 ° C

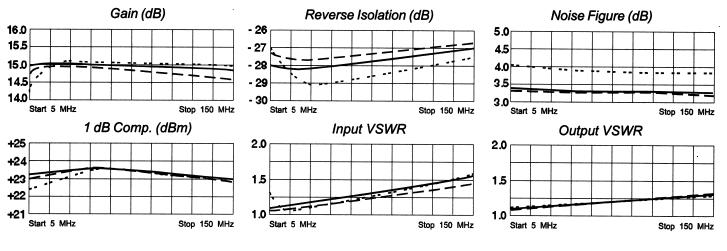
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	+55 (Typ.)
Third Order Two Tone Intercept Point	+38 (Typ.)

# **Maximum Ratings**

•	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)
	0.5 Watt

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend ---- + 25 °C ---- + 85 °C ---- - -55 °C



# RF AMPLIFIER TM5138PM **MODEL**

TM5125PM, 4 Pin TO-8 (T4) Available as:

TN5125PM, 4 Pin Surface Mount (SM3) BX5125PM, Connectorized Housing (H1)

## **Features**

■ High Gain: 20.5 dB Typical ■ High Power: +24 dBm Typical ■ Low Noise: 2.0 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 125 MHz	10 - 100 MHz
Gain (dB)	20.5	19.5 Min./21 Max.
Power @ 1 dB Comp. (dBm)	+24.0	+22.5 Min.
Reverse Isolation (dB)	- 24	- 23 Max.
VSWR In Out	1.7:1 1.35:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.0 Max.
Power Vdc mA	+15 80	+15 90 Max.

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+58	(Typ.)
Second Order Two Tone Intercept Point	+52	(Typ.)
Third Order Two Tone Intercept Point	+40	(Tvp.)

# Maximum Ratings

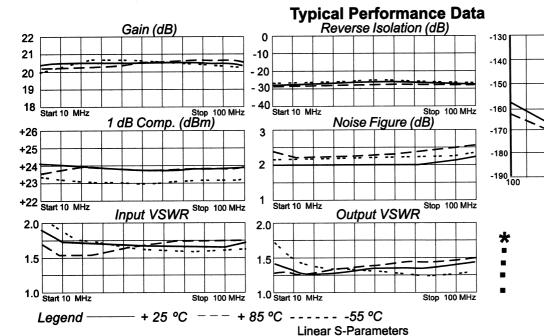
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power 50 m	W (1 Minute Max.)

# Maximum Peak Power ...... 0.5 Watt (3 μsec Max.) Guaranteed Phase Noise Performance (dBc/Hz) ★

Frequency	Typical	Guarantee (min.)
100 Hz	- 158	-154
1 KHz	- 163	-160
10 KHz	- 176	-174
100 KHz	- 176	-174
1 MHz	- 176	-174

Phase Noise (dBc/Hz)

Guarantee



FREQ.		S11		21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.39	-32.94	9.94	-151.50	.05	-151.80	.26	-19.89
10	.29	-26.29	10.56	-168.32	.05	-172.06	.15	-23.55
20	.26	-20.09	10.79	176.24	.05	169.91	.12	8.61
50 75	.25	-25.12	10.79	162.45	.05	154.52	.17	18.79
75		04.00	40.00	450.04	O.C.	400.00	20	45.60

2707 Black Lake Place, Philadelphia, PA 19154

100K

**Typical** 

Available as: TM5147, 4 Pin TO-8 (T4)

TN5147, 4 Pin Surface Mount (SM3)

FP5147, 4 Pin Flatpack (FP4)

BX5147, Connectorized Housing (H1)

PN5147, Reduced Size Surface Mount (SM11)

## **Features**

- Low Noise Figure: 3.25 dB Typical
- Wide Frequency Range
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 1100 MHz	20 - 1100 MHz
Gain (dB)	14	13.0 Min.
Power @ 1 dB Comp. (dBm)	+11	+9.0 Min.
Reverse Isolation (dB)	- 18	- 16 Max.
VSWR In Out	<1.6:1 <1.6:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.0 Max.
Power Vdc mA	+15 27	+15 29 Max.

# Typical Intermodulation Performance at 25 ° C

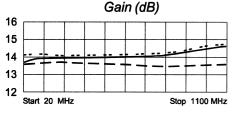
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+23 (Typ.)

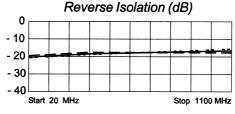
# **Maximum Ratings**

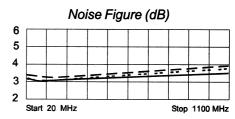
maximumitatings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	
	(3 μsec Max.)

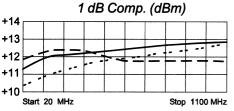
Note: Care should always be taken to effectively ground the case of each unit.

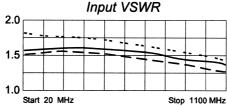
# **Typical Performance Data**

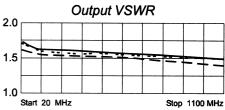












egend ----- + 25 °C --- + 85 °C ----- -55 °C

## **Linear S-Parameters**

FREQ. MHz	§ Mag	511 Deg	§ Mag	321 Deg	s Mag	12 Deg	Mag	<b>S22</b> Deg
10	.22	-155	4.96	-173	.12	8	.25	164
50 100	.22 .22	-179 175	5.06 5.06	176 169	.12 .12	3	.22 .21	164 155
250	.21	158	5.06	150	.12	ī	.22	128
500 750	.18 .13	135 117	5.04 5.12	121	.14 .15	- 0	.23	82
1000	.08	121	5.12 5.21	91 59	.16	- 6 -14	.24 .21	42 6
1250	.10	153	5.16	23	.17	-21	.17	- 26
1500	.16	146	4.70	- 17	.18	-29	.11	- 40



Available as:

TM5149, 4 Pin TO-8 (T4)

TN5149, 4 Pin Surface Mount (SM3) FP5149, 4 Pin Flatpack (FP4)

BX5149, Connectorized Housing (H1)

### **Features**

High Gain: 23.5 dB Typical Low Noise Figure: <3 dB Typical Operating Temp. - 55 °C to +85 °C **Environmental Screening Available** 

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 150 MHz	5 - 150 MHz		
Gain (dB)	23.5	22.5 Min.		
Power @ 1 dB Comp. (dBm)	+18	+17.0 Min.		
Reverse Isolation (dB)	- 29	- 28 Max.		
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	<3.0	3.2 Max.		
Power Vdc mA	+15 35	+15 38 Max.		

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

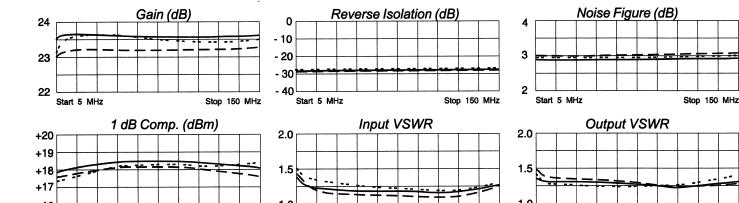
Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	+37 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Start 5 MHz

# **Typical Performance Data**



Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

### Linear S-Parameters

Stop 150 MHz

FREQ.	S11	\$21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.16 -121	14.72 -168	.04 6	.15 169
10	.12 -146	14.91 -178	.04 1	.13 170
50	.09 170	14.85 159	.03 - 8	.11 167
100	.05 142	14.90 136	.04 - 16	.06 159
150	.01 2	15.00 113	.04 - 28	.04 -111
200	.09 - 52	15.19 90	.04 - 38	.12 - 93

Stop 150 MHz



2707 Black Lake Place, Philadelphia, PA 19154

Stop 150 MHz

Available as: TM5150, 4 Pin TO-8 (T4)

TN5150, 4 Pin Surface Mount (SM3)

FP5150, 4 Pin Flatpack (FP4)

BX5150, Connectorized Housing (H1)

## **Features**

- Low Noise Figure: 2.5 dB Typical
- Medium Output Power: +18 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

# **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 300 MHz	10 - 300 MHz
Gain (dB)	20.0 ±.5	19.0 Min.
Power @ 1 dB Comp. (dBm)	+18	+17 Min.
Reverse Isolation (dB)	- 23	- 22 Max.
VSWR In Out	1.75:1 1.5:1	2.5:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 47	+15 53 Max

# Typical Intermodulation Performance at 25 ° C

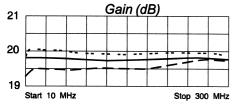
Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+43 (Typ.)
Third Order Two Tone Intercept Point	+32 (Typ.)

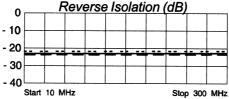
# **Maximum Ratings**

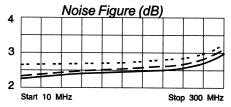
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

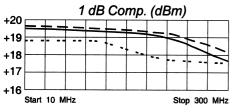
Note: Care should always be taken to effectively ground the case of each unit.

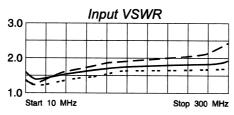
# **Typical Performance Data**

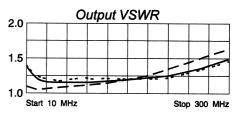












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.23 - 44	9.95 -173	.07 -172	.16 - 76
50	.19 - 57	10.0 159	.07 158	.07 - 87
100	.24 - 94	9.90 136	.07 133	.07 - 79
200	.29 -162	9.76 90	.07 86	.09 - 77
300	.30 121	9.91 38	.07 37	.21 -108



# RF AMPLIFIER **MODEL** TM5150PM

Available as: TM5150PM, 4 Pin TO-8 (T4)

TN5150PM, 4 Pin Surface Mount (SM3) FP5150PM, 4 Pin Flatpack (FP4)

BX5150PM, Connectorized Housing (H1)

# **Features**

■ Low Noise Figure: 2.5 dB Typical

■ Meduim Output Power: +18 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 300 MHz	10 - 300 MHz
Gain (dB)	20.0±0.5	19.0 Min.
Power @ 1 dB Comp. (dBm)	+18	+17 Min.
Reverse Isolation (dB)	- 23	- 22 Max.
VSWR In Out	1.75:1 1.5:1	2.5:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 47	+15 53 Max.

Note: Care should always be taken to effectively ground the case of each unit.

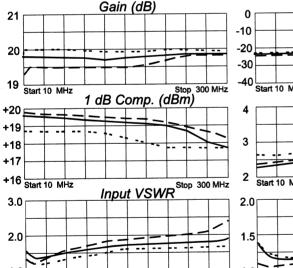
# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+48	(Typ.)
Second Order Two Tone Intercept Point	+43	(Typ.)
Third Order Two Tone Intercept Point		

Maximum Ratings	
<b>Ambient Operating Temperature</b>	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	

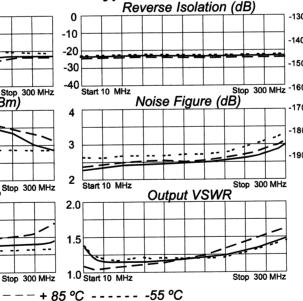
# Guaranteed Phase Noise Performance (dBc/Hz) \*

Frequency	Typical	Guarantee
100 Hz	- 162	(min.) - 158
1 KHz	- 170	- 168
10 KHz	- 172	- 170
100 KHz	- 173	- 170
1 MHz	- 173	- 170

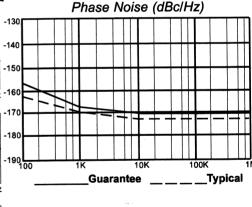


+ 25 °C

Legend



**Typical Performance Data** 



### **★Phase Noise Test Conditions:**

- Carrier Frequency: 160 mHz
- Power Output: +18 dBm
- Temperature: 25 °C
- Agilent ES5500 System

## **Linear S-Parameters**

Stop 300 MHz

FREQ.	S	11	9	<b>S21</b>	S	12	S	22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
=======	:========	:=======						
10	.23	-44	9.95	-173	.07	- 172	.16	- 76
50	.19	-57	10.0	159	.07	158	.07	- 87
100	.24	-94	9.90	136	.07	133	.07	- 79
200	.29	-162	9.76	90	.07	86	.09	- 77
300	.30	121	9.91	38	.07	37	.21	- 108



# RF AMPLIFIER TM5152PM MODEL

Available as: TM5152PM, 4 Pin TO-8 (T4)

TN5152PM, 4 Pin Surface Mount (SM3)

BX5152PM, Connectorized Housing (H1)

FP5152PM, 4 Pin Flatpack (FP4)

## **Features**

■ High Gain: 17 dB Typical

■ High Output Power: +20 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency	10 - 300 MHz	10 - 300 MHz
Gain (dB)	17.0	16.0 Min.
Power @ 1 dB Comp. (dBm)	+20	+17.5 Min.
Reverse Isolation (dB)	- 20	- 19 Max.
VSWR In Out	<1.75:1 < 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	3.8 Max.
Power Vdc mA	+15 55	+15 60 Max.

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

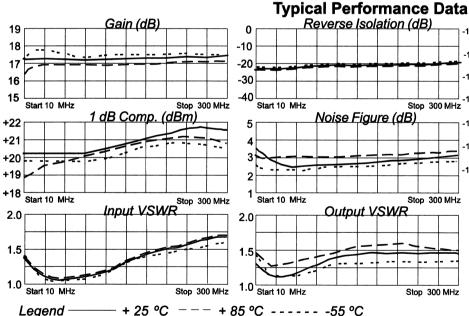
Second Order Harmonic Intercept Point	+53	(Typ.)
Second Order Two Tone Intercept Point	+47	(Typ.)
Third Order Two Tone Intercept Point	+33	(Typ.)

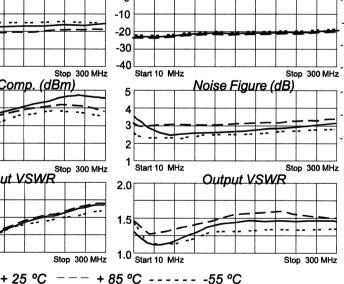
# Maximum Ratings

maximum ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	. 50 mW (1 Minute Max.)
Maximum Peak Power	0.5 Watt (3 µsec Max.)

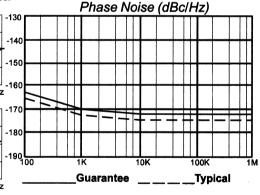
# Guaranteed Phase Noise Performance (dBc/Hz) \*

Frequency	Typical	Guarantee (min.)
100 Hz	- 166	- 164
1 KHz	- 172	- 170
10 KHz	- 174	- 172
100 KHz	- 174	- 172
1 MHz	- 174	- 172





Reverse Isolation (dB)



### ★Phase Noise Test Conditions:

- Carrier Frequency: 80 MHzPower Output: +20 dBm
- Temperature: 25 °C
- Agilent ES5500 System

### **Linear S-Parameters**

FREQ. MHz		S11	S	21	S	12	S2	22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.16	- 76	6.84	-156	.09	-155	.15	-33
50	.04	- 87	7.19	166	.09	163	.08	
100	.07	- 94	7.15	148	.09	145	.12	20 23
200	.15	-123	7.16	114	.10	108	.18	3
300	.24	-159	7.21	80	.11	75	.18	-30
400	.29	155	7.38	43	.11	41	.16	-82
500	29	RQ.	7 30	1	11	5	10	-161



Available as: TM5155, 4 Pin TO-8 (T4)

TN5155, 4 Pin Surface Mount (SM3)

FP5155, 4 Pin Flatpack (FP4)

BX5155, Connectorized Housing (H1)

## **Features**

■ High 3rd Order Intercept: +37 dBm Typical

■ Medium Gain: 15 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 300 MHz	5 - 300 MHz
Gain (dB)	15.0	15.0 ± 1.0 Min.
Power @ 1 dB Comp. (dBm)	>+22	+21 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<5	6.0 Max.
Power Vdc mA	+15 85	+15 90 Max.

Note: Care should always be taken to effectively ground the case of each unit.

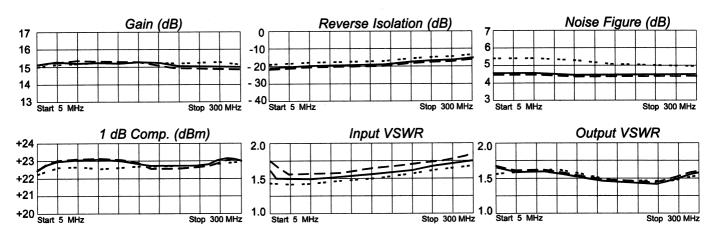
# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+54	(Typ.)
Second Order Two Tone Intercept Point	+48	(Typ.)
Third Order Two Tone Intercept Point	+37	(Typ.)

## **Maximum Ratings**

Maxilliulli Nauliya	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 17Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

# **Typical Performance Data**



Legend ----+ 85 °C ----- -55 °C

## **Linear S-Parameters**

FREQ.		311		S21		S12	S2	22
FREQ. MHz	Mag	Deg	Mag	Deg	Ma	ng Deg	Mag	Deg
5	.24	-30	5.73	-166	.090	15	.25	53
10 50	.20 .19	-20 -19	5.86 5.86	-175 168	.092 .094	8	.23 .22	25 -15
100	.19	-33	5.90	152	.101	4	.19	-41
150 200	.20 .21	-50 -71	5.88 5.87	137 122	.109 .120	5 3	.18 .15	-68 -105
300	.24	-111	5.59	91	.143	-5	.18	-163



# RF AMPLIFIER MODEL TM5155PM

Available as: TM5155PM, 4 Pin TO-8 (T4)

TN5155PM, 4 Pin Surface Mount (SM3)

FP5155PM, 4 Pin Flatpack (FP4)

BX5155PM, Connectorized Housing (H1)

# **Features**

■ High 3rd Order Intercept: +37 dBm Typical

■ Medium Gain: 15 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 300 MHz	5 - 300 MHz
Gain (dB)	15.0	15.0 ± 1.0 Min.
Power @ 1 dB Comp. (dBm)	>+22	+21 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<5	6.0 Max.
Power Vdc mA	+15 85	+15 90 Max.

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

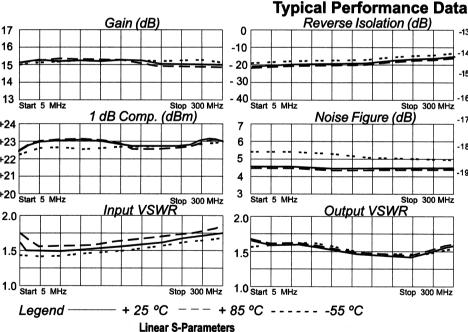
Second Order Harmonic Intercept Point +54	(Typ.)
Second Order Two Tone Intercept Point+48	
Third Order Two Tone Intercept Point+37	

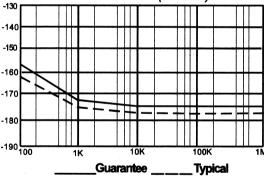
# Maximum Ratings

maxima namigo	
<b>Ambient Operating Temperature</b>	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 17 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 mW (1 Minute Max.)
Maximum Peak Power	0.5 Watt (3 µsec Max.)

# Guaranteed Phase Noise Performance (dBc/Hz) ★

Frequency	Typical	Guarantee (min.)
100 Hz	- 162	- 158
1 KHz	- 175	- 172
10 KHz	- 178	- 175
100 KHz	- 178	- 175
1 MHz	- 178	- 175





Phase Noise (dBc/Hz)

## ★Phase Noise Test Conditions:

- Carrier Frequency: 160 MHz
- Power Output: +22 dBm
- Temperature: 25 °C
- Agilent ES5500 System

FREQ. MHz	S11		S21		S12		S22	
MHz	Mag	Deg	Mag Mag	Deg	Mag	Deg	Mag	Deg
5	.24	-30	5.73	-166	.090	15	.25	53
10	.20	-20	5.86	-175	.092	8	.23	25
50	.19	-19	5.86	168	.094	5	.22	-15
100	.19	-33	5.90	152	.101	4	.19	-41
150	.20	-50	5.88	137	.109	5	.18	-68
200	.21	-71	5.87	122	.120	3	.15	-105
300	.24	-111	5.59	91	.143	-5	.18	163



Available as: TM5171, 4 Pin TO-8 (T4)

TN5171, 4 Pin Surface Mount (SM3)

FP5171, 4 Pin Flatpack (FP4)

BX5171, Connectorized Housing (H1) PN5171, Reduced Size Surface Mount (SM11)

## **Features**

■ High Output Power: +26 dBm Typ.

■ High Dynamic Range: Ip³ = +39 dBm Typ.

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	20 - 150 MHz	20 - 150 MHz	
Gain (dB)	13.5	13 Min./14 Max.	
Power @ 1 dB Comp. (dBm)	+27	+26 Min.	
Reverse Isolation (dB)	- 25	Max.	
VSWR In Out	1.5:1 1.5:1	1.6:1 Max. 1.6:1 Max.	
Noise figure (dB)	6.5	7 Max.	
Power Vdc mA	+15 105	+15 110 Max.	

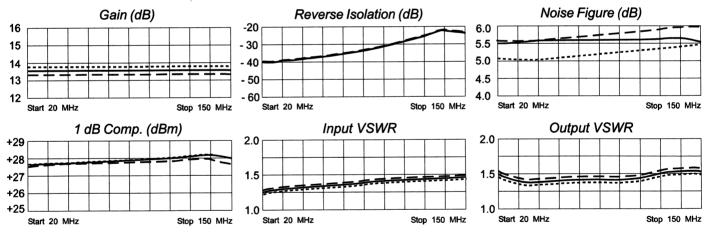
Typical Intermodulation Performance at 25 ° C

**Maximum Ratings** 

Maximumitatings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend ----- + 25 °C ---- - 55 °C



Available as: TM5175, 4 Pin TO-8 (T4)

TN5175, 4 Pin Surface Mount (SM3)

FP5175, 4 Pin Flatpack (FP4)

BX5175, Connectorized Housing (H1) PN5175, Reduced Size Surface Mount (SM11)

## **Features**

■ High Gain: 16.3 dB Typical

■ High Output Power: > +18 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 500 MHz	20 - 500 MHz
Gain (dB)	16.3	16.3 ± 0.8
Power @ 1 dB Comp. (dBm)	+18	+16.5 Min.
Reverse Isolation (dB)	- 20	-18.0 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	3.8 Max.
Power Vdc mA	+15 45	+15 50 Max.

# Typical Intermodulation Performance at 25 ° C

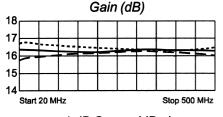
Second Order Harmonic Intercept Point	+47 (Typ.)
Second Order Two Tone Intercept Point	+41 (Typ.)
Third Order Two Tone Intercept Point	+32 (Typ.)

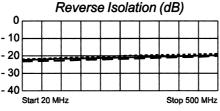
## **Maximum Ratings**

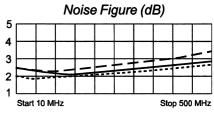
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
·	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

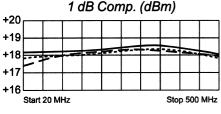
Note: Care should always be taken to effectively ground the case of each unit.

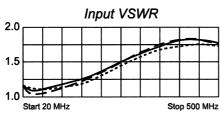
# **Typical Performance Data**

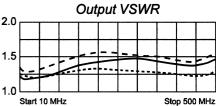












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

### **Linear S-Parameters**

FREQ.	S	11	S2	21	S1	2	S	22
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
5	16	- 76	6.49	-156	.09	 -155	.15	- 33
50	.04	- 87	6.48	166	.09	163	.08	20
100	.07	- 94	6.44	148	.09	145	.12	23
200	.15	-123	6.46	114	.10	108	.18	3
300	.24	-159	6.50	80	.11	75	.18	- 30
400	.29	155	6.65	41	.11	41	.16	- 82
500	.29	89	6.58	1	.11	5	.19	-161



Available as: TM5198, 4 Pin TO-8 (T4)

TN5198, 4 Pin Surface Mount (SM3)

FP5198, 4 Pin Flatpack (FP4)

BX5198, Connectorized Housing (H1)

### **Features**

■ Low Noise Figure: 3.0 dB Typical

■ Excellent Reverse Isolation

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 450 MHz	5 - 450 MHz
Gain (dB)	28.0	27 Min/29Max.
Gain Flatness (dB-Max)	+/- 0.5	+/- 0.8
Power @ 1 dB Comp. (dBm)	+12	+11.5 Min.
Reverse Isolation (dB)	-20	-19 Min.
VSWR In Out	1.3:1 1.3:1	1.5:1 Max. 1.5:1 Max.
Noise figure (dB)	3.0	3.9 Max.
Power Vdc mA	+5 50	+5 50 Max.

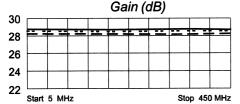
# Typical Intermodulation Performance at 25 ° C

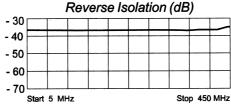
Second Order Harmonic Intercept Point	+44 (Typ.)
Second Order Two Tone Intercept Point	+38 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

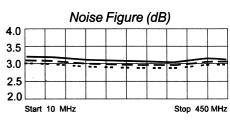
# **Maximum Ratings**

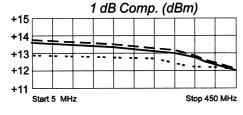
Ambient Operating Temperature	55°C to + 125 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	+ 8 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

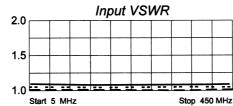
Note: Care should always be taken to effectively ground the case of each unit. Typical Performance Data

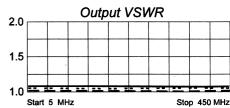












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

Available as: TM5304, 4 Pin TO-8 (T4)

TN5304, 4 Pin Surface Mount (SM3)

FP5304, 4 Pin Flatpack (FP4) BX5304, Connectorized Housing (H1)

## **Features**

■ High Gain: 19.5 dB Typical

■ Low Noise Figure: <2.5 dB Typical ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 200 MHz	5 - 200 MHz		
Gain (dB)	19.5	18.5 Min.		
Power @ 1 dB Comp. (dBm)	+10.5	+9.5 Min.		
Reverse Isolation (dB)	- 26	- 25 Max.		
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	<2.5	3.0 Max.		
Power Vdc mA	+15 24	+15 25 Max.		

# Typical Intermodulation Performance at 25 ° C

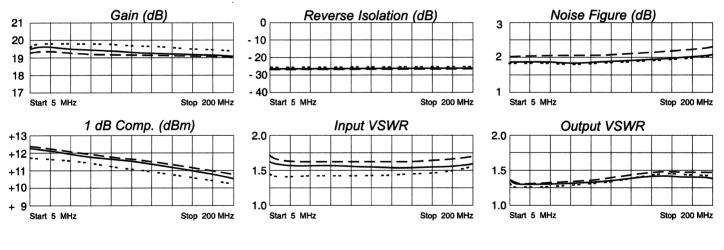
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

## **Maximum Ratings**

<u> </u>	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 17Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



eaend -----+ 85 °C ----- -55 °C

# Linear S-Parameters

FREQ. MHz	S´ Mag	11 Deg	\$ Mag	521 Deg	 Mag	S12 Deg	 Mag	S22 Deg
5	.24	- 18	9.29	-173	.05	-172	.15	- 29
10	.23	- 14	9.37	180	.05	-179	.13	- 18
50	.22	- 32	9.27	160	.05	157	.13	- 19
100	.21	- 65	9.20	138	.05	137	.15	- 37
150	.21	-104	9.09	117	.05	111	.17	- 60
200	.24	-145	8.85	94	.05	89	.16	- 82
300	.37	150	7.82	45	.05	46	.07	-106



Available as: TM5325, 4 Pin TO-8 (T4)

TN5325, 4 Pin Surface Mount (SM3) FP5325, 4 Pin Flatpack (FP4) BX5325, Connectorized Housing (H1)

## **Features**

Low Noise Figure: 2.0 dB TypicalHigh Output Power: +24 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 125 MHz	10 - 100 MHz	
Gain (dB)	20.5	20.5 ± 1.0	
Power @ 1 dB Comp. (dBm)	+24	+22.5 Min.	
Reverse Isolation (dB)	- 24	- 23 Max.	
VSWR In Out	1.70:1 1.35:1	2.2:1 Max. 2.0:1 Max.	
Noise figure (dB)	2.0	3.0 Max.	
Power Vdc mA	+12 85	+12 95 Max.	

# Typical Intermodulation Performance at 25 ° C

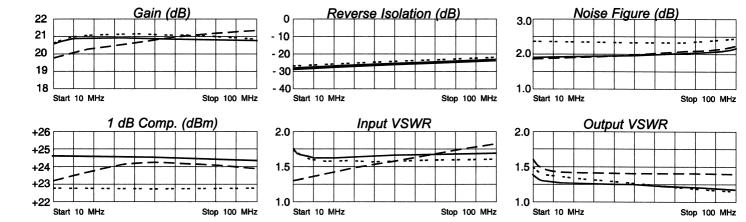
Second Order Harmonic Intercept Point	+58 (Typ.)
Second Order Two Tone Intercept Point	+52 (Typ.)
Third Order Two Tone Intercept Point	+40 (Typ.)

# **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend -----+ 85 °C ---- -55 °C

## Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.35 - 32	10.28 -157	.05 -159	.27 - 27
10	.27 - <b>28</b>	10.95 -171	.05 -174	.16 - 32
50	.23 - 36	11.12 <b>161</b>	.06 151	.11 - 3
100	.26 - 68	11.10 139	.06 127	.10 - 10
150	.32 -106	10.87 115	.07 103	.06 - 29



Available as: TM5338, 4 Pin TO-8 (T4)

TN5338, 4 Pin Surface Mount (SM3)

FP5338, 4 Pin Flatpack (FP4)

BX5338, Connectorized Housing (H1)

## **Features**

High Output Power: +25 dBm Typical
 Low Noise Figure: 2.7 dB Typical
 Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 150 MHz	5 - 150 MHz	
Gain (dB)	15	14.0 Min.	
Power @ 1 dB Comp. (dBm)	+25	+23.0 Min.	
Reverse Isolation (dB)	- 20	- 19 Max.	
VSWR In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	2.7	3.5 Max.	
Power Vdc mA	+12 88	+12 100 Max.	

# Typical Intermodulation Performance at 25 ° C

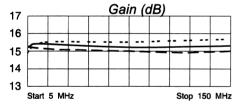
<b>31</b>	
Second Order Harmonic Intercept Point	+50 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	

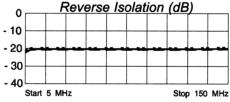
# **Maximum Ratings**

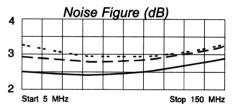
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

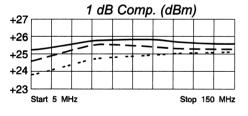
Note: Care should always be taken to effectively ground the case of each unit.

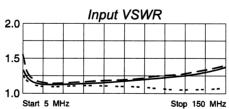
# **Typical Performance Data**

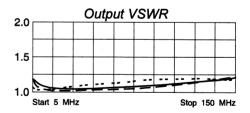












Legend -----+ 85 °C ----- -55 °C

### **Linear S-Parameters**

FREQ. MHz	( Mag	S11 Deg	\$ Mag	S21 Deg	S Mag	S12 Deg	: Mag	S22 Deg
	mag	209	· · · · · ·	209	ITIGG	DOG	iviag	
5	.16	- 96	5.81	-164	.09	-171	.09	- 42
25	.06	-140	5.85	169	.10	167	.02	- 90
50	.07	-153	5.83	154	.10	151	.02	-105
75	.07	-155	5.78	139	.10	135	.02	-116
100	.09	-162	5.78	125	.10	120	.04	-152
125	.12	-164	5.80	110	.10	105	.06	179
150	.17	-169	5.80	94	.10	89	.09	149



Available as: TN5352, 4 Pin Surface Mount (SM3)

BX5352, Connectorized Housing (HI)

## **Features**

High Gain: 17 dB Typical

High Output Power: +20 dBm Typical
 Operating Temp. - 55 °C to +85 °C
 Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 300	10 - 300
Gain (dB)	17	16.0 Min.
Power @ 1 dB Comp. (dBm)	+20	+17.5 Min.
Reverse Isolation (dB)	- 20	- 19 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	3.8 Max.
Power Vdc m A	+12 55	+12 60 Max.

# Typical Intermodulation Performance at 25 ° C

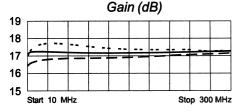
Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+47 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

## **Maximum Ratings**

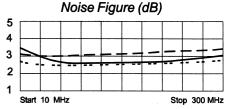
111021111011111011190	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 µsec Max.)

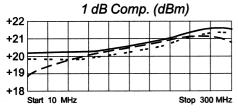
Note: Care should always be taken to effectively ground the case of each unit.

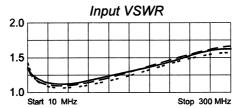
# **Typical Performance Data**

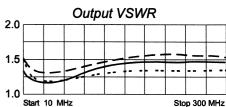












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

### **Linear S-Parameters**

FREQ.	S1	1	S	21		12		322
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.16	- 76	6.84	-156	.09	-155	.15	- 33
50	.04	- 87	7.19	166	.09	163	.08	20
100	.07	- 94	7.15	148	.09	145	.12	23
200	.15	-123	7.16	114	.10	108	.18	3
300	.24	-159	7.21	80	.11	75	.18	- 30
400	.29	155	7.38	43	.11	41	.16	- 82
500	.29	89	7.30	1	.11	5	.19	-161



Available as: TM5441, 4 Pin TO-8 (T4)

TN5441, 4 Pin Surface Mount (SM3) FP5441, 4 Pin Flatpack (FP4)

BX5441, Connectorized Housing (H1)

## **Features**

- 5 Volt Operation
- Medium Power: +15 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 400 MHz	10 - 400 MHz
Gain (dB)	14.5	13.0 Min.
Power @ 1 dB Comp. (dBm)	+15	+12.0 Min.
Reverse Isolation (dB)	- 20	- 17 Max.
VSWR In Out	1.25:1 1.6:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.8	4.5 Max.
Power Vdc mA	+5 33	+5 36 Max.

# Typical Intermodulation Performance at 25 ° C

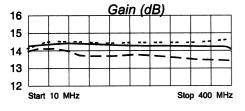
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

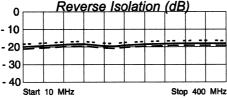
## **Maximum Ratings**

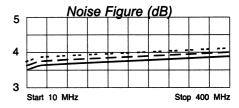
maximum radings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

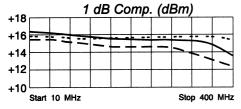
Note: Care should always be taken to effectively ground the case of each unit.

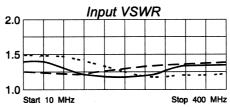
# **Typical Performance Data**

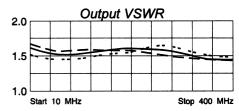












Legend ------+ 85 °C ----- -55 °C

## Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.15 -147	5.21 -176	.10 6	.24 169
50	.13 -177	6.29 162	.10 - 7	.22 180
100	.12 178	5.22 142	.10 - 15	.22 -178
200	.09 -165	5.10 103	.10 - 33	.24 179
300	.12 -149	5.10 62	.11 - 54	.22 158
400	.14 166	5.01 13	.12 - 82	.18 80
500	.22 31	4.06 - 47	.11 -128	.49 - 23



Available as: TM5519, 4 Pin TO-8 (T4)

TN5519, 4 Pin Surface Mount (SM3) FP5519, 4 Pin Flatpack (FP4)

BX5519, Connectorized Housing (H1)

## **Features**

- 5 Volt Operation
- Low Noise Figure: 2.25 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+14.5	+11.5 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	1.5:1 1.9:1	2.0:1 Max. 2.2:1 Max.
Noise figure (dB)	2.25	3.0 Max.
Power Vdc mA	+5 30	+5 35 Max.

Typical Intermodulation Performance at 25 ° C

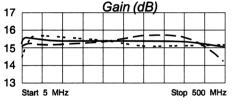
Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	+39 (Typ.)
Third Order Two Tone Intercept Point	+29 (Typ.)

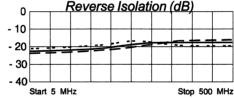
**Maximum Ratings** 

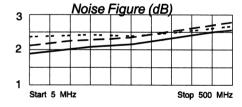
maxiiiaiii katii 193	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
•	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

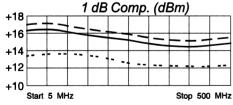
Note: Care should always be taken to effectively ground the case of each unit.

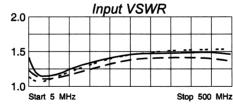
# **Typical Performance Data**

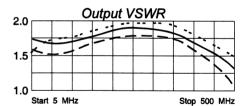












Leaend ----- + 25 °C --- + 85 °C ---- - -55 °C

## Linear S-Parameters

FREQ.		311		S21		S12		322
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.15	-57	5.84	-165	.09	-165	.28	-16
50	.08	-76	6.01	166	.09	161	.25	-30
100	.12	-105	5.92	150	.09	140	.26	-53
200	.18	-147	5.78	119	.10	105	.31	-92
300	.21	175	5.71	90	.11	76	.32	-122
400	.20	137	5.73	57	.12	49	.28	-146
500	.20	103	5.58	19	.13	24	.16	-163



Available as: TM5544, 4 Pin TO-8 (T4)

TN5544, 4 Pin Surface Mount (SM3)

FP5544, 4 Pin Flatpack (FP4)

BX5544, Connectorized Housing (H1)

## **Features**

- 5 Volt Operation
- Low Noise Figure: 2.5 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	12.5	11.0 Min.
Power @ 1 dB Comp. (dBm)	+14.5	+11.5 Min.
Reverse Isolation (dB)	- 15.5	- 14.5 Max.
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+5 35	+5 42 Max.

# Typical Intermodulation Performance at 25 ° C

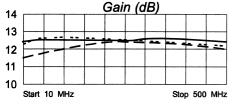
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+27 (Typ.)

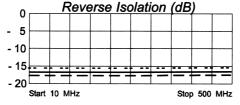
# **Maximum Ratings**

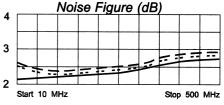
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

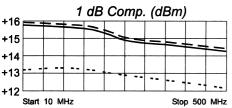
Note: Care should always be taken to effectively ground the case of each unit.

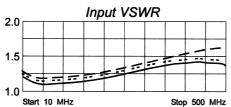
# **Typical Performance Data**

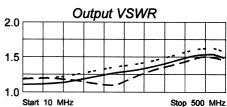












—+ 25 °C −−−+ 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S1	1		521		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.04	-127	4.11	-172	.17	-171	.03	-119
50	.04	-154	4.15	171	.17	170	.01	-174
100	.05	-167	4.16	159	.17	158	.00	56
200	.08	169	4.21	135	.17	135	.07	-35
300	.11	152	4.23	112	.17	113	.14	-65
400	.14	135	4.25	86	.17	92	.20	-85
500	.15	131	4.15	59	.17	69	.22	-104



Available as: TM5670, 4 Pin TO-8 (T4)

TN5670, 4 Pin Surface Mount (SM3) FP5670, 4 Pin Flatpack (FP4) BX5670, Connectorized Housing (H1)

## **Features**

■ Low Noise Figure: 2.0 dB Typical

5 Volt Operation

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	<b>MIN/MAX</b> Ta = -55 °C to +85 °C
Frequency	20 - 250 MHz	20 - 250 MHz
Gain (dB)	8.2	7.0 Min.
Power @ 1 dB Comp. (dBm)	+15.5	+13.5 Min.
Reverse Isolation (dB)	- 11	- 10 Max.
VSWR In Out	1.35:1 1.20:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.0 Max.
Power Vdc mA	+5 25	+5 30 Max.

# Typical Intermodulation Performance at 25 ° C

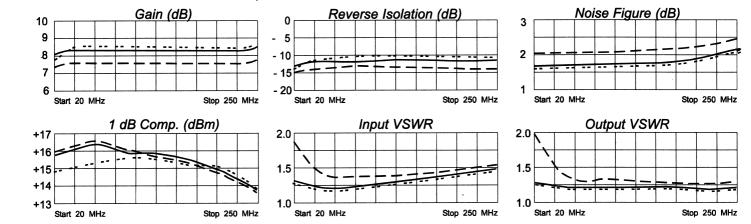
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+28 (Typ.)

# **Maximum Ratings**

maxiiiluiii ixatiiiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend -----+ 85 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.14 153	2.50 7	.28 7	.13 150
50	.11 -180	2.54 -9	.28 -9	.09 165
100	.12 -174	2.54 -21	.28 -20	.09 165
150	.14 -169	2.54 -32	.27 -31	.10 167
200	.18 -171	2.56 -44	.27 <b>-4</b> 3	.11 168
250	.23 -173	2.58 -56	.26 -55	.14 166



Available as: TM5817, 4 Pin TO-8 (T4)

TN5817, 4 Pin Surface Mount (SM3) FP5817, 4 Pin Flatpack (FP4)

BX5817, Connectorized Housing (H1) PN5817, Reduced Size Surface Mount (SM11)

## **Features**

■ High Output Power: >+22 dBm Typical

■ High Third Order Intercept: +32 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	14	14 ± 1
Power @ 1 dB Comp. (dBm)	>+23	+20.0 Min.
Reverse Isolation (dB)	- 20	-18.0 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<6.0*	7.0* Max.
Power Vdc mA	+15 98	+15 102 Max.

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+49	(Typ.)
Second Order Two Tone Intercept Point	+44	(Typ.)
Third Order Two Tone Intercept Point	+32	(Typ.)

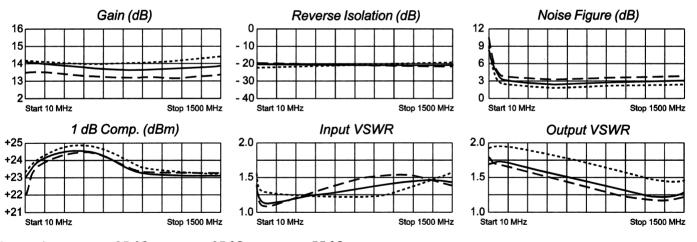
## **Maximum Ratings**

maxiiiiuiii italiiigə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 17 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

<sup>\*</sup> Noise figure is greater than 7.0 dB for frequencies below 30 MHz.

## Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



.egend ----- + 25 °C ---- + 85 °C ----- -55 °C

### **Linear S-Parameters**

FREQ.	S11		S21		S12		S22	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	 ,18	-114	5.26	-167	.102	7	.26	171
100	.07	-165	5.08	171	.099	- 4	.27	173
300	.08	-132	4.97	152	.099	- 12	.26	159
500	.12	-127	4.89	134	.099	- 22	.23	145
700	.16	-124	4.83	117	.098	- 32	.19	131
900	.18	-130	4.82	98	.098	- 42	.16	115
1100	.21	-130	4.86	79	.097	- 54	.11	96
1300	.20	-131	4.92	59	.097	- 67	.11	73
1500	.21	-131	4.97	35	.096	- 83	.13	40



Available as: T

TM5834, 4 Pin TO-8 (T4)

TN5834, 4 Pin Surface Mount (SM3) FP5834, 4 Pin Flatpack (FP4) BX5834, Connectorized Housing (H1)

# **Features**

■ High Output Power: +27.5 dBm Typical

■ High IP3: +40 dBm

Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 100 MHz	10 - 100 MHz
Gain (dB)	19.7±0.5	18.7 Min./20.7 Max.
Power @ 1 dB Comp. (dBm)	+27.5	+26 Min.
Reverse Isolation (dB)	- 25	- 24 Max.
VSWR In Out	1.7:1 1.3:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.5 Max.
Power Vdc mA	+15 135	+15 145 Max.

# Typical Intermodulation Performance at 25 ° C

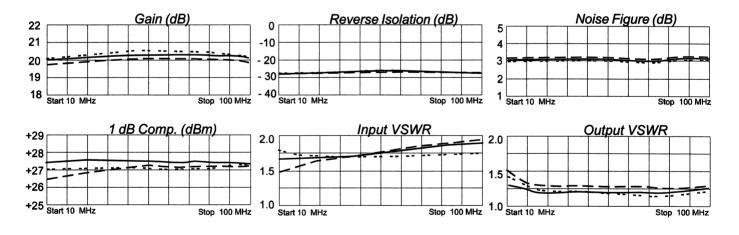
Second Order Harmonic Intercept Point	+58	(Typ.)
Second Order Two Tone Intercept Point	+52	(Typ.)
Third Order Two Tone Intercept Point	+40	(Typ.)

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend ——— + 25 °C --- + 85 °C ---- -55 °C

# **Linear S-Parameters**

FREQ. MHz	S Mag	511 Deg	 Mag	S21 Deg	S Mag	S12 Deg	 Mag	S22 Deg
5	.21	- 54	8.79	-127	.04	-124	.34	72
10	.16	- 29	9.89	-157	.05	-157	.14	40
20	.16	- 27	10.12	-175	.05	-178	.09	26
50	.19	- 50	10.11	164	.05	160	.09	18
75	.21	- 72	10.00	151	.05	145	.09	12
100	.24	- 91	9.84	139	.05	132	.09	5
150	.32	-126	9.26	116	.06	108	.06	-6



# RF AMPLIFIER **MODEL** *TM5834PM*

Available as: TM5834PM, 4 Pin TO-8 (T4)

> TN5834PM, 4 Pin Surface Mount (SM3) BX5834PM, Connectorized Housing (H1)

## **Features**

Superior Phase Noise Performance

High Gain: 19.7± 0.5 dB

Low Noise: <3.5 dB Typ., High Power: +27.5 dBm Typ.

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 100 MHz	10 - 100 MHz
Gain (dB)	19.7±0.5	18.7 Min./20.7 Max.
Power @ 1 dB Comp. (dBm)	+27.5	+26 Min.
Reverse Isolation (dB)	- 25	- 24 Max.
VSWR In Out	1.7:1 1.3:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.5 Max.
Power Vdc mA	+15 135	+15 145 Max.

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

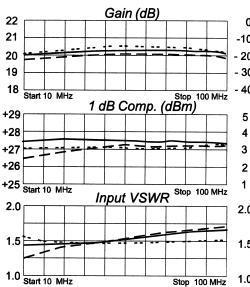
Second Order Harmonic Intercept Point	+58	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point		

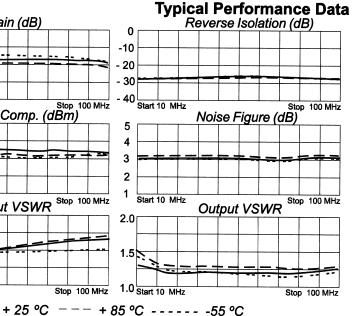
## **Maximum Ratings**

Ambient Operating Temperature.	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	
Maximum Peak Power	

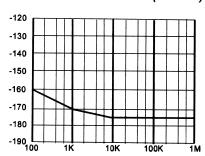
## Guaranteed Phase Noise Performance (dBc/Hz) \*

Frequency	Typical	Guarantee (min.)
100 Hz	162	158
1 KHz	172	168
10 KHz	176	172
100 KHz	176	172
1 MHz	176	172





## Residual Phase Noise (dBc/Hz)



## \*Residual Phase Noise Test Conditions:

- Carrier Frequency: 70 mHz
- Power Output: +27.5 dBm
- Temperature: 25 °C
- Agilent ES5500 System

## **Linear S-Parameters**

FREQ.	S	11	;	S21	S	12		22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.21	- 54	8.79	-127	.04	-124	.34	72
10	.16	- 29	9.89	-157	.05	-157	.14	40
20	.16	- 27	10.12	-175	.05	-178	.09	26
50	.19	- 50	10.11	164	.05	160	.09	18
75	.21	- 72	10.00	151	.05	145	.09	12
100	.24	- 91	9.84	139	.05	132	.09	<u>'</u> -
150	.32	-126	9.26	116	.06	108	.06	-ĕ



Available as: TM6112, 4 Pin TO-8 (T4)

TN6112, 4 Pin Surface Mount (SM3) FP6112, 4 Pin Flatpack (FP4) BX6112, Connectorized Housing (H1)

### **Features**

■ Low Noise Figure: 2 dB Typical

Medium Output Power: +14 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 200 MHz	10 - 200 MHz
Gain (dB)	16.4	15.5 Min.
Power @ 1 dB Comp. (dBm)	+14.5	+12.0 Min.
Reverse Isolation (dB)	- 20	- 19 Max.
VSWR In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.0 Max.
Power Vdc mA	+15 27	+15 30 Max.

# Typical Intermodulation Performance at 25 ° C

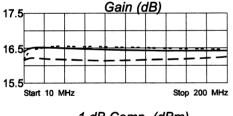
Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	+38 (Typ.)
Third Order Two Tone Intercept Point	+28 (Typ.)

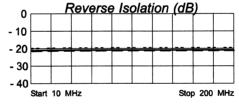
## **Maximum Ratings**

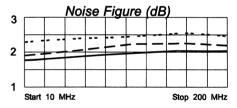
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

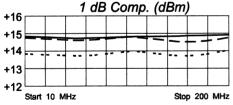
Note: Care should always be taken to effectively ground the case of each unit.

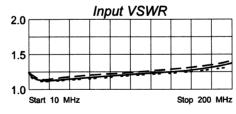
# **Typical Performance Data**

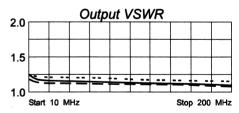












## Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.11 - 74	6.66 -172	.09 -172	.13 - 42
50	.06 - 84	6.67 168	.09 167	.08 - 23
100	.09 - 99	6.65 154	.09 151	.07 - 29
150	.12 -113	6.62 140	.09 136	.06 - 40
200	.18 -125	6.63 125	.10 123	.05 - 72
250	.25 -139	6.59 110	.10 108	.04 -122



Available as: TM6117, 4 Pin TO-8 (T4)

TN6117, 4 Pin Surface Mount (SM3)

FP6117, 4 Pin Flatpack (FP4)

BX6117, Connectorized Housing (H1)

### **Features**

- Low Noise Figure: <1.3 dB Typical</p>
- Medium Third Order Intercept: +28 dBm Typical Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	5 - 250 MHz
Gain (dB)	8.2	7.0 Min.
Power @ 1 dB Comp. (dBm)	+10	+9.0 Min.
Reverse Isolation (dB)	- 11	- 10 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<1.3	2.0 Max.
Power Vdc mA	+15 12	+15 13 Max.

# Typical Intermodulation Performance at 25 ° C

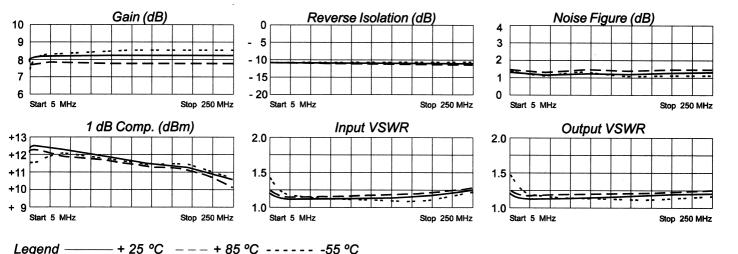
Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+28 (Typ.)

## **Maximum Ratings**

Ambient Operating Temperature .	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



#### Linear S-Parameters

FREQ.		31		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.08	167	2.50	9	-28	9	.09	166
10	.07	164	2.53	3	.28	3	.07	160
50	.05	176	2.55	-10	.29	-10	.06	164
100	.05	-177	2.56	-22	.28	-22	.06	154
150	.06	-163	2.56	-34	.28	-32	.07	149
200	.08	-155	2.56	<del>-4</del> 6	.27	-44	.08	145
250	.12	-155	2.56	-58	.27	-56	.10	147



Available as: TM6118, 4 Pin TO-8 (T4)

TN6118, 4 Pin Surface Mount (SM3) FP6118, 4 Pin Flatpack (FP4) BX6118, Connectorized Housing (H1)

### **Features**

Low Noise: <2 dB Typical</p>

High Intercept: >+33 dBm Typical

Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 200 MHz	10 - 200 MHz
Gain (dB)	10	10 ± .6 Min.
Power @ 1 dB Comp. (dBm)	+18	+16.5 Min.
Reverse Isolation (dB)	- 12.5	- 12 Max.
VSWR In Out	1.2:1 1.2:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.5	2.0 Max.
Power Vdc mA	+15 18	+15 20 Max.

# Typical Intermodulation Performance at 25 ° C

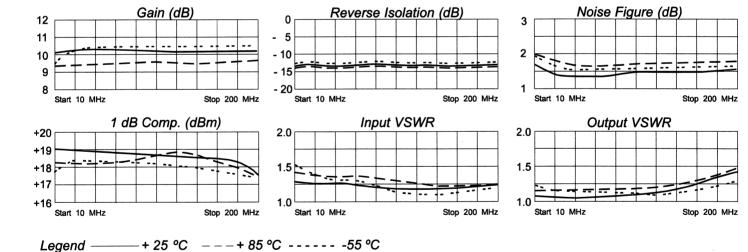
Second Order Harmonic Intercept Point	+59 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+33 (Typ.)

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



### **Linear S-Parameters**

FREQ.		S11		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.14	169	3.18	4	.23	4	.05	112
25	.12	171	3.24	-5	.23	-4	.02	92
50	.12	171	3.23	-14	.23	-12	.02	108
100	.09	172	3.21	-29	.23	-27	,05	125
150	.08	-164	3.24	-44	.22	-42	.10	122
200	12	-135	3 22	-61	21	-57	.17	113



–+ 25 °C

Available as: TM6119, 4 Pin TO-8 (T4)

TN6119, 4 Pin Surface Mount (SM3)

FP6119, 4 Pin Flatpack (FP4)

BX6119, Connectorized Housing (H1)

### **Features**

- High Output Power: +23 dBm Midband Typ.
- High Third Order Intercept: +40 dBm Midband Typ.
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	30 - 250 MHz	30 - 250 MHz
Gain (dB)	8 ± 0.5	6.5 Min.
Power @ 1 dB Comp. (dBm)	+23	+20.0 Min.
Reverse Isolation (dB)	- 13	- 12 Max.
VSWR In Out	1.7:1 1.5:1	2.3:1 Max. 2.0:1 Max.
Noise figure (dB)	3.0	3.5 Max.
Power Vdc mA	+15 43	+15 50 Max.

## Typical Intermodulation Performance at 25 ° C

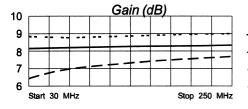
Second Order Harmonic Intercept Point	+50 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

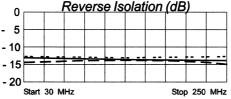
## **Maximum Ratings**

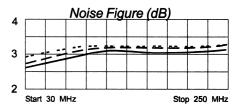
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

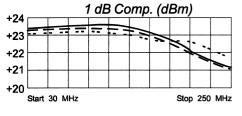
Note: Care should always be taken to effectively ground the case of each unit.

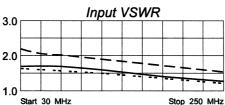
# **Typical Performance Data**

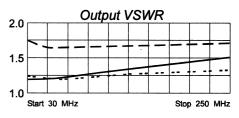












Legend — + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	8	31		S2 <u>1</u>		S12		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
30	.25	166	2.63	- 4	.22	- 5	.08	117
50	.24	160	2.62	-11	.22	-12	.09	109
100	.23	143	2.59	-25	.21	-26	.13	86
150	.20	126	2.61	-38	.21	-40	.18	70
200	.16	112	2.61	-52	.20	-54	.21	60
250	.11	107	2.63	-66	.20	-68	.22	52



Available as: TM6121, 4 Pin TO-8 (T4)

TN6121, 4 Pin Surface Mount (SM3) FP6121, 4 Pin Flatpack (FP4)

BX6121, Connectorized Housing (H1)
PN6121, Reduced Size Surface Mount (SM11)

## **Features**

High Intercept: > +37 dBm Typical
 Low Noise Figure: < 3 dB Typical</li>
 Operating Temp. - 55 °C to +85 °C
 Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 200 MHz	20 - 200 MHz
Gain (dB)	10	10 ± .6
Power @ 1 dB Comp. (dBm)	+20	+18.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3	4.0 Max.
Power Vdc mA	+15 60	+15 70 Max.

# Typical Intermodulation Performance at 25 ° C

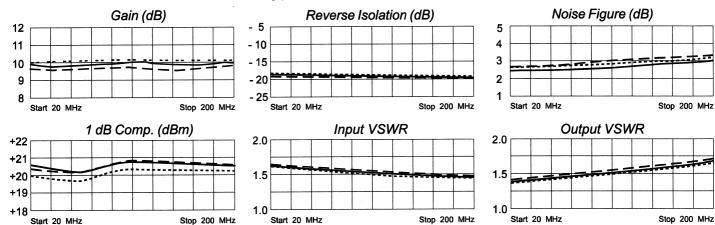
Second Order Harmonic Intercept Point	+60 (Typ.)
Second Order Two Tone Intercept Point	+55 (Typ.)
Third Order Two Tone Intercept Point	+38 (Typ.)

## **Maximum Ratings**

waxiiiiuiii rauiiys	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 17 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ. MHz	<b>S1</b> 1 Mag	 Deg	<b>S</b> Mag	<b>21</b> Deg	<b>S</b> Mag	12 Deg	<b>S</b> Mag	22 Deg
10	.20		3.10	-174	.11	-175	.21	-169
20	.19	-166	3.12	178	.12	176	.22	-176
50	.18	176	3.09	165	.11	163	.22	176
100	.18	161	3.07	147	.11	143	.23	-165
150	.18	151	3.08	130	.11	126	.24	155
200	.20	139	3.10	112	.11	108	.24	148
300	.25	108	3.01	71	.09	78	.30	143



Available as: TM6131, 4 Pin TO-8 (T4)

TN6131, 4 Pin Surface Mount (SM3)

FP6131, 4 Pin Flatpack (FP4)

BX6131, Connectorized Housing (H1)

## **Features**

■ High Intercept: +37 dBm Typical

■ High Output Power: +20 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 500 MHz	10 - 500 MHz		
Gain (dB)	10.3	9 min/ 11 max		
Power @ 1 dB Comp. (dBm)	+20	+18.0 Min.		
Reverse Isolation (dB)	- 22	- 20 Max.		
VSWR In Out	1.25:1 1.25:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	4.5	6.5 Max.		
Power Vdc mA	+15 62	+15 70 Max.		

## Typical Intermodulation Performance at 25 ° C

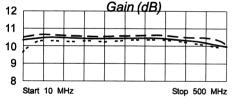
<i>J</i> I			-
Second C	Order Harmonic Intercept Point	+56	(Typ.)
Second C	Order Two Tone Intercept Point	+50	(Typ.)
	er Two Tone Intercept Point		

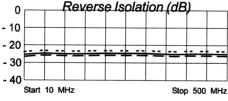
## **Maximum Ratings**

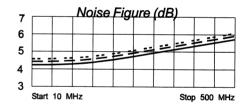
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	
	(3 μsec Max.)

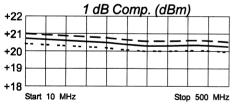
Note: Care should always be taken to effectively ground the case of each unit.

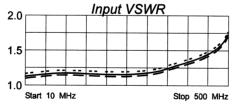
## **Typical Performance Data**

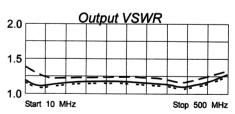












Legend ——— + 25 °C ---- - 55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.11 - 41	3.39 -156	.08 -157	.09 -105
50	.07 - 16	3.49 168	.08 167	.05 149
100	.06 - 17	3.47 152	.08 149	.06 105
200	.05 - 47	3.50 123	.08 119	.09 48
300	.05 -133	3.55 94	.09 91	.08 - 11
400	.14 159	3.57 61	.10 64	.07 - 87
500	.29 120	3.40 25	11 35	10 179



Available as: TM613

TM6134, 4 Pin TO-8 (T4)

TN6134, 4 Pin Surface Mount (SM3) FP6134, 4 Pin Flatpack (FP4)

## BX6134, Connectorized Housing (H1)

### **Features**

- High Output Power: +26 dBm Typ.
- High Dynamic Range: lp3 = +39 dBm Typ.
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

		·		
CHARACTERISTIC	TYPICAL	MIN/MAX		
	Ta= 25 °C	Ta = -55 °C to +85 °C		
Frequency	20 - 200 MHz	20 - 200 MHz		
Gain (dB)	14.3	12.5 Min.		
Power @ 1 dB Comp. (dBm)	+26	+23.0 Min.		
Reverse Isolation (dB)	- 17	- 15 Max.		
VSWR In Out	1.60:1 1.35:1	2.5:1 Max. 2.5:1 Max.		
Noise figure (dB)	4	6.0 Max.		
Power Vdc	+15	+15 110 Max.		
m A	90	110 Max.		

# Typical Intermodulation Performance at 25 ° C

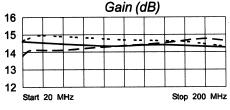
Second Order Harmonic Intercept Point	+58 (Typ.)
Second Order Two Tone Intercept Point	+54 (Typ.)
Third Order Two Tone Intercept Point	+39 (Typ.)

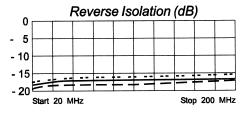
## **Maximum Ratings**

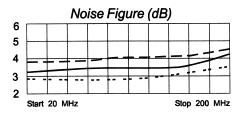
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

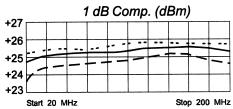
Note: Care should always be taken to effectively ground the case of each unit.

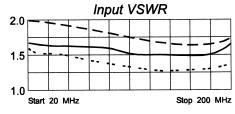
# **Typical Performance Data**

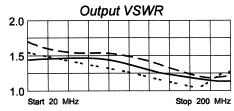












\_egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11		S2 <u>1</u>		S1 <u>2</u>		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
20	.25	-179	5.27	180	.13	179	.17	7
50	.24	175	5.23	165	.13	163	.17	- 10
100	.23	173	5.19	146	.13	1 <del>44</del>	.13	- 34
150	.26	178	5.17	127	.14	125	.07	- 80
200	.33	178	5.11	108	.15	107	.08	162



Available as: TM6143, 4 Pin TO-8 (T4)

TN6143, 4 Pin Surface Mount (SM3)

FP6143, 4 Pin Flatpack (FP4)

BX6143, Connectorized Housing (H1)

## **Features**

■ High Gain: 15.7 dB Typical
 ■ Low Noise: 1.6 dB Typical
 ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15.7	14.5 Min.
Power @ 1 dB Comp. (dBm)	+7.5	+5.0 Min.
Reverse Isolation (dB)	- 19	- 16 Max.
VSWR In Out	1.7:1 1.6:1	2.5:1 Max. 2.5:1 Max.
Noise figure (dB)	1.6	2.5 Max.
Power Vdc mA	+15 14.5	+15 16 Max.

# Typical Intermodulation Performance at 25 ° C

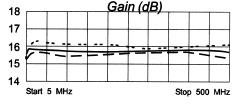
Second Order Harmonic Intercept Point	+33 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+20 (Tvp.)

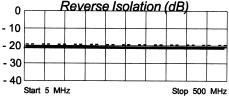
## **Maximum Ratings**

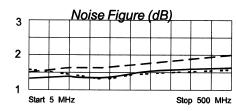
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

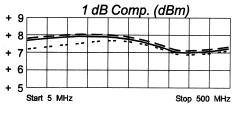
Note: Care should always be taken to effectively ground the case of each unit.

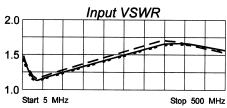
# **Typical Performance Data**

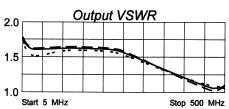












.egend ------ + 25 °C --- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.16 - 65	6.00 -165	.09 -165	.28 - 23
50 100	.08 - 72 .11 - 92	6.14 167 6.12 153	.10 165 .10 147	.24 - 26 .23 - 46
200 300	.18 -120 .23 -143	6.11 124 6.14 95	.10 117	.22 - 85
400	.25 -171	6.25 64	.11 89 .11 65	.19 -122 .09 -158
500	.22 145	6.07 27	.11 41	.04 - 3



Available as:

TM6145, 4 Pin TO-8 (T4)

TN6145, 4 Pin Surface Mount (SM3)

FP6145, 4 Pin Flatpack (FP4)

BX6145, Connectorized Housing (H1)

### **Features**

- Low Noise Figure: 2.5 dB Typical
- Midband Output Power: +19 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	10.7	10.0 Min.
Power @ 1 dB Comp. (dBm)	+19	+16.0 Min.
Reverse Isolation (dB)	- 12	- 11 Max.
VSWR In Out	1.5:1 <2.5:1	2.0:1 Max. 3.0:1 Max.
Noise figure (dB)	3.0	5.0 Max.
Power Vdc mA	+15 50	+15 55 Max.

Note: Care should always be taken to effectively ground the case of each unit.

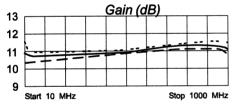
# Typical Intermodulation Performance at 25 ° C

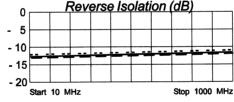
Second Order Harmonic Intercept Point	+54 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+35 (Typ.)

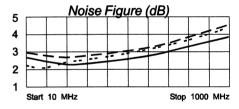
## Maximum Ratings

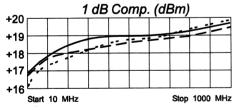
Maximumitatingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

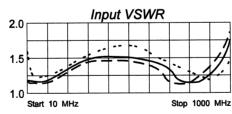
# **Typical Performance Data**

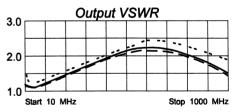












### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.11	113	3.52	-165	.22	-169	.12	100
100	.10	81	3.52	169	.22	169	.13	77
200 400 600	.15	56	3.50	155	.22	155	.21	56 25
400	.21	20	3.50	128	.22	132	.35	25
600	.18	- 16	3.57	102	.23	111	.42	- 9
800	.07	-101	3.73	73	.25	89	.39	- 49
1000	.27	121	3.73	38	.28	63	.27	-108



Available as: TM6147, 4 Pin TO-8 (T4)

TN6147, 4 Pin Surface Mount (SM3)

FP6147, 4 Pin Flatpack (FP4)

BX6147, Connectorized Housing (H1)

## **Features**

■ Medium Gain: 17 dB Typical

■ High Output Power: +20 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	17	16.0 Min.
Power @ 1 dB Comp. (dBm)	+20	+17.5 Min.
Reverse Isolation (dB)	- 19	- 17 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	4.5 Max.
Power Vdc mA	+15 50	+15 55 Max.

# Typical Intermodulation Performance at 25 ° C

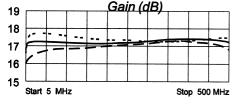
Second Order Harmonic Intercept Point	+50 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+35 (Typ.)

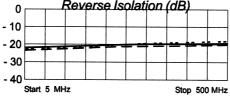
## **Maximum Ratings**

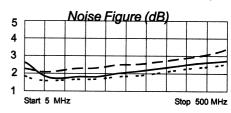
•	axiiiiaiii i tatiiigo	
Α	Ambient Operating Temperature	-55°C to + 100 °C
S	Storage Temperature	-62°C to + 125 °C
C	Case Temperature	+ 125 °C
	OC Voltage	+ 18 Volts
C	Continuous RF Input Power	+ 13 dBm
S	Short Term RF Input Power	50 Milliwatts
		(1 Minute Max.)
M	flaximum Peak Power	0.5 Watt
		(3 μsec Max.)

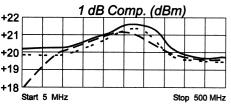
Note: Care should always be taken to effectively ground the case of each unit.

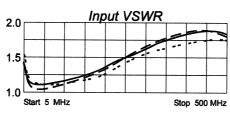
## **Typical Performance Data**

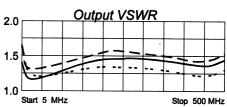












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	\$22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.16 - 76	6.84 -156	.09 -155	.15 - 33	
50	.04 - 87	7.19 166	.09 163	.08 20	
100	.07 - 94	7.15 148	.09 145	.12 23	
200	.15 -123	7.16 114	.10 108	.18 3	
300	.24 -159	7.21 80	.11 75	.18 - 30	
400	.29 155	7.38 43	.11 41	.16 - 82	
500	.29 89	7.30 1	.11 5	.19 -161	



Available as:

TM6149, 4 Pin TO-8B (T4)

TN6149-3, 4 Pin Surface Mount (SM3) FP6149-4, 4 Pin Flatpack (FP4) BX6149, Connectorized Housing (H1) PN6149, Reduced Size Surface Mount (SM11)

## **Features**

■ Medium Gain: 15.3 dB Typical

■ Medium Output Power: +16 dBm Typical

- Operating Temp. 55 °C to + 85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15.3	14.5 Min.
Power @ 1 dB Comp. (dBm)	+16	+14.5 Min.
Reverse Isolation (dB)	-19	-18 Max.
VSWR In Out	<1.25:1 <1.25:1	2:0:1 Max. 2:0:1 Max.
Noise figure (dB)	<5.0	6.0 Max.
Power Vdc mA	+15 45	+15 48 Max.

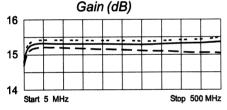
Typical Intermodulation Performance at 25 ° C

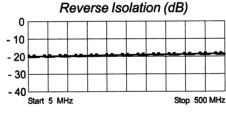
**Maximum Ratings** 

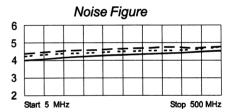
Maxilliulli Nauliya	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBn
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.
Maximum Peak Power	
	(3 usec Max.

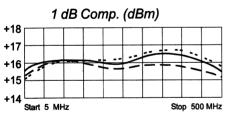
Note: Care should always be taken to effectively ground the case of each unit.

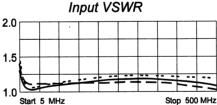
## **Typical Performance Data**

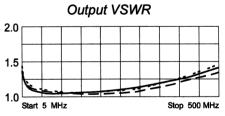












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

### **Linear S-Parameters**

FRFO.	FREOS11		S2	S21		S12		S22	
MHZ	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg	
5	.14	- 66	5.58	-167	.09	13	.14	119	
50	.02	22	5.85	172	.09	1	.01	93	
100	.03	49	5.81	161	.09	-2	.01	-171	
200	.07	52	5.78	141	.10	-7	.03	-160	
300	.08	44	5.75	121	.10	-12	.05	169	
400	.08	41	5.75	101	.11	-17	.09	140	
500	.05	50	5.71	79	.12	-25	.14	110	
600	.06	136	5.67	56	.13	-34	.22	77	



Available as:TM6153, 4 Pin TO-8 (T4)
TN6153-3, 4 Pin Surface Mount (SM3)
FP6153-4, 4 Pin Flatpack (FP4)
BX6153, Connectorized Housing (H1)
PN6153, Reduced Size Surface Mount (SM11)

#### **Features**

- GaAs FET: Low Noise Figure:<3 dB Typical
- Medium Output Power:>+7 dBm Typical
- Operating Case Temp. -55 °C to + 85°C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency	300-1800 MHz	300-1800 MHz
Gain (dB)	11.5	10.5 Min.
Power @ 1 dB Comp. (dBm)	>+7	+6.0 Min.
Reverse Isolation (dB)	- 17	-15 Max.
VSWR In Out	<2.5:1 <2.0:1	3.0:1 Max. 2.5:1 Max.
Noise figure (dB)	<3	4.0 Max.
Power Vdc m A	+15 18	+15 20 Max.

Note: Care should always be taken to effectively ground the case of each unit.

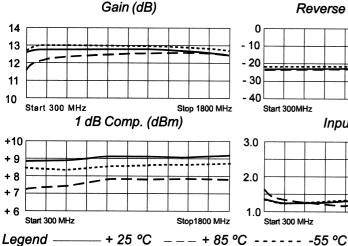
# Typical Intermodulation Performance at 25 ° C

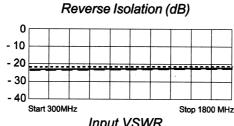
Second Order Harmonic Intercept Point 328	(Typ.)
Second Order Two Tone Intercept Point +22	(Typ.)
Third Order Two Tone Intercept Point ÷18	

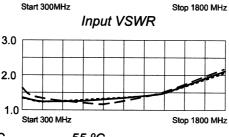
### Maximum Ratings

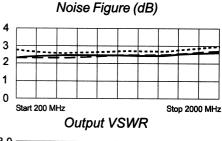
waxiiiluiii Naliiiy5	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

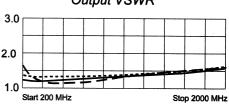
# **Typical Performance Data**











#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
300 400 600 800 1000 1400 1600 1800	.27 -41 .29 -53 .33 -76 .38 -96 .39 -117 .38 -137 .32 -163 .20 140 .28 22	3.83 148 3.79 138 3.74 117 3.67 97 3.72 78 3.83 56 4.02 31 4.14 1 4.13 -31	.11 -14 .11 -19 .11 -30 .11 -40 .11 -49 .12 -60 .12 -75 .13 -94 .14 -118	.05 25 .06 12 .07 -15 .06 -36 .07 -41 .06 -58 .05 -55 .05 -22



Available as: TM6155, 4 Pin TO-8 (T4)

TN6155, 4 Pin Surface Mount (SM3) FP6155, 4 Pin Flatpack (FP4)

BX6155, Connectorized Housing (H1)

### **Features**

■ Medium Gain: 12.5 dB Typical

■ High Output Power: > +19.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	300 - 1000 MHz	300 - 1000 MHz
Gain (dB)	12.5	10.5 Min.
Power @ 1 dB Comp. (dBm)	+19.5	+18.0 Min.
Reverse Isolation (dB)	- 13	- 12 Max.
VSWR In Out	<1.5:1 <2.0:1	2.0:1 Max. 3.0:1 Max.
Noise figure (dB)	<4.0	5.5 Max.
Power Vdc mA	+15 50	+15 60 Max.

# Typical Intermodulation Performance at 25 ° C

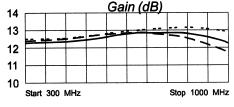
Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

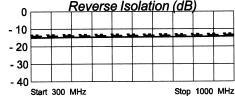
## **Maximum Ratings**

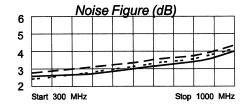
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

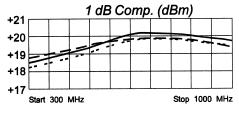
Note: Care should always be taken to effectively ground the case of each unit.

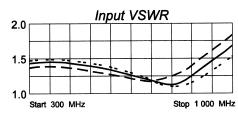
## **Typical Performance Data**

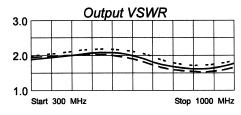












Legend ------ + 25 °C --- + 85 °C ---- - -55 °C

## Linear S-Parameters

FREQ.	S	11		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
200	.18	91	4.15	144	ـ 17	148	.28	8
300	.18	56	4.16	126	.18	130	.31	1
400	.18	23	4.16	107	.18	115	.33	- 9
500	.17	- 10	4.26	88	.18	99	.34	- 23
600	.13	- 47	4.34	69	.19	83	.33	- 39
800	.08	172	4.42	25	.21	48	.25	- 87
1000	.25	52	4.15	- 23	.22	7	.21	173



Available as: TM6157, 4 Pin TO-8 (T4)

TN6157, 4 Pin Surface Mount (SM3) FP6157, 4 Pin Flatpack (FP4) BX6157, Connectorized Housing (H1)

## **Features**

■ Medium Gain: 13 dB Typical

■ High Output Power: +22 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 500 MHz	20 - 500 MHz
Gain (dB)	13	10.5 Min.
Power @ 1 dB Comp. (dBm)	+22	+20.0 Min.
Reverse Isolation (dB)	- 23.5	- 22.5 Max.
VSWR In Out	<1.2:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<7.5	8.5 Max.
Power Vdc mA	+15 75	+15 85 Max.

# Typical Intermodulation Performance at 25 ° C

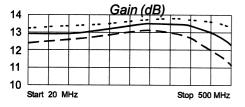
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

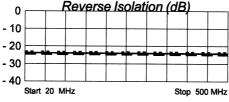
## **Maximum Ratings**

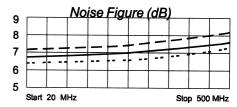
Maximum Natings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

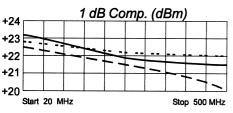
Note: Care should always be taken to effectively ground the case of each unit.

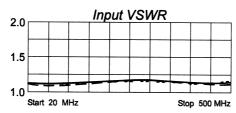
## **Typical Performance Data**

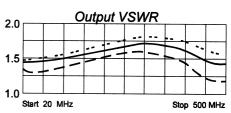












.egend ----- + 25 °C --- + 85 °C ----- -55 °C

## Linear S-Parameters

FREQ.		S11		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.06	-138	4.40	-170	.06	-170	.18	- 13
20	.05	-156	4.42	-180	.06	-179	.17	- 11
100	.06	-157	4.41	152	.06	150	.19	- 39
200	.08	-158	4.50	122	.06	122	.23	- 78
300	.09	-175	4.63	89	.06	91	.26	-117
400	.08	158	4.57	51	.06	68	.23	-164
500	.05	101	4.04	10	.05	42	.16	107



Available as: TM6160, 4 Pin TO-8 (T4)

TN6160-3, 4 Pin Surface Mount (SM3) FP6160-4, 4 Pin Flatpack (FP4) BX6160, Connectorized Housing (H1)

### **Features**

■ High Gain: 28 dB Typical

■ Low Noise Figure:<2 dB Typical</p>

■ Operating Temp. - 55 °C to + 85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	100-600 MHz	100-600 MHz
Gain (dB)	28	26 Min.
Power @ 1 dB Comp. (dBm)	+17	+16 Min.
Reverse Isolation (dB)	- 43	- 40 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2	3.0 Max.
Power Vdc m A	+15 65	+15 75 Max.

Typical Intermodulation Performance at 25 ° C

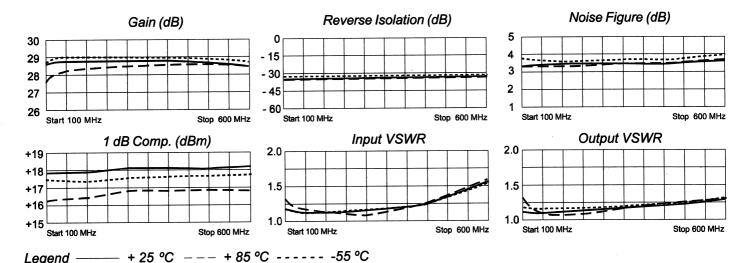
Second Order Harmonic Intercept Point	+51	(Typ.)
Second Order Two Tone Intercept Point	+46	(Typ.)
Third Order Two Tone Intercept Point	+32	(Typ.)

**Maximum Ratings** 

Maximum Raunys	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
50	.12 -168	25.49 -17	.01 -16	.13 -17
100	.16 -158	25.77 <b>-4</b> 8	.01 <b>-51</b>	.16 -50
200	.21 -175	25.09 -103	.01 -105	.20 -94
300	.16 175	24.57 -156	.01 -159	.22 -121
400	.15 -159	24.23 150	.01 162	.22 -145
500	.25 -176	24.57 93	.01 127	.17 -166
600	.31 115	25.28 28	.01 75	.08 -161



Available as: TM6162, 4 Pin TO-8 (T4)

TN6162, 4 Pin Surface Mount (SM3)

FP6162, 4 Pin Flatpack (FP4) BX6162, Connectorized Housing (H1)

## **Features**

- Low Noise Figure: <1.4 dB Typical
- Medium Output Power: +16 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 125 MHz	10 - 100 MHz
Gain (dB)	12.7	11.5 Min.
Power @ 1 dB Comp. (dBm)	+16	+14.0 Min.
Reverse Isolation (dB)	- 15.5	- 15 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<1.4	2.0 Max.
Power Vdc m A	+15 11	+15 12 Max.

# Typical Intermodulation Performance at 25 ° C

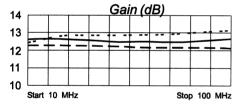
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+32 (Typ.)

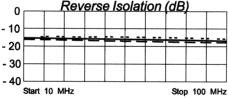
## **Maximum Ratings**

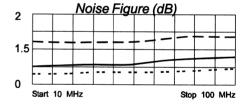
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

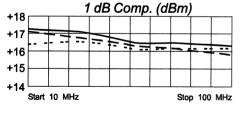
Note: Care should always be taken to effectively ground the case of each unit.

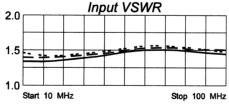
# **Typical Performance Data**

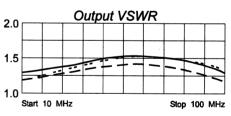












Legend ——— + 25 °C ---- -55 °C

### Linear S-Parameters

FREQ.	S11	\$2 <u>1</u>	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.15 -179	4.27 4	.17 2	.10 12	
10	.15 -180	4.32 - 4	$.17 - \overline{4}$	.12 - 12	
50	.19 179	4.29 - 43	.16 - 41	.20 - 96	
100	.19 162	4.31 - 92	.14 - 87	.12 -167	
150	.40 -175	3.46 -161	08 -153	47 - 29	



Available as: TM6171, 4 Pin TO-8 (T4)

TN6171, 4 Pin Surface Mount (SM3) FP6171, 4 Pin Flatpack (FP4)

BX6171, Connectorized Housing (H1)

### **Features**

■ Low Noise Figure: <2.3 dB Typical

High Gain: 15.2 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 500 MHz	5 - 500 MHz		
Gain (dB)	15.2	14.0 Min.		
Power @ 1 dB Comp. (dBm)	+0.5	- 2 Min.		
Reverse Isolation (dB)	- 21	- 20 Max.		
VSWR In Out	<1.6:1 <1.4:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	2.3	3.0 Max.		
Power Vdc mA	+15 11	+15 12 Max.		
Note: Care should always be taken to effectively ground the case of each unit.				

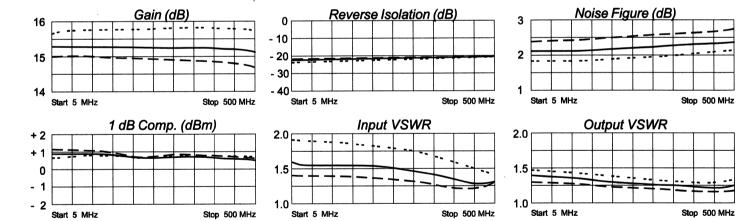
# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+21 (Typ.)
Second Order Two Tone Intercept Point	+15 (Typ.)
Third Order Two Tone Intercept Point	+12 (Typ.)

**Maximum Ratings** 

Maxilliulli italiliyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

# **Typical Performance Data**



Leaend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		<b>S22</b>	
MHz	Mag Deg	Mag	Deg	Mag	Deg	Mag	Deg	
5	.22 -175	5.74	-178	.07	4	.16	-175	
50	.21 165	5.75	167	.07	- 2	.16	170	
100	.21 150	5.73	153	.08	- 5	.15	160	
200	.20 123	5.71	127	.08	- 11	.13	138	
300	.18 102	5.73	99	.08	- 18	.12	114	
400	.14 95	5.75	70	.09	- 28	.10	84	
500	.13 126	5.71	38	.09	- 40	.11	35	
600	.29 136	5.37	2	.10	- 53	.16	- 17	



Available as: TM6176, 4 Pin TO-8 (T4)

TN6176, 4 Pin Surface Mount (SM3) FP6176, 4 Pin Flatpack (FP4) BX6176, Connectorized Housing (H1)

### **Features**

■ Medium Noise Figure: <4 dB Typical

■ Medium Output Power: +14 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERIST	C TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	13.5	12.0 Min.
Power @ 1 dB Comp. (dBm)	+14	+12.0 Min.
Reverse Isolation (dB)	- 16	- 15 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	5.0 Max.
Power Vdc mA	+15 38	+15 41 Max.

# Typical Intermodulation Performance at 25 ° C

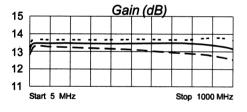
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+27 (Typ.)

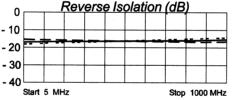
## **Maximum Ratings**

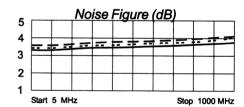
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

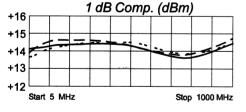
Note: Care should always be taken to effectively ground the case of each unit.

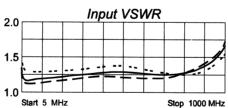
# **Typical Performance Data**

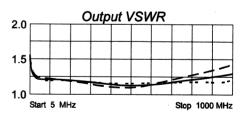












egend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.12 - 51	4.60 -170	.11 10	.17 144
50	.05 1	4.73 173	.11 - 1	.09 165
100	.06 18	4.72 164	.11 - 3	.08 165
200	.08 26	4.71 148	.12 - 6	.07 159
400	.14 12	4.70 115	.12 - 15	.04 168
600	.16 - 25	4.65 81	.13 -25	.04 -140
800	.14 - 93	4.49 46	.13 -38	.07 -124
1000	23 172	4 23 6	13 -52	14 -119



Available as: TM6182, 4 Pin TO-8 (T4)

TN6182, 4 Pin Surface Mount (SM3) FP6182, 4 Pin Flatpack (FP4) BX6182, Connectorized Housing (H1) PN6182, Reduced Size Surface Mount (SM11)

### **Features**

■ High Gain: 28.5 dB Typical

■ Low Noise Figure: 2.7 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C			
Frequency	5 - 1000 MHz	5 - 1000 MHz			
Gain (dB)	28.5	27.2 Min.			
Power @ 1 dB Comp. (dBm)	+15	+9 Min.			
Reverse Isolation (dB)	- 36	- 33 Max.			
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.			
Noise figure (dB)	2.7	4.5 Max.			
Power Vdc mA	+15 44	+15 50 Max.			

Note: Care should always be taken to effectively ground the case of each unit.

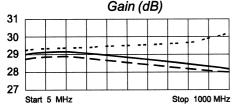
# Typical Intermodulation Performance at 25 ° C

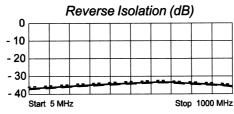
Second Order Harmonic Intercept Point	Too (Iyk
Second Order Two Tone Intercept Point	+31 (Typ
Third Order Two Tone Intercept Point	+22 (Tyr

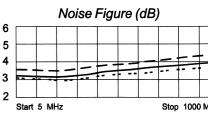
## **Maximum Ratings**

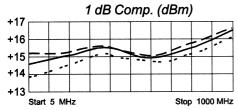
111051111111111111111111111111111111111	
Ambient Operating Temperature	55°C to + 100°
Storage Temperature	62°C to + 125°
Case Temperature	+ 125
DC Voltage	+ 18 Vo
Continuous RF Input Power	+ 6 dB
Short Term RF Input Power	50 Milliwa
	(1 Minute Ma
Maximum Peak Power	
	(3 µsec Ma

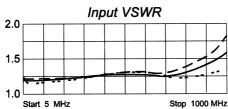
## **Typical Performance Data**

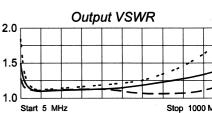












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ. MHz	S Mag	<b>611</b> Deg	\$ Mag	<b>321</b> Deg	<b>S</b> Mag	112 Deg	§ Mag	<b>22</b> Deg
10 50 100 250	.22 .22 .22 .22 .21	-155 -179 175 158	4.96 5.06 5.06 5.06	-173 176 169 150 121	.12 .12 .12 .12 .12 .14	8 3 2 1	.25 .22 .21 .22 .23	164 164 155 128 82
500 750 1000 1250 1500	.18 .13 .08 .10 .16	135 117 121 153 146	5.04 5.12 5.21 5.16 4.70	91 59 23 - 17	.14 .15 .16 .17 .18	- 0 - 6 -14 -21 -29	.23 .24 .21 .17 .11	42 6 - 26 - 40



Available as: TM6183, 4 Pin TO-8 (T4)

TN6183, 4 Pin Surface Mount (SM3) FP6183, 4 Pin Flatpack (FP4)

BX6183, Connectorized Housing (H1)
PN6183, Reduced Size Surface Mount (SM11)

## **Features**

■ High Gain: 29 dB Typical

■ Low Noise Figure: <4 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	29.0	28.0 Min.
Power @ 1 dB Comp. (dBm)	+15	+13.5 Min.
Reverse Isolation (dB)	- 36	- 34 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	5.0 Max.
Power Vdc mA	+15 70	+15 83 Max.

# Typical Intermodulation Performance at 25 ° C

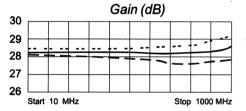
Second Order Harmonic Intercept Point	+37 (Typ.)
Second Order Two Tone Intercept Point	+32 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

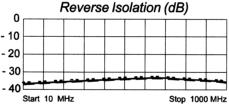
## **Maximum Ratings**

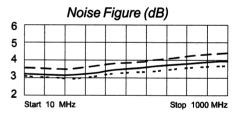
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

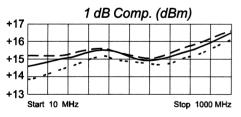
Note: Care should always be taken to effectively ground the case of each unit.

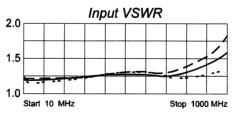
# **Typical Performance Data**

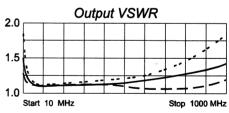












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ\$11		Q\$11\$21		S12		S22		
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.18	33	22.77	23	.01	 24	.36	113
10	.19	13	23.76	10	.01	12	.17	99
50	.18	-10	23.90	-9	.02	8	.05	76
100	.18	-22	23.93	-21	.01	2	.04	66
200	.17	-47	24.04	-44	.01	3	.04	54
400	.15	-93	23.87	-89	.01	-6	.04	41
600	.12	-129	23.38	-134	.02	1	.05	75
800	.10	-130	23.59	-178	.02	-12	.12	91
1000	.24	-135	25.96	132	.02	-26	.31	62

**Amplifonix** 

Available as: TM6184, 4 Pin TO-8 (T4)

TN6184-3 4 Pin Surface Mount (SM3) FP6184-4, 4 Pin Flatpack (FP4) BX6184, Connectorized Housing (H1)

## **Features**

22

■ High Gain: 20 dB Typical

■ Medium Output Power: +11 dBmTypical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency	10-2000 MHz	10-2000 MHz
Gain (dB)	19.5	18.0 Min.
Power @ 1 dB Comp. (dBm)	>+11	+10.0 Min.
Reverse Isolation (dB)	-30	- 25 Max.
VSWR In	<1.75:1	2.0:1 Max.
Out	<1.75:1	2.0:1 Max.
Noise figure (dB)	<4.5	6.0 Max.
Power Vdc	+15	+15
mA	54	60 Max.

Note: Care should always be taken to effectively ground the case of each unit.

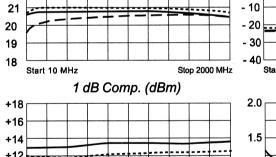
# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+43(Typ.)
Second Order Two Tone Intercept Point	+37(Typ.)
Third Order Two Tone Intercept Point	+23(Typ.)

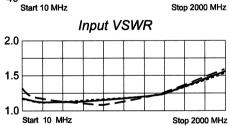
## **Maximum Ratings**

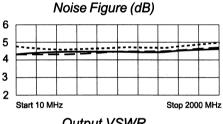
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	20 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2Watt
	(3 µsec Max.)

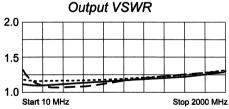
# Typical Performance Data Reverse Isolation (dB)



Gain (dB)







Legend -----+ 85 °C ---- -55 °C

Stop2000 MHz

### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.02 -168	9.97 3	.03 4	.06 163
50	.03 -143	9.90 -9	.03 0	.06 -158
100	.05 -130	9.85 -19	.03 -1	.08 -140
200	.09 -128	9.79 -39	.03 -3	.14 -135
400	.15 -142	9.79 -39 9.60 -77	.03 -9	.23 -148
800	.17 -172	9.43 -152	.03 -13	.29 173
800 1200		9.39 130	.03 -28	15 166
1600	.14 176	9.03 54	.03 -45	.25 -173
2000	.26 60	9.64 -45	.05 -78	.15 166 .25 -173 .23 102



Available as: TM6191, 4 Pin TO-8 (T4)

TN6191, 4 Pin Surface Mount (SM3)

FP6191, 4 Pin Flatpack (FP4)

BX6191, Connectorized Housing (H1) PN6191, Reduced Size Surface Mount (SM11)

### **Features**

■ Low Noise Figure: 2.5 dB Typical

■ Medium Output Power:+20 dBm Min.

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	100 - 600 MHz	100 - 600 MHz
Gain (dB)	23.5	22.0 Min.
Power @ 1 dB Comp. (dBm)	+ 21.5	+20 Min.
Reverse Isolation (dB)	- 35	- 33 Max.
VSWR In Out	<1.25:1 <1.50:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	4.0 Max.
Power Vdc mA	+15 95	+15 100 Max.

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+57 (Typ.)
Second Order Two Tone Intercept Point	+52 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

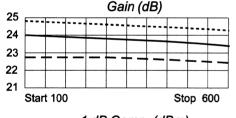
Note: Care should always be taken to effectively ground the case of each unit.

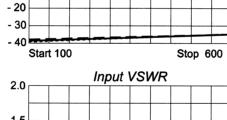
# **Typical Performance Data**

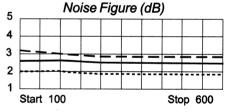
0

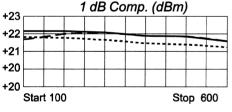
- 10

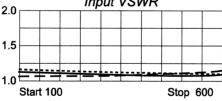
Reverse Isolation (dB)

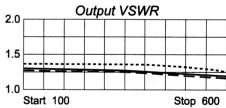












Legend ----- + 25 °C ---- - 55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
100	.05 175	15.95 -17	.0131 3	.12 -173
200	.04 175	15.83 -39	.0129 2	.09 173
300	.03 -179	15.73 -59	.0146 4	.13 162
400	.02 -170	15.60 -80	.0155 5	.14 177
500	.02 -139	15.42 -101	.0163 1	.10 -167
600	.01 -98	14.93 -122	.0172 -1	.04 148



Available as: TM6198, 4 Pin TO-8 (T4)

TN6198, 4 Pin Surface Mount (SM3)

FP6198, 4 Pin Flatpack (FP4)

BX6198, Connectorized Housing (H1)
PN6198, Reduced Size Surface Mount (SM11)

### **Features**

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available
- 5 Volt Bias

## **Specifications**

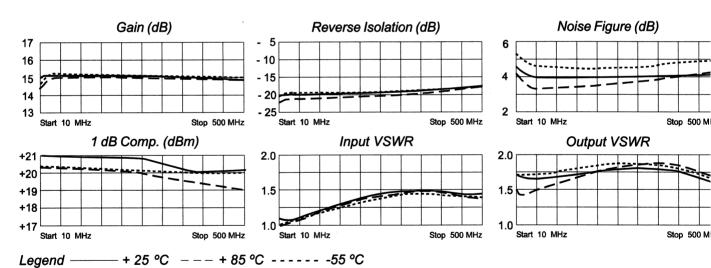
CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	15	13.5 Min.
Power @ 1 dB Comp. (dBm)	+20	+18.0 Min.
Reverse Isolation (dB)	- 19	- 18 Max.
VSWR In Out	<1.4:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	6.0 Max.
Power Vdc mA	+5 70	+5 75 Max.

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °
Storage Temperature	62°C to + 125°
Case Temperature	+ 125 °
DC Voltage	+ 7 Vo
Continuous RF Input Power	+ 13 dB
Short Term RF Input Power	100 Milliwa
	(1 Minute Max
Maximum Peak Power	0.2 Watt
	(3 usec Max

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



## Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.08 - 61	6.00 -173	.0952 -174	.25 - 8
20	.06 - 81	6.13 179	.0969 178	.24 - 13
50	.07 -100	6.13 168	.0983 165	.23 - 24
100	.10 -114	6.05 154	.0997 148	.23 - 42
200	.17 -136	5.88 126	.1014 118	.26 - 74
300	.21 -158	5.75 100	.1101 90	.27 -100
400	.19 -175	5.66 72	.1149 64	.26 -117
500	.15 179	5.53 43	.1226 41	.23 -121



Available as: TM6203, 4 Pin TO-8 (T4)

TN6203, 4 Pin Surface Mount (SM3) FP6203, 4 Pin Flatpack (FP4) BX6203, Connectorized Housing (H1)

### **Features**

- High Power: 26.5 dB Typical 1dBm Comp.
- High Third Order Intercept: +37 dBm
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	14.5	13 Min.
Power @ 1 dB Comp. (dBm) Reverse	26.5	25.0 Min.
Isolation (dB)	- 21	- 19 Max.
VSWR In Out	1.8 1.25	2.0 Max. 2.0 Max.
Noise figure (dB)	< 4.0*	7.5* Max.
Power Vdc mA	+15 125	+15 135 <b>M</b> ax.

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+37 (Typ.)

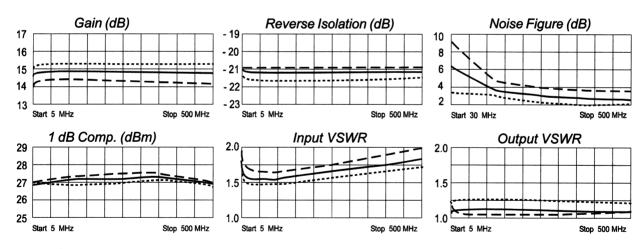
**Maximum Ratings** 

Maximamitatings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

<sup>\*</sup>Noise Figure is Greater below 30MHz.

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



egend ----- + 25 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.27 - 34	5.40 - 161	.0880 6	.06 177
50	.20 - 14	5.58 176	.0856 - 2	.09 178
100	.20 - 20	5.58 170	.0853 - 4	.09 173
200	.21 - 37	5.56 159	.0857 - 9	.09 164
300	.22 - 53	5.54 149	.0858 -13	.08 157
400	.23 - 69	5.51 138	.0858 -18	.08 151
500	.26 - 83	5.49 127	.0858 -23	.07 149



Available as:

TM6210, 4 Pin TO-8 (T4) TN6210, 4 Pin Surface Mount (SM3)

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point ...... +31 (Typ.) Second Order Two Tone Intercept Point ...... +26 (Typ.)

Third Order Two Tone Intercept Point ...... +18 (Tvp.)

FP6210, 4 Pin Flatpack (FP4)

BX6210, Connectorized Housing (H1)

## **Features**

- 5 Volt Bias; +7.5 dBm Typ. Midband Output Power
- Low Noise Figure: 1.8 dB Typ. Midband Value
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 500 MHz	5 - 500 MHz	
Gain (dB)	15.25	14.0 Min.	
Power @ 1 dB Comp. (dBm)	+7.5	+4.5 Min.	
Reverse Isolation (dB)	- 20	- 18 Max.	
VSWR In Out	<1.75:1 <1.75:1	2.5:1 Max. 2.5:1 Max.	
Noise figure (dB)	<2.0	3.0 Max.	
Power Vdc mA	+5 12	+5 15 Max.	

**Maximum Ratings** 

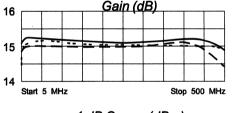
Ambient Operating Temperature ...... -55°C to + 100 °C Storage Temperature ......-62°C to + 125 °C Case Temperature ......+ 125 °C DC Voltage ...... + 10 Volts Continuous RF Input Power ...... + 13 dBm

Short Term RF Input Power ...... 50 Milliwatts ......(1 Minute Max.)

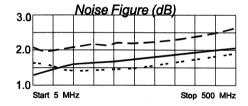
(3 usec Max.)

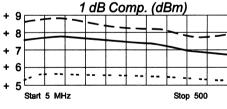
Note: Care should always be taken to effectively ground the case of each unit.

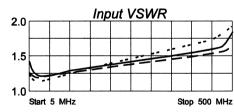
# **Typical Performance Data**

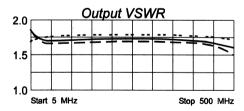












Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.11 - 43	5.90 -176	.09 -177	.27 - 16
50	.09 - 58	5.86 165	.09 161	.25 - 29
100	.11 - 86	5.81 <b>148</b>	.09 141	.26 - 52
200	.16 -129	5.72 117	.10 106	.29 - 95
300	.19 -171	5.72 84	.10 75	.30 -133
400	.21 134	5.68 49	.10 46	.29 -170
500	.28 70	5.42 10	.10 19	.23 144



Available as: TM6212, 4 Pin TO-8 (T4)

TN6212, 4 Pin Surface Mount (SM3) FP6212, 4 Pin Flatpack (FP4)

BX6212, 4 Fin Flatpack (FF4)
BX6212, Connectorized Housing (H1)

PN6212, Reduced Size Surface Mount (SM11)

### **Features**

■ 10 MHz to 1300 MHz: 10 dB Typical Gain

■ High Power: +22.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1300 MHz	10 - 1300 MHz
Gain (dB)	10	8.5 Min.
Power @ 1 dB Comp. (dBm)	+22.5	+19.5 Min.
Reverse Isolation (dB)	- 16	- 15 Max.
VSWR In Out	1.6:1 1.4:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<6.0*	8.5* Max.
Power Vdc mA	+15 92	+15 100 Max.

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+42 (Typ.)
Third Order Two Tone Intercept Point	+34 (Typ.)

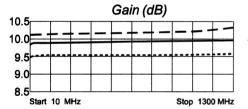
## **Maximum Ratings**

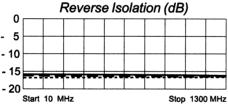
55°C to + 100 °C
62°C to + 125 °C
+ 125 °C
+ 18 Volts
+ 18 dBm
100 Milliwatts
(1 Minute Max.)
0.5 Watt
(3 µsec Max.)

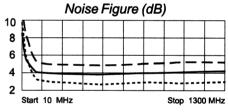
<sup>\*</sup> Noise Figure is greater for Frequencies below 30 MHz.

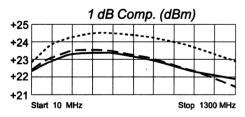
Note: Care should always be taken to effectively ground the case of each unit.

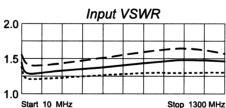
# **Typical Performance Data**

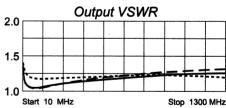












## **Linear S-Parameters**

FREQ.	\$11	\$21	\$12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.19 - 37	3.18 -166	.14 11	.14 111
100	.13 - 20	3.24 175	.15 - 3	.01 158
300	.14 - 44	3.24 160	.15 - 14	.03 -117
500	.16 - 65	3.24 147	.15 - 23	.06 -114
700	.17 - 83	3.24 133	.14 - 34	.08 -118
900	.19 - 98	3.23 119	.14 - 43	.09 -118
1000	.19 -103	3.23 112	.14 - 48	.10 -116
1100	.20 -110	3.26 105	.14 - 53	.11 -115
1200	.20 -116	3.29 98	.14 - 58	.12 -118
1300	.20 -122	3.31 91	.14 - 63	.12 -120



Available as: TM6134, 4 Pin TO-8 (T4)

TN6134-3 4 Pin Surface Mount (SM3) FP6134-4, 4 Pin Flatpack (FP4) BX6134, Connectorized Housing (H1)

PN6334, Reduced Size Surface Mount (SM11)

## **Features**

■ High Output Power: +26 dBm Typ.

■ High Dynamic Range: IP3 = +41 dBm Typ.

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20-200MHz	20-200MHz
Gain (dB)	14	12.5 Min.
Power @ 1 dB Comp. (dBm)	+26	+23.5 Min.
Reverse Isolation (dB)	+20	-18 Max.
VSWR In Out	<1.8:1 <1.8:1	2.5:1 Max. 2.5:1 Max.
Noise figure (dB)	3.5	5.0 Max.
Power Vdc mA	+12 95	+12 105 Max.

Note: Care should always be taken to effectively ground the case of each unit.

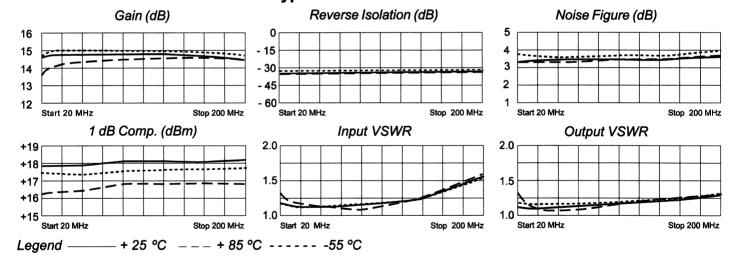
## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+56 (Typ.)
Second Order Two Tone Intercept Point	+50 (Typ.)
Third Order Two Tone Intercept Point	+41 (Tvp.)

**Maximum Ratings** 

waximum Ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+6 dBm
Short Term RF Input Power	20 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

## **Typical Performance Data**



#### Linear S-Parameters

FREQ.	S11	Deg	:	S21		612		522
MHz	Mag [		Mag	Deg	Mag	Deg	Mag	Deg
20		-9	5.04	-175	.08	-177	.29	15
50		-28	5.12	170	.08	166	.29	-5
100	.25	-56	5.13	153	.08	142	.28	-23
150		-81	5.07	137	.09	123	.25	-43
200		101	4.98	122	.09	106	.22	-65



Available as: TM6345, 4 Pin TO-8 (T4)

TN6345, 4 Pin Surface Mount (SM3) FP6345, 4 Pin Flatpack (FP4) BX6345, Connectorized Housing (H1)

### **Features**

■ Midband Noise Figure: 2.5 dB Typical

■ Midband Output Power: +17 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1100 MHz	10 - 1100 MHz
Gain (dB)	12.3	10.5 Min.
Power @ 1 dB Comp. (dBm)	+17	+15.0 Min.
Reverse Isolation (dB)	- 13.5	- 12.0 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 3.0:1 Max.
Noise figure (dB)	<3.0	4.0 Max.
Power Vdc mA	+15 45	+15 48 Max.

# Typical Intermodulation Performance at 25 ° C

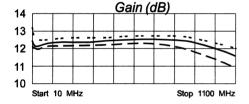
Second Order Harmonic Intercept Point	+54	(Typ.)
Second Order Two Tone Intercept Point	+46	(Typ.)
Third Order Two Tone Intercept Point	+33	(Typ.)

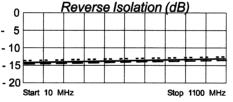
## **Maximum Ratings**

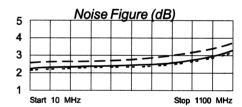
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

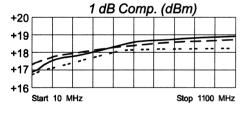
Note: Care should always be taken to effectively ground the case of each unit.

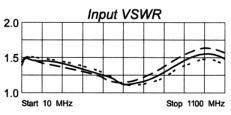
## **Typical Performance Data**

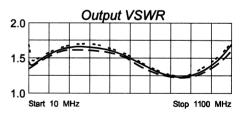












egend ----- + 25 °C ---- + 85 °C ---- - -55 °C

### Linear S-Parameters

FREQ.		S11		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.17	179	4.20	-166	.17	-169	.18	18
100	.18	132	4.14	162	.18	163	.20	9
200	.17	93	4.13	140	.18	144	.24	1
400	.13	26	4.14	99	.18	109	.24	- 26
600	.05	- 83	4.15	57	.20	73	.20	- 53
800	.15	144	4.10	12	.20	36	.13	-111
1100	.19	44	3.73	- 61	.21	- 23	.24	144



Available as: TM6416, 4 Pin TO-8 (T4)

TN6416, 4 Pin Surface Mount (SM3) FP6416, 4 Pin Flatpack (FP4) BX6416, Connectorized Housing (H1)

### **Features**

■ Medium Gain: 15 dB Typical

■ Medium Output Power: +13.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+13.5	+12.0 Min.
Reverse Isolation (dB)	- 17.5	- 17 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	4.5 Max.
Power Vdc mA	+15 35	+15 38 Max.

# Typical Intermodulation Performance at 25 ° C

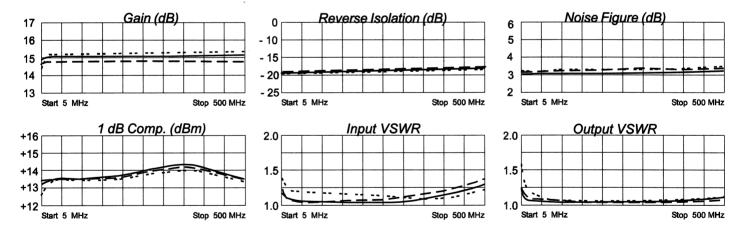
Second Order Harmonic Intercept Point	+41 (Typ.)
Second Order Two Tone Intercept Point	+35 (Typ.)
Third Order Two Tone Intercept Point	+27 (Typ.)

## **Maximum Ratings**

maxiiiiuiii rauiiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Leaend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
170 62	Wild Dog	mag bog		mag bog
5	.08 -118	5.54 -173	.11 9	.09 129
50	.05 -173	5.65 173	.11 -0	.02 154
100	.05 179	5.63 164	.12 -1	.03 175
200	.04 -176	5.65 147	.12 -3	.03 177
300	.04 -145	5.66 130	.12 -4	.04 172
400	.07 -128	5.69 113	.13 -8	.04 145
500	.12 -127	5.73 96	.14 -12	.06 111



Available as: TM6421, 4 Pin TO-8 (T4)

TN6421, 4 Pin Surface Mount (SM3) FP6421, 4 Pin Flatpack (FP4) BX6421, Connectorized Housing (H1)

## **Features**

High Gain: 30 dB Typ.

Medium Output Power: +9 dBm Typ. Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 400 MHz	5 - 400 MHz
Gain (dB)	30	27 Min.
Power @ 1 dB Comp. (dBm)	+9	+7 Min.
Reverse Isolation (dB)	- 36	- 33 Max.
VSWR In Out	1.35:1 1.65:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	6.0 Max.
Power Vdc mA	+15 37	+15 40 Max.

# Typical Intermodulation Performance at 25 ° C

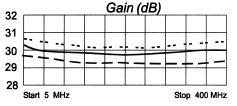
Second Order Harmonic Intercept Point	+41 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+22 (Typ.)

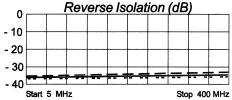
## **Maximum Ratings**

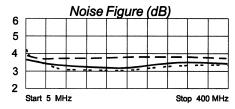
maximam ratingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

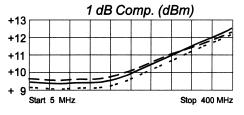
Note: Care should always be taken to effectively ground the case of each unit.

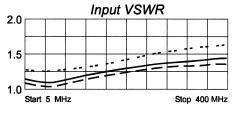
# **Typical Performance Data**

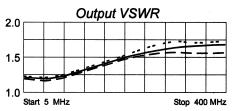












Legend ——— + 25 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	S1	<b>1</b>		321		512		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.06	-148	32.67	3	.01	7	.07	-162
50	.06	163	31.75	- 21	.01	2	.08	-165
100	.07	147	31.43	- 41	.01	6	.11	-162
200	.11	112	31.15	- 82	.01	14	.17	-176
300	.15	85	31.19	-123	.01	13	.23	163
400	.19	61	31.59	-166	.02	- 3	.26	140



Available as: TM

TM6440, 4 Pin TO-8 (T4)

TN6440, 4 Pin Surface Mount (SM3)

FP6440, 4 Pin Flatpack (FP4) BX6440, Connectorized Housing (H1)

### **Features**

■ Low Current Drain: 15mA with +9 dBm Output

Medium Gain: +13 dBm Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 400 MHz
Gain (dB)	13.0	12.0 Min.
Power @ 1 dB Comp. (dBm)	+9.0	+7.5 Min.
Reverse Isolation (dB)	- 18.5	- 17.5 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.6	5.0 Max.
Power Vdc mA	+15 15	+15 17 Max.

Note: Care should always be taken to effectively ground the case of each unit.

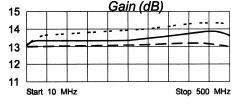
# Typical Intermodulation Performance at 25 ° C

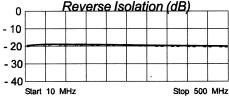
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

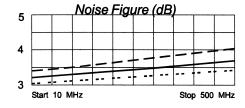
## **Maximum Ratings**

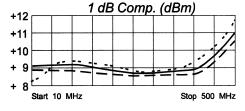
maxima i i i i i i i i i i i i i i i i i i	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

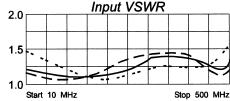
# **Typical Performance Data**

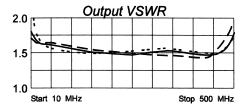












Legend ——— + 25 °C ---- + 85 °C ---- - -55 °C

## Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.10 -125	4.62 -175	.11 7	.29 165
50	.08 172	4.78 165	.12 - 8	.23 176
100	.05 136	4.78 147	.12 - 20	.22 179
200	.04 - 4	4.74 112	.11 - 42	.20 -168
300	.12 - 76	4.76 76	.11 - <b>66</b>	.20 -154
400	.15 -130	4.91 36	.11 - 93	.16 -135
500	.11 95	4.91 - 17	.10 -131	.30 - 82



Available as: TM6441, 4 Pin TO-8 (T4)

TN6441, 4 Pin Surface Mount (SM3) FP6441, 4 Pin Flatpack (FP4) BX6441, Connectorized Housing (H1)

## **Features**

- Medium Output Power: +16 dBm Typical
- High Dynamic Range: 85 dB Typical\*
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 400 MHz	20 - 400 MHz
Gain (dB)	14.5	13.0 Min.
Power @ 1 dB Comp. (dBm)	+16.0	+15.0 Min.
Reverse Isolation (dB)	- 19	- 18 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	5.0 Max.
Power Vdc mA	+15 32	+15 35 Max.

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+48 (Typ.)
Third Order Two Tone Intercept Point	+31 (Typ.)

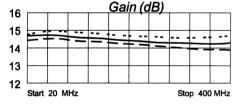
## **Maximum Ratings**

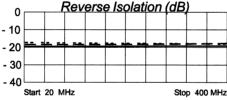
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

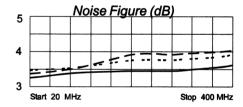
Spurious-free Dynamic Range Calculated for 1 MHz Bandwidth

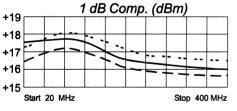
## Note: Care should always be taken to effectively ground the case of each unit.

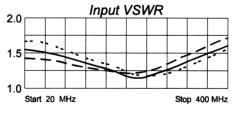
# **Typical Performance Data**

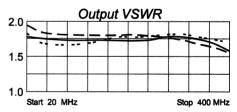












egend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.22 -154	5.38 -176	.10 7	.30 170
20	.22 -169	5.46 177	.10 2	.28 173
50	.21 179	5.47 164	.10 - 6	.27 178
100	.18 168	5.43 146	.10 - 15	.27 -180
200	.09 176	5.30 110	.10 - 31	
300	.13 -126	5.17 74	.11 - 49	.29 179 .29 166
400	.24 -136	5.18 34	.11 - 72	.24 124
500	.20 -160	4.98 - 18	.10 -108	.35 7



Available as: TM6442, 4 Pin TO-8 (T4)

TN6442, 4 Pin Surface Mount (SM3) FP6442, 4 Pin Flatpack (FP4)

BX6442, Connectorized Housing (H1)

## **Features**

- High Output Power: +22 dBm Typical
- High Dynamic Range IP3= 37 dBm
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 400 MHz	20 - 400 MHz
Gain (dB)	14	12.5 Min.
Power @ 1 dB Comp. (dBm)	+22	+19.0 Min.
Reverse Isolation (dB)	- 19	- 17 Max.
VSWR In Out	1.15:1 1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	6.0 Max.
Power Vdc mA	+15 62	+15 65 Max.

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

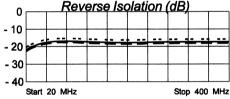
Second Order Harmonic Intercept Point	+57 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+37 (Typ.)

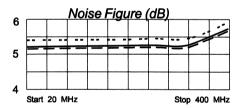
## **Maximum Ratings**

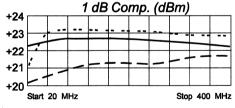
maxiii aiii i tatii go	
Ambient Operating Temperature.	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

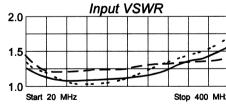
## **Typical Performance Data**

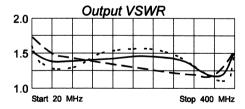












Leaend ------ + 25 °C --- + 85 °C ---- - -55 °C

## Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.13 -115	5.08 -173	.10 10	.23 153
50	.08 -168	5.23 161	.10 - 6	.16 177
100	.06 -170	5.19 138	.10 - 18	.16 -171
200	.07 -123	5.07 93	.11 - 39	.18 -169
300	.15 -155	5.04 45	.11 - 66	.11 159
400	.22 97	4.82 - 16	.12 -108	.12 - 14



Available as: TM6443, 4 Pin TO-8 (T4)

TN6443, 4 Pin Surface Mount (SM3)

FP6443, 4 Pin Flatpack (FP4)

BX6443, Connectorized Housing (H1)

## **Features**

- Low Power Drain: 10 mA @+5 Volts Typical
- Output Power: +6.5 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 400 MHz	10 - 400 MHz	
Gain (dB)	13.2	12.0 Min.	
Power @ 1 dB Comp. (dBm)	+6.5	+5.0 Min.	
Reverse Isolation (dB)	- 17	- 15 Max.	
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<3.5	5.0 Max.	
Power Vdc mA	+5 10	+5 12 Max.	

# Typical Intermodulation Performance at 25 ° C

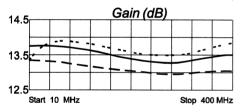
Second Order Harmonic Intercept Point	+33	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+19	(Typ.)

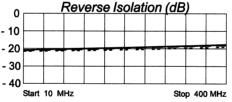
## **Maximum Ratings**

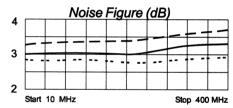
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

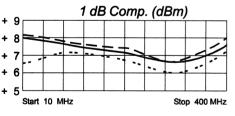
Note: Care should always be taken to effectively ground the case of each unit.

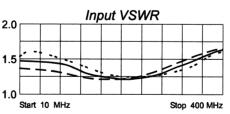
# **Typical Performance Data**

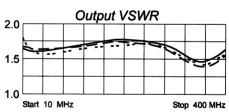












.egend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.15 -158	4.86 -179	.11 3	.22 172
50	.14 169	4.89 161	.11 - 9	.21 -175
100	.11 154	4.84 141	.12 - 19	.24 -169
200	.03 -177	4.71 100	.12 - 39	.29 -176
300	.12 -137	4.72 58	.12 - 61	.28 154
400	.16 157	4.87 6	.13 - 97	.27 54
500	.25 11	3.52 - 65	.10 -150	.69 - 52



Available as: TM6444, 4 Pin TO-8 (T4)

TN6444, 4 Pin Surface Mount (SM3) FP6444, 4 Pin Flatpack (FP4) BX6444, Connectorized Housing (H1)

## **Features**

■ Medium Power at 1dB Compresssion: +11 dBm

■ High Efficiency: 15 mA at +5V

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 400 MHz	10 - 400 MHz	
Gain (dB)	13	12.0 Min.	
Power @ 1 dB Comp. (dBm)	+11	+9.0 Min.	
Reverse Isolation (dB)	- 18	- 17 Max.	
VSWR In Out	1.50:1 1.50:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<4.0	5.5 Max.	
Power Vdc mA	+5 15	+5 17 Max.	

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	+37 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

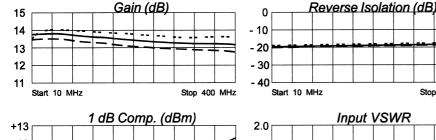
## **Maximum Ratings**

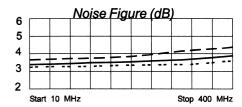
Stop 400 MHz

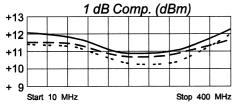
waximum kaungs	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

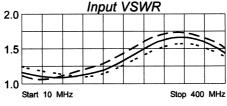
Note: Care should always be taken to effectively ground the case of each unit.

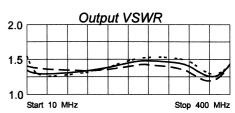
## **Typical Performance Data**











Leaend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11 <u>-</u>	S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.19 - 87	4.60 -164	.10 16	.33 154	
10	.11 -105	4.75 -175	.10 7	.26 158	
50	.06 -139	4.87 160	.11 - 10	.19 165	
100	.05 -125	4.85 137	.11 - 23	.15 165	
200	.14 - 92	4.72 91	.11 - 50	.11 -161	
300	.23 -110	4.55 44	.11 - 80	.14 -159	
400	.18 -110	4.41 - 13	.11 -122	.09 23	
500	.50 - 82	2.98 - 87	.07 179	.67 - 59	



Available as: TM6457, 4 Pin TO-8 (T4)

TN6457, 4 Pin Surface Mount (SM3)

FP6457, 4 Pin Flatpack (FP4)

BX6457, Connectorized Housing (H1)

### **Features**

- 5 Volt Operation
- Low Noise Figure: <2.0 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 400 MHz	5 - 400 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+10	+7.5 Min.
Reverse Isolation (dB)	- 19	- 18 Max.
VSWR In Out	1.5:1 1.7:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.0	3.0 Max.
Power Vdc mA	+5 15.5	+5 18 Max.

# Typical Intermodulation Performance at 25 ° C

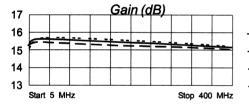
Second Order Harmonic Intercept Point	+41 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+24 (Typ.)

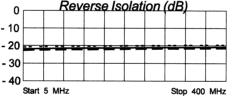
### **Maximum Ratings**

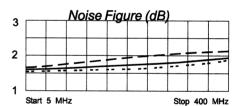
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

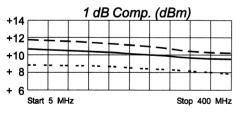
Note: Care should always be taken to effectively ground the case of each unit.

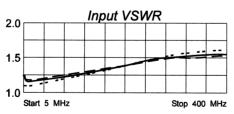
## **Typical Performance Data**

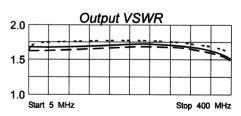












.egend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	522	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.12 - 53	5.89 -166	.09 -166	.27 - 16	
50	.08 - 62	6.10 167	.10 166	.25 - 20	
100	.11 - 88	6.05 152	.09 152	.25 - 34	
200	.19 -123	6.01 124	.09 123	.25 - 63	
300	.24 -154	6.08 94	.09 94	.25 - 89	
400	.28 171	6.12 62	.09 67	.21 -111	
500	.30 123	5.93 25	.08 37	12 -122	



Available as: TM6487, 4 Pin TO-8 (T4)

TN6487, 4 Pin Surface Mount (SM3) FP6487, 4 Pin Flatpack (FP4) BX6487, Connectorized Housing (H1)

### **Features**

- High Output at 1dB Compresssion: +17.5 dBm
- High Efficiency: 33 mA at 15V
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = $-55$ °C to $+85$ °C
Frequency	10 - 400 MHz	10 - 400 MHz
Gain (dB)	15.5	14.0 Min.
Power @ 1 dB Comp. (dBm)	+17.5	+15.0 Min.
Reverse Isolation (dB)	- 20	- 18 Max.
VSWR In Out	1.50:1 1.70:1	2.0:1* Max. 2.0:1 Max.
Noise figure (dB)	3.2	5.0 Max.
Power Vdc	+15	+15
m A	33	37 Max.

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+32 (Typ.)

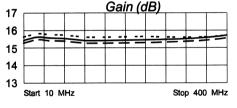
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

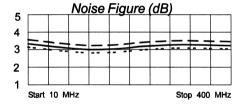
\* 2.5:1 from 300 to 400 MHz

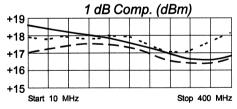
Note: Care should always be taken to effectively ground the case of each unit.

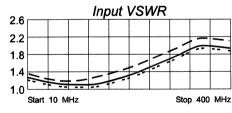
## **Typical Performance Data**

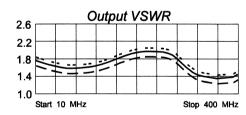












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S11S21		S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
10	.15 -136	6.09 -175	.09 8	.28 166	
50	.13 174	6.25 161	.09 - 7	.23 -180	
100	.09 155	6.17 139	.09 - 18	.24 -172	
200	.02 - 79	5.95 97	.10 - 39	.26 -166	
300	.15 -111	5.93 54	.10 - 61	.24 -170	
400	.20 178	5.91 4	.11 - 93	.05 -156	
500	38 30	477 - 64	10 -146	55 - 69	



Available as: TM6501, 4 Pin TO-8 (T4)

TN6501, 4 Pin Surface Mount (SM3) FP6501, 4 Pin Flatpack (FP4)

BX6501, Connectorized Housing (H1)

### **Features**

Low Noise Figure: 2.5 dB Typical

- High Gain: 16.5 dB Typical■ Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	16.5	15.5 Min.
Power @ 1 dB Comp. (dBm)	+3	+1.0 Min.
Reverse Isolation (dB)	- 20	- 18 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 10	+15 12 Max.

# Typical Intermodulation Performance at 25 ° C

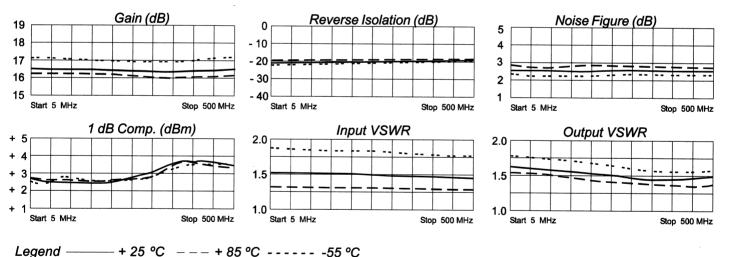
Second Order Harmonic Intercept Point		
Second Order Two Tone Intercept Point	+17	(Typ.)
Third Order Two Tone Intercept Point	+15	(Typ.)

### **Maximum Ratings**

55°C to + 100 °C
62°C to + 125 °C
+ 125 °C
+ 18 Volts
+ 13 dBm
50 Milliwatts
(1 Minute Max.)
0.5 Watt
(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

FREQ.			QS11		321		S12		\$22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg		
5	.21	-175	6.85	-177	.09	5	.21	-173		
50	.20	172	6.81	171	.09	Ī	.20	171		
100	.20	163	6.81	161	.09	Ó	.20	162		
200	.20	146	6.74	141	.10	-1	.19	145		
300	.19	131	6.69	123	.10	- <u>2</u>	.17	132		
400	.19	116	6.75	104	.10	-5	.17	124		
500	.19	103	6.88	84	.11	<b>-</b> 7	.18	119		
600	.19	92	7.16	62		-11	23	109		



Available as: TM6502, 4 Pin TO-8 (T4)

TN6502, 4 Pin Surface Mount (SM3) BX6502, Connectorized Housing (H1)

### **Features**

■ High Gain: 20 dB Typical

■ Medium Power @ 1 dB: 19 dBm Typical

■ Operating Temp. -55 °C to +85 °C

■ Environmental Screening available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency (MHz)	10 -500	10 - 500	
Gain (dB)	20	+ 19 Min.	
Power @ 1 dB Comp. (dBm)	19.5	+18.5 Min.	
Reverse Isolation (dB)	- 23	- 22 Max.	
VSWR In Out	1.4:1 1.3:1	1.75:1 Max. 1.75:1 Max.	
Noise figure (dB)	4	5 Max.	
Power Vdc mA	15 80	15 85 Max.	

Typical Intermodulation Performance at 25 ° C

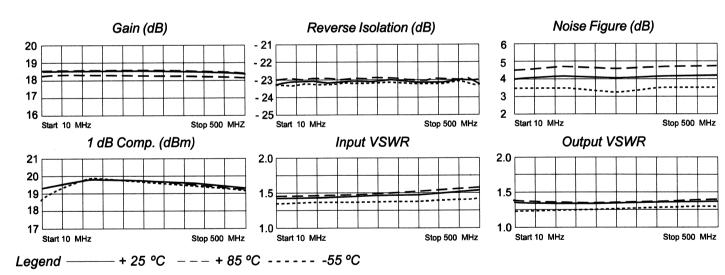
Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+40(Typ.)
Third Order Two Tone Intercept Point	+35(Typ.)

**Maximum Ratings** 

waxiiiuiii Nauiiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**





Available as: TM6503, 4 Pin TO-8 (T4)

TN6503, 4 Pin Surface Mount (SM3) FP6503, 4 Pin Flatpack (FP4) BX6503, Connectorized Housing (H1)

### **Features**

■ Low Noise Figure: 3.5 dB Typical

■ High Gain: +16.5 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	16.5	15.5 Min.
Power @ 1 dB Comp. (dBm)	+1.5	0.0 Min.
Reverse Isolation (dB)	- 20	- 18 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	4.5 Max.
Power Vdc mA	+15 10	+15 12 Max.

# Typical Intermodulation Performance at 25 ° C

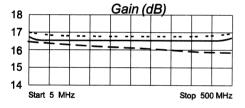
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+14 (Typ.)

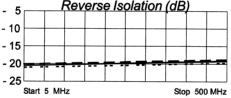
### **Maximum Ratings**

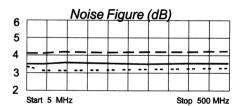
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

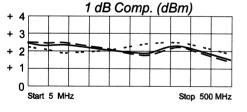
Note: Care should always be taken to effectively ground the case of each unit.

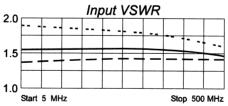
## **Typical Performance Data**

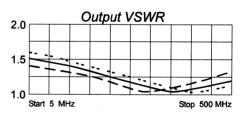












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5 50	.23 -177 .23 165	6.84 -178 6.76 169	.09 4	.21 -176
100	.23 149	6.73 158	.09 -1 .09 -1	.19 171 .18 162
200	.23 120	6.71 136	.10 -3	.12 147
300	.22 90	6.67 114	.10 -8	.06 147
400	.21 60	6.69 92	.11 -13	.03 -118
500	.19 24	6.78 69	.11 -19	.08 -114



Available as: TM6505, 4 Pin TO-8 (T4)

TN6505, 4 Pin Surface Mount (SM3) FP6505, 4 Pin Flatpack (FP4)

BX6505, Connectorized Housing (H1)

### **Features**

■ Medium Gain: 15 dB Typical

■ Medium Output Power: +10 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+10	+8.5 Min.
Reverse Isolation (dB)	- 18	- 16 Max.
VSWR In Out	<1.25:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.0	5.0 Max.
Power Vdc mA	+15 24	+15 27 Max.

# Typical Intermodulation Performance at 25 ° C

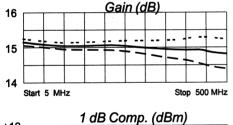
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

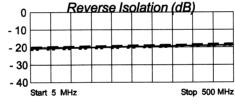
### **Maximum Ratings**

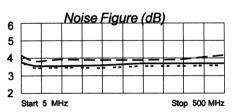
Maxilliulii itauliyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

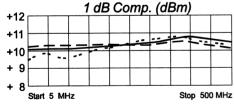
Note: Care should always be taken to effectively ground the case of each unit.

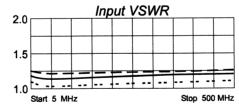
# **Typical Performance Data**

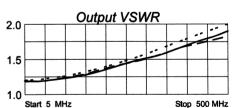












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQS11			\$21			S12		S22	
MHz	Mag De	g	Mag `	Deg	Mag	Deg	Mag	Deg	
5	.08 -3	3	5.80	-178	.10	2	.05	1.14	
50	.07 -	,	5.70	170	.10	-0	.05	1.16	
100	.07 -10	)	5.69	159	.10	-2	.07	1.16	
200	.08 -19		5.66	139	.10	-1	.11	1.13	
300	.08 -38		5.63	118	.11	-3	.17	1.10	
400	.08 -63		5.56	97	.11	-7	.24	1.05	
500	.08 -92		5.44	74	.12	-10	.30	1.01	



Available as: TM6507, 4 Pin TO-8 (T4)

TN6507, 4 Pin Surface Mount (SM3) FP6507, 4 Pin Flatpack (FP4)

BX6507, Connectorized Housing (H1) PN6507, Reduced Size Surface Mount (SM11)

### **Features**

Gain: 15.5 dB Typical

HighOutput Power: +24 dBmTypical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 500 MHz	10 - 500 MHz	
Gain (dB)	15.5	14.0 Min.	
Power @ 1 dB Comp. (dBm)	+24	+20.0 Min.	
Reverse Isolation (dB)	- 17	- 16 Max.	
VSWR In Out	1.5:1 1.7:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	4.0*	6.0* Max.	
Power Vdc mA	+15 110	+15 110 Max.	

## Typical Intermodulation Performance at 25 ° C

<b>3</b> 1	
Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	+40 (Typ.)
Third Order Two Tone Intercept Point	+35 (Typ.)

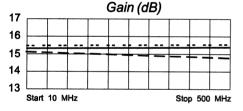
### **Maximum Ratings**

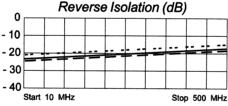
maxiiiiuiii ratiiiy5	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

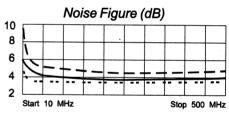
<sup>\*</sup> Noise Figure may be greater for frequencies below 20 MHz.

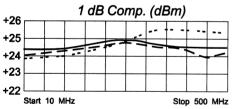
Note: Care should always be taken to effectively ground the case of each unit.

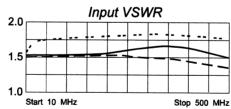
# **Typical Performance Data**

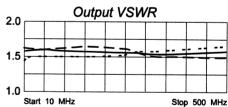












.egend ----- + 25 °C --- + 85 °C ---- -55 °C

### **Linear S-Parameters**

FREQ.	\$11		\$21		\$12		S22	
MHz 	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.16	-136	5.94	 -171	<sub>-</sub> 10	10	.20	144
50	.14	177	6.13	172	.10	1	.12	158
100	.14	159	6.12	161	.10	- 1	.12	155
200 300	.14 .13	134 117	6.04	139	.10	- 4	.11	141
400	.13	108	5.96 5.88	119 98	.11 .12	- 8 - 11	.11	119
500	.12	114	5.79	77	.12	- 18	.10 .11	103 85



# RF AMPLIFIER MODEL TM6509PM

Available as:

TM6509PM, 4 Pin TO-8 (T4)

TN6509PM, 4 Pin Surface Mount (SM3) FP6509PM, 4 Pin Flatpack (FP4)

BX6509PM, Connectorized Housing (H1)

### **Features**

- Superior Phase Noise Performance
- High Output Power: +23 dBm Typical
- High Dynamic Range: IP3 = +36 dBm Typ.
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

16

1.5

Legend -

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	14.5	13.0 Min.
Power @ 1 dB Comp. (dBm)	+23	+20 Min.
Reverse Isolation (dB)	- 18	- 15 Max.
VSWR In Out	<1.4:1 <1.2:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.6	6.0 Max.
Power Vdc m A	+15 88	+15 95 Max.

Note: Care should always be taken to effectively ground the case of each unit.

Gain (dB)

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point +	<b>-56</b>	(Typ
Second Order Two Tone Intercept Point +	<del>-</del> 50	(Typ
Third Order Two Tone Intercept Point +	⊦36	(Typ

Third Order two tone intercept For	iii +30 (iyp
Maximum Ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 %
DC Voltage	+ 13 Volt
Continuous RF Input Power	+ 13 dBr
Short Term RF Input Power	50 mW (1 Minute Max
Maximum Peak Power	0.5 Watt (3 µsec Max

### Guaranteed Phase Noise Performance (dBc/Hz) ★

Frequency	Typical	Guarantee (min.)
100 Hz	-156	-152
1 KHz	-170	-168
10 KHz	-175	-172
100 KHz	-175	-172
1 MHz	-175	-172

-130

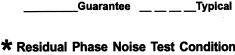
15 0 - 10 14 - 20 13 - 30 500 MHz -160 12 1 dB Comp. (dBm) Noise Figure (dB) +24 7 6 +23 -180 5 +22 -190 4 +21 3 +20 Stop 500 MHz Stop 500 MHz Input VSWR **Output VSWR** 2.0 2.0

1.5

\_\_\_ + 85 °C ----- -55 °C

Stop 500 MHz 1.0

+ 10



Phase Noise (dBc/Hz)

- Carrier Frequency: 500 MHz ■ Power Output +23 dBm
- Power Output +23 dBr ■ Temperature: 25 °C
- Agilent ES5500 System

### **Linear S-Parameters**

Stop 500 MHz

Typical Performance Data

Reverse Isolation (dB)

FREQ.	Mag	S11	;	S21	S	S12		S22
MHz		Deg	Mag	Deg	Mag	Deg	Mag	Deg
5 100 200 300 400 500	.23 .13 .40 .58 .10	-41 80 24 -31 -91 -137	5.86 5.46 5.51 5.50 5.53 5.45	-163 159 137 114 90 64	.08 .11 .12 .14 .15 .17	19 3 3 2 -1 -9	.27 .05 .04 .04 .08	86 23 23 45 71 66



+ 25 °C

Available as:

s: TM6510, 4 Pin TO-8 (T4)

TN6510, 4 Pin Surface Mount (SM3)

FP6510, 4 Pin Flatpack (FP4)

BX6510, Connectorized Housing (H1)

### **Features**

■ Low Noise Figure: 2.5 dB Typical

■ High Gain: 16.5 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	16.5	15.5 Min.
Power @ 1 dB Comp. (dBm)	+3	+1.0 Min.
Reverse Isolation (dB)	- 20	- 18 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 10	+15 12 Max.

# Typical Intermodulation Performance at 25 ° C

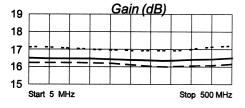
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	+17 (Typ.)
Third Order Two Tone Intercept Point	+15 (Typ.)

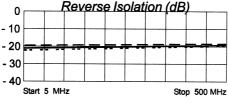
### **Maximum Ratings**

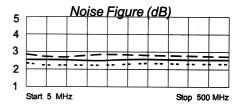
waxiiiuiii Natiiiys	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

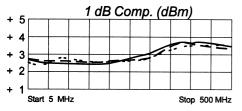
Note: Care should always be taken to effectively ground the case of each unit.

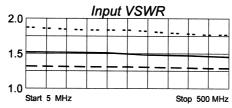
## **Typical Performance Data**

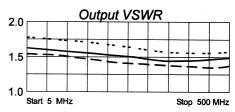












.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.21	-175	6.85	-177	.09	5	.21	-173
50	.20	172	6.81	171	.09	1	.20	171
100	.20	163	6.81	161	.09	Ó	.20	162
200	.20	146	6.74	141	.10	-1	.19	145
300	.19	131	6.69	123	.10	-2	.17	132
400	.19	116	6.75	104	.10	-5	.17	124
500	.19	103	6.88	84	.11	<b>-</b> 7	.18	119
600	.19	92	7.16	62	.11	-11	.23	109



Available as: TM6511, 4 Pin TO-8 (T4)

TN6511, 4 Pin Surface Mount (SM3)

FP6511, 4 Pin Flatpack (FP4) BX6511, Connectorized Housing (H1)

### **Features**

Low Noise Figure: 2.5 dB Typical
 High Gain: 16.5 dB Typical
 Operating Temp. - 55 °C to +85 °C
 Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 500 MHz	5 - 500 MHz		
Gain (dB)	16.5	15.5 Min.		
Power @ 1 dB Comp. (dBm)	+2	+1.0 Min.		
Reverse Isolation (dB)	- 20	- 18 Max.		
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	2.5	3.0 Max.		
Power Vdc mA	+15 10	+15 12 Max.		

# Typical Intermodulation Performance at 25 ° C

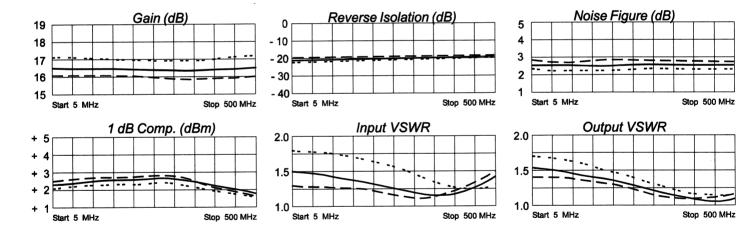
Second Order Harmonic Intercept Point	+21 (Typ.)
Second Order Two Tone Intercept Point	+16 (Typ.)
Third Order Two Tone Intercept Point	+14 (Typ.)

### **Maximum Ratings**

Maximumitatings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	5	M1		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.21	-175	6.85	-177	.09	5	.21	-173
50	.20	172	6.81	171	.09	1	.20	171
100	.20	163	6.81	161	.09	0	.20	162
200	.20	146	6.74	141	.10	-1	.19	145
300	.19	131	6.69	123	.10	-2	.17	132
400	.19	116	6.75	104	.10	-5	.17	124
500	.19	103	6.88	84	.11	-7	.18	119
600	.19	92	7.16	62	.11	-11	.23	109



Available as: TM6512, 4 Pin TO-8 (T4)

TN6512, 4 Pin Surface Mount (SM3) FP6512, 4 Pin Flatpack (FP4)

BX6512, Connectorized Housing (H1)

### **Features**

High Gain: 21 dB Typical

■ Low Noise Figure: 2.5 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	21	19.0 Min.
Power @ 1 dB Comp. (dBm)	+10.0	+8.0 Min.
Reverse Isolation (dB)	- 22	- 20 Max.
VSWR In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 23	+15 26 Max.

## Typical Intermodulation Performance at 25 ° C

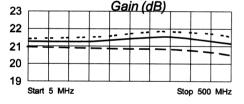
Second Order Harmonic Intercept Point	+33	(Typ.)
Second Order Two Tone Intercept Point	+27	(Typ.)
Third Order Two Tone Intercept Point	+21	(Tvp.)

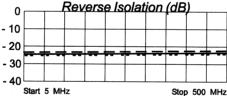
### **Maximum Ratings**

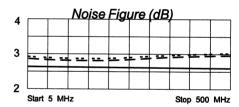
maximam radingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

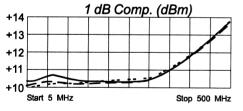
Note: Care should always be taken to effectively ground the case of each unit.

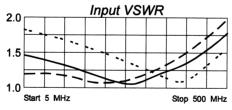
## **Typical Performance Data**

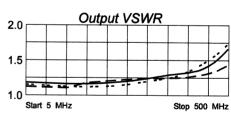












### Linear S-Parameters

FREQ MHz Mag	S11	S21	S12	S22	
	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.17 -152	11.53 -173	.06 8	.13 142	
10	.17 -166	11.69 -178	.06 6	.09 147	
50	.16 174	11.77 168	.06 - 0	.06 154	
100	.14 164	11.78 154	.06 - 1	.05 138	
200	.08 154	11.83 127	.06 - 2	.02 92	
300	.04 -139	11.92 99	.06 - 5	.03 - 9	
400	.16 -112	11.99 67	.07 - 9	.05 4	
500	.32 -133	11.51 31	.08 - 18	19 6	



Available as:

TM6513, 4 Pin TO-8 (T4)

TN6513, 4 Pin Surface Mount (SM3) FP6513, 4 Pin Flatpack (FP4)

BX6513, Connectorized Housing (H1)

### **Features**

- 24 Volt Operation
- Medium Output Power: +16.5 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	17	15.5 Min.
Power @ 1 dB Comp. (dBm)	+16.5	+15.0 Min.
Reverse Isolation (dB)	- 19	- 18 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.75	5.0 Max.
Power Vdc mA	+24 50	+24 53 Max.

Typical Intermodulation Performance at 25 ° C

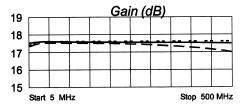
Second Order Harmonic Intercept Point	+47 (Typ.)
Second Order Two Tone Intercept Point	+41 (Typ.)
Third Order Two Tone Intercept Point	+29 (Typ.)

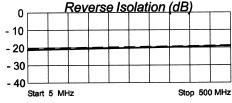
**Maximum Ratings** 

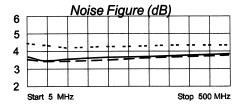
1110021111011111100011130	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 26 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

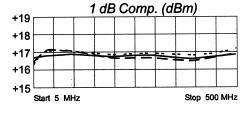
Note: Care should always be taken to effectively ground the case of each unit.

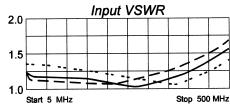
# **Typical Performance Data**

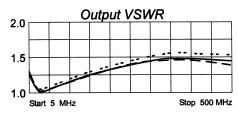












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.10 -126	7.62 -172	.08 10	.10 113
50	.08 178	7.74 169	.08 -0	.03 - <del>9</del> 8
100	.07 166	7.71 156	.08 -3	.07 -106
200	.04 154	7.63 132	.08 -5	.14 -126
300	.02 -124	7.59 107	.09 -8	.19 -150
400	.10 -108	7.54 81	.10 -13	.20 -178
500	.21 -128	7.42 54	.11 <b>-20</b>	.17 135



Available as: TM6514, 4 Pin TO-8 (T4)

TN6514, 4 Pin Surface Mount (SM3)

FP6514, 4 Pin Flatpack (FP4)

BX6514, Connectorized Housing (H1)

### **Features**

- Low Noise Figure: <2.0 dB Typical
- Low Supply Current: 8 mA Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	30-200 MHz	30 -200 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	> -2	-3.0 Min.
Reverse Isolation (dB)	- 20	- 18.5 Max.
VSWR In Out	<1.4:1 <1.2:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.0	3.0 Max.
Power Vdc mA	+15 8	+15 9 Max.

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+17 (Typ.)
Second Order Two Tone Intercept Point	+11 (Typ.)
Third Order Two Tone Intercept Point	+11 (Tvp.)

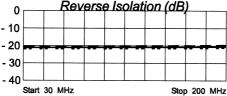
### **Maximum Ratings**

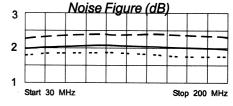
•	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	
	(3 µsec Max.)

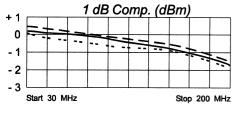
Note: Care should always be taken to effectively ground the case of each unit.

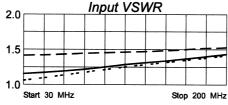
## **Typical Performance Data**

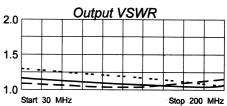












\_egend ------ + 25 °C --- + 85 °C ---- - -55 °C

### Linear S-Parameters

FREQ. MHz	S Mag	511 Deg	: Mag	S21 Deg	: Mag	S12 Deg	: Mag	S22 Deg
10	.07	171	6.82	179	.10	2	.09	-179
30 50	.07	147	6.80	174	.10	ō	.09	174
50	.08	135	6.80	169	.09	- 1	.08	170
100	.11	100	6.75	158	.10	- 4	.06	156
150	.14	75	6.64	147	.10	- 7	.04	154
200	.18	56	6.50	136	.10	- 8	.01	-120
300	.24	24	6.21	114	.10	- 16	.09	- 74



Available as: TM651

TM6515, 4 Pin TO-8 (T4)

TN6515, 4 Pin Surface Mount (SM3) FP6515, 4 Pin Flatpack (FP4)

BX6515, Connectorized Housing (H1)

### **Features**

- Medium Gain: +12.5 dB Typical
- Medium Output Power: +16.5 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	12.5	11.0 Min.
Power @ 1 dB Comp. (dBm)	+16.5	+15.0 Min.
Reverse Isolation (dB)	- 16	- 15 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	5.5 Max.
Power Vdc m A	+15 50	+15 55 Max.
Note: Care should always	be taken to effectively gr	ound the case of each unit.

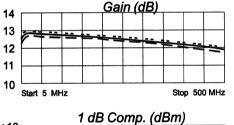
# Typical Intermodulation Performance at 25 ° C

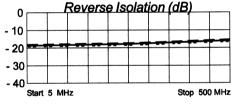
Second Order Harmonic Intercept Point	+50 (Typ.)
Second Order Two Tone Intercept Point	+43 (Typ.)
Third Order Two Tone Intercept Point	+31 (Typ.)

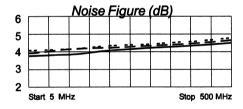
### **Maximum Ratings**

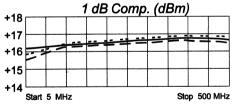
Maximanina	
Ambient Operating Tem	perature55°C to + 100 °C
	62°C to + 125 °C
	+ 125 °C
DC Voltage	+ 18 Volts
	wer + 13 dBm
Short Term RF Input Po	wer 50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

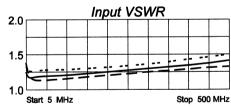
# **Typical Performance Data**

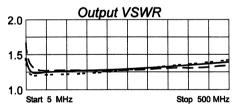












Leaend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11- Mag D	eg	: Mag	S21 Deg		512 Deg	 Mag	522 Deg
5	.11 -1	26	4.26	-172	.13	9	.18	144
50	.09 1	71	4.37	173	.14	- 0	.11	175
100		50	4.34	164	.14	- 2	.11	-178
200		25	4.26	147	.14	- 6	.12	-172
300		06	4.17	131	.14	- 9	.14	-170
400	.15	89	4.03	115	.15	- 13	.15	-174
500	.17	78	3.92	100	.15	- 18	.17	179
600	.18	68	3.79	85	.16	- 23	.18	171



Available as: TM6516, 4 Pin TO-8 (T4)

TN6516, 4 Pin Surface Mount (SM3) FP6516, 4 Pin Flatpack (FP4) BX6516,Connectorized Housing (H1)

#### **Features**

- Medium Gain: +14.5 dB Typical
- Medium Output Power: +14 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	14.5	13.5 Min.
Power @ 1 dB Comp. (dBm)	+14	+12.0 Min.
Reverse Isolation (dB)	- 17.5	- 17 Max.
VSWR In Out	<1.4:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	4.5 Max.
Power Vdc mA	+15 35	+15 38 Max.

# Typical Intermodulation Performance at 25 ° C

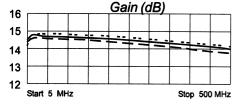
<b>J</b> 1	
Second Order Harmonic Intercept Point	+44 (Typ.)
Second Order Two Tone Intercept Point	+38 (Typ.)
Third Order Two Tone Intercept Point	+28 (Typ.)

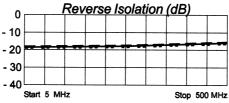
### **Maximum Ratings**

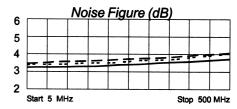
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

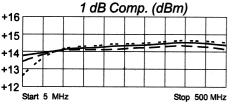
Note: Care should always be taken to effectively ground the case of each unit.

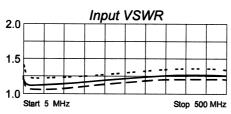
## **Typical Performance Data**

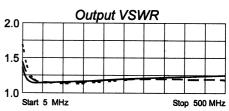












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.11 -101	5.26 -170	.11 11	.17 137
50	.06 168	5.45 172	.12 0	.07 167
100	.06 135	5.44 162	.12 - 2	.07 179
200	.09 103	5.34 144	.12 - 5	.07 -175
300	.11 84	5.22 126	.12 - 8	.09 -172
<b>40</b> 0	.12 71	5.09 109	.13 - 12	.10 178
500	.11 65	4.97 91	.14 - 17	.11 166
600	.10 68	4.83 73	.15 -23	.10 142



Available as: TM6517, 4 Pin TO-8 (T4)

TN6517, 4 Pin Surface Mount (SM3) FP6517, 4 Pin Flatpack (FP4) BX6517,Connectorized Housing (H1)

### **Features**

■ High Gain: 22.5 dB Gain Typical

Low Noise Figure: <2.4 dB Typical</p>

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	22.5	21.0 Min.
Power @ 1 dB Comp. (dBm)	+10	+8.0 Min.
Reverse Isolation (dB)	- 24	- 21 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.4	3.0 Max.
Power Vdc mA	+15 22	+15 25 Max.

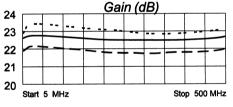
# Typical Intermodulation Performance at 25 ° C

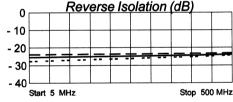
Second Order Harmonic Intercept Point	+32 (Typ.)
Second Order Two Tone Intercept Point	+26 (Typ.)
Third Order Two Tone Intercept Point	+22 (Typ.)

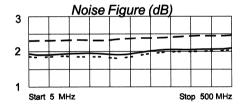
### **Maximum Ratings**

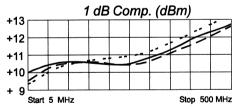
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

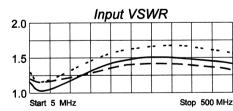
# **Typical Performance Data**

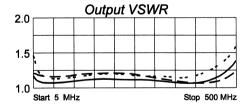












\_eaend ------ + 25 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11		S11S21			S12		S22		
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg		
5	.07	-127	13.16	-174	.05	10	.09	112		
50	.06	136	13.33	165	.05	-4	.02	29		
100	.08	96	13.17	150	.05	-8	.03	-19		
200	.12	38	12.80	119	.05	-19	.06	-44		
300	.15	. <del>.0</del>	12.33	89	.06	-35	.09	-54		
400	.14	-52	12.16	58	.06	<del>-4</del> 8	.13	-51		
500	.09	-126	12.35	24	.06	-69	.22	-38		



Available as: TM6518, 4 Pin TO-8 (T4)

TN6518, 4 Pin Surface Mount (SM3) FP6518, 4 Pin Flatpack (FP4) BX6518, Connectorized Housing (H1)

### **Features**

■ High Power: +25 dBm Typical 1 dB Comp.

■ Noise Figure: 5.25 dB Typical
■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	14	12.5 Min.
Power @ 1 dB Comp. (dBm)	+25	+22.5 Min.
Reverse Isolation (dB)	- 16.5	- 15.5 Max.
VSWR In Out	<1.5:1 <1.3:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.25	6.5 Max.
Power Vdc mA	+15 125	+15 135 Max.

# Typical Intermodulation Performance at 25 ° C

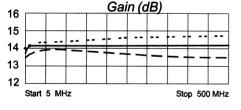
Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+33 (Typ.)

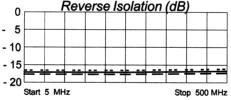
### **Maximum Ratings**

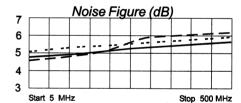
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

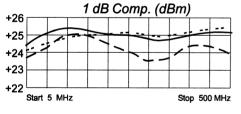
Note: Care should always be taken to effectively ground the case of each unit.

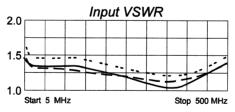
## **Typical Performance Data**

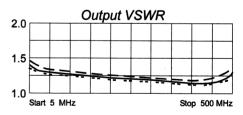












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		\$22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.17	-135	4.89	-169	.11	14	.24	159
50	.14	165	5.04	169	.12	0	.18	166
100	.14	140	5.02	156	.12	-1	.17	160
200	.14	101	5.03	132	.12	- <del>7</del>	.15	144
300	.15	60	5.06	107	.13	-12	.14	136
400	.16	27	5.08	80	.14	-19	.13	140
500	.18		5.11	52	.15	-28	.19	143



Available as: TM6519, 4 Pin TO-8 (T4)

TN6519, 4 Pin Surface Mount (SM3) FP6519, 4 Pin Flatpack (FP4) BX6519, Connectorized Housing (H1) PN6519, Reduced Size Surface Mount (SM11)

### **Features**

- High Output Power: +19 dBm Typical
- High Third Order Intercept: > +33 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	14.3	12.0 Min.
Power @ 1 dB Comp. (dBm)	>+19	+17.0 Min.
Reverse Isolation (dB)	- 16	-15.0 Max.
VSWR In Out	<1.5:1 <1.6:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<5.5	6.0 Max.
Power Vdc mA	+15 70	+15 73 Max.

# Typical Intermodulation Performance at 25 ° C

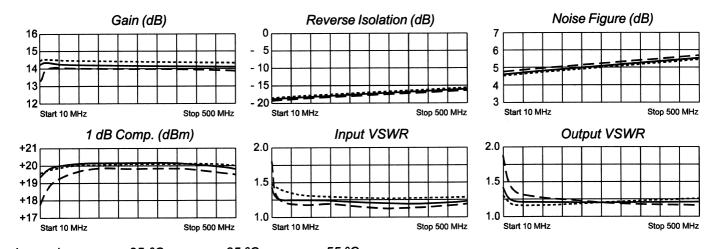
Second Order Harmonic Intercept Point	+45	(Typ.)
Second Order Two Tone Intercept Point	+40	(Typ.)
Third Order Two Tone Intercept Point	+34	(Tvp.)

### **Maximum Ratings**

	axiiiiaiii i tatii igo	
An	nbient Operating Temperature	55°C to + 100 °C
Sto	orage Temperature	62°C to + 125 °C
Ca	se Temperature	+ 125 °C
DC	CVoltage	+ 18Volts
Co	ontinuous RF Input Power	+ 13 dBm
Sh	ort Term RF Input Power	50 Milliwatts
		(1 Minute Max.)
Ma	aximum Peak Power	0.2 Watt
		(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### **Linear S-Parameters**

FREQ S11		S11		21	S12		<b>\$22</b> -	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
5	.17	-109	5.21	-164	.11	18	.22	135
10	.12	-135	5.33	-174	.11	9	.13	139
50	.09	-179	5.39	172	.12	1	.09	160
100	.09	168	5.39	162	.12	- 1	.08	156
200	.07	119	5.40	142	.12	- 4	.07	150
300	.06	73	5.39	122	.13	- 9	.07	138
400	.07	17	5.38	102	.14	- 15	.07	133
500	08	- 30	5.34	82	.15	- 22	.08	121



Available as: TM6520, 4 Pin TO-8 (T4)

TN6520, 4 Pin Surface Mount (SM3) FP6520, 4 Pin Flatpack (FP4) BX6520,Connectorized Housing (H1)

### **Features**

- High Efficiency: 13 dBm Typ. @ 170 mW DC
- Low Noise Figure: <3.5 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	14.5	13.5 Min.
Power @ 1 dB Comp. (dBm)	+13	+11.5 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	<1.3:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.5 Max.
Power Vdc mA	+5 33	+5 36 Max.

### Typical Intermodulation Performance at 25 ° C

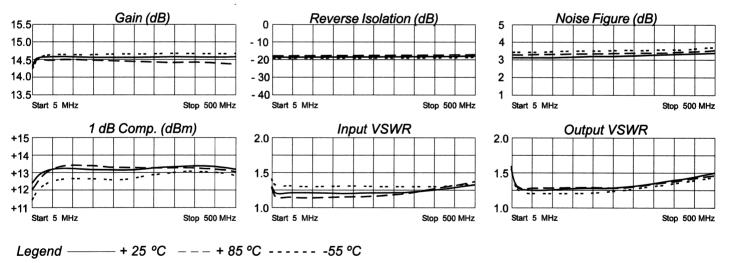
<b>9</b> •	
Second Order Harmonic Intercept Point	+40 (Typ.)
Second Order Two Tone Intercept Point	+34 (Typ.)
Third Order Two Tone Intercept Point	+27 (Typ.)

### **Maximum Ratings**

55°C to + 100 °C
62°C to + 125 °C
+ 125 ℃
+ 10 Volts
+ 13 dBm
50 Milliwatts
(1 Minute Max.)
0.5 Watt
(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.15 - 74	5.43 -167	.10 14	.20 124
50	.06 -160	5.52 171	.11 0	.05 151
100	.06 -162	5.51 161	.11 - 3	.05 152
200	.05 -149	5.49 140	.11 - 8	.03 158
300	.07 -128	5.49 120	.12 - 12	.03 171
400	.10 -123	5.47 99	.13 - 19	.03 176
500	.14 -130	5.41 78	.14 - 27	.04 -179



Available as:

TM6521, 4 Pin TO-8 (T4)

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point ...... +36 (Typ.)

Second Order Two Tone Intercept Point ...... +30 (Typ.)

Third Order Two Tone Intercept Point ...... +22 (Typ.)

TN6521, 4 Pin Surface Mount (SM3) FP6521, 4 Pin Flatpack (FP4) BX6521, Connectorized Housing (H1)

### **Features**

- High Gain: +30 dB Typical
- Low Noise Figure: <3.0 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTI	C TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	30	28 Min.
Power @ 1 dB Comp. (dBm)	+9	+7 Min.
Reverse Isolation (dB)	- 34	- 33 Max.
VSWR In Out	<1.25:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	4.0 Max.
Power Vdc mA	+15 36	+15 40 Max.

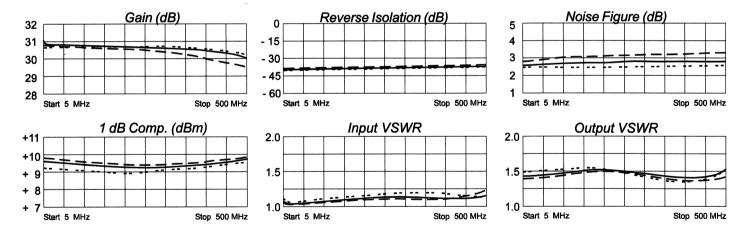
**Maximum Ratings** 

55°C to + 100 °C
62°C to + 125 °C
+ 125 ℃
+ 18 Volts
+ 13 dBm
50 Milliwatts
(1 Minute Max.)
0.5 Watt

(3 usec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

### Linear S-Parameters

FREQ. MHz	: Mag	S11 Deg	S Mag	S21	S Mag	S12 Deg	: Mag	S22 Deg
IVIITZ	iviay	Deg	iviay	Deg	iviag	Deg	iviay	DOJ
5	.03	-113	35.56	3	.01	5	.18	-172
50	.02	-150	34.77	- 24	.01	0	.19	-176
100	.03	-161	34.64	- 48	.01	5	.20	-174
200	.05	160	34.41	- 96	.01	- 3	.21	-179
300	.06	112	34.10	-146	.01	- 5	.19	174
400	.06	40	33.10	162	.01	- 7	.17	177
500	.08	- 65	31.40	106	.02	- 22	.20	160
600	.17	-147	26.97	42	.02	- 37	.26	78



Available as: TM6523, 4 Pin TO-8 (T4)

TN6523, 4 Pin Surface Mount (SM3) FP6523, 4 Pin Flatpack (FP4) BX6523,Connectorized Housing (H1)

### **Features**

High Gain: 25.5 dB Typical

■ Medium Output Power: +16 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	25.5	23.0 Min.
Power @ 1 dB Comp. (dBm)	+16	+14.0 Min.
Reverse Isolation (dB)	- 33	- 32 Max.
VSWR In Out	<1.3:1 <1.3:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.5	7.0 Max.
Power Vdc mA	+15 75	+15 80 Max.

## Typical Intermodulation Performance at 25 ° C

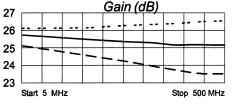
Second Order Harmonic Intercept Point	+40 (Typ.)
Second Order Two Tone Intercept Point	+35 (Typ.)
Third Order Two Tone Intercept Point	+26 (Typ.)

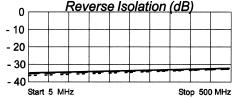
### **Maximum Ratings**

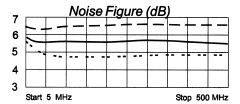
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

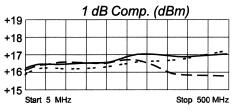
Note: Care should always be taken to effectively ground the case of each unit.

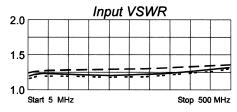
## **Typical Performance Data**

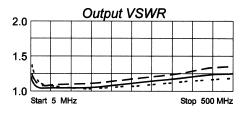












egend ------ + 25 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.		S11		521		512		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.10	14	19.48	9	.02	12	.10	103
50	.11	-1	19.27	-17	.02	-0	.02	66
100	.10	-4	19.09	-35	.02	1	.02	59
200	.11	-2	18.74	-70	.02	5	.04	64
300	.11	-2	18.47	-104	.02	1	.07	47
400	.13	-6	18.31	-139	.02	Ó	.09	22
500	.14	-19	18.39	-173	.02	-2	.11	-11



Available as: TM6524, 4 Pin TO-8 (T4)

TN6524, 4 Pin Surface Mount (SM3) FP6524, 4 Pin Flatpack (FP4) BX6524,Connectorized Housing (H1)

### **Features**

33

High Gain: 31 dB Typical

Medium Output Power: +15 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTI	C TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	31	29.0 Min.
Power @ 1 dB Comp. (dBm)	+15	+14.0 Min.
Reverse Isolation (dB)	- 36	- 35 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.0 Max.
Power Vdc mA	+15 70	+15 75 Max.

Note: Care should always be taken to effectively ground the case of each unit.

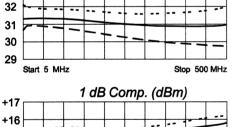
# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+36 (Typ.)
Second Order Two Tone Intercept Point	+30 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

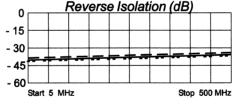
### **Maximum Ratings**

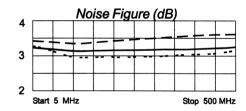
<b>Ambient Operating Temperature</b>	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

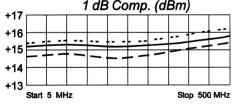
# **Typical Performance Data**

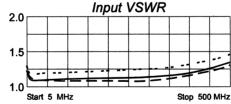


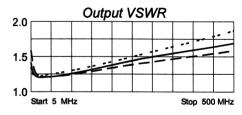
Gain (dB)











Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11 <u>-</u>	S21	S1 <u>2</u>	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.09 140	36.70 11	.01 16	.17 134
50	.03 172	36.52 -17	.01 4	.09 176
100	.04 -180	36.06 -36	.01 5	.10 180
200	.04 163	34.99 -71	.01 2	.15 166
300	.04 125	34.61 -105	.01 - 3	.21 142
400	.07 58	34.92 -141	.01 - 6	.26 111
500	.13 8	35.06 -171	.01 <b>-2</b> 0	.32 77
600	.22 - 28	34.94 143	.01 -30	.34 41



Available as: TM6526, 4 Pin TO-8 (T4)

> TN6526, 4 Pin Surface Mount (SM3) FP6526, 4 Pin Flatpack (FP4)

### BX6526, Connectorized Housing (H1)

### **Features**

High Gain: 28 dB Typical

■ High Output Power: +20.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	28	26.0 Min.
Power @ 1 dB Comp. (dBm)	+20.5	+18.5 Min.
Reverse Isolation (dB)	- 38	- 35 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.75	4.0 Max.
Power Vdc mA	+15 93	+15 96 Max.

# Typical Intermodulation Performance at 25 ° C

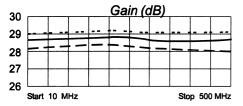
Second Order Harmonic Intercept Point	+56 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+34 (Typ.)

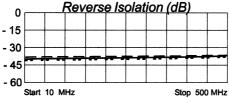
### **Maximum Ratings**

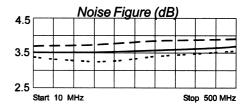
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

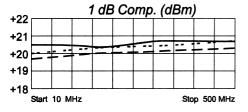
Note: Care should always be taken to effectively ground the case of each unit.

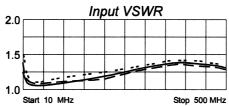
## **Typical Performance Data**

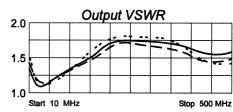












--- + 85 °C ---- -55 °C – + 25 °C

#### **Linear S-Parameters**

FREQ.	S11	S21		S12	8	322
MHz	Mag Deg	Mag De	g Mag	Deg	Mag	Deg
10	.07 95	26.94	9 .01	18	.13	128
50	.03 90	27.31 - 1	8 .01	5	.06	-155
100	.04 90	27.35 - 4	1 .01	- 12	.12	-142
200	.09 84	27.23 - 8	4 .01	- 10	.23	-161
300	.15 55	26.84 -12		- 28	.25	165
400	.16 27	26.60 -17		- 60	.24	128
500	.12 - 3	27.36 13		- 45	24	76



Available as: TM6533. 4 Pin TO-8 (T4)

> TN6533, 4 Pin Surface Mount (SM3) FP6533, 4 Pin Flatpack (FP4)

BX6533, Connectorized Housing (H1)

### **Features**

High Gain: 16.5 dB Typical

■ Medium Output Power: +17 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	+17	+15.0 Min.
Reverse Isolation (dB)	- 18.5	- 17 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	5.5 Max.
Power Vdc mA	+15 50	+15 55 Max.

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+48	(Typ
Second Order Two Tone Intercept Point	+42	(Typ
Third Order Two Tone Intercept Point	+32	(Typ

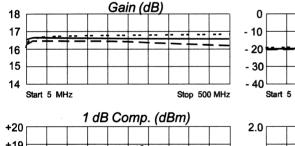
### **Maximum Ratings**

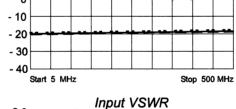
maximam ratings	
Ambient Operating Temperature	55°C to + 100°
Storage Temperature	62°C to + 125°
Case Temperature	+ 125 '
DC Voltage	+ 18 Vo
Continuous RF Input Power	+ 13 dB
Short Term RF Input Power	50 Milliwa
	(1 Minute Ma:
Maximum Peak Power	
	(3 µsec Ma

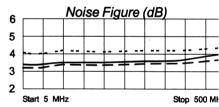
Note: Care should always be taken to effectively ground the case of each unit.

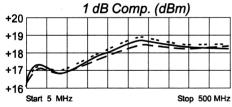
# **Typical Performance Data**

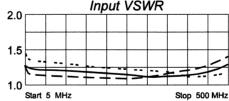
Reverse Isolation (dB)

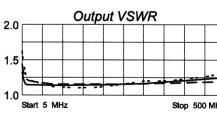












#### Linear S-Parameters

FREQ.	S	S11		S21	;	S12		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.13	-121	6.73	-170	.09	11	.15	136
50	.09	-180	6.90	171	.10	-0	.06	161
100	.08	170	6.88	159	.09	-1	.05	170
200	.07	161	6.85	138	.10	-2	.05	171
300	.05	170	6.79	117	.10	-4	.07	162
400	.07	-164	6.79	94	.11	-8	.09	148
500	.13	-158	6.71	70	.12	-12	.12	122



Available as: RN6535, 4 Pin Surface Mount (SM19)

BR6535, Connectorized Housing (H2)

### **Features**

■ High Gain: 32.5 dB Typical
■ Low Noise: 2 dB Typical
■ High Power: +22 dBm Typical

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 400 MHz	10 - 400 MHz
Gain (dB)	32.5	30.0 Min.
Power @ 1 dB Comp. (dBm)	+22	+20.0 Min.
Reverse Isolation (dB)	- 36	- 35 Max.
VSWR In Out	1.75:1 1.5:1	2.5:1 Max. 2.5:1 Max.
Noise figure (dB)	1.8	3.0 Max.
Power Vdc mA	+15 90	+15 100 Max.

# Typical Intermodulation Performance at 25 ° C

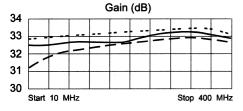
Second Order Harmonic Intercept Point	+54 (Typ.)
Second Order Two Tone Intercept Point	+48 (Typ.)
Third Order Two Tone Intercept Point	+37 (Typ.)

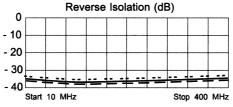
### **Maximum Ratings**

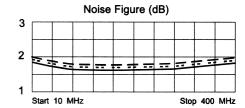
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	3 μsec Max.)

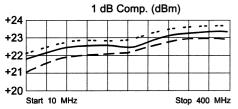
Note: Care should always be taken to effectively ground the case of each unit.

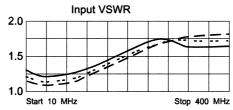
## **Typical Performance Data**

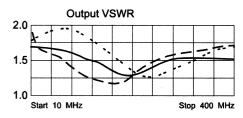












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11 <u>-</u>		8	321		S12		-S22
MHz	Mag D	eg	Mag	Deg	Mag	Deg	Mag	Deg
10	.11 -1	17	42.18	12	.01	13	.26	5
50	.07 -1	54	42.28	-22	.01	-18	.23	-23
100	.06 -1	36	42.36	-49	.01	-51	.17	-51
200	.18 -1	34	42.67	-101	.01	-121	.01	-21
300	.24 -1	67	42.80	-156	.01	-164	.14	-3
400	.25 -1	78	40.98	142	.02	139	.17	-123



Available as: TM6543, 4 Pin TO-8 (T4)

TN6543, 4 Pin Surface Mount (SM3) FP6543, 4 Pin Flatpack (FP4) BX6543, Connectorized Housing (H1) PN6543, Reduced Size Surface Mount (SM11)

### **Features**

■ Low Noise Figure: <2.5 dB Typical

■ Medium Output Power: +11 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	11	10.0 Min.
Power @ 1 dB Comp. (dBm)	+11	+9.0 Min.
Reverse Isolation (dB)	- 13.5	- 13 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.5	3.0 Max.
Power Vdc mA	+15 25	+15 27 Max.

# Typical Intermodulation Performance at 25 ° C

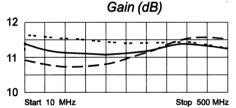
Second Order Harmonic Intercept Point	+41	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+24	(Typ.)

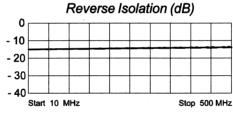
### **Maximum Ratings**

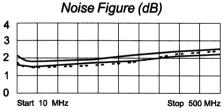
Ambient Operating Temperature.	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	50 Watt
	(3 μsec Max.)

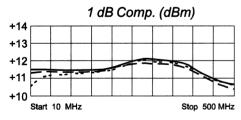
Note: Care should always be taken to effectively ground the case of each unit.

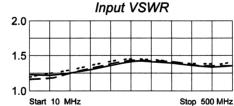
### **Typical Performance Data**

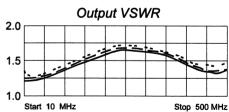












Legend ----- + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	: Mag	S11 Deg	: Mag	521 Deg	( Mag	S12 Deg	S Mag	522 Deg
10	.11	-15	3.73	-176	.18	-177	.10	-162
50	.10	5	3.65	166	.18	163	.11	132
100	.11	21	3.61	151	.18	145	.15	88
200	.18	23	3.59	123	.18	111	.24	30
300	.19	10	3.62	95	.18	79	.25	-22
400	.17	6	3.72	62	.19	49	.18	-80
500	.17	23	3.65	25	.19	14	.16	151



Available as: TM6544, 4 Pin TO-8 (T4)

TN6544, 4 Pin Surface Mount (SM3) FP6544, 4 Pin Flatpack (FP4) BX6544.Connectorized Housing (H1)

### **Features**

Low Noise: 2 dB Typ.

High Dynamic Range IP3 = +32 dBm Typ. Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	12	10.5 Min.
Power @ 1 dB Comp. (dBm)	+15	+13.0 Min.
Reverse Isolation (dB)	- 15.5	- 14.5 <b>Ma</b> x.
VSWR In Out	<1.35:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.5 Max.
Power Vdc mA	+15 35	+15 38 Max.

### Typical Intermodulation Performance at 25 ° C

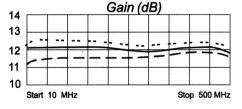
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+32 (Typ.)

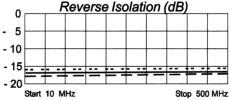
### Maximum Ratings

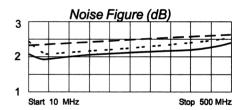
Maximumitatings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
· · · · · · · · · · · · · · · · · · ·	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

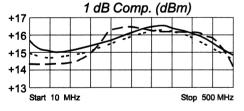
Note: Care should always be taken to effectively ground the case of each unit.

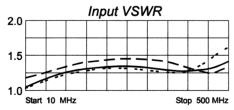
## **Typical Performance Data**

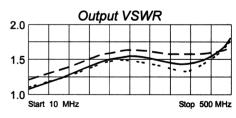












#### Linear S-Parameters

FREQ.	S11		\$11\$21		S21	S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg	
10	.01	-33	4.01	-174	.16	-174	.01	-7	
50	.04	63	4.03	168	.16	168	.06	70	
100	.09	51	4.00	153	.16	153	.12	66	
200	.15	14	3.96	126	.16	126	.20	50	
300	.15	-30	3.95	99	.16	99	.21	40	
400	.11	-103	4.02	69	.16	71	.19	52	
500	18	150	3.93	34	16	40	28	78	



Available as: TM6545, 4 Pin TO-8 (T4)

TN6545, 4 Pin Surface Mount (SM3) FP6545, 4 Pin Flatpack (FP4) BX6545, Connectorized Housing (H1)

### **Features**

- High Dynamic Range
- High Output Power: +20 dBm Typical■ Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+20.5	+18.0 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.25:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	5.5 Max.
Power Vdc mA	+15 60	+15 65 Max.

# Typical Intermodulation Performance at 25 ° C

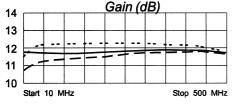
Second Order Harmonic Intercept Point	+54 (Typ.)
Second Order Two Tone Intercept Point	+48 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

### **Maximum Ratings**

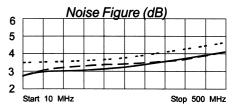
<u> </u>	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

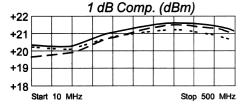
Note: Care should always be taken to effectively ground the case of each unit.

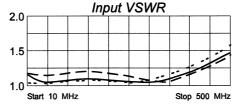
## **Typical Performance Data**

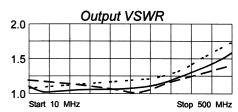












— + 25 °C −−− + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11		S11S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.04	-76	3.93	-174	.16	-174	.03	
50	.04	75	3.89	168	.16	167	.04	64
100	.09	58	3.86	155	.16	153	.08	62
200	.16	21	3.88	130	.16	126	.13	45
300	.18	-23	3.94	104	.17	101	.12	32
400	.17	-87	4.06	76	.17	75	.08	67
500	.22	-169	4.04	44	.18	49	.19	106



Available as:

TM6546, 4 Pin TO-8 (T4)

TN6546-3, 4 Pin Surface Mount (SM3) FP6546-4, 4 Pin Flatpack (FP4) BX6546, Connectorized Housing (H1)

### **Features**

High lp3: > +38 dBm Typical

High Output Power: +25 dBm Typical Operating Temp. - 55 °C to +85 °C

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+38 (Tvp.)

### **Specifications**

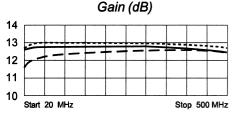
CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 500	20 - 500
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+25	+23 Min.
Reverse Isolation (dB)	- 19	-18 Max.
VSWR In Out	1.8:1 1.7:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.0	6.0 Max.
Power Vdc mA	+15 105	+15 110 Max.

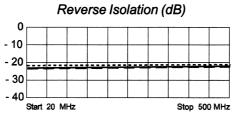
**Maximum Ratings** 

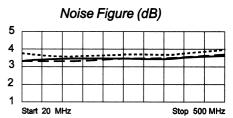
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
·	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

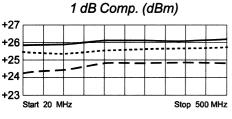
Note: Care should always be taken to effectively ground the case of each unit.

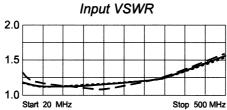
### **Typical Performance Data**

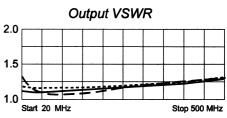












Legend — + 25 °C + 85 °C 55 °C	eaend	- + 25 °C		+ 85 °C		-55 °C	)
--------------------------------	-------	-----------	--	---------	--	--------	---

Linear : Freq	Linear S-Parameters FreqS11		S2	21	S1	2	S2	2
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
=====	=====	======		======		======	======	=====
10	.19	165	3.80	-171	.09	-173	.19	31
50	.17	-179	3.88	163	.09	160	.19	-24
100	.19	-176	3.85	142	.09	139	.22	-60
200	.24	171	3.70	104	.09	98	.27	-111
300	.26	146	3.65	67	.09	62	.30	-153
400	.21	117	3.62	28	.10	27	.26	170
500	.16	96	3.64	-16	.11	-9	.17	132



Available as: TM6547, 4 Pin TO-8 (T4)

TN6547, 4 Pin Surface Mount (SM3) FP6547, 4 Pin Flatpack (FP4) BX6547, Connectorized Housing (H1)

PN6547, Reduced Size Surface Mount (SM11)

### **Features**

■ Low Noise Figure: < 4.0 dB Typical
■ High Output Power: +19 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	12.5	11.0 Min.
Power @ 1 dB Comp. (dBm)	+19	+17.5 Min.
Reverse Isolation (dB)	- 17	- 15 Max.
VSWR In Out	1.75:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	4.5 Max.
Power Vdc mA	+15 55	+15 58 Max.

Typical Intermodulation Performance at 25 ° C

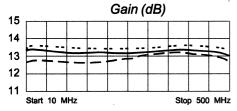
Second Order Harmonic Intercept Point	+54	(Typ.)
Second Order Two Tone Intercept Point	+48	(Typ.)
Third Order Two Tone Intercept Point	÷35	(Typ.)

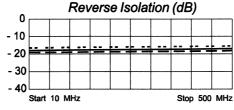
### **Maximum Ratings**

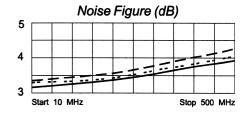
waxiiiiuiii rauiiys	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

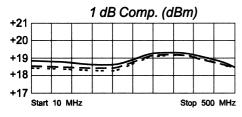
Note: Care should always be taken to effectively ground the case of each unit.

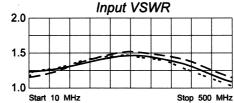
## **Typical Performance Data**

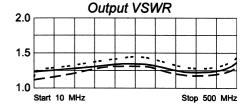












Legend ----- + 25 °C --- + 85 °C ---- -55 °C

#### **Linear S-Parameters**

FREQ.	EQ \$11		S	21	S	12		22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.10	- 13	4.62	-173	.13	-174	.10	- 8
50	.10	7	4.62	169	.13	169	.11	3
100	.12	14	4.57	155	.13	153	.12	5
200	.17	6	4.54	129	.13	127	.15	- 8
300	.18	- 16	4.53	103	.13	102	.14	- 39
400	.13	- 44	4.52	75	.14	76	.12	- 94
500	.04	- 89	4.43	43	.14	50	.17	-170
600	.09	92	4.05	10	.15	22	.31	140



Available as:

TM6554, 4 Pin TO-8 (T4)

TN6554, 4 Pin Surface Mount (SM3)

FP6554, 4 Pin Flatpack (FP4) BX6554, Connectorized Housing (H1)

### **Features**

- High Gain: 27.5 dB Typical
- Medium Output Power: +8 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 400 MHz	5 - 400 MHz
Gain (dB)	27.5	25.0 Min.
Power @ 1 dB Comp. (dBm)	+8	+6.0 Min.
Reverse Isolation (dB)	- 35	- 34 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5	6.0 Max.
Power Vdc mA	+15 33	+15 38 Max.

## Typical Intermodulation Performance at 25 ° C

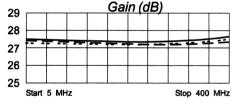
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+19 (Typ.)

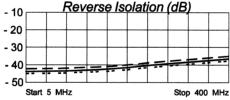
### **Maximum Ratings**

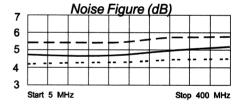
maximum radings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

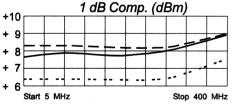
Note: Care should always be taken to effectively ground the case of each unit.

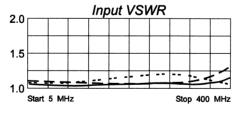
# **Typical Performance Data**

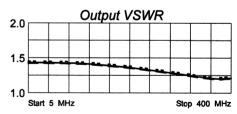












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQS11 MHz Mag Deg				511	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.02 -103	23.84 2	.01 5	.18 -8			
50	.01 -156	23.68 -24	.01 10	.17 -19			
100	.02 <b>-176</b>	23.47 -48	.01 14	.17 -37			
200	.04 145	23.18 - <del>9</del> 6	.01 10	.15 -71			
300	.02 108	23.37 -145	.13 12	.12 -110			
400	.08 <b>-9</b> 6	24.69 164	.15 -10	.09 164			



Available as: TN

TM6555, 4 Pin TO-8 (T4)

TN6555, 4 Pin Surface Mount (SM3) FP6555, 4 Pin Flatpack (FP4)

BX6555, Connectorized Housing (H1)

### **Features**

■ Medium Gain: 14.7 dB Typical

■ Medium Output Power:+11.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 500 MHz	5 - 500 MHz		
Gain (dB)	14.7	13.5 Min.		
Power @ 1 dB Comp. (dBm)	+11.5	+9.0 Min.		
Reverse Isolation (dB)	- 18.5	- 17.5 Max.		
VSWR In Out	1.15:1 1.25:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	4.0	6.5 Max.		
Power Vdc mA	+15 33	+15 36 Max.		
Note: Care should always be taken to effectively ground the case of each unit.				

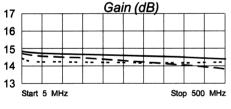
# Typical Intermodulation Performance at 25 ° C

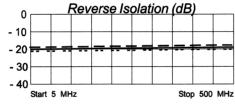
Second Order Harmonic Intercept Point	+40 (Typ.)
Second Order Two Tone Intercept Point	+35 (Typ.)
Third Order Two Tone Intercept Point	+24 (Typ.)

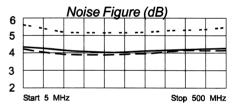
### **Maximum Ratings**

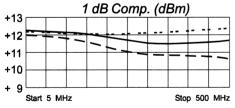
111.65.1111.61111.1	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

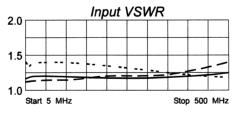
# **Typical Performance Data**

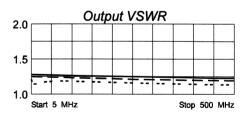












Legend ----- + 25 °C ---- - 55 °C

#### Linear S-Parameters

FREQS11			S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.07	-179	5.56	-176	.10	2	.13	179
50	.08	179	5.49	172	.10	- 0	.13	171
100	.08	172	5.45	164	.10	- 0	.13	162
200	.07	172	5.39	148	.10	- 1	.13	141
300	.07	173	5.35	132	.10	- 2	.12	125
400	.08	-175	5.31	116	.11	- 4	.12	107
500	.11	-166	5.21	99	.11	- 7	.13	89



Available as: TM6556, 4 Pin TO-8 (T4)

TN6556, 4 Pin Surface Mount (SM3) FP6556, 4 Pin Flatpack (FP4) BX6556,Connectorized Housing (H1)

### **Features**

■ High Gain: 26 dB Typical

■ IP<sub>3</sub> = +28 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 400 MHz	5 - 400 MHz
Gain (dB)	26	24.0 Min.
Power @ 1 dB Comp. (dBm)	+14	+12.5 Min.
Reverse Isolation (dB)	- 35	- 34 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	6.5 Max.
Power Vdc mA	+15 66	+15 70 Max.

### Typical Intermodulation Performance at 25 ° C

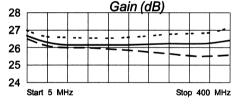
Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+47 (Typ.)
Third Order Two Tone Intercept Point	+28 (Typ.)

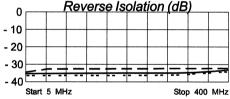
### **Maximum Ratings**

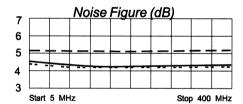
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

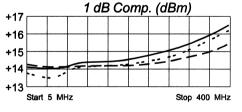
Note: Care should always be taken to effectively ground the case of each unit.

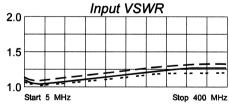
## **Typical Performance Data**

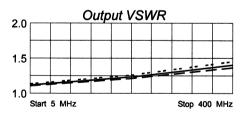












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		\$	521	S	612		S22
MHz	Mag De	g	Mag	Deg	Mag	Deg	Mag	Deg
5 50 100 200 300 400	.04 -5 .02 2 .04 4 .08 3 .10	5 2 1 6	22.01 21.35 21.18 20.92 20.79 21.20	4 - 20 - 40 - 78 -117 -156	.01 .01 .01 .01 .01	2 5 13 12 17	.05 .06 .07 .11 .13	-166 -163 -157 -161 -172 -178



Available as: TM6557, 4 Pin TO-8 (T4)

TN6557, 4 Pin Surface Mount (SM3) FP6557, 4 Pin Flatpack (FP4) BX6557,Connectorized Housing (H1)

### **Features**

■ Gain: 15 dB Typical

Power Output: +15 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	15	13.5 Min.
Power @ 1 dB Comp. (dBm)	+15.5	+14.0 Min.
Reverse Isolation (dB)	- 18	- 16 Max.
VSWR In Out	1.20:1 1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	6.5 Max.
Power Vdc mA	+15 44	+15 48 Max.

# Typical Intermodulation Performance at 25 ° C

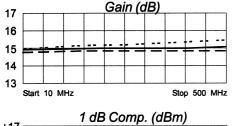
Second Order Harmonic Intercept Point	+45	(Typ.)
Second Order Two Tone Intercept Point	+38	(Typ.)
Third Order Two Tone Intercept Point	+30	(Typ.)

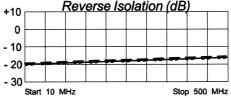
### **Maximum Ratings**

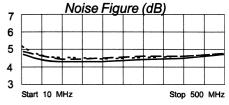
waxiiiuiii Nauiiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

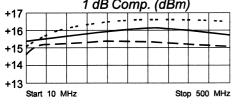
Note: Care should always be taken to effectively ground the case of each unit.

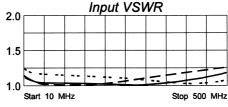
## **Typical Performance Data**

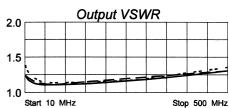












Legend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.		311		321		S1 <u>2</u>		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.08	-85	5.61	-175	.11	8	.11	129
100	.02	166	5.64	165	.11	2	.05	135
200	.01	121	5.61	148	.11	2	.06	107
300	.03	-39	5.58	132	.12	3	.07	89
400	.06	-80	5.62	116	.13	-2	.09	63
500	.11	-96	5.62	99	.14	-2	.12	55



Available as: TM6558, 4 Pin TO-8 (T4)

TN6558, 4 Pin Surface Mount (SM3) FP6558, 4 Pin Flatpack (FP4)

BX6558, Connectorized Housing (H1) PN6558, Reduced Size Surface Mount (SM11)

### **Features**

- High Output Power: +19 dBm Typical
- High Third Order Intercept: +36 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTI	C TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	12	10.5 Min.
Power @ 1 dB Comp. (dBm)	+19.0	+17.5 Min.
Reverse Isolation (dB)	- 16	- 15 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.8	6.5 Max.
Power Vdc mA	+15 65	+15 72 Max.

# Typical Intermodulation Performance at 25 ° C

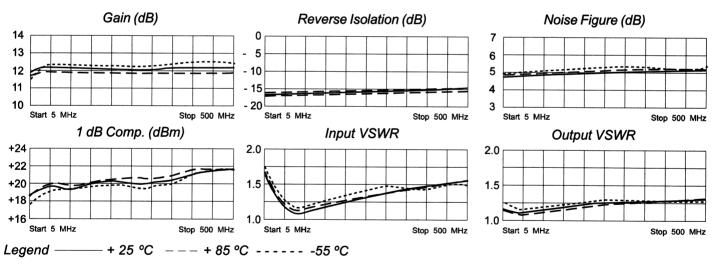
Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+48 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

### **Maximum Ratings**

maximum ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



### Linear S-Parameters

FREQ.	S11	S21	S12	<b>\$22</b>
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.21 - 65	3.93 -160	.14 6	.07 40
50	.04 - 2	4.07 168	.14 - 3	.06 10
100	.07 13	4.05 153	.14 - 7	.07 8
200	.12 - 1	3.99 125	.14 - 15	.09 - 10
300	.17 - 25	3.97 97	.15 - 25	.11 - 40
400	.20 - 48	4.00 68	.15 - 35	.12 - 72
500	.20 - 71	4.05 39	.16 - 45	.14 -114
600	.16 - 87	4.12 7	.17 - 58	.15 -166
700	.09 - 57	4.01 - 30	.19 - 73	.17 130
800	.25 - 28	3.52 - 70	.20 - 94	.22 63



Available as: TM65

TM6559, 4 Pin TO-8 (T4)

TN6559, 4 Pin Surface Mount (SM3)

FP6559, 4 Pin Flatpack (FP4) BX6559, Connectorized Housing (H1)

### **Features**

■ Medium Gain: 11.5 dB Typical

■ High Output Power: +22 dBm Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85	
Frequency		5 - 500 MHz	5 - 500	) MHz
Gain (dB)		11.5	10.0	Min.
Power @ 1 dB Comp. (dBm)		+22	+20.0	Min.
Reverse Isolation (dB)		- 15	- 14	Max.
VSWR II	n Out	<1.5:1 <1.5:1	2.0:1 2.0:1	Max. Max.
Noise figure (dB)		5.5	7.0	Max.
-	dc 1A	+15 88	+15 95	Max.

# Typical Intermodulation Performance at 25 ° C

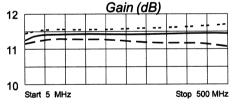
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

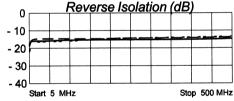
### **Maximum Ratings**

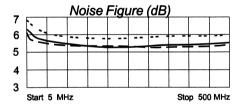
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

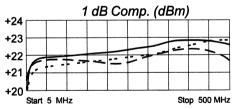
Note: Care should always be taken to effectively ground the case of each unit.

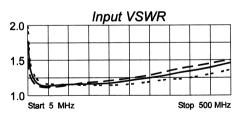
## **Typical Performance Data**

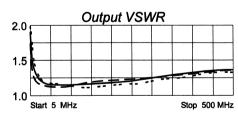












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.31 - 51	3.70 -154	.12 32	.39 113
50	.05 -112	3.65 175	.16 2	.07 110
100	.06 -121	3.66 166	.16 - 1	.07 102
200	.08 -121	3.66 149	.16 - 2	.09 81
300	.11 -127	3.65 133	.17 - 5	.11 71
400	.15 -134	3.67 117	.17 - 8	.14 59
500	.19 -142	3.66 101	.17 - 12	.16 49



Available as: TM6570, 4 Pin TO-8 (T4)

TN6570, 4 Pin Surface Mount (SM3) FP6570, 4 Pin Flatpack (FP4)

BX6570, Connectorized Housing (H1)

#### **Features**

Low Noise Figure: <2.5 dB Typical</p>

■ High Output Power: > +17.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 500 MHz	10 - 500 MHz
Gain (dB)	8.0	7.0 Min.
Power @ 1 dB Comp. (dBm)	>+17.5	+17.0 Min.
Reverse Isolation (dB)	- 11	- 9.5 Max.
VSWR In Out	<1.85:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.5	3.0 Max.
Power Vdc mA	+15 35	+15 40 Max.

## Typical Intermodulation Performance at 25 ° C

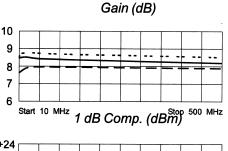
Second Order Harmonic Intercept Point		
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+35	(Typ.)

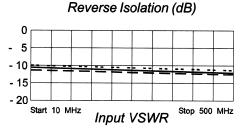
#### **Maximum Ratings**

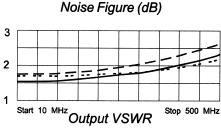
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

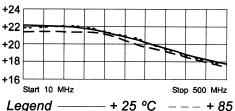
Note: Care should always be taken to effectively ground the case of each unit.

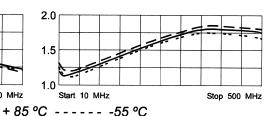
## **Typical Performance Data**

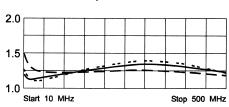












#### Linear S-Parameters

FREQ.	S11	S21	S12	\$22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.13 148	2.56 12	.29 12	.13 150
50	.09 -160	2.63 - 12	.29 - 12	.07 -175
100	.13 -151	2.62 - 26	.29 - 25	.08 -167
200	.20 -157	2.60 - 52	.28 - 52	.11 -170
300	.25 -176	2.59 - 79	.27 - 79	.13 176
400	.27 163	2.59 -106	.26 -107	.11 155
500	.26 141	2.58 -136	.25 -137	.07 148
600	.24 117	2.53 -167	.25 -170	.06 140



Available as: TM6572, 4 Pin TO-8 (T4)

TN6572-3, 4 Pin Surface Mount (SM3) FP6572-4, 4 Pin Flatpack (FP4) BX6572, Connectorized Housing (H1)

#### **Features**

■ High Efficiency: +13 dBm Typ. @ 150 mW DC

■ Low Voltage: +5 volt Bias

■ Operating Temp. - 55 °C to +85 °C

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+44 (Typ.)
Second Order Two Tone Intercept Point	+38 (Typ.)
Third Order Two Tone Intercent Point	+27 (Typ.)

#### **Specifications**

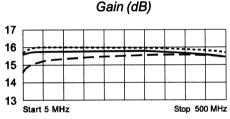
-			
CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	I	5 - 500 MHz	5 - 500 MHz
Gain (dB)		14.7	13.5 Min.
Power @ Comp.		+13	+11 Min.
Reverse Isolation	n (dB)	- 18	- 16 Max.
VSWR	ln	<1.25:1	2.0:1 Max.
	Out	<1.25:1	2.0:1 Max.
Noise figure (dB)		<4	5.5 Max.
Power	Vdc m A	+5 30	+5 35 Max.

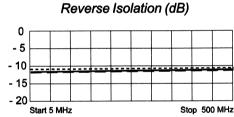
**Maximum Ratings** 

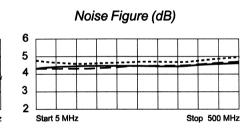
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 10 Volts
Continuous RF Input Power	
Short Term RF Input Power	
•	
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

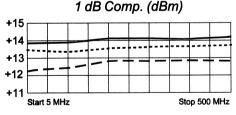
Note: Care should always be taken to effectively ground the case of each unit.

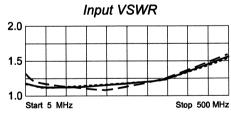
### **Typical Performance Data**

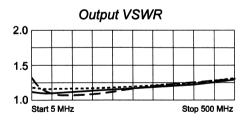












eaend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

Freq	S1	11	S2	21	S1	2	S2	22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.10	-137	5.40	 -173	 .11	-8	.09	145
50	.09	178	5.48	172	.12	1	.05	179
100	.08	175	5.48	163	.12	1	.05	-170
200	.08	171	5.48	146	.12	2	.08	-162
300	.07	168	5.47	129	.13	1	.10	-164
400	.06	-180	5.47	111	.13	1	.14	179
500	.08	-165	5.46	93	.14	-1	.18	163



Available as: TM6573, 4 Pin TO-8 (T4)

TN6573, 4 Pin Surface Mount (SM3) FP6573, 4 Pin Flatpack (FP4) BX6573, Connectorized Housing (H1)

#### **Features**

High Gain: 32 dB Typical

Low Noise Figure: 2.5 dB Typical Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	32	29 Min.
Power @ 1 dB Comp. (dBm)	+2.0	- 2.5 Min.
Reverse Isolation (dB)	- 39.5	- 38 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 20	+15 25 Max.

## Typical Intermodulation Performance at 25 ° C

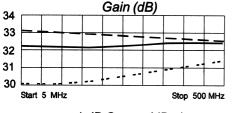
Second Order Harmonic Intercept Point	+25 (Typ.)
Second Order Two Tone Intercept Point	+19 (Typ.)
Third Order Two Tone Intercept Point	+14 (Typ.)

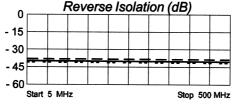
#### **Maximum Ratings**

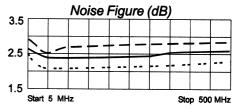
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

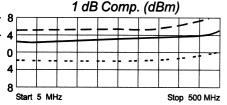
Note: Care should always be taken to effectively ground the case of each unit.

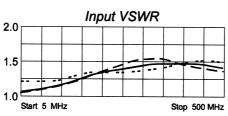
## **Typical Performance Data**

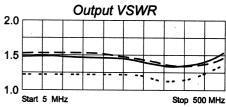












Legend ——— + 25 °C ---- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.02 -115	43.29 2	.01 - 8	.20 -174
50	.05 -112	43.04 - 20	.01 - 7	.20 173
100	.09 -121	43.06 - 39	.01 - 3	.19 164
200	.15 -142	43.16 - 78	.01 - 12	.19 145
300	.20 -162	43.89 -118	.01 - 1	.17 130
400	.21 -179	44.11 -160	.01 - 17	.14 129
500	.20 169	43.91 156	.01 - 19	.19 141
600	.21 173	43.44 108	.01 - 21	.36 130



Available as: TM6574, 4 Pin TO-8 (T4)

TN6574, 4 Pin Surface Mount (SM3) FP6574, 4 Pin Flatpack (FP4)

BX6574,Connectorized Housing (H1)

#### **Features**

■ High Gain: 30 dB Typ.

Medium Output Power: +9 dBm Typ.

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	30	27 Min.
Power @ 1 dB Comp. (dBm)	+9	+7 Min.
Reverse Isolation (dB)	- 36	- 33 Max.
VSWR In Out	1.35:1 1.65:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	6.0 Max.
Power Vdc mA	+15 37	+15 40 Max.

## Typical Intermodulation Performance at 25 ° C

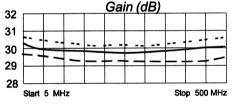
Second Order Harmonic Intercept Point	+41	(Typ.)
Second Order Two Tone Intercept Point	+36	(Typ.)
Third Order Two Tone Intercept Point	+22	(Typ.)

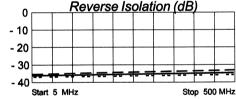
#### **Maximum Ratings**

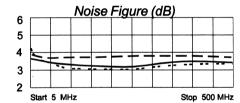
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

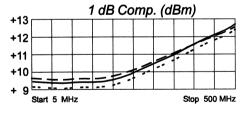
Note: Care should always be taken to effectively ground the case of each unit.

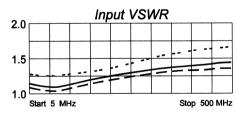
## **Typical Performance Data**

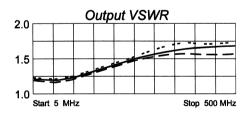












Legend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.		S11		321		S12		322
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.06	-148	32.67	3	.01	7	.07	-162
50	.06	163	31.75	- 21	.01	2	.08	-165
100	.07	147	31.43	- 41	.01	6	.11	-162
200	.11	112	31.15	- 82	.01	14	.17	-176
300	.15	85	31.19	-123	.01	13	.23	163
400	.19	61	31.59	-166	.02	- 3	.26	140
500	.21	39	32.23	149	.02	-11	.26	123



Available as:

TM6575, 4 Pin TO-8 (T4)

TN6575, 4 Pin Surface Mount (SM3) FP6575, 4 Pin Flatpack (FP4)

BX6575, Connectorized Housing (H1)

### **Features**

■ High Gain: +21 dB Typical
 ■ Low Noise: 2.7 dB Typical
 ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	21	19 Min.
Power @ 1 dB Comp. (dBm)	+ 9.5	+ 8.5 Min.
Reverse Isolation (dB)	- 23	- 21 Max.
VSWR In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.7	3.5 Max.
Power Vdc mA	+15 23	+15 27 Max.

## Typical Intermodulation Performance at 25 ° C

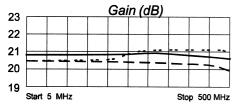
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+21 (Typ.)

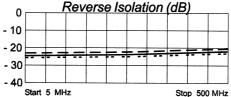
#### **Maximum Ratings**

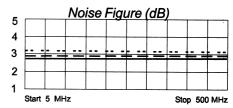
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

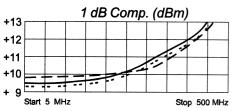
Note: Care should always be taken to effectively ground the case of each unit.

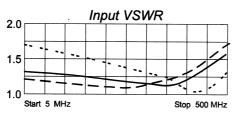
## **Typical Performance Data**

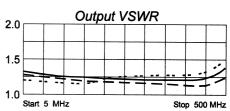












egend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.16 -174	10.41 -177	.05 5	.14 -174
50	.15 163	10.37 168	.05 1	.13 167
100	.14 145	10.35 155	.05 1	.12 152
200	.11 108	10.36 129	.06 1	.11 122
300	.06 46	10.43 103	.06 0	.09 95
400	.09 -69	10.57 73	.07 -3	.11 74
500	.23 -129	10.17 38	.08 -9	.18 41



Available as: TM6576, 4 Pin TO-8 (T4)

TN6576, 4 Pin Surface Mount (SM3) FP6576, 4 Pin Flatpack (FP4) BX6576,Connectorized Housing (H1)

#### **Features**

High Gain: 28 dB Typical

■ High Output Power: +16 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTI	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	28	26.0 Min.
Power @ 1 dB Comp. (dBm)	+16	+14 Min.
Reverse Isolation (dB)	- 34	- 33 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	6.0 Max.
Power Vdc mA	+15 64	+15 68 Max.

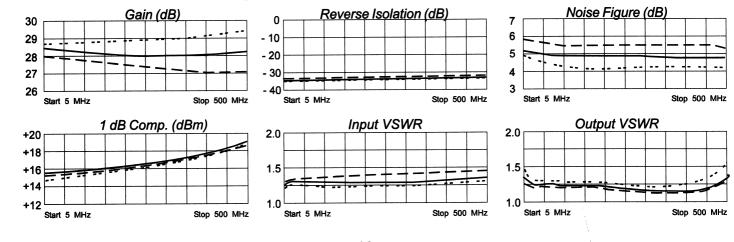
Typical Intermodulation Performance at 25 ° C

**Maximum Ratings** 

maximam rating o	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 usec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



gend ------ + 25 °C --- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.11 10	26.16 9	.01 8	.14 57
50	.12 - 3	25.78 - 20	.01 -7	.11 - 2
100	.12 - 5	25.66 - 41	.01 6	.11 - 18
200	.12 - 8	25.56 - 82	.01 8	.09 - 44
300	.13 - 19	25.65 -123	.02 2	.08 - 83
400	.15 - 35	25.76 -166	.02 9	.09 -136
500	.17 - 66	26.10 149	.02 -1	.17 169



Available as: TM6577, 4 Pin TO-8 (T4)

TN6577, 4 Pin Surface Mount (SM3) FP6577, 4 Pin Flatpack (FP4) BX6577, Connectorized Housing (H1)

#### **Features**

High Gain: 16.5 dB Typical

■ Medium Output Power: +17 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	+17	+15.0 Min.
Reverse Isolation (dB)	- 18.5	- 17 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	5.5 Max.
Power Vdc mA	+15 50	+15 55 Max.

## Typical Intermodulation Performance at 25 ° C

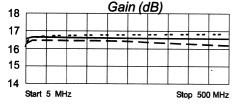
Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+42 (Typ.)
Third Order Two Tone Intercept Point	+32 (Typ.)

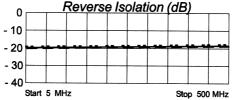
#### **Maximum Ratings**

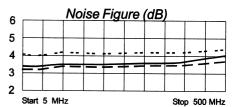
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

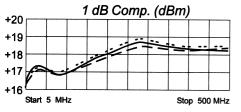
Note: Care should always be taken to effectively ground the case of each unit.

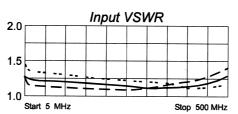
## **Typical Performance Data**

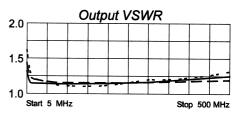












egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.13 -121	6.73 -170	.09 11	.15 136
50	.09 -180	6.90 171	.10 -0	.06 161
100	.08 170	6.88 159	.09 -1	.05 170
200	.07 161	6.85 138	.10 -2	.05 171
300	.05 170	6.79 117	.10 -4	.07 162
400	.07 -164	6.79 94	.11 -8	.09 148
500	.13 -158	6.71 70	.12 -12	.12 122



Available as: TM658

TM6581, 4 Pin TO-8 (T4)

TN6581, 4 Pin Surface Mount (SM3) FP6581, 4 Pin Flatpack (FP4)

## BX6581,Connectorized Housing (H1)

#### **Features**

■ High Gain: >22 dB Typical

■ Low Noise Figure: <3.5 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 500 MHz	20 - 500 MHz
Gain (dB)	22	21.0 Min.
Power @ 1 dB Comp. (dBm)	+16	+13.5 Min.
Reverse Isolation (dB)	- 29	- 28 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.5 Max.
Power Vdc mA	+15 27	+15 30 Max.

## Typical Intermodulation Performance at 25 ° C

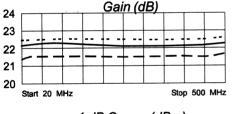
Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	+40 (Typ.)
Third Order Two Tone Intercept Point	+28 (Typ.)

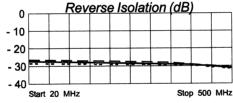
#### **Maximum Ratings**

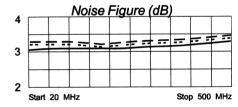
Maximaniiitatiiigo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

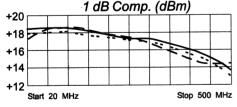
Note: Care should always be taken to effectively ground the case of each unit.

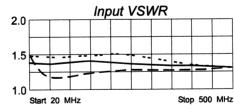
## **Typical Performance Data**

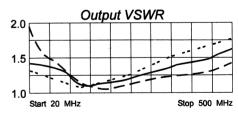












Legend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.20 -125	12.73 -168	.04 3	.19 167
20 50	.16 -154	12.87 -180	.04 - 2 .04 - 7	.18 167 .16 159
50 100	.14 169 .15 132	12.98 163 12.96 141	.04 - 7	.12 147
100 200 300 400	.16 79	12.91 99	.04 - 40	.12 147 .06 -175
300	.16 32	12.79 56	.04 - 66 .03 - 96	.13 -173 .18 130
400 500	.15 - 16 .15 - 90	12.80 9 12.93 - 43	.03 - 90 .03 -131	.23 50
600	.13 - 30	12.99 -112	.02 172	.32 6



Available as: TM6582, 4 Pin TO-8 (T4)

TN6582, 4 Pin Surface Mount (SM3) FP6582, 4 Pin Flatpack (FP4) BX6582,Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 3.5 dB Typical

■ High Output Power: +21 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	20 - 500 MHz	30 - 500 MHz	
Gain (dB)	23	21.5 Min.	
Power @ 1 dB Comp. (dBm)	+21	+17.0 Min.	
Reverse Isolation (dB)	- 29	- 27 Max.	
VSWR In Out	1.5:1 1.25:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	3.5	4.5 Max.	
Power Vdc mA	+15 47	+15 52 Max.	

## Typical Intermodulation Performance at 25 ° C

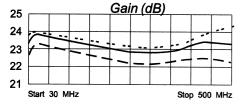
Second Order Harmonic Intercept Point	+49 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+33 (Typ.)

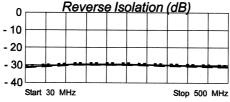
#### **Maximum Ratings**

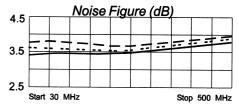
Maximum ratings	
Ambient Operating Temperature	55°C to + 100°C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+10 dBm
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

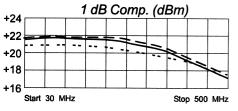
Note: Care should always be taken to effectively ground the case of each unit.

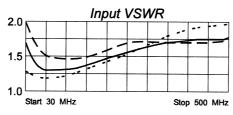
## **Typical Performance Data**

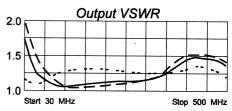












egend ----- + 25 °C ---- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
20 50 100 200 300 400 500	.36 - 52 .19 - 57 .16 - 56 .20 - 74 .26 -104 .29 -144 .29 136	13.26 -158 14.65 165 14.61 130 13.87 70 13.54 13 13.99 - 50 14.49 -129	.03 25 .03 5 .03 - 19 .03 - 43 .03 - 74 .03 -114 .03 -174	.42 120 .15 100 .03 135 .09 -166 .08 137 .10 8



Available as: TM6583, 4 Pin TO-8 (T4)

TN6583, 4 Pin Surface Mount (SM3) FP6583, 4 Pin Flatpack (FP4) BX6583, Connectorized Housing (H1)

#### **Features**

■ High Gain: 30 dB Typical

■ Low Power Drain: 65 mW @ 5 Volts

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 500 MHz	10 - 500 MHz	
Gain (dB)	30	28.0 Min.	
Power @ 1 dB Comp. (dBm)	-1	-4 Min.	
Reverse Isolation (dB)	- 37.5	- 36 Max.	
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<2.3	3.0 Max.	
Power Vdc m A	+5 13	+5 16 Max.	
Note: Care should always be taken to effectively ground the case of each unit.			

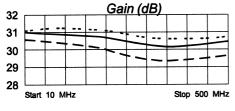
## Typical Intermodulation Performance at 25 ° C

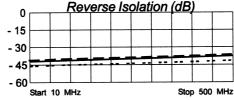
Second Order Harmonic Intercept Point	+19 (Typ.)
Second Order Two Tone Intercept Point	+13 (Typ.)
Third Order Two Tone Intercept Point	+10 (Typ.)

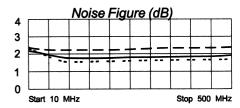
#### **Maximum Ratings**

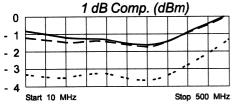
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 10 Volts
Continuous RF Input Power	+6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

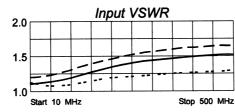
## **Typical Performance Data**

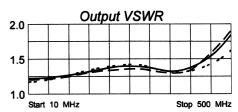












— + 25 °C − − − + 85 °C ---- -55 °C

#### **Linear S-Parameters**

FREQ.	91	\$21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.09 - 5	28.14 - 3	.01 2	.08 -169
50	.10 9	28.10 - 21	.01 14	.0 <b>8 -171</b>
100	.14 9	27.98 - 42	.01 8	.09 <b>-166</b>
200	.19 - 8	26.87 - 83	.01 15	.12 -173
300	.23 - 36	25.35 -120	.01 14	.12 -178
400	.26 - 68	25.86 -157	.01 12	.13 -158
500	29 -108	27.37 160	.01 12	.31 -157



Available as: TM6587, 4 Pin TO-8 (T4)

TN6587, 4 Pin Surface Mount (SM3) FP6587, 4 Pin Flatpack (FP4) BX6587,Connectorized Housing (H1)

#### **Features**

- High Output Power: +17 dBm Typical
- High 3rd Order Intercept: +32 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 400 MHz	10 - 400 MHz	
Gain (dB)	13	12 Min.	
Power @ 1 dB Comp. (dBm)	+17	+16.0 Min.	
Reverse Isolation (dB)	- 19	- 18 Max.	
VSWR In Out	1.75:1 1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	4.0	5.0 Max.	
Power Vdc mA	+15 32	+15 35 Max.	

## Typical Intermodulation Performance at 25 ° C

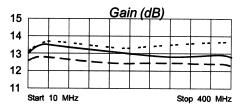
Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+47 (Typ.)
Third Order Two Tone Intercept Point	+32 (Typ.)

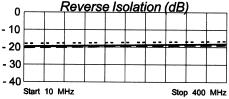
#### **Maximum Ratings**

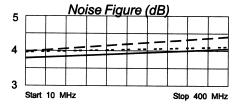
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	
	(3 µsec Max.)

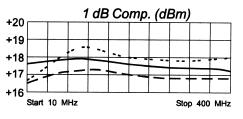
Note: Care should always be taken to effectively ground the case of each unit.

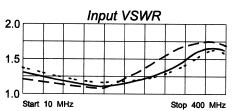
## **Typical Performance Data**

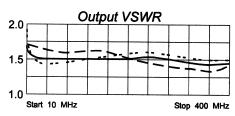












.egend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5 10	.14 - 93 .09 -110	4.46 -167 4.54 -176	.11 14	.24 156
50	.05 -151	4.61 167	.12 6 .12 - 3	.18 163 .16 -174
100	.04 -145	4.60 151	.12 - 10	.18 -162
200	.06 - 99	4.52 121	.12 - 21	.25 -166
300	.15 - 99	4.51 90	.13 - 34	.27 172
400	.26 -118	4.54 55	.13 - 52	.21 118



Available as: TM6588, 4 Pin TO-8 (T4)

TN6588, 4 Pin Surface Mount (SM3) FP6588, 4 Pin Flatpack (FP4) BX6588,Connectorized Housing (H1)

#### **Features**

■ High Gain: 18.5 dB Typical

■ High Output Power: +21 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

TYPICAL	i MIN/MAX
	IAIIIA\IAI\V
Ta= 25 °C	Ta = -55 °C to +85 °C
5 - 500 MHZ	5 - 450 MHz
18.5	17.5 Min.
+21	+19 Min.
- 20	- 17 Max.
<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
4.5	7.0 Max.
+15 80	+15 87 Max.
	5 - 500 MHz 18.5 +21 - 20 <1.75:1 <1.5:1 4.5

## Typical Intermodulation Performance at 25 ° C

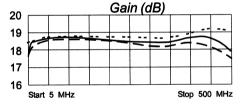
Second Order Harmonic Intercept Point	+50 (Typ.)
Second Order Two Tone Intercept Point	+44 (Typ.)
Third Order Two Tone Intercept Point	+35 (Typ.)

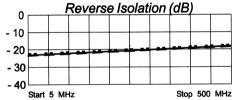
### **Maximum Ratings**

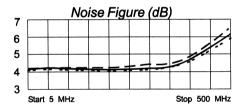
Maxilliulli italiliyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

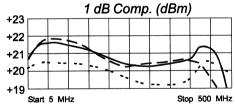
Note: Care should always be taken to effectively ground the case of each unit.

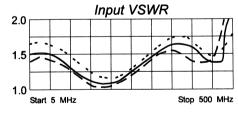
## **Typical Performance Data**

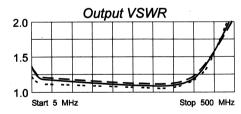












.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.20 -150	7.94 -172	.07 9	.29 171
50	.20 166	8.39 161	.07 - 3	.22 166
100	.15 144	8.44 141	.08 - 8	.20 155
200	.03 - 1	8.45 99	.09 - 25	.12 127
300	.20 - 94	8.32 55	.10 - 46	.02 65
400	.23 -152	8.45 6	.12 - 74	.04 47
450	.15 135	8.62 - 24	.13 - 95	.21 28
500	.33 19	7.91 - 65	.14 -126	.52 - 8



Available as:

TR6589, 4 Pin Surface Mount (SM3) FP6589-4, 4 Pin Flatpack (FP4)

BR6589, Connectorized Housing (H2)

#### **Features**

■ High Gain: 26.5 dB Typical

■ High Output Power: +22 dBm Typical

■ Operating Temp. -55 °C +85 °C

■ Environmental Screening available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	26.5	25 Min.
Power @ 1 dB Comp. (dBm)	+22	+20 Min.
Reverse Isolation (dB)	- 33	- 31 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.75	5.0 Max.
Power Vdc mA	+15 130	+15 135 Max.

Note: Care should always be taken to effectively ground the case of each unit.

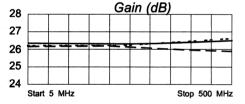
## Typical Intermodulation Performance at 25 ° C

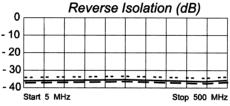
Second Order Harmonic Intercept Point	+61 (Typ.)
Second Order Two Tone Intercept Point	+55 (Typ.)
Third Order Two Tone Intercept Point	+35 (Typ.)

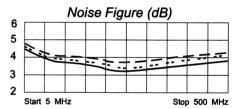
#### **Maximum Ratings**

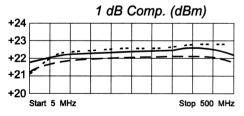
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	
	3 μsec Max.)

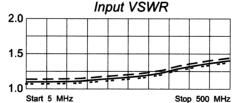
### **Typical Performance Data**

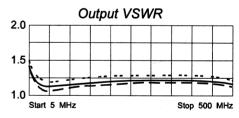












Legend ----- + 25 °C ---- - 55 °C

#### Linear S-Parameters

FREQ. MHz	S Mag	S11 Deg	S Mag	521 Deg	S Mag	512 Deg	: Mag	S22 Deg
5	.05	126	21.71	15	.01	19	.17	86
50	.02	66	20.95	-15	.02	-1	.03	- 26
100	.04	63	20.84	-31	.02	7	.05	-73
200	.08	54	20.77	-62	.02	8	09	-119
300	.11	34	20.83	-94	.02	4	.13	-149
450	.14	14	20.92	-126	.02	5	.14	-177
100 200 300 400 450 500	.16	-11	21.00	-159	.02	-2	.15	156



Available as:

TM6603, 4 Pin TO-8 (T4)

TN6603, 4 Pin Surface Mount (SM3) FP6603, 4 Pin Flatpack (FP4) BX6603, Connectorized Housing (H1)

#### **Features**

- 24 Volt Operation
- Medium Output Power: +15.5 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	10	8.5 Min.
Power @ 1 dB Comp. (dBm)	+15.5	+14.0 Min.
Reverse Isolation (dB)	- 15.5	- 14 Max.
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.5	7.0 Max.
Power Vdc mA	+24 50	+24 55 Max.

## Typical Intermodulation Performance at 25 ° C

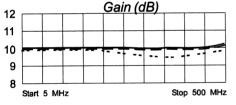
Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+42 (Typ.)
Third Order Two Tone Intercept Point	+30 (Typ.)

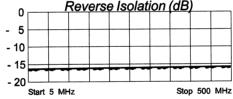
### **Maximum Ratings**

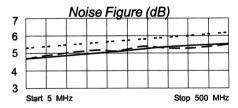
Maxilliulii Nauliyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 26 Volts
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

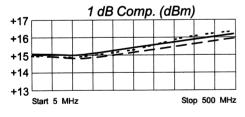
Note: Care should always be taken to effectively ground the case of each unit.

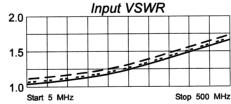
## **Typical Performance Data**

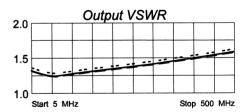












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.02 - 72	3.20 -178	.14 4	.13 -164
50	.02 - 87	3.30 172	.14 1	.13 -176
100	.04 - 89	3.19 164	.14 0	.13 -174
200	.09 -107	3.19 148	.15 -0	.15 -170
300	.14 -120	3.18 132	.15 -1	.17 -169
400	.19 -132	3.21 116	.16 -2	.20 -174
500	.26 -145	3.24 100	.17 -2	.23 -180



Available as: TM6605, 4 Pin TO-8 (T4)

TN6605, 4 Pin Surface Mount (SM3)

FP6605, 4 Pin Flatpack (FP4)

BX6605, Connectorized Housing (H1)

#### **Features**

Medium Gain: 15.5 dB TypicalMedium Output Power: +10 dBm

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 600 MHz	10 - 600 MHz
Gain (dB)	15.5	14.0 Min.
Power @ 1 dB Comp. (dBm)	+10	+8.0 Min.
Reverse Isolation (dB)	- 18.5	- 17 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	4.5 Max.
Power Vdc mA	+15 24	+15 27 Max.

### Typical Intermodulation Performance at 25 ° C

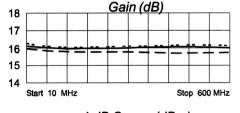
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+23 (Typ.)

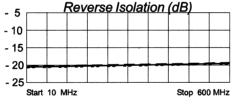
#### **Maximum Ratings**

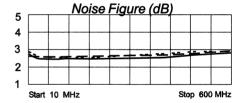
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

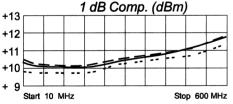
Note: Care should always be taken to effectively ground the case of each unit.

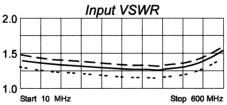
## **Typical Performance Data**

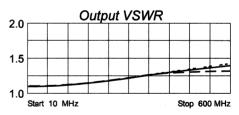












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQS11		S11S21			S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.14	-3	6.42	179	.09	0	.03	1
50	.13	<del>.9</del>	6.32	170	.09	-2	.04	-28
100	.13	-15	6.29	161	.09	-2	.04	-56
200	.12	-33	6.29	141	.09	-5	.07	-91
300	.11	-60	6.29	122	.10	-8	.09	-121
400	.10	-100	6.32	102	.10	-13	.12	-146
500	.14	-146	6.35	81	.11	-17	.15	-178
600	.22	175	6.31	59	.11	-25	.18	150



Available as: TM660

TM6607, 4 Pin TO-8 (T4)

TN6607, 4 Pin Surface Mount (SM3)

FP6607, 4 Pin Flatpack (FP4)

BX6607, Connectorized Housing (H1)

#### **Features**

Medium Gain: 15 dB Typical

■ Medium Output Power: +14.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+14.5	+12.5 Min.
Reverse Isolation (dB)	- 19	- 18 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<5.0	6.0 Max.
Power Vdc mA	+2 <b>4</b> 50	+24 54 Max.

Maximum Ratings

Second Order Harmonic Intercept Point	+40 (Typ.)
Second Order Two Tone Intercept Point	+34 (Typ.)
Third Order Two Tone Intercept Point	+24 (Typ.)

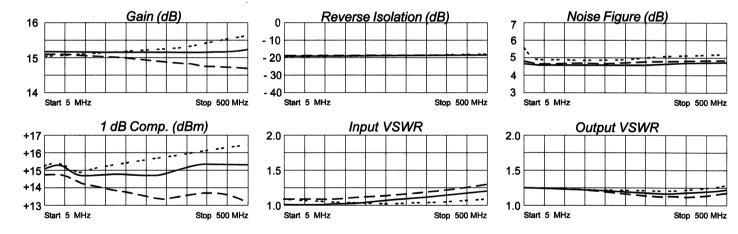
Typical Intermodulation Performance at 25 ° C

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 26 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 uses May )

(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Leaend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S Mag	S11 Deg	; Mag	S21 Deg	 Mag	512 Deg	 Mag	S22 Deg
5	.03	-147	5.74	-178	.09	-168	.09	109
50	.02	177	5.74	171	.10	177	.09	108
100	.02	179	5.74	161	.09	170	.12	88
200	.00	-128	5.71	143	.10	158	.19	65
300	.03	- 83	5.70	124	.10	135	.30	34
400	.05	-100	5.73	104	.10	114	.35	4
500	.10	-118	5.75	84	.11	92	.28	- 30
600	.14	-138	5.74	62	.11	<b>6</b> 6	.09	- 75



Available as: TM6609, 4 Pin TO-8 (T4)

TN6609, 4 Pin Surface Mount (SM3) FP6609, 4 Pin Flatpack (FP4) BX6609,Connectorized Housing (H1)

#### **Features**

Medium Gain: 11.5 dB Typical

■ High Output Power: +22 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+22	+20.0 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.5	7.0 Max.
Power Vdc mA	+24 88	+24 95 Max.

### Typical Intermodulation Performance at 25 ° C

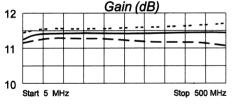
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

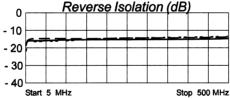
#### **Maximum Ratings**

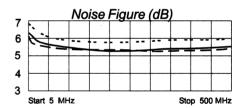
maxima tatingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 27 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

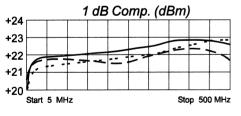
Note: Care should always be taken to effectively ground the case of each unit.

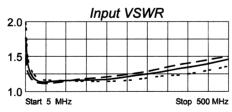
## **Typical Performance Data**

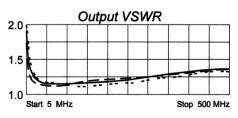












egend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.31 - 51	3.70 -154	.12 32	.39 113
50	.05 <b>-112</b>	3.65 175	.16 2	.07 110
100	.06 -121	3.66 166	.16 - 1	.07 102
200	.08 -121	3.66 149	.16 - 2	.09 81
300	.11 -127	3.65 133	.17 - 5	.11 71
<b>40</b> 0	.15 -134	3.67 117	.17 - 8	.14 59
500	.19 -142	3.66 101	.17 - 12	.16 49



Available as: TM6654, 4 Pin TO-8 (T4)

TN6654, 4 Pin Surface Mount (SM3) FP6654, 4 Pin Flatpack (FP4)

BX6654, Connectorized Housing (H1)

#### **Features**

■ High Gain: 29 dB Typical

■ Low Noise Figure: < 2.5 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		5 - 500 MHz	5 - 500 MHz
Gain (dB)		29	27.5 Min.
Power @ 1 dB Comp. (dBm)		+11	+10.0 Min.
Reverse Isolation	(dB)	- 34.5	- 33 Max.
VSWR	In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure	e (dB)	<2.5	3.0 Max.
Power	Vdc m A	+5 40	+5 45 Max.

Note: Care should always be taken to effectively ground the case of each unit.

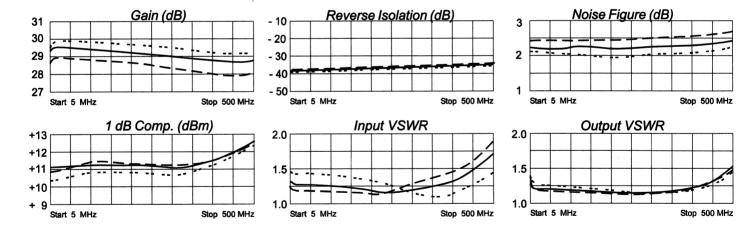
## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

## **Typical Performance Data**



Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.13 175	28.91 11	.01 13	.13 134	
50	.12 161	29.63 - 21	.01 6	.09 176	
100	.11 141	29.48 - 43	.01 - 3	.08 180	
200	.09 92	28.91 - 83	.01 2	.07 166	
300	.07 12	27.94 -131	.01 - 4	.07 142	
400	.13 - <b>6</b> 6	27.11 -175	.01 - 9	.09 111	
500	.27 -115	27.29 137	.02 - 21	.21 77	



Available as: TM6659, 4 Pin TO-8 (T4)

TN6659, 4 Pin Surface Mount (SM3) FP6659, 4 Pin Flatpack (FP4)

BX6659, Connectorized Housing (H1)

#### **Features**

- High Output Power: +22 dBm Typical
- High Third Order Intercept: +36 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERIS	ric	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		5 - 800 MHz	10 - 700 MHz
Gain (dB)		10.5	9.0 Min.
Power @ 1 dB Comp. (dBm)		+22	+20.0 Min.
Reverse Isolation (dB)		- 14	- 13 Max.
VSWR In	- 1	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)		6.5	8.0 Max.
Power Vo		+15 88	+15 95 Max.

## Typical Intermodulation Performance at 25 ° C

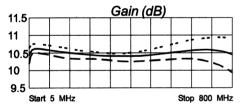
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+36 (Typ.)

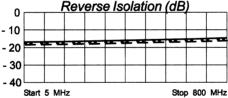
### **Maximum Ratings**

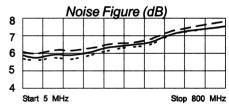
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

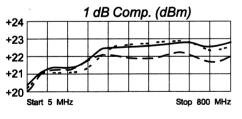
Note: Care should always be taken to effectively ground the case of each unit.

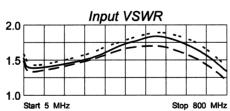
## **Typical Performance Data**

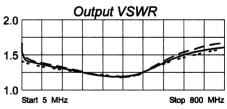












egend ------ + 25 °C --- + 85 °C ----- -55 °C

### Linear S-Parameters

FREQ.	S11	S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.21 -131	3.33 -165	.15 11	.21 161	
50	.17 162	3.41 170	.15 - 1	.17 159	
100	.18 139	3.38 158	.16 - 0	.16 145	
200	.20 103	3.34 136	.17 - 4	.13 112	
300	.23 74	3.32 115	.18 - 9	.11 69	
400	.24 51	3.34 94	.19 -16	.10 18	
500	.23 30	3.36 72	.19 -23	.12 - 33	
600	.20 6	3.41 49	.20 -31	.18 - 74	
700	.13 - 25	3.40 25	.19 - 39	.23 -105	
800	.05 -103	3.31 - 1	.19 -46	.28 -135	



Available as: TM6667, 4 Pin TO-8 (T4)

TN6667, 4 Pin Surface Mount (SM3) FP6667, 4 Pin Flatpack (FP4)

BX6667, Connectorized Housing (H1)

#### **Features**

■ High Efficiency: +15 dBm Typ. @ 480 mW DC

■ Low Noise Figure: < 4.0 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 700 MHz	5 - 600 MHz
Gain (dB)	14	12.5 Min.
Power @ 1 dB Comp. (dBm)	+15	+14.0 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	5.5 Max.
Power Vdc mA	+15 33	+15 35 Max.

Maximum Ratings

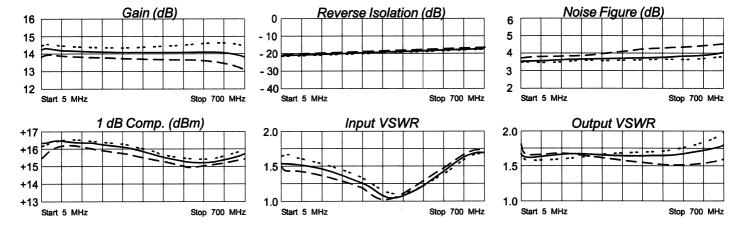
Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+30 (Typ.)

Typical Intermodulation Performance at 25 ° C

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
·	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 usec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



\_egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQS11	S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.23 -163	5.16 -175	.09 6	.25 179
50	.22 173	5.19 168	.09 - 1	.24 176
100	.21 165	5.16 155	.09 - 4	.24 173
200	.16 149	5.09 129	.10 - 9	.25 166
300	.10 130	5.04 104	.11 -15	.25 155
400	.02 50	5.06 77	.11 -22	.25 139
500	.11 - 53	5.05 49	12 - 33	.25 120
600	.21 - 75	5.01 19	.13 -44	.27 92
700	29 04	4 96 - 16	14 _ 58	34 53



Available as: TM6670, 4 Pin TO-8 (T4)

TN6670, 4 Pin Surface Mount (SM3) FP6670, 4 Pin Flatpack (FP4) BX6670,Connectorized Housing (H1)

#### **Features**

- Low Noise Figure: 1.8 dB Typical
- High Output Power: > +20 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 300 MHz	10 - 300 MHz
Gain (dB)	8.0	6.0 Min.
Power @ 1 dB Comp. (dBm)	>+20	+18.0 Min.
Reverse Isolation (dB)	- 11	- 10 Max:
VSWR In Out	<1.5:1 <1.5:1	2.5:1 Max. 2.5:1 Max.
Noise figure (dB)	1.8	3.0 Max.
Power Vdc mA	+15 25	+15 30 Max.

## Typical Intermodulation Performance at 25 ° C

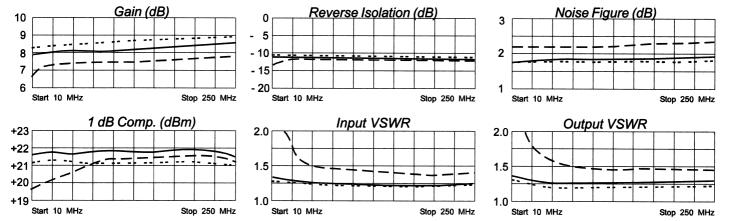
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.19 138	2.48 17	.28 18	.21 141
10	.12 1 <del>4</del> 6	2.56 8	.29 8	.13 144
20	.09 160	2.58 1	.29 2	.10 159
50	.08 -179	2.60 - 7	.29 - 7	.08 173
100	.11 -164	2.60 - 18	.29 - 17	.08 -171
150	.14 -164	2.62 - 27	.28 -27	.09 -160
200	.19 -167	2.64 - 37	.27 - 37	.11 -149
250	.25 -175	2.67 - 48	.26 -47	.16 -149
300	.32 177	2.67 - 59	.25 -58	21 -152



TM6672, 4 Pin TO-8 (T4) Available as:

TN6672, 4 Pin Surface Mount (SM3) FP6672, 4 Pin Flatpack (FP4)

BX6672.Connectorized Housing (H1)

#### **Features**

- High Efficiency: +13 dBm Typ. @ 270 mW DC
- Low Noise Figure: < 4.5 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 500 MHz	5 - 500 MHz	
Gain (dB)	14.7	13.5 Min.	
Power @ 1 dB Comp. (dBm)	+13	+11.0 Min.	
Reverse Isolation (dB)	- 18	- 16 Max.	
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	4.0	5.5 Max.	
Power Vdc mA	+ 9 30	+ 9 35 Max.	

Note: Care should always be taken to effectively ground the case of each unit.

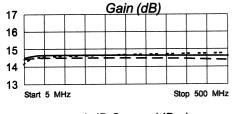
## Typical Intermodulation Performance at 25 ° C

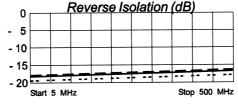
Second Order Harmonic Intercept Point	+44	(Typ.)
Second Order Two Tone Intercept Point	+38	(Typ.)
Third Order Two Tone Intercept Point	+27	(Typ.)

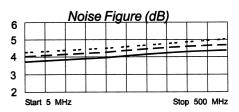
### **Maximum Ratings**

Maximumitatingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

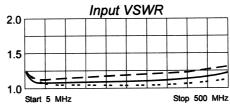
## **Typical Performance Data**

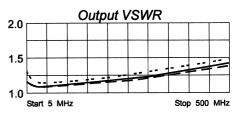












— + 25 °C − − − + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.12 -129	5.57 -171	.11 10	.14 138
50	.09 170	5.68 172	.11 1	.06 163
100	.09 150	5.66 163	.11 - 1	.06 169
200	.10 119	5.63 146	.11 - 4	.05 167
300	.10 89	5.57 129	.12 - 7	.04 -177
400	.11 61	5.55 112	.12 -10	.04 -152
500	.11 34	5.54 94	.12 - 14	.07 -145
600	.11 - 2	5.54 76	.12 - 17	.09 -154



Available as: TM6674, 4 Pin TO-8 (T4)

TN6674, 4 Pin Surface Mount (SM3)

FP6674, 4 Pin Flatpack (FP4)

BX6674, Connectorized Housing (H1)

#### **Features**

High Gain: 28 dB Typical

■ Low DC Power: +65 mW @ 5V Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	28	26.0 Min.
Power @ 1 dB Comp. (dBm)	- 1.0	- 2.0 Min.
Reverse Isolation (dB)	- 39	- 37 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.5	<4.0 Max.
Power Vdc mA	+ 5 13	+ 5 15 Max.

### Typical Intermodulation Performance at 25 ° C

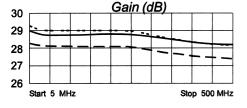
Second Order Harmonic Intercept Point	+23 (Typ.)
Second Order Two Tone Intercept Point	+17 (Typ.)
Third Order Two Tone Intercept Point	+ 9 (Tvp.)

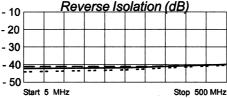
### **Maximum Ratings**

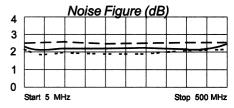
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

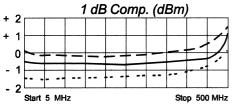
Note: Care should always be taken to effectively ground the case of each unit.

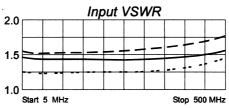
## **Typical Performance Data**

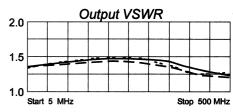












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.21 - 7	27.22 3	.01 -14	.16 -169
50	.20 - 10	26.32 - 19	.01 7	.17 -175
100	.20 - 21	26.42 - 37	.01 - 12	.17 -174
200	.20 - 39	26.34 - 74	.01 11	.17 -178
300	.21 - 61	25.78 -113	.01 <b>- 1</b> 0	.18 -178
400	.23 - 83	25.76 -150	.01 16	.16 171
500	.25 -112	25.74 170	.01 4	.14 -177
600	.32 -135	26.01 130	.01 - <b>4</b> 1	.16 -177



Available as: TM6

TM6675, 4 Pin TO-8 (T4)

TN6675, 4 Pin Surface Mount (SM3)

FP6675, 4 Pin Flatpack (FP4) BX6675, Connectorized Housing (H1)

### **Features**

■ High Gain: 20.5 dB Typical

■ Low Noise Figure: <2.3 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	20.5	19.0 Min.
Power @ 1 dB Comp. (dBm)	+ 5	+ 4.0 Min.
Reverse Isolation (dB)	- 23.5	- 22.5 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.3	3.0 Max.
Power Vdc mA	+15 15	+15 17 Max.

Note: Care should always be taken to effectively ground the case of each unit.

## Typical Intermodulation Performance at 25 ° C

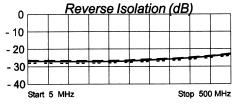
Second Order Harmonic Intercept Point	+26 (Typ.)
Second Order Two Tone Intercept Point	+21 (Typ.)
Third Order Two Tone Intercept Point	+18 (Typ.)

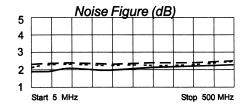
#### **Maximum Ratings**

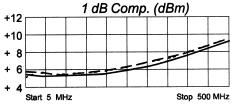
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

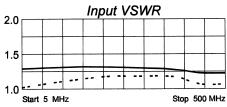
## **Typical Performance Data**

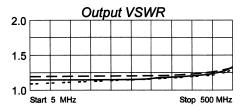












Leaend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.14 0	11.31 -179	.05 3	.07 - 5
50	.14 - 2	11.19 168	.05 - 2	.08 - 9
100	.15 - 5	11.09 156	.05 - 1	.08 - 22
200	.14 - 17	10.89 132	.05 - 5	.08 - 51
300	.13 - 32	10.71 109	.05 - 6	.07 - 92
400	.10 - 61	10.68 84	.06 - 10	.08 -154
500	.08 -126	10.64 58	.06 - 14	.15 148



Available as:

TM6677, 4 Pin TO-8 (T4)

TN6677-3, 4 Pin Surface Mount (SM3) FP6677-4, 4 Pin Flatpack (FP4) BX6677, Connectorized Housing (H1)

### **Features**

■ Medium Output Power: +16.5 dBm

■ High Third Order I.P.: +30 dBm

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	5 - 600	5 - 600
Gain (dB)	16.5	14.5 Min.
Power @ 1 dB Comp. (dBm)	+16.5	+14.5 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	1.50:1 1.50:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	7.0 Max.
Power Vdc mA	+15 50	+15 56 Max.

## Typical Intermodulation Performance at 25 ° C

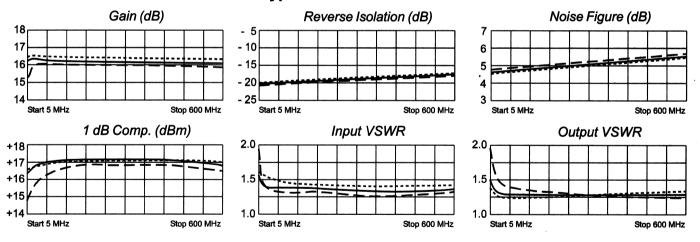
Second Order Harmonic Intercept Point	+49 (Typ.)
Second Order Two Tone Intercept Point	+43 (Typ.)
Third Order Two Tone Intercept Point	+30 (Tvp.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	
Maximum Peak Power	
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**





Available as:

TM6681, 4 Pin TO-8 (T4)

TN6681, 4 Pin Surface Mount (SM3)

FP6681, 4 Pin Flatpack (FP4)

BX6681, Connectorized Housing (H1)

#### **Features**

■ High Reverse Isolation: -37 dB Typical

■ Very Low Output VSWR: 1.1:1 Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 500 MHz	20 - 500 MHz	
Gain (dB)	17.5	15.5 Min.	
Power @ 1 dB Comp. (dBm)	+9.5	+7.0 Min.	
Reverse Isolation (dB)	- 37	- 35 Max.	
VSWR In Out	1.40:1 1.10:1	2.00:1 Max. 1.25:1 Max.	
Noise figure (dB)	3.0	4.0 Max.	
Power Vdc mA	+15 29	+15 32 Max.	
Note: Care should always	be taken to effectively g	round the case of each unit.	

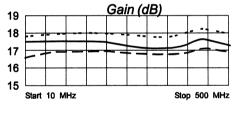
## Typical Intermodulation Performance at 25 ° C

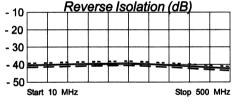
Second Order Harmonic Intercept Point	+33 (Typ.)
Second Order Two Tone Intercept Point	+28 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

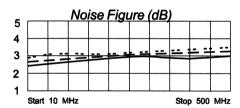
#### **Maximum Ratings**

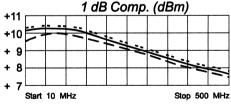
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

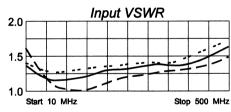
## **Typical Performance Data**

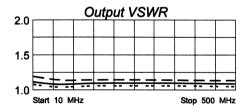












Leaend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	\$12 Mag Deg	S22 Mag Deg
IVETE	iviay bey	iviay bey	IVIAY DOY	IVIAY DOS
10	.30 - 84	7.21 -156	.01 15	.03 165
50	.06 -161	7.55 164	.01 16	.03 167
100	.07 107	7.53 139	.01 - 19	.02 -179
200	.14 41	7.29 94	.01 - 19	.03 -111
300	.18 - 8	7.11 48	.01 - 32	.04 -126
400	.19 - 77	7.46 - 2	.01 - 60	.02 -114
500	29 152	7.37 - 81	01 -123	03 -123



Available as: TM6683, 4 Pin TO-8 (T4)

TN6683, 4 Pin Surface Mount (SM3)

FP6683, 4 Pin Flatpack (FP4)

BX6683, Connectorized Housing (H1)

#### **Features**

■ High Gain: 34 dB Typical

Low Power Drain: 70 mW @ 5 Volts

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency		10 - 250 MHz	10 - 250 MHz	
Gain (dB)		34	32.5 Min.	
Power @ 1 dl Comp. (dB	-	-1	-3 Min.	
Reverse Isolation (dB)		- 47.5	- 45 Max.	
VSWR	In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (	dB)	<2.0	3.0 Max.	
Power	Vdc mA	+5 14	+5 16 Max.	

## Typical Intermodulation Performance at 25 ° C

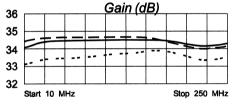
Second Order Harmonic Intercept Point	+15 (Typ.)
Second Order Two Tone Intercept Point	+ 9 (Typ.)
Third Order Two Tone Intercept Point	+10 (Tvp.)

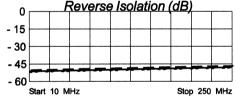
#### **Maximum Ratings**

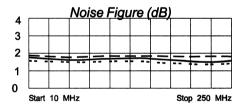
55°C to + 100 °C
62°C to + 125 °C
+ 125 ℃
+ 8 Volts
+ 10 dBm
50 Milliwatts
(1 Minute Max.)
0.5 Watt
(3 µsec Max.)

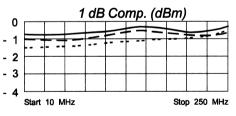
Note: Care should always be taken to effectively ground the case of each unit.

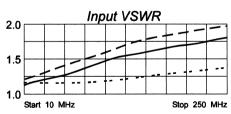
## **Typical Performance Data**

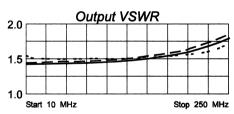












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S	11	S	521	S	512	S	522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.02	134	24.54	- 7	.00	17	.18	- 7
50	.10	72	24.93	- 36	.00	- 44	.18	- 27
100	.17	48	26.11	- 71	.00	64	.18	- 53
200	.26	12	28.09	-13 <del>4</del>	.00	28	.21	- 90
300	.31	- 20	29.12	-178	.01	9	.41	-125



Available as: TM6719

TM6719, 4 Pin TO-8 (T4)

TN6719, 4 Pin Surface Mount (SM3)

FP6719, 4 Pin Flatpack (FP4)

BX6719, Connectorized Housing (H1)

#### **Features**

- Low Noise Figure: <1.7 dB Typical
- Medium Output Power: > +9 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency.	5 - 500 MHz	5 - 500 MHz
Gain (dB)	33	31.0 Min.
Power @ 1 dB Comp. (dBm)	+9	+8.0 Min.
Reverse Isolation (dB)	- 42	- 40 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.7	2.0 Max.
Power Vdc m A	+15 35	+15 38 Max.

Note: Care should always be taken to effectively ground the case of each unit.

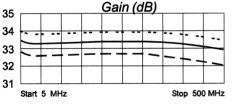
## Typical Intermodulation Performance at 25 ° C

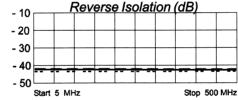
Second Order Harmonic Intercept Point	+42 (Typ.)
Second Order Two Tone Intercept Point	+36 (Typ.)
Third Order Two Tone Intercept Point	+20 (Typ.)

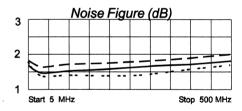
#### **Maximum Ratings**

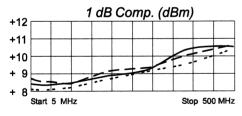
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

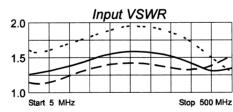
## **Typical Performance Data**

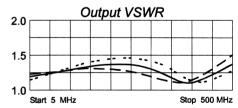












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.11 -163	47.18 3	.01 12	.09 -163
5Ŏ	.13 -166	46.15 -24	.01 -20	.10 -165
100	.16 -165	45.93 -48	.01 -5	.13 -164
200	.20 -173	46.18 <del>-9</del> 7	.01 -8	.16 179
300	.21 171	46.31 -147	.01 -16	.13 160
400	.17 165	46.10 160	.01 -25	.06 -171
500	16 -158	44.77 104	.01 -41	.17 -148



Available as: TM6721, 4 Pin TO-8 (T4)

TN6721, 4 Pin Surface Mount (SM3)

FP6721, 4 Pin Flatpack (FP4)

BX6721, Connectorized Housing (H1)

### **Features**

High Gain: 30 dB Typical

■ Low Noise Figure: < 3 dB Typical ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 500 MHz	5 - 500 MHz	
Gain (dB)	30	28.0 Min.	
Power @ 1 dB Comp. (dBm)	+9	+7.5 Min.	
Reverse Isolation (dB)	- 36	- 34 Max.	
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<3.0	4.0 Max.	
Power Vdc mA	+15 38	+15 41 Max.	

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+22 (Typ.)

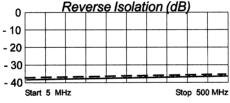
### **Maximum Ratings**

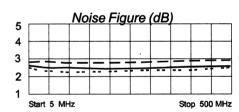
Maximum Ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

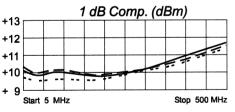
Note: Care should always be taken to effectively ground the case of each unit.

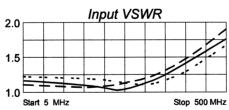
## **Typical Performance Data**

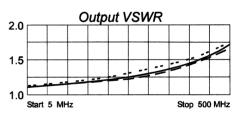












egend ----- + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		S11		321		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.08	-163	34.22	3	.01	9	.06	-169
50	.07	165	33.49	-21	.01	-13	.06	-165
100	.06	151	33.32	<b>-4</b> 2	.01	-3	.08	-161
200	.02	138	33,35	-84	.01	-15	.10	-158
300	.06	-100	33.19	-128	.01	-13	.14	-162
400	.16	-130	32.86	-173	.01	-15	.19	-170
500	.29	-161	31.51	139	.01	-16	.27	172



Available as: TM7101, 4 Pin TO-8 (T4)

TN7101, 4 Pin Surface Mount (SM3) FP7101, 4 Pin Flatpack (FP4) BX7101, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 1.8 dB Typical

■ High Gain: 27.5 dB Typical■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 150 MHz	10 - 150 MHz
Gain (dB)	27.5	26.0 Min.
Power @ 1 dB Comp. (dBm)	+16.5	+15.0 Min.
Reverse Isolation (dB)	- 31.5	- 30 Max.
VSWR In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.8	2.5 Max.
Power Vdc mA	+15 20	+15 23 Max.

Note: Care should always be taken to effectively ground the case of each unit.

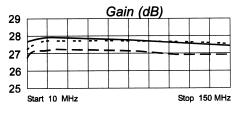
## Typical Intermodulation Performance at 25 ° C

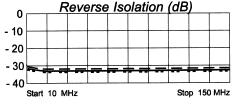
Second Order Harmonic Intercept Point	+41 (Typ.)
Second Order Two Tone Intercept Point	+35 (Typ.)
Third Order Two Tone Intercept Point	+30 (Typ.)

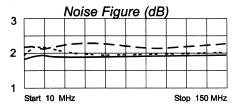
#### **Maximum Ratings**

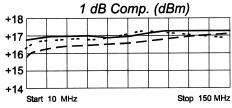
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

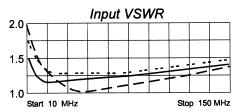
## **Typical Performance Data**

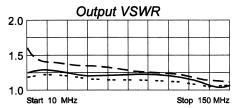












#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.23 - 99	24.64 -165	.02 - 4	.11 -161	
25	.09 -145	25.10 175	.02 1	.13 171	
50	.07 151	24.87 158	.02 - 1	.12 153	
75	.09 109	24.67 144	.02 1	.11 133	
100	.12 81	24.39 130	.02 - 2	.08 124	
125	.14 64	24.14 117	.02 - 10	.05 105	
150	.16 53	23.80 105	.03 - 10	.02 87	
200	.20 26	23.32 79	.03 - 15	.04 -132	
300	.24 - 32	23.14 27	.02 - 47	.13 -169	



Available as: TM7102, 4 Pin TO-8 (T4)

TN7102-3, 4 Pin Surface Mount (SM3) FP7102-4, 4 Pin Flatpack (FP4) BX7102, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 2 dB Typical

Medium Output Power: +17 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 150 MHz	20 - 150 MHz
Gain (dB)	24.5	22.5 Min.
Power @ 1 dB Comp. (dBm)	+17	+16.0 Min.
Reverse Isolation (dB)	- 28	- 27 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.0 Max.
Power Vdc mA	+15 31	+15 35 Max.

## Typical Intermodulation Performance at 25 ° C

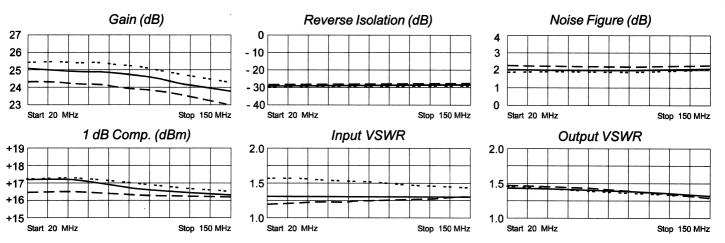
Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	+40 (Typ.)
Third Order Two Tone Intercept Point	+29 (Typ.)

#### **Maximum Ratings**

•	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Legend ----- + 25 °C ---- - 55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.13 -148	17.84 -179	.04 6	.20 163
20	.13 -162	17.93 173	.03 2	.18 169
50	.13 -169	17.64 157	.04 4	.17 174
100	.12 -171	16.64 133	.03 -5	.16 178
150	.12 -166	15.32 111	.04 -7	.13 -180
200	.12 -158	13.90 90	.04 -13	.10 -165



Available as: TM7103, 4 Pin TO-8 (T4)

TN7103-3, 4 Pin Surface Mount (SM3) FP7103, 4 Pin Flatpack (FP4) BX7103, Connectorized Housing (H1)

#### **Features**

5 Volt Oper.; High Gain: 26 dB Typical
 Low Noise Figure: 2.3 dB Typical
 Operating Temp. - 55 °C to +85 °C
 Environmental Screening Available

Specifications

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 150 MHz	10 - 150 MHz
Gain (dB)	26.5	25.0 Min.
Power @ 1 dB Comp. (dBm)	+9.5	+8.0 Min.
Reverse Isolation (dB)	- 31	- 30 Max.
VSWR In Out	1.40:1 1.40:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.3	2.75 Max.
Power Vdc mA	+5 15.5	+5 18 Max.

## Typical Intermodulation Performance at 25 ° C

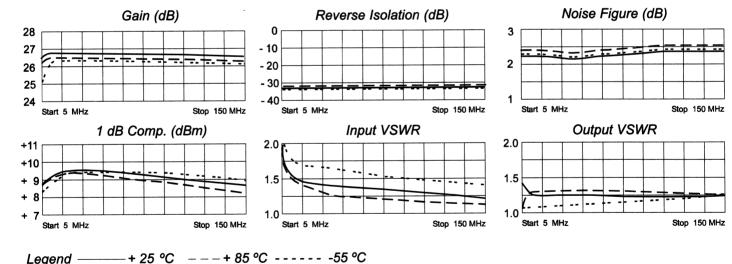
Second Order Harmonic Intercept Point	+34 (Typ.)
Second Order Two Tone Intercept Point	+28 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

**Maximum Ratings** 

meximum: radiii ge	
<b>Ambient Operating Temperature</b>	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

FREQ.		311		321		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.36	- 97	22.85	-152	.02	5	.06	91
25	.21	-169	25.53	171	.02	1	.07	23
50	.19	162	25.21	153	.03	2	.07	16
100	.16	124	24.55	123	.03	- 5	.07	15
150	.13	83	23.90	94	.03	-13	.08	20



Available as: TM7104, 4 Pin TO-8 (T4)

TN7104, 4 Pin Surface Mount (SM3)

FP7104, 4 Pin Flatpack (FP4)

BX7104, Connectorized Housing (H1)

#### **Features**

High Gain: 24 dB Typical

Low Noise Figure: 1.9 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 150 MHz	5 - 150 MHz
Gain (dB)	24	22.5 Min.
Power @ 1 dB Comp. (dBm)	+12	+10.5 Min.
Reverse Isolation (dB)	- 27	- 26 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.9	2.5 Max.
Power Vdc mA	+5 20	+5 23 Max.

### Typical Intermodulation Performance at 25 ° C

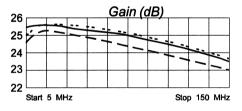
Second Order Harmonic Intercept Point	+37	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+25	(Typ.)

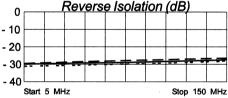
#### **Maximum Ratings**

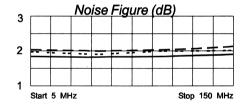
Ambient Operating Temperature.	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

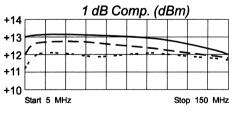
Note: Care should always be taken to effectively ground the case of each unit.

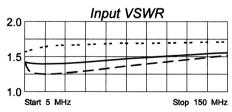
## **Typical Performance Data**

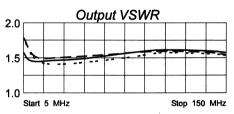












#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.20 -146	18.83 -173	.03 9	.24 169
10	.19 -162	19.10 179	.03 5	.21 171
20	.20 -170	19.08 170	.03 1	.20 174
50	.21 -174	18.44 149	.03 - 2	.20 173
100	.24 -180	16.68 118	.04 - 6	.22 161
150	.27 -172	14.75 91	.04 - 12	.21 137
200	.30 -160	12.98 65	.04 - 23	.19 101



Available as: TM7111, 4 Pin TO-8 (T4)

TN7111, 4 Pin Surface Mount (SM3) FP7111, 4 Pin Flatpack (FP4) BX7111,Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 1.4 dB Typical

Medium Output Power: +17 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 100 MHz	10 - 100 MHz
Gain (dB)	12.5	11.0 Min.
Power @ 1 dB Comp. (dBm)	+17	+15.5 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.4	2.0 Max.
Power Vdc mA	+15 14	+15 15 Max.

Typical Intermodulation Performance at 25 ° C

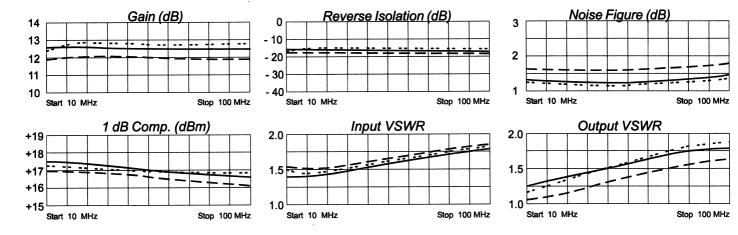
Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+47 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

**Maximum Ratings** 

111.65 11111 11111 11111 13	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
•	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.16 177	4.24 5	.17 5	.10 23
10	.15 178	4.32 - 3	.17 - 3	.11 - 6
25	.16 -178	4.32 - 18	.17 - 17	.15 - 46
50	.21 175	4.26 - 38	.16 - <b>3</b> 6	.21 - 80
75	.25 160	4.21 - 58	.16 <i>-</i> 56	.27 -102
100	.28 141	4.17 - 77	.15 - 74	.29 -119
150	.19 109	4.25 -123	.14 -119	.17 -128



Available as: TM7147, 4 Pin TO-8 (T4)

TN7147, 4 Pin Surface Mount (SM3)
FP7147, 4 Pin Flatpack (FP4)
BX7147, Connectorized Housing (H1)
PN7147, Reduced Size Surface Mount (SM11)

#### **Features**

■ Low Noise figure: 2.1 dB Typical
■ Operating Temp. - 55 °C to +85 °C
■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC		TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		5 - 300 MHz.	10 - 250 MHz.
Gain (dB)		12.5 dB	11 dB Min.
Noise Figu	re (dB)	2.1 dB	3.0 dB Max.
Power @ 1 Comp.		+15.5 dBm	+14.0 dBm Min.
VSWR	In Out	<1.2:1 <1.2:1	1.5:1 1.5:1 Max.
Power	Vdc mA	+5 36 mA	+5 40 mA Max.

## Typical Intermodulation Performance at 25 ° C

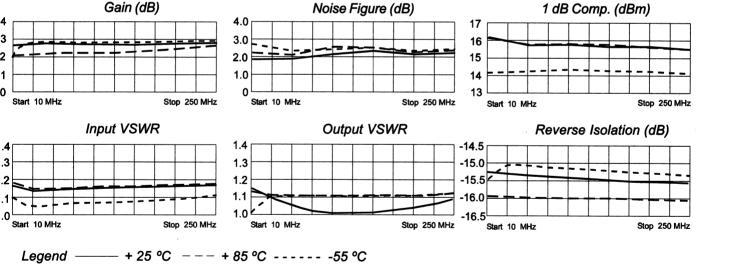
Second Order Harmonic Intercept Point....... 52 dBm (Typ.) Second Order Two Tone Intercept Point....... 46 dBm (Typ.) Third Order Two Tone Intercept Point.......... 31 dBm (Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 8 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
•••••	
Maximum Peak Power	0.5 Watt
	(3 usec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





Available as: TM7170, 4 Pin TO-8 (T4)

TN7170, 4 Pin Surface Mount (SM3) FP7170, 4 Pin Flatpack (FP4) BX7170,Connectorized Housing (H1)

#### **Features**

- Low Noise Figure: <1.5 dB Typical
- High Efficiency: +10 dBm @ 11.5 mA Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 250 MHz	10 - 250 MHz	
Gain (dB)	8.5	7.5 Min.	
Power @ 1 dB Comp. (dBm)	+10	+ 9.0 Min.	
Reverse Isolation (dB)	- 9.5	- 9.0 Max.	
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<1.5	2.5 Max.	
Power Vdc mA	+15 11.5	+15 12.5 Max.	

## Typical Intermodulation Performance at 25 ° C

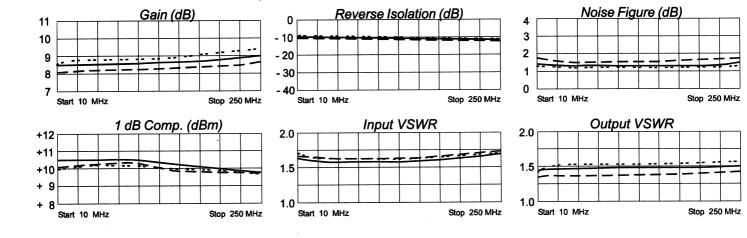
Second Order Harmonic Intercept Point	+44	(Typ.)
Second Order Two Tone Intercept Point	+38	(Typ.)
Third Order Two Tone Intercept Point	+26	(Typ.)

### **Maximum Ratings**

waxiiiiuiii kaunys	
Ambient Operating Temperature.	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

— + 25 °C − − − + 85 °C ---- -55 °C

FREQ.	911	\$21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
10	.23 179	2.64 3	.27 3	.18 10	
20	.22 177	2.67 -1	.27 -1	.19 2	
50	.22 173	2.67 -8	. <b>27 -7</b>	.19 -8	
100	.23 168	2.68 -18	.26 -16	.19 -22	
150	.23 164	2.71 -27	.26 -25	.19 -35	
200	.24 161	2.76 -37	.26 -25 .25 -33	.20 -51	
250	.26 158	2.82 -47	.24 -43	.20 -69	
300	29 156	2.92 -57	.22 -52	.22 -90	



Available as: TM7201, 4 Pin TO-8 (T4)

TN7201, 4 Pin Surface Mount (SM3) FP7201, 4 Pin Flatpack (FP4) BX7201,Connectorized Housing (H1)

#### **Features**

■ High Gain: 29 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	5 - 250 MHz	5 - 250 MHz		
Gain (dB)	29	27.5 Min.		
Power @ 1 dB Comp. (dBm)	+ 7	+ 5.5 Min.		
Reverse Isolation (dB)	- 40	- 38 Max.		
VSWR In Out	<1.25:1 <1.4:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	< 5.0	6.5 Max.		
Power Vdc mA	+15 35	+15 38 Max.		

### Typical Intermodulation Performance at 25 ° C

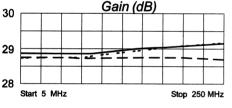
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+19 (Tvp.)

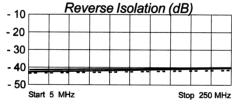
#### **Maximum Ratings**

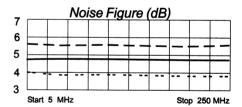
maximum raungs	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

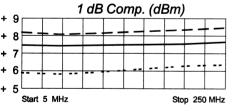
Note: Care should always be taken to effectively ground the case of each unit.

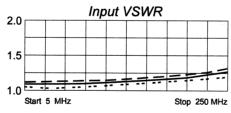
### **Typical Performance Data**

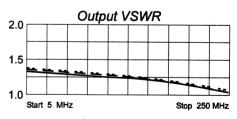












.egend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.05 -27	27.77 2	.01 8	.14 -10
25	.04 -16	27.75 -10	.01 10	.13 -7
50	.04 -23	27.80 -21	.01 21	.13 -9
100	.05 -43	27.97 -43	.01 11	.12 -19
150	.07 -49	28.22 -64	.01 29	.09 -28
200	.08 -54	28.43 -87	.01 25	.06 -37
250	.11 -59	28.69 -110	.01 32	.02 -61



Available as:

TM7202, 4 Pin TO-8 (T4)

TN7202, 4 Pin Surface Mount (SM3) FP7202, 4 Pin Flatpack (FP4) BX7202, Connectorized Housing (H1)

#### **Features**

■ High Gain: 27 dB Typical ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	5 - 250 MHz
Gain (dB)	27	26.0 Min.
Power @ 1 dB Comp. (dBm)	+16.5	+15.0 Min.
Reverse Isolation (dB)	- 38	- 36 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	6.5 Max.
Power Vdc mA	+15 88	+15 100 Max.

### Typical Intermodulation Performance at 25 ° C

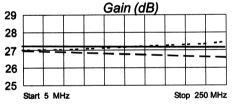
Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	+38 (Typ.)
Third Order Two Tone Intercept Point	+29 (Typ.)

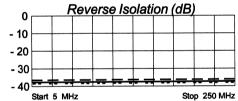
#### **Maximum Ratings**

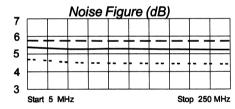
Maximaninatingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

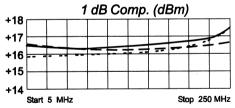
Note: Care should always be taken to effectively ground the case of each unit.

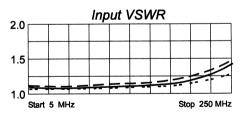
### **Typical Performance Data**

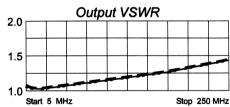












-+ 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22		
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg		
5	.03 -76	22.89 2	.01 5	.03 -104		
25	.01 -72	22.87 - 11	.01 16	.02 -116		
50	.02 -67	22.80 - 24	.01 7	.04 -118		
100	.03 -67	22.80 - 49	.01 39	.07 -139		
150	.05 -52	22.82 - 74	.01 38	.10 -155		
200	.08 -43	22.76 - 99	.01 41	.14 -171		
250	.15 -44	22.71 -125	.01 35	.19 176		



Available as: TM7203, 4 Pin TO-8 (T4)

TN7203, 4 Pin Surface Mount (SM3)

FP7203, 4 Pin Flatpack (FP4)
BX7203, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 3.5 dB Typical

■ High Gain: +32 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	5 - 250 MHz
Gain (dB)	32	30.0 Min.
Power @ 1 dB Comp. (dBm)	+ 8	+ 6.5 Min.
Reverse Isolation (dB)	- 40	- 37 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3	4.0 Max.
Power Vdc mA	+15 35	+15 38 Max.

### Typical Intermodulation Performance at 25 ° C

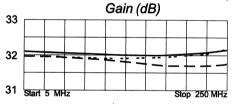
J1	
Second Order Harmonic Intercept Point	+36 (Typ.)
Second Order Two Tone Intercept Point	+30 (Typ.)
Third Order Two Tone Intercept Point	+18 (Tvp.)

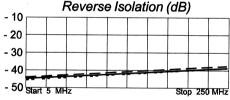
#### **Maximum Ratings**

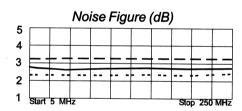
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	
·	(3 μsec Max.)

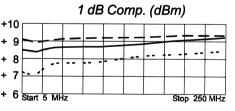
Note: Care should always be taken to effectively ground the case of each unit.

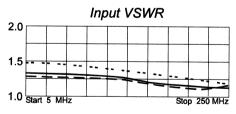
### **Typical Performance Data**

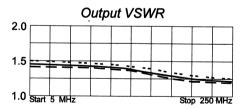












Legend ——— + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.					,	S21		512		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg		
5	.14	-169	40.30	2	.01	-0	.19	-7		
10	.14	-175	40.29	-2	.01	š	.19	-5		
20	.13	-178	40.24	-8	.01	Ĭ	.19	. <del>7</del>		
50	.13	-179	40.09	-24	.01	10	.18	-14		
100	.12	177	39.69	<b>-4</b> 7	.01	17	.16	-27		
150	.10	177	39.77	-70	.01	23	.14	<del>-44</del>		
200	.07	-176	39.96	<del>-9</del> 4	.01	23	.11	-69		
250	.04	-113	40.67	-118	.01	27	.09	-119		
300	14	-75	41.64	-145	.01	20	16	-169		

**Amplifonix** 

Available as: TM7205, 4 Pin TO-8 (T4)

TN7205, 4 Pin Surface Mount (SM3) FP7205, 4 Pin Flatpack (FP4) BX7205,Connectorized Housing (H1)

#### **Features**

■ 5 Volt Oper.; Low Noise: 1.6 dB Typical

■ HighGain:20 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX	
	Ta= 25 °C	Ta = -55 °C to +85 °C	
Frequency	10 - 200 MHz	10 - 200 MHz	
Gain (dB)	20	19 Min.	
Power @ 1 dB Comp. (dBm)	+14	+12.0 Min.	
Reverse Isolation (dB)	- 24	- 23 Max.	
VSWR In	<1.8:1	2.0:1 Max.	
Out	<1.6:1	2.0:1 Max.	
Noise figure (dB)	1.6	2.2 Max.	
Power Vdc	+5	+5	
m A	18	21 Max.	

Note: Care should always be taken to effectively ground the case of each unit.

### Typical Intermodulation Performance at 25 ° C

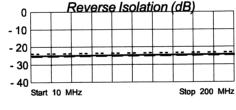
Second Order Harmonic Intercept Point	+32 (Typ.)
Second Order Two Tone Intercept Point	+26 (Typ.)
Third Order Two Tone Intercept Point	+21 (Typ.)

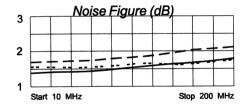
#### **Maximum Ratings**

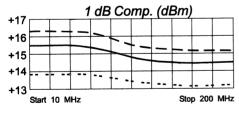
	Ambient Operating Temperature	
	Storage Temperature	62°C to + 125 °C
(	Case Temperature	+ 125 °C
	DC Voltage	+ 10 Volts
,	Continuous RF Input Power	+ 13 dBm
	Short Term RF Input Power	
		(1 Minute Max.)
	Maximum Peak Power	0.5 Watt
		(3 μsec Max.)

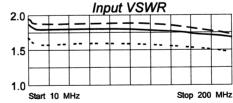
### **Typical Performance Data**

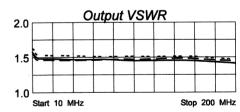












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22·
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.31 - 20	9.69 -176	.05 -177	.23 - 22
50	.30 - 33	9.78 159	.05 153	.21 - 12
100	.29 - 61	9.72 136	.05 128	.20 - 16
150	.28 - 92	9.70 113	.06 100	.20 - <b>28</b>
200	.24 -130	9.62 88	.06 75	.19 - <b>4</b> 5
250	.20 167	9.43 60	.06 47	.15 - 77
300	.26 80	8.52 29	.06 20	.10 -144



Available as: TM7207, 4 Pin TO-8 (T4)

TN7207-3, 4 Pin Surface Mount (SM3) FP7207-4, 4 Pin Flatpack (FP4) BX7207, Connectorized Housing (H1)

#### **Features**

■ Medium Output Power: +16 dBm Typ.

■ Low Noise Figure: 2 dB Typ.

Operating Temp. - 55 °C to +85 °C

#### **Specifications**

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency		10 - 300 MHz	10 - 200 MHz	
Gain (dB)		18	17 Min.	
Power @ 1 d Comp. (dB		+16 +15		
Reverse Isolation (dB)		- 21	- 21 Max.	
VSWR	In Out	<1.7:1 <1.7:1	2:01 Max. 2.0:1 Max.	
Noise figure (dB)		2.0	3.0 Max.	
Power	Vdc mA	+15 33	+15 40 Max.	

### Typical Intermodulation Performance at 25 ° C

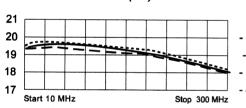
Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+42 (Typ.)
Third Order Two Tone Intercept Point	+31 (Tvp.)

#### **Maximum Ratings**

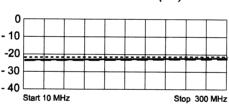
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	100 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

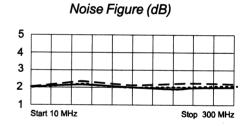
Note: Care should always be taken to effectively ground the case of each unit.

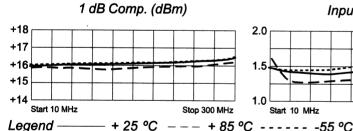
#### Typical Performance Data Reverse Isolation (dB)

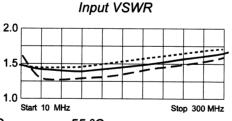


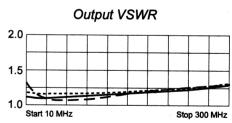
Gain (dB)











Linear	S-Parameters

Freq	S1		S2	21	S1	2	S2	22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.21	 -39	9.42	 -172	.069	-171	.15	-56
50	.15	-29	9.53	167	.069	165	.05	-8
100	.16	-41	9.35	150	.073	148	.06	23
150	.17	-59	9.16	134	.077	132	.08	37
200	.19	-77	8.88	118	.081	119	.10	41
250	.21	-98	8.51	102	.085	104	.12	43
300	.22	-120	8.01	87	.090	92	.14	40



Available as: TM7208

TM7208, 4 Pin TO-8 (T4)

TN7208, 4 Pin Surface Mount (SM3)

FP7208, 4 Pin Flatpack (FP4)

BX7208, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: <1.4 dB Typical</p>

■ High Gain: 22.5 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	5 - 250 MHz
Gain (dB)	22.5	21.0 Min.
Power @ 1 dB Comp. (dBm)	+ 3	+ 0.0 Min.
Reverse Isolation (dB)	- 25	- 24 Max.
VSWR In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<1.4	2.0 Max.
Power Vdc mA	+15 10	+15 12 Max.

Note: Care should always be taken to effectively ground the case of each unit.

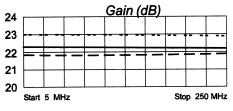
### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+20	(Typ.)
Second Order Two Tone Intercept Point	+13	(Typ.)
Third Order Two Tone Intercept Point	+16	(Typ.)

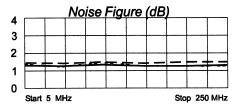
#### **Maximum Ratings**

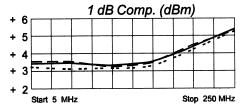
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

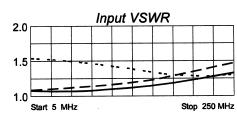
### **Typical Performance Data**

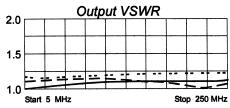












Legend ——— + 25°C ---- + 85°C ---- -55°C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.03 -165	13.11 -178	.05 5	.01 -140
50	.02 -159	12.99 164	.05 -1	.03 79
100	.04 -128	13.00 147	.05 1	.04 64
150	.07 -115	13.02 130	.05 1	.04 65
200	.11 -117	13.04 112	.06 -1	.04 76
250	16 -126	12.97 93	.06 -1	.07 110



Available as: TM7210, 4 Pin TO-8 (T4)

TN7210, 4 Pin Surface Mount (SM3) FP7210, 4 Pin Flatpack (FP4) BX7210,Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: <1.5dB Typical

■ High Power: +13 dBm Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10-300 MHz	10-200 MHz	
Gain (dB)	9±0.5	8.0 Min.	
Power @ 1 dB Comp. (dBm)	+14	+12.5 Min.	
Reverse Isolation (dB)	- 11.5	- 11 Max.	
VSWR In Out	<1.5:1 <1.35:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	1.3	2.0 Max.	
Power Vdc mA	+15 15	+15 17 Max.	
Note: Care should always be taken to effectively ground the case of each unit.			

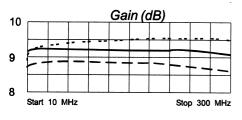
### Typical Intermodulation Performance at 25 ° C

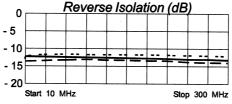
Second Order Harmonic Intercept Point	+53	(Typ.)
Second Order Two Tone Intercept Point	+48	(Typ.)
Third Order Two Tone Intercept Point	+31	(Typ.)

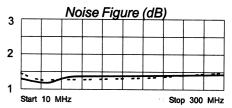
#### **Maximum Ratings**

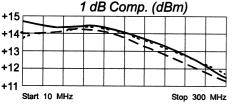
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

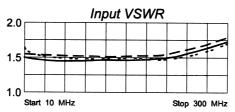
#### **Typical Performance Data**

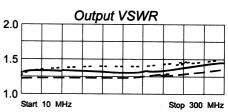












egend ----- + 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.		M1 <u>-</u>		521		S1 <u>2</u>	:	S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.21	180	2.85	2	.26	8	.13	8
50	.19	173	2.89	-11	.26	-14	.15	-14
100 150	.19	170	2.89	-24	.26	-38	.14	-38
150	.18	169	2.89	-36	. 26	-62	.14	-62
200	.20	170	2.88	-49	.25	-91	.13	-91



Available as:

TM7211, 4 Pin TO-8 (T4)

TN7211, 4 Pin Surface Mount (SM3)

FP7211, 4 Pin Flatpack (FP4)

BX7211, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: <2.0 dB Typical

■ High Power: +20 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10-200 MHz	30 -200 MHz
Gain (dB)	8.5	7.5 Min.
Power @ 1 dB Comp. (dBm)	+20	+19.0 Min.
Reverse Isolation (dB)	- 12	- 11 Max.
VSWR In Out	<1.75:1 <1.35:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.8	3.0 Max.
Power Vdc mA	+15 30	+15 33 Max.

Note: Care should always be taken to effectively ground the case of each unit.

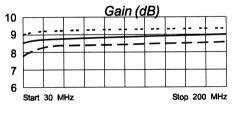
### Typical Intermodulation Performance at 25 ° C

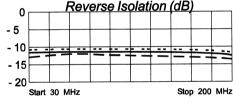
Second Order Harmonic Intercept Point	+61 (Typ.)
Second Order Two Tone Intercept Point	+55 (Typ.)
Third Order Two Tone Intercept Point	+40 (Typ.)

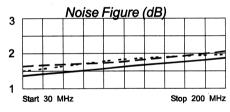
#### **Maximum Ratings**

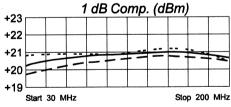
Ambient Operating Temperature	
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

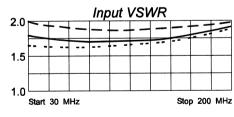
### **Typical Performance Data**

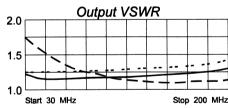












Legend ------ + 25 °C --- + 85 °C ----- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22-	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag D	eg
20	.33 155	2.61 11	.24 12		95
50	.28 165	2.71 - 1	.25 - 2	.08 6	30
100	.27 169	2.73 -14	.25 -14	.05 -2	25
150	.28 172	2.76 -24	.24 -23	.08 -7	74
200	.31 171	2.78 -34	.23 -33	.13 -9	96



Available as: RN7215, 4 Pin Surface Mount (SM19)

BR7215, Connectorized Housing (H2)

#### **Features**

■ High Gain: 31.5 dB Typical

■ Medium Output Power: +13.5 dBm Typical

### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+45 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+26 (Tvp.)

#### **Specifications**

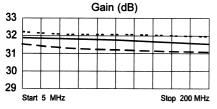
CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 200 MHz	5 - 200 MHz
Gain (dB)	31.5	30.0 Min.
Power @ 1 dB Comp. (dBm)	+13	+10.0 Min.
Reverse Isolation (dB)	- 40	- 35 Max.
VSWR In Out	<1.10:1 <1.25:1	1.5:1 Max. 1.5:1 Max.
Noise figure (dB)	2.5	4.0 Max.
Power Vdc	+15 58	+15 70 Max.

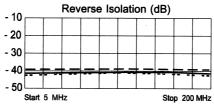
#### **Maximum Ratings**

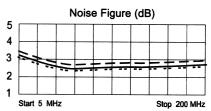
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	3 usec Max.)

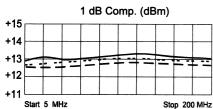
Note: Care should always be taken to effectively ground the case of each unit.

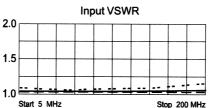
#### **Typical Performance Data**

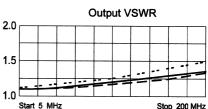












.egend ----- + 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	\$	11	8	S21		612		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5 25 50 75 100	.03 .01 .02 .04 .05	- 54 - 86 -160 -160 -150	39.35 38.74 38.53 38.23 38.23	2 - 9 - 19 - 28 - 37	.01 .01 .01 .01 .01 .01	4 - 2 10 21	.07 .08 .09 .10	-175 -176 -168 -168 -175
125 150 175 200	.05 .04 .03 .05	-148 -162 161 147	38.18 38.18 37.93 38.06	- 46 - 56 - 66 - 75	.01 .01 .01 .01	29 15 31 27	.12 13 .12 .14 .16	178 173 174 172



# **RF AMPLIFIER MODEL TR7216**

RN7216, 4 Pin Surface Mount (SM19) Available as:

BR7216, Connectorized Housing (H2)

#### **Features**

■ Low Noise Figure: < 2.5 dB Typical

■ High 3rd Order Intercept: > +33 dBm Typical

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point+49	(Typ.)
Second Order Two Tone Intercept Point+44	(Typ.)
Third Order Two Tone Intercent Point +23	(Typ.)

#### **Specifications**

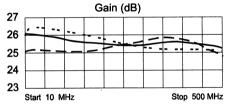
CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		10 - 500 MHz	10 - 500 MHz
Gain (dB)		25.5	24.0 Min.
Power @ 1 dB Comp. (dBm)		+20	+18.0 Min.
Reverse Isolation	(dB)	- 32	- 30 Max.
VSWR	In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)		<2.5	3.0 Max.
Power	Vdc m A	+12 65	+12 70 Max.

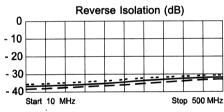
**Maximum Ratings** 

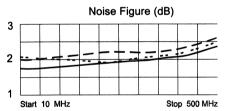
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	3 μsec Max.)

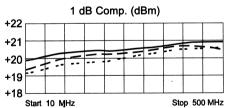
Note: Care should always be taken to effectively ground the case of each unit.

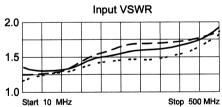
### **Typical Performance Data**

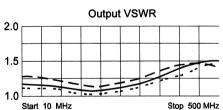












Legend	+ 25 °C	+ 85 °C	 -55 °C
Leaema	. 20 0		

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.16 - 29	20.16 9	.01 1	.09 -137
20	.14 - 29	20.14 - 4	.01 - 4	.08 -162
50	.14 - 43	19.77 - 26	.01 - 30	.08 171
100	.15 - 69	19.35 - 55	.01 - 69	.06 145
200	.19 -115	18.91 -110	.01 -123	.05 149
300	.21 -154	18.60 -166	.02 173	.10 127
400	.24 173	18.70 135	.03 135	.17 77
500	.31 135	18.02 72	.03 88	.20 23



Available as: TR7217, 4 Pin TO-8B (T8)

TN7217-8, 10 Pin Gull-Wing Flatpack (SG4) BR7217, Connectrized Housing (H2)

#### **Features**

- Low Noise Figure: < 2.5 dB Typical
- High 3rd Order Intercept: > +33 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 400 MHz	10 - 400 MHz
Gain (dB)	25.5	24.0 Min.
Power @ 1 dB Comp. (dBm)	+20	+18 Min.
Reverse Isolation (dB)	- 32	- 30 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.5	3.0 Max.
Power Vdc mA	+15 65	+15 70 Max.

### Typical Intermodulation Performance at 25 ° C

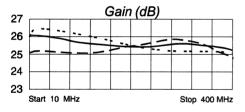
Second Order Harmonic Intercept Point	+49(Typ.)
Second Order Two Tone Intercept Point	+44 (Typ.)
Third Order Two Tone Intercept Point	+33(Typ.)

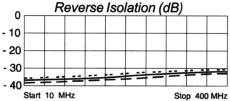
#### **Maximum Ratings**

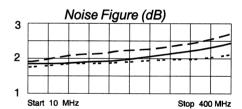
maximam radingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

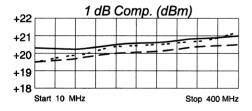
Note: Care should always be taken to effectively ground the case of each unit.

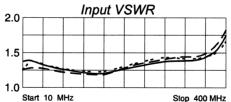
#### **Typical Performance Data**

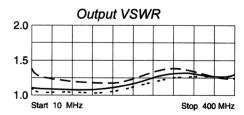












Legend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5 10 50 100 200 300 400	.17 - 21 .16 - 14 .14 - 33 .12 - 62 .10 - 148 .15 139 .26 129	19.49 26 20.21 9 19.79 - 24 19.38 - 49 19.25 - 99 19.45 -150 18.48 94	.01 22 .01 4 .01 - 27 .01 - 52 .01 - 110 .02 -163 .02 118	.08 -89 .04 -131 .03 155 .03 113 .03 134 .10 130 .11 105



Available as: TM7

TM7221, 4 Pin TO-8 (T4)

TN7221, 4 Pin Surface Mount (SM3)

FP7221, 4 Pin Flatpack (FP4)
BX7221, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 2 dB Typical

■ High Gain: 28.5 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 200 MHz	20 - 200 MHz
Gain (dB)	28.5	27.0 Min.
Power @ 1 dB Comp. (dBm)	+18.5	+15 Min.
Reverse Isolation (dB)	- 31.5	- 30 Max.
VSWR In Out	<1.5:1 <1.4:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.0	3.0 Max.
Power Vdc mA	+15 29	+15 32 Max.

# Typical Intermodulation Performance at 25 ° C

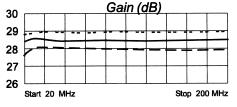
Second Order Harmonic Intercept Point	+44 (Typ.)
Second Order Two Tone Intercept Point	+38 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

#### **Maximum Ratings**

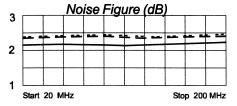
Maximaniii	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

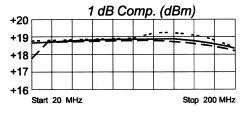
Note: Care should always be taken to effectively ground the case of each unit.

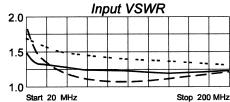
#### **Typical Performance Data**

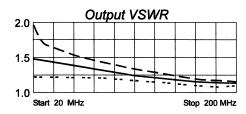












Legend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.39	- 92	25.50	-151	.02	14	.24	140
25	.18	-130	26.62	-178	.02	2	.18	153
50	.12	-169	26.61	163	.02	2	.17	148
100	.09	139	26.43	135	.02	6	.14	135
150	.08	76	26.38	110	.03	- 5	.10	127
200	.10	20	26.34	85	.02	- 11	.06	132
300	.26	- 69	27.30	33	.02	- 27	.05	-161



Available as: TM7222, 4 Pin TO-8 (T4)

TN7222, 4 Pin Surface Mount (SM3) FP7222, 4 Pin Flatpack (FP4) BX7222, Connectrized Housing (H1)

#### **Features**

High Gain: 29 dB Typical

Low Noise Figure:<2.9 dB Typical</p>

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20-250 MHz	20-250 MHz
Gain (dB)	29	27.5 Min.
Power @ 1 dB Comp. (dBm)	+20.5	+18.0 Min.
Reverse Isolation (dB)	+18.0	- 34 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.9	4.0 Max.
Power Vdc mA	+15 47	+15 52 Max.

### Typical Intermodulation Performance at 25 ° C

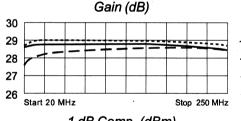
Second Order Harmonic Intercept Point	+44	(Typ)
Second Order Two Tone Intercept Point	+38	(Typ)
Third Order Two Tone Intercept Point	+32	(Typ)

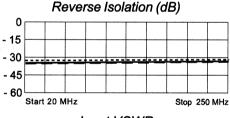
#### **Maximum Ratings**

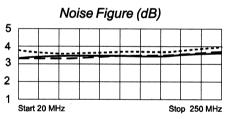
•
55°C to + 100 °C
62°C to + 125 °C
+ 125 °C
+18Volts
+ 13 dBm
50 Milliwatts
( 1 Minute Max.)
0.5 Watt
(3,usec Max.)

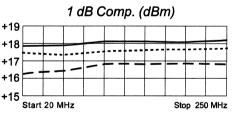
Note: Care should always be taken to effectively ground the case of each unit.

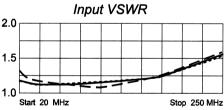
#### **Typical Performance Data**

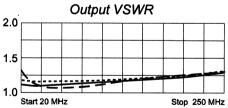












.eaend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10 20 50 100 150 200 250 300	.42 - 86 .21 -118 .11 -165 .17 95 .23 59 .28 29 .29 - 4 .26 - 53	26.71 -141 28.88 -170 29.24 158 28.73 124 28.29 92 27.96 60 28.50 27 31.16 - 12	.02 16 .02 7 .02 - 1 .02 - 13 .02 - 18 .02 - 46 .01 - 56	.33 105 .18 95 .14 61 .14 - 0 .18 - 63 .26 -127 .38 -172 .46 156



Available as: TM72

TM7270, 4 Pin TO-8 (T4)

TN7270, 4 Pin Surface Mount (SM3) FP7270, 4 Pin Flatpack (FP4) BX7270,Connectorized Housing (H1)

#### **Features**

- Low Noise Figure: <1.6 dB Typical
- High Efficiency: +15 dBm @ 15 mA Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 250 MHz	10 - 250 MHz
Gain (dB)	8.3	7.0 Min.
Power @ 1 dB Comp. (dBm)	+13 * +15 **	+11.0 * Min. +13.0 ** Min.
Reverse Isolation (dB)	- 10.5	- 10.0 Max.
VSWR In Out	1.5:1 1.3:1	1.8:1 Max. 1.8:1 Max.
Noise figure (dB)	1.4	2.5 Max.
Power Vdc mA	+15 15	+15 18 Max.

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+55 (Typ.)
Second Order Two Tone Intercept Point	+50 (Typ.)
Third Order Two Tone Intercept Point	+30 (Typ.)

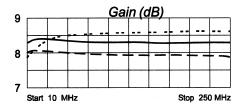
**Maximum Ratings** 

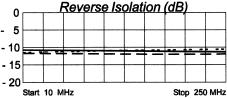
55°C to + 100 °C
62°C to + 125 °C
+ 125 °C
+ 18 Volts
+ 13 dBm
50 Milliwatts
(1 Minute Max.)
0.5 Watt
(3 µsec Max.)

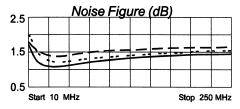
Frequency = 10 - 250 MHz

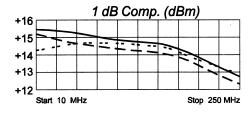
Note: Care should always be taken to effectively ground the case of each unit.

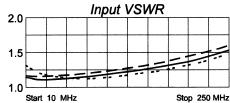
#### **Typical Performance Data**

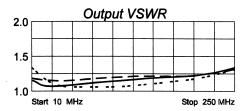












Leaend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ. MHz	S Mag	S11 Deg	: Mag	S21 Deg	S Mag	12 Deg	: Mag	S22 Deg
5	.06	135	2.43	10	.27	10	.08	146
10	.04	128	2.48	4	.28	4	.04	148
20	.03	125	2.50	-2	.28	-1	.03	-156
50	.05	170	2.49	-10	.28	-10	.08	-136
100	.12	-171	2.47	-21	.27	-20	.12	-151
150	.20	-160	2.50	-32	.27	-32	.11	-151
200	.25	-157	2.49	-44	.26	-43	.15	-132
250	.26	-166	2.45	-55	.24	-55	.24	-140
300	.31	174	2.41	-67	.22	-66	.32	-154



<sup>\*</sup> Frequency = 10 - 160 MHz

Available as:

TM7271, 4 Pin TO-8 (T4)

TN7271, 4 Pin Surface Mount (SM3) FP7271, 4 Pin Flatpack (FP4)

BX7271, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: < 2.0 dB Typical

■ High Gain: 18 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	1 - 300 MHz	5 - 250 MHz
Gain (dB)	18	16.0 Min.
Power @ 1 dB Comp. (dBm)	+0.5	- 1.0 Min.
Reverse Isolation (dB)	- 23	- 22 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.5	2.8 Max.
Power Vdc mA	+15 9	+15 12 Max.

### Typical Intermodulation Performance at 25 ° C

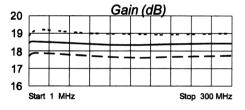
<b>3</b> 1	
Second Order Harmonic Intercept Point	+18 (Typ.)
Second Order Two Tone Intercept Point	+13 (Typ.)
Third Order Two Tone Intercept Point	+13 (Typ.)

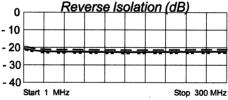
#### **Maximum Ratings**

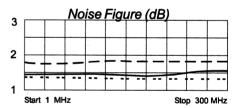
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

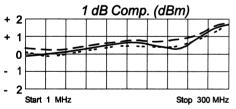
Note: Care should always be taken to effectively ground the case of each unit.

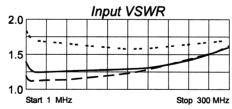
#### **Typical Performance Data**

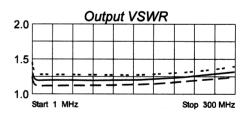












Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
1	.16 -148	8.36 -163	.05 20	.12 -140
5	.12 -173	8. <del>4</del> 8 -178	.06 4	.09 -174
50	.11 -178	8.39 167	.06 - 1	.08 162
100	.11 -171	8.31 154	.06 - 2	.08 150
150	.12 -161	8.23 1 <del>4</del> 2	.06 - 4	.08 143
200	.14 -155	8.25 129	.06 - 6	.09 136
250	.18 -154	8.28 116	.06 - 9	.12 130
300	.22 -157	8.33 103	.07 - 11	.15 121



Available as: TM7272, 4 Pin TO-8 (T4)

TN7272, 4 Pin Surface Mount (SM3) FP7272, 4 Pin Flatpack (FP4) BX7272,Connectorized Housing (H1)

#### **Features**

■ Gain: 14.7 dB Typical

■ Low VSWR: 1.25:1 Maximum ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	10 - 200 MHz
Gain (dB)	14.7	14 Min/ 15.5 Max
Power @ 1 dB Comp. (dBm)	+14	+12.0 Min.
Reverse Isolation (dB)	- 18.5	- 18 Max.
VSWR In Out	<1.15:1 <1.15:1	1.25:1 Max. 1.25:1 Max.
Noise figure (dB)	3.0	5.0 Max.
Power Vdc mA	+5 35	+5 38 Max.

Typical Intermodulation Performance at 25 ° C

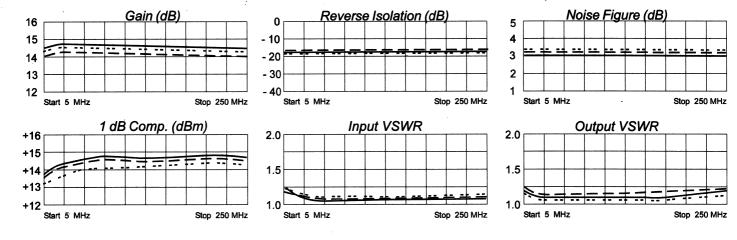
Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	+41 (Typ.)
Third Order Two Tone Intercept Point	+29 (Tvp.)

**Maximum Ratings** 

maximam ratingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S	31		321		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.09	- 92	5.34	-172	.11	10	.10	126
50	.02	179	5.49	173	.12	2	.02	-176
100	.02	128	5.44	163	.12	- 0	.03	-140
150	.03	108	5.44	145	.12	- 1	.04	-131
200	.03	96	5.42	147	.11	- 1	.05	-133
250	.04	71	5.42	138	.12	- 1	.07	-137



Available as: TM7274, 4 Pin TO-8 (T4)

TN7274, 4 Pin Surface Mount (SM3) FP7274, 4 Pin Flatpack (FP4) BX7274.Connectorized Housing (H1)

#### **Features**

■ High Gain: 31 db Typical

■ Medium Output Power: +9.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 300 MHz	5 - 300 MHz
Gain (dB)	31	29 Min.
Power @ 1 dB Comp. (dBm)	+9.5	+8.0 Min.
Reverse Isolation (dB)	- 38	- 36 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3	4.0 Max.
Power Vdc mA	+15 40	+15 44 Max.

#### Typical Intermodulation Performance at 25 ° C

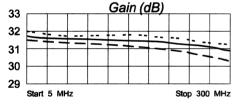
Second Order Harmonic Intercept Point	+37 (Typ.)
Second Order Two Tone Intercept Point	+32 (Typ.)
Third Order Two Tone Intercept Point	+21 (Typ.)

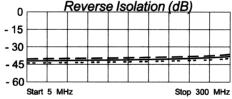
#### **Maximum Ratings**

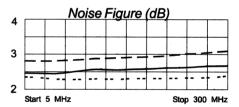
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

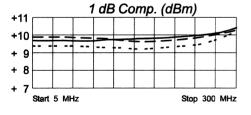
Note: Care should always be taken to effectively ground the case of each unit.

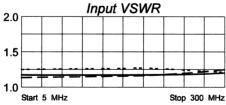
#### **Typical Performance Data**

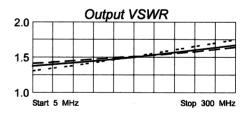












Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.		S11		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.11	-163	36.70	3	.01	7	.17	-174
10	.10	-173	36.76	- 3	.01	4	.17	-177
50	.10	162	36.20	- 24	.01	- 2	.17	177
100	.10	139	36.14	- 49	.01	7	.19	173
200	.10	86	35.42	- 98	.01	19	.23	156
300	.10	12	33.84	-148	.01	8	.26	135
400	.17	- 71	31.35	159	.01	- 2	.29	117



Available as: TM7275, 4 Pin TO-8 (T4)

TN7275, 4 Pin Surface Mount (SM3) FP7275, 4 Pin Flatpack (FP4) BX7275,Connectorized Housing (H1)

#### **Features**

■ High Gain: 20.5 dB Typical

■ Low Noise Figure: <3.0 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	5 - 250 MHz
Gain (dB)	20.5	19.0 Min.
Power @ 1 dB Comp. (dBm)	+9.5	+8.0 Min.
Reverse Isolation (dB)	- 25	- 22 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	3.5 Max.
Power Vdc mA	+15 24	+15 27 Max.

### Typical Intermodulation Performance at 25 ° C

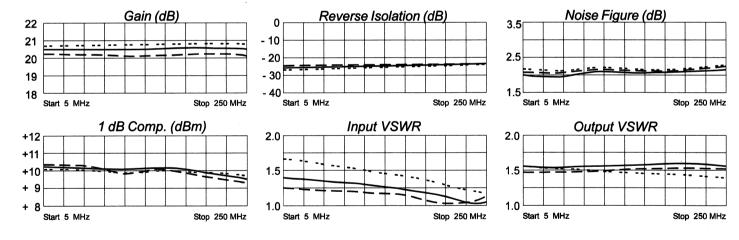
Second Order Harmonic Intercept Point	+33 (Typ.)
Second Order Two Tone Intercept Point	+27 (Typ.)
Third Order Two Tone Intercept Point	+22 (Tvp.)

#### **Maximum Ratings**

waxiiiuiii Natiiigs	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11		S11S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.17	-176	10.65	-178	.06	5	.21	-173
10	.16	179	10.63	179	.06	3	.21	-177
25	.16	173	10.62	173	.06	1	21	-179
50	.15	165	10.61	164	.06	3	.21	-180
100	.13	148	10.61	148	.06	1	.21	-178
150	.10	134	10.62	132	.06	- 1	.22	180
200	.16	115	10.59	114	.07	- 0	.22	176
250	.01	- 34	10.58	97	.07	- 3	.23	169



Available as: TM7277, 4 Pin TO-8 (T4)

TN7277, 4 Pin Surface Mount (SM3) FP7277, 4 Pin Flatpack (FP4) BX7277, Connectrized Housing (H1)

#### **Features**

■ High Output Power: +24 dBm Typical

■ High Third Order Intercept: +41 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	5 - 250 MHz
Gain (dB)	10.5	9.5 Min.
Power @ 1 dB Comp. (dBm)	+24	+20.0 Min.
Reverse Isolation (dB)	- 12.5	- 11.5 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.0	5.0 Max.
Power Vdc mA	+15 70	+15 75 Max.

### Typical Intermodulation Performance at 25 ° C

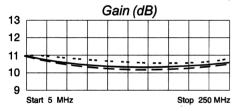
Second Order Harmonic Intercept Point	+54(Typ.)
Second Order Two Tone Intercept Point	+48(Typ.)
Third Order Two Tone Intercept Point	+41(Typ.)

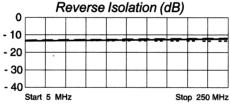
#### **Maximum Ratings**

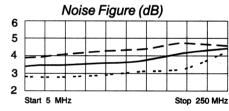
waxiiiuiii italiiigə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

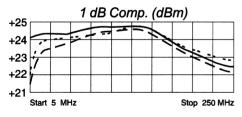
Note: Care should always be taken to effectively ground the case of each unit.

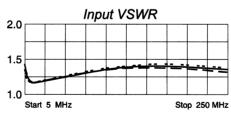
#### **Typical Performance Data**

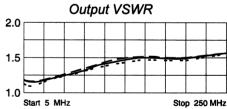












.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.		S11		521		S12	:	S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.15	-105	3.56	-170	<sub>-</sub> 21	-173	.08	-93
10	.09	-118	3.53	-180	.22	179	.07	-125
50	.09	-122	3.43	152	.22	151	.11	-146
100	.14	-126	3.34	123	.22	122	.17	-177
150	.17	-132	3.32	96	.23	96	.20	142
200	.18	-134	3.32	67	.24	70	.21	93
250	.17	-130	3.37	38	.24	47	.24	38



Available as: TM7278, 4 F

TM7278, 4 Pin TO-8 (T4)

TN7278, 4 Pin Surface Mount (SM3)

FP7278, 4 Pin Flatpack (FP4)

BX7278, Connectorized Housing (H1)

#### **Features**

- High Output Power: +21.5 dBm Typical
- High Third Order Intercept: +36 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 300 MHz	5 - 300 MHz
Gain (dB)	13.5	12.5 Min.
Power @ 1 dB Comp. (dBm)	+21.5	+19.0 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.25:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4	5.5 Max.
Power Vdc mA	+15 65	+15 75 Max.

### Typical Intermodulation Performance at 25 ° C

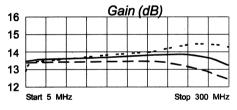
Second Order Harmonic Intercept Point	+55 (Typ.)
Second Order Two Tone Intercept Point	+49 (Typ.)
Third Order Two Tone Intercept Point	+36 (Typ.)

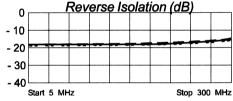
#### **Maximum Ratings**

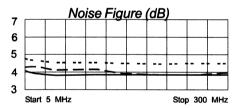
maxima i tatii ge	
Ambient Operating Temperature.	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	· · · · · · · · · · · · · · · · · · ·
	(3 μsec Max.)

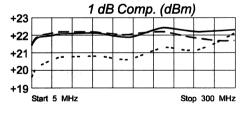
Note: Care should always be taken to effectively ground the case of each unit.

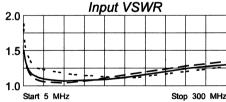
#### **Typical Performance Data**

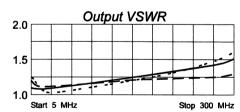












Legend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.20	-92	4.67	-162	.13	6	.07	135
20	.06	-140	4.80	178	.13	2	.05	174
50	.04	160	4.80	165	.13	2	.05	-159
100	.05	97	4.84	147	.14	3	.08	-149
150	.06	44	4.90	128	.14	2	.11	-161
200	.09	2	4.95	108	.15	2	.14	176
250	.12	-37	4.92	85	.16	-2	.16	137
300	.14	-72	4.61	59	.18	-7	.21	84



Available as: TM7279, 4 Pin TO-8 (T4)

TN7279, 4 Pin Surface Mount (SM3)

FP7279, 4 Pin Flatpack (FP4) BX7279, Connectorized Housing (H1)

#### **Features**

- High Output Power: +23 dBm Typical
- High Third Order Intercept: +36 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 300 MHz	5 - 250 MHz
Gain (dB)	14	12.5 Min.
Power @ 1 dB Comp. (dBm)	+23	+21.0 Min.
Reverse Isolation (dB)	- 15.5	- 14.5 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	6.0 Max.
Power Vdc mA	+15 88	+15 95 Max.

### Typical Intermodulation Performance at 25 ° C

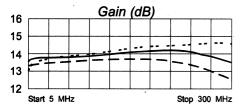
Second Order Harmonic Intercept Point	+52(Typ.)
Second Order Two Tone Intercept Point	+46(Typ.)
Third Order Two Tone Intercept Point	+36(Typ.)

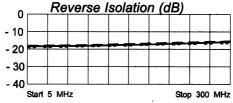
#### **Maximum Ratings**

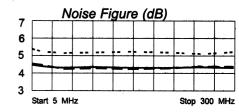
maximum radingo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

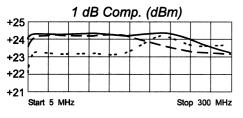
Note: Care should always be taken to effectively ground the case of each unit.

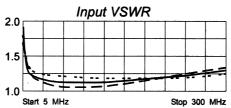
#### **Typical Performance Data**

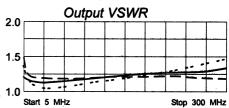












eaend -----+ 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11		1 S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.22	<del>-9</del> 1	4.76	-160	.13	8	.09	137
20	.08	-140	4.92	179	.13	3	.07	171
50	.05	165	4.93	166	.13	2	.07	-173
100	.06	107	4.99	148	.13	2	.08	-161
150	.06	58	5.06	130	.14	1	.11	-166
200	.08	15	5.12	111	.15	Ó	.12	174
250	.11	-28	5.08	89	.16	-3	.14	142
300	.13	-65	4.76	64	.17	-9	.16	91



Available as: TM7281, 4 F

TM7281, 4 Pin TO-8 (T4)

TN7281, 4 Pin Surface Mount (SM3) FP7281, 4 Pin Flatpack (FP4)

BX7281, 4 Pin Flatpack (FP4)
BX7281, Connectorized Housing (H1)

#### **Features**

■ High Gain: 25.5 dB Typical
 ■ Low Noise: 2.2 dB Typical
 ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 300 MHz	20 - 250 MHz
Gain (dB)	25.5	23.0 Min.
Power @ 1 dB Comp. (dBm)	+17.5	+15.5 Min.
Reverse Isolation (dB)	- 32	- 30 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.4	3.3 Max.
Power Vdc mA	+15 30	+15 33 Max.

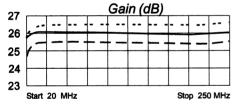
### Typical Intermodulation Performance at 25 ° C

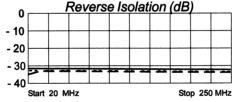
#### **Maximum Ratings**

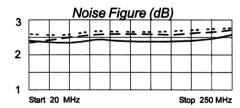
waxiii uiii i tauiige	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

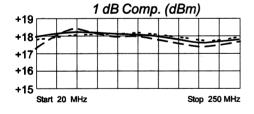
Note: Care should always be taken to effectively ground the case of each unit.

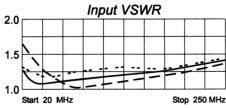
#### **Typical Performance Data**

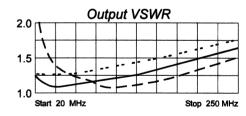












Legend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.		M1		21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.21	- 86	19.49	-162	.02	4	.10	77
20	.10	-104	19.91	-178	.02	2	.06	48
50	.02	175	20.13	161	.02	- 5	.04	- 12
100	.06	75	20.02	134	.02	- 10	.07	- 73
150	.11	47	19.92	109	.02	- 19	.12	-103
200	.14	23	19.79	84	.02	- 26	.17	-128
250	.18	- 4	19.83	59	.02	- 29	.22	-149
300	.21	- 32	19.96	32	.02	- 38	.27	-168



Available as: TM7282, 4 Pin TO-8 (T4)

> TN7282, 4 Pin Surface Mount (SM3) FP7282, 4 Pin Flatpack (FP4)

BX7282, Connectorized Housing (H1)

#### **Features**

■ High Output Power: +21 dBm Typical

High Gain: 23.5 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 250 MHz	20 - 250 MHz
Gain (dB)	23.5	21.0 Min.
Power @ 1 dB Comp. (dBm)	+21	+18.0 Min.
Reverse Isolation (dB)	- 28	- 27 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.3:1 Max.
Noise figure (dB)	4.0	5.0 Max.
Power Vdc m A	+15 45	+15 50 Max.

### Typical Intermodulation Performance at 25 ° C

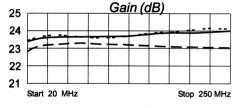
Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+34 (Typ.)

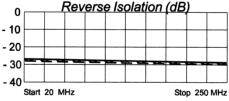
#### **Maximum Ratings**

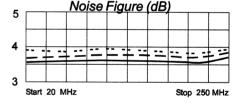
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

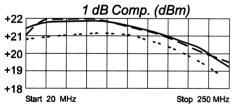
Note: Care should always be taken to effectively ground the case of each unit.

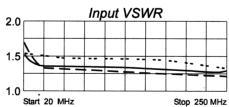
#### **Typical Performance Data**

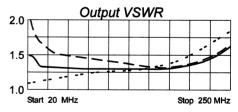












#### Linear S-Parameters

FREQ.	REQS11		S11S21		S21	S12		S22	
MHz	Mag D	eg	Mag	Deg	Mag	Deg	Mag	Deg	
10		94	14.03	-148	.03	19	.34	112	
20	.22 -1	128	14.93	-171	.03	6	.19	99	
50	.16 -1	168	15.15	164	.03	- 5	.13	76	
100	.15 1	157	15.21	136	.03	- 13	.13	38	
150	.13 1	127	15.31	111	.03	- 23	.13	- 9	
200	.12	91	15.46	84	.03	- 38	.15	- 69	
250	.10	40	15.34	56	.03	- 51	.24	-129	
300	.12 -	34	14.77	25	.02	- 69	.41	-173	



Available as: TM7286, 4 Pin TO-8 (T4)

TN7286, 4 Pin Surface Mount (SM3) FP7286, 4 Pin Flatpack (FP4)

BX7286, Connectorized Housing (H1)

#### **Features**

■ Low Noise: <2.5 dB Typical

■ Medium Output Power: >+8 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	10 - 200 MHz
Gain (dB)	28	26.0 Min.
Power @ 1 dB Comp. (dBm)	+8	+7.0 Min.
Reverse Isolation (dB)	- 38.5	- 37 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<2.5	3.5 Max.
Power Vdc mA	+5 21	+5 24 Max.

### Typical Intermodulation Performance at 25 ° C

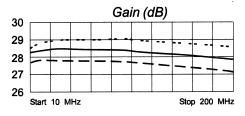
Second Order Harmonic Intercept Point	+34 (Typ.)
Second Order Two Tone Intercept Point	+28 (Typ.)
Third Order Two Tone Intercept Point	+20 (Typ.)

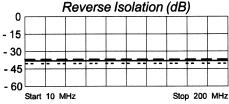
#### **Maximum Ratings**

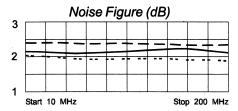
Ambient Operating Temperature.	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

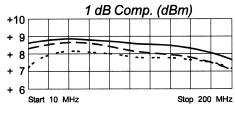
Note: Care should always be taken to effectively ground the case of each unit.

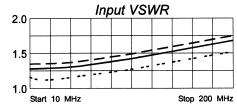
#### **Typical Performance Data**

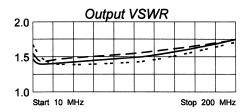












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.13 27	25.53 11	.01 21 ·	.24 160
10	.13 17	25.96 2	.02 1	.19 164
50	.14 16	26.09 - 28	.01 - 4	.17 -176
100	.18 22	25.93 - 58	.01 -16	.19 -165
150	.22 24	25.16 - 88	.01 4	.23 -159
200	.25 18	24.27 -119	.00 57	.29 -158
250	.31 12	22.40 -150	.01 - 32	.34 -162



Available as: TM7287, 4 Pin TO-8 (T4)

TN7287, 4 Pin Surface Mount (SM3) FP7287, 4 Pin Flatpack (FP4) BX7287,Connectorized Housing (H1)

#### **Features**

■ High Efficiency: 70 mW D.C. with > +10 dBm Output

■ Low Noise Figure: 3.0 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 300 MHz	10 - 300 MHz
Gain (dB)	15.5	14.5 Min.
Power @ 1 dB Comp. (dBm)	+10	+9.0 Min.
Reverse Isolation (dB)	- 20	- 19 Max.
VSWR In Out	<1.5:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.75	4.0 Max.
Power Vdc mA	+5 14.5	+5 16 Max.

#### Typical Intermodulation Performance at 25 ° C

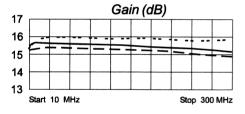
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+24 (Typ.)

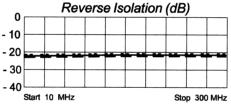
#### **Maximum Ratings**

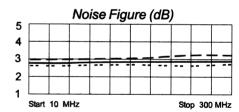
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 usec Max.)

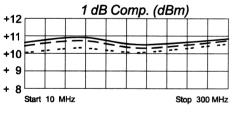
Note: Care should always be taken to effectively ground the case of each unit.

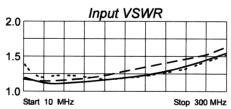
#### **Typical Performance Data**

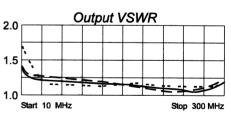












.egend ----- + 25 °C --- + 85 °C ---- -55 °C

#### **Linear S-Parameters**

FREQ.		11		521		S1 <u>2</u>		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.08	-100	6.00	-177	.09	5	.14	153
50	.04	-139	6.10	162	.09	-10	.09	171
100	.04	-112	6.07	141	.10	-21	.08	-179
200	.12	-106	5.96	101	.10	<del>-4</del> 6	.05	-144
300	.23	-147	5.85	57	.10	-75	.10	- 42



Available as: TM7288, 4 Pin TO-8 (T4)

TN7288, 4 Pin Surface Mount (SM3) FP7288, 4 Pin Flatpack (FP4)

BX7288,Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 1.8 dB Typical

■ Medium Output Power: +7.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 250 MHz	5 - 250 MHz
Gain (dB)	22	21 Min.
Power @ 1 dB Comp. (dBm)	+7.5	+6.5 Min.
Reverse Isolation (dB)	- 23	- 22 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.8	2.2 Max.
Power Vdc mA	+15 18	+15 20 Max.

Typical Intermodulation Performance at 25 ° C

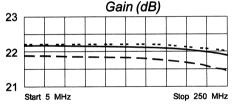
Second Order Harmonic Intercept Point	+29 (Typ.)
Second Order Two Tone Intercept Point	+23 (Typ.)
Third Order Two Tone Intercept Point	+20 (Typ.)

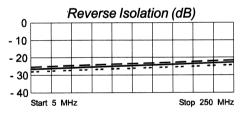
**Maximum Ratings** 

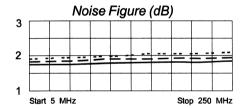
maximam raunge	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

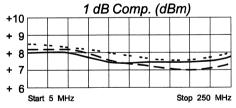
Note: Care should always be taken to effectively ground the case of each unit.

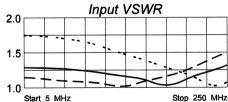
#### Typical Performance Data

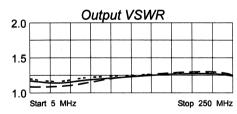












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.13 -176	12.66 -179	.05 4	.08 -172
10	.12 -180	12.68 177	.05 3	.08 -174
50	.11 162	12.68 161	.05 2	.08 -167
100	.08 140	12.60 141	.06 4	.09 -159
150	.04 110	12.53 121	.06 3	.11 -161
200	.05 - 49	12.51 100	.06 - 1	.12 -172
250	14 - 78	12.27 77	.07 - 5	.10 162



Available as: TN7347, 4 Pin TO-8 (T4)

TN7347, 4 Pin Surface Mount (SM3) FP7347, 4 Pin Flatpack (FP4) BX7347, Connectorized Housing (H1)

PN7347, Reduced Size Surface Mount (SM11)

#### **Features**

■ Low Noise Figure: 2.0dB Typical

■ Medium Output: +16dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5-300 MHz	5-300 MHz
Gain (dB)	13.5	12.5 Min.
Power @ 1 dB Comp. (dBm)	+16.0	-22 Min.
Reverse Isolation (dB)	-22	-21 Max.
VSWR In Out	<1.5:1 <1.5:1	1.7:1 Max. 1.5:1 Max.
Noise figure (dB)	2.0	3.0 Max.
Power Vdc mA	+15 45	+15 50 Max.

Typical Intermodulation Performance at 25 ° C

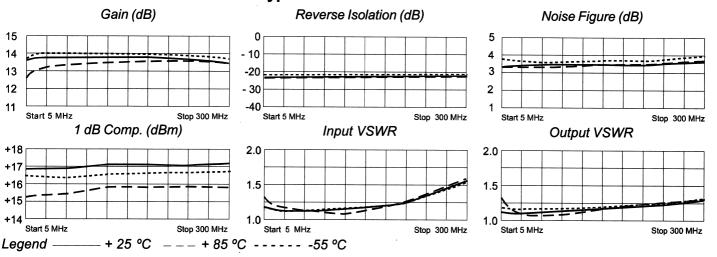
Second Order Harmonic Intercept Point	+50	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+32	(Tvp.)

**Maximum Ratings** 

waxiiiiuiii ixauiiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+13 dBm
Short Term RF Input Power	100 Milliwatts
Maximum Peak Power	0.2 Watt
	(3 µsec Max)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5 20 50 100 150 200 250 300	.19 -98 .10 -150 .09 -168 .07 -162 .07 -141 .11 -135 .16 -141	4.72 -159 4.92 179 4.92 170 4.93 156 4.92 142 4.93 129 4.93 116 4.88 102	.076 -158 .076 178 .077 171 .077 157 .077 145 .077 129 .076 117 .077 107	-27 -18 - 9 - 7 -13 -13 24 55



Available as: TM7370, 4 Pin TO-8 (T4)

TN7370, 4 Pin Surface Mount (SM3)

FP7370, 4 Pin Flatpack (FP4)

BX7370, Connectorized Housing (H1)

#### **Features**

■ High Output Power: +23 dBm Typical

■ Low Noise: 1.9 dBm Typical
■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	20 - 250 MHz	20 - 250 MHz
Gain (dB)	8.5	7.3 Min.
Power @ 1 dB Comp. (dBm)	+23	+20.0 Min.
Reverse Isolation (dB)	- 11.0	- 10.5 Max.
VSWR In Out	<1.25:1 <1.35:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.9	3.4 Max.
Power Vdc mA	+15 45	+15 48 Max.

Note: Care should always be taken to effectively ground the case of each unit.

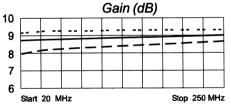
#### Typical Intermodulation Performance at 25 ° C

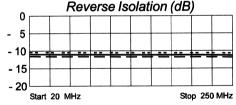
Second Order Harmonic Intercept Point	+55 (Typ.)
Second Order Two Tone Intercept Point	+49 (Typ.)
Third Order Two Tone Intercept Point	+40 (Typ.)

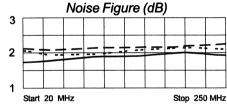
#### **Maximum Ratings**

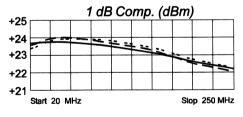
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

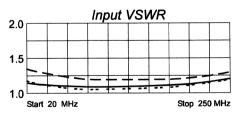
#### **Typical Performance Data**

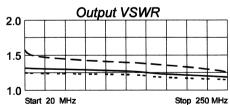












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		311		S21		S12		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.10	126	2.72	6	.27 .27	6 - 10	.17 .13	151 151
50 100	.05 .04	145 155	2.73 2.73	- 10 - 23	.27	- 24	.13	133
150 200	.04 .05	167 -179	2.72 2.74	- 36 - 48	.27 .27	- 36 - 50	.12 .11	117 104
250 300	.08 .14	-171 -177	2.75 2.75	- 61 - 75	.27 .26	- 62 - 76	.10 .08	102 112



Available as: TM7371, 4 Pin TO-8 (T4)

TN7371, 4 Pin Surface Mount (SM3) FP7371, 4 Pin Flatpack (FP4)

BX7371,Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: < 2.0 dB Typical

High Gain: 18 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	1 - 300 MHz	5 - 250 MHz
Gain (dB)	18	16.0 Min.
Power @ 1 dB Comp. (dBm)	+2	+1.0 Min.
Reverse Isolation (dB)	- 21	- 20 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.75	2.5 Max.
Power Vdc mA	+15 9	+15 12 Max.

#### pecinications maximum Ratin

Maximum Ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	

Second Order Two Tone Intercept Point ...... +15 (Typ.)

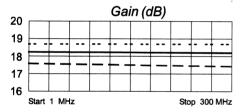
Third Order Two Tone Intercept Point ...... +14 (Typ.)

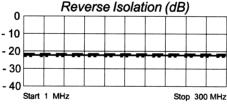
**Typical Intermodulation Performance at 25 ° C**Second Order Harmonic Intercept Point ........... +20 (Typ.)

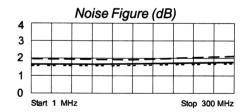
(3 μsec Max.)

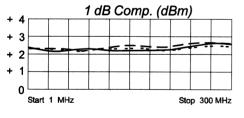
Note: Care should always be taken to effectively ground the case of each unit.

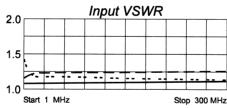
#### **Typical Performance Data**

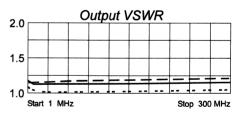












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
1	.06 - 92	8.31 -165	.08 18	.07 -88
5	.02 - 14	8.35 -178	.08 4	.03 - 17
50	.02 - 6	8.32 170	.08 - 0	.03 - 5
100	.03 - 18	8.29 159	.08 - 0	.03 - 23
150	.03 - 27	8.28 149	.08 - 4	.04 - 37
200	.04 - 38	8.26 138	.08 - 4	.04 - 47
250	.04 - 52	8.27 127	.08 - 5	.05 - 64
300	.05 - 74	8.25 117	08 - 7	05 - 76



Available as: TM7379, 4 Pin TO-8 (T4)

TN7379, 4 Pin Surface Mount (SM3) FP7379, 4 Pin Flatpack (FP4)

BX7379, Connectorized Housing (H1)

#### **Features**

■ High Output Power: +23 dBm Typical

■ Medium Gain: 14 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 250 MHz	5 - 200 MHz	
Gain (dB)	14	12.5 Min.	
Power @ 1 dB Comp. (dBm)	+23	+21.0 Min.	
Reverse Isolation (dB)	- 16	- 15 Max.	
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	4.5	6.0 Max.	
Power Vdc mA	+12 88	+12 100 Max.	

Note: Care should always be taken to effectively ground the case of each unit.

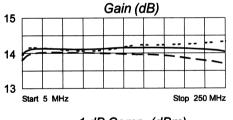
### Typical Intermodulation Performance at 25 ° C

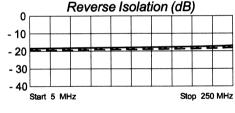
Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+47 (Typ.)
Third Order Two Tone Intercept Point	+38 (Typ.)

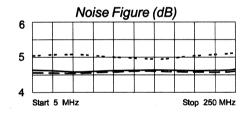
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 15 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	- (3 μsec Max.)

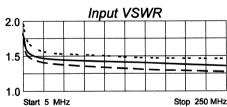
### **Typical Performance Data**

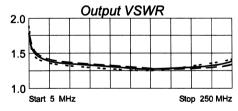












\_egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.29 -117	4.97 -159	.12 19	.28 142
10	.21 -145	5.04 -172	.12 10	.20 151
50	.18 169	5.08 166	.12 5	.15 160
100	.18 145	5.07 149	.13 6	.13 149
150	.17 124	5.09 132	.14 6	.12 147
200	.16 107	5.10 114	.15 5	.12 151
250	.14 89	5.02 96	.16 3	.16 154



Available as: TM7380, 4 Pin TO-8 (T4)

TN7380, 4 Pin Surface Mount (SM3) FP7380, 4 Pin Flatpack (FP4)

BX7380, Connectorized Housing (H1)

#### **Features**

High Gain: 27.5 dB Typical
 Low Noise: 2.2 dB Typical
 Operating Temp. - 55 °C to +85 °C
 Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 200 MHz	10 - 200 MHz
Gain (dB)	27.5	26.0 Min.
Power @ 1 dB Comp. (dBm)	+17.0	+15.0 Min.
Reverse Isolation (dB)	- 32	- 31 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.2	3.0 Max.
Power Vdc mA	+15 28	+15 32 Max.

Typical Intermodulation Performance at 25 ° C

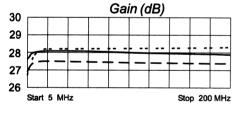
Second Order Harmonic Intercept Point	+40 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+31 (Tvp.)

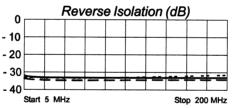
#### **Maximum Ratings**

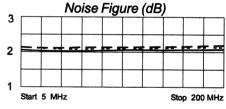
maximam ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

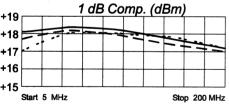
Note: Care should always be taken to effectively ground the case of each unit.

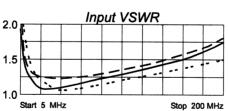
#### **Typical Performance Data**

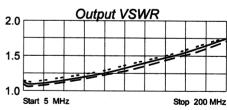












Legend ----- + 25 °C ---- - 55 °C

#### Linear S-Parameters

FREQ.	S11S21S12		-521512		S12 S22	
MHz	Mag Deg Mag Deg Mag Deg				Mag Deg Mag I	
5	.31 - 87	24.07 -156	.03 - 4	.12 - 89		
10	.17 -113	25.12 -172	.02 - 4	.10 -131		
50	.08 140	25.31 156	.02 - 7	.08 -165		
100	.12 83	25.12 128	.02 - 12	.08 -152		
150	.18 43	25.05 100	.02 -23	.13 -138		
200	.26 9	25.03 72	.02 -33	.21 -145		
250	.35 - 25	25.22 42	.02 -48	.28 -158		



Available as: TM7382, 4 Pin TO-8 (T4)

TN7382, 4 Pin Surface Mount (SM3) FP7382, 4 Pin Flatpack (FP4)

BX7382, Connectorized Housing (H1)

#### **Features**

High Reverse Isolation: -32 dB TypicalHigh Output Power: +18 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	20 - 300 MHz	20 - 250 MHz		
Gain (dB)	18	16.0 Min.		
Power @ 1 dB Comp. (dBm)	+17.5	+16.0 Min.		
Reverse Isolation (dB)	- 32	- 30.0 Max.		
VSWR In Out	<1.5:1 <1.2:1	2.0:1 Max. 1.4:1 Max.		
Noise figure (dB)	4.0	5.0 Max.		
Power Vdc mA	+15 45	+15 53 Max.		

Note: Care should always be taken to effectively ground the case of each unit.

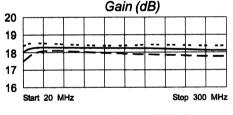
### Typical Intermodulation Performance at 25 ° C

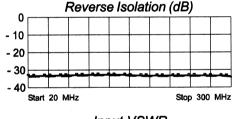
Second Order Harmonic Intercept Point	+37	(Typ.)
Second Order Two Tone Intercept Point	+31	(Typ.)
Third Order Two Tone Intercept Point	+29	(Typ.)

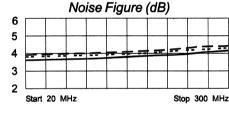
#### **Maximum Ratings**

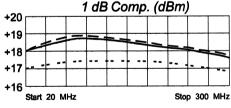
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

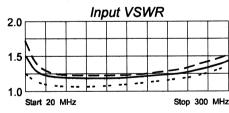
#### **Typical Performance Data**

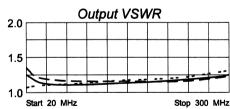












\_egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg	
20	.20 -66	7.99 -167	.02 11	.11 87	
50	.10 -66	8.22 167	.02 - 0	.07 52	
100	.07 -67	8.20 141	.02 - 16	.06 20	
150	.08 -70	8.16 118	.02 - 17	.07 - 11	
200	.10 -72	8.13 95	.02 -28	.07 - 44	
250	.15 -81	8.11 72	.02 -41	.08 - 99	
300	.21 -94	8.00 46	.01 -65	.13 -146	



Available as: TM7481, 4 Pin TO-8 (T4)

TN7481, 4 Pin Surface Mount (SM3)

FP7481, 4 Pin Flatpack (FP4)

BX7481, Connectorized Housing (H1)
PN7481, Reduced Size Surface Mount (SM11)

#### **Features**

■ Low Noise Figure: 2.3 dB Typical

Medium Output Power: 16.5 dBm Typical

Operating Temp. - 55 °C to +85 °C

Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	10 - 300 MHz	15 - 300 MHz		
Gain (dB)	28.0	27.0 Min		
Power @ 1 dB Comp. (dBm)	+16.5	+15.0 Min.		
Reverse Isolation (dB)	32	Max.		
VSWR In Out	1.8:1 1.8:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	2.3	3.0 Max.		
Power Vdc mA	+15 27.0	+15 32.0 Max.		

#### Typical Intermodulation Performance at 25 ° C

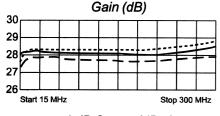
Second Order Harmonic Intercept Point	+39	(Typ.)
Second Order Two Tone Intercept Point	+33	(Typ.)
Third Order Two Tone Intercept Point	+29	(Typ.)

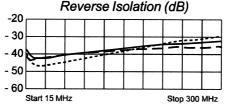
#### **Maximum Ratings**

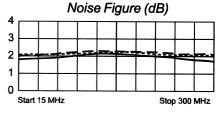
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 17 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

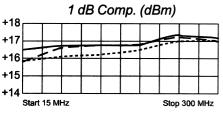
Note: Care should always be taken to effectively ground the case of each unit.

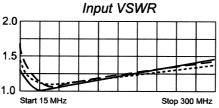
#### **Typical Performance Data**

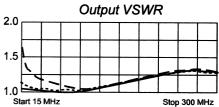












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S	11	\$21		S12		S22	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
15	.25	- 80	25.44	- 163	.0220	 - 2	.04	
50	.02	95	26.48	158	.0213	- 3	.03	
100	.12	57	26.03	129	.0223	- 7	.04	
150	.19	35	25.57	103	.0231	- 11	.09	
200	.25	13	25.36	77	.0233	- 21	.15	
250	.29	- 11	25.61	50	.0232	- 30	.19	
300	.33	- 41	26.53	21	.0231	- 37	.21	



Available as: TM7487, 4 Pin TO-8 (T4)

TN7487, 4 Pin Surface Mount (SM3) FP7487, 4 Pin Flatpack (FP4) BX7487, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: <3 dB Typical

■ Low Power Dissipation: 65 mW @ +5 Volts

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
5 - 350 MHz	10 - 300 MHz
15.5	14.5 Min.
+ 8	+ 7.0 Min.
- 20	- 19 Max.
<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
3	4.0 Max.
+5 13	+5 14.5 Max.
	Ta= 25 °C 5 - 350 MHz 15.5 + 8 - 20 <1.5:1 <1.5:1 3 +5

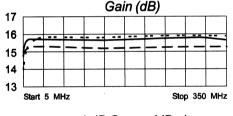
#### Typical Intermodulation Performance at 25 ° C

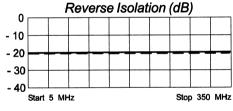
Second Order Harmonic Intercept Point	+36 (Typ.)
Second Order Two Tone Intercept Point	+30 (Typ.)
Third Order Two Tone Intercept Point	+22 (Typ.)

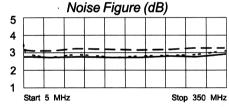
#### **Maximum Ratings**

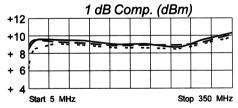
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

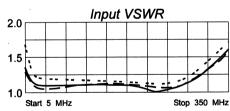
#### **Typical Performance Data**

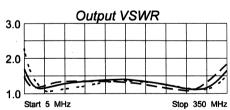












\_egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQS11		S21		S12		S22		
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.19	-72	5.47	-163	.08	18	.27	144
10	.10	-86	5.76	-173	.09	9	.18	142
50	.02	173	6.00	164	.09	-8	.09	-174
100	.04	100	5. <b>9</b> 9	145	.09	-19	.12	-153
150	.04	61	5. <b>9</b> 5	127	.10	-30	.15	-156
200	.02	26	5.96	108	.10	<del>-4</del> 0	.15	-168
250	.03	-136	6.00	89	.10	-53	.10	170
300	.11	-167	6.04	67	.10	-67	.04	58
350	.23	165	5.97	42	.10	-86	.21	-13



Available as: CZ8110, 3 Pin TO-39 (T10)
TN8110-3, 4 Pin Surface Mount (SM3)
FP8110-4, 4 Pin Flatpack (FP4)

BX8110-4, 4 Pin Flatpack (FP4)
BX8110, Connectorized Housing (H1)
PN8110. Reduced Size Surface Mount (SM11)

Pg. 9-3 Pg. 9-6 Pg. 9-8

Pa. 9-10

Pa. 9-8

#### **Features**

■ Low Cost; Medium Gain: 15 dB Typical

■ Low Noise Figure: <4 dB Typical

■ Operating Temp. - 55 °C to + 125 °C

■ Environmental Screening available

#### Specifications\*

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 125 °C		
Frequency	KHz - 400 MHz	KHz - 400 MHz		
Gain (dB)	15	13.0 Min.		
Power @ 1 dB Comp. (dBm)	- 0.2	- 5.0 Min.		
Reverse isolation (dB)	- 19	- 18 Max.		
VSWR in Out	<1.5:1 <2.0:1	2.5:1 Max. 2.5:1 Max.		
Noise figure (dB)	<4.0	5.5 <b>Ma</b> x.		
Power Vdc mA	+3 10	+3 12 Max.		

#### Typical Intermodulation Performance at 25 ° C.

Second Order Harmonic Intercept Point . . . . . +15 (Typ.) Second Order Two Tone Intercept Point . . . . . + 8 (Typ.) Third Order Two Tone Intercept Point . . . . . . +10 (Typ.)

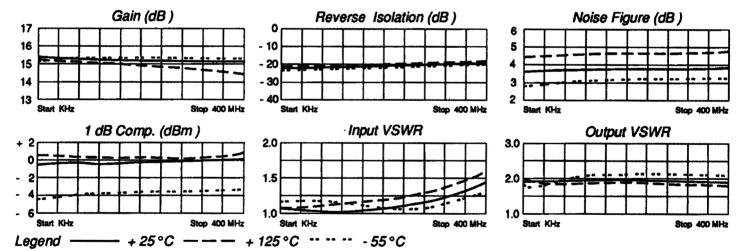
#### **Maximum Ratings**

•	
Ambient Operating Temperature	55 °C to + 125 °C
Storage Temperature	
Case Temperature	
DC Current	
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	
-	(1 Minute Max.)
Maximum Peak Power	0.25 Watt
	(3 μsec Max.)

Decoupling impedance is 1 Kohm

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



The CZB1X0 Series Amplifiers are designed for application in 50 ohm systems. Three external capacitors and a decoupling impedance are required. The decoupling impedance must be large in comparison to the 50 ohm load to minimize gain reduction. Data sheet curves are based on the noted decoupling impedance. The external capacitors determine the low frequency response of the Amplifier.

The CZ81XO Series Amplifiers can be cascaded in series of two or more units without oscillation problems.

# Application information Schematic Diagram Decoupling Impedance Cex CZ8110 So Ohm Output



# RF AMPLIFIER MODEL CZ8120

**Available as:** CZ8120, 3 Pin TO-39 (T10)

TN8120-3, 4 Pin Surface Mount (SM3)

FP8120-4, 4 Pin Flatpack (FP4)

**BX8120, Connectorized Housing (H1)** 

Pg. 9-6 PN8120, Reduced Size Surface Mount (SM11) Pg. 9-8

Pg. 9-1

Pg. 9-8 Pg. 9-3

#### **Features**

■ Low Cost; Medium Gain: 15 dB Typical

■ Medium Output Power: +8 dBm Typical

■ Operating Temp. - 55 °C to + 125 °C

**■** Environmental Screening available

#### Specifications\*

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 125 °C
Frequency	KHz - 400 MHz	KHz - 400 MHz
Gain (dB)	15	13.0 Min.
Power @ 1 dB Comp. (dBm)	+9	+7.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<2.0:1 <2.2:1	2.5:1 Max. 2.5:1 Max.
Noise figure (dB)	<5.0	6.5 Max.
Power Vdc mA	+5 25	+5 28 Max.

Note: Care should always be taken to effectively ground the case of each unit.

### Typical Intermodulation Performance at 25 ° C

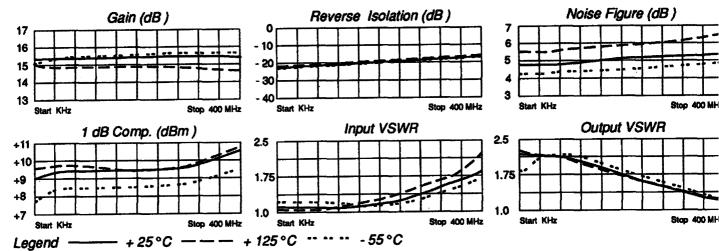
Second Order Harmonic Intercept Point +31	(Typ
Second Order Two Tone Intercept Point +25	(Typ
Third Order Two Tone Intercept Point +21	(Typ

#### **Maximum Ratings**

Ambient Operating Temperature 5	5 °C to + 125 °C
Storage Temperature 6	2 °C to + 125 °C
Case Temperature	+ 125 %
DC Current	
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max
Maximum Peak Power	0.5 Wa
	(3 µsес Мах

Decoupling Impedance is 1 Kohm

#### **Typical Performance Data**



# **Application Information** Schematic Discren CZ8120



Available as: CZ8130, 3 Pin TO-39 (T10) Pg. 9-10 TN8130-3, 4 Pin Surface Mount (SM3) Pg. 9-8

FP8130-4, 4 Pin Flatpack (FP4)

BX8130. Connectorized Housing (H1) Pa. 9-6

PN8130, Reduced Size Surface Mount (SM11) Pg. 9-8

Pa. 9-3

#### **Features**

■ Low Cost; Medium Gain: 14 dB Typical

■ High Output Power: + 18 dBm Typical

■ Operating Temp. - 55 °C to + 125 °C

■ Environmental Screening available

#### Specifications\*

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 125 °C		
Frequency	KHz - 400 MHz	KHz - 400 MHz		
Gain (dB)	14	13.0 Min.		
Power @ 1 dB Comp. (dBm)	+18	+15.0 Min.		
Reverse Isolation (dB)	- 20	- 15.5 Max.		
VSWR In Out	<2.25:1 <2.0:1	3.0:1 Max. 2.5:1 Max.		
Noise figure (dB)	<6.0	7.0 Max.		
Power Vdc mA	+5.75 60	+5.75 65 Max.		

### Typical Intermodulation Performance at 25 ° C.

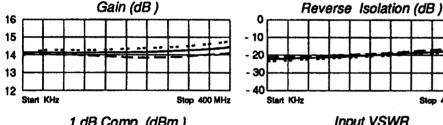
Second Order Harmonic Intercept Point . . . . . . +46 (Typ.) Second Order Two Tone Intercept Point . . . . . . +40 (Typ.) Third Order Two Tone Intercept Point . . . . . . +30 (Typ.)

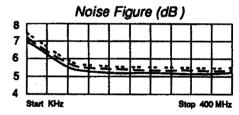
### **Maximum Ratings**

55 °C to + 125 °C
62 °C to + 125 °C
+ 125 °C
100 mA
+ 18 dBm
100 Milliwatts
(1 Minute Max.)
0.5 Watt
(3 μsec Max.)

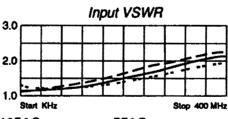
Decoupling Impedance is 330 Ohms

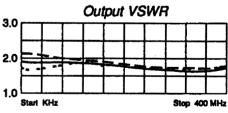
# **Typical Performance Data**











+ 25°C + 125°C Leaend - 55°C

The CZ81X0 Series Amplifiers can be cascaded in series of two or more units without oscillation problems.

# Application information CZ8130

# **Amplifonix**

### Available as: CN8203, 4 Pin Surface Mount (SM3)

# RF AMPLIFIER MODEL CZ8203

#### **Features**

■ High Gain: 20 dB Typical

■ Medium Output Power: +9.5 dBm Typical

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+45 (Typ.)
Second Order Two Tone Intercept Point	+39 (Typ.)
Third Order Two Tone Intercept Point	+21 (Typ.)

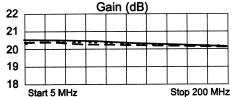
# Specifications Maximum Ratings

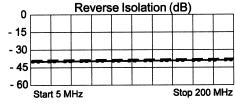
CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	<b>MIN/MAX</b> Ta = -55 °C to +85 °C	
Frequency	5 - 200 MHz	5 - 200 MHz	
Gain (dB)	20	19.0 Min.	
Power @ 1 dB Comp. (dBm)	+9.5	+8.0 Min.	
Reverse Isolation (dB)	- 38	- 36 Max.	
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	6.0	7.0 Max.	
Power Vdc	+15 62	+15 66 Max.	

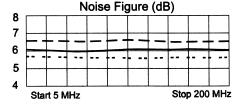
111622111161111111111111111111111111111	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	200 Milliwatts
•	(1 Minute Max.)
Maximum Peak Power	
	(3 usec Max )

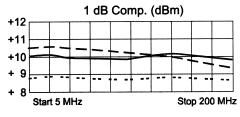
Note: Care should always be taken to effectively ground the case of each unit.

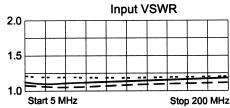
# **Typical Performance Data**

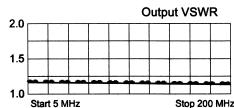












Legend ——— + 25 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.04 -164	10.66 3	.01 6	.06 -17
25	.04 -168	10.64 -7	.01 -5	.06 -7
50	.04 -162	10.61 -15	.01 9	.06 -6
100	.05 -145	10.50 -31	.01 8	.06 -7
150	.06 -134	10.32 -46	.01 17	.06 -10
200	.08 -127	10.14 -62	.01 18	.06 -11



Available as: CZ8205, 4 Pin Surface Mount (SM3)

#### **Features**

- Low Cost: 14 dB Gain Typical
- High Output Power: +21 dBm Typical

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 200 MHz	5 - 200 MHz	
Gain (dB)	13.5	12.0 Min.	
Power @ 1 dB Comp. (dBm)	+21	+19.0 Min.	
Reverse Isolation (dB)	- 20	- 18 Max.	
VSWR In Out	<1.75:1 <1.75:1	2.5:1 Max. 2.0:1 Max.	
Noise figure (dB)	6.0	7.0 Max.	
Power Vdc mA	+15 95	+15 105 Max.	

Note: Care should always be taken to effectively ground the case of each unit.

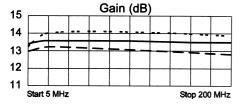
# Typical Intermodulation Performance at 25 ° C

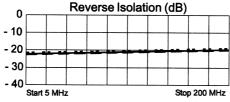
Second Order Harmonic Intercept Point	+35 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+25 (Tvp.)

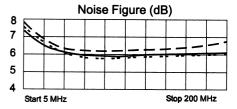
#### **Maximum Ratings**

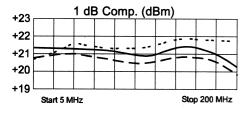
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	( 3 μsec Max.)

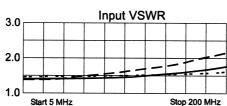
# **Typical Performance Data**

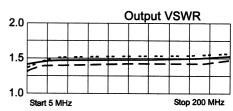












Legend — + 25 °C ---- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ. MHz	S11 Mag- Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.14 -153	4.68 -172	.08 10	.14 47
25	.16 -167	4.99 176	.08 4	.18 - 0
50	.16 -164	5.01 167	.08 4	.18 - 18
100	.19 -159	5.03 152	.09 6	.18 - 46
150	.22 -153	5.04 138	.09 7	.19 - 73
200	.26 -151	5.03 123	.10 8	.20 -102
250	.31 -152	5.02 108	.11 8	.23 -132



#### Available as: CN8206, 4 Pin Surface Mount (SM3)

# RF AMPLIFIER MODEL CZ8206

#### **Features**

- 12 Volt Operation; High Gain: 32 dB Typical
- Low Noise Figure: <3.5 dB Typical

#### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX	
	Ta= 25 °C	Ta = -55 °C to +85 °C	
Frequency	5 - 200 MHz	5 - 200 MHz	
Gain (dB)	32	30.0 Min.	
Power @ 1 dB Comp. (dBm)	+3.5	+1.0 Min.	
Reverse Isolation (dB)	- 42	- 40 Max.	
VSWR In	<1.75:1	2.0:1 Max.	
Out	<1.75:1	2.0:1 Max.	
Noise figure (dB)	<3.5	4.0 Max.	
Power Vdc	+12	+12	
m A	30	35 Max.	

Note: Care should always be taken to effectively ground the case of each unit.

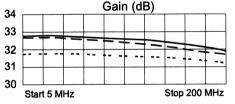
### Typical Intermodulation Performance at 25 ° C

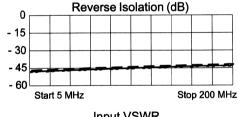
Second Order Harmonic Intercept Point	+32	(Typ.)
Second Order Two Tone Intercept Point	÷26	(Typ.)
Third Order Two Tone Intercept Point	+15	(Typ.)

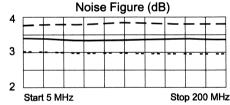
#### **Maximum Ratings**

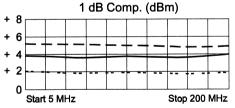
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	( 3 μsec Max.)

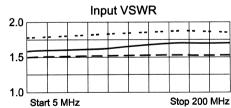
### **Typical Performance Data**

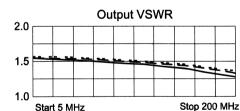












Legend ----- + 25 °C ---- - 55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
5	.22 -170	43.97 3	.01 36	.21 - 3
5Ŏ	.23 -176	43.71 - 22	.01 24	.21 - 12
100	.24 -176	42.78 - 45	.01 - 18	.19 - 14
150	.26 -174	41.88 - 67	.01 5	.18 - 31
200	.25 -179	39.53 - 90	.01 30	.13 - 31
250	.26 -177	36.66 -112	.01 30	.10 - 31
300	.25 -175	33.40 -134	.01 54	.05 - 18



Available as: CN8207, 4 Pin Surface Mount (SM3)

#### **Features**

- 5 Volt Operation
- High Gain: 18 dB Typical

# **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 200 MHz	5 - 200 MHz
Gain (dB)	18	17.0 Min.
Power @ 1 dB Comp. (dBm)	+4	0 Min.
Reverse Isolation (dB)	- 25	- 24 Max.
VSWR In Out	<1.25:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	5.0 Max.
Power Vdc mA	+5 17	+5 21 Max.

Note: Care should always be taken to effectively ground the case of each unit.

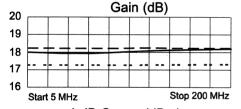
## Typical Intermodulation Performance at 25 ° C

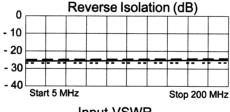
Second Order Harmonic Intercept Point	+23 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+15(Typ.)

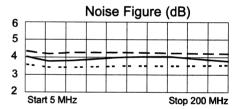
#### **Maximum Ratings**

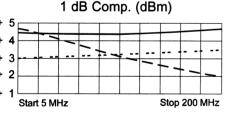
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

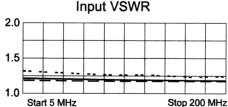
#### **Typical Performance Data**

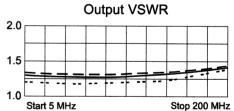












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		S11		521		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.09	-167	7.89	-178	.05	3	.12	-170
25	.09	179	7.87	174	.05	2	.12	-177
50	.09	176	7.88	167	.05	ō	.12	-175
100	.08	174	7.91	153	.05	3	.12	-173
150	.07	178	7.96	139	.06	1	.14	-170
200	.07	-177	8.05	125	.05	5	.17	-168
250	.07	-163	8.13	110	.06	2	.22	-171



Available as: CZ8210, 3 Pin TO-39 (T10)

TN8210-3, 4 Pin Surface Mount (SM3)

FP8210-4, 4 Pin Flatpack (FP4)

BX8210, Connectorized Housing (H1)
PN8210, Reduced Size Surface Mount (SM11)

Pg. 9-6 Pg. 9-6

Pg. 9-1

Pg. 9-8

Pg. 9-3

#### **Features**

■ Low Cost; Medium Gain: 10 dB Typical

■ Noise Figure: <6 dB Typical

■ Operating Temp. - 55 °C to + 125 °C

■ Environmental Screening available

### Specifications\*

CHARACTERISTIC	STIC TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 125 °C
Frequency	KHz - 600 MHz	KHz - 600 MHz
Gain (dB)	10	9.0 Min.
Power @ 1 dB Comp. (dBm)	-3.5	-6.0 Min.
Reverse isolation (dB)	- 15	- 14 Max.
VSWR in Out	<1.75:1 <1.75:1	2.5:1 Max. 2.5:1 Max.
Noise figure (dB)	<6.0	7.5 Max.
Power Vdc mA	+1.8 10	+1.8 12 Max.

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° (

Se	cond Order Harmonic Intercept Point	+14	(Typ
Se	cond Order Two Tone Intercept Point	+ 8	(Typ
Th	ird Order Two Tone Intercept Point	+ 7	(Typ

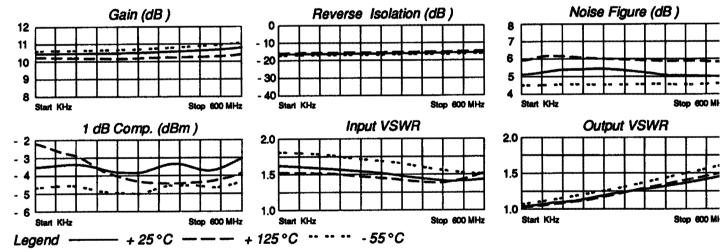
### **Maximum Ratings**

Storage Temperature	- 6	2	°C	to	+	125 °
Case Temperature					+	125°
DC Current						25 m
Continuous RF Input Power	 				. +	6 dBi
Short Term RF Input Power				25	M	illiwat
•						
Maximum Peak Power					0.2	⊵5 Wa
						с Мах

Ambient Operating Temperature . . . . . . . - 55 °C to + 125 °

\* Decoupling Impedance is 1 Kohm

### **Typical Performance Data**



The CZ82X0 Series Amplifiers are designed for application in 50 ohm systems. Three external capacitors and a decoupling impedance are required. The decoupling impedance must be large in comparison to the 50 ohm load to minimize gain reduction. Data sheet curves are based on the noted decoupling impedance. The external capacitors determine the low frequency response of the Amplifier.

The CZ82XO Series Amplifiers can be cascaded in series of two or more units without oscillation problems.

# Application information Schematic Diagram Decoupling Impudance CZ8210 CZ82



Available as: CZ8230, 3 Pin TO-39 (T10)

TN8230-3, 4 Pin Surface Mount (SM3)

FP8230-4, 4 Pin Flatpack (FP4)

BX8230, Connectorized Housing (H1) Pg. 9-6 PN8230, Reduced Size Surface Mount (SM11) Pg. 9-8

Pg. 9-10

Pa. 9-8

Pg. 9-3

#### **Features**

■ Low Cost; Medium Gain: 10 dB Typical

■ High Output Power: +16 dBm Typical

■ Operating Temp. - 55 °C to + 125 °C

■ Environmental Screening available

#### Specifications\*

CHARACTERISTIC		TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 125 °C
Frequenc	y	KHz - 600 MHz	KHz - 600 MHz
Gain (dB)	,	10	9.0 Min.
Power @ Comp. (c		+16	+13.0 Min.
Reverse isolation	ı (dB)	- 14.5	- 32 Max.
VSWR	In Out	<2.5:1 <2.0:1	3.0:1 Max. 2.5:1 Max.
Noise figu	re (dB)	<7.0	8.0 Max.
Power	Vdc mA	+4.5 60	+4.5 66 Max.

# Typical Intermodulation Performance at 25 ° C.

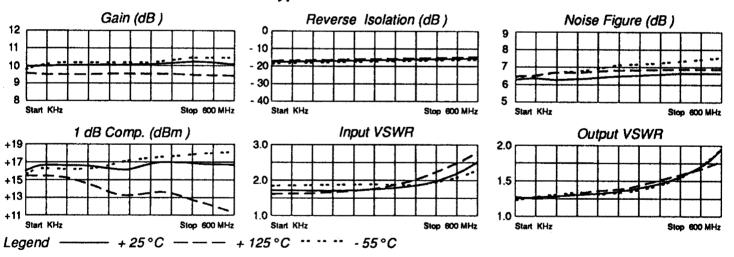
Second Order Harmonic Intercept Point . . . . . +38 (Typ.)
Second Order Two Tone Intercept Point . . . . . +32 (Typ.)
Third Order Two Tone Intercept Point . . . . . . +25 (Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature 55	°C to + 125 °C
Storage Temperature 62	°C to + 125 °C
Case Temperature	
DC Current	100 mA
Continuous RF Input Power	
Short Term RF Input Power	100 Milliwatts
(	1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

Decoupling impedance is 330 Ohms

# **Typical Performance Data**



The CZ82XO Series Amplifiers are designed for application in 50 ohm systems. Three external capacitors and a decoupling impedance are required. The decoupling impedance must be large in comparison to the 50 ohm load to minimize gain reduction. Data sheet curves are based on the noted decoupling impedance. The external capacitors determine the low frequency response of the Amplifier.

The CZ82XO Series Amplifiers can be cascaded in series of two or more units without oscillation problems.

# Application Information Schematic Diagram Decoupling Impedance Cax CZ8230 So Ohm Input CZ8230 So Ohm Output



Available as: CZ8310, 3 Pin TO-39 (T10)

TN8310-3, 4 Pin Surface Mount (SM3) FP8310-4, 4 Pin Flatpack (FP4)

BX8310. Connectorized Housing (H1)

PN8310, Reduced Size Surface Mount (SM11)

Pg. 9-6 Pg. 9-8

(3 µsec Max

Pg. 9-1

Pg. 9-8

Pa. 9-3

#### **Features**

■ Low Cost; Medium Gain: 8 dB Typical

■ Noise Figure: < 7 dB Typical

■ Operating Temp. - 55 °C to + 125 °C

■ Environmental Screening available

#### Specifications\*

CHARACTERISTIC		TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 125 °				
Frequency		KHz - 1000 MHz	KHz -1000 MH:				
Gain (dB)		8	7.0	Min.			
Power @ 1 Comp. (dB	wer @ 1 dB omp. (dBm) -1.5		-4.0	-4.0	Min.		Min.
Reverse Isolation (	dB)	- 13	- 12.0 Max.				
VSWR	In Out	<2.5:1 <2.5:1	3.5:1 3.0:1	Max. Max.			
Noise figure	(dB)	<7.0	8.0	Max.			
Power	Vdc mA	+1.6 10	+1.6 12	Max.			

Note: Care should always be taken to effectively ground the case of each unit.

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+13	(Typ
Second Order Two Tone Intercept Point	+ 8	(Тур
Third Order Two Tone Intercept Point	+ 7	(Typ

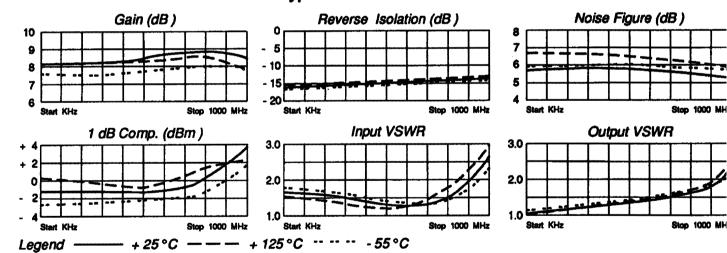
### **Maximum Ratings**

Storage Temperature	 	 	 	- 6	2	°C	to	+1	25 %
Case Temperature	 	 	 					+	125 °
DC Current	 	 	 					. 1	25 m
Continuous RF Input Power.	 	 	 					+	6 dBr
Short Term RF Input Power.	 	 	 	• •		. :	25	Mil	liwatt
•									Max
Maximum Peak Power	 	 	 				(	0.2	5 Wat

Ambient Operating Temperature . . . . . . . - 55 °C to + 125 °C

\* Decoupling Impedance is 1 Kohm

### **Typical Performance Data**



The CZ83XO Series Amplifiers are designed for application in 50 ohm systems. Three external capacitors and a decoupling impedance are required. The decoupling impedance must be large in comparison to the 50 ohm load to minimize gain reduction. Data sheet curves are based on the noted decoupling impedance. The external capacitors determine the low frequency response of the Amplifier.

The CZB3XO Series Amplifiers can be cascaded in series of two or more units without oscillation problems.

# Application information Schematic Diagram Decoupling Impedance Cax Cax Cax So Ohm Input



Available as: CZ8330, 3 Pin TO-39 (T10)
TN8330-3, 4 Pin Surface Mount (SM3)

FP8330-4, 4 Pin Flatpack (FP4)
BX8330. Connectorized Housing (H1)

BX8330, Connectorized Housing (H1) Pg. 9-6 PN8330, Reduced Size Surface Mount (SM11) Pg. 9-8

Pg. 9-10

Pg. 9-8

Pg. 9-3

#### **Features**

■ Low Cost; Medium Gain: 6.2 dB Typical

■ High Output Power: + 14 dBm Typical

■ Operating Temp. - 55 °C to + 125 °C

■ Environmental Screening available

#### Specifications\*

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 125 °C			
Frequency	KHz - 1000 MHz	KHz -1000 MHz			
Gain (dB)	6.2	5.0 Min.			
Power @ 1 dB Comp. (dBm)	+14	+10.0 Min.			
Reverse Isolation (dB)	- 14	- 12.0 Max.			
VSWR In Out	<2.5:1 <2.5:1	3.0:1 Max. 3.0:1 Max.			
Noise figure (dB)	<9.5	11.0 Max.			
Power Vdc mA	+4.5 60	+4.5 65 Max.			

# Typical Intermodulation Performance at 25 ° C.

Second Order Harmonic Intercept Point ......+37 (Typ.)
Second Order Two Tone Intercept Point .....+31 (Typ.)
Third Order Two Tone Intercept Point .....+25 (Typ.)

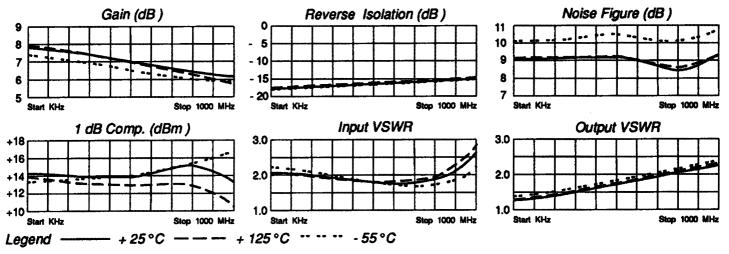
#### **Maximum Ratings**

	•		
<b>Ambient Operating</b>	Temperature	5!	5 °C to + 125 °C
Storage Temperatu	Jre	62	2 °C to + 125 °C
Case Temperature			+ 125 °C
DC Current			100 mA
Continuous RF Inp	ut Power		+ 18 dBm
Short Term RF Inpo	ut Power		. 100 Milliwatts
·		(	(1 Minute Max.)
Maximum Peak Po	wer		0.5 Watt
			(3 μsec Max.)

Decoupling impedance is 330 Ohms

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



The CZB3X0 Series Amplifiers are designed for application in 50 ohm systems. Three external capacitors and a decoupling impedance are required. The decoupling impedance must be large in comparison to the 50 ohm load to minimize gain reduction. Data sheet curves are based on the noted decoupling impedance. The external capacitors determine the low frequency response of the Amplifier.

The CZ83X0 Series Amplifiers can be cascaded in series of two or more units without oscillation problems.

# Application Information Schematic Diagram Decoupling impedance CZ8330 CZ8330



Available as: TM9101, 4 Pin TO-8 (T4)

TN9101, 4 Pin Surface Mount (SM3) FP9101, 4 Pin Flatpack (FP4) BX9101, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 2.4 dB Typical

■ Medium Gain: 15 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+1	-2.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.4	4.0 Max.
Power Vdc mA	+15 9	+15 12 Max.

# Typical Intermodulation Performance at 25 ° C

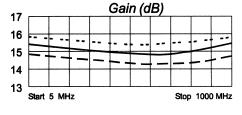
Second Order Harmonic Intercept Point	+20 (Typ.)
Second Order Two Tone Intercept Point	+15 (Typ.)
Third Order Two Tone Intercept Point	+12 (Typ.)

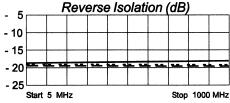
#### **Maximum Ratings**

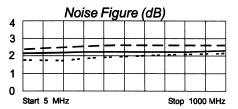
Maximum Naunys	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

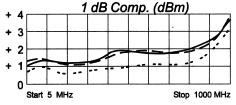
Note: Care should always be taken to effectively ground the case of each unit.

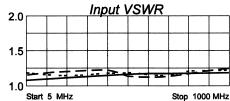
# **Typical Performance Data**

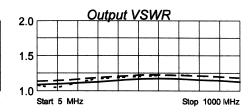












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	\$11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.03 -11	5.89 -178	.11 3	.03 - 23
100	.04 21	5.82 165	.11 - 2	.04 12
200	.05 22	5.76 150	.11 - 6	.04 7
400	.07 14	5.61 121	.11 -12	.07 - 19
600	.08 - 4	5.50 92	.11 -19	.08 - 55
800	.08 -37	5.60 63	.11 -27	.07 - 94
1000	.11 -97	5.94 30	.12 -36	.05 -131



Available as: TM9102, 4 Pin TO-8 (T4)

TN9102, 4 Pin Surface Mount (SM3) FP9102, 4 Pin Flatpack (FP4)

BX9102, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 15 dB Typical

■ Medium Output Power: +10 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	15	13.5 Min.
Power @ 1 dB Comp. (dBm)	+10	+7.5 Min.
Reverse Isolation (dB)	- 17.5	- 16.5 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.0	4.5 Max.
Power Vdc mA	+15 23	+15 25 Max.

# Typical Intermodulation Performance at 25 ° C

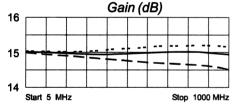
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+23 (Typ.)

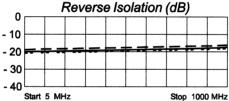
#### **Maximum Ratings**

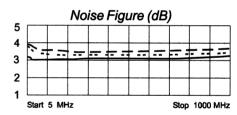
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

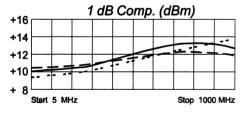
Note: Care should always be taken to effectively ground the case of each unit.

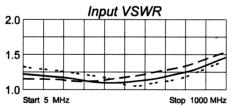
### **Typical Performance Data**

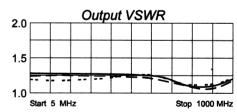












egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ. MHz	: Mag	S11 Deg	: Mag	521 Deg	( Mag	S12 Deg	: Mag	S22 Deg
5	.12	-169	5.58	-178	.10	4	.14	-171
50	.11	179	5.58	172	.10	Ó	.14	169
100	.11	173	5.55	164	.11	- 2	.14	158
200	.10	168	5.52	147	.11	- 5	.14	138
400 600	.07	177	5.43	115	.11	-10	.14	103
600	.08	-163	5.39	83	.12	-18	.13	78
800	.10	-167	5.43	50	.13	-27	.09	78
1000	.08	-169	5.36	13	.14	-36	.17	108



Available as:

TM9106, 4 Pin TO-8 (T4)

TN9106, 4 Pin Surface Mount (SM3) FP9106, 4 Pin Flatpack (FP4)

BX9106, Connectorized Housing (H1)

#### **Features**

■ High Output Power: +19 dBm Typical ■ Medium Noise Figure: < 4.8 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	12	10.5 Min.
Power @ 1 dB Comp. (dBm)	+19	+16.0 Min.
Reverse Isolation (dB)	- 14.5	- 13.5 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.8	6.0 Max.
Power Vdc mA	+15 70	+15 75 Max.

# Typical Intermodulation Performance at 25 ° C

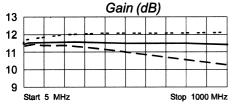
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	+32 (Typ.)
Third Order Two Tone Intercept Point	+27 (Typ.)

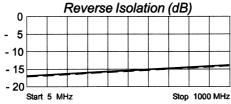
#### **Maximum Ratings**

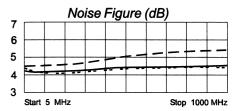
maximam radinge	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

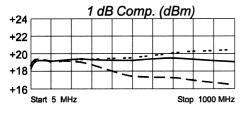
Note: Care should always be taken to effectively ground the case of each unit.

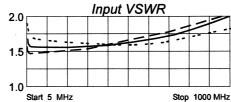
# **Typical Performance Data**

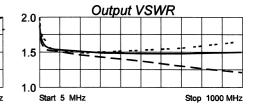












- + 25 °C - - - + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12	S22		
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.27	-133	3.82	-164	.14	16	.30	-172
10	.23	-156	3.88	-173	.15	8	.24	-177
50	.22	-177	3.93	176	.15	2	.22	174
100	.23	179	3.93	168	.15	1	.21	166
200	.22	174	3.92	156	.15	1	.20	152
400	.23	167	3.91	131	.16	0	.20	126
600	.25	160	3.90	105	.17	-2	.19	101
800	.28	149	3.81	79	.18	-5	.19	143
1000	.32	133	3.69	52	.20	-9		83



Available as: TM9107, 4 Pin TO-8 (T4)

TN9107, 4 Pin Surface Mount (SM3) FP9107, 4 Pin Flatpack (FP4) BX9107.Connectorized Housing (H1)

#### **Features**

- 5 Volt Operation
- Medium Output Power: +13 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1200 MHz	5 - 1000 MHz
Gain (dB)	13.5	11.5 Min.
Power @ 1 dB Comp. (dBm)	+13	+10.0 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.5:1 <1.7:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.9	5.0 Max.
Power Vdc mA	+ 5 33	+ 5 36 Max.

# Typical Intermodulation Performance at 25 ° C

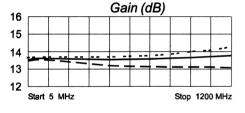
Second Order Harmonic Intercept Point	+32 (Typ.)
Second Order Two Tone Intercept Point	+26 (Typ.)
Third Order Two Tone Intercept Point	+22 (Typ.)

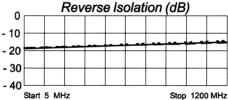
#### **Maximum Ratings**

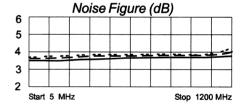
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

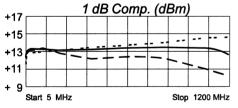
Note: Care should always be taken to effectively ground the case of each unit.

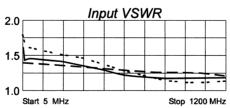
### **Typical Performance Data**

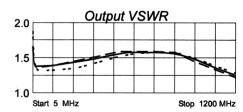












\_egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
	.22 -139	4.82 -168	.12 13	.22 148
10 <sup>ŏ</sup>	.18 -158	4.83 -175	.12 6	.18 158
50	.18 -179	4.90 174	.12 1	.16 159
100	.18 175	4.89 166	.12 -2	.16 146
200	.17 162	4.88 151	.13 -4	.17 118
400	.13 152	4.81 122	.13 -11	.21 73
600	.09 151	4.80 92	.14 -20	.23 34
800	.07 177	4.77 63	.15 -29	.22 -1
1000	.10 -173	4.81 32	.16 -41	.17 -36
1200	11 179	487 -2	17 -54	08 -65



Available as: TM9111, 4 Pin TO-8 (T4)

TN9111, 4 Pin Surface Mount (SM3) FP9111, 4 Pin Flatpack (FP4) BX9111,Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 2.4 dB Typical
 ■ Low VSWR: <1.25:1 Typical</li>
 ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	15	14.0 Min.
Power @ 1 dB Comp. (dBm)	+1	-2.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<1.25:1 <1.25:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.4	4.0 Max.
Power Vdc mA	+15 9	+15 12 Max.

# Typical Intermodulation Performance at 25 ° C

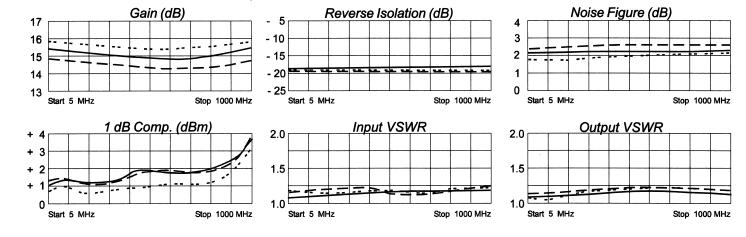
Second Order Harmonic Intercept Point	+20 (Typ.)
Second Order Two Tone Intercept Point	+15 (Typ.)
Third Order Two Tone Intercept Point	+12 (Typ.)

#### **Maximum Ratings**

waxiiiluiii Naliiyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**



# Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
	.03 -11	5.89 -178	.11 3	.03 - 23
100	.04 21	5.82 165	.ii - ž	.04 12
200	.05 22	5.76 150	.11 - 6	.04 7
400	.07 14	5.61 121	.11 -12	.07 - 19
400 600	.08 - 4	5.50 92	.11 -19	.08 - 55
800	.08 -37	5.60 63	.11 <b>-2</b> 7	.07 - 94
1000	.11 - <del>9</del> 7	5.94 30	.12 -36	.05 -131



Available as: TM9112, 4 Pin TO-8 (T4)

TN9112, 4 Pin Surface Mount (SM3) FP9112, 4 Pin Flatpack (FP4) BX9112, Connectorized Housing (H1)

#### **Features**

■ Typical Gain: 16 dB Gain Typical
 ■ Low Noise Figure: <3 dB Typical</li>
 ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

# Specifications

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	16	14.5 Min.
Power @ 1 dB Comp. (dBm)	+11	+9 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	<1.5:1 <1.7:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3	4 Max.
Power Vdc mA	+15 22	+15 22 Max.

# Typical Intermodulation Performance at 25 ° C

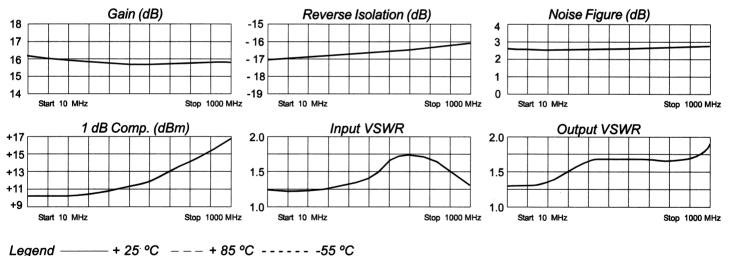
Second Order Harmonic Intercept Point	+35 (Typ.)
Second Order Two Tone Intercept Point	+28 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

# **Typical Performance Data**





Available as:

TM9114, 4 Pin TO-8 (T4)

TN9114, 4 Pin Surface Mount (SM3) FP9114, 4 Pin Flatpack (FP4)

BX9114,Connectorized Housing (H1)

#### **Features**

■ High Gain: 20 dB Typical

■ Medium Output Power: +6.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 1500 MHz	10 - 1500 MHz	
Gain (dB)	20	18.0 Min.	
Power @ 1 dB Comp. (dBm)	+7	+5.0 Min.	
Reverse Isolation (dB)	- 32	- 30 Max.	
VSWR In Out	<1.4:1 <1.4:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<4.0	5.5 Max.	
Power Vdc mA	+12 34	+12 38 Max.	

# Typical Intermodulation Performance at 25 ° C

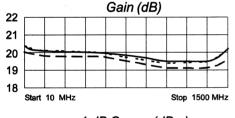
Second Order Harmonic Intercept Point	+47 (Typ.)
Second Order Two Tone Intercept Point	+42 (Typ.)
Third Order Two Tone Intercept Point	+21 (Typ.)

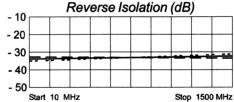
#### **Maximum Ratings**

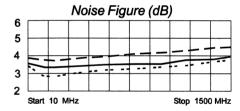
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 15 Volts
Continuous RF Input Power	+ 6 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

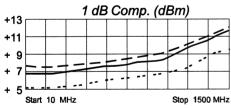
Note: Care should always be taken to effectively ground the case of each unit.

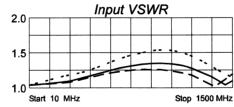
### **Typical Performance Data**

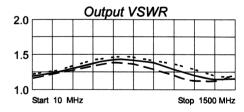












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10 50 100 200 400 600 800 1000 1200 1400 1500	.02 -38 .02 -50 .02 -73 .03 -118 .07 -170 .12 150 .17 113 .18 81 .14 52 .04 28 .04 167	10.48 0 10.26 9 10.18 -18 10.12 36 10.04 -72 10.10 -108 10.10 -145 9.95 178 9.95 141 9.91 105 10.20 84	.02 0 .02 -5 .02 -7 .02 -0 .02 -4 .02 -1 .02 -14 .02 -14 .02 -20 .03 -37 .03 -47	.08 -170 .08 -172 .09 -171 .10 -171 .15 176 .18 151 .19 122 .16 88 .12 47 .08 -56

Amplifonix

Available as:

TM9115, 4 Pin TO-8 (T4)

TN9115, 4 Pin Surface Mount (SM3) FP9115, 4 Pin Flatpack (FP4)

BX9115, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 14.5 dB Typical

■ Medium Output Power: +9.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	14.5	13.0 Min.
Power @ 1 dB Comp. (dBm)	+ 9.5	+ 8.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	< 4	5.5 Max.
Power Vdc m A	+15 24	+15 27 Max.

# Typical Intermodulation Performance at 25 ° C

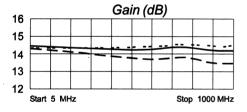
Second Order Harmonic Intercept Point	+38 (Typ.)
Second Order Two Tone Intercept Point	+32 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

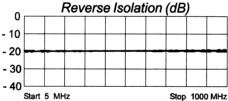
#### **Maximum Ratings**

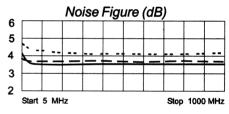
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

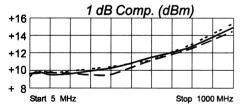
Note: Care should always be taken to effectively ground the case of each unit.

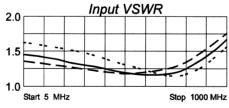
### **Typical Performance Data**

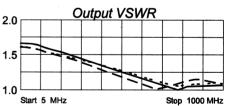












.egend ----- + 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	FREQS11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.18 -172	5.29 -177	.10 4	.24 -172
10	.18 -177	5.29 -180	.10 2	.24 -177
50	.17 174	5.28 172	.10 -1	.23 174
100	.17 168	5.27 163	.10 -2	.23 166
200	.16 156	5.22 146	.10 -3	.21 152
400	.11 138	5.16 112	.10 -8	.15 126
600	.07 153	5.16 79	.11 -15	.08 101
800	.11 178	5.16 42	.12 -24	.01 143
1000	.26 160	5.09 3	.13 -36	.04 83



Available as: TM9117, 4 Pin TO-8 (T4)

TN9117, 4 Pin Surface Mount (SM3) FP9117, 4 Pin Flatpack (FP4) BX9117,Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 12 dB Typical

■ Medium Output Power: +15.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	12	10.0 Min.
Power @ 1 dB Comp. (dBm)	+15.5	+14.5 Min.
Reverse Isolation (dB)	- 14.5	- 13.5 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4	6.0 Max.
Power Vdc mA	+15 46	+15 47 Max.

# Typical Intermodulation Performance at 25 ° C

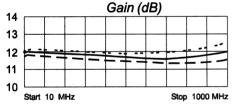
Second Order Harmonic Intercept Point	+46	(Typ.)
Second Order Two Tone Intercept Point	+40	(Typ.)
Third Order Two Tone Intercept Point	+28	(Typ.)

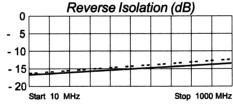
#### **Maximum Ratings**

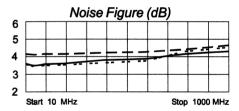
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

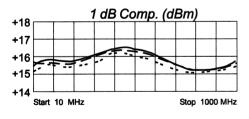
Note: Care should always be taken to effectively ground the case of each unit.

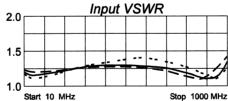
# **Typical Performance Data**

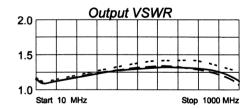












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		S11		321		S12		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.09	-23	3.94	-177	.15	4	.06	59
50	.07	3	3.97	173	.15	-1	.04	-13
100	.08	12	3.96	165	.15	-3	.05	<b>-4</b> 5
200	.10	22	3.95	149	.15	-7	.08	-78
400	.14	17	3.90	118	.15	-14	.13	-121
600	.14	-2	3.87	88	.17	-23	.17	-153
800	.09	-45	3.89	56	.18	-34	.15	170
1000	.16	169	4.01	18	.20	-53	.05	97



Available as: TM9118, 4 Pin TO-8 (T4)

TN9118, 4 Pin Surface Mount (SM3) FP9118, 4 Pin Flatpack (FP4) BX9118, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 14.7 dB Typical

■ Medium Output Power: +16 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 800 MHz	10 - 800 MHz
Gain (dB)	14.7	13.5 Min.
Power @ 1 dB Comp. (dBm)	+16	+15.0 Min.
Reverse Isolation (dB)	- 19	- 18 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	5.5 Max.
Power Vdc mA	+15 45	+15 47 Max.

### Typical Intermodulation Performance at 25 ° C

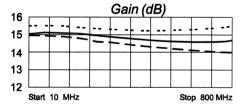
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+26 (Typ.)

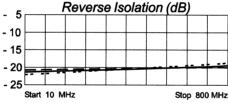
#### **Maximum Ratings**

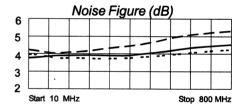
maximum ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

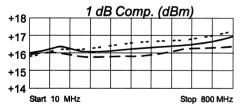
Note: Care should always be taken to effectively ground the case of each unit.

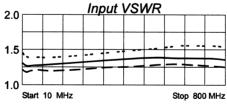
### **Typical Performance Data**

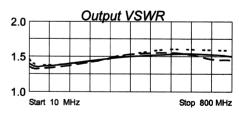












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.17 -155	6.02 -175	.08 6	.17 160
50	.16 176	6.06 173	.09 2	.15 158
100	.16 165	6.03 164	.09 1	.15 143
200	.1 <b>7 148</b>	5.88 147	.09 - 1	.16 114
400	.17 118	5.51 11 <b>6</b>	.10 - 2	.19 67
600	.17 89	5.30 88	.11 - 8	.20 31
800	.17 57	5.34 58	.12 -15	.19 - 2
1000	.13 19	5.53 <b>25</b>	.13 -23	.15 - 21



Available as: TM9119, 4 Pin TO-8 (T4)

TN9119, 4 Pin Surface Mount (SM3) FP9119, 4 Pin Flatpack (FP4) BX9119,Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 9 dB Gain Typical
 ■ High Output Power: +21 dBm Typical
 ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	9	7.0 Min.
Power @ 1 dB Comp. (dBm)	+21	+19.0 Min.
Reverse Isolation (dB)	- 13	- 12 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	8.5	11.0 Max.
Power Vdc mA	+15 100	+15 110 Max.

# Typical Intermodulation Performance at 25 ° C

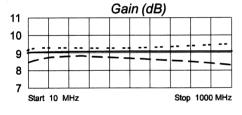
Second Order Harmonic Intercept Point	+45	( <b>Typ.</b> )
Second Order Two Tone Intercept Point	+40	( <b>Typ.</b> )
Third Order Two Tone Intercept Point	+34	(Тур.)

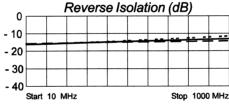
#### **Maximum Ratings**

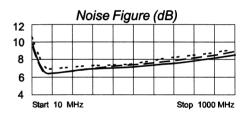
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

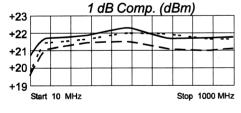
Note: Care should always be taken to effectively ground the case of each unit.

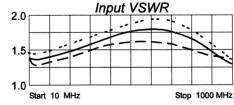
# **Typical Performance Data**

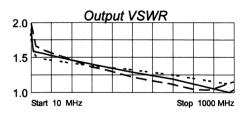












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S Mag	11 Deg	: Mag	S21 Deg	S Mag	S12 Deg	: Mag	S22 Deg
10	.16	-131	2.82	-170	.15	13	.27	154
50	.15	174	2.83	175	.17	2	.22	167
100	.16	154	2.84	167	.17	0	.21	165
300	.22	101	2.84	136	.18	-5	.17	144
500	.27	67	2.83	106	.19	-11	.13	131
700	.27	41	2.83	75	.21	-20	.08	121
900	.19	26	2.85	44	.22	-31	.03	101
1000	.13	38	2.84	27	.22	-39	.02	-47



Available as: TM9121, 4 Pin TO-8 (T4)

TN9121, 4 Pin Surface Mount (SM3) FP9121, 4 Pin Flatpack (FP4)

BX9121, Connectorized Housing (H1)

#### **Features**

- Medium Gain: 15 dB Gain Typical
- Medium Output Power: +13.5 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTE	RISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		10 - 1500 MHz	10 - 1500 MHz
Gain (dB)		15	13.5 Min.
Power @ 1 d Comp. (dE	_	+13.5	+12.0 Min.
Reverse Isolation (d	dB)	- 16	- 15 Max.
VSWR	In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure	(dB)	<4.0	5.0 Max.
Power	Vdc mA	+15 34	+15 37 Max.

# Typical Intermodulation Performance at 25 ° C

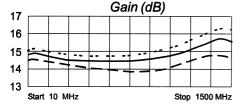
<b>3</b> 1	
Second Order Harmonic Intercept Point	+40 (Typ.)
Second Order Two Tone Intercept Point	+34 (Typ.)
Third Order Two Tone Intercept Point	+26 (Typ.)

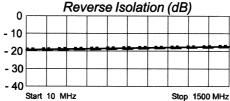
#### **Maximum Ratings**

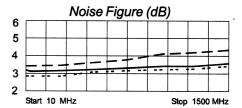
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 µsec Max.)

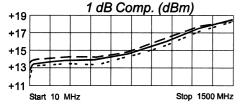
Note: Care should always be taken to effectively ground the case of each unit.

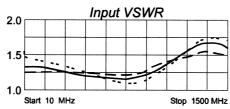
#### **Typical Performance Data**

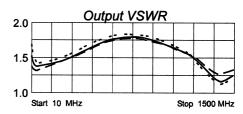












.egend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S Mag	311 Deg	: Mag	S21 Deg	S Mag	S12 Deg	: Mag	S22
	iviag		iviag	Dog	IVIAY	Deg	iviay	Deg
10	.15	-139	5.42	-173	.11	9	.20	148
50	.14	-171	5.56	176	.11	1	.15	150
100	.15	-176	5.57	168	.11	-1	.15	138
250	.13	174	5.48	147	.12	-7	.19	99
500	.08	-178	5.32	115	.12	-16	.25	51
750	.06	-135	5.22	83	.13	-30	.29	9
1000	.13	-103	5.30	50	.13	-42	.25	-29
1250	.21	-112	5.62	12	.13	-52	.16	-82
1500	.19	-130	5.81	<b>-4</b> 0	.17	-66	.14	104



Available as: TM9123, 4 Pin TO-8 (T4)

TN9123, 4 Pin Surface Mount (SM3) FP9123, 4 Pin Flatpack (FP4) BX9123,Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 12 dB Typical

■ Low Noise Figure: <4.0 dB Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	12	10.0 Min.
Power @ 1 dB Comp. (dBm)	+4	+3.0 Min.
Reverse Isolation (dB)	- 16	- 14 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	4.5 Max.
Power Vdc mA	+15 14	+15 16 Max.

Typical Intermodulation Performance at 25 ° C

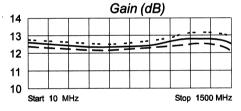
Second Order Harmonic Intercept Point	+28 (Typ.)
Second Order Two Tone Intercept Point	+22 (Typ.)
Third Order Two Tone Intercept Point	+17 (Typ.)

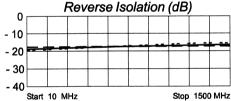
**Maximum Ratings** 

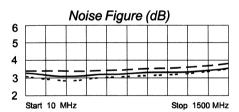
11165411116111111	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

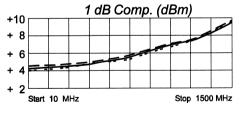
Note: Care should always be taken to effectively ground the case of each unit.

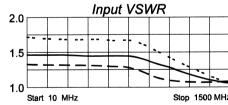
# **Typical Performance Data**

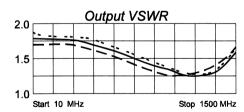












Leaend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	\$ Mag	611 Deg	: Mag	521 Deg	( Mag	S12 Deg	Mag	S22 Deg
. 5	.20	-175	4.00	-178	.13	4	.30	-175
50 <sup>°</sup>	.19	173	3.98	175	.13	- 0	.29	174
100	.19	166	3.95	169	.13	- 0	.29	167
250	.19	143	3.92	153	.13	- 1	.28	147
500	.18	113	3.82	129	.13	- 3	.25	115
800	.18	75	3.80	99	.15	- 9	.19	76
1000	.14	54	3.84	80	.15	- 16	.15	46
1200	.11	34	4.06	59	.16	- 21	.12	- 2
1400	.05	- 1	4.20	33	.16	- 28	.12	- 77
1600	.06	170	4.00	2	16	- 32	20	-144



Available as: TM9124, 4 Pin TO-8 (T4)

TN9124, 4 Pin Surface Mount (SM3) FP9124, 4 Pin Flatpack (FP4) BX9124,Connectorized Housing (H1)

#### **Features**

- High Gain: 20 dB Typical
- Medium Output Power: +8 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	20	18.0 Min.
Power @ 1 dB Comp. (dBm)	+8	+6.0 Min.
Reverse Isolation (dB)	- 32	- 30 Max.
VSWR In Out	<1.4:1 <1.4:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	5.5 Max.
Power Vdc mA	+15 34	+15 38 Max.

# Typical Intermodulation Performance at 25 ° C

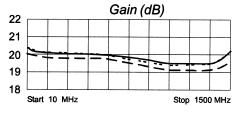
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+21 (Typ.)

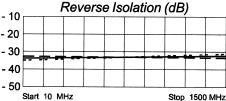
#### **Maximum Ratings**

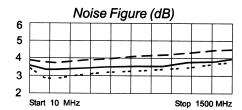
9 1	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

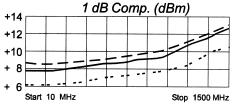
Note: Care should always be taken to effectively ground the case of each unit.

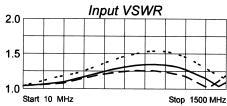
### **Typical Performance Data**

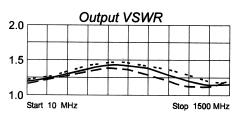












.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ. MHz	S11-			521		S1 <u>2</u>		S22
IVITIZ.	Mag D	eg	Mag	Deg	Mag	Deg	Mag	Deg
10 50 100 200 400 600 800 1000 1200 1400 1500	.02		10.48 10.26 10.18 10.12 10.04 10.10 9.95 9.75 9.91 10.20	-0 -9 -18 -36 -72 -108 -145 178 141 105 84	.02 .02 .02 .02 .02 .02 .02 .02 .03 .03	0 -5 -7 -0 -4 -1 -14 -20 -37 -47 -52	.08 .08 .09 .10 .15 .18 .19 .16 .12 .08	-170 -172 -171 -171 176 151 122 88 47 -14



Available as: TM9125, 4 Pin TO-8 (T4)

TN9125, 4 Pin Surface Mount (SM3)

FP9125, 4 Pin Flatpack (FP4)

BX9125, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 10.5 dB Typical

■ Medium Output Power: +8 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	10.5	9.0 Min.
Power @ 1 dB Comp. (dBm)	+8	+7.0 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	6.0 Max.
Power Vdc mA	+15 24	+15 27 Max.

# Typical Intermodulation Performance at 25 ° C

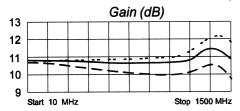
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+21 (Typ.)

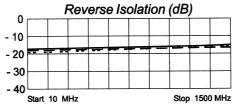
#### **Maximum Ratings**

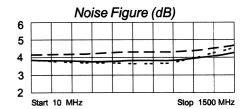
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

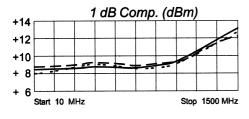
Note: Care should always be taken to effectively ground the case of each unit.

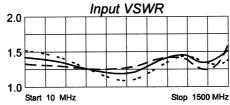
# **Typical Performance Data**

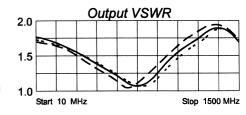












Legend ------ + 25 °C --- + 85 °C ----- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S11S2		21 S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.20	-176	3.61	-180	.13	2	.29	-177
100	.19	173	3.61	167	.13	- 2	.28	170
250	.17	163	3.58	147	.13	- 6	.25	152
500	.11	155	3.48	114	.14	- 14	.16	131
750	.06	174	3.40	82	.14	- 22	.06	146
1000	.09	-132	3.34	47	.15	- 35	.14	-156
1250	.09	-173	3.49	11	.15	- 50	.22	-179
1500	.24	9	3.60	- 48	.16	- 76	.16	160



Available as: TM9126, 4 Pin TO-8 (T4)

TN9126, 4 Pin Surface Mount (SM3)

FP9126, 4 Pin Flatpack (FP4)

BX9126, Connectorized Housing (H1)

#### **Features**

■ High Gain: 20.5 dB Typical

■ Medium Output Power: +15 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	20.5	18.5 Min.
Power @ 1 dB Comp. (dBm)	+15.0	+13.0 Min.
Reverse Isolation (dB)	- 30	- 27 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<5.0	6.0 Max.
Power Vdc mA	+15 64	+15 70 Max.

### Typical Intermodulation Performance at 25 ° C

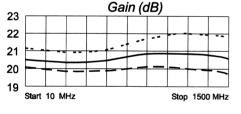
Second Order Harmonic Intercept Point	+51 (Typ	.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+28 (Typ	.)

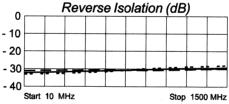
### **Maximum Ratings**

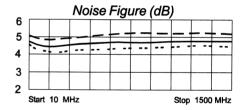
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

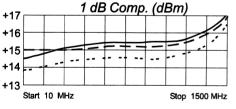
Note: Care should always be taken to effectively ground the case of each unit.

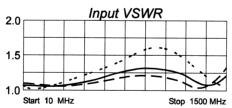
### **Typical Performance Data**

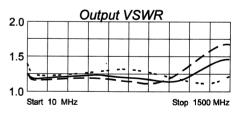












Legend ——— + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S11S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
10	.02 50	10.68 5	.03 8	.12 145	
50	.01 - 33	10.64 - 11	.03 - 1	.08 166	
100	.02 - 74	10.62 - 24	.03 - 8	.08 172	
300	.05 -154	10.50 - 71	.03 - 19	.09 166	
500	.10 156	10.61 -119	.03 - 35	.10 151	
700	.17 110	10.95 -167	.03 - 54	.10 133	
900	.20 65	11.55 143	.03 - 64	.07 117	
1100	.19 20	11.83 89	.03 - 83	.05 146	
1300	.11 - 30	11.55 32	.03 -100	.12 160	
1500	.07 102	10.77 - 27	.03 -125	.21 128	



Available as: TM9127, 4 Pin TO-8 (T4)

TN9127, 4 Pin Surface Mount (SM3) FP9127, 4 Pin Flatpack (FP4) BX9127, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 9 dB Typical

■ Medium Output Power: +16 dBm Typical

- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	9	8.0 Min.
Power @ 1 dB Comp. (dBm)	+16.0	+14.0 Min.
Reverse Isolation (dB)	- 11	- 10 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<6.0	8.0 Max.
Power Vdc mA	+15 52	+15 57 Max.

# Typical Intermodulation Performance at 25 ° C

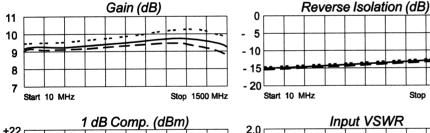
Second Order Harmonic Intercept Point	+48	(Typ.)
Second Order Two Tone Intercept Point	+42	(Typ.)
Third Order Two Tone Intercept Point	+32	(Typ.)

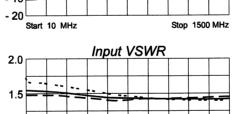
#### **Maximum Ratings**

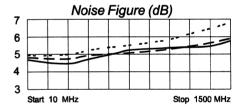
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

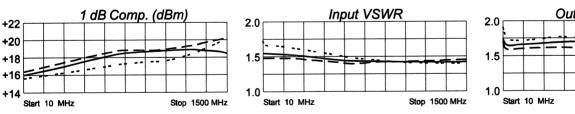
Note: Care should always be taken to effectively ground the case of each unit.

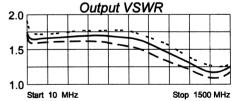
# **Typical Performance Data**











– + 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	S11		S11S21S12		512	S22		
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.23	-156	2.83	-173	.17	9	.28	165
100	.22	178	2.89	168	.18	- 0	.24	162
250	.21	167	2.89	149	.18	- 3	.25	141
500	.19	156	2.92	117	.19	- 9	.25	107
750	17	148	2.92	85	.21	- 17	.24	77
1000	.17	135	2.96	52	.23	- 26	.20	53
1250	17	104	2.95	18	.25	- 39	.13	41
1500	17	48	2.81	- 19	.28	- 53	.11	80
1750	23	- 19	2.43	- 58	.30	- 72	.21	77



Available as: TM9128, 4 Pin TO-8 (T4)

TN9128, 4 Pin Surface Mount (SM3)

FP9128, 4 Pin Flatpack (FP4)

BX9128, Connectorized Housing (H1)

#### **Features**

- Medium Output Power: +15.5 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	11.5	10 Min.
Power @ 1 dB Comp. (dBm)	+15	+13.5 Min.
Reverse Isolation (dB)	- 14.4	- 13.5 Max.
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	6.0 Max.
Power Vdc mA	+15 40	+15 45 Max.

# Typical Intermodulation Performance at 25 ° C

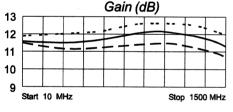
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	+43 (Typ.)
Third Order Two Tone Intercept Point	+29 (Typ.)

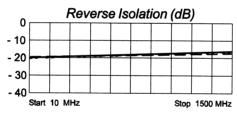
#### **Maximum Ratings**

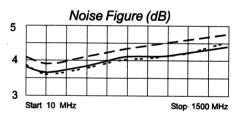
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

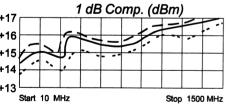
Note: Care should always be taken to effectively ground the case of each unit.

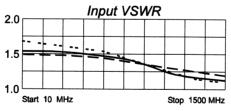
### **Typical Performance Data**

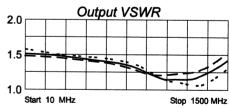












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ. MHz	S Mag	511 Deg	\$ Mag	521 Deg	( Mag	S12 Deg	: Mag	S22 Deg
10	.22	-161	3.85	-174	.14	7	.24	167
50	.22	-177	3.89	176	.15	1	.21	168
100	.22	179	3.90	169	.15	- Ò	.21	163
300	.21	167	3.88	146	.15	- 4	.20	132
500	.20	157	3.92	124	.16	- 8	.19	100
700	.17	149	3.98	100	.16	- 0 -14	.16	100
900	.14	140	4.02	76	.10			67
1100	.10	139	4.04	76 51		-19	. <u>11</u>	25
1300					.17	-24	.07	- 42
	.09	131	3,96	23	.18	-31	.07	-143
1500	.05	128	3.71	- 5	.19	-37	16	167



Available as: TM9129, 4 Pin TO-8 (T4)

TN9129, 4 Pin Surface Mount (SM3) FP9129, 4 Pin Flatpack (FP4) BX9129, Connectrized Housing (H1) PN9129, Reduced Size Surface Mount (SM11)

#### **Features**

- High Output Power: > +24 dBm Typical
- High Third Order Intercept: +34 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

10 - 1500 MHz 8	10 - 1500 MHz 6.0 Min.		
8	6.0 Min.		
>+20.5	+19 Min.		
- 15	-13.0 Max.		
<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.		
<8	9.5* Max.		
+15 95	+15 100 Max.		
	- 15 <1.5:1 <1.5:1 <8 +15		

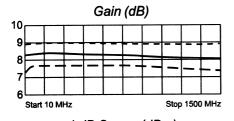
Typical Intermodulation Performance at 25 ° C

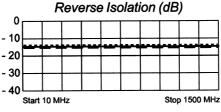
**Maximum Ratings** 

waximum katings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

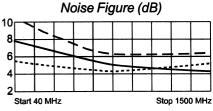
<sup>\*</sup> Noise Figure will be Greater Below 40 MHz

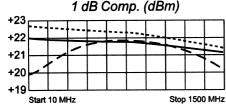
#### und the case of each unit.

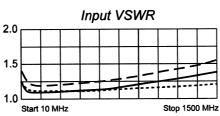


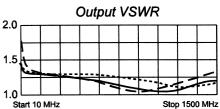


**Typical Performance Data** 









Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		\$22	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	.11	- 81	2.58	-167	.165	10	.19	151
50	.03	- 98	2.64	-180	.168	1	.14	166
100	.02	-118	2.65	176	.169	0	.13	167
250	.02	-141	2.66	167	.171	- 7	.12	163
500	.02	-171	2.64	153	.173	- 15	.10	159
750	.03	177	2.59	139	.167	- 23	.09	152
1000	.04	177	2.54	125	.164	- 31	.08	139
1250	.06	163	2.50	112	.158	- 40	.05	120
1500	.06	161	2.42	99	.144	- 46	.02	25



Available as: T

TM9133, 4 Pin TO-8 (T4)

TN9133, 4 Pin Surface Mount (SM3)

FP9133, 4 Pin Flatpack (FP4)

BX9133, Connectorized Housing (H1)

#### **Features**

- Medium Gain: 9.5 dB Gain Typical
- Low Noise Figure: <4.5 dB Typical</p>
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	9.5	8.0 Min.
Power @ 1 dB Comp. (dBm)	+3	+2.0 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	5.5 Max.
Power Vdc mA	+15 14	+15 16 Max.

# Typical Intermodulation Performance at 25 ° C

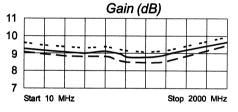
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	+23 (Typ.)
Third Order Two Tone Intercept Point	+16 (Tvp.)

#### **Maximum Ratings**

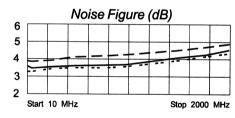
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

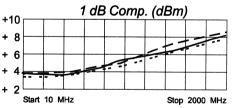
Note: Care should always be taken to effectively ground the case of each unit.

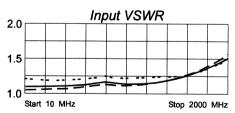
# **Typical Performance Data**

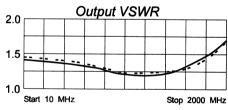












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		511		S21		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.05	-169	2.94	-179	.16	2	.16	-175
50	.05	179	2.94	176	.16	1	.16	175
100	.05	178	2.93	171	.16	-1	.15	170
250	.05	160	2.90	158	.16	-3	.15	149
500	.05	150	2.86	137	.16	-6	.14	120
<b>75</b> 0	.07	141	2.86	116	.17	-10	.12	79
1000	.07	123	2.79	95	.17	-16	.09	44
1250	.08	134	2.83	76	.17	-22	.08	-6
1500	.11	134	2.95	57	.17	-28	.11	-53
1750	.14	138	3.16	36	.16	-33	.16	-89
2000	.19	153	3.42	15	.16	-35	23	-119



Available as: TM9134, 4 Pin TO-8 (T4)

TN9134, 4 Pin Surface Mount (SM3) FP9134, 4 Pin Flatpack (FP4) BX9134,Connectorized Housing (H1)

#### **Features**

■ High Gain: 16.5 dB Gain Typical

■ Medium Output Power: +6 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	16.5	14.0 Min.
Power @ 1 dB Comp. (dBm)	+6	+3.0 Min.
Reverse Isolation (dB)	- 28	- 27 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	6.0 Max.
Power Vdc mA	+15 35	+15 40 Max.

# Typical Intermodulation Performance at 25 ° C

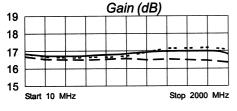
Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+16 (Typ.)

### **Maximum Ratings**

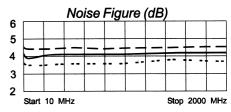
Maxilliulli Nauliyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

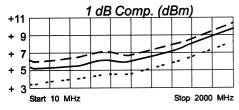
Note: Care should always be taken to effectively ground the case of each unit.

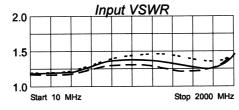
### **Typical Performance Data**

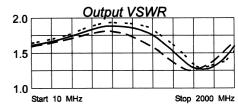












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		31		S21		312		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
.10	.01	-70	6.38	0	.03	4	.19	-174
<del>5</del> 0	0.00	-30	6.28	-8	.03	3	.19	-180
100	0.00	126	6.24	-16	.03	1	.19	178
250	.02	100	6.22	-38	.03	-7	.20	172
500	.05	102	6.32	-38 -77	.03	-10	.24	160
750	.08	93	6.43	-117	.03	-20	.26	141
1000	.10	83	6.49	-156	.03	-31	.27	116
1250	.11	79	6.60	165	.04	-39	.24	88
1500	.11	93	6.81	127	.03	-64	.15	56
1750	.17	111	7.35	87	.03	-68	.04	-13
2000	.32	123	8.70	45	.03	-68	.13	-145



Available as: TM9135, 4 Pin TO-8 (T4)

TN9135, 4 Pin Surface Mount (SM3)

FP9135, 4 Pin Flatpack (FP4)

BX9135, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 10 dB Typical

■ Medium Output Power: +10 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	10	8.5 Min.
Power @ 1 dB Comp. (dBm)	+9	+7.5 Min.
Reverse Isolation (dB)	- 16	- 13 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	6.5 Max.
Power Vdc mA	+15 25	+15 29 Max.

# Typical Intermodulation Performance at 25 ° C

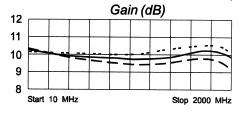
Second Order Harmonic Intercept Point	+41 (Typ.)
Second Order Two Tone Intercept Point	+35 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

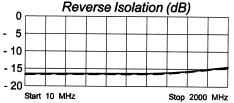
### **Maximum Ratings**

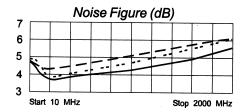
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

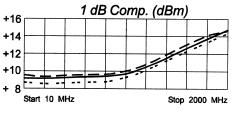
Note: Care should always be taken to effectively ground the case of each unit.

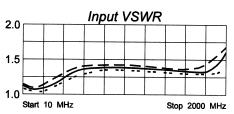
### **Typical Performance Data**

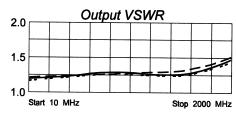












.egend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.07 - 9	3.29 -180	.15 1	07 470
100 100		3.25 168	.15 - 4	.07 -178
200	.07 - 30 .08 - 57	3.22 156	.15 - 4	.08 153
400	.10 - 99	3.13 133	.15 - 7	.08 130
600	.12 -134	3.06 112	.15 - 16	.10 88 .12 53
800	.14 -160	3.01 90	.15 - 24	.12 33
1000	.16 173	2.97 69	.15 - 40	
1200	.16 144	3.02 47	15 - 47	.13 - 2
1400	.16 109	3.10 24	.16 - 56	.13 - 33 .12 - 71
1600	.16 65	3.17 - 1	.17 - 66	
1800	.17 12	3.18 - 29	.18 - 77	.13 -108 .16 -151
2000	23 - 36	3.01 - 61	19 - 92	.10 -131 10 170

**Amplifonix** 

# RF AMPLIFIER TM9136 MODEL

TM9136, 4 Pin TO-8 (T4) Available as:

TN9136, 4 Pin Surface Mount (SM3) FP9136, 4 Pin Flatpack (FP4)

BX9136. Connectorized Housing (H1)

#### **Features**

■ High Gain: 17 dB Typical

■ Medium Output Power: +12 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	17	15.0 Min.
Power @ 1 dB Comp. (dBm)	+12	+11.0 Min.
Reverse Isolation (dB)	- 26	- 25.0 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<5.5	7.5 Max.
Power Vdc mA	+15 63	+15 68 Max.

# Typical Intermodulation Performance at 25 ° C

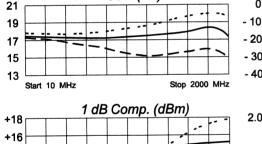
Second Order Harmonic Intercept Point	+33 (Typ.)
Second Order Two Tone Intercept Point	+28 (Typ.)
Third Order Two Tone Intercept Point	+22 (Typ.)

Maximum Ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

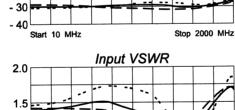
Note: Care should always be taken to effectively ground the case of each unit.

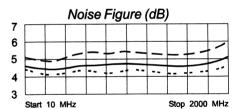
### **Typical Performance Data**

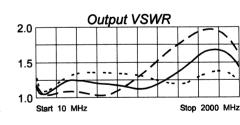
Reverse Isolation (dB)

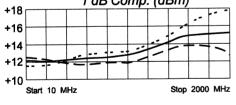


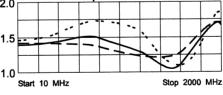
Gain (dB)











— + 25 °C − − − + 85 °C ---- -55 °C

#### Linear S-Parameters

0

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.16 178	7.66 6	.03 9	.08 104
5Õ	.16 179	7.63 - 8	.03 2	.01 151 .02 -123
100	.16 179	7.62 - 19	.03 - 5	
250	.17 175	7.51 - 48	.03 - 6	.07 -141
500	.19 159	7.31 - 95	.03 -11	.10 176
750	.20 138	7.16 -141	.03 -17	.08 122
1000	.18 104	7.24 173	.03 -26	.05 21
1250	.12 66	7.35 126	.03 -44	.11 - 72
1500	.02 22	7.51 76	.03 -50	.20 -126
1750	.12 120	7.85 21	.04 -55	.24 -180
2000	26 42	7.22 - 54	.05 -81	.14 103



Available as: TM9137, 4 Pin TO-8 (T4)

TN9137, 4 Pin Surface Mount (SM3) FP9137, 4 Pin Flatpack (FP4)

BX9137, Connectorized Housing (H1)

#### **Features**

■ Medium Output Power: +15.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 2000 MHz	10 - 2000 MHz	
Gain (dB)	9.5	7.0 Min.	
Power @ 1 dB Comp. (dBm)	+15.5	+13.0 Min.	
Reverse Isolation (dB)	- 9.5	- 8.5 Max.	
VSWR In Out	1.75:1 1.5:1	2.2:1 Max. 2.2:1 Max.	
Noise figure (dB)	6.5	10.0 Max.	
Power Vdc mA	+15 45	+15 50 Max.	

# Typical Intermodulation Performance at 25 ° C

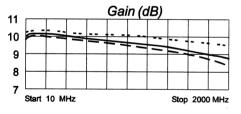
Second Order Harmonic Intercept Point	+44 (Typ.)
Second Order Two Tone Intercept Point	+38 (Typ.)
Third Order Two Tone Intercept Point	+28 (Tvp.)

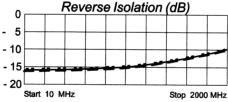
### **Maximum Ratings**

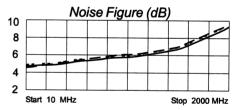
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

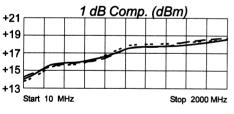
Note: Care should always be taken to effectively ground the case of each unit.

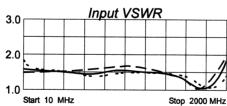
#### **Typical Performance Data**

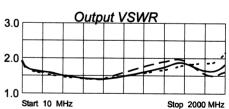












Legend ----- + 25 °C ---- - 55 °C

#### Linear S-Parameters

FREQ. MHz	,	S11		521		S1 <u>2</u>		522
IVITZ.	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.22	-153	3.14	-172	.16	10	.28	163
100	.21	-178	3.21	169	.16	- 1	.24	160
200	.21	179	3.20	156	.16	- 4	.23	144
400	.20	177	3.18	132	.17	- 9	.22	110
600	.19	179	3.15	108	.17	- 15	.20	71
800	.19	-177	3.08	84	.18	- 22	.20	29
1000	.20	-176	3.05	61	.19	- 30	.22	- 14
1200	.21	-179	2.97	37	.21	- 30 - 38	.26	- 56
1400	.20	171	2.93	12	.23	- 49	.28	- 97
1600	.15	155	2.87	- 12	.25	- 62	.30	-140
1800	.05	94	2.88	- 39	.29	- 79	.29	164
2000	.21	- 38	2.96	- 70	.32	-106	.35	<sub>2</sub> 92

**Amplifonix** 

Available as: TM9138, 4 Pin TO-8 (T4)

TN9138, 4 Pin Surface Mount (SM3)

FP9138, 4 Pin Flatpack (FP4)

BX9138, Connectorized Housing (H1)

#### **Features**

- Medium Output Power: +19 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	7.5	6.0 Min.
Power @ 1 dB Comp. (dBm)	+19	+16.5 Min.
Reverse Isolation (dB)	- 9.75	- 9 Max.
VSWR In Out	1.8:1 1.5:1	2.2:1 Max. 2.2:1 Max.
Noise figure (dB)	6.0	9.5 Max.
Power Vdc mA	+15 65	+15 72 Max.

Note: Care should always be taken to effectively ground the case of each unit.

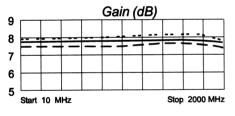
# Typical Intermodulation Performance at 25 ° C

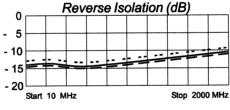
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

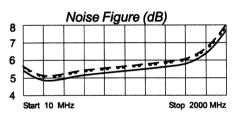
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

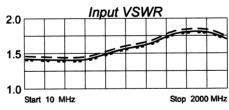
### **Typical Performance Data**

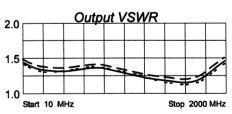












Legend ----- + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		M1		321		S12		S22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.17	-148	2.49	-172	.19	10	.22	157
100	.16	-176	2.56	171	.20	2	.18	158
200	.16	180	2.56	160	.20	1	.17	143
400	.17	176	2.55	139	.20	2	.17	111
600	.17	174	2.53	119	.21	1	.18	80
600 800	.18	172	2.49	100	.22	-1	.17	49
1000	.19	170	2.46	82	.24	-3	.15	15
1200	.21	165	2.45	64	.25	-5	.14	-23
1400	.23	156	2.48	46	.27	-9	.13	-71
1600	.24	144	2.56	28	.30	-12	.16	-121
1800	.24	127	2.67	7	.33	-17	.23	-165
2000	.23	102	2.69	-20	.36	-27	.30	151



Available as: TM9139, 4 Pin TO-8 (T4)

TN9139, 4 Pin Surface Mount (SM3)

FP9139, 4 Pin Flatpack (FP4)

BX9139, Connectrized Housing (H1) PN9139, Reduced Size Surface Mount (SM11)

#### **Features**

High Output Power: > +24 dBm Typical

High Third Order Intercept: +34 dBm Typical

Operating Temp. - 55 °C to +85 °C

**Environmental Screening Available** 

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	8	6.0 Min.
Power @ 1 dB Comp. (dBm)	>+24	+22 Min.
Reverse Isolation (dB)	- 15	-13.0 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<8	9.5 Max.
VSWR Vdc mA	+15 90	+15 95 Max.

# Typical Intermodulation Performance at 25 ° C

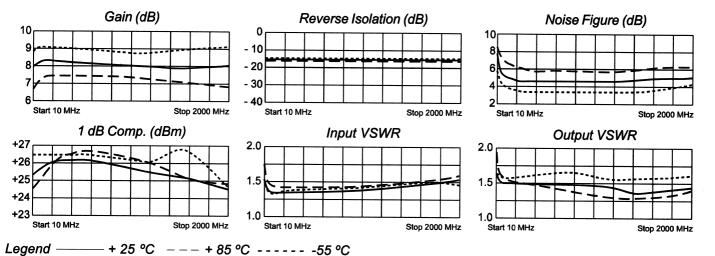
Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+42 (Typ.)
Third Order Two Tone Intercept Point	+35 (Typ.)

#### **Maximum Ratings**

······································	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



#### **Linear S-Parameters**

FREQ.	S11		\$11 \$21		\$12		S22	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	.11	- 80	2.56	-168	.167	9	.17	154
100	.02	- 88	2.61	176	.171	- 1	.13	168
200	.02	-117	2.62	170	.172	- 5	.12	165
400	.02	-149	2.61	159	.172	- 11	.11	159
600	.02	-159	2.61	148	.173	- 16	.10	152
800	.03	-175	2.58	137	.168	- 22	.09	142
1000	.04	176	2.57	126	.168	- 28	.07	127
1200	.04	160	2.55	115	.164	- 33	.06	111
1400	.04	162	2.49	106	.157	- 38	.03	52
1600	.10	156	2.58	96	.173	- 44	.01	95
1800	.10	137	2.56	84	.164	- 53	.04	- 28
2000	.11	132	2.59	72	157	04	00	- 20



Available as: TM9143, 4 Pin TO-8 (T4)

TN9143, 4 Pin Surface Mount (SM3) FP9143, 4 Pin Flatpack (FP4)

BX9143, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 2.5 dB Typical

■ Medium Output Power: +10 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	10.5	9.0 Min.
Power @ 1 dB Comp. (dBm)	+10	+8.0 Min.
Reverse Isolation (dB)	- 11.5	- 11 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	4.5 Max.
Power Vdc mA	+15 25	+15 28 Max.

Note: Care should always be taken to effectively ground the case of each unit.

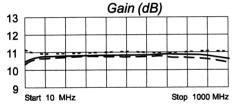
## Typical Intermodulation Performance at 25 ° C

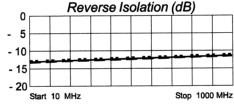
Second Order Harmonic Intercept Point	+44	(Typ.)
Second Order Two Tone Intercept Point	+38	(Typ.)
Third Order Two Tone Intercept Point	+27	(Typ.)

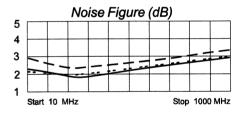
#### **Maximum Ratings**

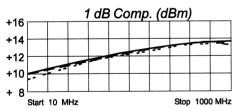
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

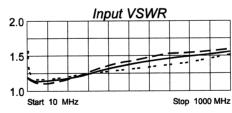
## **Typical Performance Data**

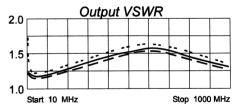












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ. MHz	S	11 Deg	S2 Mag	21 Deg	S1 Mag	2 Deg	-	Mag	22 Deg
10	.06	-83	6.40	-174	.1031	7	\ \	.09	91
100	.05	74	6.37	164	.1050	-2		.04	50
200	.10	63	6.25	147	.1064	-5		.06	33
300	.14	53	6.13	131	.1092	-9		.07	18
400	.18	41	6.02	115	.1115	-13		.08	1
500	.20	30	5.94	99	.1156	-17		.09	-17
600	.21	20	5.88	84	.1213	-22		.08	-36
700	.21	-8	5.86	68	.1231	-27		.08	-52
800	.20	-e	5.91	51	.1305	-32		.07	-69
900	.16	-23	5.95	33	.1337	-39		.05	-79
1000	- 09	-23 -53	6.02	13	.1418	-45		.04	-63



Available as:

TM9144, 4 Pin TO-8 (T4)

TN9144, 4 Pin Surface Mount (SM3)

FP9144, 4 Pin Flatpack (FP4)

BX9144, Connectorized Housing (H1)
PN9144, Reduced Size Surface Mount (SM11)

#### **Features**

■ Low Noise Figure: 3.0 dB Typical

■ Medium Output Power: +13 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	13	12 Min.
Power @ 1 dB Comp. (dBm)	+ 13	+ 11 Min.
Reverse Isolation (dB)	- 16	- 15 Max.
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.0	4.0 Max.
Power Vdc mA	+15 30	+15 35 Max.

## Typical Intermodulation Performance at 25 ° C

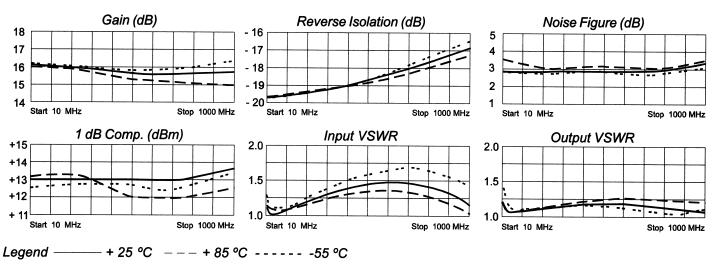
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+25 (Tvp.)

#### **Maximum Ratings**

3 -	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 17 Volts
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

FREQ. MHz	S Mag	511 Deg	S2 Mag	21 Deg	S1 Mag	2 Deg	S Mag	22 Deg
10	.06	-83	6.40	-174	.1031	 7	.09	91
100	.05	74	6.37	164	.1050	-2	.04	50
200	.10	63	6.25	147	.1064	-5	.06	33
300	.14	53	6.13	131	.1092	-9	.07	18
400	.18	41	6.02	115	.1115	-13	.08	1
500	.20	30	5.94	99	.1156	-17	.09	-17
600	.21	20	5.88	84	.1213	-22	.08	-36
700	.21	8	5.86	68	.1231	-27	.08	-52
800	.20	-ē	5.91	51	.1305	-32	.07	-69
900	.16	-23	5.95	33	.1337	-39	.05	-79
1000	.09	-53	6.02	13	.1418	-45	.04	-63



TM9157, 4 Pin TO-8 (T4) Available as:

TN9157, 4 Pin Surface Mount (SM3) FP9157, 4 Pin Flatpack (FP4) BX9157, Connectorized Housing (H1)

#### **Features**

- .3 to 1000 MHz
- Low VSWR: < 1.5:1 Typ.
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	0.3 - 1000 MHz	0.3 to 1000 MHz
Gain (dB)	10.2	8.5 Min.
Power @ 1 dB Comp. (dBm)	+14	+13 Min.
Reverse Isolation (dB)	- 18	- 15 Max.
VSWR In Out	<1.2:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	6.0 Max.
Power Vdc mA	+15 44	+15 48 Max.

Note: Care should always be taken to effectively ground the case of each unit.

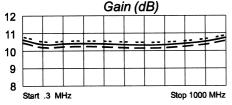
## Typical Intermodulation Performance at 25 ° C

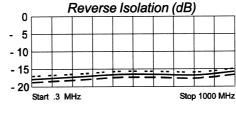
Second Order Harmonic Intercept Point+43	(Typ.)
Second Order Two Tone Intercept Point+37	(Typ.)
Third Order Two Tone Intercept Point+27	(Typ.)

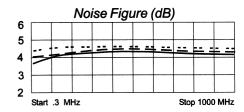
#### **Maximum Ratings**

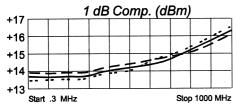
Ambient Operating Temperating	erature55°C to + 100 °C
	62°C to + 125 °C
	+ 125 °C
	+ 18 Volts
	er+ 13 dBm
	er 50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

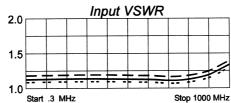
## **Typical Performance Data**

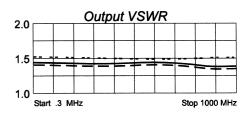












#### Linear S-Parameters

FREQS11		3iF		521	S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
3	.02	- 2	3.45	-178	.13	3	.19	-158
5	.05	2	3.36	179	.13	- 0	.20	-179
50	.05	Ō	3.35	173	.13	- 1	.20	177
100	.05	- 5	3.33	166	.13	- 1	.20	176
200	.05	- 10	3.32	152	.13	- 4	.19	172
400	.06	- 34	3.32	125	.13	- 8	.19	169
600	.07	- 73	3.32 3.35	97	.14	- 13	.18	168
800	.09	-121	3.42	68	.15	- 21	.19	164
1000	.15	-171	3.50	36	.16	- 28	.18	158



Available as: TM9163, 4 Pin TO-8 (T4)

TN9163, 4 Pin Surface Mount (SM3) FP9163, 4 Pin Flatpack (FP4) BX9163, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 16 dB Gain Typical

■ Low Noise Figure: <2.5 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		5 - 1000 MHz
Trequency	5 - 1000 MHz	5 - 1000 MHZ
Gain (dB)	16	15.0 Min.
Power @ 1 dB Comp. (dBm)	+5	+3.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In	<1.25:1	2.0:1 Max.
Out	<1.5:1	2.0:1 Max.
Noise figure (dB)	<2.5	3.5 Max.
Power Vdc	+15	+15
mA	14	16 Max.

## Typical Intermodulation Performance at 25 ° C

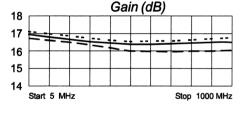
Second Order Harmonic Intercept Point	+27 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+16 (Typ.)

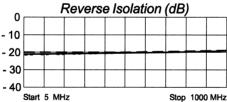
#### **Maximum Ratings**

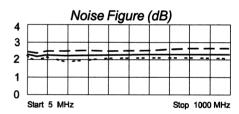
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125°C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
•	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

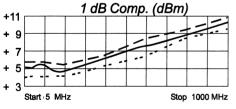
Note: Care should always be taken to effectively ground the case of each unit.

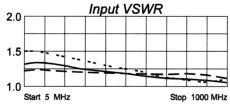
## **Typical Performance Data**

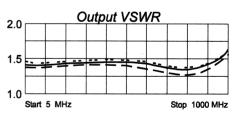












.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQS11		51		521	S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.13	-173	7.07	-177	.09	4	.17	-176
10	.13	-176	7.04	180	.09	2	.16	179
50	.14	177	6.96	171	.09	- 1	.15	167
100	.13	173	6.91	163	.09	- 0	.16	153
200	.12	166	6.80	146	.09	- 4	.17	128
400	.08	161	6.64	113	.10	- 11	.18	91
600	.06	173	6.55	80	.10	- 18	.17	69
800	.05	174	6.59	45	.11	- 25	.15	73
1000	.02	75	6.56	3	.12	- 36	.27	86



Available as: TM916

TM9164, 4 Pin TO-8 (T4)

TN9164, 4 Pin Surface Mount (SM3) FP9164, 4 Pin Flatpack (FP4)

BX9164, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 3.6 dB Typical

High Gain: 26 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1200 MHz	10 - 1200 MHz
Gain (dB)	26	24.0 Min.
Power @ 1 dB Comp. (dBm)	+8.5	+6.5 Min.
Reverse Isolation (dB)	- 34	- 33 Max.
VSWR In Out	<1.6:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.6	4.5 Max.
Power Vdc mA	+15 35	+15 40 Max.

Maximum Ratings

Second Order Harmonic Intercept Point	+39 (Typ.)
Second Order Two Tone Intercept Point	+33 (Typ.)
Third Order Two Tone Intercept Point	+20 (Typ.)

Typical Intermodulation Performance at 25 ° C

Ambient Operating Temperature -55°C to + 100 °C

Storage Temperature -62°C to + 125 °C

Case Temperature + 125 °C

DC Voltage + 18 Volts

Continuous RF Input Power + 6 dBm

Short Term RF Input Power 50 Milliwatts

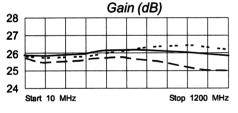
(1 Minute Max.)

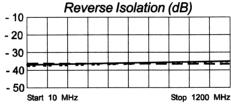
Maximum Peak Power 0.5 Watt

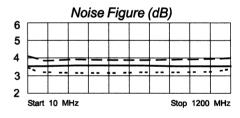
(3 µsec Max.)

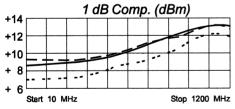
Note: Care should always be taken to effectively ground the case of each unit.

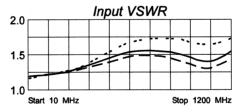
## **Typical Performance Data**

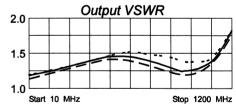












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		311	S21			S12	S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.09	-173	19.73	- 1	۔01	4	.08	-175
50	.09	-178	19.35	- 12	.01	- 0	.09	-171
100	.09	178	19.33	- 24	.01	-6	.10	-168
300	.15	155	19.80	- 72	.01	7	.16	-178
500	.21	123	20.59	-122	.01	- 3	.21	157
700	.25	90	20.46	-176	.01	3	.19	126
900	.22	64	19.55	129	.02	0	.12	109
1100	.16	64	19.09	72	.01	- 5	.15	149
1200	.18	77	19.06	40	.02	- 8	.25	140



Available as:

TM9165, 4 Pin TO-8 (T4)

TN9165, 4 Pin Surface Mount (SM3)

FP9165, 4 Pin Flatpack (FP4)

BX9165, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 10.5 dB Typical

■ Medium Output Power: +11 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	10.5	9.0 Min.
Power @ 1 dB Comp. (dBm)	+11	+9.0 Min.
Reverse Isolation (dB)	- 15.5	- 14 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	6.0 Max.
Power Vdc mA	+15 30	+15 34 Max.

## Typical Intermodulation Performance at 25 ° C

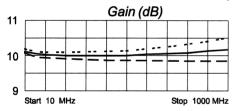
Second Order Harmonic Intercept Point	+42	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+24	(Typ.)

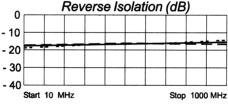
### **Maximum Ratings**

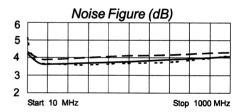
waxiiiluiii Nauiiys	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

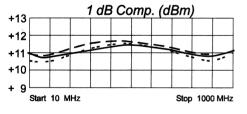
Note: Care should always be taken to effectively ground the case of each unit.

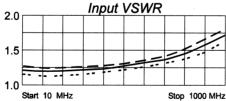
## **Typical Performance Data**

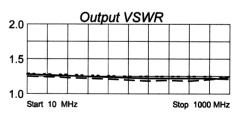












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.10 - 4	3.22 -180	.14 0	.12 -175
5Õ	.09 - 7	3.19 175	.14 - 1	.12 178
100	.09 - 12	3.18 170	.14 - 1	.12 177
300	.10 - 25	3.16 149	.14 - 3	.11 168
500	.12 - 49	3.18 128	.15 - 6	.10 166
700	.16 - 74	3.18 107	.16 -11	.09 167
900	.22 -104	3.24 85	.16 - 18	.09 174
1000	.27 -119	3.26 73	.16 - 20	.09 -179



Available as: TM9166, 4 Pin TO-8 (T4)

TN9166, 4 Pin Surface Mount (SM3) FP9166, 4 Pin Flatpack (FP4)

BX9166, Connectorized Housing (H1)

#### **Features**

■ High Gain: 23.5 dB Typical

■ Medium Output Power: +15 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1200 MHz	10 - 1200 MHz
Gain (dB)	23.5	22.0 Min.
Power @ 1 dB Comp. (dBm)	+15	+13.5 Min.
Reverse Isolation (dB)	- 30.5	- 29 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	5.5 Max.
Power Vdc mA	+15 64	+15 70 Max.

## Typical Intermodulation Performance at 25 ° C

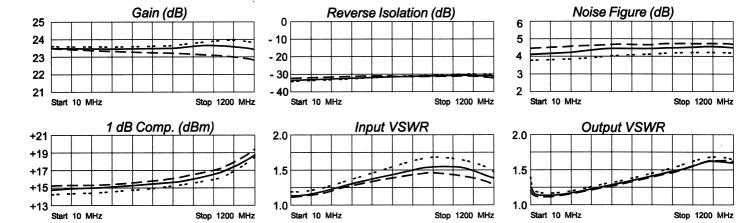
Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+28 (Typ.)

#### **Maximum Ratings**

Maxiiiuiii itauiigə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Leaend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.07 163	14.98 5	.02 8	.11 133
50	.07 179	14.98 - 9	.02 2	.06 161
100	.07 -177	15.03 - 21	.02 2	.06 173
300	.12 171	14.98 - 65	.02 2	.09 165
500	.17 138	14.96 -109	.02 - 3	.14 129
700	.23 100	15.10 -154	.03 - 10	.18 84
900	.24 57	15.11 159	.03 - 19	.21 33
1200	.14 - 25	14.72 82	.03 -41	.23 - 51



Available as: TM9

TM9167, 4 Pin TO-8 (T4)

TN9167, 4 Pin Surface Mount (SM3)

FP9167, 4 Pin Flatpack (FP4)

BX9167, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 12.5 dB Typical

■ Medium Output Power: +15.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 800 MHz	10 - 800 MHz
Gain (dB)	12.5	11.5 Min.
Power @ 1 dB Comp. (dBm)	+15.5	+14.5 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	5.5 Max.
Power Vdc m A	+15 32	+15 35 Max.

## Typical Intermodulation Performance at 25 ° C

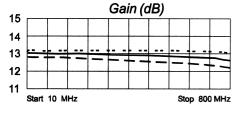
<b>J</b> 1	
Second Order Harmonic Intercept Point	+51 (Typ.)
Second Order Two Tone Intercept Point	+45 (Typ.)
Third Order Two Tone Intercept Point	+30 (Typ.)

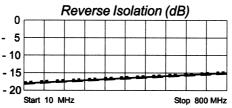
### **Maximum Ratings**

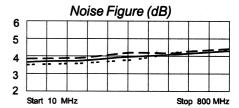
waxiiiluiii Natiiiy5	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

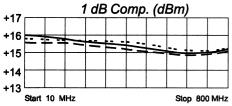
Note: Care should always be taken to effectively ground the case of each unit.

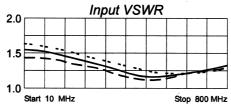
## **Typical Performance Data**

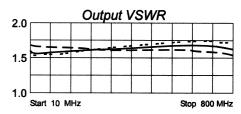












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11		S21	S12		S22		
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.22	-172	4.49	-179	.13	4	.24	177
50	.21	172	4.49	170	.13	- · 1	.23	179
100	.21	161	4.48	159	.13	- 4	.23	177
200	.18	140	4.45	137	.13	- 7	.24	174
400	.11	90	4.42	94	.14	- 17	.24	168
600	.08	- 13	4.38	48	.16	- 32	.25	153
800	.12	-101	4.28	- 3	.18	- 51	.25	109
1000	.09	144	3.65	- 71	.20	- 82	.30	- 23



Available as: TR9169, 4 Pin TO-8B (T8)

RN9169, 4 Pin Surface Mount (SM19) BR9169, Connectorized Housing (H2)

#### **Features**

- High Output Power: +20.5 dBm Typical
- High Third Order Intercept: +33 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	25.5	24.0 Min.
Power @ 1 dB Comp. (dBm)	+20.5	+19.0 Min.
Reverse Isolation (dB)	- 36	- 35 Max.
VSWR In Out	1.6:1 1.7:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	*4.0	*5.5 Max.
Power Vdc mA	+15 125	+15 135 Max.

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+53 (Typ.)
Second Order Two Tone Intercept Point	+48 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

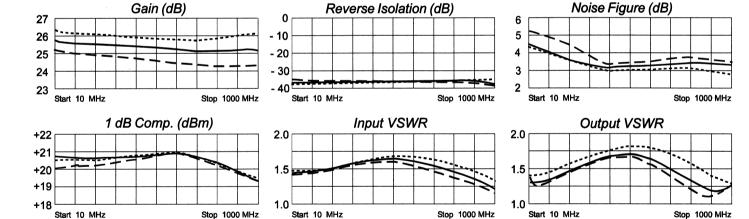
### **Maximum Ratings**

waximum kaungs	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+13 dBm
Short Term RF input Power	50 Milliwatts
·	(1 minute Max.)
Maximum Peak power	0.5 Watt
•	(3 µsec Max.)

<sup>\*</sup> Noise Figure can be Greater below 30MHz.

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S Mag	511 Deg	( Mag	521 Deg	( Mag	612 Deg	( Mag	522 Deg
10	.07	162	19.68	5	.02	8	.10	148
100	.07	176	19.52	- 24	.02	- 0	.12	-145
200	.08	170	19.23	- 49	.02	3	.19	-149
400	.11	146	18.95	- 97	.02	10	.28	-174
600	.15	109	19.35	-145	.02	10	.27	156
800	.15	49	19.52	161	.02	6	.15	138
1000	.13	- 41	19.69	102	.02	- 2	.17	177



Available as: TR9189, 4 Pin TO-8B (T8)

BR9189, Connectorized Housing (H2) RN9189, 4 PIN Surface Mount (SM19)

#### **Features**

■ High Gain: 23 dB Typical

■ High Output Power: > +25 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 400 MHz	10 - 400 MHz
Gain (dB)	23	22.0 Min.
Power @ 1 dB Comp. (dBm)	+25.5	+24.5 Min.
Reverse Isolation (dB)	- 32	-31 Max
VSWR In Out	1.8:1 1.8:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	6.0 Max.
Power Vdc mA	+15 205	+15 220 Max.

## Typical Intermodulation Performance at 25 ° C

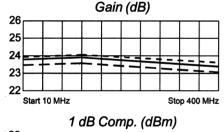
Second Order Harmonic Intercept Point	+50	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+35	(Typ.)

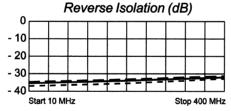
#### **Maximum Ratings**

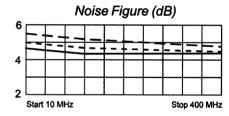
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 95 ℃
DC Voltage	+ 17 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

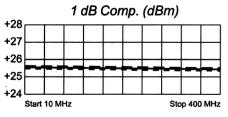
Note: Care should always be taken to effectively ground the case of each unit.

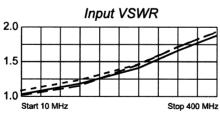
### **Typical Performance Data**

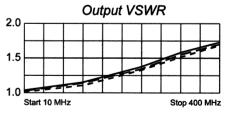












Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11		S21		S12		\$22	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	.09	-167	15.77	3	.0165	5	.10	-110
100	.10	-170	15.75	-51	.0172	- 11	.06	-135
200	.15	-167	15.56	-102	.0184	- 21	.12	-152
300	.20	-178	15.26	-155	.0200	- 36	.19	-176
400	.26	-162	14.72	-152	.0218	- 50	.27	-154



Available as: TM9269, 4 Pin TO-8 (T4)

TN9269, 4 Pin Surface Mount (SM3) FP9269, 4 Pin Flatpack (FP4)

BX9269, Connectorized Housing (H1)

#### **Features**

■ High Gain: 22dB Typical

■ High Output Power: 21 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1300MHz	10 - 1200 MHz
Gain (dB)	22	20 Min.
Power @ 1 dB Comp. (dBm)	+21	+20 Min.
Reverse Isolation (dB)	- 36	- 35 Max.
VSWR In Out	1.7:1 1.7:1	2:1 Max. 2:1 Max.
Noise figure (dB)	4.5	6.0 Max.
Power Vdc mA	+15 130	140 Max.

## Typical Intermodulation Performance at 25 ° C

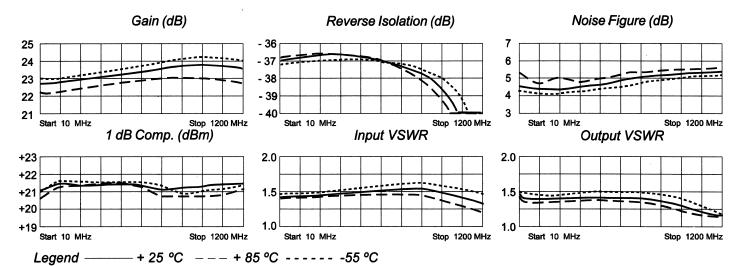
Second Order Harmonic Intercept Point+56	(Typ.)
Second Order Two Tone Intercept Point+50	(Typ.)
Third Order Two Tone Intercept Point+35	(Typ.)

## **Maximum Ratings**

maxiiiiaiiii taaiigo	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 17 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Linear S-Parameters

FREQ.	S11			21		12		<b>322</b>
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.13	164	13.75	14	.0142	9	.21	160
100	.13	177	13.74	- 16	.0145	5	.19	169
200	.14	173	13.81	- 35	.0161	12	.19	162
300	.15	167	14.05	- 54	.0165	11	.19	154
400	.16	158	14.17	- 73	.0154	10	.20	145
500	.17	147	14.46	- 92	.0153	12	.20	132
600	.18	134	14.56	-112	.0147	7	.21	119
700	.18	118	14.70	-131	.0137	12	.22	102
800	.17	99	14.82	-152	.0156	15	.21	83
900	.17	78	14.65	-174	.0178	2	.21	62
1000	.16	50	14.53	165	.0143	11	.22	35
1100	.15	14	14.05	143	.0133	18	.22	10
1200	18	-26	13.70	121	0104	14	22	-21



Available as: TM9302, 4 Pin TO-8 (T4)

TN9302, 4 Pin Surface Mount (SM3) FP9302, 4 Pin Flatpack (FP4)

BX9302, Connectorized Housing (H1) PN9302, Reduced Size Surface Mount (SM11)

#### **Features**

- Medium Output Power: +10 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	1700 - 2300 MHz	1700 - 2300 MHz
Gain (dB)	10.5	9 Min.
Power @ 1 dB Comp. (dBm)	+10	+ <del>9</del> Min.
Reverse Isolation (dB)	- 19	- 17 Max.
VSWR In Out	1.75 1.5	2.0 Max. 2.0 Max.
Noise figure (dB)	> 4	5.5 <b>Ma</b> x.
Power Vdc mA	+15 21	+15 24 Max.

## Typical Intermodulation Performance at 25 ° C

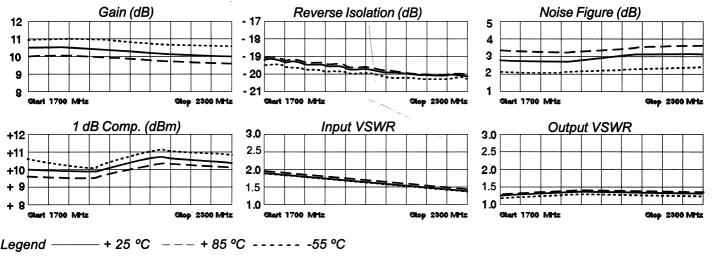
Second Order Harmonic Intercept Point	+34(Typ.)
Second Order Two Tone Intercept Point	+28(Typ.)
Third Order Two Tone Intercept Point	+22(Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 10 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



#### Linear S-Parameters

FREQ. MHz	S Mag	S11 Deg	\$ Mag	S21 Deg	\$ Mag	S12 Deg	: Mag	S22 Deg
1600	.29	177	3.32	79	.1065	- 51	.06	- 43
1700	.28	166	3.35	71	.1042	- 55	.06	- 57
1800	.28	156	3.34	64	.1000	- 60	.07	- 68
1900	.27	144	3.34	56	.1004	- 63	.07	- 88
2000	.27	131	3.30	48	.0968	- 67	.07	-105
2100	.26	116	3.26	41	.0948	- 71	.06	-120
2200	.25	100	3.27	34	.0922	- 76	.05	-128
2300	.24	83	3.28	27	.0942	- 80	.05	-129
2400	.23	65	3.29	19	.0941	- 88	.06	-124



Available as: TM93

TM9311, 4 Pin TO-8 (T4)

TN9311, 4 Pin Surface Mount (SM3) FP9311, 4 Pin Flatpack (FP4)

BX9311, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 2.3 dB Typical ■ Medium Gain: +16.5 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	+2	- 1 Min.
Reverse Isolation (dB)	- 18.5	- 18 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.3	3.0 Max.
Power Vdc mA	+15 10	+15 12 Max.

## Typical Intermodulation Performance at 25 ° C

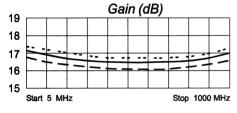
Second Order Harmonic Intercept Point	+23 (Typ.)
Second Order Two Tone Intercept Point	+17 (Typ.)
Third Order Two Tone Intercept Point	+14 (Typ.)

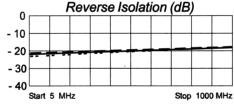
### **Maximum Ratings**

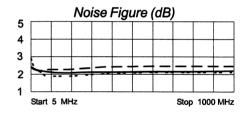
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

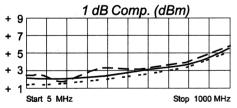
Note: Care should always be taken to effectively ground the case of each unit.

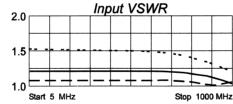
## **Typical Performance Data**

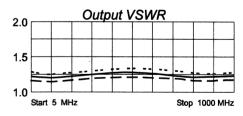












Legend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ.	S11S21		S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
5	.11 -173	7.19 -177	.09 4	.10 -172	
50	.11 173	7.04 172	.09 -0	.09 159	
100	.11 163	6.99 164	.09 -2	.09 140	
200	.11 145	6.89 149	.09 -3	.10 109	
400	.10 115	6.69 120	.10 -8	.12 63	
600	.10 88	6.62 91	.10 -13	.12 29	
800	.08 60	6.76 61	.11 -21	.10 9	
1000	.02 23	7.14 26	.12 -29	.11 4	



Available as: TM9312, 4 Pin TO-8 (T4)

TN9312, 4 Pin Surface Mount (SM3) FP9312, 4 Pin Flatpack (FP4)

BX9312, Connectorized Housing (H1)

#### **Features**

- Low Noise Figure: <3 dB Typical
- Medium Gain: +16.5 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	+7	+5 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	4.0 Max.
Power Vdc mA	+15 18	+15 20 Max.

## Typical Intermodulation Performance at 25 ° C

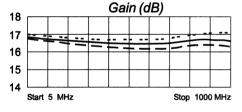
Second Order Harmonic Intercept Point	+30 (Typ.)
Second Order Two Tone Intercept Point	+24 (Typ.)
Third Order Two Tone Intercept Point	+20 (Typ.)

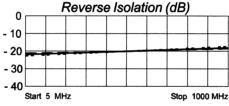
#### **Maximum Ratings**

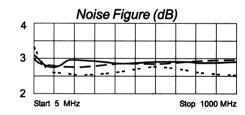
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

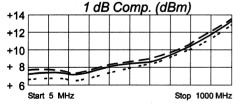
Note: Care should always be taken to effectively ground the case of each unit.

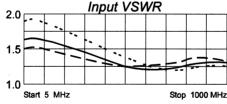
## **Typical Performance Data**

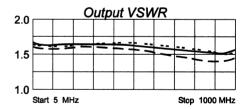












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.24	-174	7.30	-176	.08	4	.26	-176
50	.24	174	6.90	171	.09	- 0	.25	169
100	.23	166	6.88	162	.08	0	.25	160
200	.22	151	6.83	143	.09	- 3	.25	138
400	.15	132	6.69	108	.09	- 12	.24	101
600	.10	145	6.65	71	.10	- 20	.24	69
800	.13	155	6.78	33	.11	- 34	.22	43
1000	.14	120	6.80	- 13	.12	- 48	.23	39



Available as: TM9313, 4 Pin TO-8 (T4)

TN9313, 4 Pin Surface Mount (SM3)

FP9313, 4 Pin Flatpack (FP4)

BX9313, Connectorized Housing (H1)

#### **Features**

■ Medium Gain 16 dB Typical

■ Medium Output Power: +12 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	16	15.0 Min.
Power @ 1 dB Comp. (dBm)	+12	+10.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.5	4.5 Max.
Power Vdc mA	+15 29	+15 32 Max.

## Typical Intermodulation Performance at 25 ° C

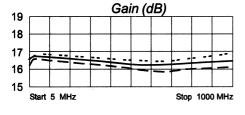
Second Order Harmonic Intercept Point	+41	(Typ.)
Second Order Two Tone Intercept Point	+35	(Typ.)
Third Order Two Tone Intercept Point	+23	(Tvp.)

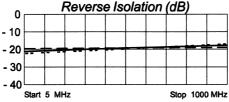
#### Maximum Ratings

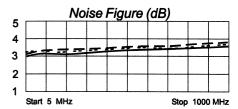
Maximum Naunga	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

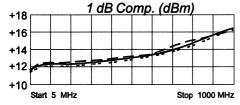
Note: Care should always be taken to effectively ground the case of each unit.

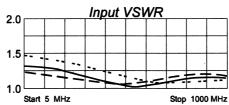
## **Typical Performance Data**

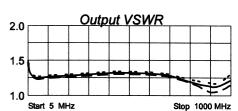












Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ. MHz	: Mag	S11 Deg	: Mag	521 Deg	S Mag	S12 Deg	S Mag	522 Deg
			<del>-</del>					
5	.15	-133	6.64	-170	و0۔	12	.18	149
50	.13	178	6.88	173	.09	1	.11	153
100	.13	169	6.84	164	.10	-0	.11	140
200	.11	155	6.78	147	.10	-1	.12	112
400	.06	128	6.62	115	.10	-7	.15	63
600	.01	-94	6.52	84	.11	-14	.14	28
800	.06	-111	6.57	50	.12	-21	.09	5
1000	.06	-149	6.68	12	.13	-31	.10	70



Available as: TM9316, 4 Pin TO-8 (T4)

TN9316, 4 Pin Surface Mount (SM3)

FP9316, 4 Pin Flatpack (FP4)

BX9316, Connectorized Housing (H1)

#### **Features**

■ Low 5 Volt Operation

■ Low Noise: 3.0 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1300 MHz	10 - 1200 MHz
Gain (dB)	13	12.0 Min.
Power @ 1 dB Comp. (dBm)	+6	+4.5 Min.
Reverse Isolation (dB)	- 16	- 14 Max.
VSWR In Out	1.25:1 1.35:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3	4.0 Max.
Power Vdc mA	+5 15	+5 18 Max.

### Typical Intermodulation Performance at 25 ° C

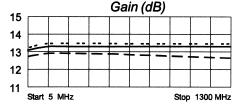
Second Order Harmonic Intercept Point		
Second Order Two Tone Intercept Point	+28	(Typ.)
Third Order Two Tone Intercept Point	+19	(Typ.)

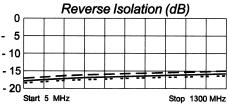
#### **Maximum Ratings**

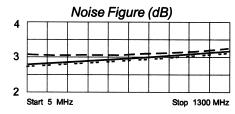
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

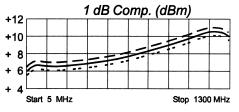
Note: Care should always be taken to effectively ground the case of each unit.

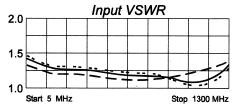
## **Typical Performance Data**

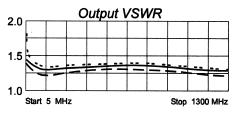












.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.14	-155.31	4.51	-175.22	.13	6.49	.14	158.63
100	.14	175.67	4.57	170.22	.13	1.12	.12	154.02
200	.13	161.98	4.57	159.28	.14	1.19	.12	133.81
400	.11	147.92	4.58	138.22	.14	1.50	.12	95.62
600	.07	135.15	4.55	117.40	.15	74	.14	57.41
800	.04	155.21	4.52	95.54	.16	-4.29	.14	24.53
1000	.06	-154.82	4.53	73.69	.16	-6.11	.14	-7.08
1200	.13	-153.92	4.56	51.02	.17	-9.16	.14	-36.96
1300	.19	-156.59	4.60	39.64	.17	-9.38	.15	-53.83



Available as: TM9318, 4 Pin TO-8 (T4)

TN9318, 4 Pin Surface Mount (SM3)

FP9318, 4 Pin Flatpack (FP4)

BX9318, Connectorized Housing (H1)

#### **Features**

■ Medium Output Power: +16 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+42 (Typ.)
Third Order Two Tone Intercept Point	+30 (Tvp.)

#### **Specifications**

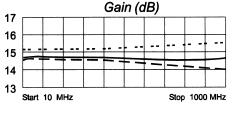
CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	14.7	13.5 Min.
Power @ 1 dB Comp. (dBm)	+16	+14.5 Min.
Reverse Isolation (dB)	- 18.5	- 17 Max.
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.75	5.5 Max.
Power Vdc	+15 47	+15 50 Max.

**Maximum Ratings** 

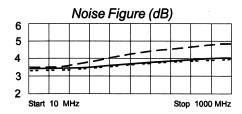
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

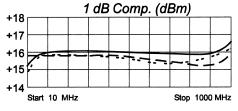
Note: Care should always be taken to effectively ground the case of each unit.

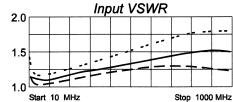
## **Typical Performance Data**

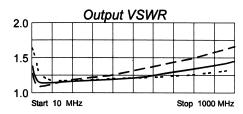












Legend ------ + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		512		S22
MHz	Mag Deg	. Mag	Deg	Mag	Deg	Mag	Deg
10	.11 - 78	5.43	-170	.11	11	.16	116
100	.02 117	5.65	167	.11	- 2	.05	84
200	.06 82	5.61	152	.11	- 6	.05	54
400	.11 51	5.52	123	.11	-15	.08	- 6
600	.14 24	5.46	94	.11	-22	.13	- 54
800	.16 - 10	5.45	65	.11	-27	.18	- 96
1000	.16 - 61	5.49	34	.10	-32	.22	-139



Available as:

TM9319, 4 Pin TO-8 (T4)

TN9319, 4 Pin Surface Mount (SM3)

FP9319, 4 Pin Flatpack (FP4)

BX9319, Connectorized Housing (H1)

PN9319, Reduced Size Surface Mount (SM11)

#### **Features**

- High Output Power: +22 dBm Typical
- High Third Order Intercept: +35 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+22	+20.0 Min.
Reverse Isolation (dB)	- 18	- 16 Max.
VSWR In Out	<1.75:1 <1.50:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.5*	7.5* Max.
Power Vdc mA	+15 90	+15 99 Max.

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+52 (Typ.)
Second Order Two Tone Intercept Point	+46 (Typ.)
Third Order Two Tone Intercept Point	+35 (Typ.)

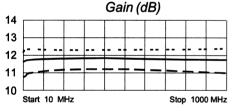
#### **Maximum Ratings**

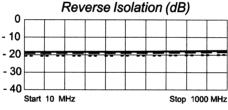
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

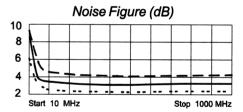
<sup>\*</sup> Noise Figure is Greater below 20 MHz.

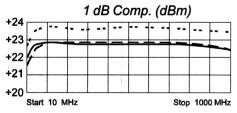
Note: Care should always be taken to effectively ground the case of each unit.

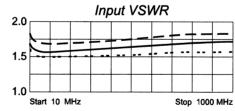
## **Typical Performance Data**

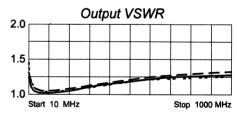












egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.		311		21		312	S	22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.26	- 27	3.85	-165	.12	11	.14	99
100	.22	- 18	3.90	175	.12	- 2	.00	7
200	.22	- 30	3.92	167	.12	- 6	.02	- 72
400	.23	- 54	3.91	152	.12	-13	.06	- 93
600	.25	- 77	3.91	138	.12	-21	.09	-106
800	.26	- 98	3.90	124	.12	-29	.11	-116
1000	.27	-118	3.89	109	.12	-38	.13	-123



Available as: TM9322, 4 Pin TO-8 (T4)

TN9322, 4 Pin Surface Mount (SM3)

FP9322, 4 Pin Flatpack (FP4) BX9322, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 10 dB Typical

■ Medium Output Power: +10 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	10	8.5 Min.
Power @ 1 dB Comp. (dBm)	+9	+7.5 Min.
Reverse Isolation (dB)	- 16	- 13 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	6.5 Max.
Power Vdc mA	+15 25	+15 29 Max.

## Typical Intermodulation Performance at 25 ° C

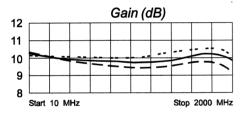
Second Order Harmonic Intercept Point	+41 (Typ.)
Second Order Two Tone Intercept Point	+35 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

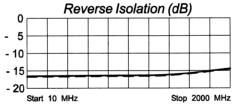
#### **Maximum Ratings**

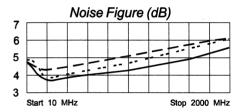
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

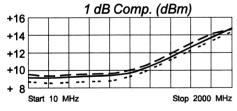
Note: Care should always be taken to effectively ground the case of each unit.

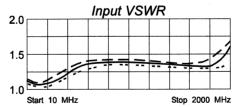
## **Typical Performance Data**

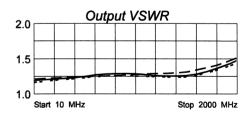












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.07 - 9	3.29 -180	.15 1	.07 -178
100	.07 - 30	3.25 168	.15 - 4	.08 153
200	.08 - 57	3.22 156	.15 - 7	.08 130
400	.10 - 99	3.13 133	.15 - 16	.10 88
600	.12 -134	3.06 112	.15 - 24	.12 53
800	.14 -160	3.01 90	.15 - 31	.13 27
1000	.16 173	2.97 69	.15 - 40	.13 - 2
1200	.16 144	3.02 47	.15 - 47	.13 - 33
1400	.16 109	3.10 24	.16 - 56	.12 - 71
1600	.16 65	3.17 - 1	.17 - 66	.13 -108
1800	.17 12	3.18 - 29	.18 - 77	.16 -151
2000	.23 - 36	3.01 - 61	.19 - 92	.19 170



Available as: TM9323, 4 Pin TO-8 (T4)

TN9323, 4 Pin Surface Mount (SM3)

FP9323, 4 Pin Flatpack (FP4)

BX9323, Connectorized Housing (H1)

#### **Features**

- Medium Gain: 8.5 dB Typical
- Medium Output Power: +15 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	8.5	7.5 Min.
Power @ 1 dB Comp. (dBm)	+15	+14.0 Min.
Reverse Isolation (dB)	- 13	- 11 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.5	7.5 Max.
Power Vdc mA	+15 50	+15 55 Max.

## Typical Intermodulation Performance at 25 ° C

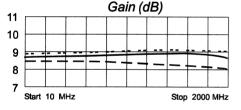
Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+30 (Typ.)

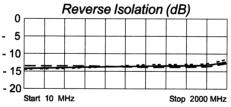
#### **Maximum Ratings**

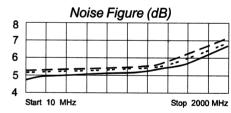
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

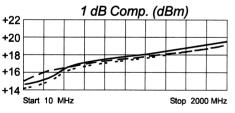
Note: Care should always be taken to effectively ground the case of each unit.

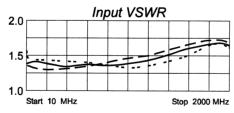
## **Typical Performance Data**

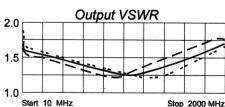












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQS11		S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.16 -134	2.53 -170	.18 13	.26 152
100	.14 -173	2.66 173	.19 2	.18 160
250	.15 -175	2.68 158	.19 1	.17 143
500 750	.15 -180	2.69 135	.20 - 2	.15 108
750	.15 177	2.70 113	.20 - 6	.12 62
1000	.17 -179	2.73 90	.21 - 9	.11 7
1250	.18 178	2.78 67	.21 -14	.14 - 47
1500	.21 168	2.79 44	.21 -16	.18 - 88
1750	.24 148	2.74 21	.23 -19	.23 -120
2000	.24 117	2.68 - 5	26 -24	24 -149



TM9324, 4 Pin TO-8 (T4) Available as:

TN9324, 4 Pin Surface Mount (SM3) FP9324, 4 Pin Flatpack (FP4) BX9324, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 16 dB Typical ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	16	14.0 Min.
Power @ 1 dB Comp. (dBm)	+6.5	+4.5 Min.
Reverse Isolation (dB)	- 28	- 27 Max.
VSWR In Out	<1.5:1 <1.8:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.75	6.0 Max.
Power Vdc mA	+15 38	+15 43 Max.

## Typical Intermodulation Performance at 25 ° C

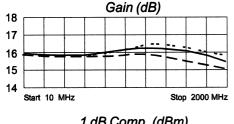
Second Order Harmonic Intercept Point	+43 (Typ.)
Second Order Two Tone Intercept Point	+37 (Typ.)
Third Order Two Tone Intercept Point	+19 (Typ.)

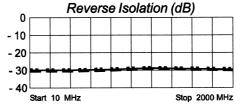
#### **Maximum Ratings**

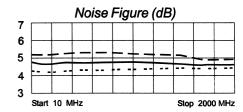
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

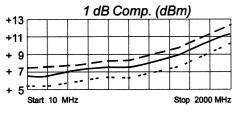
Note: Care should always be taken to effectively ground the case of each unit.

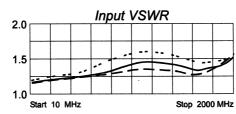
## **Typical Performance Data**

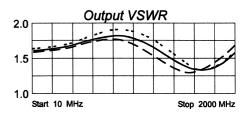












– + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		311		S21		S12		S22·
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.10	-173	6.98	0	.03	4	.21	-176
50	.11	177	6.88	-8	.03	-0	.22	-180
100	.11	172	6.84	-16	.03	1	.22	178
250	.12	156	6.83	-39	.03	<b>-4</b>	.24	173
500	.15	129	6.90	-79	.03	-3	.28	158
750	.18	100	7.01	-119	.03	-7	.31	132
1000	.21	70	7.17	-160	.03	-11	.30	98
1250	.18	44	7.04	158	.03	-21	.23	55
1500	.14	39	6.92	117	.03	-43	.15	-9
1750	.16	50	7.04	75	.03	-46	.16	-99
2000	.27	29	7.61	22	.03	-54	.30	-165



Available as: TM9325, 4 Pin TO-8 (T4)

TN9325, 4 Pin Surface Mount (SM3)

BX9325, Connectorized Housing (H1)

FP9325, 4 Pin Flatpack (FP4)

#### **Features**

- Low Noise Figure: <3.5 dB Typical</p>
- Medium Output Power: > +9 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	14	13.0 Min.
Power @ 1 dB Comp. (dBm)	+9	+7.5 Min.
Reverse Isolation (dB)	- 17	- 16 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.5 Max.
Power Vdc mA	+15 24	+15 28 Max.

## Typical Intermodulation Performance at 25 ° C

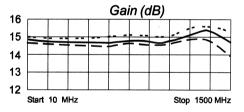
Second Order Harmonic Intercept Point	+36 (Typ.)
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+22 (Typ.)

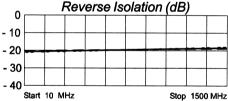
### **Maximum Ratings**

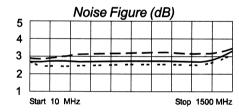
55°C to + 100 °C
62°C to + 125 °C
+ 125°°C
+ 18 Volts
+ 13 dBm
50 Milliwatts
(1 Minute Max.)
0.5 Watt
(3 μsec Max.)

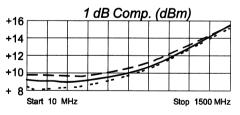
Note: Care should always be taken to effectively ground the case of each unit.

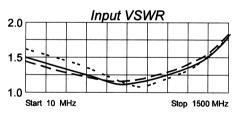
### **Typical Performance Data**

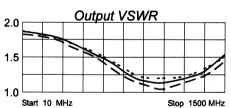












— + 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.				S21		S12		522
MHz	Mag D	eg	Mag	Deg	Mag	Deg	Mag	Deg
10	19 -1	78	5.54	-180	.09	2	.30	-178
50	.19 1	75	5.53	173	.09	2	.30	_
100	.19 1	68	5.52	167	.10	-3	.29	174
250	.16 1	52	5.46	146	.10	-4	.27	168
500	.09 1	31	5.42	113	.11	-8	.22	146
750	.04 1	62	5.51	80	.11	-19	.13	111
1000	.11 -1	68	5.37	44	.12	-29	.05	70
1250		25	5.73	4	.13	-41	.08	72
1500	.29	31	5.28	-51	.14	-61	.21	87



Available as: TM9327, 4 Pin TO-8 (T4)

TN9327, 4 Pin Surface Mount (SM3) FP9327, 4 Pin Flatpack (FP4) BX9327, Connectorized Housing (H1)

#### **Features**

■ Medium Gain: 15 dB Typical

■ Medium Output Power: +17.5 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	15	13.0 Min.
Power @ 1 dB Comp. (dBm)	+17.5	+16.0 Min.
Reverse Isolation (dB)	- 27.5	- 26.0 Max.
VSWR In Out	<1.25:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<6.5	7.5 Max.
Power Vdc mA	+15 108	+15 118 Max.

## Typical Intermodulation Performance at 25 ° C

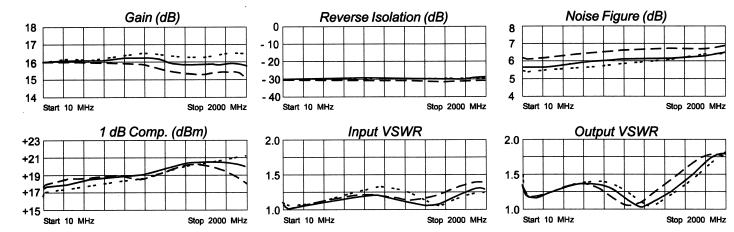
Second Order Harmonic Intercept Point	+44	(Typ.)
Second Order Two Tone Intercept Point	+38	(Typ.)
Third Order Two Tone Intercept Point	+29	(Typ.)

#### **Maximum Ratings**

	Ambient Operating Temperature	55°C to + 100 °C
	Storage Temperature	62°C to + 125 °C
	Case Temperature	+ 125 °C
	DC Voltage	+ 18 Volts
	Continuous RF Input Power	+ 13 dBm
í	Short Term RF Input Power	50 Milliwatts
		(1 Minute Max.)
	Maximum Peak Power	
		(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Legend ——— + 25 °C -----55 °C Linear S-Parameters

FREQ. MHz	: Mag	S11 Deg	S21 Mag Deg		612 Deg	; Mag	S22 Deg
10	.03	126	6.32 8	.03	11	.15	136
50	.01	172	6.43 <i>-</i> 7	.03	2	.08	164
100	.01	-150	6.44 -17	.03	-1	.08	177
250	.03	-141	6.40 -45 6.38 -90	.03	-5	.10	-173
500	.06	-175	6.38 <i>-</i> 90	.03	-11	.14	171
750	.08	150	6.44 -134	.03	-16	.14	143
1000	.08	113	6.59 179	.03	-24	.09	104
1250	.05	85	6.37 132	.03	-38	.01	-141
1500	.04	111	6.27 85	.03	-48	.12	-153
1750	.09	105	6.32 35	.04	-55	.22	166
2000	.11	65	5.74 <i>-</i> 27	.04	-76	.26	111



Available as: TM9328, 4 Pin TO-8 (T4)

TN9328, 4 Pin Surface Mount (SM3)

FP9328, 4 Pin Flatpack (FP4)

BX9328, Connectorized Housing (H1)

#### **Features**

■ Low Noise Figure: 3.25 dB Typical

■ 5 Volt Operation

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Gain (dB)	14	12.5 Min.
Power @ 1 dB Comp. (dBm)	+12	+9.0 Min.
Reverse Isolation (dB)	- 16	- 14 Max.
VSWR In Out	1.6:1 1.6:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	3.25	4.5 Max.
Power Vdc mA	+5 27	+5 30 Max.

## Typical Intermodulation Performance at 25 ° C

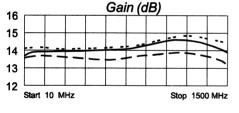
Second Order Harmonic Intercept Point	+37 (Typ.)
Second Order Two Tone Intercept Point	+31 (Typ.)
Third Order Two Tone Intercept Point	+23 (Typ.)

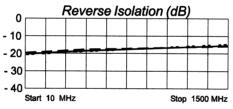
### **Maximum Ratings**

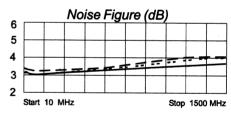
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 μsec Max.)

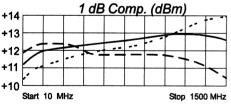
Note: Care should always be taken to effectively ground the case of each unit.

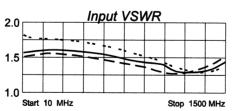
## **Typical Performance Data**

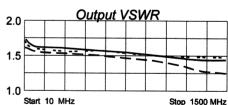












#### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.22	-155	4.96	-173	.12	8	.25	164
50	.22	-179	5.06	176	.12	š	.22	164
100	.22	175	5.06	169	.12	2	.21	155
250	.21	158	5.06	150	.12	1	.22	128
500	.18	135	5.04	121	.14	- Ò	.23	82
750	.13	117	5.12	91	.15	- 6	.24	42
1000	.08	121	5.21	59	.16	-14	.21	-6
1250	.10	153	5.16	23	.17	-21	.17	- 26
1500	.16	146	4.70	- 17	.18	-29	11	- 40



Available as:

TM9329, 4 Pin TO-8 (T4)

TN9329, 4 Pin Surface Mount (SM3)

FP9329, 4 Pin Flatpack (FP4)

BX9329, Connectorized Housing (H1) PN9329, Reduced Size Surface Mount (SM11)

#### **Features**

- High Output Power: +20 dBm Typical
- High Third Order Intercept: +39 dBm Typical
- Operating Temp. -55 C to +85 C
- Environmental Screening available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 -1500 MHz	10 - 1500 MHz
Gain (dB)	9.5	8.5 Min.
Power @ 1 dB Comp. (dBm)	+20.0	+19.0 Min.
Reverse Isolation (dB)	- 16	- 15 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	* 4.0	* 8.0 Max.
Power Vdc mA	+15 90	+15 95 Max.

Typical Intermodulation Performance at 25 ° C

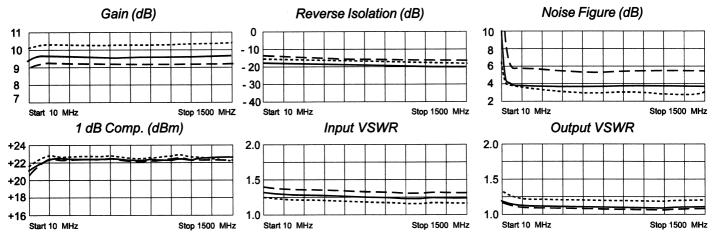
**Maximum Ratings** 

Maximum Radings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

NOISE FIGURE IS HIGHER FOR FREQUENCIES BELOW 50 MHZ

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

**Linear S-Parameters** 

FREQ.	S	11	S2	21	S	12	Si	22
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	.13	-30	3.02	-1 <b>7</b> 2	.135	6	.16	165
100	.09	-14	3.20	175	.142	- 4	.11	168
200	.09	-21	3.18	169	.141	- 8	.10	163
400	.08	-38	3.18	157	.142	- 15	.10	149
600	.08	-55	3.17	145	.141	- 25	.10	138
800	.08	-71	3.16	134	.138	- 33	.10	129
1000	.07	-94	3.19	122	.135	- 43	.10	124
1200	.08	-107	3.20	110	.132	- 51	.09	107
1500	.08	-136	3.26	92	.131	- 64	.10	- 88



Rev. B 07/02/02

Available as: TM9331, 4 Pin TO-8 (T4)

TN9331, 4 Pin Surface Mount (SM3) FP9331, 4 Pin Flatpack (FP4) BX9331, Connectorized Housing (H1)

### **Features**

■ Medium Gain: 11.5 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	11.5	10.5 Min.
Power @ 1 dB Comp. (dBm)	>+2	0 Min.
Reverse Isolation (dB)	- 15	- 14 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	4.5 Max.
Power Vdc mA	+15 11	+15 12 Max.

## Typical Intermodulation Performance at 25 ° C

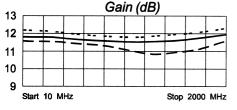
Second Order Harmonic Intercept Point	+27	(Typ.)
Second Order Two Tone Intercept Point		
Third Order Two Tone Intercept Point	+14	(Typ.)

### **Maximum Ratings**

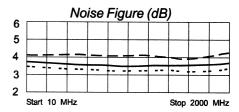
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

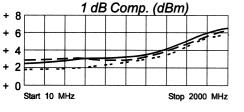
Note: Care should always be taken to effectively ground the case of each unit.

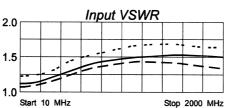
## **Typical Performance Data**

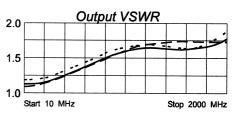












.egend ------ + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		311		S21		512		322
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
10	.07	-176	3.92	-179	.15	2	.06	-176
100	.07	149	3.90	172	.15	1	.06	141
200	.08	127	3.89	164	.15	2	.08	111
400	.11	89	3.85	150	.15	2	.12	71
600	.14	63	3.83	135	.16	2	.16	43
800	.17	42	3.79	120	.16	1	.19	15
1000	.19	21	2.73	106	.17	- 3	.21	- 9
1200	.20	1	3.72	91	.17	- 5	.23	- 34
1400	.21	- 21	3.74	76	.17	- 9	.24	- 59
1600	.20	- 41	3.84	62	.18	- 10	.25 .26	- 87
1800	.19	- 68	3.99	47	.18	- 11	.26	-116
2000	.19	- 97	4.10	31	.18	- 12	.27	149

<u>Amplifonix</u>

## RF AMPLIFIER TM9333 **MODEL**

TM9333. 4 Pin TO-8 (T4) Available as:

> TN9333, 4 Pin Surface Mount (SM3) FP9333, 4 Pin Flatpack (FP4) BX9333, Connectorized Housing (H1) PN9333. Reduced Size Surface Mount (SM11)

#### **Features**

■ Medium Gain: 11.5 dB Typical

Medium Output Power: +16 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+16.0	+14.0 Min.
Reverse Isolation (dB)	- 15	- 13 Max.
VSWR In Out	<1.25:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	5.0	6.5 Max.
Power Vdc mA	+15 48	+15 52 Max.

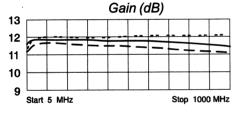
Typical Intermodulation Performance at 25 ° C

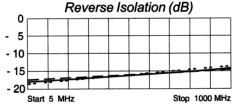
Second Order Harmonic Intercept Point	+50 (Typ.	)
Second Order Two Tone Intercept Point	+44 (Typ.	)
Third Order Two Tone Intercept Point	+30 (Typ.	.)

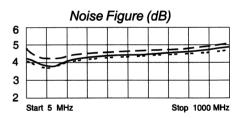
Maximum Ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

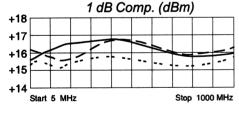
Note: Care should always be taken to effectively ground the case of each unit.

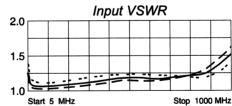
## **Typical Performance Data**

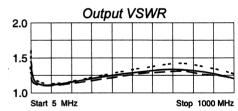












- + 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
IVINZ	Mag Deg	Mag Deg	Mag Deg	Iviag Dog
- 5	.10 - 97	3.79 -169	.14 13	.03 132
50 <sup>°</sup>	.04 174	3.91 174	.15 0	.05 174
100	.04 138	3.91 166	.15 - 1	.05 -175
200	.05 106	3.91 152	.15 - 3	.06 -153
400	,08 59	3.89 123	.16 - 9	.11 -151
600	.09 12	3.86 94	.17 - 16	.14 -165
800	.09 - 67	3.82 64	.19 - 25	.15 172
1000	.21 -152	3.79 32	.20 - 39	.08 150



Available as: TM9352, 4 Pin TO-8 (T4)

TN9352, 4 Pin Surface Mount (SM3)

FP9352, 4 Pin Flatpack (FP4)

BX9352, Connectorized Housing (H1) PN9352, Reduced Size Surface Mount (SM11)

#### **Features**

- Low 5 Volt Bias
- Medium Gain: +10 dB Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 2000 MHz	5 - 2000 MHz	
Gain (dB)	10	8.5 Min.	
Power @ 1 dB Comp. (dBm)	+8.0	+5.0 Min.	
Reverse Isolation (dB)	- 13	- 12 Max.	
VSWR In Out	1.5:1 1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	4.0	5.5 Max.	
Power Vdc mA	+5 18	+5 20 Max.	

## Typical Intermodulation Performance at 25 ° C

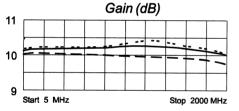
Second Order Harmonic Intercept Point +33	(Typ.)
Second Order Two Tone Intercept Point +28	(Typ.)
Third Order Two Tone Intercept Point+20	(Tvp.)

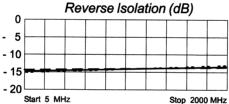
### **Maximum Ratings**

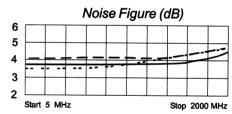
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	100 Milliwatts
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

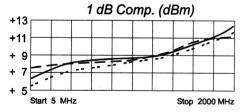
Note: Care should always be taken to effectively ground the case of each unit.

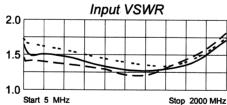
## **Typical Performance Data**

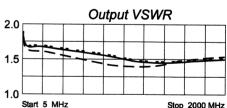












.egend ----- + 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg
10	.22 -21	3.33 -170		
10 100	.20 -11	3.35 -170 3.35 175	.1212 5 .1205 -3	.11 160
200	.20 -20	3.34 168	.1205 -3	.10 174
400	.21 -37	3.33 155	.1194 -6	.09 176
600	.22 -54	3.32 143		.09 175
800	.23 -69	3.32 143 3.34 130	.1224 -19 .1215 -27	.08 179
1000	.24 -84	3.34 130 3.36 117	.1215 -27	.08 -180
1200	.25 -96	3.39 104	.1244 -33	.08 -177
1400	.25 -111	3.41 91	.1240 -43	.08 -174
1600	.25 -125	3.47 77		.09 -176
1800	.24 -143		.1270 -59 .1321 -72	.08 179
2000	.21 -174			.06 172
2000	.21 -1/4	3.57 46	.1313 -81	.04 173



Available as:

TM9355, 4 Pin TO-8 (T4)

TN9355, 4 Pin Surface Mount (SM3)

FP9355, 4 Pin Flatpack (FP4)

BX9355, Connectorized Housing (H1) PN9355, Reduced Size Surface Mount (SM11)

#### **Features**

■ Medium Gain: 16.5 dB Typical

■ Low Noise Figure: <3 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	+6	+4.0 Min.
Reverse Isolation (dB)	- 18.5	- 17.5 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	4.0 Max.
Power Vdc mA	+15 16	+15 20 Max.

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+31	(Typ.)
Second Order Two Tone Intercept Point	+25	(Typ.)
Third Order Two Tone Intercept Point	+19	(Typ.)

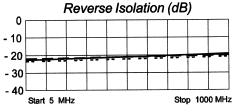
### **Maximum Ratings**

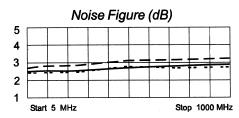
Maxillulli izatiligə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	(3 µsec Max.)

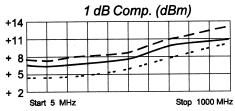
Note: Care should always be taken to effectively ground the case of each unit.

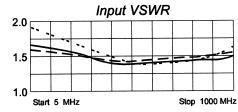
## Typical Performance Data

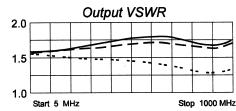












Legend ----- + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.		S11		321		312	_		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg		Mag	Deg
10	.22	-21	3.33	-170	.1212	5		.11	160
100	.20	-11	3.35	175	.1205	-3		.10	174
200	.20	-20	3.34	168	.1194	-6		.09	176
400	.21	-37	3.33	155	.1207	-12		.09	175
600	.22	-54	3.32	143	.1224	-19	,	.08	179
800	.23	-69	3.34	130	.1215	-27		.08	-180
1000	.24	-84	3.36	117	.1244	-33		.08	-177
1200	.25	-96	3.39	104	.1240	-43		.08	-174
1400	.25	-111	3.41	91	.1275	-50		.09	-176
1600	.25	-125	3.47	77	.1270	-59		.08	179
1800	.24	-143	3.56	63	.1321	-72		.06	172
2000	.21	-174	3.57	46	.1313	-81		.04	173



Available as:

TM9363, 4 Pin TO-8 (T4)

TN9363, 4 Pin Surface Mount (SM3)

FP9363, 4 Pin Flatpack (FP4)

BX9363, Connectorized Housing (H1) PN9363, Reduced Size Surface Mount (SM11)

#### **Features**

■ High Gain: 16.5 dB Typical

■ Low Noise Figure: <3 dB Typical ■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	+6	+4.0 Min.
Reverse Isolation (dB)	- 18.5	- 17.5 Max.
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.0	4.0 Max.
Power Vdc mA	+15 16	+15 20 Max.

## Typical Intermodulation Performance at 25 ° C

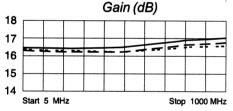
Second Order Harmonic Intercept Point	+31 (Typ.)
Second Order Two Tone Intercept Point	+25 (Typ.)
Third Order Two Tone Intercept Point	+19 (Typ.)

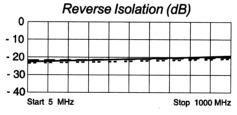
#### **Maximum Ratings**

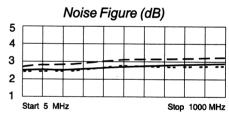
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

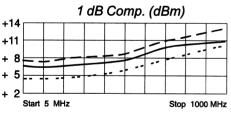
Note: Care should always be taken to effectively ground the case of each unit.

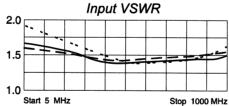
## **Typical Performance Data**

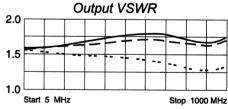












+ 25 °C --- + 85 °C ---- -55 °C

#### Linear S-Parameters

FREQ.	S	1	:	S21		S12		522
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.21	-176	6.77	-176	.09	5	.23	-175
50	.21	175	6.72	172	.09	- 1	.22	169
100	.20	170	6.69	163	.09	- 2	.22	159
200	.19	161	6.58	147	.09	- 4	.22	138
400	.14	148	6.39	115	.10	- 8	.21	99
600	.10	149	6.29	84	.10	- 15	.18	67
800	.09	154	6.32	51	.11	- 21	.13	35
1000	.06	-173	6.13	14	.12	- 33	.04	95
1200	.07	-167	5.92	- 27	.13	- 45	.19	107



Available as: TM9366, 4 Pin TO-8 (T4)

TN9366, 4 Pin Surface Mount (SM3) FP9366, 4 Pin Flatpack (FP4)

BX9366, Connectorized Housing (H1)

#### **Features**

■ High Gain: 27.5 dB Typical
 ■ Low Noise Figure: <4 dB Typical</li>
 ■ Operating Temp. -55 °C to +85 C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	27.5	25.5 Min.
Power @ 1 dB Comp. (dBm)	+15	+13.5 Min.
Reverse Isolation (dB)	- 36	- 34 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.0	5.0 Max.
Power Vdc mA	+15 63	+15 70 Max.

## Typical Intermodulation Performance at 25 ° C

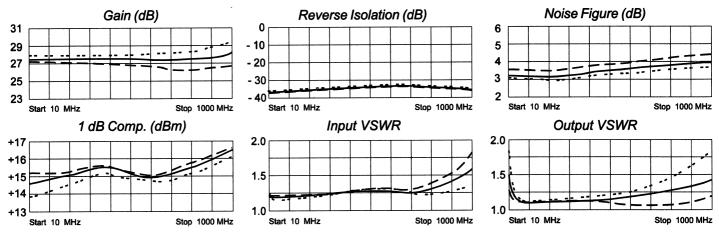
Second Order Harmonic Intercept Point	+37(Typ.)
Second Order Two Tone Intercept Point	+32(Typ.)
Third Order Two Tone Intercept Point	+25(Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.18 33	22.77 23	.01 24	.36 113
10	.19 13	23.76 10	.01 12	.17 99
50	.18 - 10	23.90 - 9	.02 8	.05 <b>7</b> 6
100	.18 - 22	23.93 - 21	.01 2	.04 66
200	.17 - 47	24.04 - 44	.01 3	.04 54
400	.15 - 93	23.87 - 89	.01 - 6	.04 41
600	.12 -129	23.38 -134	.02 1	.05 75
800	.10 -130	23.59 -178	.02 - 12	.12 91
1000	.24 -135	25.96 132	.02 - 26	.31 62



## RF AMPLIFIER TM9511 **MODEL**

Available as: TM9511, 4 Pin TO-8 (T4)

> TN9511, 4 Pin Surface Mount (SM3) FP9511, 4 Pin Flatpack (FP4) BX9511, Connectrized Housing (H1) PN9511, Reduced Size Surface Mount (SM11)

#### **Features**

■ Low Noise Figure: <2.3 dB Typical

■ High Gain: +16.5 dB Typical

■Operating Temp. - 55 °C to +85 °C

■Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Gain (dB)	16.5	15.0 Min.
Power @ 1 dB Comp. (dBm)	+1	- 1 Min.
Reverse Isolation (dB)	- 18.5	- 18 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	2.3	3.0 Max.
Power Vdc m A	+15 9.5	+15 11 Max.

## Typical Intermodulation Performance at 25 ° C

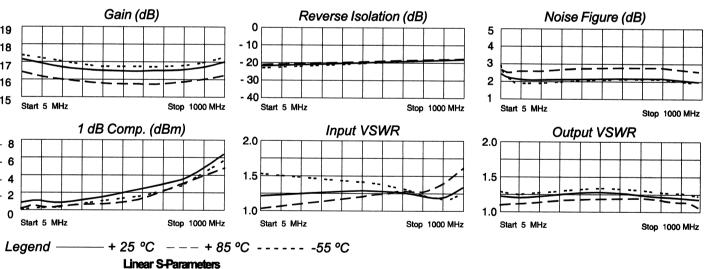
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	+16(Typ.)
Third Order Two Tone Intercept Point	+14(Typ.)

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
5	.11 -173	7.19 -177	.09 4	.10 -172
50	.11 173	7.04 172	.09 - 0	.09 159
100	.11 163	6. <del>9</del> 9 164	.09 - 2	.09 140
200	.11 145	6.89 149	.09 - 3	.10 109
400	.10 115	6.69 120	.10 - 8	.12 63
600	.10 88	6.62 91	.10 -13	.12 29
800	.08 60	6.76 61	.11 -21	.10 9
1000	.02 23	7.14 26	.12 -29	.11 - 4



Available as: TN9518, 4 Pin Surface Mount (SM3)

**BX9518 Connectorized Housing (HI)** 

#### **Features**

Medium Gain: +16 dB Typical Operating Temp. - 55 °C to +85 °C

#### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	14.7	13.5 Min.
Power @ 1 dB Comp. (dBm)	+16	+14.5 Min.
Reverse Isolation (dB)	- 18.5	- 17 Max.
VSWR In Out	1.5:1 1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.0	5.5 Max.
Power Vdc mA	+15 44	+15 50 Max.

## Typical Intermodulation Performance at 25 ° C

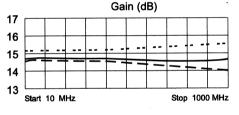
Second Order Harmonic Intercept Point	+47(Typ.)
Second Order Two Tone Intercept Point	+41(Typ.)
Third Order Two Tone Intercept Point	+29(Typ.)

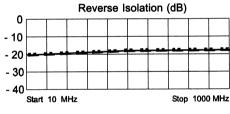
### Maximum Ratings

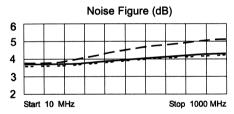
Maxilliulli Nauliyə	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	3 μsec Max.)

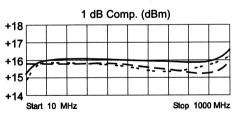
Note: Care should always be taken to effectively ground the case of each unit.

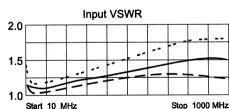
## Typical Performance Data

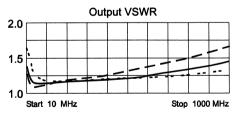












-+ 25 °C --- + 85 °C ----- -55 °C

Linear S-Pa FREQ.	S	11	S2	21	S1	12	Si	22
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	.17	-160	5.20	-176	.11	6	.19	163
50	.17	174	5.27	171	.12	-2	.17	169
100	.16	160	5.25	161	.12	-6	.16	163
200	.14	134	5.24	141	.12	-12	.14	150
400	.08	51	5.25	102	.13	-26	.06	131
600	.15	-50	5.27	60	.13	<del>-4</del> 5	.06	-108
800	.23	-107	5.21	15	.14	-65	.16	-137
1000	.10	-171	5.11	-37	.14	-87	.15	-177



Available as: TM9522

TM9522, 4 Pin TO-8 (T4)

TN9522-3, 4 Pin Surface Mount (SM3) FP9522-4, 4 Pin Flatpack (FP4) BX9522, Connectorized Housing (H1)

#### **Features**

■ High Gain: 20.5 dB Typical

Medium Output Power: +14 dBm Typical

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+48	(Typ.)
Second Order Two Tone Intercept Point	+42	(Typ.)
Third Order Two Tone Intercept Point	+25	(Typ.)

#### **Maximum Ratings**

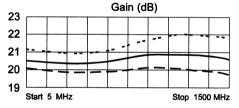
•	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
Maximum Peak Power	0.5 Watt
	3 μsec Max.)

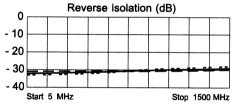
### **Specifications**

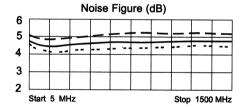
CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 1500 MHz	5 - 1500 MHz
Gain (dB)	20.5	18.5 Min.
Power @ 1 dB Comp. (dBm)	+14.0	+10.0 Min.
Reverse Isolation (dB)	- 30	- 27 Max.
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<5.0	6.0 Max.
Power Vdc mA	+15 64	+15 70 Max.

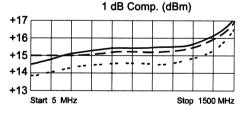
Note: Care should always be taken to effectively ground the case of each unit.

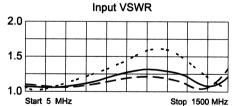
## **Typical Performance Data**

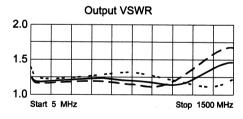












Legend — + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQS11		S11S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
10	.02 50	10.68 5	.03 8	.12 145	
50	.01 - 33	10.64 - 11	.03 - 1	.08 166	
100	.02 - 74	10.62 - 24	.03 - 8	.08 172	
300	.05 -154	10.50 - 71	.03 - 19	.09 166	
500	.10 156	10.61 -119	.03 - 35	.10 151	
700	.17 110	10.95 -167	.03 - 54	.10 133	
900	.20 65	11.55 143	.03 - 64	.07 117	
1100	.19 20	11.83 89	.03 - 83	.05 146	
1300	.11 - 30	11.55 32	.03 -100	.12 160	
1500	07 102	10.77 - 27	.03 -100 03 -125	21 128	



Available as: TM9524, 4 Pin TO-8 (T4)

TN9524-3, 4 Pin Surface Mount (SM3) FP9524-4, 4 Pin Flatpack (FP4) BX9524, Connectorized Housing (H1)

#### **Features**

■ High Gain: 22 dB Typical

■ Medium Output Power: +13 dBm Typical

# Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+37 (Tyr
Second Order Two Tone Intercept Point	+31 (Typ
Third Order Two Tone Intercept Point	+23 (Tyr

#### **Specifications**

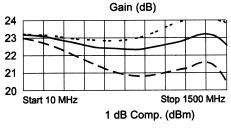
CHARACT	ERISTIC	TYPICAL Ta= 25 °C	<b>MIN/MAX</b> Ta = -55 °C to +85 °C
Frequency		10 - 1500 MHz	10 - 1500 MHz
Gain (dB)		22.0	20.0 Min.
Power @ 1 Comp. (		+13	+10.0 Min.
Reverse Isolation	(dB)	- 33	- 30 Max.
VSWR	In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.2:1 Max.
Noise figure (dB)		4.3	5.0 Max.
Power	Vdc mA	+15 56	+15 65 Max.

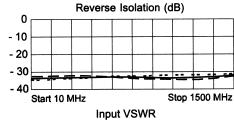
**Maximum Ratings** 

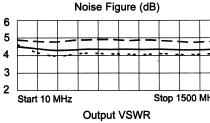
Ambient Operating Temperature	55°C to + 100 °
Storage Temperature	62°C to + 125°
Case Temperature	+ 125
DC Voltage	+ 18 Vo
Continuous RF Input Power	
Short Term RF Input Power	200 Milliwa
	(1 Minute Ma
Maximum Peak Power	
	3 usec Ma

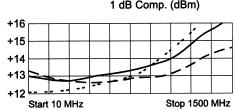
Note: Care should always be taken to effectively ground the case of each unit.

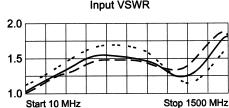
## **Typical Performance Data**

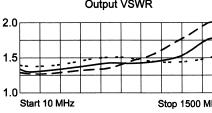












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22	
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	
10	.01 147	14.76 4	.02 6	.14 162	
50	.03 -124	14.70 - 11	.02 2	.13 172	
100	.06 -116	14.65 - 24	.02 4	.13 168	
300	.15 -145	14.00 - 73	.02 - 6	.15 148	
500	.21 -173	13.30 -119	.02 - 4	.17 111	
700	.22 159	12.74 -165	.02 - 7	.18 66	
700 900	.19 133	12.57 150	.03 - 17	.18 9	
1100	.12 117	12.59 102	.02 - 26	.21 - 51	
1300	12 149	13.19 48	.02 - 29	.28 -113	
1500	24 118	13.03 - 21	.03 - 32	.32 166	



Available as: TM956

TM9566, 4 Pin TO-8 (T4)

TN9566-3, 4 Pin Surface Mount (SM3) FP9566-4, 4Pin Flatpack (FP4) BX9566, Connectorized Housing (H1)

#### **Features**

■ High Gain: 26 dB Typical

■ Low Noise Figure: <3dB Typical

■ Low 5 Volt Bias

### **Specifications**

CHARACTERISTI	C TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	5 - 1100 MHz	10 - 1000 MHz	
Gain (dB)	26	24.5 Min.	
Power @ 1 dB Comp. (dBm)	+0.5	-0.5 Min.	
Reverse Isolation (dB)	- 35	- 34 Max.	
VSWR In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	<3.0	4.0 Max.	
Power Vdc mA	+5 18	+5 20 Max.	

Typical Intermodulation Performance at 25 ° C

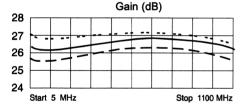
Second Order Harmonic Intercept Point	
Second Order Two Tone Intercept Point	
Third Order Two Tone Intercept Point	+12 (Typ.)

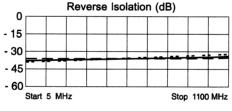
**Maximum Ratings** 

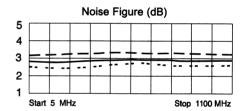
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	3 μsec Max.)

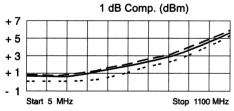
Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**

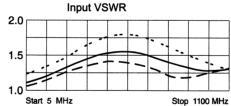


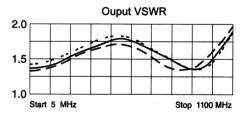






Linear S-Parameters





Legend ----- + 25 °C --- + 85 °C ---- - -55 °C

FREQ.	S	11	S	21	S1	2	S	22
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
5	.03	-38	21.05	4	.02	8	.21	-174
10	.04	-30	20.93	-0	.01	-1	.21	-175
50	.04	-67	20.48	-13	.01	3	.21	-176
100	.07	-83	20.67	-26	.01	-11	.22	-176
200	.13	-124	20.92	-52	.01	7	.24	-180
400	.19	-169	21.86	-105	.01	4	.29	165
600	.20	138	22.11	-162	.02	-1	.28	139
800	.14	62	22.13	139	.02	-1	.17	126
1000	.11	-44	21.70	75	.02	-25	.20	177
1200	.15	-144	18.54	-2	.02	2	.44	143



Available as: RN9604, 4 Pin Surface Mount (SM19)

BR9604, Connectorized Housing (H2)

#### **Features**

■ High Output Power: +21 dBm Typical

■ High Gain: +23 dB Typical

## **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	10 - 500 MHz	30 - 500 MHz	
Gain (dB)	23	21.0 Min.	
Power @ 1 dB Comp. (dBm)	+21	+19.0 Min.	
Reverse Isolation (dB)	- 32	- 30 Max.	
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	5.0	6.0 Max.	
Power Vdc mA	+15 125	+15 140 Max.	

## Typical Intermodulation Performance at 25 ° C

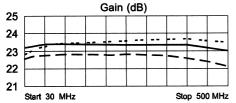
Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	+40 (Typ.)
Third Order Two Tone Intercept Point	+33 (Typ.)

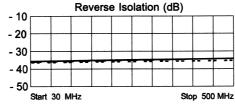
#### **Maximum Ratings**

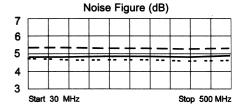
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	3 μsec Max.)

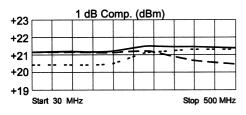
Note: Care should always be taken to effectively ground the case of each unit.

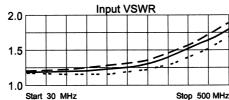
## **Typical Performance Data**

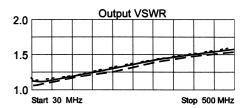












Legend ------ + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg
10	.07 -19	13.69 22	.02 2	.09 48
30	.08 -7	14.45 -3	.01 -2	.07 -4
50	.08 -7	14.54 -14	.02 0	.06 -29
100	.08 -10	14.63 -3	.02 2	.09 -63
200	.09 -7	14.72 -79	.02 1	.15 -101
300	.13 -8	14.81 -121	.02 4	.18 -129
400	.20 -22	14.65 -164	.02 6	.21 -149
500	.30 -43	14.06 150	.02 -3	.23 -167



### RF AMPLIFIER TR9666 **MODEL**

Available as: RN9666, 4 Pin Surface Mount (SM19)

BX9666, Connectorized Housing (H2)

#### **Features**

■ High Gain: 37 dB Typical

■ Low Noise Figure: <3.5 dB Typical

### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+37 (Typ.)
Second Order Two Tone Intercept Point	+31 (Typ.)
Third Order Two Tone Intercept Point	+25 (Typ.)

#### **Maximum Ratings**

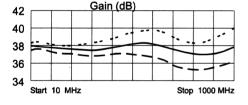
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	3 μsec Max.)

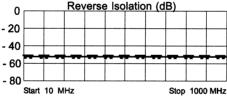
#### **Specifications**

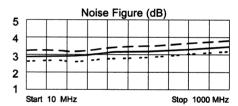
CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Gain (dB)	37	34.0 Min.
Power @ 1 dB Comp. (dBm)	+15.5	+14.0 Min.
Reverse Isolation (dB)	- 52	- 49 Max.
VSWR In	<1.5:1	2.0:1 Max.
Out	<1.6:1	2.0:1 Max.
Noise figure (dB)	<3.5	4.5 Max.
Power Vdc	+15	+15
mA	82	87 Max.

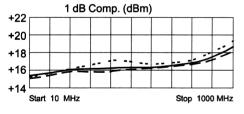
Note: Care should always be taken to effectively ground the case of each unit.

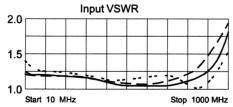
#### Typical Performance Data

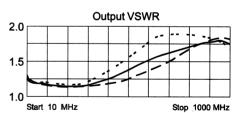












- + 25 °C - - - + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	Si Mag	11 Deg	5 Mag	521 Deg	S Mag	612 Deg	( Mag	522 Deg
10	.12	-169	80.22	-178	.002	- 19	.13	157
50	.10	160	80.76	158	.002	20	.10	164
100	.10	142	79.59	134	.002	- 13	.09	162
200	.09	108	76.91	89	.002	- 12	.07	162
400	.04	55	78.05	2	.002	- 7	.11	150
600	.02	149	83.56	- 95	.002	24	.21	72
800	.02	-146	73.82	166	.002	-134	.25	- 30
1000	.30	-165	80.90	59	.002	172	.22	-121



Available as: TM9700, 4 Pin TO-8 (T4)

TN9700, 4 Pin Surface Mount (SM3) FP9700, 4 Pin Flatpack (FP4) BX9700, Connectorized Housing (H1) PN9700, Reduced Size Surface Mount (SM11)

#### **Features**

- GaAs FET; Low Noise Figure: 2.5 dB Typical
- High Output Power: +19 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	200 - 2000 MHz	200 - 2000 MHz
Gain (dB)	12	10.5 Min.
Power @ 1 dB Comp. (dBm)	+19	+18 Min.
Reverse Isolation (dB)	- 21	-20.0 Max.
VSWR In Out	<2.0:1 <1.75:1	2.2:1 Max. 2.0:1 Max.
Noise figure (dB)	2.5	4.0 Max.
Power Vdc mA	<b>+6</b> 65	+6 72 Max.

#### Typical Intermodulation Performance at 25 ° C

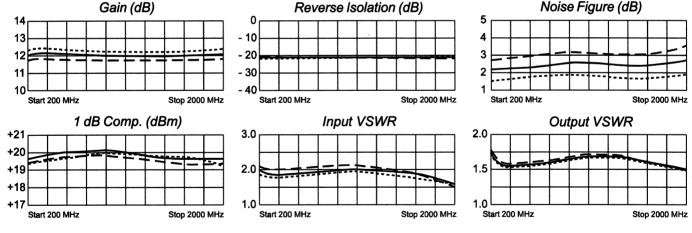
Second Order Harmonic Intercept Point	+49	(Typ.)
Second Order Two Tone Intercept Point	+43	(Typ.)
Third Order Two Tone Intercept Point	+33	(Typ.)

#### **Maximum Ratings**

Maximum Raunys	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S11		S11 S21		S12		\$22	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
200	.33	47	3.96	-179	.084	10	.26	83
400	.29	67	4.00	158	.092	- 4	.21	51
600	.29	79	3.90	141	.089	- 13	.22	34
800	.29	95	3.85	125	.088	- 19	.25	16
1000	.28	-112	3.79	111	.088	- 28	.25	- 1
1200	.29	-122	3.70	98	.087	- 37	.25	- 13
1400	.28	-138	3.80	82	.081	- 42	.23	- 34
1600	.27	-150	3.76	68	.079	- 51	.21	- 51
1800	.25	-160	3.76	50	.082	- 56	.18	- 77
2000	24	167	2.05	22	002	60	4.4	100



Available as: TM9701, 4 Pin TO-8 (T4)

TN9701-3, 4 Pin Surface Mount (SM) FP9701-4, 4 Pin Flatpack (FP4) BX9701, Connectorized Housing (H1)

PN9701, Reduced Size Suface Mount (SM11)

#### **Features**

■ GaAs FET: Low Noise Figure: 3 dB Typical■ Medium Output Power: +14 dBm Typical

## Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+48 (Typ.)
Second Order Two Tone Intercept Point	+43 (Typ.)
Third Order Two Tone Intercept Point	+29 (Typ.)

#### **Specifications**

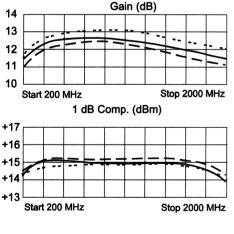
CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency	200 - 2000 MHz	200 - 2000MHz
Gain (dB)	12	11.0 Min.
Power @ 1 dB Comp. (dBm)	+15	+14.0 Min.
Reverse Isolation (dB)	- 18	- 17 Max.
VSWR In Out	<2.0:1 <1.5:1	2.2:1 Max. 2.0:1 Max.
Noise figure (dB)	3	4.0 Max.
Power Vdc	+5 48	+5 52 Max.

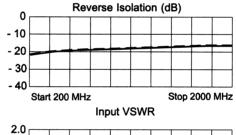
**Maximum Ratings** 

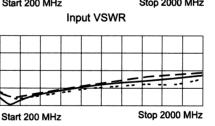
maximum ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	3 μsec Max.)

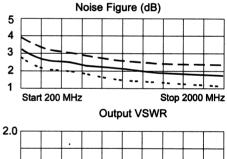
Note: Care should always be taken to effectively ground the case of each unit.

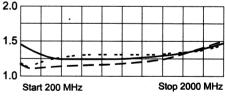
#### **Typical Performance Data**











Legend ----- + 25 °C ---- - 55 °C

Linear S-Pa	arameters							
FREQ.	S	11	S2	21	S1	2	S2	22
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
200	.31	-21	3.90	174	.10	- 6	.05	-153
400	.31	-40	3.88	151	.10	- 16	.08	-138
600	.33	-59	3.8	137	.10	- 24	.12	-146
800	.33	-79	3.79	124	.10	- 33	.12	-156
1000	.33	-97	3.82	109	.10	- 42	.14	-159
1200	.33	-115	3.86	94	.10	- 53	.16	-166
1400	.27	-138	3.84	78	.11	- 58	.19	-179
1600	.26	-164	3.87	61	.11	- 75	.18	169
1800	.22	146	3.89	41	.11	- 86	.17	156
2000	.24	71	3.73	21	.11	- 97	.16	144

1.5

1.0



Available as: TN9702, 4 Pin Surface Mount (SM3)

BX9702, Connectorized Housing (H1)

#### **Features**

■ GaAs FET; Medium Gain: 12 dB Typical ■ High Output Power: +20dBm Typical

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	500 - 1500 MHz	500 - 1500 MHz		
Gain (dB)	12	10.5 Min.		
Power @ 1 dB Comp. (dBm)	+20	+19.0 Min.		
Reverse Isolation (dB)	- 18	- 16 Max.		
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	3.0	4.5 Max.		
Power Vdc m A	+8 105	+8 110 Max.		
Note: Care should always be taken to effectively ground the case of each unit.				

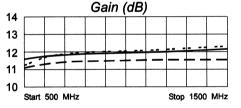
### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+46 (Typ.)
Second Order Two Tone Intercept Point	+40 (Typ.)
Third Order Two Tone Intercept Point	+31 (Typ.)

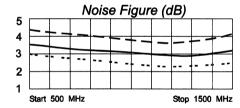
#### **Maximum Ratings**

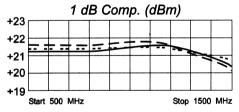
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	3 μsec Max.)

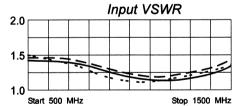
#### **Typical Performance Data**

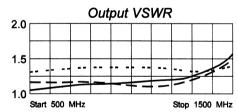












#### - + 25 °C - - - + 85 °C ----- -55 °C Linear S-Parameters

#### Mag Mag Deg Mag Deg 300 500 700 900 3.61 374 3.97 62 177 170 139 104 53 148 127 106 94 61 38



Available as: TM9705, 4 Pin TO-8 (T4)

TN9705, 4 Pin Surface Mount (SM3) WP9705, 4 Pin Gullwing (SG -15) BX9705, Connectorized Housing (H1) PN9705, Reduced Size Surface Mount (SM11)

#### **Features**

■ GaAs FET; Low Noise Figure: 1.5 dB Typical

■ High Output Power: 23 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	225 - 400 MHz	225 - 400 MHz		
Gain (dB)	15.0	14 Min/ 16 Max		
Power @ 1 dB Comp. (dBm)	+23.0	+22.0 Min.		
Reverse Isolation (dB)	-21.0	Max.		
VSWR In Out	1.7:1 1.7:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	1.5	2.0 Max.		
Power Vdc mA	+15 90	+15 100 Max.		

#### Typical Intermodulation Performance at 25 ° C

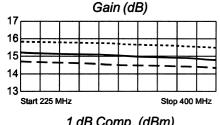
Second Order Harmonic Intercept Point		
Second Order Two Tone Intercept Point	+44	(Typ.)
Third Order Two Tone Intercept Point	+34	(Typ.)

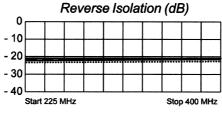
#### **Maximum Ratings**

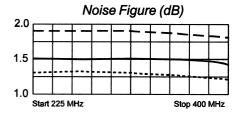
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 95 ℃
DC Voltage	+ 17 Volts
Continuous RF Input Power	+ 15 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

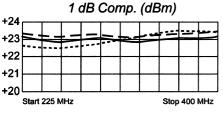
Note: Care should always be taken to effectively ground the case of each unit.

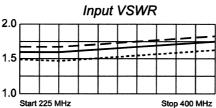
#### **Typical Performance Data**

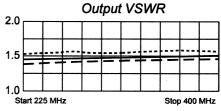












.egend----- + 25 °C - - - + 85 °C - - - - - - 55 °C

#### **Linear S-Parameters**

FREQ.	S	11	S2	21	S1	2	S	22
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
225	.22	-11	5.75	165	.0819	8	.17	- 159
260	.22	-28	5.71	160	.0825	6	.17	- 163
295	.22	-43	5.66	155	.0832	4	.17	- 166
300	.22	-57	5.61	151	.0837	2	.17	- 168
400	.23	-80	5.45	142	.0852	- 1	.18	- 173



Available as: TM9709, 4 Pin TO-8 (T4)

TN9709, 4 Pin Surface Mount (SM3) FP9709, 4 Pin Flatpack (FP4)

BX9709, Connectorized Housing (H1)
PN9709, Reduced Size Surface Mount (SM11)

#### **Features**

■ High Output Power: >+27 dBm Typical

■ High Third Order Intercept: +39 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 2000 MHz	10 - 2000 MHz
Gain (dB)	10.5	8.5 Min.
Power @ 1 dB Comp. (dBm)	>+27	+26 Min.
Reverse Isolation (dB)	- 18	-17.0 Max.
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<4.5	6.0* Max.
Power Vdc mA	+15 180	+15 190 Max.

#### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+54	(Typ.)
Second Order Two Tone Intercept Point	+48	(Typ.)
Third Order Two Tone Intercept Point	+39	(Tvp.)

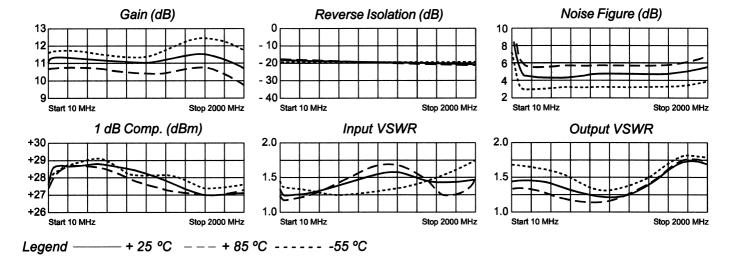
#### **Maximum Ratings**

Maximum Rau	ings	
Ambient Operation	ng Temperature	55°C to + 100 °C
Storage Tempera	ature	62°C to + 125 °C
Case Temperatur	re	+ 125 °C
DC Voltage		+ 18 Volts
Continuous RF Ir	nput Power	+ 20 dBm
Short Term RF In	put Power	200 Milliwatts
		(1 Minute Max.)
	Power	
		(3 μsec Max.)

<sup>\*</sup> Noise Figure is > 6.0 dB below 100 MHZ

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



Linear S-Parameters FREQ. -- S21 --- S12 ----- S22 -Deg. Deg. Deg. Mag Deg. 3.46 3.53 .17 .15 .15 .09 .09 .09 .11 .14 .18 100 200 400 600 800 1000 1200 1400 1600 1800 .127 166 .09 .08 .09 .17 .18 .19 .19 .14 -168 -149 -123 3.51 3.45 3.37 3.18 .126 .128 .122 .112 .113 .111 156 134 117 103 60 12 - 28 - 20 - 32 - 40 - 49 - 59 - 71 142 122 105 89 70 49 25 -122 -134 -136 -134



Available as: TM9712, 4 Pin TO-8 (T4)

TN9712, 4 Pin Surface Mount (SM3) FP9712, 4 Pin Flatpack (FP4)

BX9712, Connectrized Housing (H1)
PN9712, Reduced Size Surface Mount (SM11)

#### **Features**

■ GaAs FET Amplifier

Low Noise Figure: 3 dB Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	500 - 2000 MHz	500 - 2000 MHz
Gain (dB)	11.5	10.0 Min.
Power @ 1 dB Comp. (dBm)	+16	+15 Min.
Reverse Isolation (dB)	- 18	-17.0 Max.
VSWR In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	<3.5	4.5 Max.
VSWR Vdc mA	+15 45	+15 50 Max.

#### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point	+40 (Typ.)
Second Order Two Tone Intercept Point	+35 (Typ.)
Third Order Two Tone Intercept Point	+26 (Typ.)

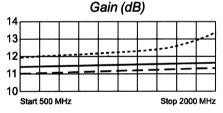
#### **Maximum Ratings**

maximam radings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**

Reverse Isolation (dB)

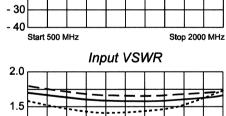


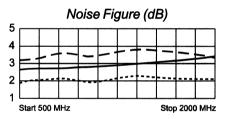
1 dB Comp. (dBm)

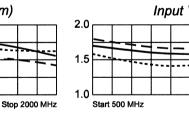
+18

+16

Start 500 MHz



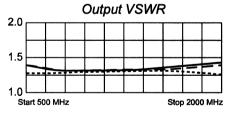




n

- 10

- 20



.egend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### **Linear S-Parameters**

FREQ.	S	S11		\$11 \$21		21	S12		<b>\$22</b> -	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.		
500	25	- 61	3.80	158	.116	- 12	.15	54		
600	.25	- 70	3.79	151	.115	- 17	.14	46		
800	.24	- 87	3.80	137	.115	- 26	.14	35		
1000	.23	-106	3.79	124	.111	- 35	.13	25		
1200	.22	-126	3.81	111	.112	- 42	.13	14		
1400	.22	-145	3.82	98	.108	- 50	.14	7		
1600	.23	-167	3.83	84	.104	- 61	.14	- 2		
1800	.23	172	3.86	70	.106	-71	.15	- 13		
2000	.25	151	3.88	55	.103	-83	.17	- 25		

Stop 2000 MHz



Available as: TM9713, 4 Pin TO-8 (T4)

TN9713, 4 Pin Surface Mount (SM3)
FP9713, 4 Pin Flatpack (FP4)
BX9713, Connectrized Housing (H1)
PN9713, Reduced Size Surface Mount (SM11)

#### **Features**

■ GaAs FET Amplifier

■ High Output Power: +21 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	500 - 2000 MHz	500 - 2000 MHz
Gain (dB)	11	8.5 Min.
Power @ 1 dB Comp. (dBm)	+21	+19.0 Min.
Reverse Isolation (dB)	- 17.5	- 16 Max.
VSWR In Out	1.8:1 1.8:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	4.5	5.5 Max.
Power Vdc mA	+15 100	+15 110 Max.

#### Typical Intermodulation Performance at 25 ° C

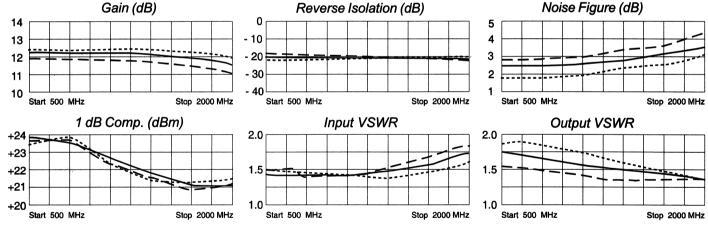
Second Order Harmonic Intercept Point	+50(Typ.)
Second Order Two Tone Intercept Point	+44(Typ.)
Third Order Two Tone Intercept Point	+34(Typ.)

#### **Maximum Ratings**

maxiiiidiii itadiige	
Ambient Operating Tempe	erature55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Pow	er + 18 dBm
Short Term RF Input Power	er 50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



.egend ——— + 25 °C --- + 85 °C ---- - 55 °C Linear S-Parameters

FREQ.	S11		S11S21		S21	S12		S22	
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg	
500	.18	169	3.88	144	.1070	- 23	.29	128	
600	.17	159	3.87	134	.1071	- 28	.28	119	
800	.16	140	3.88	116	.1065	- 39	.27	99	
1000	.16	124	3.88	98	.1049	- 51	.25	77	
1200	.14	112	3.87	79	.1040	- 63	.23	54	
1400	.14	104	3.92	60	.1010	- 76	.21	29	
1600	.14	103	3.89	40	.0976	- 91	.18	- 2	
1800	.16	98	3.76	17	.0915	- 107	.16	- 38	
2000	.18	89	3.66	- 7	.0885	- 123	.17	- 80	



Available as: TN9715, 4 Pin Surface Mount (SM3)

BX9715, Connectorized Housing (H1)

#### **Features**

■ GaAs FET Design; Medium Gain: 11 dB Typical

■ High Output Power: +26 dBm Typical

**Specifications** 

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		500 - 2000 MHz	500 - 2000 MHz
Gain (dB)		11	10.0 Min.
Power @ 1 dB Comp. (dBm)		+25	+24.0 Min.
Reverse Isolation (dB)		- 19	- 18 Max.
	n Out	<2.0:1 <1.5:1	2.3:1 Max. 2.0:1 Max.
Noise figure (dl	3)	<4.5	6.0 Max.
	/dc n A	+12 180	+12 220 Max.

#### Typical Intermodulation Performance at 25 ° C

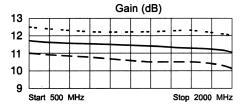
Second Order Harmonic Intercept Point	+55 (Typ.)
Second Order Two Tone Intercept Point	+49 (Typ.)
Third Order Two Tone Intercept Point	+40 (Tvp.)

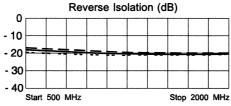
#### **Maximum Ratings**

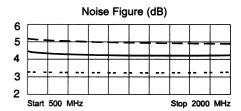
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
• • • • • • • • • • • • • • • • • • • •	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	3 usec Max.)

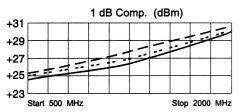
Note: Care should always be taken to effectively ground the case of each unit.

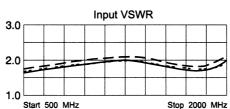
#### Typical Performance Data

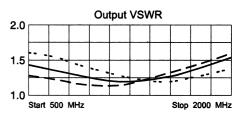












#### Linear S-Parameters

FREQ. MHz	( Mag	S11 Deg	5 Mag	521 Deg	S Mag	512 Deg	5 Mag	522 Deg
500	.26	-148	3.88	141	.11	- 26	.17	134
750	.31	-165	3.80	118	.10	- 38	.13	104
1000	.34	177	3.76	97	.10	- 48	.09	69
1250	.34	154	3.72	73	.10	- 57	.08	- 4
1500	.31	123	3.64	49	.10	- 67	.08	- 73
1750	.27	72	3.56	22	.10	- 80	.13	-110
2000	.34	5	3.36	- 8	.10	-100	.18	-129



Available as: TM9723, 4 Pin TO-8 (T4)

TN9723, 4 Pin Surface Mount (SM3) FP9723, 4 Pin Flatpack (FP4)

BX9723, Connectorized Housing (H1) PN9723, Reduced Size Surface Mount (SM11)

#### **Features**

■ GaAs FET Amplifier; Medium Gain: 13 dB Typ.

- High Output Power: > +27 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		10 - 1000 MHz	10 - 1000 MHz
Gain (dB)		13	12.0 Min.
Power @ 1 dB Comp. (dBm)		>+27	+26.0 Min.
Reverse Isolation (dB)		- 18	-17.0 Max.
VSWR	In Out	<1.75:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)		<4.0	8.0* Max.
Power	Vdc m A	+15 185	+15 195 Max.

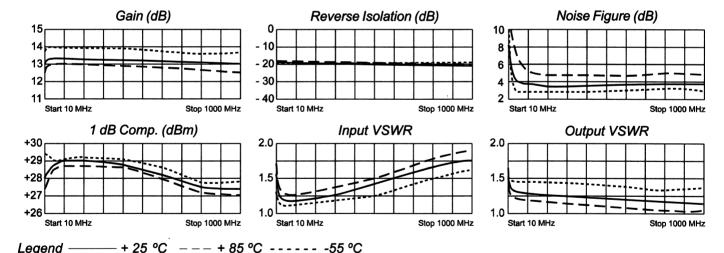
Second Order Harmonic Intercept Point	+52	(Typ.)
Second Order Two Tone Intercept Point	+48	(Typ.)
Third Order Two Tone Intercept Point	+40	(Typ.)

Typical Intermodulation Performance at 25 ° C

**Maximum Ratings** Ambient Operating Temperature ...... -55°C to + 100 °C Storage Temperature ..... -62°C to + 125 °C Case Temperature ......+ 125 °C DC Voltage ...... + 17Volts Continuous RF Input Power ...... + 18 dBm Short Term RF Input Power ...... 150 Milliwatts ...... (1 Minute Max.) Maximum Peak Power ...... 0.3 Watt (3 µsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



**Linear S-Parameters** 

FREQ.	S	11	S21		S12		\$22	
MHz	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.	Mag.	Deg.
10	21	- 57	4.51	-161	.106	11	.20	139
50	.09	- 41	4.69	179	.108	0	.13	166
100	.08	- 42	4.69	172	.109	- 2	.12	164
200	.10	- 56	4.70	161	.110	- 8	.11	159
400	.13	- 80	4.65	140	.108	- 17	.09	147
600	.19	-100	4.56	120	.104	- 27	.08	135
800	.23	-121	4.48	101	.100	- 35	.07	115
1000	.29	-139	4.47	83	.097	- 34	.04	79



Noise Figure is > 8.0 dB below 30 MHZ

Available as: TM9725, 4 Pin TO-8

TN9725-3, 4 Pin Surface Mount (SM3) FP9725-4, 4Pin Flatpack (FP4) BX9725, Connectorized Housing (H1)

#### **Features**

■Medium Gain: 11 dB Typical

■ High Output Power: +26.5 dBm Typical

■ High IP<sub>3</sub>: +38 dBm Typical

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	500 - 2000 MHz	500 - 2000 MHz	
Gain (dB)	11	10.0 Min.	
Power @ 1 dB Comp. (dBm)	+26.5	+25.0 Min.	
Reverse Isolation (dB)	- 19	- 18 Max.	
VSWR In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.	
Noise figure (dB)	3.75	6.0 Max.	
Power Vdc mA	+15 165	+15 190 Max.	

#### Typical Intermodulation Performance at 25 ° C

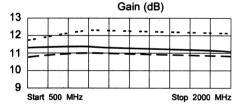
Second Order Harmonic Intercept Point	+51(Typ.)
Second Order Two Tone Intercept Point	+45(Typ.)
Third Order Two Tone Intercept Point	+38(Typ.)

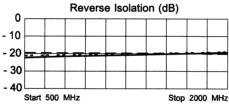
#### **Maximum Ratings**

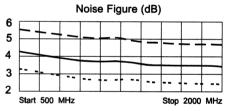
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	
	3 μsec Max.)

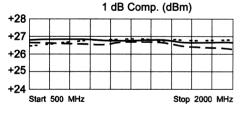
Note: Care should always be taken to effectively ground the case of each unit.

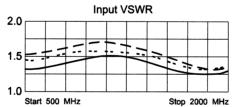
#### **Typical Performance Data**

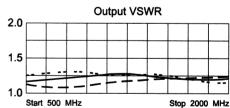












Legend ----- + 25 °C ---- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11		S21		S12	:	S22
MHz	Mag Deg	Mag	Deg	Mag	Deg	Mag	Deg
500 750 1000 1250 1500 1750 2000	20 - 76 24 -100 25 -126 24 -152 21 179 .17 139 .14 79	3.73 3.77 3.71 3.62 3.52 3.41 3.26	153 131 110 90 70 49 28	.11 .10 .10 .10 .10 .11	- 5 -13 -19 -23 -26 -32 -39	.05 .08 .10 .11 .12 .11	108 80 48 20 - 12 - 44 - 82



Available as: TR9737, 4 Pin TO-8 (T4)

FP9737-4, 4 Pin Flatpack (FP4) BR9737, Connectrized Housing (H2)

#### **Features**

■ GaAs FET Low Noise Figure: <4.5 dB Typical

- High Output Power: +24 dBm Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C		
Frequency	100 - 2000 MHz	200 - 2000 MHz		
Gain (dB)	9.5	8.0 Min.		
Power @ 1 dB Comp. (dBm)	+24	+22.0 Min.		
Reverse Isolation (dB)	- 14	- 13 Max.		
VSWR In Out	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.		
Noise figure (dB)	<4.5	6.5 Max.		
VSWR Vdc mA	+15 140	+15 160 Max.		

#### Typical Intermodulation Performance at 25 ° C

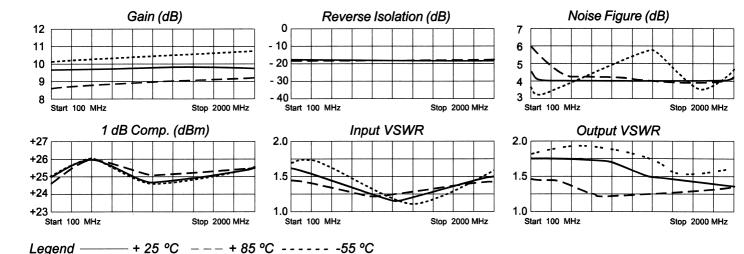
Second Order Harmonic Intercept Point	+54(Typ.)
Second Order Two Tone Intercept Point	+49(Typ.)
Third Order Two Tone Intercept Point	+38(Typ.)

#### **Maximum Ratings**

maxiiiluiii Nauiiyə	
Ambient Operating Temperatu	re55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 18 dBm
Short Term RF Input Power	100 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



#### Linear S-Parameters

FREQ.	S11		S21		S12		S22	
MHz	Mag De	g	Mag	Deg	Mag	Deg	Mag	Deg
100	.24 17	9	2.97	171	.13	- 3	.26	163
200	.24 17	1	2.95	161	.13	- 7	.26	147
500	.20 15	4	2.93	132	.14	- 18	.24	101
1000	.08 13	3	3.01	84	.15	- 41	.24	24
1500	.09 -14	0	3.11	29	.16	- 69	.22	- 54
2000	.15 17	7	3.00	-34	.16	-106	.24	- 127



Available as: TM9738, 4 Pin TO-8 (T4)

TN9738, 4 Pin Surface Mount (SM3) FP9738, 4 Pin Flatpack (FP4) BX9738, Connectorized Housing (H1) PN9738, Reduced Size Surface Mount (SM11)

#### **Features**

High Out put Power: +25 dBm Typical

■ High Third Order Intercept: +39 dBm Typical

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC		<b>TYPICAL</b> Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency		200 - 2000 MHz	200 - 2000 MHz
Gain (dB)		11	9 Min.
Power @ 1 dB Comp. (dBm)		+25.5	+24.0 Min.
Reverse Isolation	(dB)	- 19	-17.0 Max.
VSWR	In Out	<1.5:1 <1.5:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)		<4.0	5.2 Max.
Power	Vdc m A	+15 140	+15 160 Max.

### Typical Intermodulation Performance at 25 ° C

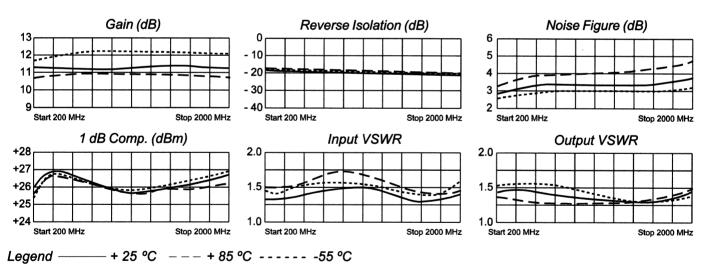
Second Order Harmonic Intercept Point	+52	(Typ.)
Second Order Two Tone Intercept Point	+46	(Typ.)
Third Order Two Tone Intercept Point	+39	(Typ.)

#### **Maximum Ratings**

3	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**





Available as: TR9755, 4 Pin TO-8B (T8)

TR9755-9, 12 Pin TO-8B (T9)

RN9755, 4 Pin Surface Mount (SM19) BR9755, Connectorized Housing (H2)

#### **Features**

- Low Noise Figure:1dB Typical
- Low 5 Volts Operation
- Operating Temp. 55 °C to + 85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	800-1200 MHz	800-1200 MHz
Gain (dB)	26	24 Min.
Power @ 1 dB Comp. (dBm)	+14	+13 Min.
Reverse Isolation (dB)	- 38	- 36 Max.
VSWR In Out	1.8:1 1.8:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.0	1.75 Max.
Power Vdc mA	+5 62	+5 65 Max.

Note: Care should always be taken to effectively ground the case of each unit.

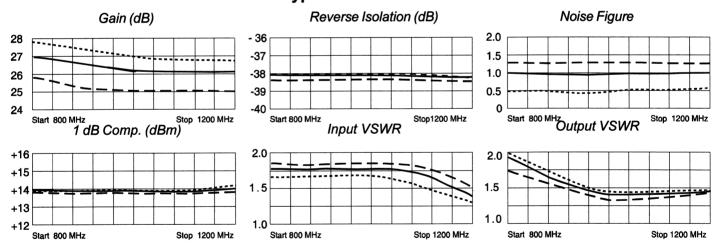
#### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point+46dBm (Typ.)
Second Order Two Tone Intercept Point +40dBm (Typ.)
Third Order Two Tone Intercept Point +25dBm (Typ.)

#### **Maximum Ratings**

Ambient Operating Temperature55°	C to + 100 °C
Storage Temperature62°C	C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 8 Volts
Continuous RF Input Power	+ 13 dBm
Short Term RF Input Power200 Milliwatts(1 I	Minute Max.)
Maximum Peak Power 0.5(3	μsec Max.)

#### **Typical Performance Data**



Legend ----- + 25 °C --- + 85 °C ---- - -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22	Del
MHz	Mag Deg	<u>M</u> ag Deg	Mag Deg	Mag Deg K	
800 900 1000 1100 1200	.18 -116 .19 -167 .15 159 .07 111 .10 -11	22.80 -128 21.58 -158 20.93 173 20.39 147 20.39 118	.0099 32 .0107 14 .0104 -9 .0105 -30 .0102 -53	.23 37 2.10 .19 15 2.10 .17 -9 2.26 .17 -36 2.35 .18 -67 2.42	.19 .20 .19 .20



Available as:

TR9756, 4 Pin TO-8B (T8)

TR9756-9, 12 Pin TO-8B (T9)

RN9756, 4 Pin Surface Mount (SM19) BR9756, Connectorized Housing (H2)

#### **Features**

- Low Noise Figure: < 1 dB Typical</p>
- Low 5 Volt Operation
- Unconditionally Stable
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (mHz)	1200 - 1700 MHz	1200 - 1700 MHz
Gain (dB)	27	25.0 Min.
Power @ 1 dB Comp. (dBm)	+15	+14 Min.
Reverse Isolation (dB)	- 38	- 36 Max.
VSWR In	1.8:1	2.0:1 Max.
Out	1.8:1	2.0:1 Max.
Noise figure (dB)	<1.0	1.75 Max.
Power Vdc	+5	+5
mA	60	63 Max.

#### Typical Intermodulation Performance at 25 ° C

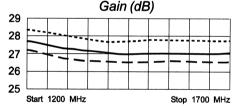
Second Order Harmonic Intercept Point......+46 dBm (Typ.) Second Order Two Tone Intercept Point......+40 dBm (Typ.) Third Order Two Tone Intercept Point......+26 dBm (Typ.)

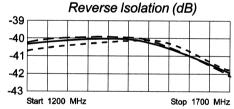
#### **Maximum Ratings**

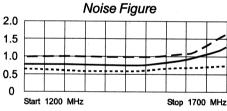
3 -	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.)

Note: Care should always be taken to effectively ground the case of each unit.

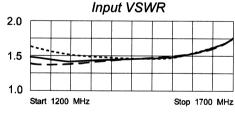
#### **Typical Performance Data**

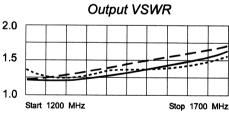












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### **Linear S-Parameters**

FREQ	8	S11S21		S12-	S12		S22			
MHz 	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg	K	Del
1200 1300 1400 1500 1600 1700	.06 .11 .14 .13 .07 .15	121 166 163 152 108 -25	24.08 22.94 21.96 21.77 21.35 21.35	-157 176 152 126 99 69	.0103 1 .0115 .0113 .0097	16 01 82 53 39	.01 .02 .03 .04 .05	-42 -99 -130 -153 -170 170	2.22 2.20 2.07 2.12 2.51 3.29	.24 .24 .26 .25 .21 .15



Available as:

TR9757, 4 Pin TO-8B (T8)

TR9757-9, 12 Pin TO-8B (T9) RN9757, 4 Pin Surface Mount (SM19) BR9757, Connectorized Housing (H2)

#### **Features**

Low Noise Figure: 1.5 dB Typical

■ Low 5 Volt Operation

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	1700-2400MHz	1700-2400MHz
Gain (dB)	23	22 Min.
Power @ 1 dB Comp. (dBm)	+15	+14 Min.
Reverse Isolation (dB)	-33	-32 Max.
VSWR In	1.5:1	2.0:1 Max.
Out	1.5:1	2.0:1 Max.
Noise figure (dB)	1.5	2.2 Max.
Power Vdc	+5	+5
mA	60	64 Max.

Note: Care should always be taken to effectively ground the case of each unit.

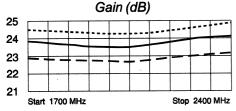
## Typical Intermodulation Performance at 25 ° C

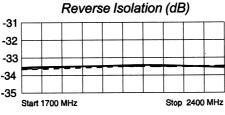
Second Order Harmonic Intercept Point.......+46dBm (Typ.) Second Order Two Tone Intercept Point.......+40dBm (Typ.) Third Order Two Tone Intercept Point......+26dBm (Typ.)

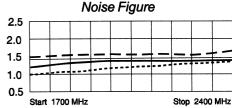
#### **Maximum Ratings**

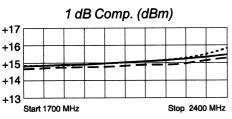
Maximum ratings	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
·	(1 Minute Max.
Maximum Peak Power	0.5 Wat
	(3 μsec Max.

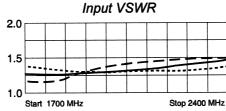
#### **Typical Performance Data**

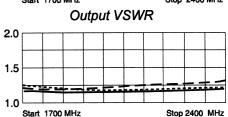












Legend ----- + 25 °C ---- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ.	S11	S21	S12	S22		
MHz	Mag Deg	Mag Deg	Mag Deg	Mag Deg	K	Del
1700	.20 -85	15.72 126	.0155 8	.24 -20	2.00	.27
1800	.20 -81	15.00 112	.0182 -20	. <b>19 -29</b>	1.87	.31
1900	.19 -78	15.04 98	. <b>0206 -5</b>	. <u>16 -42</u>	1.69	.34
2000	.20 -74	14.80 84	.0160 -20	.13 -51	2.13	.26
2100	.19 -69	14.79 69	.0177 -30	.10 -59	1.97	.28
2200	.19 -62	15.12 55	.0214 -38	.07 -62	1.66	.33
2300	.19 -50	15.50 38	.0203 -38	.06 -63	1.68	.32
2400	.24 -38	15.60 20	.0229 -36	.04 -58	1.50	.36



Available as: TR9770, 4 Pin TO-8B (T8)

TR9770-9, 12 Pin TO-8B (T9)

RN9770, 4 Pin Surface Mount (SM19) BR9770, Connectorized Housing (H2)

#### **Features**

- Low Noise Figure:1dB Typical
- **Unconditionally Stable**
- Operating Temp. 55 °C to +85 °C
- **Environmental Screening Available**

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	800-1200 MHz	800-1200 MHz
Gain (dB)	25	24 Min.
Power @ 1 dB Comp. (dBm)	+14	+13 Min.
Reverse Isolation (dB)	- 38	- 36 Max.
VSWR In Out	1.8:1 1.8:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.0	1.75 Max.
Power Vdc mA	+15 62	+15 65 Max.

### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point+46dBm (Typ.) Second Order Two Tone Intercept Point +40dBm(Typ.) Third Order Two Tone Intercept Point +25dBm(Typ.)

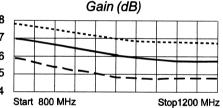
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
	(1 Minute Max.)
Maximum Peak Power	0.5 Watt
	(3 μsec Max.

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**

Reverse Isolation (dB)



1 dB Comp. (dBm)

16

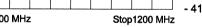
15

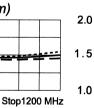
14

13

12

Start 800 MHz





-37

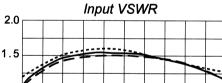
- 38

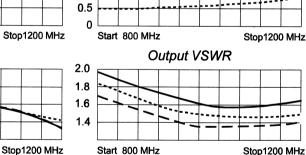
- 39

-40

Start 800 MHz

Start 800 MHz





Noise Figure

- + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S1 Mag	1 Deg	: Mag	521 Deg	{ 	S12 Deg	 Mag	S22 Deg	- К	Del
800	.21	157	21.01	-128	.0100	 27	.26	29	2.21	.20
900	.30	139	19.59	-160	.0104	11	.20	13	2.22	.18
1000	.29	115	18.96	171	.0093	-19	.16	Ĭ	2.58	.14
1100	.25	82	18.61	143	.0111	-42	.14	-14	2.30	.18
1200	.23	30	18.79	113	.0110	-66	.11	-38	2.36	.19



2707 Black Lake Place, Philadelphia, PA 19154

2.0

1.5

1.0

Available as:

TR9771, 4 Pin TO-8B (T8) TR9771-9, 12 Pin TO-8B (T9)

RN9771, 4 Pin Surface Mount (SM19) BR9771, Connectorized Housing (H2)

#### **Features**

- Low Noise Figure: <1dB Typical
- Unconditionally Stable
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C			
Frequency (MHz)	1200-1700MHz	1200-1700MHz			
Gain (dB)	27	25 Min.			
Power @ 1 dB Comp. (dBm)	+15	+14 Min.			
Reverse Isolation (dB)	- 38	- 36 Max.			
VSWR In	1.8:1	2.0:1 Max.			
Out	1.8:1	2.0:1 Max.			
Noise figure (dB)	<1.0	1.75 Max.			
Power Vdc mA	+15 60	+15 63 Max.			

Note: Care should always be taken to effectively ground the case of each unit.

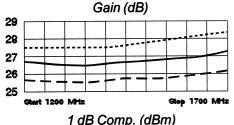
## Typical Intermodulation Performance at 25 ° C

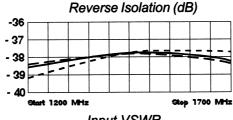
Second Order Harmonic Intercept Point	. +46dBm(Typ.)
Second Order Two Tone Intercept Point	+40dBm(Typ.)
Third Order Two Tone Intercept Point	.+26dBm (Typ.)

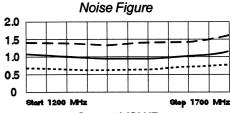
#### **Maximum Ratings**

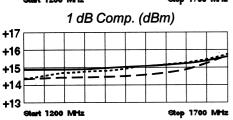
111454111141111111111111111111111111111	
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	
DC Voltage	+ 18 Volts
Continuous RF Input Power	
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.
Maximum Peak Power	
	(3 μsec Max.

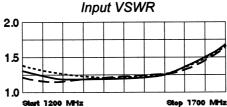
#### **Typical Performance Data**

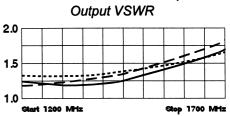












Legend ----- + 25 °C --- + 85 °C ----- -55 °C

#### Linear S-Parameters

FREQ. MHz	S11 Mag Deg	S21 Mag Deg	S12 Mag Deg	S22 Mag Deg	K	Del
1200 1300 1400 1500 1600 1700	21 57 .15 52 .10 51 .08 36 .10 11 .22 -28	24.56 -163 23.86 171 22.90 146 23.13 121 22.89 93 22.82 61	.0109 118 .0128 96 .0172 79 .0170 54 .0174 32 .0147 -5	.03 -4 .03 -37 .04 - 69 .05 -101 .06 -128 .06 -164	1.93 1.76 1.45 1.46 1.44 1.58	.27 .31 .40 .40 .40



Available as:

TR9772, 4 Pin TO-8B (T8)

TR9772-9, 12 Pin TO-8B (T9) RN9772, 4 Pin Surface Mount (SM19)

BR9772, Connectorized Housing (H2)

#### **Features**

Low Noise Figure: 1.5 dB Typical

**Unconditionally Stable** 

■ Operating Temp. - 55 °C to +85 °C

Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	1700-2400MHz	1700-2400MHz
Gain (dB)	23	22 Min.
Power @ 1 dB Comp. (dBm)	+15	+14 Min.
Reverse Isolation (dB)	-35	-33 Max.
VSWR In Out	1.8:1 1.8:1	2.0:1 Max. 2.0:1 Max.
Noise figure (dB)	1.5	2.2 Max.
Power Vdc mA	+15 65	+15 70 Max.

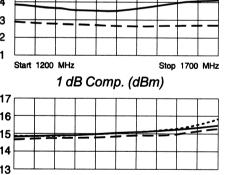
#### Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point...... +46dBm (Typ.) Second Order Two Tone Intercept Point.......+40dBm (Typ.) Third Order Two Tone Intercept Point.....+26dBm (Typ.)

#### **Maximum Ratings**

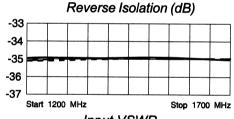
Note: Care should always be taken to effectively ground the case of each unit.

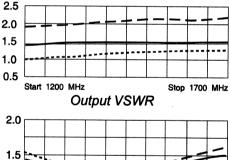
#### Typical Performance Data



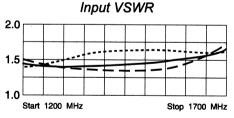
Start 1200 MHz

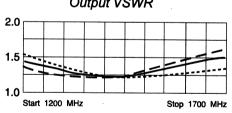
Gain (dB)





Noise Figure





+ 25 °C --- + 85 °C ---- -55 °C Legend -

Stop 1700 MHz

#### Linear S-Parameters

FREQ. MHz	S11- Mag De		: Mag	S21 Deg	S Mag	S12 Deg	: Mag	S22 Deg	ĸ	Del
======	:======::	======	-========	=======	========	=======	========	======	======	=====
1700	.20 -8	5	15.72	126	.0155	8	.24	-20	2.00	.27
1800	.20 -8	1	15.00	112	.0182	-20	.19	-29	1.87	.31
1900	.19 -7		15.04	98	.0206	-5	.16	-42	1.69	.34
2000	.20 -7		14.80	84	.0160	-20	.13	- <del>5</del> 2	2.13	.26
2100	.19 -6		14.79							
					.0177	-30	.10	-59	1.97	.28
2200	.19 -6		15.12		.0214	-38	.07	-62	1.66	.33
2300	.19 -5		15.50		.0203	-38	.06	-63	1.68	.32
2400	.24 -3	8	15.60	20	.0229	-36	.04	-58	1.50	.36



# COUGAR COMPONENTS DIRECT CROSS LIST

Cougar	Amplifonix	Cougar	Amplifonix	Cougar	Amplifonix	Cougar	Amplifonix
AC105	TM7105	AC548	TM6547	AC1218	TM9340	AP2009	TM9709
AC107	TM7207	AC555	TM6416	AC1219	TM9339	AP2509	TM9759
AC251	TM7570	AC556	TM6576	AC1226	TM9337	AR356	TR7256
AC271	TM7270	AC557	TM6516	AC1228	TM9344	AR1094	TR9794
AC272	TM7172	AC558	TM6545	AC1264	TM9164	AR2066	TR9766
AC273	TM7370	AC559	TM6655	AC1266	TM9166	AR2577	TR9777
AC281	TM7481	AC564	TM6664	AC1269	TM9269	AR2584	TM9784
AC282	TM7182	AC566	TM6524	AC1523	TM9523	GC2001	TG9001
AC293	TM7193	AC572	TM6520	AC1525	TM9225	GC2530	TG9030
AC305	TM7147	AC573	TM5673	AC1526	TM9126	LA507	TL9002
AC345	TM7145	AC575	TM6575	AC1527	TM9127	LA1017	TML9017
AC347	TM7347	AC576	TM6276	AC1528	TM9128	LC1501	TL9013
AC378	TM7278	AC577	TM6577	AC1529	TM9329	LC1502	TL9014
AC379	TM7279	AC580	TM6517	AC1582	TM9328	LG2001	TL9003
AC380	TM7381	AC581	TM6581	AC1586	TM9524	7.93	
AC381	TM7281	AC582	TM6582	AC2005	TM9135		
AC382	TM7282	AC583	TM6583	AC2017	TM9317		
AC383	TM6683	AC588	TM6588	AC2023	TM9322		
AC386	TM7386	AC751	TM9751	AC2025	TM9341	Marting Exp. 3-49	
AC391	TM7291	AC829	TM6345	AC2034	TM9134		
AC437	TM6587	AC838	TM9183	AC2037	TM9137		
AC453	TM6443	AC847	TM9147	AC2038	TM9138		
AC457	TM6444	AC848	TM9148	AC2039	TM9139		
AC487	TM6487	AC936	TM9192	AC2046	TM9146	11.00	
AC501	TM6501	AC986	TM9186	AC2075	TM9725	and the second	
AC505	TM6505	AC1012	TM9102	AC2078	TM9778		
AC508	TM6558	AC1017	TM9117	AC2348	TM9748		
AC509	TM6509	AC1018	TM9118	AC2366	TM9343	AN REST OF CHEST	
AC513	TM6675	AC1019	TM9319	AC2426	TM9342	17963	
AC514	TM6614	AC1022	TM9311	AC2578	TM9345		
AC518	TM6526	AC1035	TM9335	AGC525	TMG9553		
AC519	TM6619	AC1036	TM9113	AP294	TM7294		
AC524	TM6574	AC1037	TM6145	AP348	TM7148		
AC525	TM6625	AC1038	TM9338	AP388	TM7388		
AC540	TM5101	AC1054	TM9325	AP389	TM7189		
AC541	TM5110	AC1057	TM9157	AP448	TM6448		
AC542	TM6147	AC1063	TM9163	AP561	TM6661	999	
AC543	TM6543	AC1066	TM9366	AP1053	TM9753		
AC544	TM6544	AC1068	TM9368	AP1309	TM9769		
AC545	TM6645	AC1069	TM9369	AP1532	TM9785	1000	
AC547	TM6557	AC1082	TM9107	AP2008	TM9708		

Please visit our website for the most recent list of

<u>Drop-in Replacement Parts</u>

www.amplifonix.com

## TYCO, M/A-Com, Watkins Johnson Direct Cross List

TYCO	Amplifonix	TYCO	Amplifonix	TYCO	Amplifonix	TYCO	Amplifonix
A-1	TM6501	A-36	TM9136	A-74-1	TM7274	A-33	TM9133
A-3	TM6503	A-36-1	TM9336	A-74-2	TM6674	A-34	TM9134
A-5	TM6505	A-37	TM9137	A-75	TM66575	A-35	TM9135
A-5-5	TM6605	A-38	TM9138	A-75-2	TM7275	LA-7	TML9002
A-7	TM6607	A-39	TM9139	A-75-3	TM6675	LA-17	TML9017
A-9	TM6609	A-54	TM6554	A-76	TM6576	LA-88	TML9088
A-11	TM9111	A-55	TM6555	A-77	TM6577	LG-1	TML9003
A-11-2	TM9311	A-56	TM6556	A-77-1	TM6677	RA-89-1	TR6689
A-12	TM9112	A-57	TM6557	A-78	TM7278	A-72	TM6572
A-16-2	TM9316	A-58	TM6558	A-79	TM7279	A-73	TM6573
A-17	TM9117	A-59	TM6559	A-81	TM7281	A-74	TM6574
A-18	TM9118	A-59-1	TM6659	A-81-1	TM7381	LG-30	TML9009
A-18-1	TM9318	A-63	TM9163	A-81-2	TM6581	PA-3	TM6203
A-19	TM9119	A-63-1	TM9363	A-81-3	TM6681	PA-12	TM6212
A-19-1	TM9319	A-64	TM9164	A-82	TM7282	PA-37	TR9737
A-23	TM9123	A-65	TM9165	A-82-1	TM7382	G-30	TG9030
A-24	TM9124	A-66	TM9166	A-83	TM6583	L-1	TL9010
A-25	TM9125	A-66-1	TM9366	A-83-1	TM6683	L-2	TL9011
A-25-1	TM9325	A66-3	TM9566	A-86	TM7286	RA-66	TR9666
A-26	TM9126	A-67	TM9167	A-87	TM6587	RA-69	TR9169
A-27	TM9127	A-67-1	TM6667	A-87-1	TM6487	RA-76	TR6676
A-28	TM9128	A-70	TM7170	A-87-2	TM7287	RA-89	TR6589
A-28-2	TM9328	A-70-1	TM7270	A-88	TM6588		
A-29	TM9129	A-70-2	TM6670	AL-7	TL9012		
A-29-1	TM9329	A-70-3	TM7370	G-1	TG9001		
A-31-1	TM9331	A-71	TM7271	G-2	TG9022		

## TYCO, M/A-COM, DIRECT CROSS LIST

M/A-Com	<b>Amplifonix</b>	M/A-Com	<b>Amplifonix</b>	M/A-Com	Amplifonix	M/A-Com	<b>Amplifonix</b>
AMC103	TM6103	AM143	TM6143	AM157	TM6157	AMC123	BX6131
AM112	TM6112	AM145	TM6145	AM162	TM6162	AMC183	TM6183
AM117	TM6117	AM146	FP6146	AM171	TM6171	AMC184	TM6184
AM119	TM6119	AM147	TM6147	AM176	TM6176	AT101	FPG9101
AM124	TM6124	AM149	TM6149	AM181	TM6181	34 Jan 19 8 4	
AM131	TM6131	AM153	TM6153	AM191	TM6191		
AM134	FP6134	AM155	TM6155	AM210	TM6210		

Please visit our website for the most current list of
Drop-in Replacement Parts
www.amplifonix.com

# AVNET, AVANTEK DIRECT CROSS LIST

Avantek	Amplifonix	Avantek	Amplifonix	Avantek	Amplifonix	Avantek	Amplifonix
AFC330	TKG9330	UTC5-152	BX1560-4	UTO502	TM6605	UTO1011	TM9111
AGC553	TMG9553	UTC11-102	BX1559-4	UTO503	TM6603	UTO1012	TM9312
GPD110	CZ8110	UTC11-108	BX1558-4	UTO504	TM6704	UTO1013	TM9313
GPD120	CZ8120	UTC12-104	BX2531-4	UTO505	TM6705	UTO1023	TM9723
GPD130	CZ8130	UTD2001	TMJ9901	UTO507	TM6507	UTO1024	TM9182
GPD201	CZ8201	UTD2002	TMJ9902	UTO509	TM6509	UTO1033	TM9333
GPD202	CZ8202	UTD2004	TMJ9904	UTO510	TM6510	UTO1043	TM9143
GPD251	CZ8251	UTD1000	TMJ9910	UTO511	TM6511	UTO1044	TM9144
GPD310	CZ8310	UTF015	TG9015	UTO512	TM6512	UTO1502	TM9502
GPD320	CZ8320	UTF025	TG9001	UTO513	TM6513	UTO1522	TM9522
GPD330	CZ8330	UTF030	TG9030	UTO514	TM6514	UTO1524	TM9524
GPD401	CZ8401	UTL502	TML9052	UTO515	TM6515	UTO2012	TM9712
GPD402	CZ8402	UTL503	TML9053	UTO516	TM6516	UTO2013	TM9713
GPD403	CZ8403	UTO101	TM7101	UTO518	TM6518	UTO2022	TM9322
GPD404	CZ8404	UTO102	TM7102	UTO519	TM6519	UTO2023	TM9323
GPD405	CZ8405	UTO103	TM7103	UTO520	TM6520	UTO2024	TM9324
GPD461	CZ8461	UTO104	TM7104	UTO521	TM6521	UTO2025	TM9725
GPD462	CZ8462	UTO111	TM7111	UTO523	TM6523	UTO2027	TM9327
GPD463	CZ8463	UTO210	TM7210	UTO524	TM6524	UTO2052	TM9352
GPD464	CZ8464	UTO211	TM7211	UTO526	TM6526	UTO2055	TM9355
GPM1052	CZ8052	UTO221	TM7221	UTO533	TM6533	UTO2302	TM9302
PPA253	LN7253	UTO222	TM7222	UTO543	TM6543	15 15 15 15 15 15 15 15 15 15 15 15 15 1	
PPD2001	LNJ9901	UTO250	TM7250	UTO544	TM6544		
PPD6002	PLJ9962	UTO416	TM6416	UTO545	TM6545		
PPL504	PNL9054	UTO421	TM6421	UTO547	TM6547		
UDL502	TDL9552	UTO440	TM6440	UTO552	TM6152		
UTC5-115	BX2530-4	UTO441	TM6441	UTO554	TM6654		
UTC5-123	BX1556-4	UTO442	TM6442	UTO1001	TM9101		
UTC5-133	BX1557-4	UTO443	TM6443	UTO1002	TM9102		
UTC5-135	BX2529-4	UTO444	TM6444	UTO1005	TM9105	a service for every	
UTC5-142	BX2532-4	UTO501	TM6601	UTO1006	TM9106		
UTC5-150	BX1561-4	A PERSONAL PROPERTY.		UTO1007	TM9107		

Please visit our website for the most current list of <u>Drop-in Replacement Parts</u> www.amplifonix.com TYCO. M/A-Com. PHOENIX DIRECT CROSS LIST

TYCO	Amplifonix	TYCO	Amplifonix	TYCO	Amplifonix	TYCO	Amplifonix
PA002	TM7302	PA280	TM9128	PA630	TM9163	PA929	TM9729
PA005	TM6505	PA290	TM9329	PA640	TM9164	PA943	TM6524
PA010	TM6511	PA291	TM9391	PA650	TM9165	PA946	TM9170
PA015	TM9717	PA330	TM9330	PA661	TM6261	PA952	TM6752
PA030	TM6530	PA340	TM9134	PA663	TM9306	PA955	TR9155
PA050	TM6550	PA350	TM9135	PA670	TM9167	PA958	TR4758
PA055	TM7055	PA360	TM9136	PA671	TM6667	PA959	TR4759
PA056	TM7056	PA370	TM9137	PA700	TM7200	PA960	TM9166
PA10	TM5110	PA380	TM9180	PA701	TM7270	PA961	TR4761
PA100	TM9716	PA381	TM9381	PA780	TM7278	PA965	TM6147
PA110	TM9110	PA390	TM9139	PA790	TM7279	PA966	TM7966
PA112	TM9311	PA510	TM5107	PA820	TM7282	PA969	TR4769
PA120	TM9112	PA530	TM6143	PA860	TM7286	PA974	TR4174
PA150	TM9102	PA540	TM6554	PA861	TM9313	PA975	TM5102
PA162	TM9316	PA550	TM6555	PA870	TM6587	PA978	TM9366
PA170	TM9117	PA560	TM6556	PA871	TM6487	PA989	TR9189
PA177	TR4777	PA570	TM5126	PA891L	TR6689	PA984	TR4784
PA179	TR4779	PA702	TM6670	PA899	TM6599	PA992	TR4792
PA180	TM9118	PA703	TM7370	PA902	TM6509	PA1005	TM9705
PA181	TM9318	PA710	TM7271	PA903	TM5103	PA1017	TR4717
PA190	TM9790	PA720	TM6572	PA905	TM5101	PA1028	TM6128
PA191	TM9191	PA740	TM6521	PA907	TM9707	PA1046	TM7102
PA195	TR4795	PA741	TM7274	PA908	TM6508	PA1056	TR4756
PA196	TR4796	PA750	TM6575	PA910	TM5119	PA1059MI	TM7186
PA197	TR4797	PA752	TM7275	PA914	TM6547	PA1060	TR4760
PA198	TR4798	PA753	TM6675	PA915	TM6522	PLA070	TML9002
PA211	TM9181	PA760	TM6576	PA916	TM9706	PPA557	PN6198
PA219	TM6719	PA770	TM6577	PA918	TM7918		
PA240	TM9124	PA771	TM6571	PA919	TM7919	anga	
PA250	TM9502	PA778	TM6178	PA920	TM6519	1000	
PA260	TM9126	PA580	TM7580	PA923	TM6345	0.53	
PA270	TM9370	PA590	TM6559	PA926	TM5124	0.4	
PA278	TR4778	PA591	TM6659	PA928	TM9528		

## TYCO, ANZAC SWITCH DIRECT CROSS LIST

ANZAC	AMPLIFONIX	ANZAC	AMPLIFONIX	ANZAC	AMPLIFONI	ANZAC	AMPLIFONI
SW203	TWK2203	SW217	TWD2217	SW241	TWD2241	SW255	TWD2255
SW204	TKP2204	SW218	TWD2218	SW242	TWD2242	SW257	TWD2257
SW205	TWD2205	SW219	TWP2219	SW244	TWD2244	SW258	TWD2258
SW206	TWD2206	SW224	TWK2224	SW245	TWD2245	SW261	TWP2261
SW209	TWP2209	SW231	TWP2231	SW247	TWP2247	SW262	TWP2262
SW213	TWK2213	SW232	TWP2232	SW248	TWP2248	SW264	TWP2264
SW214	TWP2214	SW233	TWP2233	SW251	TWP2251	SW265	TWP2265
SW215	TWD2215	SW234	TWP2234	SW252	TWP2252	SW278	TWN2278
SW216	TWD2216	SW238	TWP2238	SW254	TWD2254		

Please visit our website for the most current list of

**Drop-in Replacement Parts** 

www.amplifonix.com

## **VARI-L DIRECT CROSS LIST**

Vari-L	Amplifonix	Vari-L	Amplifonix	Vari-L	Amplifonix	Vari-L	Amplifonix
VCO102	TOM9300	VCO106	TOM9309	VCO114	TOM9114	VCO118	TOM9306
VCO104	TOM9303	VCO111	TOM9111	VCO116	TOM9304	021	
VCO105	TOM9305	VCO113	TOM9301	VCO117	TOM9307	1000	and the

## **MOTOROLA DIRECT CROSS LIST**

Motorola	Amplifonix	Motorola	Amplifonix	Motorola	Amplifonix	Motorola Amplifonix
MWA110	CZ8110	MWA210	CZ8210	MWA310	CZ8310	This units are Motorola published
MWA120	CZ8120	MWA220	CZ8220	MWA320	CZ8320	IID: ID I I I I I I I I I I I I I I I I
MWA130	CZ8130	MWA230	CZ8230	MWA330	CZ8330	"Direct Replacement Devices".

## **Q-bit DIRECT CROSS LIST**

Q-bit	Amplifonix	Q-bit	Amplifonix	Q-bit	Amplifonix	Q-bit	Amplifonix
QBH101	TM5101	QBH119	TM5119	QBH138	TM5138	QBH817	TM5817
QBH102	TM5102	QBH122	TM5122	QBH147	TM5147	QBH822	TM5822
QBH103	TM5103	QBH124	TM5124	QBH149	TM5149	QBH834	TM5834
QBH104	TM5104	QBH125	TM5125	QBH150	TM5150	QBH853	TR5853
QBH105	TM5105	QBH126	TM5126	QBH152	TM5152		
QBH107	TM5107	QBH131	TM5131	QBH155	TM5155	100	
QBH109	TM5109	QBH133	TM5133	QBH175	TM5175		
QBH110	TM5110	QBH136	TM5136	QBH198	TM5198	1799	
QBH118	TM5118	QBH137	TM5137	QBH304	TM5304		

Please visit our website for the most current list of Drop-in Replacement Parts www.amplifonix.com

## **Voltage Controlled Oscillators**

We also offer drop-in replacement crosses to other manufacturers such as Vari-L.

Vari-L	Amplifonix	Vari-L	Amplifonix	Vari-L	Amplifonix	Vari-L	Amplifonix
VCO102	TOM9300	VCO106	TOM9309	VCO114	TOM9114	VCO118	TOM9306
VCO104	TOM9303	VCO111	TOM9111	VCO116	TOM9304		
VCO105	TOM9305	VCO113	TOM9301	VCO117	TOM9307		

## **VCO Application Notes**

#### Phase Noise and its effect on your PLL

The center of a Phase Locked Loop is a voltage-controlled oscillator which is locked to a reference frequency. The lock is accomplished using the DC output from a Phase Detector in the loop which is amplified and lowpass filtered providing the correction voltage for the VCO. Phase noise of a PLL output is influenced by the reference signal, loop dividers, loop bandwidth (set by the lowpass filter), and of paramount importance, the VCO. While a clean reference source combined with the extremely high low frequency loop gain will "wipe off" noise within the loop bandwidth, divider and reference spurs often dictate a narrow loop bandwidth. This places the burden of low phase noise on the VCO, since the overall phase noise is equal to that of the free running VCO at carrier offsets outside the loop bandwidth.

#### Wider bandwidths than a full octave

Generally, a VCO is specified in bandwidths of up to a full octave. To do this, a design must perform not only within the band, but also outside the band in order to duplicate the desired in-band specification in production. At times, the out of bandwidth percentage may be significant. In those cases, we may alter that VCO design and offer it (upon request) as wider than a full octave. Reducing the number of sources in wideband applications enhances frequency agility.

#### Harmonic Suppression and its effect on PLL's

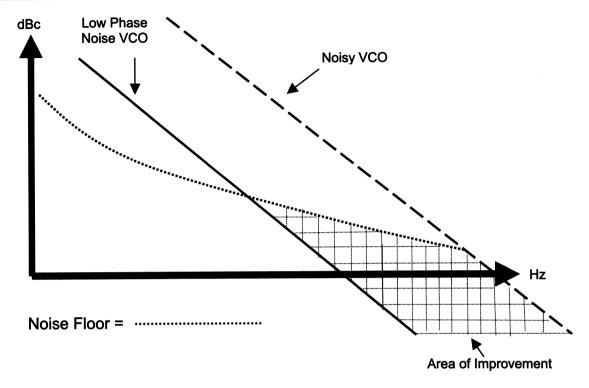
Harmonics can cause problems with PLL prescalers and can create unwanted intermodulation products in communication systems.

#### How Pulling can be an important parameter

Pulling can cause many problems for a VCO output. Reflection of RF due to load mismatch can cause variations in frequency, power, sensitivity and even phase noise. Time varying load variations are particularly troublesome and can require buffering with an amplifier and additive attenuation.

## **VCO Application Notes**

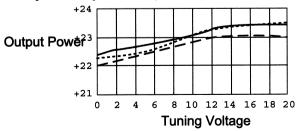
#### Why is Phase Noise important for a quiet Phase Lock Loop.



The objective in a PLL is to obtain phase lock, plain and simple. One of the elements in a PLL design is a VCO which provides the variable frequency element which is locked to the reference frequency by the loop. Within the loop, the VCO's phase noise approaches the phase noise of the reference signal. Outside of the loop, the phase noise of the VCO takes over and becomes the PLL's output noise. Thus, a quieter VCO yields a loop with lower phase noise above the loop bandwidth.

#### High power VCO's

For certain applications, higher output power from a VCO can be very helpful. It can eliminate gain blocks usually required to drive high level mixers. It also allows for increased attenuation between the VCO output and its load, minimizing load pulling effects on frequency, power or sensitivity. Many of our standard VCO are available with higher output power. Consult the factory about your unique requirements.



Voltage Controlled Oscillators

Amplifonix has a selection of VCO's from 25 MHz to 5000 Mhz. We specialize in Hermetic, Low Phase Noise VCO's for high performance applications. Amplifonix can also customize a VCO you see here to change its performance to fit your needs.

Model	1	quency ange	Power Output (dBm)	Harmonic Suppression		ng Voltage Volts)	Phase Noise @ 100KHz Offset		ower
	(1	MHz)	Typical	(dBc) Typical	Min.)	(Max.)	(dBc/Hz) Typical		(DC) (mA)
TOM9300	25	50	13	-15	0	20	-136	15	13
TOM9301	40	80	13	-13	0	20	-131	15	14
TOM9302	50	100	12	-15	0	20	-133	15	14
TOM9114	60	120	12	-11	0	20	-130	15	14
TOM9008	70	100	10	-12	0	20	-115	10	10
TOM9009	100	115	10	-12	0	15	-125	10	9.5
TOM9303	100	200	13	-13	0	20	-127	15	15
TOM9304	150	300	13	-15	0	20	-123	15	16
TOM9319	170	300	10	-15	-9	+9	-108	12	34
TOM9338	180	220	17.5	-20	0	12	-120	15	26
TOM9323	200	250	13	-15	4	13	-120	10	14
TOM9305	200	400	12.5	-30	0	20	-125	15	14
TOM9306	250	500	12	-17	0	20	-123	15	15
TOM9307	300	600	12	-15	0	20	-122	15	17
TOM9308	350	400	6	-15	0	5	-130	5	15
TOM9336	385	415	10	-7	0	5	-100	5	33
TOM9309	400	800	12	-15	0	20	-121	15	18
TOM9310	470	570	12	-17	0	15	-118	9	16
TOM9321	400	500	15	-20	0	8	-110	15	25
TOM9311	550	850	12	-20	0	12	-118	12	35
TOM9052	600	900	15	-20	0	15	-122	15	20
TOM9335	750	940	3	-11	0	5	-102	5	8
TOM9328	800	1300	13	-20	0	15	-116	15	22
TOM9100	900	1400	13	-20	0	12	-112	12	22
TOM9090	900	1600	11.5	-14	0	20	-118	15	27
TOM9313	1000	1800	11	-12	0	20	-112	15	20
TOM9314	1200	2000	12	-15	0	20	-110	15	20
TOM9111	1500	2750	12	-20	0	20	-108	15	10
TOM9315	1551	1800	7	-15	0	10	-115	5	20
TOM9320	1700	2300	12.5	-20	3	15	-105	15	45
TOM9330	1700	2700	12	-20	0	20 🖫	-101	15	19
TOM9331	1725	1790	9.5	-30	0	5	-104	5	30
TOM9329	1875	1975	7	-30	0	7.5	-105	5	24
TOM9250	2000	2500	12	-15	0	15	-105	15	30
TOM9327	2200	2300	7	-30	0	7.5	-105	5	27
TOM9325	2200	2700	12	-18	1.5	10	-105	12	33
TOM9326	2255	2280	6	-24	0.5	4.5	-105	5	20
TOM9316	2500	4000	9	-15	0	20	-105	15	25
TOM9340	3200	4000	10	-15	0	12	-95	12	27
TOM9317	3500	4500	7	-15	0	20	-100	15	25
TOM9339	3900	4100	9.5	-16	0	12	-95	12	21
TOM9318	4000	5000	7	-15	0	20	-100	15	25

### **VOLTAGE CONTROLLED TOM9008 OSCILLATOR** 70-100 MHz

Available as:

TOM9008, 4 Pin TO-8 (T4) TON9008, 4 Pin Surface Mount (SM3) BXO9008, Connectorized Housing (H1)

#### **Features**

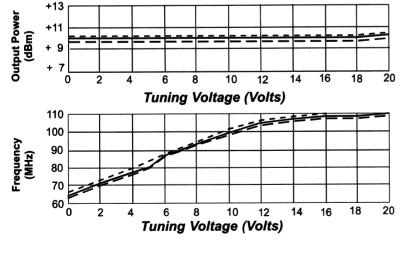
- Low Noise Bipolar Transistor
- Operating Case Temp. -20 °C to + 60 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -20°C to +60 °C
Frequency	70 - 100 MHz	70 - 100 MHz
Output Power (dBm)	+10.0	+7.0 Min.
Power Flatness (dBm)	±0.2	±1.0 Max.
Tuning Voltage Range (V)	2 to 10	1 to 20
Tuning Voltage Sensitivity (MHz/V)	4.0	1.0
Harmonics (dBc)	-12	-8 Max.
Spurious (dBc)	< -80	- 80 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-115	-110 Max.
Pushing (MHz/V)	0.2	0.65 Max.
Pulling (MHz); 12 dB RL	1.2	6.0 Max.
Frequency Drift (MHz/°C)	-0.012	-0.035 Max.
Power Vdc mA	+10 9.5	+10 10.0 Max.

NOTE: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



#### **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volt

ν. (ν)	f (MĤz)	Δf (MHz)	P (dBm)	2H (dBc)	3H (dBc)
0.00	64.0		+ 8.7	-12	 11 -
	. =	4.7	+ 9.9	-12	- 11 - 11
1.00	68.7	3.4		-	
2.00	72.1		+ 9.9	-12	- 12
3.00	75.0	2.9	+ 9.9	-12	- 12
4.00	77.9	2.9	+ 9.9	-12	- 12
5.00	81.3	3.4	+ 9.9	-12	- 12
6.00	85.6	4.3	+ 9.9	-12	- 12
7.00	90.6	5.0	+ 9.9	-12	- 12
8.00	95.4	4.8	+ 9.9	-12	- 12
9.00	99.2	3.8	+ 9.9	-12	- 12
10.00	102.2	3.0	+ 9.8	-12	- 12
11.00	104.7	2.5	+ 9.8	-12	- 12
12.00	106.7	2.0	+ 9.8	-13	- 12
13.00	108.3	1.6	+ 9.7	-12	- 12
14.00	109.6	1.3	+ 9.8	-13	- 12
15.00	110.8	1.2	+ 9.7	-13	- 12
16.00	111.7	0.9	+ 9.7	-13	- 12
17.00	112.5	0.8	+ 9.6	-12	- 12
18.00	113.3	0.8	+ 9.5	-13	- 12
		0.6	+ 9.5	-13	
19.00	113.9				- 12
20.00	114.4	0.5	+ 9.6	-13	- 12

- + 25 °C - - - - +85 °C



2707 Black Lake Place, Philadelphia, PA 19154

# VOLTAGE CONTROLLED OSCILLATOR TOM 9009

Available as:

TOM9009, 4 Pin TO-8 (T4)

TON9009, 4 Pin Surface Mount (SM3)

BXO9009, Connectorized Housing (H1)

#### **Features**

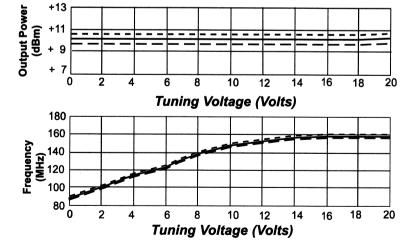
- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -20 °C to + 60 °C
- Environmental Screening Available

#### **Specifications**

CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -20°C to +60 °C
Frequency	100 - 150 MHz	100 - 150 MHz
Output Power (dBm)	+10.0	+7.0 Min.
Power Flatness (dBm)	±0.2	±1.0 Max.
Tuning Voltage Range (V)	2 to 8	1 to 15
Tuning Voltage Sensitivity (MHz/V)	7.0	4.0
Harmonics (dBc)	-12	-8 Max.
Spurious (dBc)	< -80	- 80 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-125	-120 Max.
Pushing (MHz/V)	0.2	1.0 Max.
Pulling (MHz); 12 dB RL	3.0	6.0 Max.
Frequency Drift (MHz/°C)	-0.02	-0.05 Max.
Power Vdc mA	+10 9.5	+10 10.0 Max.

NOTE: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



#### **Maximum Ratings**

Ambient Operating Temperature55	5°C to + 100 °C
Storage Temperature62	2°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volt

v. (v)	t (MHz) 	Δf (MHz) 	P (dBm)	2H (dBc)	3H (dBc)
0.00	88.2		+10.29	-13.31	- 11.87
1.00	94.6	6.4	+10.24	-13.36	- 11.64
2.00	99.4	4.8	+10.24	-13.30	- 11.58
3.00	104.0	4.6	+10.23	-13.34	- 11.63
4.00	109.3	5.3	+10.23	-12.91	- 11.66
5.00	115.5	6.2	+10.22	-12.70	- 11.97
6.00	122.5	7.0	+10.20	-12.77	- 11.98
7.00	129.6	7.1	+10.18	-13.00	- 12.12
8.00	135.7	6.1	+10.16	-13.60	- 12.32
9.00	140.9	5.2	+10.14	-13.96	- 12.35
0.00	145.1	4.2	+10.12	-14.19	- 12.47
1.00	148.2	3.1	+10.11	-14.41	- 12.69
2.00	150.7	2.5	+10.10	-14.69	- 12.83
3.00	152.5	1.8	+10.09	-14.89	- 12.77
4.00	153.7	1.2	+10.09	-14.93	- 12.76
5.00	154.5	0.8	+10.08	-15.11	- 12.70

Legend ----- + 25 °C ----- + 85 °C ----- 40 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM 905 2 600 - 900 MHz

Available as:

TOM9052, 4 Pin TO-8 (T4)

TON9052, 4 Pin Surface Mount (SM3)

TOP9052, 4 Pin Flatpack (FP4)

BXO9052, Connectorized Housing (H1)

#### **Features**

- Broad Tuning Range
- Low Noise Bipolar Transistor
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

#### **Specifications**

+17

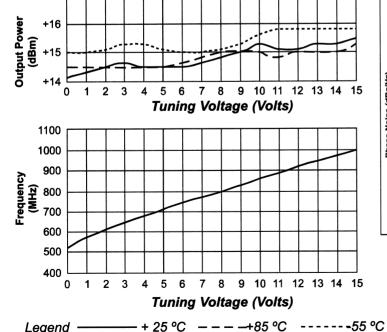
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	600 - 900 MHz	600 - 900 MHz	
Output Power (dBm)	+15	+13.0 Min.	
Power Flatness (dB)	±0.7	±1.0 Max.	
Tuning Voltage Range (v)	1.5 to 12	0 to 15	
Tuning Voltage Sensitivity (MHz/V)	25	20 Min.	
Harmonics (dBc)	-20	-12 Max.	
Spurious (dBc)	<-80	- 80 Max.	
3dB Modulation BW Zg = 50 Ohms		5 Min.	
Pushing (MHz/V)	2	4.0 Max.	
Pulling (MHz); 12 dB RL	15	20 Max.	
Frequency Drift (MHz/°C		0.1 Max.	
Power Vdc mA	+15 20	+15 25.0 Max.	

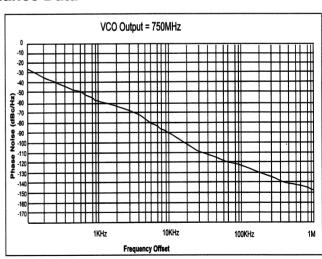
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -118dBc/Hz.



# VOLTAGE CONTROLLED OSCILLATOR TOM 900 - 1600 MHz

Available as:

TOM9090, 4 Pin TO-8 (T4)

TON9090, 4 Pin Surface Mount (SM3)

TOP9090, 4 Pin Flatpack (FP4)

BXO9090, Connectorized Housing (H1)

#### **Features**

- Low Noise Bipolar Transistor
- Borad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

#### **Specifications**

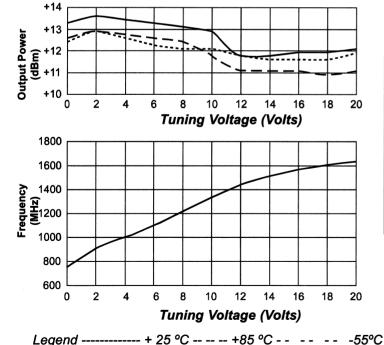
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	900 - 1600 MHz	900 - 1600 MHz	
Output Power (dBm)	+11.5	+10.0 Min.	
Power Flatness (dB)	±1.0	±2.0 Max.	
Tuning Voltage Range (v)	2 to 18	0 to 20	
Tuning Voltage Sensitivity (MHz/V)	20	15 Min.	
Harmonics (dBc)	-14	-10 Max.	
Spurious (dBc)	<-80	- 60 Max.	
3dB Modulation BW, Zg = 50 Ohms		10MHz Min.	
Pushing (MHz/V)	2.0	3.0 Max.	
Pulling (MHz); 12 dB RL	25	30 Max.	
Frequency Drift (MHz/°C		0.3 Max.	
Power Vdc mA	+15 27	+15 35.0	

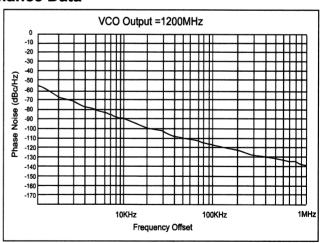
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100 KHz offset across frequency range and temperature extremes is -110 dBc/Hz.



# VOLTAGE CONTROLLED OSCILLATOR TOM9100 900 - 1400 MHz

Available as:

TOM9100, 4 Pin TO-8 (T4)
TON9100-3, 4 Pin Surface Mount (SM3)
TOP9100-4, 4 Pin Flatpack (FP4)
BXO9100, Connectorized Housing (H1)

#### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -40 °C to + 85 °C
- Environmental Screening available

#### **Specifications**

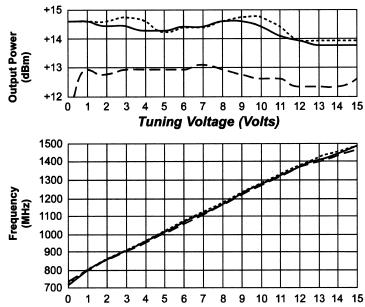
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -40 °C to +85 °C	
Frequency	900 - 1400 MHz	900 - 1400 MHz	
Output Power (dBm)	+13	+11.0 Min.	
Power Flatness (dB)	±0.4	±0.6 Max.	
Tuning Voltage Range (v)	1 to 12	1 to 15	
Tuning Voltage Sensitivity (MHz/V)	50	30 Min.	
Harmonics (dBc)	<-20	-12 Max.	
Spurious (dBc)	<-80	- 80 Max.	
Phase Noise @ 100 KHz (dBc/hz)	-112	- Max.	
Pushing (MHz/V)	<2	3.0 Max.	
Pulling (MHz); 12 dB RL	30	40.0 Max.	
Frequency Drift (MHz/°C	0.15	0.3 Max.	
Power Vdc mA	+12 22	+12 25.0 Max.	

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volt

Note: Care should always be taken to effectively ground the case of each unit.

#### **Typical Performance Data**



V <sub>t</sub>	f	Δf	Po	2H	3H
(v)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
======	========	=======	===		
0.0	729.6		+14.6	-15.0	-15.3
1.00	801.0	71.4	+14.6	-18.5	-17.0
2.00	859.5	58.6	+14.4	+25.5	-17.8
3.00	911.6	52.1	+14.4	-31.2	-19.0
4.00	962.1	50.5	+14.3	-27.8	-20.0
5.00	1013.9	51.7	+14.3	-25.2	-20.7
6.00	1066.5	52.6	+14.4	-23.3	-21.0
7.00	1119.3	52.9	+14.4	-23.3	-22.2
8.00	1172.7	53.4	+14.6	-23.3	-23.2
9.00	1224.8	52.2	+14.6	-22.8	-24.8
10.00	1277.5	52.7	+14.4	-22.0	-27.2
11.00	1326.3	48.8	+14.1	-20.0	-30.7
12.00	1371.9	45.6	+13.9	-20.2	-34.8
13.00	1411.8	39.9	+13.8	-20.7	-36.5
14.00	1445.5	33.6	+13.8	-21.0	-37.2
15.00	1477.3	31.8	+13.8	-21.3	-37.3

Legend ----- + 25 °C -- -- +85 °C - - - - - -40°C

Tuning Voltage (Volts)



## **VOLTAGE CONTROLLED TOM9111 OSCILLATOR**

1500 - 2750 MHz

#### Available as:

TOM9111, 4 Pin TO-8 (T4)

TON9111, 4 Pin Surface Mount (SM3)

TOP9111, 4 Pin Flatpack (FP4)

BXO9111, Connectorized Housing (H1)

#### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

#### **Specifications**

+16

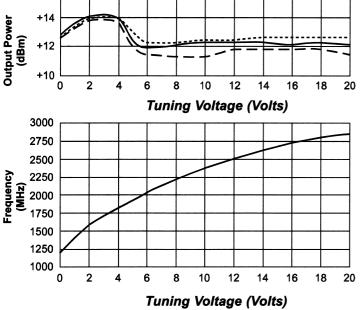
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	1500 - 2750 MHz	1500 - 2750 MHz	
Output Power (dBm)	+12	+10.0 Min.	
Power Flatness (dB)	±1.5	±1.5 Max.	
Tuning Voltage Range (v)	2 to 18	0 to 20	
Tuning Voltage Sensitivity (MHz/V)	80	30 Min.	
Harmonics (dBc)	- 20	- 10 Max.	
Spurious (dBc)	<-80	- 80 Max.	
3dB Modulation BW, Zg =50 Ohms		15MHz Min	
Pushing (MHz/V)	2.0	5.0 Max.	
Pulling (MHz); 22 dB RL	30	45 Max.	
Frequency Drift (MHz/°C	_	0.5 Max.	
Power Vdc mA	+15 19	+15 25	

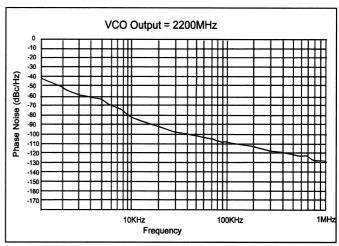
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**





#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -100dBc/Hz.

- - - -55 °C Legend



# VOLTAGE CONTROLLED OSCILLATOR TOM 9114 60 - 120 MHz

Available as:

TOM9114, 4 Pin TO-8 (T4)

TON9114, 4 Pin Surface Mount (SM3)

TOP9114, 4 Pin Flatpack (FP4)

BXO9114, Connectorized Housing (H1)

#### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

#### **Specifications**

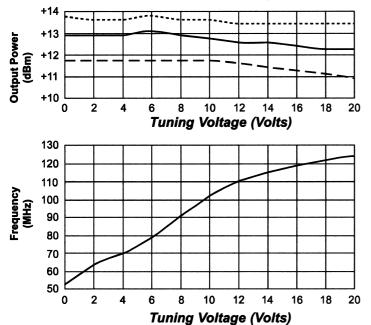
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	60 - 120 MHz	60 - 120 MHz	
Output Power (dBm)	+12	+10.0 Min.	
Power Flatness (dB)	±0.4	±0.6 Max.	
Tuning Voltage Range (v)	1 to 17	0 to 20	
Tuning Voltage Sensitivity (MHz/V)	4	1.5 Min.	
Harmonics (dBc)	-11	-10 Max.	
Spurious (dBc)	<-80	- 80 Max.	
3dB Modulation BW, Zg = 50 Ohms	·	1MHz Min.	
Pushing (MHz/V)	0.25	1.0 Max.	
Pulling (MHz); 12 dB RL	1	3.0 Max.	
Frequency Drift (MHz/°C		0.03 Max.	
Power Vdc mA	+15 14	+15 17	

#### **Maximum Ratings**

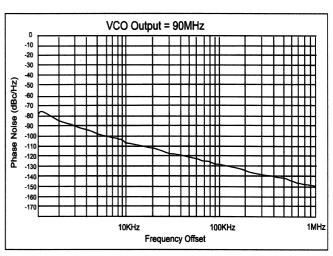
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volt

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



+ 25 °C -- -- +85 °C - -



#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -120 dBc/Hz.



## **VOLTAGE CONTROLLED** TOM9211 **OSCILLATOR**

1500 - 2750 MHz

Available as:

TOM9211, 4 Pin TO-8 (T4)

TON9211, 4 Pin Surface Mount (SM3)

TOP9211, 4 Pin Flatpack (FP4)

BXO9211, Connectorized Housing (H1)

#### **Features**

- Low Noise Bipolar Transistor
- **Broad Tuning Range**
- Operating Case Temp. -55 °C to + 100 °C
- Environmental Screening available

#### **Specifications**

+16

+14

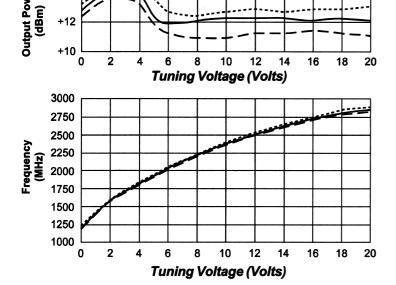
-		
CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta = 25 °C	Ta = -55 °C to +100 °C
Frequency	1500 - 2750 MHz	1500 - 2750 MHz
Output Power (dBm)	+12	+10.0 Min.
Power Flatness (dB)	±1.5	±1.5 Max.
Tuning Voltage Range (v)	2 to 18	0 to 20
Tuning Voltage	80	30 Min.
Sensitivity (MHz/V)	80	30 IVIII.
Harmonics (dBc)	- 20	- 12 Max.
Spurious (dBc)	<-80	- 80 Max.
Phase Noise	440	404 May
@ 100 KHz (dBc/hz)	- 110	- 104 Max.
Pushing (MHz/V)	< 2.0	4.0 Max.
Pulling (MHz); 22 dB RL	30	45 Max.
Frequency Drift (MHz/°C	_	0.5 Max.
Power Vdc	+15	+15
mA	19	20.0

#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Maximum DC Tuning Voltage	+ 22 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



V <sub>t</sub>	f	Δf	P <sub>o</sub>	2H	3H
(Ÿ)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
====			=====		
0.00	1198.0		+12.8	-18.3	-11.8
1.00	1409.7	211.7	+13.9	-22.2	-16.3
2.00	1582.6	172.9	+14.1	-21.8	-19.5
3.00	1713.3	130.7	+13.9	-17.5	-21.8
4.00	1817.4	104.2	+13.9	-17.0	-25.0
5.00	1931.3	113.8	+12.9	21.2	-33.2
6.00	2041.8	110.5	+11.9	-37.8	-27.0
7.00	2135.4	93.7	+12.1	-30.7	-26.8
8.00	2220.7	85.3	+12.1	-27.0	-24.2
9.00	2301.5	80.8	+12.1	-25.7	-25.1
10.00	2378.3	76.8	+12.3	-25.3	-25.5
11.00	2449.2	70.8	+12.4	25.8	-26.5
12.00	2515.4	66.3	+12.3	26.2	-27.4
13.00	2576.9	61.5	+12.3	26.7	-29.3
14.00	2633.4	56.5	+12.3	27.2	-32.2
15.00	2684.7	51.3	+12.4	27.8	-32.0
16.00	2730.6	45.9	+12.1	28.3	-31.6
17.00	2770.4	39.8	+12.3	29.3	-32.0
18.00	2803.8	33.3	+12.3	29.5	-31.7
19.00	2829.9	26.2	+12.1	29.7	-33.1
20.00	2849.4	19.5	+12.1	30.2	-33.2

- - +100 °C - - - - - - - -55 °C Legend



# VOLTAGE CONTROLLED OSCILLATOR TOM9250 2000 - 2500 MHz

Available as:

TOM9250, 4 Pin TO-8 (T4) TON9250-3, 4 Pin Surface Mount (SM3) TOP9250-4, 4 Pin Flatpack (FP4) BXO9250, Connectorized Housing (H1)

#### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

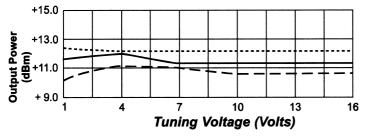
#### **Specifications**

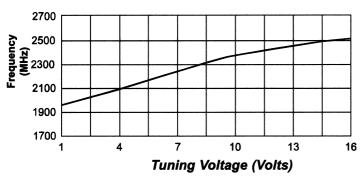
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
5Frequency	2000 - 2500 MHz	2000 - 2500 MHz	
Output Power (dBm)	+11.5	+9.0 Min.	
Power Flatness (dB)	±0.75	±1.5 Max.	
Tuning Voltage Range (v)	1 to 14	1 to 15	
Tuning Voltage Sensitivity (MHz/V)	40	15 Min.	
Harmonics (dBc)	-20	-12 Max.	
Spurious (dBc)	<-80	<-60 Max.	
3dB Modulation BW Zg = 50 Ohm		20MHz Min.	
Pushing (MHz/V)	4	9 Max.	
Pulling (MHz); 20 dB RL	25	35 Max.	
Frequency Drift (MHz/°C	0.10	0.15 Max.	
Power Vdc mA	+15 30	+15 40	

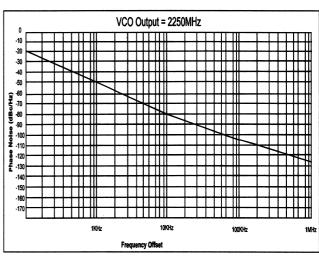
#### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volt

### **Typical Performance Data**







#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -100 dBc/Hz.

Legend ------+ 25 °C -- -- +85 °C - - - - -55 °C



## **VOLTAGE CONTROLLED** TOM9300 **OSCILLATOR**

25 - 50 MHz

### Available as:

TOM9300, 4 Pin TO-8 (T4)

TON9300, 4 Pin Surface Mount (SM3)

TOP9300, 4 Pin Flatpack (FP4)

BXO9300, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- **Broad Tuning Range**
- Operating Case Temp. -55 °C to +85 °C
- Environmental Screening available

### **Specifications**

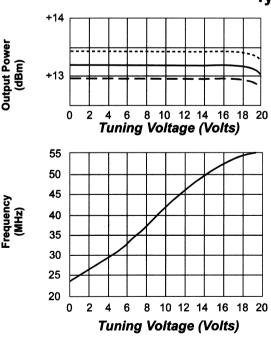
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	25 - 50 MHz	25 - 50 MHz
Output Power (dBm)	+13	+10 Min.
Power Flatness (dB)	±0.5	±1.0 Max.
Tuning Voltage Range (v)	1 to 15	0 to 20
Tuning Voltage Sensitivity (MHz/V)	2.0	1 Min.
Harmonics (dBc)	-15	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		.1MHz Min.
Pushing (MHz/V)	.20	.30 Max.
Pulling (MHz); 12dB RL	1.25	2.0 Max.
Frequency Drift (MHz/°C)		01 Max.
Power Vdc mA	+15 13	+15 16 Max.

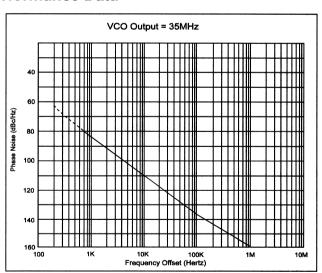
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





- - - - - - -55 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -130 dBc/Hz.



- + 25 °C

# VOLTAGE CONTROLLED OSCILLATOR TOM 9301 40 - 80 MHz

Available as:

TOM9301, 4 Pin TO-8 (T4)

TON9301, 4 Pin Surface Mount (SM3)

TOP9301, 4 Pin Flatpack (FP4)

BXO9301, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

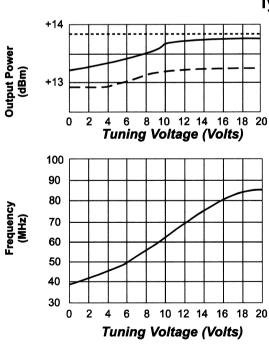
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	40 MHz	80 MHz
Output Power (dBm)	+13	+10 Min.
Power Flatness (dB)	±0.6	±2.0 Max.
Tuning Voltage Range (v)	1 to 17	0 to 20
Tuning Voltage Sensitivity (MHz/V)	2.5	1.0 Min.
Harmonics (dBc)	-13	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		.2MHz Min.
Pushing (MHz/V)	0.3	1.0 Max.
Pulling (MHz); 12dB RL	2	4 Max.
Frequency Drift (MHz/°C)	_	.02 Max.
Power Vdc mA	+15 14	+15 18 Max.

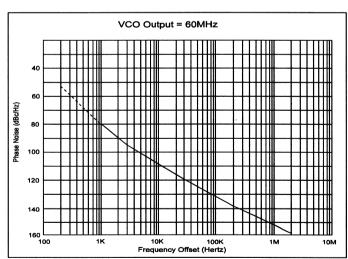
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

----54°C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100 KHz offset across frequency range and temperature extremes is -125 dBc/Hz.



## VOLTAGE CONTROLLED OSCILLATOR TOM 9302 50 - 100 MHz

Available as:

TOM9302, 4 Pin TO-8 (T4)

TON9302, 4 Pin Surface Mount (SM3)

TOP9302, 4 Pin Flatpack (FP4)

BXO9302, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

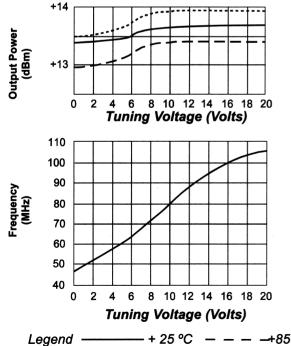
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	50 - 100 MHz	50 - 100 MHz
Output Power (dBm)	+12	+10 Min.
Power Flatness (dB)	±1.0	±1.5 Max.
Tuning Voltage Range (v)	1 to 17	0 to 20
Tuning Voltage Sensitivity (MHz/V)	4	1.5 Min.
Harmonics (dBc)	-15	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		.3MHz Min.
Pushing (MHz/V)	.5	1.5 Max.
Pulling (MHz); 12dB RL	3	5.0 Max.
Frequency Drift (MHz/°C)	_	.05 Max.
Power Vdc mA	+15 1 <b>4</b>	+15 18 Max.

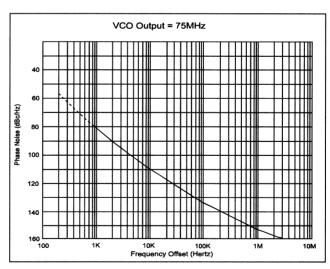
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- - - - -54 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -130 dBc/Hz.



# VOLTAGE CONTROLLED OSCILLATOR TOM 9303 100 - 200 MHz

Available as:

TOM9303, 4 Pin TO-8 (T4)

TON9303, 4 Pin Surface Mount (SM3)

TOP9303, 4 Pin Flatpack (FP4)

BXO9303, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to +85 °C
- Environmental Screening available

### **Specifications**

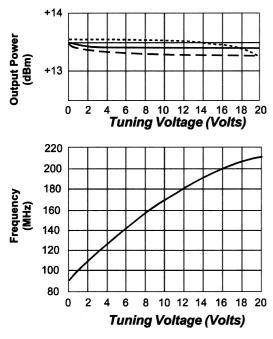
CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	100 - 200 MHz	100 - 200MHz
Output Power (dBm)	13	+10 Min.
Power Flatness (dB)	±1	±2.0 Max.
Tuning Voltage Range (v)	1 to 17	0 to 20
Tuning Voltage Sensitivity (MHz/V)	6	2 Min.
Harmonics (dBc)	-13	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		.5MHz Mln.
Pushing (MHz/V)	1	2.0 Max.
Pulling (MHz); 12dB RL	5	10 Max.
Frequency Drift (MHz/°C)		.07 Max.
Power Vdc	+15	+15
mA	15	20

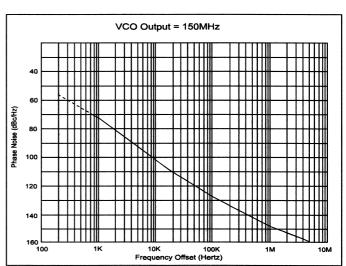
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -125 dBc/Hz.

Legend ------ +25 °C - - - - +85 °C - - - - - - -54 °C



## **VOLTAGE CONTROLLED** TOM9304 **OSCILLATOR**

150 - 300 MHz

Available as:

TOM9304, 4 Pin TO-8 (T4)

TON9304, 4 Pin Surface Mount (SM3)

TOP9304, 4 Pin Flatpack (FP4)

BXO9304, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- **Broad Tuning Range**
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

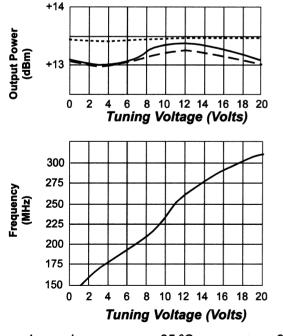
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	150 - 300 MHz	150 - 300 MHz
Output Power (dBm)	+13	+10 Min.
Power Flatness (dB)	±0.5	±1.0 Max.
Tuning Voltage Range (v)	1 to 18	0 to 20
Tuning Voltage Sensitivity (MHz/V)	9	3 Min.
Harmonics (dBc)	-15	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		.5MHz Min.
Pushing (MHz/V)	1	4 Max.
Pulling (MHz); 12dB RL	5	10 Max.
Frequency Drift (MHz/°C)		.05 Max.
Power Vdc mA	+15 16	+15 20 Max.

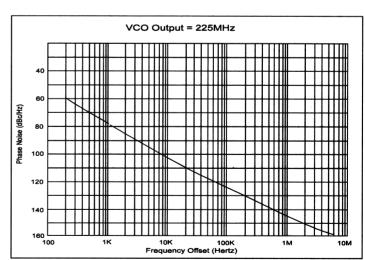
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





- - - -54 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -120 dBc/Hz.



## **VOLTAGE CONTROLLED TOM9305 OSCILLATOR**

200 - 400 MHz

### Available as:

TOM9305, 4 Pin TO-8 (T4)

TON9305, 4 Pin Surface Mount (SM3)

TOP9305, 4 Pin Flatpack (FP4)

BXO9305, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening Available

### **Specifications**

+14

+13

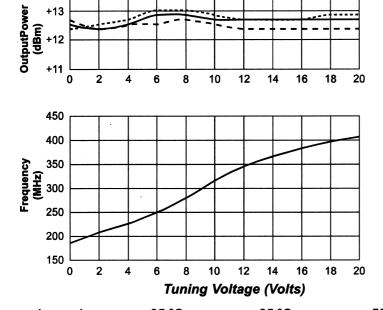
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -55°C to +85 °C
Frequency	200 - 400 MHz	200 - 400 MHz
Output Power (dBm)	+12.5	+10.0 Min.
Power Flatness (dB)	±0.4	±1.0 Max.
Tuning Voltage Range (v)	1 to 19	0 to 20
Tuning Voltage Sensitivity (MHz/V)	20	5.0 Min.
Harmonics (dBc)	-30	-17 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohms		3MHz Min.
Pushing (MHz/V)	1.0	2.0 Max.
Pulling (MHz); 12 dB RL	4	9.0 Max.
Frequency Drift (MHz/°C	_	0.1 Max.
Power Vdc mA	+15 14	+15 18 Max.

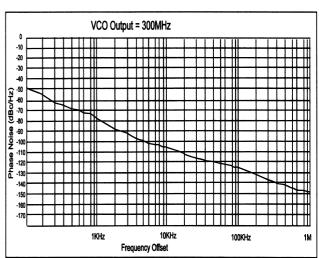
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volt

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -120dBc/Hz.



## **VOLTAGE CONTROLLED TOM9306 OSCILLATOR** 250 - 500 MHz

Available as:

TOM9306, 4 Pin TO-8 (T4)

TON9306, 4 Pin Surface Mount (SM3)

TOP9306, 4 Pin Flatpack (FP4)

BXO9306, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- **Broad Tuning Range**
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

+14

+13

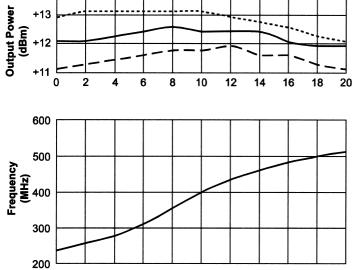
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	250 - 500 MHz	250 - 500 MHz
Output Power (dBm)	+12	+10.0 Min.
Power Flatness (dB)	± 0.4	± 1.0 Max.
Tuning Voltage Range (v)	1to 18	0 to 20
Tuning Voltage Sensitivity (MHz/V)	15	5 Min.
Harmonics (dBc)	-17	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohms		4MHz Min.
Pushing (MHz/V)	1	3.0 Max.
Pulling (MHz); 12 dB RL	3	8.0 Max.
Frequency Drift (MHz/°C	_	0.05 Max.
Power Vdc mA	+15 15	+15 20.0

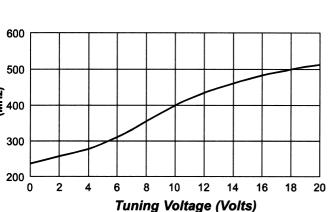
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volts

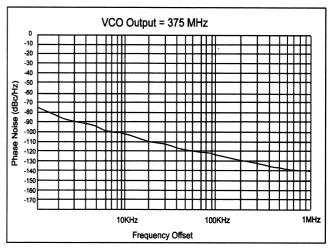
Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**









#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -120dBc/Hz.



# VOLTAGE CONTROLLED OSCILLATOR TOM 9307 300 - 600 MHz

Available as:

TOM9307, 4 Pin TO-8 (T4)

TON9307, 4 Pin Surface Mount (SM3)

TOP9307, 4 Pin Flatpack (FP4)

BXO9307, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

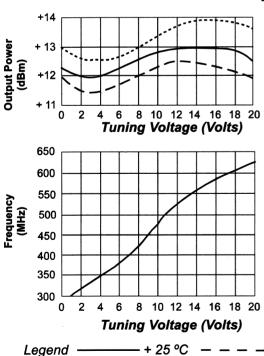
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	300 - 600 MHz	300 - 600 MHz
Output Power (dBm)	12	+10 Min.
Power Flatness (dB)	±1	±2.0 Max.
Tuning Voltage Range (v)	1 to 17	0 to 20
Tuning Voltage Sensitivity (MHz/V)	20	5 Min.
Harmonics (dBc)	-15	-10
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		8MHz Min.
Pushing (MHz/V)	2	4 Max.
Pulling (MHz); 12dB RL	5	15 Max.
Frequency Drift (MHz/°C)		05 Max.
Power Vdc mA	+15 17	+15 25

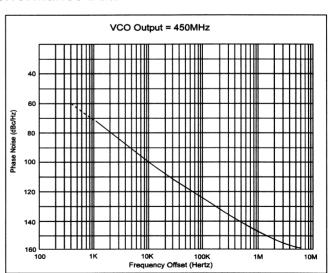
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is 120 dBc/Hz.





## VOLTAGE CONTROLLED OSCILLATOR TOM 9308 350 - 400 MHz

Available as:

TOM9308, 4 Pin TO-8 (T4)

TON9308, 4 Pin Surface Mount (SM3)

TOP9308, 4 Pin Flatpack (FP4)

BXO9308, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

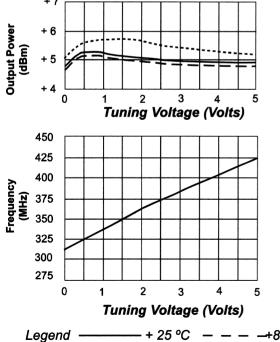
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	350 - 400 MHz	350 - 400 MHz
Output Power (dBm)	+6	+4 Min.
Power Flatness (dB)	±0.6	±0.8 Max.
Tuning Voltage Range (v)	1 to 4	0 to 5
Tuning Voltage Sensitivity (MHz/V)	25	15 Min.
Harmonics (dBc)	-15	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		5MHz Min.
Pushing (MHz/V)	1	3.0 Max.
Pulling (MHz); 12dB RL	2	5 Max.
Frequency Drift (MHz/°C)		.04 · Max.
Power Vdc mA	+5 12	+5 16 Max.

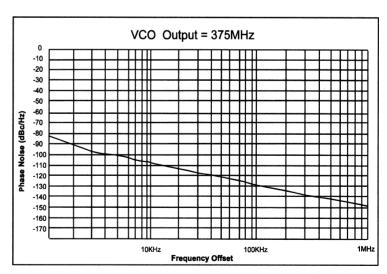
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Maximum DC Tuning Voltage	+ 10 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- - - -54 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is 120 dBc/Hz.



# VOLTAGE CONTROLLED OSCILLATOR TOM 9309 400 - 800 MHz

Available as:

TOM9309, 4 Pin TO-8 (T4)

TON9309, 4 Pin Surface Mount (SM3)

TOP9309, 4 Pin Flatpack (FP4)

BXO9309, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

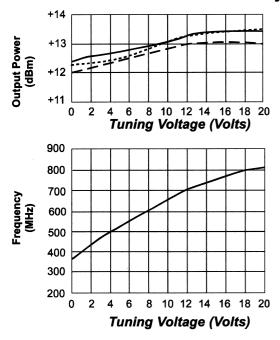
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	400 - 800 MHz	400 - 800 MHz
Output Power (dBm)	12	10 Min.
Power Flatness (dB)	±1	±2 Max.
Tuning Voltage Range (v)	1 to 18	0 to 20
Tuning Voltage Sensitivity (MHz/V)	25	10 Min.
Harmonics (dBc)	-15	-10
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohm		10MHz Min.
Pushing (MHz/V)	1	4 Max.
Pulling (MHz); 12dB RL	10	25 Max.
Frequency Drift (MHz/°C)		07 Max.
Power Vdc mA	+15 18	+15 25

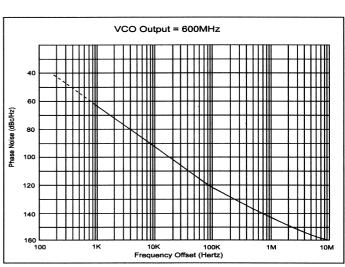
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

----54 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -118 dBc/Hz.



## VOLTAGE CONTROLLED OSCILLATOR TOM 9310 470 - 570 MHz

Available as:

TOMA9310, 4 Pin TO-8 (T4) TONA9310, 4 Pin Surface Mount (SM3)

TOPA9310, 4 Pin Flatpack (FP4) BXOA9310, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

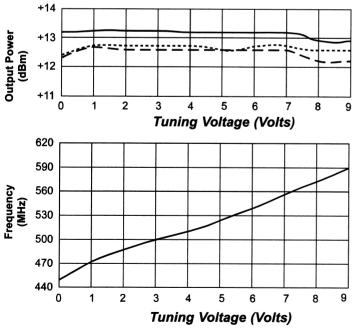
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	470 - 570 MHz	470 - 570 MHz
Output Power (dBm)	+12	+10. Min.
Power Flatness (dB)	±0.25	±0.5 Max.
Tuning Voltage Range (v)	1 to 10	0 to 15
Tuning Voltage Sensitivity (MHz/V)	25	10 Min.
Harmonics (dBc)	-17	-12 Max.
Spurious (dBc)	<-80	- 80 Max.
3dB Modulation BW, Zg = 50 Ohms		5MHz Min.
Pushing (MHz/V)	0.5	1.0 Max.
Pulling (MHz); 12 dB RL	12	20 Max.
Frequency Drift (MHz/°C	0.125	0.25 Max.
Power Vdc mA	+ 9 16	+ 9 20.0 Max.

### **Maximum Ratings**

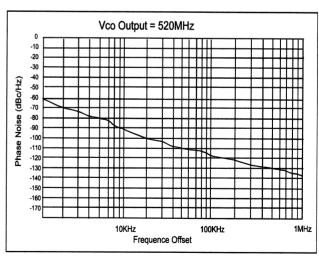
Ambient Operating Temperature55°C to	+ 100 °C
Storage Temperature62°C to	
Case Temperature	+ 125 °C
DC Voltage +	15 Volts
Maximum DC Tuning Voltage +	15 Volts
Minimum DC Tuning Voltage	0 Volt

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



+ 25 °C -- -- +85 °C - - --



### Notes:

-55 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -110dBc/Hz.



## **VOLTAGE CONTROLLED** TOM9311 **OSCILLATOR**

550 - 850 MHz

### Available as:

TOM9311, 4 Pin TO-8 (T4)

TON9311, 4 Pin Surface Mount (SM3)

TOP9311, 4 Pin Flatpack (FP4)

BXO9311, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

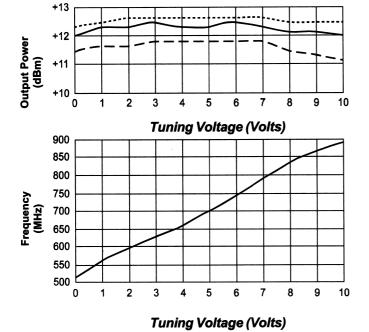
- Opcomodions		
CHARACTERISTIC	<b>TYPICAL Ta = 25 °C</b>	MIN/MAX Ta = -55 °C to +85 °C
Frequency	550 - 850 MHz	550 - 850 MHz
Output Power (dBm)	+12	+10.0 Min.
Power Flatness (dB)	±0.3	±1.0 Max.
Tuning Voltage Range (v)	1 to 10	0 to 12
Tuning Voltage Sensitivity (MHz/V)	30	20 Min.
Harmonics (dBc)	-20	-15 Max.
Spurious (dBc)	<-80	- 80 Max.
Phase Noise @ 100 KHz (dBc/hz)		5MHz Min.
Pushing (MHz/V)	3	4.0 Max.
Pulling (MHz); 20 dB RL	10	15.0 Max.
Frequency Drift (MHz/°C	0.3	0.7 Max.
Power Vdc mA	+12 35	+12 40.0

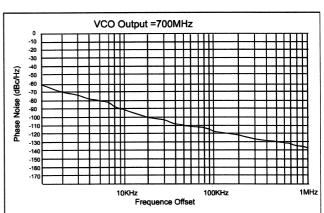
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volt
3 3	

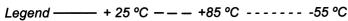
Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





- 1. Phase noise is measured using the Aerofles PN9000.
- 2. Worst cae phase noise @ 100KHZ offset across frequency rance and temperature extremes is - 100 dBc/Hz.





# VOLTAGE CONTROLLED OSCILLATOR TOM 9313 1000 - 1800 MHz

Available as:

TOM9313, 4 Pin TO-8 (T4) TON9313, 4 Pin Surface Mount (SM3)

TOP9313, 4 Pin Flatpack (FP4)

BXO9313, Connectorized Housing (H1)

### **Features**

- Broad Tuning Range
- Low Noise Bipolar Transistor
- Operating Case Temp. -55 °C to +85 °C
- Environmental Screening available

### **Specifications**

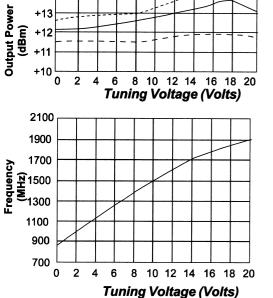
CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = -55 °C to + 85 °C	
Frequency	1000 - 1800 MHz	1000 - 1800 MHz	
Output Power (dBm)	12	10 Min.	
Power Flatness (dB)	±1.0	±2.0 Max.	
Tuning Voltage Range (v)	1 to 18	0 to 20	
Tuning Voltage Sensitivity (MHz/V)	50	25 Min.	
Harmonics (dBc)	-15	-10	
Spurious (dBc)	<-80	- 60 Max.	
3dB Modulation BW, Zg = 50 Ohm		15MHz Min.	
Pushing (MHz/V)	10	15 Max.	
Pulling (MHz); 14dB RL	15	30 Max.	
Frequency Drift (MHz/°C)	_	.30 Max.	
Power Vdc mA	+15 19	+15 25	

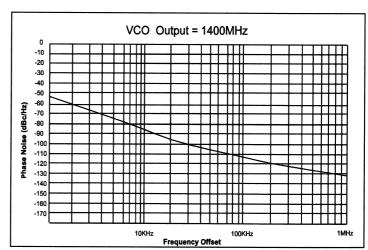
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -110 dBc/Hz.

Legend ----- + 25 °C - - - - +85°C -----54 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9314 1200 - 2000 MHz

Available as:

TOM9314, 4 Pin TO-8 (T4) TON9314, 4 Pin Surface Mount (SM3)

TOP9314, 4 Pin Flatpack (FP4)

BXO9314. Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to +85 °C
- Environmental Screening available

### **Specifications**

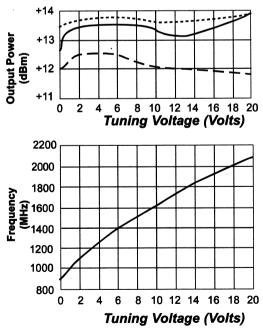
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C	
Frequency	1200 - 2000 MHz	1200 - 2000 MHz	
Output Power (dBm)	12	10 Min.	
Power Flatness (dB)	±1	±2 Max.	
Tuning Voltage Range (v)	3 to 18	0 to 20	
Tuning Voltage	65	25 Min.	
Sensitivity (MHz/V)	00		
Harmonics (dBc)	15	-10	
Spurious (dBc)	<-80	- 60 Max.	
3dB Modulation BW,		15MHz Min.	
Zg = 50 Ohm			
Pushing (MHz/V)	10	20 Max.	
Pulling (MHz); 14dB RL	15	30 Max.	
Frequency Drift (MHz/°C)		35 Max.	
Power Vdc	+15	+15	
mA	20	30	

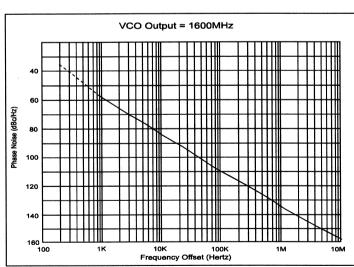
### **Maximum Ratings**

maximum radiiige	
Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- - - -54 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -105 dBc/Hz.



- + 25 °C

## VOLTAGE CONTROLLED OSCILLATOR TOM9315 1550 - 1800 MHz

Available as:

TOM9315, 4 Pin TO-8 (T4)
TON9315, 4 Pin Surface Mount (SM3)
TOP9315, 4 Pin Flatpack (FP4)
BXO9315, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

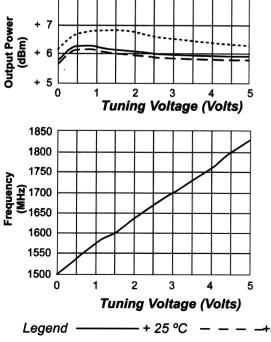
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C	
Frequency	1550 - 1800 MHz	1550 - 1800 MHz	
Output Power (dBm)	+7.0	+5 Min.	
Power Flatness (dB)	±1.0	±1.5 Max.	
Tuning Voltage Range (v)	1 to 4.5	0 to 5	
Tuning Voltage Sensitivity (MHz/V)	65	50 Min.	
Harmonics (dBc)	-20	-10 Max.	
Spurious (dBc)	<-80	- 80 Max.	
3dB Modulation BW, Zg = 50 Ohm		10MHz Min.	
Pushing (MHz/V)	4	10 Max.	
Pulling (MHz); 12dB RL	15	20 Max.	
Frequency Drift (MHz/°C)	_	- 0.3 Max.	
Power Vdc mA	+5 22	+5 30 Max.	

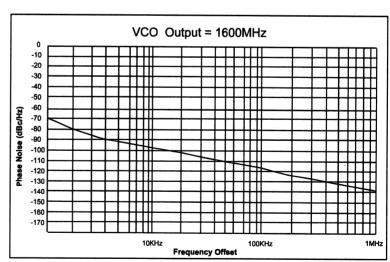
**Maximum Ratings** 

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

----54 °C

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -110 dBc/Hz.



## **VOLTAGE CONTROLLED TOM9316 OSCILLATOR**

2500 - 4000 MHz

### Available as:

TOM9316, 4 Pin TO-8 (T4) TON9316, 4 Pin Surface Mount (SM3) TOP9316, 4 Pin Flatpack (FP4) BXO9316, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

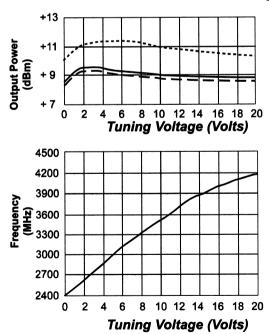
•			
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	2500 - 4000 MHz	2500 - 4000 MHz	
Output Power (dBm)	+9	+7 Min.	
Power Flatness (dB)	±1.0	±2.0 Max.	
Tuning Voltage Range (v)	1 to 18	0 to 20	
Tuning Voltage Sensitivity (MHz/V)	85	25 Min.	
Harmonics (dBc)	-15	-10 Max.	
Spurious (dBc)	<-80	- 80 Max.	
3dB Modulation BW, Zg =50 Ohms		15MHz Min.	
Pushing (MHz/V)	5	15 Max.	
Pulling (MHz); 22 dB RL	15	25 Max.	
Frequency Drift (MHz/°C	_	- 0.5 Max.	
Power Vdc mA	+15 25	+15 30 Max.	

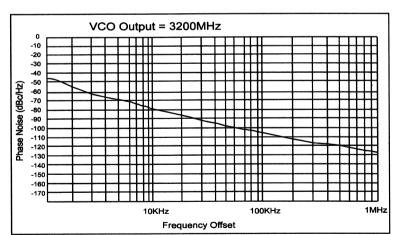
### **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -100dBc/Hz.

-+ 85 °C -----55°C Legend



## **VOLTAGE CONTROLLED** TOM9317 **OSCILLATOR**

3500 - 4500 MHz

Available as:

TOM9317, 4 Pin TO-8 (T4) TON9317, 4 Pin Surface Mount (SM3) TOP9317, 4 Pin Flatpack (FP4)

BXO9317, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- **Broad Tuning Range**
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

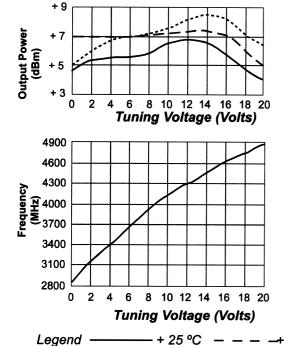
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C	
Frequency	3500 - 4500 MHz	3500 - 4500 MHz	
Output Power (dBm)	+7	+5 Min.	
Power Flatness (dB)	±1.0	±2.0 Max.	
Tuning Voltage Range (v)	4 to 15	0 to 20	
Tuning Voltage Sensitivity (MHz/V)	85	25 Min.	
Harmonics (dBc)	-15	-10 Max.	
Spurious (dBc)	<-80	- 80 Max.	
3dB Modulation BW, Zg = 50 Ohm	_	20Mhz Min.	
Pushing (MHz/V)	5	15 Max.	
Pulling (MHz); 22dB RL	15	25 Max.	
Frequency Drift (MHz/°C)		- 0.5 Max.	
Power Vdc mA	+15 25	+15 30 Max.	

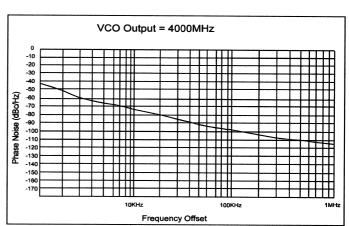
### **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





### Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -90 dBc/Hz.

----55 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9318 4000 - 5000 MHz

Available as:

TOM9318, 4 Pin TO-8 (T4) TON9318, 4 Pin Surface Mount (SM3) TOP9318, 4 Pin Flatpack (FP4) BXO9318, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening available

### **Specifications**

+ 9

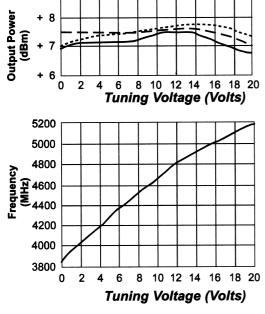
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	4000 - 5000 MHz	4000 - 5000 MHz	
Output Power (dBm)	+7	+5	Min.
Power Flatness (dB)	±1.0	±2.0	Max.
Tuning Voltage Range (v)	1 to 15	0 to 20	
Tuning Voltage Sensitivity (MHz/V)	85	30	Min.
Harmonics (dBc)	-20	-10	Max.
Spurious (dBc)	<-80	- 80	Max.
3dB Modulation BW, Zg = 50 Ohm		20	Min.
Pushing (MHz/V)	10	20	Max.
Pulling (MHz); 22dB RL	20	30	Max.
Frequency Drift (MHz/°C)		- 0.5	Max.
Power Vdc mA	+15 25	+15 30	Max.

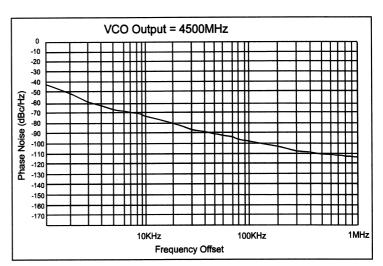
### **Maximum Ratings**

Ambient Operating Temperature	54°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -90 dBc/Hz.

Legend ——— + 25 °C − − − → 85 °C − − − − 55 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM 9319 170-300 MHz

Available as:

TOM9319, 4 Pin TO-8 (T4) TON9319, 4 Pin Surface Mount (SM3) BXO9319, Connectorized Housing (H1)

### **Features**

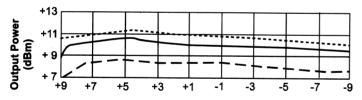
- Modulation Sensitivity Ratio: 1.7:1 Typical
- 3 dB Modulation Bandwidth: 4 MHz (50 ohm source)
- Operating Case Temp. -55 °C to + 100 °C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

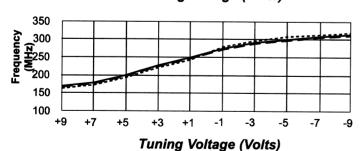
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -55°C to +100 °C
Frequency	170 - 300 MHz	170-300 MHz
Output Power (dBm)	+10.0	+8.0 Min.
Power Flatness (dBm)	±0.5	±1.0 Max.
Tuning Voltage Range (V)	+8 to -4	+9 to -9
Tuning Voltage Sensitivity (MHz/V)	10.0	5.0 Min.
Harmonics (dBc)	-15	-8 Max.
Spurious (dBc)	<-70	- 70 Max.
Phase Noise @10 KHz @ 100 KHz (dBc/Hz)	- 78 -108	- 75 -105 Max.
Pushing (MHz/V)	2.0	4.0 Max.
Pulling (MHz); 12 dB RL	4.0	8.0 Max.
Frequency Drift (MHz/°C)	0.05	0.05 Max.
Power Vdc mA	+12 34.0	+12 45.0 Max.

NOTE: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**



### Tuning Voltage (Volts)



## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	11 Volt

V <sub>t</sub> (V)	f <sub>o</sub> (MHz)	Δf (MHz)	P <sub>o</sub> (dBm)	2H (dBc)	3H (dBc)
+11	136.0	=======	+ 5.5	-18	-23
+10	152.0	16.0	+ 7.2	-19	-20
+9	162.8	10.8	+ 8.4	-20	-17
+8	171.0	8.2	+ 9.8	-21	-15
+7	179.5	8.5	+10.0	-22	-14
+6	188.4	8.9	+10.2	-21	-14
+5	200.6	12.2	+10.3	-18	-14
+4	213.7	13.1	+10.3	-18	-14
+3	227.0	13.3	+10.3	-17	-14
+2	239.2	12.2	+10.2	-18	-14
+1	250.9	11.7	+10.0	-20	-14
0	261.7	10.8	+ 9.8	-21	-14
-1	271.4	9.7	+ 9.9	-23	-14
-2	279.7	8.3	+ 9.8	-24	-14
-3	287.2	7.5	+ 9.7	-26	-14
-4	293.6	6.4	+ 9.6	-26	-14
-5	299.2	5.6	+ 9.5	-27	-14
-6	304.2	5.0	+ 9.5	-27	-14
-7	308.8	4.6	+ 9.4	-24	-15
-8	312.8	4.0	+ 9.4	-24	-15
-9	316.2	3.4	+ 9.4	-23	-15
-10	319.1	2.9	+ 9.4	-23	-14
-11	321.4	2.3	+ 9.4	-23	-14

Legend — + 25 °C − − − +100 °C -----55 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM 9320 1700-2300 MHz

Available as:

TOM9320, 4 Pin TO-8 (T4) TON9320, 4 Pin Surface Mount (SM3) BXO9320, Connectorized Housing (H1)

### **Features**

- Medium Output Power: +12.5 dBm Typical
- Operating Case Temp. 0 °C to + 65 °C
- Environmental Screening Available

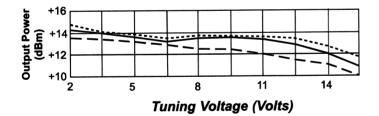
### **Specifications**

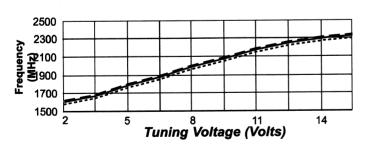
TYPICAL Ta = +25 °C	MIN/MAX Ta = 0°C to +65 °C
1700 2300 MHz	
1700 - 2300 MITIZ	1700 - 2300 MHz
+12.5	+10.0 Min.
±1.0	±1.5 Max.
4 to 14	3 to 15
60.0	40.0 Min.
-20	-15 Max.
<-60	- 60 Max.
-105	-100 Max.
5.0	9.0 Max.
50	65 Max.
0.15	0.30 Max.
+15 45.0	+15 50.0 Max.
	±1.0 4 to 14 60.0 -20 <-60 -105 5.0 50 0.15

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volt

## **Typical Performance Data**





ν <u>.</u> (۷)	f (MHz)	Δf (MHz)	P <sub>o</sub> (dBm)	2H (dBc)	3H (dBc)
2.00	1584.2		+14.5	 -25	-35
3.00	1657.8	73.6	+14.1	-31	-32
4.00	1729.6	71.8	+13.6	-33	-28
5.00	1796.2	66.7	+13.5	-42	-25
6.00	1861.5	65.3	+13.5	-45	-23
7.00	1924.2	62.6	+13.5	-37	-20
8.00	1982.3	58.1	+13.4	-35	-19
9.00	2038.2	55.9	+13.5	-32	-22
10.00	2091.1	53.0	+13.9	-33	-25
11.00	2141.7	50.6	+13.7	-32	-28
12.00	2191.7	50.0	+13.3	-33	-29
13.00	2241.9	50.2	+13.0	-35	-26
14.00	2291.7	49.8	+12.6	-37	-27
15.00	2342.0	50.3	+11.7	-48	-51

Legend ——— + 25 °C − − − −+65 °C ----- 0 °C



## **VOLTAGE CONTROLLED** TOM9321 **OSCILLATOR**

400-500 MHz

### Available as:

TOM9321, 4 Pin TO-8 (T4) TON9321, 4 Pin Surface Mount (SM3) BXO9321, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -40 °C to + 85 °C
- Environmental Screening Available

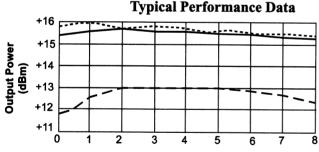
### **Specifications**

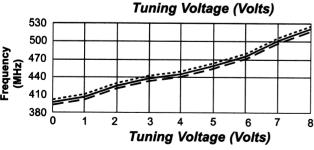
•		
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -40°C to +85 °C
Frequency	400 - 500 MHz	400 - 500 MHz
Output Power (dBm)	+15.0	+11.0 Min.
Power Flatness (dBm)	±0.5	±1.0 Max.
Tuning Voltage Range (V)	0 to 8	0 to 8
Tuning Voltage Sensitivity (MHz/V)	10 to 25	9 to 25
Harmonics (dBc)	-20	-11 Max.
Spurious (dBc)	<-60	- 60 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-110	-107 Max.
Pushing (MHz/V)	0.5	1.0 Max.
Pulling (MHz); 12 dB RL	3	6 Max.
Frequency Drift (MHz/°C)		-0.15 Max.
Power Vdc	+15	+15
mA	25.0	30.0 Max.

**Maximum Ratings** 

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	
DC Voltage	
Maximum DC Tuning Voltage	
Minimum DC Tuning Voltage	0 Volt

NOTE: Care should always be taken to effectively ground the case of each unit.





ν <sub>ι</sub> (ν)	f (MHz)	Δf (MHz)	P (dBm)	2H (dBc)	3H (dBc)
0.00	394.0		+15.39	-24.45	-21.52
1.00	409.6	15.6	+15.65	-25.12	-22.44
2.00	420.8	11.3	+15.71	-24.88	-21.73
3.00	431.6	10.8	+15.60	-24.50	-20.94
4.00	443.4	11.8	+15.59	-24.36	-21.13
5.00	458.3	14.9	+15.49	-24.32	-21.83
6.00	477.6	19.3	+15.53	-24.82	-22.59
7.00	500.2	22.6	+15.35	-25.21	-23.19
8.00	523.0	22.8	+15.23	-26.28	-25.06

- + 25 °C - - - - +85 °C



## **VOLTAGE CONTROLLED TOM9323 OSCILLATOR** 200-250 MHz

Available as:

TOM9323, 4 Pin TO-8 (T4) TON9323, 4 Pin Surface Mount (SM3) BXO9323, Connectorized Housing (H1)

### **Features**

- Center Frequency: 225 MHz @ 8 Tuning Volts Typical
- **■** Low Noise Bipolar Transistor
- Operating Case Temp. 0 °C to + 70 °C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

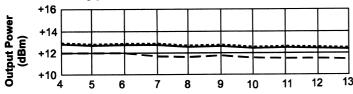
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = 0°C to +70 °C
Frequency	200 - 250 MHz	200 - 250 MHz
Output Power (dBm)	+13.0	+10.0 Min.
Power Flatness (dBm)	±0.2	±0.5 Max.
Tuning Voltage Range (V)	4 to 13	4 to 13
Tuning Voltage Sensitivity (MHz/V)	7.0	4.0 Min.
Harmonics (dBc)	-15	-10 Max.
Spurious (dBc)	<-80	- 60 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-120	-110 Max.
Pushing (MHz/V)	0.5	2.0 Max.
Pulling (MHz); 12 dB RL	5.0	10.0 Max.
Frequency Drift (MHz/°C)	0.05	0.10 Max.
Power Vdc mA	+10 14.0	+10 16.0 Max.

**Maximum Ratings** 

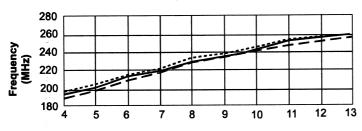
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volt

NOTE: Care should always be taken to effectively ground the case of each unit

## Typical Performance Data



### **Tuning Voltage (Volts)**



**Tuning Voltage (Volts)** 

٧,	f	Δf	P <sub>0</sub>	2H	3H
(V)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
======	========		===		
4.0	193.9		+12.8	-15	-16
5.0	202.9	9.0	+12.7	-15	-16
6.0	211.1	8.2	+12.6	-15	-16
7.0	218.6	7.5	+12.6	-15	-17
8.0	225.7	7.1	+12.6	-15	-17
9.0	232.8	7.1	+12.6	-15	-17
10.0	239.3	6.5	+12.3	-16	-18
11.0	245.4	6.1	+12.4	-15	-19
12.0	251.2	5.8	+12.4	-15	-19
13.0	256.4	5.2	+12.4	-15	-19

- + 25 °C ----+70 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9324 2200-2500 MHz

Available as:

TOM9324, 4 Pin TO-8 (T4) TON9324, 4 Pin Surface Mount (SM3) BXO9324, Connectorized Housing (H1)

### **Features**

- Low Frequency Drift
- Operating Case Temp. -54 °C to + 85 °C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

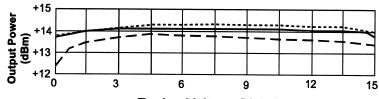
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -54°C to +85 °C	
Frequency	2200 - 2500 MHz	2200 - 2500 MHz	
Output Power (dBm)	+14.0	+12.5 Min.	
Power Flatness (dBm)	±0.25	±0.5 Max.	
Tuning Voltage Range (V)	2 to 11	1 to 13	
Tuning Voltage Sensitivity (MHz/V)	30.0	15.0 Min.	
Harmonics (dBc)	-25	-20 Max	
Spurious (dBc)	<-80	<- 80 Max.	
Phase Noise @ 100 KHz (dBc/Hz)	-105	-100 Max.	
Pushing (MHz/V)	4.0	7.0 Max.	
Pulling (MHz); 24 dB RL	30.0	35.0 Max.	
Frequency Drift (MHz/°C)	± 0.05	±0.2 Max.	
Power Vdc mA	+15 27.0	+15 30.0 Max.	

**Maximum Ratings** 

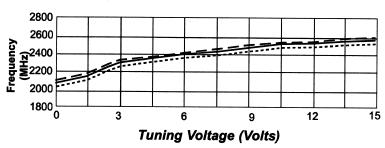
Ambient Operating Temperature55°C to + 10	00 °C
Storage Temperature62°C to + 12	
Case Temperature + 12	
DC Voltage+ 20	
Maximum DC Tuning Voltage+ 20	Volts
Minimum DC Tuning Voltage	Volts

NOTE: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**







V <sub>t</sub>	f .	Df	P.	2H	3H
(V)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc
0.00	2109.2		+13.8	-29	-56
1.00	2160.8	51.6	+14.2	-28	-53
2.00	2204.6	43.8	+14.0	-27	-52
3.00	2250.4	45.8	+14.2	-25	-49
4.00	2294.6	44.2	+14.3	-25	-47
5.00	2337.5	42.9	+14.3	-25	-46
6.00	2376.9	39.4	+14.3	-25	-50
7.00	2412.0	35.1	+14.3	-25	-49
8.00	2441.9	29.9	+14.2	-25	-50
9.00	2467.0	25.1	+14.2	-25	-46
10.00	2488.5	21.5	+14.1	-25	-48
11.00	2507.0	18.5	+14.1	-25	-48
12.00	2523.1	16.1	+14.1	-25	-44
13.00	2537.0	13.9	+14.0	-25	-43
4.00	2549.3	12.3	+14.0	-25	-43
15.00	2560.2	10.9	+13.9	-25	-43

Legend ---- + 25 °C ---- +85 °C ---- 54 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM 9325 2200-2700 MHz

Available as:

TOM9325, 4 Pin TO-8 (T4) TON9325, 4 Pin Surface Mount (SM3) BXO9325, Connectorized Housing (H1)

### **Features**

■ Tuning Variation: 2.2:1 Maximum■ Operating Case Temp. 0 °C to + 50 °C

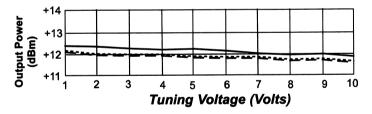
■ Screening to the tables of MIL-STD-883 available

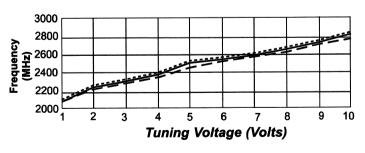
### **Specifications**

•		
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = 0°C to +50 °C
Frequency	2200 - 2700 MHz	2200 - 2700 MHz
Output Power (dBm)	+12.0	+10.0 Min.
Power Flatness (dBm)	±0.5	±1.0 Max.
Tuning Voltage Range (V)	2 to 8	1.5 to 10
Tuning Voltage	80.0	50.0 Min.
Sensitivity (MHz/V)		
Harmonics (dBc)	-18	-12 Max.
Spurious (dBc)	<- 50	- 50 Max.
Phase Noise @10 KHz @ 100 KHz (dBc/Hz)	- 80 -105	- 75 -100 Max.
Pushing (MHz/V)	3.0	7.0 Max.
Pulling (MHz); 20 dB RL	28.0	35.0 Max.
Frequency Drift (MHz/°C)	0.8	1.2 Max.
Power Vdc	+12	+12
mA	33.0	40.0 Max.

## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts





(v)	f (MHz)	∆f (MHz)	P <sub>o</sub> (dBm)	2H (dBc)	3H (dBc)
1.5	2160.2		+12.5	-24	-44
2.0	2214.8	54.6	+12.5	-34	<del>-4</del> 1
3.0	2310.0	95.2	+12.3	-22	<del>-4</del> 6
4.0	2404.2	94.2	+12.3	-17	-39
5.0	2494.2	90.0	+12.2	-16	-36
6.0	2564.4	70.2	+12.2	-21	-37
7.0	2635.0	70.6	+12.1	-17	-35
8.0	2699.3	64.3	+12.1	-14	-35
9.0	2755.3	56.0	+12.1	-13	-33
10.0	2802.2	46.9	+12.0	-13	-33



## **VOLTAGE CONTROLLED TOM9326 OSCILLATOR**

2255-2280 MHz

TOM9326, 4 Pin TO-8 (T4) TON9326, 4 Pin Surface Mount (SM3) BXO9326, Connectorized Housing (H1)

### **Features**

- Low Tuning Voltage Sensitivity
- Operating Case Temp. 0 °C to + 50 °C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = 0°C to +50 °C
Frequency	2255 - 2280 MHz	2255 - 2280 MHz
Output Power (dBm)	+6.0	+4.5 Min.
Power Flatness (dBm)	±0.25	±0.5 Max.
Tuning Voltage Range (V)	0.5 to 4.5	0.5 to 4.5
Tuning Voltage Sensitivity (MHz/V)	7.0	5.0 Min.
Harmonics (dBc)	-24	-20 Max.
Spurious (dBc)	<- 80	- 80 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-105	-100 Max.
Pushing (MHz/V)	6.0	9.0 Max.
Pulling (MHz); 12 dB RL	30.0	40.0 Max.
Frequency Drift (MHz/°C)	0.08	0.17 Max.
Power Vdc mA	+5 20.0	+5 23.0 Max.

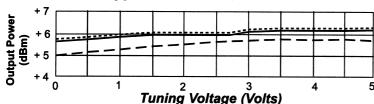
## **Maximum Ratings**

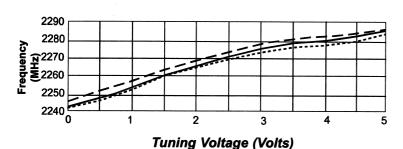
Available as:

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Maximum DC Tuning Voltage	+ 15 Volts
Minimum DC Tuning Voltage	0 Volts

NOTE: Care should always be taken to effectively ground the case of each unit.

## Typical Performance Data





(V)	f (MHz)	Δf (MHz)	(dBm)	2H (dBc)	3H (dBc)
0.0	2241.9		+5.7	 -27	-37
0.5	2250.1	16.4	+5.8	-25	-38
1.0	2256.5	12.8	+5.9	-26	-38
1.5	2261.8	10.6	+5.9	-25	-38
2.0	2266.5	9.4	+6.0	-25	-37
2.5	2270.8	8.6	+6.0	-25	-37
3.0	2274.8	8.0	+6.0	-24	-38
3.5	2278.5	7.4	+6.0	-23	-38
4.0	2281.8	6.6	+6.1	-23	-38
4.5	2285.0	6.4	+6.1	-23	-38
5.0	2288.0	6.0	+6.1	-23	-38

- + 25 °C - - - - +50 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9327

Available as:

TOM9327, 4 Pin TO-8 (T4)
TON9327, 4 Pin Surface Mount (SM3)
BXO9327, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Linear Tuning
- Operating Case Temp. -30 °C to + 55 °C
- Environmental Screening Available

### **Specifications**

+9

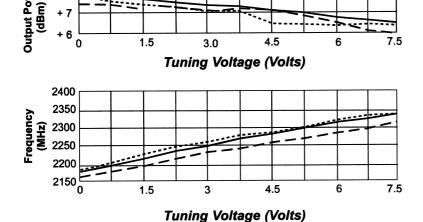
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -30°C to +55 °C	
Frequency	2200 - 2300 MHz	2200 - 2300 MHz	
Output Power (dBm)	+7.0	+5.0 Min.	
Power Flatness (dBm)	±0.75	±1.0 Max.	
Tuning Voltage Range (V)	1.0 to 6.0	0.0 to 7.5	
Tuning Voltage Sensitivity (MHz/V)	25.0	15.0 Min.	
Harmonics (dBc)	-30	-20 Max	
Spurious (dBc)	<- 80	<- 80 Max.	
Phase Noise @ 100 KHz (dBc/Hz)	-105	-100 Max.	
Pushing (MHz/V)	5.0	9.0 Max.	
Pulling (MHz); 12 dB RL	40.0	55.0 Max.	
Frequency Drift (MHz/°C)	-0.35	-1.0 Max.	
Power Vdc mA	+5 27.0	+5 30.0 Max.	

**Maximum Ratings** 

-55°C to + 100 °C
-62°C to + 125 °C
+ 125 °C
+ 10 Volts
+ 15 Volts
0 Volts

NOTE: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



V, (V)	f (MHz)	Df (MHz)	P (dBm)	2H (dBc)	3H (dBc)
0.00	2174.1		+8.16	-27.42	<b>-4</b> 7.99
0.50	2188.9	29.5	+7.96	-27.40	-46.30
1.00	2204.4	31.0	+7.84	-27.51	-45.04
1.50	2215.5	22.2	+7.73	-27.61	-45.67
2.00	2226.3	21.5	+7.61	-27.73	-43.75
2.50	2236.4	20.3	+7.51	-27.97	-43.75
3.00	2246.8	20.7	+7.42	-28.23	-41.77
3.50	2257.4	21.3	+7.29	-28.25	-42.60
4.00	2269.9	25.0	+7.24	-28.32	-43.13
4.50	2279.4	19.0	+7.07	-28.48	<b>-4</b> 3.07
5.00	2289.9	21.0	+7.04	-29.09	-43.61
5.50	2300.0	20.2	+6.86	-29.32	-45.22
6.00	2310.0	20.0	+6.86	-29.97	-45.42
6.50	2320.9	21.8	+6.79	-30.81	-44.75
7.00	2329.6	17.5	+6.77	-31.03	-46.37
7.50	2337.8	16.2	+6.67	-31.46	-47.62

Legend ----- + 25 °C ---- + 55 °C ---- - 30 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM 9328 800-1300 MHz

Available as:

TOM9328, 4 Pin TO-8 (T4) TON9328, 4 Pin Surface Mount (SM3) BXO9328, Connectorized Housing (H1)

### **Features**

- Broad Tuning Range
- Low Noise Bipolar Transistor
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening Available

### **Specifications**

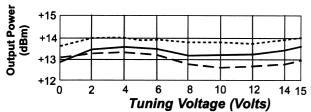
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -55°C to +85 °C
Frequency	800 - 1300 MHz	800 - 1300 MHz
Output Power (dBm)	+13.0	+10.0 Min.
Power Flatness (dBm)	±0.5	±1.0 Max.
Tuning Voltage Range (V)	1.0 to 14.0	0.0 to 15.0
Tuning Voltage Sensitivity (MHz/V)	>38.0	30.0 Min.
Harmonics (dBc)	-20	-10 Max
Spurious (dBc)	<- 80	- 60 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-116	-112 Max.
Pushing (MHz/V)	2.0	4.0 Max.
Pulling (MHz); 20 dB RL	6.0	12.0 Max.
Frequency Drift (MHz/°C)		0.15 Max.
Power Vdc mA	+15 22.0	+15 25.0 Max.

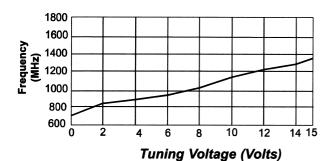
## **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

NOTE: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





V, (V)	f (MHz)	<b>D</b> f (MHz)	P。 (dBm)	2H (dBc)	3H (dBc)
0.00	701.67	0.00	+12.97	-11.68	- 8.92
1.00	771.16	69.49	+13.24	-14.30	-11.33
2.00	812.90	41.74	+13.40	-18.92	-13.13
3.00	846.02	33.12	+13.42	-24.51	-14.04
4.00	876.77	30.75	+13.36	-33.27	-14.65
5.00	909.26	32.49	+13.44	-32.15	-15.57
6.00	946.63	37.37	+13.43	-24.80	-16.47
7.00	988.75	42.12	+13.43	-20.85	-17.76
8.00	1035.62	46.87	+13.29	-19.11	-18.84
9.00	1086.36	50.74	+13.22	-18.74	-20.80
10.00	1136.35	49.99	+13.22	-18.75	-21.68
11.00	1184.22	47.87	+13.19	-18.82	-22.23
12.00	1228.47	44.25	+13.24	-19.56	-23.06
13.00	1267.46	38.99	+13.39	-20.37	-23.85
14.00	1301.58	34.12	+14.47	-20.69	-25.19
15.00	1331.58	30.00	+13.68	-21.03	-25.91

Legend ----- + 25 °C ----- + 85 °C ----- -55 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9329 1875-1975 MHz

Available as:

TOM9329, 4 Pin TO-8 (T4)
TON9329, 4 Pin Surface Mount (SM3)
BXO9329, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Linear Tuning
- Operating Case Temp. -30 °C to + 55 °C
- Environmental Screening Available

### **Specifications**

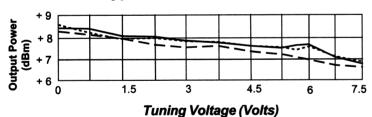
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -30°C to +55 °C	
Frequency	1875 - 1975 MHz	1875 - 1975 MHz	
Output Power (dBm)	+7.0	+5.0 Min.	
Power Flatness (dBm)	±0.5	±0.75 Max.	
Tuning Voltage Range (V)	0.5 to 5.5	0.0 to 7.5	
Tuning Voltage Sensitivity (MHz/V)	25.0	15.0 Min.	
Harmonics (dBc)	-30	-20 Max.	
Spurious (dBc)	<- 80	<- 80 Max.	
Phase Noise @ 100 KHz (dBc/Hz)	-105	-100 Max.	
Pushing (MHz/V)	6.0	9.0 Max.	
Pulling (MHz); 12 dB RL	40.0	55.0 Max.	
Frequency Drift (MHz/°C)	-0.35	-0.50 Max.	
Power Vdc mA	+5 24.0	+5 30.0 Max.	

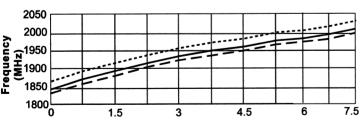
## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Maximum DC Tuning Voltage	+ 15 Volts
Minimum DC Tuning Voltage	0 Volts

NOTE: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





Tuning Voltage (Volts)

V <sub>t</sub>	f	Δf	Po	2H	3H
(Ÿ)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
====				====:	====
0.00	1851.9		+8.49	-28.96	-33.91
0.50	1868.4	33.0	+8.45	-29.45	-33.52
1.00	1883.0	29.2	+8.31	-30.63	-34.13
1.50	1895.6	25.3	+8.12	-32.05	-34.59
2.00	1907.3	23.2	+8.08	-32.79	-33.97
2.50	1918.6	22.8	+7.95	-33.32	-34.35
3.00	1929.0	20.7	+7.82	-34.06	-35.94
3.50	1939.0	20.0	+7.82	-34.93	-37.88
4.00	1948.6	19.3	+7.64	-36.10	-38.50
4.50	1958.1	19.0	+7.55	-37.23	-37.58
5.00	1967.6	19.0	+7.47	-38.03	-38.80
5.50	1976.6	18.0	+7.46	-38.65	-39.44
6.00	1985.8	18.2	+7.32	-39.38	-38.47
6.50	1995.3	19.0	+7.15	-39.36	-38.83
7.00	2004.3	18.0	+7.02	-40.15	-38.87
7.50	2013.8	19.0	+6.93	-40.70	-38.52

Legend ----- + 25 °C - - - - +55 °C -----30 °C



## VOLTAGE CONTROLLED OSCILLATOR TOM 9330 1700 - 2700 MHz

Available as:

TOM9330, 4 Pin TO-8 (T4) TON9330, 4 Pin Surface Mount (SM3) BXO9330, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Operating Case Temp. 0 °C to + 70 °C
- Environmental Screening available

### **Specifications**

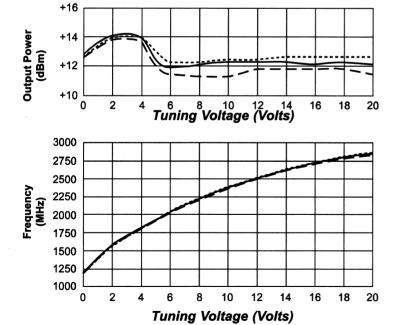
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = 0 °C to +70 °C
Frequency	1700 - 2700 MHz	1700 - 2700 MHz
Output Power (dBm)	+12	+10.0 Min.
Power Flatness (dBm)	±1.5	±1.5 Max.
Tuning Voltage Range (V)	3 to 17	0 to 20
Tuning Voltage Sensitivity (MHz/V)	80	30 Min.
Harmonics (dBc)	- 20	- 14 Max.
Spurious (dBc)	<-80	- 80 Max.
Phase Noise @ 100 KHz (dBc/hz)	- 101	- 95 Max.
Pushing (MHz/V)	5.0	10.0 Max.
Pulling (MHz); 22 dB RL	30	45 Max.
Frequency Drift (MHz/°C)	_	0.5 Max.
Power Vdc	+15	+15
mA	19	20.0

## **Maximum Ratings**

-55°C to + 100 °C
-62°C to + 125 °C
+ 125 ℃
+ 20 Volts
+ 22 Volts
0 Volts

NOTE: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



V <sub>t</sub>	f	Δf	Po	2H	3H
(V)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
=====		=======			
0.00	1198.0		+12.8	-18.3	-11.8
1.00	1409.7	211.7	+13.9	-22.2	-16.3
2.00	1582.6	172.9	+14.1	-21.8	-19.5
3.00	1713.3	130.7	+13.9	-17.5	-21.8
4.00	1817.4	104.2	+13.9	-17.0	-25.0
5.00	1931.3	113.8	+12.9	21.2	-33.2
6.00	2041.8	110.5	+11.9	-37.8	-27.0
7.00	2135.4	93.7	+12.1	-30.7	-26.8
8.00	2220.7	85.3	+12.1	-27.0	-24.2
9.00	2301.5	80.8	+12.1	-25.7	-25.1
10.00	2378.3	76.8	+12.3	-25.3	-25.5
11.00	2449.2	70.8	+12.4	25.8	-26.5
12.00	2515.4	66.3	+12.3	26.2	-27.4
13.00	2576.9	61.5	+12.3	26.7	-29.3
14.00	2633.4	56.5	+12.3	27.2	-32.2
15.00	2684.7	51.3	+12.4	27.8	-32.0
16.00	2730.6	45.9	+12.1	28.3	-31.6
17.00	2770.4	39.8	+12.3	29.3	-32.0
18.00	2803.8	33.3	+12.3	29.5	-31.7
19.00	2829.9	26.2	+12.1	29.7	-33.1
20.00	2849.4	19.5	+12.1	30.2	-33.2

Legend -----+70 °C ----- 0 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9331 1725-1790 MHz

Available as:

TOM9331, 4 Pin TO-8 (T4) TON9331, 4 Pin Surface Mount (SM3) BXO9331, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Linear Tuning
- Operating Case Temp. -35 °C to + 60 °C
- Environmental Screening Available

### **Specifications**

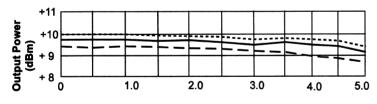
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -35°C to +60 °C	
Frequency	1725 - 1790 MHz	1725 - 1790 MHz	
Output Power (dBm)	+9.5	+8.0 Min.	
Power Flatness (dBm)	±0.5	±0.75 Max.	
Tuning Voltage Range (V)	0.5 to 4.5	0.0 to 5.0	
Tuning Voltage Sensitivity (MHz/V)	20.0	15.0 Min.	
Harmonics (dBc)	-30	-20 Max.	
Spurious (dBc)	<- 80	<- 80 Max.	
Phase Noise @ 100 KHz (dBc/Hz)	-104	-100 Max.	
Pushing (MHz/V)	6.0	9.0 Max.	
Pulling (MHz); 12 dB RL	40.0	55.0 Max.	
Frequency Drift (MHz/°C)	-0.35	-0.50 Max.	
Power Vdc mA	+5 30.0	+5 35.0 Max.	

### **Maximum Ratings**

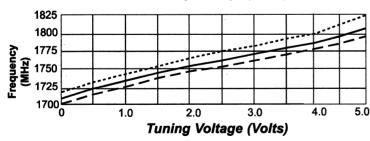
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 10 Volts
Maximum DC Tuning Voltage	+ 15 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



### Tuning Voltage (Volts)



V <sub>t</sub> (V)	f <sub>o</sub> (MHz)	Δf (MHz)	P <sub>o</sub> (dBm)	2H (dBc)	3H (dBc)
0.00	======================================		=== +9.79	-31.5	-37.9
0.50	1718.3	22.5	+9.80	-30.9	-39.8
1.00	1730.1	23.8	+9.81	-30.7	-36.8
1.50	1741.5	22.7	+9.72	-30.5	-33.9
2.00	1751.5	20.0	+9.70	-30.3	-36.6
2.50	1762.1	21.3	+9.64	-30.4	-32.7
3.00	1770.6	17.0	+9.48	-29.7	-33.4
3.50	1779.4	17.5	+9.51	-29.8	-32.4
4.00	1788.1	17.5	+9.35	-29.5	-31.8
4.50	1797.3	18.2	+9.29	-29.8	-32.5
5.00	1806.0	17.5	+9.17	-29.7	-31.7

Legend ----- + 25 °C - - - - +60 °C ----- 35 °C



## **VOLTAGE CONTROLLED TOM9332 OSCILLATOR**

1400 - 1800 MHz

### Available as:

TOM9332, 4 Pin TO-8 (T4)

TON9332, 4 Pin Surface Mount (SM3)

BXO9332, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- **Broad Tuning Range**
- Operating Case Temp. -55 °C to + 95 °C
- Environmental Screening available

### **Specifications**

+15

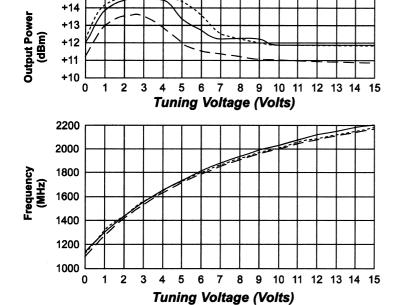
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +95 °C
Frequency	1400 - 1800 MHz	1400 - 1800 MHz
Output Power (dBm)	>+12	+10.0 Min.
Power Flatness (dBm)	±1.0	±1.5 Max.
Tuning Voltage Range (V)	1.5 to 8	0 to 15
Tuning Voltage Sensitivity (MHz/V)	<125	40 Min.
Harmonics (dBc)	<-18	-10 Max.
Spurious (dBc)	<-80	- 80 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-108	-100 Max.
Pushing (MHz/V)	<2	3.0 Max.
Pulling (MHz); 22 dB RL	21	30.0 Max.
Frequency Drift (MHz/°C)		0.2 Max.
Power Vdc mA	+15 20	+15 24.0 Max.

### **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



V <sub>t</sub>	f	Δf	Po	2H	3H
(v)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
======	========	=======	===		
0.0	1135.4		+12.0	- 8.8	-19.5
1.00	1300.8	165.4	+13.9	-14.2	-17.8
2.00	1437.2	136.3	+14.4	-19.0	-19.5
3.00	1554.5	117.3	+14.5	-19.3	-22.8
4.00	1650.1	95.6	+14.2	-18.0	-26.2
5.00	1733.3	83.3	+13.4	-19.2	-33.5
6.00	1813.4	80.1	+12.7	-22.8	-32.5
7.00	1880.3	66.9	+12.2	-27.7	-30.2
8.00	1939.3	58.9	+12.2	-34.2	-28.8
9.00	1991.8	52.6	+12.2	-36.0	-29.0
10.00	2038.3	46.5	+11.9	-32.0	-29.3
11.00	2079.8	41.5	+11.9	-30.3	-29.3
12.00	2118.6	38.8	+12.2	-29.3	-30.2
13.00	2152.4	33.8	+12.0	-28.5	-30.5
14.00	2183.1	30.7	+11.9	-27.5	<-30
15.00	2208.9	25.8	+11.7	-27.0	<-30

+ 25 °C -- -- +95 °C -- -- -55°C



## VOLTAGE CONTROLLED OSCILLATOR TOM 9334 1000 - 1600 MHz

Available as:

TOM9334, 4 Pin TO-8 (T4) TON9334, 4 Pin Surface Mount (SM3) BXO9334, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range

### **Specifications**

+14

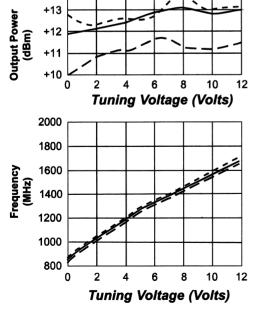
•		
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -45°C to +85 °C
Frequency	1000 - 1600 MHz	1000 - 1600 MHz
Output Power (dBm)	+12.5	+10.0 Min.
Power Flatness (dBm)	±0.7	±1.0 Max.
Tuning Voltage Range (V)	1 to 11	1 to 11
Tuning Voltage Sensitivity (MHz/V)	60	40 Min.
Harmonics (dBc)	-20	-12 Max.
Spurious (dBc)	<-80	- 80 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-113	-102 Max.
Pushing (MHz/V)	<2.5	5.0 Max.
Pulling (MHz); 20 dB RL	20	25 Max.
Frequency Drift (MHz/°C)	-	0.2 Max.
Power Vdc mA	+15 19	+15 20.0

## **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 22 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**



f	Δf	P	2H	3H
(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
=========		===		
885.1		+11.9	-19.0	-19.0
986.9	101.9	+12.1	-23.3	-18.2
1084.0	97.1	+12.1	-25.5	-19.2
1162.1	78.1	+12.1	-24.0	-20.5
1232.0	69.9	+12.3	-22.5	-22.3
1297.6	65.6	+12.4	-22.5	-24.5
1358.2	60.6	+12.9	-22.8	-26.5
1414.3	56.1	+13.1	-22.5	-29.2
1469.2	54.9	+13.1	-21.3	-33.0
1526.4	57.2	+12.9	-19.7	-36.7
1579.7	53.4	+12.6	-19.7	-39.2
1628.9	49.2	+12.8	-19.5	-38.8
	(MHz) ====================================	**MHz** (MHz)**  *********************************	885.1 +11.9 986.9 101.9 +12.1 1084.0 97.1 +12.1 1162.1 78.1 +12.1 1232.0 69.9 +12.3 1297.6 65.6 +12.4 1358.2 60.6 +12.9 1414.3 56.1 +13.1 1469.2 54.9 +13.1 1526.4 57.2 +12.9 1579.7 53.4 +12.6	(MHz) (MHz) (dBm) (dBc)

Legend ----- + 25 °C -----45 °C -----45 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM 9335 750-940 MHz

Available as:

TOM9335, 4 Pin TO-8 (T4) TON9335, 4 Pin Surface Mount (SM3) BXO9335, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -40 °C to + 85 °C
- Environmental Screening Available

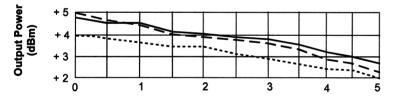
### **Specifications**

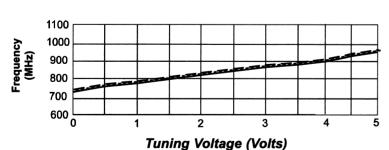
<u> </u>		
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -40°C to +85 °C
Frequency	750 - 940 MHz	750 - 940 MHz
Output Power (dBm)	+3.0	+2.0 Min.
Power Flatness(dBm)	±1.0	±1.5 Max.
Tuning Voltage Range (v)	0.0 to 5.0	0.0 to 5.0
Tuning Voltage Sensitivity (MHz/V)	40.0	30 to 55 Min.
Harmonics (dBc)	-11	-10 Max
Spurious (dBc)	<- 60	<- 60 Max.
Phase Noise @ 100 KHz (dBc/hz)	-102	-100 Max.
Pushing (MHz/V)	3.0	6.0 Max.
Pulling (MHz); 12 dB RL	25.0	35.0 Max.
Frequency Drift ( MHz/ °C)		±0.25 Max.
Power Vdc mA	+5 8.0	+5 10.0 Max.

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.





٧,	f	Δf	P	2H	3H
(v)	(MHz)	(MHz)	(dBm)	(dBc)	(dBc)
======		=======			
0.00	737.3		+4.90	-11.8	-29.6
0.50	762.1	49.8	+4.55	-12.1	-30.0
1.00	782.6	41.0	+4.42	-12.4	-31.0
1.50	802.1	39.0	+4.11	-12.6	-31.2
2.00	821.1	38.0	+4.10	-13.0	-31.1
2.50	840.5	38.8	+3.93	-13.1	-30.2
3.00	861.1	41.2	+3.72	-13.5	-29.8
3.50	882.0	41.8	+3.48	-13.7	-29.2
4.00	903.6	43.2	+3.24	-14.1	-28.5
4.50	926.3	45.3	+3.00	-14.3	-28.9
5.00	949.8	47.0	+2.82	-14.7	-31.3

Legend ——— + 25 °C − − − − +85 °C ---- 40 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9336 385-415 MHz

Available as:

TOM9336, 4 Pin TO-8 (T4) TON9336, 4 Pin Surface Mount (SM3) BXO9336, Connectorized Housing (H1)

### **Features**

- 5 Volt Operation
- Operating Case Temp. 0 °C to + 50 °C
- Environmental Screening Available

### **Specifications**

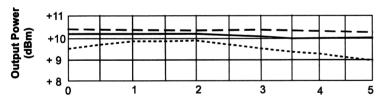
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = 0°C to +50 °C
Frequency	385 - 415 MHz	385 - 415 MHz
Output Power (dBm)	+10.0	+6.0 Min.
Power Flatness (dBm)	±0.25	±0.5 Max.
Tuning Voltage Range (V)	0.0 to 5.0	0.0 to 5.0
Tuning Voltage Sensitivity (MHz/V)	10.0	5.0 Min.
Harmonics (dBc)	- 7.0	-5.0 Max.
Spurious (dBc)	<- 60	<- 60 Max.
Phase Noise @ 100 KHz (dBc/Hz)	-100	- 90 Max.
Pushing (MHz/V)	3.0	8.0 Max.
Pulling (MHz); 12 dB RL	3.0	5.0 Max.
Frequency Drift (MHz/°C)	±.04	±.10 Max.
Power Vdc mA	+5 33.0	+5 40.0 Max.

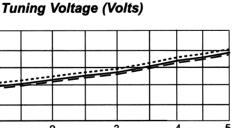
## **Maximum Ratings**

Ambient Operating Temperature	55°C to + 85 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 10 Volts
Maximum DC Tuning Voltage	+ 10 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





Tuning Voltage (Volts)

v, (V)	f <sub>o</sub> (MHz)	Δf (MHz)	P <sub>o</sub> (dBm)	2H (dBc)	3H (dBc)
======	========	=======	===		
0.00	376.8		+10.3	-7.6	-20.5
1.00	384.8	8.0	+10.4	-7.8	-20.3
2.00	394.8	10.0	+10.5	-7.8	-22.0
3.00	405.7	10.9	+10.3	-7.7	-25.6
4.00	416.2	10.5	+10.1	-7.3	-21.9
5.00	426.8	10.6	+10.0	-7.3	-21.2

Legend ----- + 25 °C - - - - + 50 °C ----- 9 °C



## **VOLTAGE CONTROLLED TOM9338 OSCILLATOR**

180-220 MHz

### Available as:

TOM9338, 4 Pin TO-8 (T4) TON9338, 4 Pin Surface Mount (SM3) BXO9338, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- **Broad Tuning Range**
- Operating Case Temp. -40 °C to +85 °C
- Environmental Screening Available

### **Specifications**

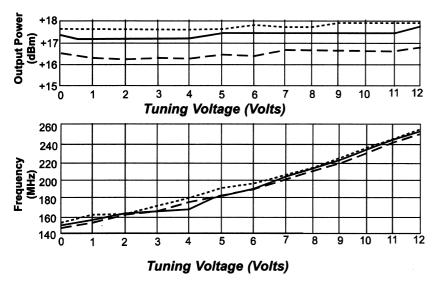
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -40°C to +85 °C
Frequency	180 - 220 MHz	180 - 220 MHz
Output Power (dBm)	+17.5	+15.0 Min.
Power Flatness (dBM)	±0.25	±0.5 Max.
Tuning Voltage Range (V)	4.0 to 9.0	0.0 to 12.0
Tuning Voltage Sensitivity (MHz/V)	9.0	3.0 Min.
Harmonics (dBc)	20.0	10.0 Max.
3dB Modulation BW, Zg = 50 Ohms		5 MHz Min.
Pushing (MHz/V)	0.5	2.0 Max.
Pulling (MHz); 14 dB RL	5.0	10.0 Max.
Frequency Drift (MHz/°C)		.10 Max.
Power Vdc mA	+15 26.0	+15 30.0 Max.

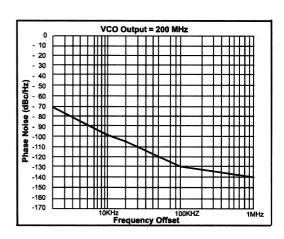
## **Maximum Ratings**

Ambient Operating Temperature	40°C to + 85 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 15 Volts
Maximum DC Tuning Voltage	+ 15 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





#### Notes:

- 1- Phase Noise is measured using the Aeroflex PN9000.
- 2- Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -120dBc/Hz



# VOLTAGE CONTROLLED OSCILLATOR TOM 9339 3900-4100 MHz

Available as:

TOM9339, 4 Pin TO-8 (T4) TON9339, 4 Pin Surface Mount (SM3) BXO9339, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to + 85 °C
- Environmental Screening Available

### **Specifications**

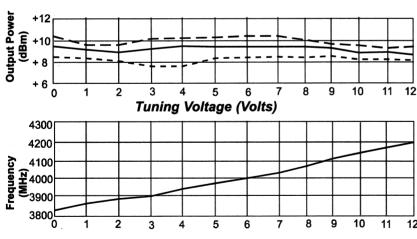
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -40°C to +85 °C
Frequency	3900 - 4100 MHz	3900 - 4100 MHz
Output Power (dBm)	+ 9.5	+ 8.0 Min.
Power Flatness (dBM)	±0.25	±0.5 Max.
Tuning Voltage Range (V)	2.0 to 10.0	0.0 to 12.0
Tuning Voltage Sensitivity (MHz/V)	35.0	20.0 Min.
Harmonics (dBc)	-16.0	-12.0 Max.
Spurious (dBc)	< -80	< -60
3dB Modulation BW, Zg = 50 Ohms		20MHz Max.
Pushing (MHz/V)	2.0	6.0 Max.
Pulling (MHz); 14 dB RL	14.0	20.0 Max.
Frequency Drift (MHz/°C)	0.10	0.15 Max.
Power Vdc mA	+12 21.0	+12 25.0 Max.

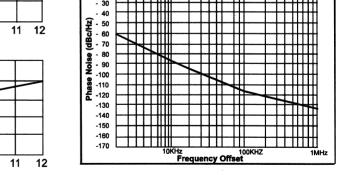
### **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 85 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

## **Typical Performance Data**





Tuning Voltage (Volts)

#### Notes:

1- Phase Noise is measured using the Aeroflex PN9000.

VCO Output = 4000 MHz

2- Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -95 dBc/Hz

Legend — + 25 °C − − − +50 °C ----- 0 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM 9340 3200-4000 MHz

Available as:

TOM9340, 4 Pin TO-8 (T4)
TON9340, 4 Pin Surface Mount (SM3)
BXO9340, Connectorized Housing (H1)

### **Features**

- Low Noise Bipolar Transistor
- Broad Tuning Range
- Operating Case Temp. -55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

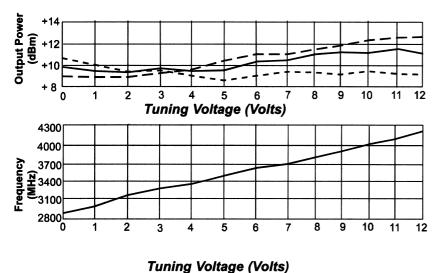
CHARACTERISTIC	TYPICAL Ta = +25 °C	MIN/MAX Ta = -40°C to +85 °C
Frequency	3200 - 4000 MH	3200 - 4000 MHz
Output Power (dBm)	+10.0	+ 8.0 Min.
Power Flatness (dBM)	±0.75	±1.5 Max.
Tuning Voltage Range (V)	1.0 to 11.0	0.0 to 12.0
Tuning Voltage Sensitivity (MHz/V)	100.0	80.0 Min.
Harmonics (dBc)	-15.0	-10.0 Max.
Spurious (dBc)	< -80	< -60
3dB Modulation BW, Zg = 50 Ohms		25MHz Max.
Pushing (MHz/V)	3.0	8.0 Max.
Pulling (MHz); 14 dB RL	7.0	12.0 Max.
Frequency Drift (MHz/°C)	0.10	0.15 Max.
Power Vdc mA	+12 27.0	+12 30.0 Max.

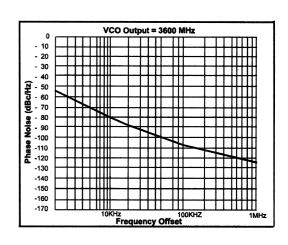
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 85 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volts
Maximum DC Tuning Voltage	+ 20 Volts
Minimum DC Tuning Voltage	0 Volts

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**





#### Notes

- 1- Phase Noise is measured using the Aeroflex PN9000.
- 2- Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -95 dBc/Hz

Legend \_\_\_\_\_ + 25 °C \_ \_ \_ \_ +50 °C -----0 °C



# VOLTAGE CONTROLLED OSCILLATOR TOM9341 2200 - 2400 MHz

Available as:

TOM9341, 4 Pin TO-8 (T4)
TON9341-3, 4 Pin Surface Mount (SM3)
TOP9341-4, 4 Pin Flatpack (FP4)
BXO9341, Connectorized Housing (H1)

### **Features**

- n Low Noise Bipolar Transistor
- n Operating Case Temp. -55 °C to +85 °C
- n Environmental Screening available

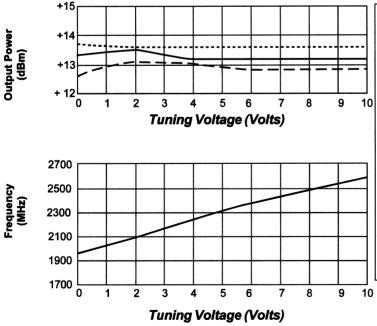
### **Specifications**

Opcomoduono		
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	2200 - 2400 MHz	2200 - 2400 MHz
Output Power (dBm)	+13	+12 Min.
Power Flatness (dBm)	±0.2	±1.0 Max.
Tuning Voltage Range (v)	3 to 9	3 to 9
Tuning Voltage	45	30 Min.
Sensitivity (MHz/V)		
Harmonics (dBc)	-30	-20 Max.
Spurious (dBc)	<-80	-60 Max.
Phase Noise	-105	-100 Max.
@ 100KHz (dBc/Hz)	-105	-100 Max.
Pushing (MHz/V)	4	8 Max.
Pulling (MHz); 20 dB RL	35	43 Max.
Frequency Drift (MHz/°C	0.07	0.15 Max.
Power Vdc	+15	+15
mA	35	40

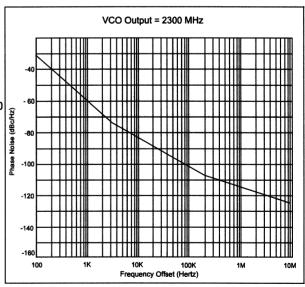
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 20 Volt
Maximum DC Tuning Voltage	+ 20 Volt
Minimum DC Tuning Voltage	0 Vo

### **Typical Performance Data**



+ 25 °C -- -- +85 °C -- -- -55 °C



Notes:

- 1. Phase Noise is measured using the Aeroflex PN9000.
- 2. Worst case phase noise @ 100KHz offset across frequency range and temperature extremes is -100 dBc/Hz.



**Limiting Amps** 

Amplifonix Limiting Amplifiers range from 7 dB to as high as +55 dB of gain before limiting. These units also duplicate the performance of existing Watkins-Johnson, M/A-Com and Avantek styles as listed in the Cross Reference List.

Model	Frequ Ran (MF	nge	Ga (d (Typ.)	ain B) (Min.)	Input Power Limiting Range (dBm)	Output Level Saturated (dBm) (Typ.) (Min.)	Output Power Flatness (Max.)	Noise Figure Typ. (dB)	VSWR (Max.)		wer /p. (mA)
TDL9552	5	500	32	30	-23 to +17	(-2.0) (-4.0)	±0.5	11.1	2.0:1	±15	±60
ENL9653	5	500	38	30	-30 to +10	(-0.5) (-2.0)	±1.0	10	2.0:1	15	70
TML9052	5	500	9.5	7.0	- 3 to + 7	(-2.0) (-4.0)	±0.5	11	2.0:1	±15	±80
TML9053	5	500	9.5	7.0	- 6 to + 7	(-2.0) (-4.0)	±1.0	10	1.5:1	15	20
TML9002	50	500	12.5	11	0 to +20	(+15) (+13)	±1.0	9	2.0:1	15	54
TML9004	50	500	10	9.0	0 to +20	(+13.5) (+12)	±1.0	9	2.0:1	12	50
TML9017	10 1	000	11.5	9.5	0 to +20	(+15) (+13)	±1.0	7.5	2.2:1	15	36
ENL9654	10 1	000	55	35	-52 to +10	(0) (-4.0)	±0.4	9	2.2:1	15	80

### **Direct Crosses to Other Manufacturer's Parts**

W-J, M/A-Com	Amplifonix	Avantek, Avnet	Amplifonix
PPL504	PNL9054	LA-7	TML9002
UDL502	TDL9552	LA-17	TML9017
UTL502	TML9052	LA-88	TML9088
UTL503	TML9053	LG-1	TML9003
		LG-30	TML9009
		AL-7	TL9012

## **Limiters**

Limiting amplifiers operate from 5 MHz to 1 GHz and are useful in protecting circuitry from overdrive damage and for removing amplification modulation from FM signals. Available in 4 Pin TO-8, Surface Mount Packages and Connectorized Housings.

Model	R	quency ange WHz)	Level at Three @1 dB Co (dE	Power Limiting shold empression 3m)	Limitin @+20dl (dE	m Output g Level Bm Input Bm)	@	ion Loss 15 V dB)	VSWR In/Out	Po	wer
	Low	High	(Тур.)	(Max.)	(Тур.)	(Max.)	(Typ.)	(Max.)	(Max.)	DC	mA
TL9010	50	1000	-2.0	+1.0	-1.0	+3.0	2	3.0	2.0:1/2.0:1	+15	7
TL9011	5	500	-2.0	+1.0	-1.0	+3.0	2	3.0	2.0:1/2.0:1	+15	7

### **Direct Crosses to Other Manufacturer's Parts**

Watkins - Johnson, M/A-Com	Amplifonix
L-1	TL9010
L-2	TL9011

# RF LIMITING AMPLIFIER MODEL TML9002

Package Style: 4 Pin TO-8

Also Available in: Surface Mount Package

and Connectorized Housings

### **Features**

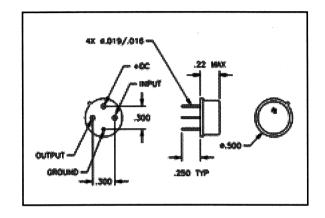
- Frequency: 50 to 500 MHz
- Low Phase Shift per dB of Compression
- Operating Temp. -55C to +85C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C	
Frequency	50 - 500 MHz	50 - 500 MHz	
Small Signal Gain (dB)	12.6	11 Min.	
Saturated Output Power (dBm) 50-300 300-500	12 11.5	8 +7 Min.	
Saturated Flatness	± 0.2	± 0.7	
VSWR Input/Output	1.2:1/1.4:1	2.0:1 Max.	
Noise figure (dB)	7.0	9 <sub>Max.</sub>	
Power +Vdc mA	+15 54	+15 58 Max.	

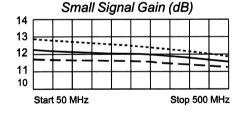
**Maximum Ratings** 

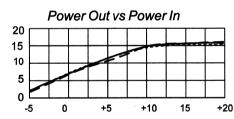
<b>Ambient Operating Temperature</b>	e55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+17 Volts
Continuous RF Input Power	+ 15 dBm

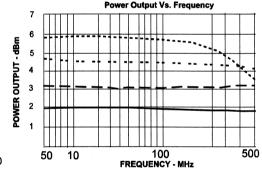


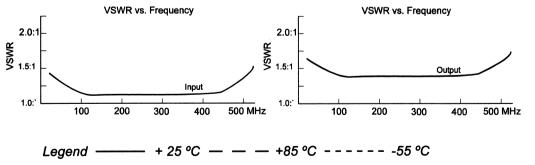
Note: Care should always be taken to effectively ground the case of each unit.

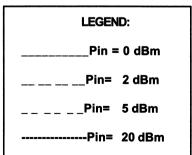
### **Typical Performance Data**













# RF LIMITING AMPLIFIER MODEL TML9004

Package Style: 4 Pin TO-8

Also Available in: Surface Mount Package

and Connectorized Housings

### **Features**

- Frequency: 50 to 500 MHz
- Power Output (1 dB comp.) +11 dBm
- Operating Temp. -55C to +85C
- Environmental Screening Available

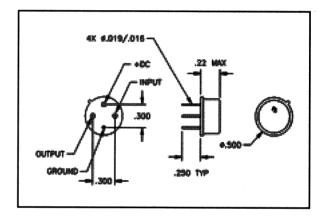
### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	50 - 500 MHz	50 - 500 MHz
Small Signal Gain (dB)	10	9 Min.
Saturated Output Power (dBm)	11	+8 Min.
Saturated Flatness(dB)	± 0.8	± 1.0
VSWR Input/Output	1.2:1/1.4:1	2.0:1 Max.
Noise figure (dB)	7.0	9 Max.
Power +Vdc mA	+12 50	+12 50 Max.

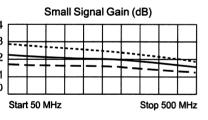
Note: Care should always be taken to effectively ground the case of each unit.

### **Maximum Ratings**

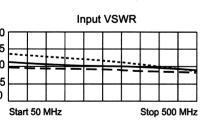
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+17 Volts
Continuous RF Input Power	

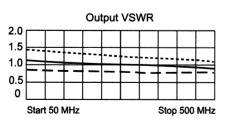


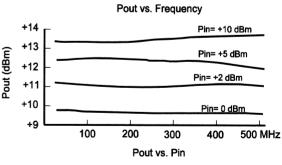
### **Typical Performance Data**















# RF LIMITER MODEL TL9010

Available as: TNL9010, 4 Pin Surface Mount (SM3)

FPL9010, 4 Pin Flatpack (FP4)

BXL9010, Connectorized Housing (H1)

### **Features**

- Voltage Variable Limiting Level
- Good Even Order Harmonic Suppresion
- **■** Low Insertion Loss
- Low VSWR
- 4 Pin TO-8 Metal Hermetic Package
- Operating Temp. -55 °C to + 100 °C

### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX
Frequency (MHz)	5-1000	50-1000
Insertion loss (dB) @15V	2.0	3.0
Power @ 1 dB comp. (dBm) V= +15V	-2	+1.0
Max output level (dBm) @ +20 dBm input	-1	+3.0
VSWR In Out	1.7:1 1.7:1	2.0:1 2.0:1
Max Input Level (dBm)		+26
Bias Power Vdc mA	15 7	20 10

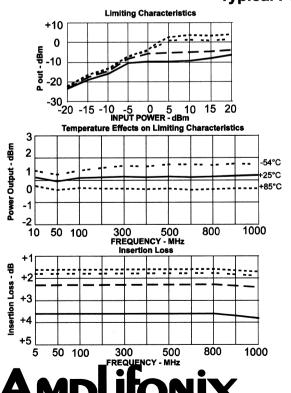
**Maximum Ratings** 

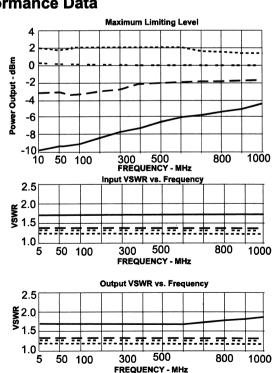
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 13dBm
Short Term RF Input Power	50 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	0.2 Watt
	(3 μsec Max.)

Legend:\_\_\_\_+5Vdc \_\_ \_\_ \_+10Vdc \_ \_ \_+15Vdc -----+20Vdc

Note: Care should always be taken to effectively ground the case of each unit.

### **Typical Performance Data**





# RF LIMITER MODEL

## TL9011

Available as: TNL9011, 4 Pin Surface Mount (SM3)

FPL9011, 4 Pin Flatpack (FP4) BXL9011, Connectorized Housing (H1)

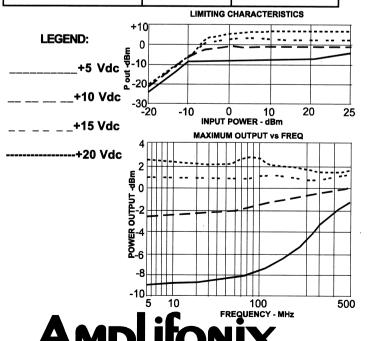
### **Features**

- Voltage Variable Limiting Level
- Good Even Order Harmonic Suppresion
- Low Insertion Loss
- Low VSWR
- 4 Pin TO-8 Metal Hermetic Package
- Operating Temp. -55 °C to + 85 °C

### **Specifications**

Note: Care should always be taken to effectively ground the case of each unit.

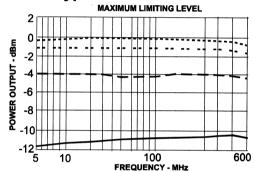
, , , , , , , , , , , , , , , , , , ,						
CHARACTERISTIC	TYPICAL	MIN/MAX				
Frequency (MHz)	5 - 500	5 - 500				
Insertion Loss Power	2.0	3.0				
Input= -20 dBm V=+15	2.0	3.0				
Output Level at Limiting						
Threshold (1 dB comp.)						
V= +20	5	1.0				
V= +15	-1.5	0.0				
V= +10	-4.0	-2.5				
V= +5	-11.0	-9.0				
Max. Output Limiting Level						
@ +20 dBm (100 MHz)						
V= +20	+2.0	+3.0				
V= +15	+1.0	+2.0				
V= +10	-2.0	0.0				
V= +5	-7.0					
VSWR In	1.7:1	2.0:1				
Out	1.7:1	2.0:1				
Max Input Level (dBm)		+26				
Bias Power Vdc	+15	+20				
m A	7	10				

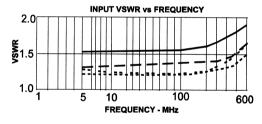


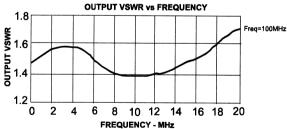
### **Maximum Ratings**

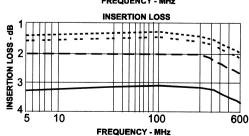
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power	
Maximum Peak Power	1.0 Watt
	(3 msec Max )

### **Typical Performance Data**









# RF LIMITING AMPLIFIER 'MODEL TML9017

Available as:

TNL9017, 4 Pin Surface Mount (SM3) BXL9017, Connectorized Housing (H1)

TML9017, 4 Pin TO-8 (T4)

### **Features**

- High Output Level: +10 dBm Typical
- Good Even Order Supression
- Operating Temp. -55°C to +85°C
- Environmental Screening Available

### Typical Intermodulation Performance at 25°C

Second Order Harmonic Intercept Point+43 (Typ.)
Second Order Two Tone Intercept Point+37 (Typ.)
Third Order Two Tone Intercept Point+24 (Typ.)

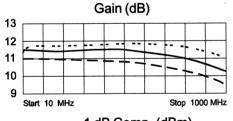
### **Specifications**

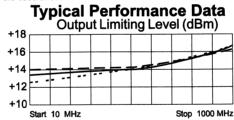
CHARACTERISTIC	TYPICAL	MIN/MAX
Frequency (MHz)	10 - 1000 MHz	10 - 1000 MHz
Small Signal Gain (dB)	11.5	9.5 Min.
Power @ 1 dB comp. (dBm)	+11	+7.0 Min.
Output Limiting Level (dBm)PIN=+20 dBm	+15	+17 Max.
VSWR In Out	<1.75:1 <1.85:1	2.0:1 Max. 2.2:1 Max.
Noise Figure (dB)	5.8	7.5 Max.
Power Vdc	+15	+15
m A	36	42 Max.

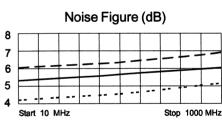
**Maximum Ratings** 

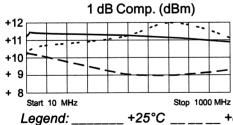
11102111110111111	
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 23 dBm
Short Term RF Input Power	400 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	
	(3 μsec Max.)

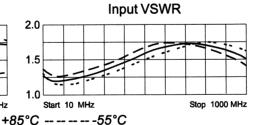
Note: Care should always be taken to effectively ground the case of each unit.

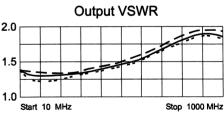












 . 20	_	 	•	_	•	
		Linear	S-	Pa	rameters	

Freq	S	11	S2	21	S1	2	S2	22
MHz	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
=====		======		======	=======		======	=====
10	.12	- 31	3.61	-176	.09	7	.16	166
50	.09	- 12	3.67	171	.10	- 2	.14	154
100	.09	- 6	3.64	160	.10	- 4	.15	136
200	.12	- 7	3.63	139	.10	-11	.15	101
400	.19	- 35	3.65	97	.10	-26	.21	35
600	.25	- 73	3.63	54	.11	-44	.28	- 22
800	.26	-113	3.50	8	.10	-77	.33	- 77
1000	.19	-153	3.26	- 39	.11	-72	.32	-137



# RF LIMITING AMPLIFIER MODEL TML9052

Package Style: 4 Pin TO-8

Also Available in: Surface Mount Package

and Connectorized Housings

### **Features**

- Frequency: 5 to 500 MHz
- Low Phase Shift per dB of Compression
- Operating Case Temp. -55 C to + 85 C
- Environmental Screening available

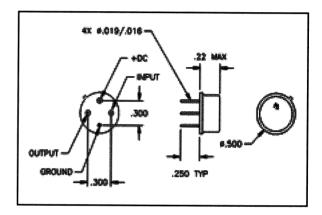
### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Small Signal Gain (dB)	9	7.0 Min.
Saturated Output Power (dBm)	-2	-4 Min.
Saturated Flatness(dB)	±0.4	±0.5
VSWR Input/Output	1.5:1/1.9:1	2.0:1 Max.
Even Harmonic Suppression @ P <sub>IN</sub> = -50 to +7 dBm	11	9
Noise figure (dB)	5.5	11 Max.
Power +Vdc -Vdc mA mA	+15 -15 20 20	+15 -15 20 20 Max.

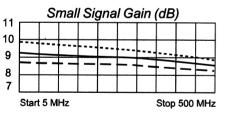
Note: Care should always be taken to effectively ground the case of each unit.

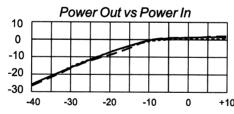
### **Maximum Ratings**

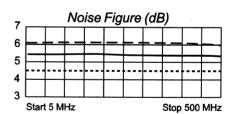
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+17 Volts
Continuous RF Input Power	

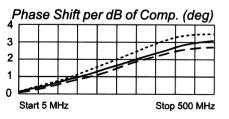


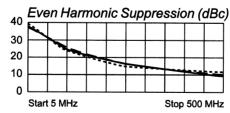
### **Typical Performance Data**

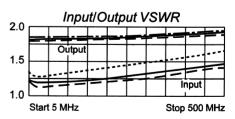












.egend ----- + 25 °C ------ -55 °C



# RF LIMITING AMPLIFIER MODEL TML9053

Package Style: 4 Pin TO-8

Also Available in: Surface Mount Package

and Connectorized Housings

### **Features**

- Frequency: 5 to 500 MHz; Input Power Range: 13 dB
- Low Phase Shift per dB of Compression
- Operating Case Temp. -55 C to + 85 C
- Environmental Screening available

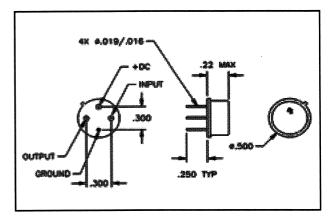
### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Small Signal Gain (dB)	9.5	7.0 Min.
Saturated Output Power (dBm)	- 2	- 4 Min.
Saturated Flatness(dB)	±0.3	±1.0 Max.
VSWR Input/Output	1.6/1.7	2.0:1 Max.
Even Harmonic Suppression @ P <sub>IN</sub> = +7 dBm	12	10 Min.
Noise figure (dB)	<8.0	10.5 Max.
Power +Vdc mA	+15 20	+15 21 Max.

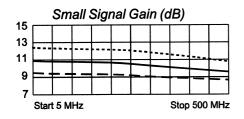
Note: Care should always be taken to effectively ground the case of each unit.

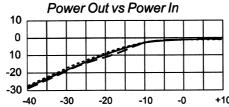
### **Maximum Ratings**

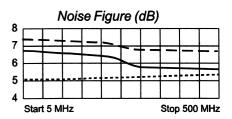
Ambient Operating Temperat	ure55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+17 Volts
Continuous RF Input Power.	+ 15 dBm

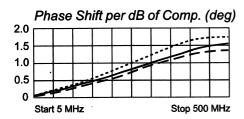


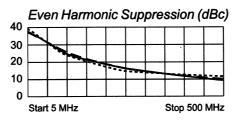
### **Typical Performance Data**

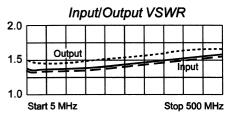














# RF LIMITING AMPLIFIER MODEL *ENL*9653

Package Style: 10 Pin 0.800" x 0.400"

**Surface Mount Package** 

### **Features**

Compression Range: 40 dB Typical

Low Phase Shift Variation

Operating Temperature: -55 °C to +85 °C

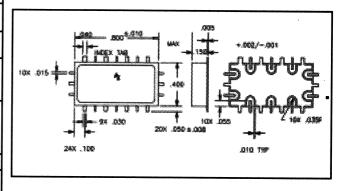
■ Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Small Signal Gain (dB)	>38	30 Min.
SaturatedPower @P <sub>IN</sub> = 0 dBm (dBm)	- 0.5	- 4.0 Min.
Saturated Flatness @ P <sub>IN</sub> = 0 dB	±0.8	±1.5 Max.
VSWR In Out	< 1.25:1 < 1.25:1	2.0:1 Max. 2.0:1 Max.
Phase Shift per dB of Comp. per MHz, (deg.)	0.0035	— Min.
Even Harmonic Suppression @ P <sub>IN</sub> = -33 to +10 dBm (dBc)	20	15 Max.
Noise figure (dB)	< 8	11 Max.
Power Vdc mA	+15 60	+15 Max. 70 Max.

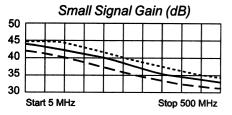
### **Maximum Ratings**

Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125.°C
DC Voltage	+17 Volts
Continuous RF Input Power	+15 dBm

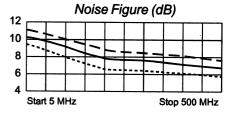


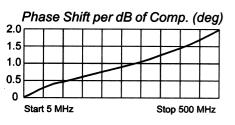
Note: Care should always be taken to effectively ground the case of each unit.

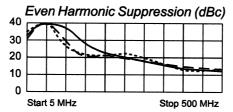
### **Typical Performance Data**

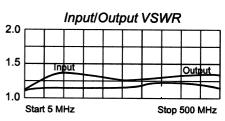












Legend ——— + 25 °C — — — +85 °C -----55 °C



## RF LIMITING AMPLIFIER MODEL *ENL*9654

Package Style: 10 Pin 0.800" x 0.400"

Surface Mount Package (See Outline Dwg.)

### **Features**

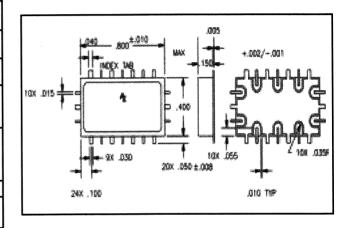
- Compression Range: 55 dB Typical
- Low Phase Shift Variation
- Operating Temperature: -55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	<b>TYPICAL</b> Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Small Signal Gain (dB)	>55	30 Min.
Saturated Power @P <sub>IN</sub> = 0 dBm (dBm)	- 0.5	- 4.0 Min.
Saturated Flatness @ P <sub>IN</sub> = 0 dBm	±0.9	±1.5 Max.
VSWR In Out	< 1.25:1 < 1.50:1	2.0:1 Max. 2.0:1 Max.
Phase Shift per dB of Comp. per MHz, (deg.)	0.004	— Min.
Even Harmonic Suppression @ P <sub>IN</sub> = -55 to +10 dBm (dBc)	> 14	12 Max.
Noise figure (dB)	< 10	12 Max.
Power Vdc mA	+15 75	+15 Max. 80 Max.

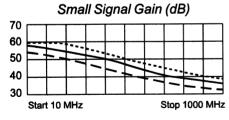
### **Maximum Ratings**

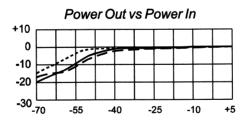
Ambient Operating Temperature	-55°C to + 100 °C
Storage Temperature	-62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuouse RF Input Power	+13 dBm

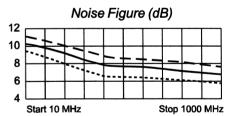


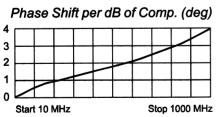
Note: Care should always be taken to effectively ground the case of each unit.

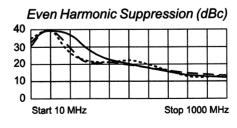
### **Typical Performance Data**

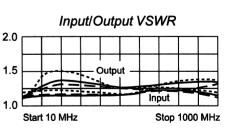












Legend ----- + 25 °C -- -- +85 °C ----- -55 °C



## **Threshold Detectors**

A Threshold Detector provides thermally compensated accurate RF level measurement at critical points in the system. The threshold level can be controlled with an external resistor or an external voltage. Included on this page is a list of Drop-in Replacements to other manufacturer's parts.

Model	Frequency Range (MHz)	Input Flatness (dBm) Typ.	Input Operation (dB) Typ. Max.	VSWR In/Out	Power Typ.
				Max.	(DC) (mA)
TMJ9904	10 2000	±1.0	-20 to +10	2.2:1	+15 5
TMJ9902	10 2000	±0.7	-10 to +10	2.0:1	+15 12
PLJ9962	100 2000	±1.0	-10 to +10	2.0:1	+15 12

## **Direct Crosses to Other Manufacturers' Threshold Detectors**

Avantek, Avnet	Amplifonix
UTD2002	TMJ9902
UTD2004	TMJ9904
PPD6002	PLJ9962

## **Level Detectors**

A Level Detector provides a video output proportional to the input power. Applications may include amplitude detection, automatic level control and signal monitoring. Included on this page is a list of Drop-in Replacements to other manufacturer's parts.

Model	Frequency Range	Detected Voltage (mV)	Input Flatness (dBm)	Tange Sensi	tivity	VSWR In/Out	Power Typ.
	(MHz)	Тур.		Тур.	Max.	Max.	(DC) (mA)
TMJ9910	10 2000	120	±1.0	-45	40	1.7:1	+15 5
TMJ9911	10 2000	120	±1.0	-45	40	1.7:1	+15 12
LNJ9901	20 2000	120	±0.3	-38	-	2.2:1	+15 12

## **Direct Crosses to Other Manufacturers' Level Detectors**

W-J, M/A-Com	Amplifonix	Avantek, Avnet	Amplifonix
L-1	TL9010	UTD2001	TMJ9901
L-2	TL9011	PPD2001	LNJ9901
		UTD1000	TMJ9910

# THRESHOLD DETECTOR TMJ9902

**PACKAGE: 5 Pin TO-8** 

### **Features**

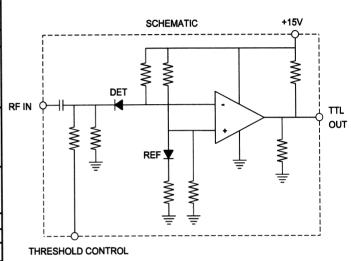
- External Threshold Control Voltage or Resistance
- -10dBm to + 10dBm Input Operating Range
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Input Flatness (dB) P =-20 to + 10dBm	±0.4	±1.0 Max.
Input VSWR (Max)	<1.75:1	2.0:1 Max.
Threshold Control Level (V/Ohms)  @ $P_{IN} = -20 \text{ dBm}$ @ $P_{IN} = 0 \text{ dBm}$ @ $P_{IN} = +10 \text{ dBm}$	0.1/325 0.3/950 1.0/3400	
Threshold Temp. Stability (dB)  @ P <sub>IN</sub> = -20 dBm  @ P <sub>IN</sub> = 0 dBm  @ P <sub>IN</sub> = +10 dBm		±1.5 Max. ±1.0 Max. ±0.5 Max.
Threshold Hystersis Voltage Control (dB) Resistance Control (dB) Output @ P <sub>IN</sub> = Threshold (V)	<0.1 <1.0 3.2	2.7 Min.
Output Short Circuit Current (mA)	8	3.0 Min.
Rise Time/Fall Time (ns)	125	
Power Vdc m A	+15 12	+15 15 Max.

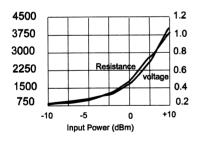
### **Maximum Ratings**

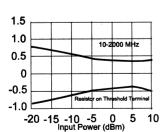
Operating Case Temperature	55 °C to + 125 °C
Storage Temperature	62 °C to + 150 °C
Continuous RF Input Power	
DC Voltage	+ 17 Volt

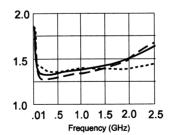


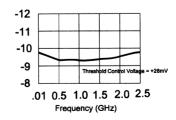
Note: Care should always be taken to effectively ground the case of each unit.

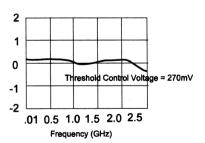
### **Typical Performance Data**

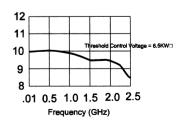














## **THRESHOLD DETECTOR**

**TMJ9904**10 - 2000 MHz

PACKAGE: 5 Pin TO-8

### **Features**

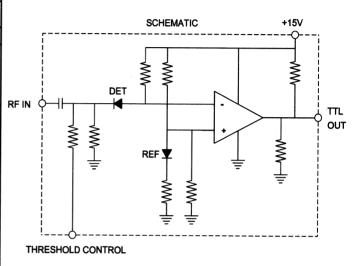
- External Threshold Control Voltage or Resistance
- -20dBm to + 10dBm Input Operating Range
- Operating Temp. 55 °C to +85 °C
- Environmental Screening Available

### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX		
	Ta= 25 °C	Ta = -55 ℃	to +85 °C	
Input Flatness (dB) P =-20 to + 10dBm	±1.0	±1.5		
Input VSWR (Max)	<1.75:1	2.0:1	Max.	
Threshold Control Level (V/Ohms)				
@ P <sub>IN</sub> = -20 dBm	.026/200			
@ P <sub>IN</sub> = 0 dBm	.265/2.0K			
@ P <sub>IN</sub> = +10 dBm	.870/6.5K			
Threshold Temp. Stability (dB)		<u> </u>		
@ P <sub>IN</sub> = -20 dBm		±1.5	Max.	
@ P <sub>IN</sub> = 0 dBm		±1.0	Max.	
@ P <sub>IN</sub> = +10 dBm		±0.5	Max.	
Threshold Hystersis				
Voltage Control (dB)	<0.1			
Resistance Control (dB)	<1.0			
Output @ P <sub>IN</sub> = Threshold (V)	3.2	2.7	Min.	
Output Short Circuit Current (mA)	8	3.0	Min.	
Rise Time/Fall Time (ns)	125			
Power Vdc	+15	+15		
m A	3	5	Max.	

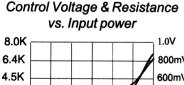
### **Maximum Ratings**

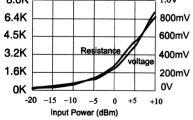
Operating Case Temperature	55 °C to + 125 °C
Storage Temperature	62 °C to + 150 °C
Continuous RF Input Power	+ 15dBm
DC Voltage	+ 17 Volts

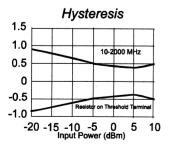


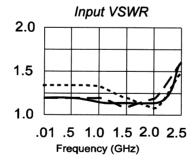
Note: Care should always be taken to effectively ground the case of each unit.

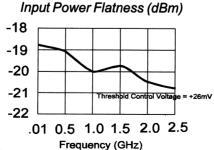
### **Typical Performance Data**



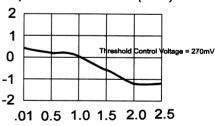




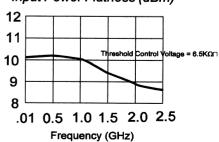








Frequency (GHz) Input Power Flatness (dBm)



## ANALOG LEVEL PACKAGE: 4 Pin 0.45" Sq. Surface **DETECTOR** TNJ9910

**Mount Package (SM3)** 

### **Features**

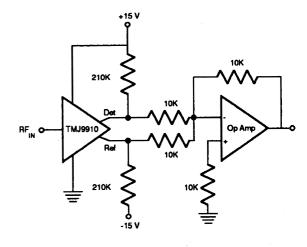
- -120 mV Output for -10 dBm Input Power
- **■** ±1.0 dB Flatness
- Operating Temp. -54 °C to +85 °C
- Environmental Screening available

### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = 0 °C to + 50 °C		
Detected Voltage (mV) f = 500 MHz *#	-120	-90 Min.		
Flatness (referred to input) (dB) f = 10 - 1000 MHz *#	±0.7	±1.0 <b>Ma</b> x.		
Variation over Temperature (dB) (referred to input), f = 500 MHz *#	±1			
Tangential Sensitivity (TSS)(dBm) 1 = 500 MHz, BW <sub>VID</sub> = 1 MHz <sup>a</sup>	-45	-40 Max.		
Input VSWR, 50 Ω f = 10 - 500 MHz	1.5:1	1.5:1 Max.		
Output Offset Voltage (mV)  I <sub>D</sub> = I <sub>REF</sub> = 50 µA, no RF Drive	±10	±15.0 Max.		
Differential Voltage Tracking (mV)	±5			
Output Capacitance (pf)	1000	1300 Max.		
Power Vdc mA	+15 16	+15 20 Max.		

### **Maximum Ratings**

Operating CaseTemperature	55 °C to + 125 °C
Storage Temperature	62 °C to + 150 °C
Bias Current (Diode)	
Continuous RF Input Power	
Short Term RF Input Power	100 mW
	(1 Minute Max.)

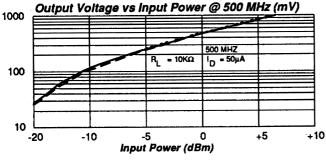


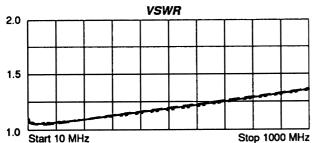
**Bias Circuit** 

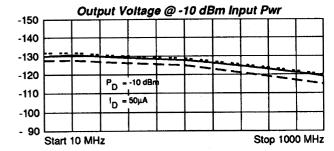
Note: Care should always be taken to effectively ground the case of each unit. \*  $I_D=50\,\mu\text{A},~R=10\text{K}\Omega$ 

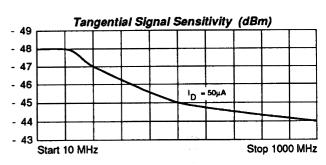
### #PIN = -10 dBm (RF Input)

### **Typical Performance Data**









### ANALOG LEVEL PACKAGE: 5 Pin TO-8 **DETECTOR** TMJ9911

### **Features**

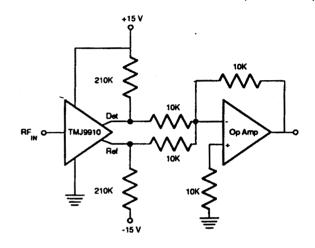
- -120 mV Output for -10 dBm Input Power.
- ±1.0 dB Flatness
- Operating Temp. -54 °C to +85 °C
- **Environmental Screening available**

### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = 0 °C to + 50 °C		
Detected Voltage (mV) f = 500 MHz *#	-120	-90	Min.	
Flatness (referred to input) (dB) f = 10 - 1000 MHz *#	±0.7	±1.5	Max.	
Variation over Temperature (dB) (referred to input), f = 500 MHz *\$	±1			
Tangential Sensitivity (TSS)(dBm) f = 500 MHz, BW <sub>VID</sub> = 1 MHz*	- 32	- 30	Max.	
Input VSWR, 50 $\Omega$ f = 10 - 500 MHz	1.5:1	1.5:1	Max.	
Output Offset Voltage (mV) I <sub>D</sub> = I <sub>REF</sub> = 50 µA, no RF Drive	±10	±15.0	Max.	
Differential Voltage Tracking (mV)	±5			
Output Capacitance (pf)	1000	1300	Max.	
Power Vdc mA	+15 16	+15 20	Max.	

### **Maximum Ratings**

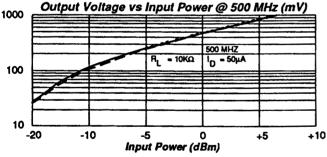
Operating CaseTemperature	55 °C to + 125 °C
Storage Temperature	
Bias Current (Diode)	1 mA
Continuous RF Input Power	+ 17 dBm
Short Term RF Input Power	
·	(1 Minute Max.)

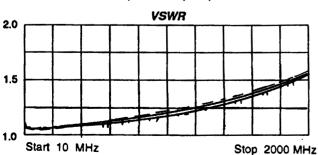


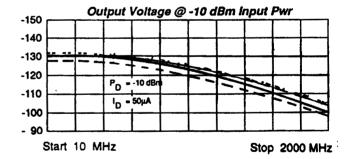
**Bias Circuit** 

#### = -10 dBm (RF Input)

### Typical Performance Data







Legend ---- + 25°C -- + 50°C

Note: Care should always be taken to effectively ground the case of each unit. • 10  $\,$  = 50  $\mu A,~R~$  = 10  $K\Omega$ 

## **Digital Attenuators**

Amplifonix Digital Attenuators range from KHz to 2000 MHz.

These designs have sensitivity of as little as 0.1 dB and continue to a full 63.5 dB.

Model	Freque Rang (MHz	je 🏻	Steps	Attenuation Range (dB)		on Loss IB) (Max.)	Switching Speed (µs)		Package Type	Powe Typ. (DC)	
TAN6007	KHz	50	4	2.0 to 30	1.5	2.0	0.03	TTL	SG-4	(+5/-5 V)	3/3
TAD5006	10 1	150	4	2.0 to 30	2.5	3.3	10	TTL	DP-5	(+5 V)	22
TAD5007	10 1	150	4	3.0 to 45	2.5	3.3	10	TTL	DP-5	(+5 V)	25
TAN6008	50 5	500	4	2.0 to 30	2.0	. 3.3	0.03	TTL	SG-4	(+5/-5 V)	3/3
TAD6006	50 5	500	4	2.0 to 30	2.2	3.0	0.02	TTL	DP-11	(+5/-5 V)	3/3
TAD6005	50 3	300	5	1.0 to 31	3.0	4.0	0.03	TTL	DP-5	(+5/-12 V)	3/4
TAD2104	20 20	000	5	1.0 to 31	6.5	8.5	0.02	TTL	DP-5	(+5/-12 V)	5/8
TAD5008	50 2	250	5	2.0 to 62	4.2	5.5	2.5	TTL	DP-5	(+5 V)	10
TAD5009	50 2	250	7	0.1 to 12.7	3.0	4.2	2.5	TTL	DP-8	(+5 V)	10
TAD5010	50 2	250	7	0.5 to 63.5	6.0	7.5	10	TTL	DP-8	(+5 V)	25

## Voltage Variable (Analog) Attenuators

Amplifonix Analog Attenuators range from 100 KHz to 2000 MHz.

Units can be adjusted up to a max attention of 40 dB.

Model	Frequency Range (MHz)	Insertion Loss (Typ.) (Max.)	Attenuation (dB) (Typ.) (Min.)	VSWR	Control Voltage	Control Current	Power Typ. (DC) (mA
TG9015	5 1000	2.0 2.5	20 15	2.0:1	0 to -10	0 to 7.0	15 7.0
TG9005	0.1 1400	2.0 2.5	26 25	2.0:1	0 to +15	0 to 7.5	15 10
TG9001	5 2000	2.9 2.5	34 18	2.0:1	0 to +15	0 to 6.5	15 10
TG9006	5 1600	2.0 2.5	34 18	2.0:1	0 to +12	0 to 6.5	12 10
TG9025	5 2000	2.0 3.0	33 20	2.0:1	0 to +15	0 to 7.0	15 10
TG9030	100 2000	2.5 3.5	40 25	2.2:1	0 to +15	0 to 10	15 10

### **Direct Crosses to Other Manufacturer's Parts**

W-J, M/A-Com	<b>Amplifonix</b>	Avantek, Avnet	Amplifonix	Cougar	Amplifonix
G-1	TG9001	UTF015	TG9015	GC2001	TG9001
G-2	TG9022	UTF025	TG9001	GC9030	TG9030
G-3	TG9030	UTF015	TG9015		

<sup>\*</sup> Please visit our website for the most current list of Drop-in Replacement Parts \*

**TAD2104** 

## Available in: DP-5, 24 Pin DIP Package and Connectorized Housings

### **Features**

■ 10 - 2000 MHz; 31 dB Attenuation Range

■ Fast Switching Speed: 15 ns Typical (GaAs)

■ Integral TTL Driver

■ OperatingTemp. -55 °C to + 85 °C

■ Environmental Screening available

### **Specifications**

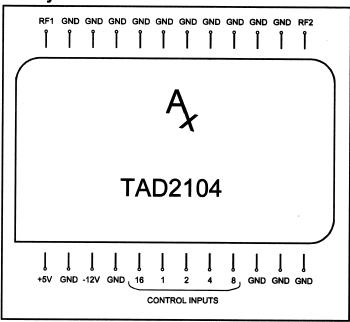
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C					
Frequency	10 - 2000 MHz	10 - 2000 MHz					
Insertion Loss (dB)	<6.5	8.5 Max.					
Attenuation Range (dB)	1 - 31	1 - 31 Min.					
Steps (dB)	1,2,4,8,16	1,2,4,8,16					
Accuracy	±0.5 dB ±2%	±0.5 dB Max. ±4%					
VSWR	1.5:1	1.75:1 Max.					
Switching Speed (nsec)	<20	30 Max.					
Transients (mV)	<25	35 Max.					
DC VDC Bias mA	- 12 4.5	- 12 8.0 Max.					
DC VDC Bias mA	+5 3.0	+5 5.0 Max.					

Note: Care should always be taken to effectively ground the case of each unit.

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	

### **Pin Layout**

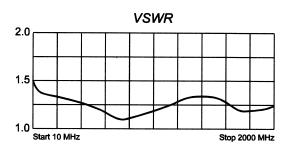


### **Truth Table**

Control Input	Attenuator Setting
5 Line TTL	
1	Attenuate
0	Thru

### Typical Performance Data







## **TAD5006**

### Available in:

DP-5, 24 Pin DIP Package and Connectorized Housings

### ■ 10 - 150 MHz

- 30dB Attenuation Range
- Integral TTL Driver
- Operating Temp.-55°C to + 85°C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

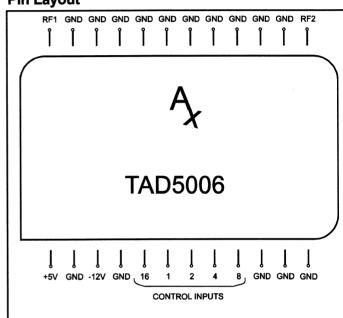
CHARACTERIST	LIC	<b>TYPICAL Ta = 25 °C</b>	MIN/MAX Ta = -55 °C to +85 °C			
Frequency		10 - 150 MHz	10 - 150 MHz			
Insertion Loss	(dB)	2.5	3.3 Max.			
Attenuation Rang	ge (dB)	2 - 30	2 - 30			
Steps	(dB)	2,4,8,16	2,4,8,16			
Accuracy		±0.2 dB ±0.5%	±0.3 dB Max. ±1%			
VSWR		1.4:1	1.65:1 Max.			
Switching Speed	(µsec)	3	10 Max.			
Switching Translents	(V)	0.5	1.0 Max.			
DC Bias	VDC mA	+5 22	+5 30 Max.			

Note: Care should always be taken to effectively ground case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	
Storage Temperature	65°C to + 125 °C
Case Temperature	
DC Voltage	+6 Volts
Continuous RF Input Power	

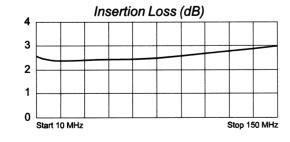
### **Pin Layout**

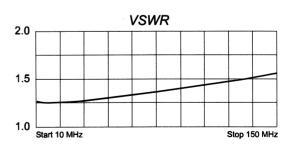


#### Truth Table

math rabio	
Control Input	Attenuator Setting
4 Line TTL	
1	Attenuate
0	Thru
1	

### Typical Performance Data







## **TAD5007**

### Available in:

DP-5, 24 Pin DIP Package and Connectorized Housings

### ■ 10 - 150 MHz

- 45 dB Attenuation Range
- Integral TTL Driver
- ■Operating Temp. -55°C to +85°C
- ■Screening to the tables of MIL-STD-883 available

### **Specifications**

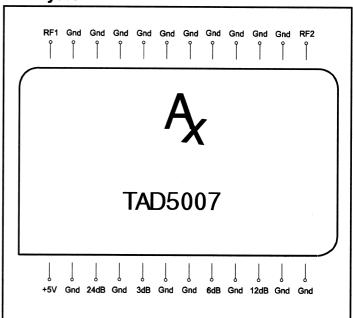
Specifications				
CHARACTERISTIC		<b>TYPICAL Ta = 25 °C</b>	MIN/MAX Ta = -55 °C to +85 °C	
Frequency		10 - 150 MHz	10 - 150 MHz	
Insertion Loss	(dB)	2.5	3.3 Max.	
Attenuation Ran	ge (dB)	3 - 45	3 - 45	
Steps	(dB)	3,6,12,24	3,6,12,24	
Accuracy		±0.2 dB ±0.5%	±0.3 dB Max. ±1%	
VSWR		1.4:1	1.65:1 Max.	
Switching Speed	(µsec)	10	15 Max.	
Transients	(V)	0.5	1.0 Max.	
DC Bias	VDC mA	+5 25	+5 30 Max.	

Note: Care should always be taken to effectively groung the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	65°C to + 125 °C
Case Temperature	
DC Voltage	+ 6 Volts
Continuous RF Input Power	

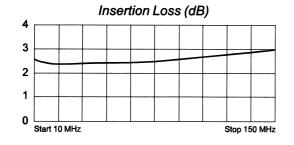
### **Pin Layout**

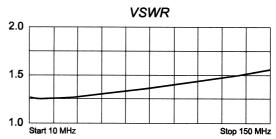


### **Truth Table**

Control Input 4 Line TTL	Attenuator Setting
1	Attenuate
0	Thru

### Typical Performance Data







## **TAD5008**

## Available in: DP-5, 24 Pin DIP Package and Connectorized Housings

### ■50 - 250 MHz

- 62 dB Attenuation Range
- ■Integral TTL Driver
- ■Operating Temp. -55°C to +85°C
- ■Screening to the tables of MIL-STD-883 available

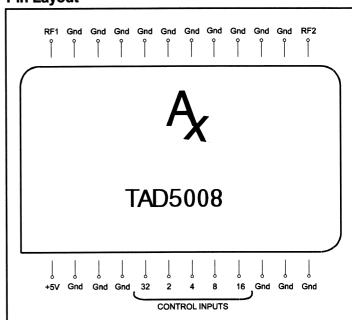
### **Specifications**

Specifications		
CHARACTERISTIC	<b>TYPICAL Ta = 25 °C</b>	MIN/MAX Ta = -55 °C to +85 °C
Frequency	50 - 250 MHz	50 - 250 MHz
Insertion Loss (dB)	4.5	5.5 Max.
Attenuation Range (dB)	2 - 62	2 - 62
Steps (dB)	2,4,8,16,32	2,4,8,16,32
Accuracy	±0.2 dB ±1.5%	±0.25 dB <sub>Max</sub> . ±2.5%
VSWR	1.5:1	1.7:1 Max.
Switching Speed (µsec)	2.5	3 Max.
Switching Transients (V)	0.8	1.0 Max.
DC VDC Bias mA	+5 10	+5 15 Max.

### **Maximum Ratings**

Ambient Operating Temperature	55℃ to + 100 ℃
Storage Temperature	-65°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 6.0 Volts
Continuous RF Input Power	

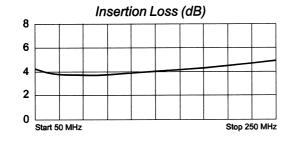
### **Pin Layout**

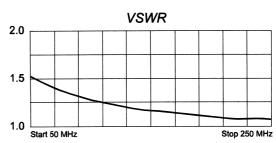


### **Truth Table**

Control Input	Attenuator Setting
5 Line TTL	
1	Attenuate
0	Thru

### Typical Performance Data







Package: 38 Pin DIP (DP-8)

Also Available In: Connectorized Housings

### **Features**

- 50 250 MHz
- 12.7 dB Attenuation Range
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

### **Specifications**

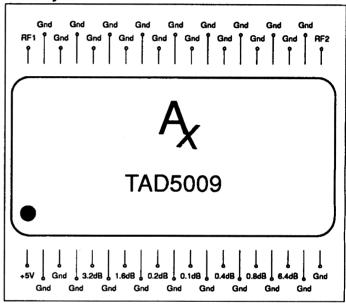
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	50 - 250 MHz	50 - 250 MHz
Insertion Loss (dB)	3	4.2 Max.
Attenuation Range (dB)	0.1 - 12.7	0.1 - 12.7
Steps (dB)	0.1,0.2,0.4,0.8, 1.6,3.2,6.4	0.1,0.2,0.4,0.8, 1.6,3.2,6.4
0.1 to 0.8 dB Accuracy 0.9 to 6.3 dB 6.4 to 12.7 dB		± (0.05 dB +2%) Max. ± (0.20 dB +2%) Max. ± (0.30 dB +3%) Max.
VSWR	1.25:1	1.5:1 Max.
Switching Speed (µsec)	2.5	5 Max.
Switching Transients (V)	0.8	1.0 Max.
DC Vdc Bias mA	+5 10	+5 15 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	55	°C to + 100 °C	;
Storage Temperature	65	°C to + 125 °C	>
Case Temperature		+ 125 °C	;
DC Voltage		+6 Volts	
Continuous RF Input Power		+20 dBm	1

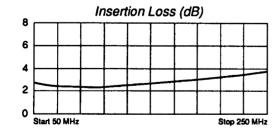
### Pin Layout

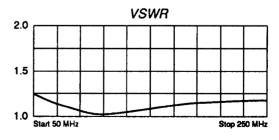


### **Truth Table**

Control Input 7 Line TTL	Attenuator Setting
1	Attenuate
0	Thru

### **Typical Performance Data**







**Outline Drawings: Pages 14-19** 

Available in: DP-8, 38 Pin Dip Package

and Connectorized Housings

### **Features**

- 50 250 MHz
- 63.5 dB Attenuation Range
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

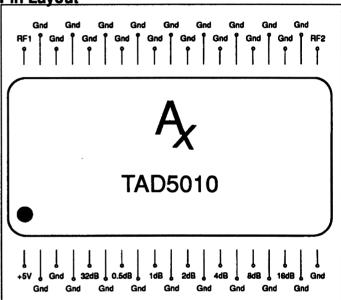
opeomoations		
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	50 - 250 MHz	50 - 250 MHz
Insertion Loss (dB)	5.0	7.5 Max.
Attenuation Range (dB)	0.5 - 63.5	0.5 - 63.5
Steps (dB)	0.5,1,2,4,8,16,32	0.5,1,2,4,8,16,32
Accuracy	±0.2 dB ±1.5%	±0.25 dB <sub>Max</sub> . ±2.5%
VSWR	1.25:1	1.5:1 Max.
Switching Speed (µsec)	6	10 Max.
Switching Transients (V)	0.8	1.0 Max.
DC Vdc Blas mA	+5 25	+5 30 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	- 55 °	°C to + 100 °C
Storage Temperature	- 65 °	°C to + 125 °C
Case Temperature		+ 125 °C
DC Voltage		+6 Valts
Continuous RF Input Power		+30 dBm

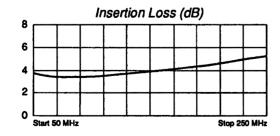
### Pin Layout

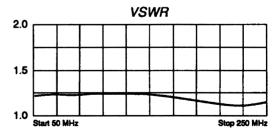


### **Truth Table**

Control Input 7 Line TTL	Attenuator Setting
1	Attenuate
0	Thru

### **Typical Performance Data**







### **TAD6005**

### Available in:

DP-5, 24 Pin DIP Package and Connectorized Housings

### ■ 50 - 300 MHz

■ Fast Switching Speed: 20 ns Typical (GaAs)

■ Integral TTL Driver

■Operating Temp. -55°C to +85°C

■Screening to the tables of MIL-STD-883 available

### **Specifications**

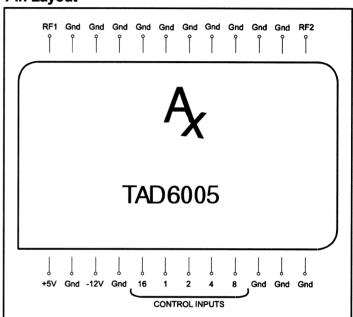
opecinications		
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	40 - 350 MHz	50 - 300 MHz
Insertion Loss (dB)	3.0	4.0 Max.
Attenuation Range (dB)	1 - 31	1 -31
Steps (dB)	1,2,4,8,16	1,2,4,8,16
Accuracy	±0.15 dB ±1%	±0.25 dB <sub>Max.</sub>
VSWR	1.2:1	1.4:1 Max.
Switching Speed (nsec)	20	30 Max.
Transients (mV)	300	350 Max.
DC VDC Bias mA	+5 3	+6 5 Max.
DC VDC Bias mA	- 12 4	- 12 8 Max.

Note: Care should always be taken to effectively ground case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	65°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	
Continuous RF Input Power	+30 dBm

### Pin Layout

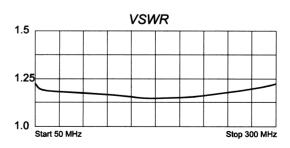


### **Truth Table**

Control Input	Attenuator Setting
5 Line TTL	
1	Attenuate
0	Thru

### Typical Performance Data







## **TAD6006**

### Available in:

DP-11, 14 Pin DIP Package and Connectorized Housings

### ■ 50 - 500 MHz

- Fast Switching Speed: 20 ns Typical (GaAs)
- Integral TTL Driver
- ■Operating Tem.-55°C to +85 °C
- ■Screening to the tables of of MIL-STD-883 available

### **Specifications**

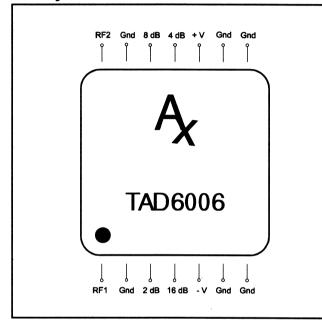
Opcomodions		
CHARACTERISTIC	<b>TYPICAL Ta = 25 °C</b>	MIN/MAX Ta = -55 °C to +85 °C
Frequency	50 - 500 MHz	50 - 500 MHz
Insertion Loss (dB)	2.2	3.0 Max.
Attenuation Range (dB)	2 - 30	2 -30
Steps (dB)	2,4,8,16	2,4,8,16
Accuracy	±0.15 dB ±1%	±0.25 dB <sub>Max</sub> . ±2%
VSWR	1.15:1	1.5:1 Max.
Switching Speed (nsec)	20	30 Max.
Transients (mV)	300	350 Max.
DC VDC Bias mA	+5 3	+5 5 Max.
DC VDC Bias mA	- 5 3	- 5 5 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	65°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	
Continuous RF Input Power	

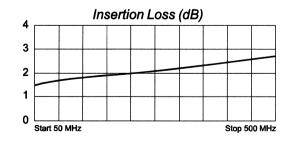
### **Pin Layout**

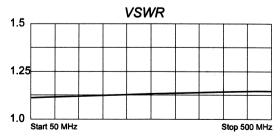


### **Truth Table**

Control Input 4 Line TTL	Attenuator Setting
1	Attenuate
0	Thru

### Typical Performance Data







### **TAN6007**

### Available in:

SG4, 10 Lead Gull Wing Package and Connectorized Housings

### **Features**

- DC 50 MHz
- Fast Switching Speed: 20 ns Typical (GaAs)
- Integral TTL Driver
- Operating Temp. -55 °C to +85 °C
- Screening to the tables of MIL-STD-883 available

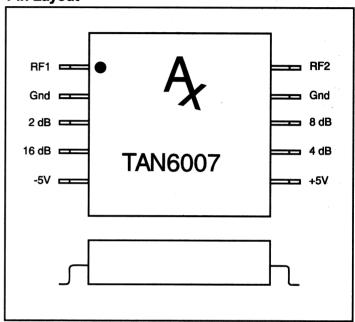
### **Specifications**

- Opcomodione		
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	DC - 50 MHz	DC - 50 MHz
Insertion Loss (dE	) 1.5	2.0 Max.
Attenuation Range (dB	2 - 30	2 -30
Steps (dB	2,4,8,16	2,4,8,16
Accuracy	±0.15 dB ±1%	±0.25 dB <sub>Max.</sub> ±2%
VSWR	1.3:1	1.4:1 Max.
Switching Speed (nsec	20	30 Max.
Transients (mV	300	350 Max.
DC VDC	1	+5
Bias mA	3	5 Max.
DC VDC Bias mA	1 -	- 5 5 Max.

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	65°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 6.0, -6 Volts
Continuous RF Input Power	+30 dBm

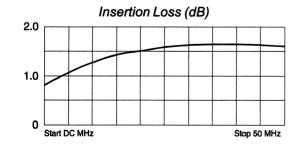
### **Pin Layout**

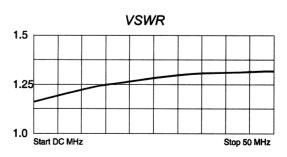


### **Truth Table**

Control Input	Attenuator Setting
4 Line TTL	·
1	Attenuate
0	Thru

### **Typical Performance Data**







## **TAN6008**

### Available in:

DP-5, 24 Pin DIP Package and Connectorized Housings

### ■50 - 500 MHz

■Fast Switching Speed: 20 ns Typical (GaAs)

■Integral TTL Driver

■ Operating Temp.-55°C to +85°C

■ Screening to the tables of MIL-STD-883 available

### **Specifications**

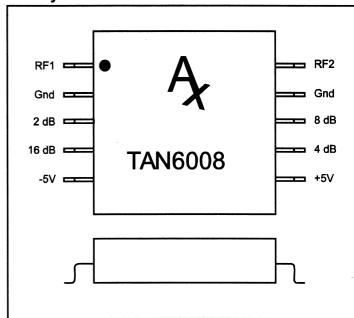
Opcomodione		
CHARACTERISTIC	<b>TYPICAL Ta = 25 °C</b>	MIN/MAX Ta = -55 °C to +85 °C
Frequency	50 - 500 MHz	50 - 500 MHz
Insertion Loss (dB)	2.0	3.3 Max.
Attenuation Range (dB)	2 - 30	2 -30
Steps (dB)	2,4,8,16	2,4,8,16
Accuracy	±0.15 dB ±1%	±0.25 dB <sub>Max</sub> . ±2%
VSWR	1.3:1	1.5:1 Max.
Switching Speed (nsec)	20	30 Max.
Transients (mV)	300	350 Max.
DC VDC Bias mA	+5 3	+5 5 Max.
DC VDC Bias mA	- 5 3	- 5 5 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	65°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+6.0, -6Volts
Continuous RF Input Power	+30 dBm

### **Pin Layout**

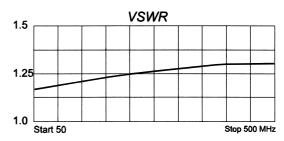


### **Truth Table**

Control Input	Attenuator Setting
4 Line TTL	
1	Attenuate
0	Thru
	j .

### Typical Performance Data







Available in: 5 Pin TO-8, Flatpack, Surface Mount Flatpack, and Connectorized Housings

### **Features**

- 5 MHz to 2000 MHz
- Low Insertion Loss
- Operating Temp. 55 °C to + 85 °C
- Environmental Screening Available

### **Specifications**

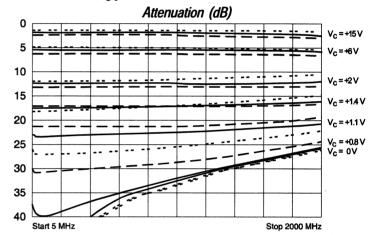
CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency (MHz)	5 - 2000 MHz	5 - 2000 MHz
Insertion Loss (Vc = 15)		
5-500 MHz	2.0	2.3 Max.
5-1000 MHz (dB)	2.2	2.5 Max.
5-2000 MHz	2.5	3.5 Max.
Max Attenuation		
5-500 MHz	33	31 Min.
5-1000 MHz (dB)	27	25 Min.
5-2000 MHz	23	18 Min.
VSWR (Worst Case)		
5-500 MHz	1.75.1	2.0:1 Max.
5-1000 MHz (dB)	1.75.1	2.0:1 Max.
5-2000 MHz	2.2:1	2.2:1 Max.
Flatness over Freq.		
5-500 MHz	±0.15	±0.25 Max.
5-1000 MHz (dB)	±0.5	±1.0 Max.
5-2000 MHz	±0.7	±1.5 Max.
Bias Power Vdc	+15	+15
mA	5.5	10 Max.
Control Power Vdc	0 to +15	0 to +15
mA	5.5	0 to 7 Max.
Switching Speed (µsec) 10% to 90%	40	60 Max.

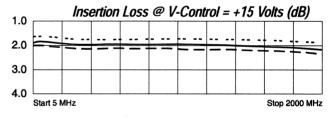
Note: Care should always be taken to effectively ground the case of each unit.

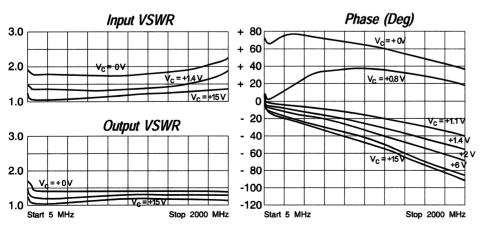
### **Maximum Ratings**

Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 ℃
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	1 Watt
	(3 μsec Max.)

### **Typical Performance Data**









Legend ——— + 25 °C ---- -55 °C

PACKAGE: 5 Pin TO-8

### **Features**

- 0.1 MHz to 1400 MHz Typical
- 31 dB Attenuation Range
- Operating Temp. 55 °C to + 85 °C
- Screening to the tables of MIL-STD-883 available

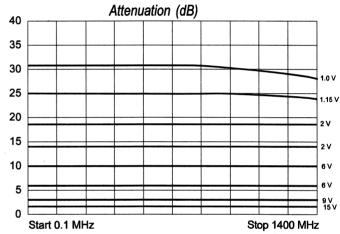
### **Specifications**

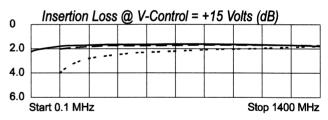
Specificatio			T
CHARACTERIS	TIC	TYPICAL	MIN/MAX
		Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency (MHz	:)	0.1 - 1400 MHz	0.1 - 1400 MHz
Insertion Loss			
(Vc = 15)		2.0 dB	2.5 dB Max.
Max Attenuation	1		
5-500 MHz		31 dB	30 dB Min.
5-1400 MHz		26 dB	25 dB Min.
VSWR (Worst C	ase)		
5-500 MHz		<1.5:1	1.8:1 Max.
500-1400 MHz		<1.6:1	2.0:1 Max.
Flatness over F	req.		
0.1-1400 MHz (	dB)	±0.2	±0.5 Max.
Bias Power	Vdc	+15	+18
	mA	10	12 Max.
Control Power	Vdc	0 to +15	0 to +15
	mA	0 to 6	0 to 7.5

### **Maximum Ratings**

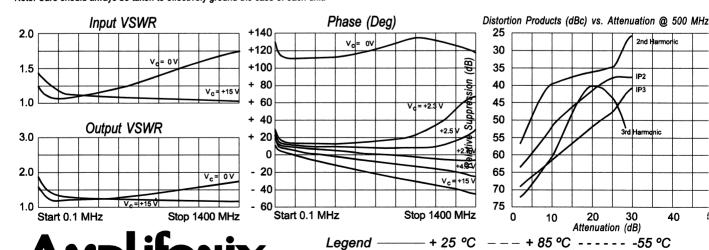
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	1 Watt
	(3 µsec Max.)

### **Typical Performance Data**





Note: Care should always be taken to effectively ground the case of each unit.



**Available in:** 5 Pin TO-8, Flatpack, Surface Mount Flatpack, and Connectorized Housings

### **Features**

- 5 MHz to 1600 MHz
- Low Insertion Loss
- Operating Temp. 55 °C to + 85 °C
- Environmental Screening Available

### **Specifications**

	·	·
CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta= 25 °C	Ta = -55 °C to +85 °C
Frequency (MHz)	5 - 1600 MHz	5 - 1600 MHz
Insertion Loss (Vc = 15)		
5-500 MHz	2.0	2.3 Max.
5-1000 MHz (dB)	2.2	2.5 Max.
5-2000 MHz	2.5	3.5 Max.
Max Attenuation		
5-500 MHz	33	31 Min.
5-1000 MHz (dB)	27	25 Min.
5-2000 MHz	23	18 Min.
VSWR (Worst Case)		
5-500 MHz	1.75.1	2.0:1 Max.
5-1000 MHz (dB)	1.75.1	2.0:1 Max.
5-2000 MHz	2.2:1	2.5:1 Max.
Flatness over Freq.		
5-500 MHz	±0.15	±0.25 Max.
5-1000 MHz (dB)	±0.5	±1.0 Max.
5-2000 MHz	±0.7	±1.5 Max.
Bias Power Vdc	+12	+12
mA	5.5	10 Max.
Control Power Vdc	0 to +12	0 to +12
mA	6.5	0 to 7 Max.
Switching Speed (µsec)	40	60 Max.

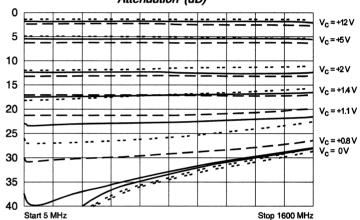
Note: Care should always be taken to effectively ground the case of each unit.

### **Maximum Ratings**

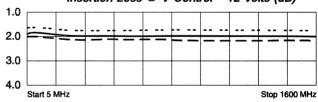
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	1 Watt
	(3 μsec Max.)

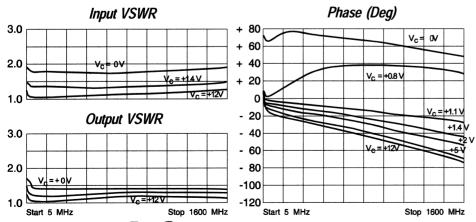
### **Typical Performance Data**

Attenuation (dB)



### Insertion Loss @ V-Control = 12 Volts (dB)





**Amplifonix** 

Legend ——— + 25 °C ---- + 85 °C ---- - -55 °C

Package: 5 Pin TO-8 (T5)
Also Available in: Flatpack, Surface

**Mount and Connectorized Housings** 

### **Features**

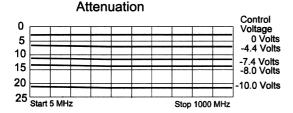
\* Negative Control Voltage: 0 to -10 Volts

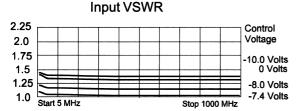
\* > 20 dB Attenuation Typical

- \* Operating Temp. 0 C to +50 C
- \* Environmental Screening available

### **Specifications**

CHARACTERISTIC	TYPICAL	MIN/MAX
	Ta = 25 °C	Ta = 0 °C to +50 °C
Frequency	5 - 1000 MHz	5 - 1000 MHz
Insertion Loss (Vc=0V) 5-500 MHz 500-1000 MHz (dB)	1.5 2.0	2.0 Max. 2.5 Max.
Max Attenuation (dB) (Vc = -10V)	20	15 Min.
VSWR (worst Case In Attenuation In Range) Out	-4 7E.4	2.0:1 Max. 2.0:1 Max.
Flatness over Freq.	±0.5 dB	±0.75 dB Max.
Switching (ms) Speed 10% to 90%	0.5	0.75 Max.
Bias Vdc Power mA	+ 15 7	+ 15 10 Max.
Control Power Vdc	0 to -10	0 to -10
mA	0 to 7	0 to 10 Max.

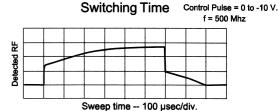




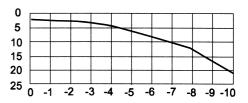
### **Maximum Ratings**

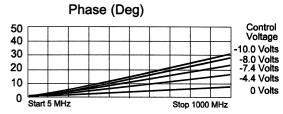
Ambient Operating Temperature	55°C to + 125 °C
Storage Temperature	62°C to + 150 °C
Case Temperature	+ 150 °C
DC Voltage	+ 18 Volts
Control Voltage	15 Volts
Continuous RF Input Power	+23 dBm

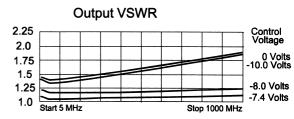
### Typical Performance Data @ 25° C



### Attenuation (dB) vs. Control Voltage







Legend ----- + 25 °C ---- 0 °C



PACKAGE: 5 Pin TO-8

### **Features**

- 100 MHz to 2000 MHz Typical
- 40 dB Attenuation Range to 1000 MHz
- Operating Temp. 55 °C to + 85 °C
- Screening to the tables of MIL-STD-883 available

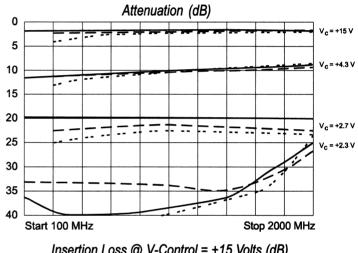
### **Specifications**

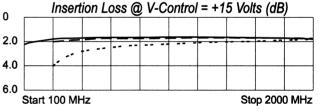
CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	100 - 2000 MHz	300 - 2000 MHz
Insertion Loss (Vc = 15) 100-500 MHz 500-1000 MHz (dB) 1000-2000 MHz	<2.2 <1.8 <2.0	4.0 Max. 3.0 Max. 2.5 Max.
Max Attenuation 100-500 MHz 500-1000 MHz (dB) 1000-2000 MHz	<45 <40 <30	40 Min. 35 Min. 20 Min.
<b>VSWR (Worst Case)</b> 100-300 MHz 300-2000 MHz	2.0:1 <2.5:1	3.0:1 Max.
Output 100-300 MHz 300-2000 MHz	<2.0:1 <1.75:1	2.0:1 Max.
Flatness over Freq. 5-500 MHz 5-1000 MHz (dB)	±0.5 ±1	±3.0 Max. ±2.0 Max.
Bias Power Vdc mA	+15 8	+15 10 Max.
Control Power Vdc mA	0 to +15 0 to 6.5	0 to +15 0 to 10 Max.
Switching Speed (nsec) 10% to 90%	<200	400 Max.

### **Maximum Ratings**

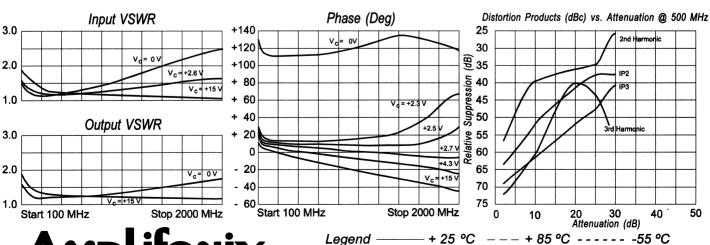
Ambient Operating Temperature	55°C to + 100 °C
Storage Temperature	62°C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 18 Volts
Continuous RF Input Power	+ 20 dBm
Short Term RF Input Power	200 Milliwatts
	(1 Minute Max.)
Maximum Peak Power	1 Watt
	(3 µsec Max.)

### **Typical Performance Data**





Note: Care should always be taken to effectively ground the case of each unit.



## **Linearizers**

When coupled with a TG9001 (or similar voltage variable attenuator), Linearizers change the attenuation versus control voltage curve to a linear function. Available in 5 pin TO-8 and 12 pin TO-8B as well as Flatpacks, Surface Mount Packages and Connectorized Housings.

Model	Frequency Range	Bias	Min. Attenuation @Vcon = -10 volts	Max. Attenuation @Vcon = -1 volt	Linearity Over Min/Max Attenuation Range
	(MHz)	+V -V	(Typ.)	(Typ.)	(Typ.) (Typ.)
TL9003	10 to 1000	+15 -15	3 dB	20 dB	<+ 1dB +2 dB
TL9007	10 to 1000	+12 -12	3 dB	20 dB	<+ 1dB +2 dB

### **Direct Crosses to Other Manufacturer's Parts**

W-J, M/A-Com	Amplifonix	
G-1	TG9001	
G-2	TG9022	

## **Linearized Attenuator**

Linearized Attenuators change the attenuation versus tuning voltage curve to a linear function. Available in 5 pin TO-8 and 12 pin TO-8B as well as Flatpacks, Surface Mount Packages and Connectorized Housings.

Model	Frequency Range	Bias	Min. Attenuation @Vcon = -10 volts	Max. Attenuation @Vcon = -1 volt	Linearity Over Min/Max Attenuation Range
	(MHz)	+V -V	(Typ.)	(Typ.)	(Тур.) (Тур.)
TGLR9025	5 to 2000	+15 -15	6 dB	40 dB	<+ 1dB +2 dB

## Please visit our website for the most recent additions to our line of Attenuators and Linearizers

www.amplifonix.com

## RF HYBRID LINEARIZERS TL9003

Available as: TNL9003, 4 Pin Surface Mount (SM3)

FPL9003, 4 Pin Flatpack (FP4)

BXL9003, Connectorized Housing (H1)

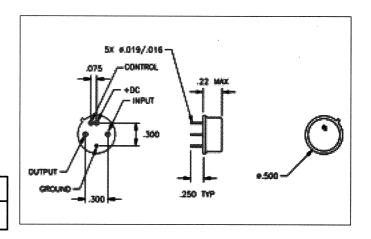
### **Features**

- 10-1000 MHz Linearizer for TG9001
- 2.5 dB Change Per Control Volt.
- Specifications Guaranteed
- 5 Pin TO-8 Metal Hermetic Package
- Operating Temp. -55 °C to + 100 °C

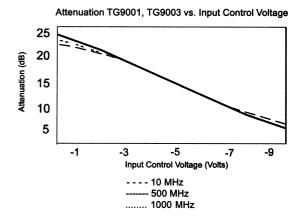
### **Specifications**

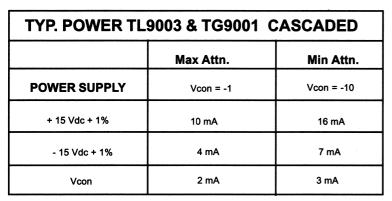
10 - 1000 MHz

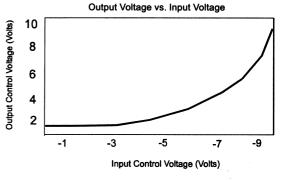
LINEARITY	TYP	MAX
3 - 20 dB	< + 1 dB	< + 2 dB



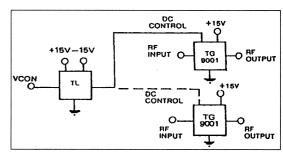
TYPICAL POWER TL9003			
	Max Attn.	Min Attn.	
POWER SUPPLY	Vcon = -1	Vcon = -10	
+ 15 Vdc + 1%	4 mA	6 mA	
- 15 Vdc + 1%	4 mA	7 mA	
Vcon	2 mA	3 mA	







 $\label{lem:note:case} \textbf{Note: Care should always be taken to effectively ground the case of each unit.}$ 





## RF HYBRID LINEARIZER TL9007

Available as: TNL9007, 4 Pin Surface Mount (SM3)

FPL9007, 4 Pin Flatpack (FP4)
BXL9007, Connectorized Housing (H1)

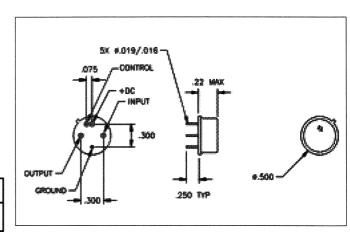
### **Features**

- 10-1000 MHz Linearizer for TG9001
- 2.5 dB Change Per Control Volt.
- Specifications Guaranteed
- 5 Pin TO-8 Metal Hermetic Package
- Operating Temp. -55 °C to + 100 °C

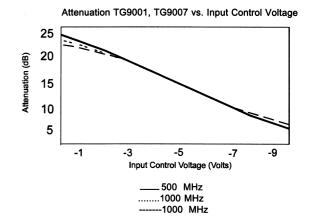
### **Specifications**

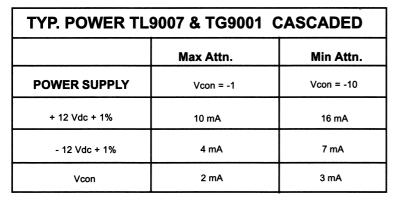
10 - 1000 MHz

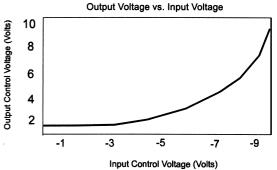
LINEARITY	TYP	MAX
3 - 20 dB	< + 1 dB	< + 2 dB



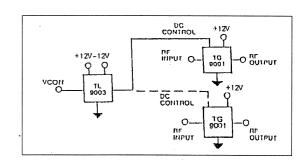
TYPICAL POWER TL9007			
	Max Attn.	Min Attn.	
POWER SUPPLY	Vcon = -1	Vcon = -10	
+ 12 Vdc + 1%	4 mA	6 mA	
- 12 Vdc + 1%	4 mA	7 mA	
Vcon	2 mA	3 mA	







Note: Care should always be taken to effectively ground the case of each unit.





# RF ATTENUATOR MODEL TGLWN9025

Package Style: SG4 Surface Mount - Gull Wing

Available as: 4 Pin TO-8B

### **Features**

■ Linearized; 5 - 1000 MHz

■ Attenuation Slope: 5 dB per Volt

■ Operating Temp. - 55 °C to +85 °C

■ Environmental Screening available

### **Specifications**

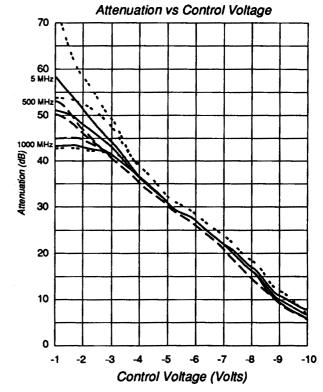
CHARACTERISTIC		TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C		
Frequency		5 - 1000 MHz	5 - 1000 N	1Hz	
Linearity					
6 - 51 dB 5 N 6 - 48 dB 500 N 6 - 42 dB 1000 N		< ± 2 dB < ± 2 dB < ± 2 dB	± 4 dB ± 4 dB ± 4 dB	Max. Max. Max.	
VSWR (Worst Case) 5-500 MHz 5-1000 MHz (di		< 1.5:1 < 1.75:1	2.0:1 2.0:1	Min. Min.	
	dc nA	+15 22	+15 30	Max.	
	dc nA	- 15 3	- 15 5	Max.	
	dc A	-1 to -10 1.25 to 2.5	-1 to -10 0.75 to 4	Max.	
Switching Speed (	μs)	50	120	Max.	

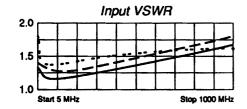
Note: Care should always be taken to effectively ground the case of each unit.

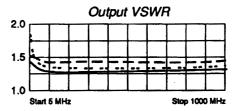
### **Maximum Ratings**

Ambient Operating Temperature 55 °C to	+ 100 °C
Storage Temperature 62 °C to	
Case Temperature	
DC Voltage	
Continuous RF Input Power	
Short Term RF Input Power 500	
(1 Min	
Maximum Peak Power	1 Watt
/3 ц	sec Max.)

### **Typical Performance Data**









Legend ----- + 25°C --- + 85°C --- - - 55°C

### **Switches - PIN Diode**

The units are available in many package configurations with up to eight (8) throws.

Control is obtained through TTL Logic.

Model	Туре	Frequency Range	Insertion Loss	Isolation	Switching Speed	Termination	Control	Package	Pov	ver
	(Throws)	(MHz)	(Typ.) (Max.)	(Typical)	(μs)				I	Current (mA)
TWM5000	SPST	10 to 1500	1.0 1.5	50	0.5	50 Ohms	TTL	T-5	(+5V)	5
TWD5001	SPDT	10 to 1000	1.0 2.0	45	4	50 Ohms	TTL	DP-3	(+15V)	15
TWD5015	SPDT	20 to 1000	1.2 2.0	45	0.7	50 Ohms	TTL	DP-3	(+5V)	15
TWD5002	SPDT	30 to 1000	0.9 1.8	70	1	50 Ohms	TTL	DP-11	(+5/-5V)	18/12
TWH7230	SPDT	10 to 3000	1.0 1.5?	70	2	Open	TTL	T-9	(+4.5 to 5.5	V) 2.4
TWH5016	SP3T	10 to 3000	1.0 1.5?	70	2	Open	TTL	T-9	(+4.5 to 5.5	V) 2.4
TWH7425	SP4T	10 to 3000	1.0 1.5	70	2	Open	TTL	T-9	(+4.5 to 5.5	V) 2.4
TWH5017	SP5T	10 to 3000	1.0 1.5	70	2	Open	TTL	T-9	(+4.5 to 5.5	V) 2.4
TWD5005	SP8T	30 to 500	1.2 1.8	55	1	50 Ohms	TTL	DP-5	(+5/-5V)	20/5

### **Cross Reference List**

Amplifonix also offers an extensive Drop-in Replacement list on dozens of older and many times obsolete Anzac, Adams Russell and M/A-Com switches.

ANZAC	<b>AMPLIFONIX</b>	ANZAC	<b>AMPLIFONIX</b>	ANZAC	AMPLIFONIX	ANZAC	AMPLIFONIX
SW203	TWK2203	SW217	TWD2217	SW241	TWD2241	SW255	TWD2255
SW204	TKP2204	SW218	TWD2218	SW242	TWD2242	SW257	TWD2257
SW205	TWD2205	SW219	TWP2219	SW244	TWD2244	SW258	TWD2258
SW206	TWD2206	SW224	TWK2224	SW245	TWD2245	SW261	TWP2261
SW209	TWP2209	SW231	TWP2231	SW247	TWP2247	SW262	TWP2262
SW213	TWK2213	SW232	TWP2232	SW248	TWP2248	SW264	TWP2264
SW214	TWP2214	SW233	TWP2233	SW251	TWP2251	SW265	TWP2265
SW215	TWD2215	SW234	TWP2234	SW252	TWP2252	SW278	TWN2278
SW216	TWD2216	SW238	TWP2238	SW254	TWD2254		

Please visit www.amplifonix.com for the latest developments in High Isolation Switch design.

### **Switches - GaAs**

These circuits operate from DC to 3 GHz and use GaAs MMIC switches to control the RF signal path. They are available with or without TTL or CMOS drivers. They should be used in place of PIN Diode switches when fast switching speed and low DC Power consumption is important.

Model	Туре	Frequer	ncy Range	Insertion Loss	Isolation	Switching Speed	VSWR	Termination	Driver	Package
		/N	MHz)	LUSS	typ.	(ns)	(typ.)			
TWM6001	SPST	10	1500	1.2	500	35	1.25:1	50	TTL	T-5
	SPST	10	1500	2.5	30	80	1.25:1	OPEN	TTL	T-8
TWN6002		10	2000	1.2	30	35	1.25:1	50	TTL	SM-2
	SPST	DC	3000	0.7	10	55	1.15:1	50	0/-5V	FP-12
	SPST	DC	3000	0.7	10	55	1.15:1	50	0/-5V	T-2
TWP2209	SPST	DC	3000	1	6	40	1.25:1	50	0/-5V	FP-7
TWN2278	SPST	DC	3000	0.9	10	55	1.1:1	50	0/-5V	SM-2
TWP2231	SPST	5	3000	1	30	55	1.2:1	50	TTL	FP-13
TWP2232	SPST	5	3000	1	60	55	1.2:1	50	CMOS	FP-13
TWD2215	SPST	5	3000	1	30	60	1.2:1	50	TTL	DP-3
TWD2216	SPST	5	3000	1	60	60	1.2:1	50	CMOS	DP-3
	SPDT	DC	2000	0.6	25	35	1.1:1	OPEN	TTL	FP-12
	SPDT	DC	2000	0.6	25	40	1.15:1	OPEN	TTL	T-2
	SPDT	5	2000	1	30	50	1.2:1	50	TTL	FP-13
	SPDT	5	2000	1	30	55	1.2:1	OPEN	TTL	FP-13
	SPDT	5	2000	1	30	55	1.2:1	OPEN	TTL	DP-3
TWD2218		5	2000	1	60	55	1.2:1	OPEN	CMOS	DP-3
	SPDT	5	3000	1.2	60	55	1.2:1	50	CMOS	DP-3
	SPDT	DC	3000	0.5	10	40	1.15:1	OPEN	0/-5V	FP-7
	SPDT	DC	3000	0.5	25	50	1.15:1	OPEN	0/-5V	T-2
	SPDT	DC	3000	0.5	10	50	1.15:1	OPEN	0/-5V	FP-12
	SPDT	DC	3000	8.0	60	45	1.2:1	OPEN	CMOS	DP-3
	SPDT	DC	3000	8.0	30	45	1.2:1	OPEN	TTL	DP-3
	SPDT	DC	3000	0.8	15	50	1.15:1	50	0/-5V	T-2
TWP2204		DC	3000	0.8	10	50	1.15:1	50	0/-5V	FP-12
	SPDT	5	3000	1.2	30	55	1.2:1	50	TTL	DP-3
TWP2248		5	2000	1	20	55	1.2:1	OPEN	TTL	FP-14
TWD2247		5	2000	1	20	55	1.2:1	50	TTL	FP-14
	SP3T	5	2000	1	40	55	1.2:1	50	CMOS	FP-14
TWD2241		5	2000	1	20	50	1.2:1	50	TTL	DP-10
	SP3T	5	2000	1	20	60	1.2:1	OPEN	TTL	DP-10
	SP3T	5	2000	1	40	60	1.2:1	50	CMOS	DP-10
	SP4T	5	2000	1	20	55	1.2:1	OPEN	TTL	FP-14
	SP4T	5	2000	1	20	55	1.2:1	50	TTL	FP-14
	SP4T	5	2000	1	40	55	1.2:1	50	CMOS	FP-14
TWD2255		5	2000	1	20	55	1.2:1	OPEN	TTL	DP-10
TWD2257		5	2000	1	40	55	1.2:1	50	CMOS	DP-10
TWD6018	SP4T	5	3000	1.4	20	50	1.5:1	50	TTL	DP-11

# SPDT RF SWITCH MODEL TWK2201

Package: 8 Pin TO-5 (T2)

Also Available in: Connectorized Housings

### **Features**

- DC 3.0 GHz
- Fast Switching Speed: 12 ns Typical
- RF1, RF2 Reflective in 'OFF' State
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

### **Specifications**

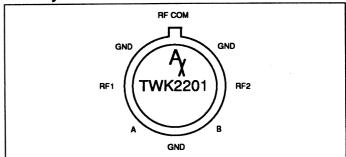
Specifica			
CHARACTERISTIC		TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency		DC - 3.0 GHz	DC - 3.0 GHz
Insertion Lo	ss (dB)	1.0	1.3 Max.
Isolation (di	3)	≥ 30	21 Min.
VSWR	"ON" "OFF"	<1.75:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Control Input High	Vdc mA	- 5.0 to - 8.0 0.30	- 8.0 Max. 1.00 Max.
Control Input Low	Vdc mA	0 to - 0.2 0.010	0 Max. 0.030 Max.
Switching Speed (nsee	c)	12	25 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	- 55	°C to + 100 °C
Storage Temperature	- 65	°C to + 125 °C
Case Temperature		+ 125 °C
DC Voltage		8.5 Volts
Continuous RF Input Power		+30 dBm

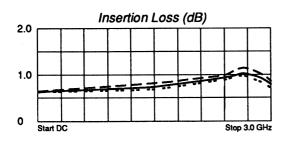
### Pin Layout

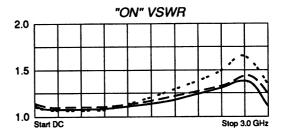


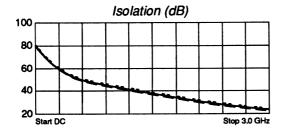
### **Truth Table**

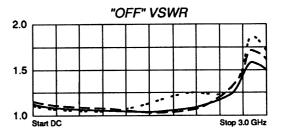
Contr	ol input	Switch State			
		RF Com	mon to:		
A	В	RF1	RF2		
High Low	Low High	ON OFF	OFF ON		

### **Typical Performance Data**









Legend ----- + 25°C --- + 85°C --- - - 55°C



# SPDT RF SWITCH MODEL TWP2202

Package: 6 Lead Flatpack (FP12)

Also Available in: Connectorized Housings

### **Features**

- DC 3.0 GHz
- Fast Switching Speed: 6 ns Typical
- RF1, RF2 Reflective in 'OFF' Position
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

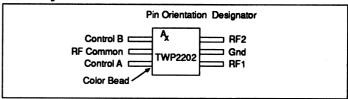
### **Specifications**

CHARACTERISTIC		<b>TYPICAL Ta = 25 °C</b>	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency		DC - 3.0 GHz	DC - 3.0 GHz
insertion Lo	ss (dB)	1.0	1.4 Max.
isolation (di	В)	≥ 30	23 Min.
VSWR	In Out	<1.4:1 <1.4:1	1.5:1 Max. 1.5:1 Max.
Control Input High	Vdc mA	- 5.0 to - 8.0 0.30	- 8.0 Max. 1.00 Max.
Control Input Low	Vdc mA	0 to - 0.2 0.010	0 Max. 0.030 Max.
Switching Speed (nsee	<b>c)</b>	6	10 Max.

### **Maximum Ratings**

Ambient Operating Temperature Storage Temperature	65 °C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+30 dBm

### **Pin Layout**

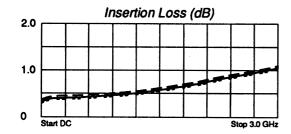


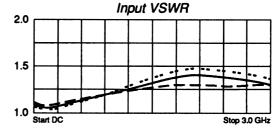
### **Truth Table**

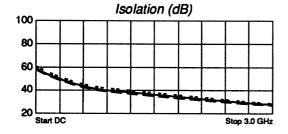
Contro	oi Input	Switch	Position		
		RF Com	mon to:		
A	В	RF1 RF2			
High	Low	ON	OFF		
Low	High	OFF	ON		

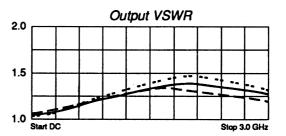
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**









Legend ----- + 25°C --- + 85°C --- - - 55°C



# SPDT RF SWITCH MODEL TWK2203

Package: 8 Pin TO-5 (T2)

Also Available in: Connectorized Housings

### **Features**

- DC 3.0 GHz
- Fast Switching Speed: 9 ns Typical
- RF1, RF2 Terminated in 'OFF' Position
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

### **Specifications**

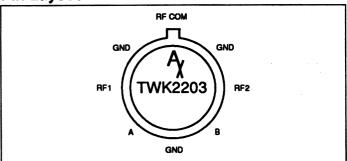
CHARACTERISTIC		TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency		DC - 3.0 GHz	DC - 3.0 GHz
Insertion Los	s (dB)	1.0	2.0 Max.
isolation (dB	)	≥ 40	30 Min.
	"ON" "OFF"	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Control Input High	Vdc mA	- 5.0 to - 8.0 0.30	- 8.0 Max. 1.00 Max.
Control Input Low	Vdc mA	0 to - 0.2 0.010	0 Max. 0.030 Max.
Switching Speed (nsec	)	9	15 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

<b>Ambient Operating Tempera</b>	ture	 	 	- 5	5 °C∶	to + 100	°C
Storage Temperature		 	 	- 6	5 °∵	to + 125	°C
Case Temperature		 	 			+ 125	°C
DC Voltage		 	 			8.5 V	olts
Continuous RF Input Power		 	 			. +30 d	Bm

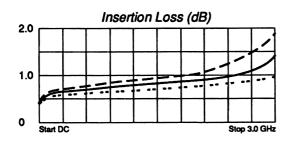
### Pin Layout

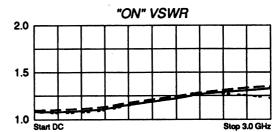


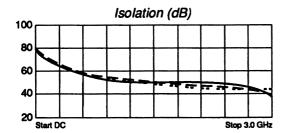
### **Truth Table**

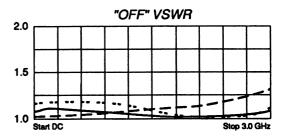
Contr	ol input	Switch Position				
		RF Common to:				
Α	В	RF1	RF2			
High Low	Low High	ON OFF	OFF ON			

### **Typical Performance Data**









Legend ----- + 25°C ---- + 85°C --- - - 55°C



# SPDT RF SWITCH MODEL TWP2204

Package: 6 Lead Flatpack (FP12)

Also Available in: Connectorized Housings

### **Features**

- DC 3.0 GHz
- Fast Switching Speed: 6 ns Typical
- RF1, RF2 Terminated in 'OFF' Position
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

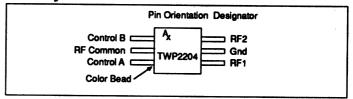
### **Specifications**

CHARACTERISTIC		TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency		DC - 3.0 GHz	DC - 3.0 GHz
Insertion Lo	ss (dB)	1.0	1.5 Max.
isolation (dB	3)	≥ 40	30 Min.
VSWR	In Out	<1.5:1 <1.75:1	2.0:1 Max. 2.0:1 Max.
Control Input High	Vdc mA	- 5.0 to - 8.0 0.30	- 8.0 Max. 1.00 Max.
Control Input Low	Vdc mA	0 to - 0.2 0.010	0 Max. 0.030 Max.
Switching Speed (nsec	)	6	10 Max.

### **Maximum Ratings**

Ambient Operating Temperature.	 - 55 °C to + 100 °C
Storage lemperature	 - 65 °C to + 125 °C
Case lemperature	 ± 125 °C
DC Voltage	- 8 5 Valte
Continuous RF Input Power	 +30 dBm

### Pin Layout



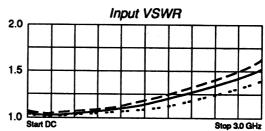
### **Truth Table**

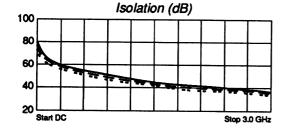
Control Input		Switch	Position
		RF Com	mon to:
A	В	RF1	RF2
High	Low	ON	OFF
Low	High	OFF	ON

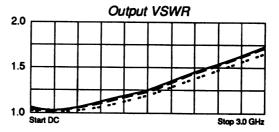
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**











# SPDT RF SWITCH MODEL TWD2206

Package: 14 Pin DIP (DP3)

Also Available in: Connectorized Housings

### **Features**

- 5 4000 MHz
- RF1, RF2 Terminated in 'OFF' State
- Integral CMOS Driver
- Operating Temp. 55 °C to +85 °C
- **■** Environmental Screening available

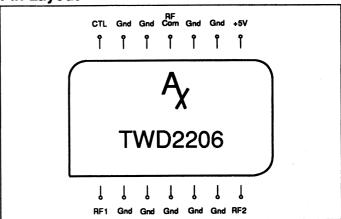
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to +85 °C
Frequency	5 - 4000 MHz	5 - 4000 MHz
Insertion Loss (dB) 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	1.5 1.9 2.5	1.8 Max. 2.2 Max. 2.8 Max.
Isolation (dB) 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	65 55 32	60 Min. 50 Min. 30 Min.
VSWR "ON"/"OFF" 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	1.25:1 1.6:1 1.6:1	1.5:1 Max. 2.0:1 Max. 2.0:1 Max
1 dB Compression (dBm) 50 MHz 500 - 3000 MHz	+18.5 +24	+18.0 Min. +22.0 Min.
Switching Speed (neec) (50% TTL to 90% RF)	40	60 Max.
DC Bias (mA) (4.5 to 5.5 VDC)	0.025	1.0 Max.

### **Maximum Ratings**

Ambient Operating Temperature	 - 5	5 °C	C to + 100 °	'C
Storage Temperature	 - 6	5 °C	C to + 125°	'C
Case Temperature	 		+ 125 °	ď
DC Voltage	 		+ 6.0 Vol	ts
Continuous RF Input Power			+30 dB	m

### Pin Layout



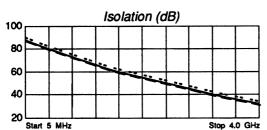
### **Truth Table**

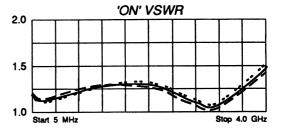
Control Input	Switch Position
TTL	RF Common Connected To
0	RF1
1	RF2

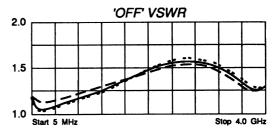
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**











Legend ----- +25°C --- +85°C --- - -55°C

# SPST RF SWITCH MODEL TWP2209

Package: 8 Lead Flatpack (FP7)

Also Available in: Connectorized Housings

### **Features**

- DC 3.0 GHz
- Fast Switching Speed: 6 ns Typical
- RF2 Terminated in 'OFF' Position
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

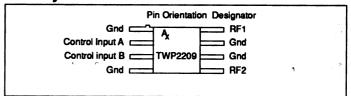
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	DC - 3.0 GHz	DC - 3.0 GHz
Insertion Loss (dE	1.0	1.5 Max.
Isolation (dB)	≥ 32	30 Min.
VSWR In Out	<1.25:1 <1.25:1	1.6:1 Max. 1.5:1 Max.
Control Vdc Input High mA	- 5.0 to - 8.0 0.150	- 8.0 Max. 0.500 Max.
Control Vdc Input Low mA	0 to - 0.2 0.010	0 Max. 0.030 Max.
Switching Speed (nsec)	6	10 Max.

### **Maximum Ratings**

Ambient Operating Temperature		- 55	°C	to + 100 °C
Storage Temperature		- 65	°C	to + 125 °C
Case Temperature				+ 125 °C
DC Voltage	_			8.5 Volts
Continuous RF Input Power				. +30 dBm

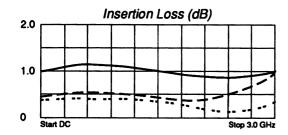
### Pin Layout

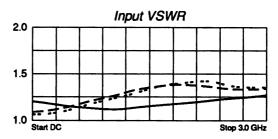


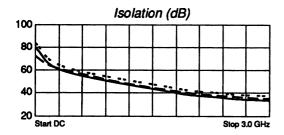
### **Truth Table**

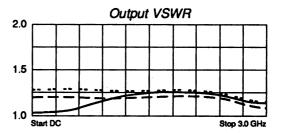
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**









Legend ----- + 25°C --- + 85°C -- -- - 55°C



# SPST RF SWITCH MODEL TWP2214

Package: 6 Lead Flatpack (FP12)

Also Available in: Connectorized Housings

### **Features**

- DC 3.0 GHz
- Fast Switching Speed: 6 ns Typical
- RF2 Terminated in 'OFF' Position
- Operating Temp. 55 °C to + 85 °C
- Environmental Screening available

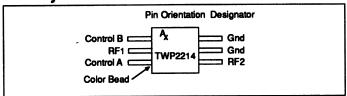
### **Specifications**

CHARACTERISTIC		TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency		DC - 3.0 GHz	DC - 3.0 GHz
Insertion Lo	es (dB)	0.8	1.3 Max.
isolation (di	B)	≥ 40	27 Min.
VSWR	In Out	<1.25:1 <1.5:1	1.8:1 Max. 1.8:1 Max.
Control Input High	Vdc mA	- 5.0 to - 8.0 0.05	- 8.0 Max. 0.30 Max.
Control Input Low	Vdc mA	0 to - 0.2 0.010	0 Max. 0.030 Max.
Switching Speed (nse	c)	6	10 Max.

### **Maximum Ratings**

Ambient Operating Temperature	-	55	°С	to + 100 °C
Storage Temperature	-	65	·°C	to + 125 °C
Case Temperature				+ 125 °C
DC Voltage				8.5 Volts
Continuous RF Input Power				+30 dBm

### Pin Layout

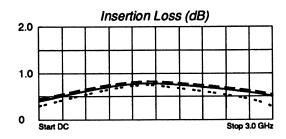


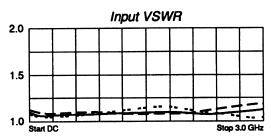
### **Truth Table**

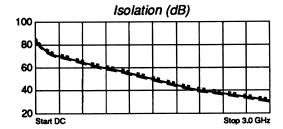
Contro	i Input	Switch Position	
A	В	RF1 to RF2	
High	Low	ON	
Low	High	OFF	

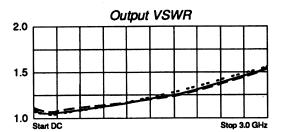
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**









Legend ----- + 25°C --- + 85°C --- - - 55°C



# SPST RF SWITCH MODEL TWD2215

Package: 14 Pin DIP (DP3)

Also Available in: Connectorized Housings

### **Features**

- 5 3000 MHz
- RF2 Terminated in 'OFF' State
- Integral TTL Driver
- Operating Temp. 55 °C to + 85 °C
- Environmental Screening available

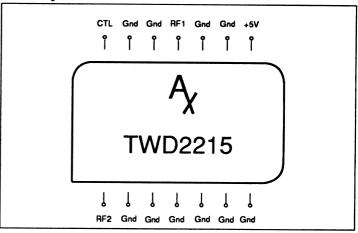
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX
Frequency	5 - 3000 MHz	Ta = - 55 °C to +85 °C 5 - 3000 MHz
Insertion Loss (dB) 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	0.8 1.2 1.8	1.2 Max. 1.5 Max. 2.2 Max.
Isolation (dB) 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	50 36 31	46 Min. 34 Min. 29 Min.
VSWR "ON"/"OFF" 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	1.25:1 1.5:1 1.5:1	1.4:1 Max. 1.6:1 Max. 1.7:1 Max
1 dB Compression (dBm) 50 MHz 500 - 3000 MHz	+18.5 +24	+18.0 Min. +22.0 Min.
Switching Speed (nsec) (50% TTL to 90% RF)	15	30 Max.
DC Bias (mA) (4.5 to 5.5 VDC)	0.025	1.0 Max.

### **Maximum Ratings**

Ambient Operating Temperature	55 °C to + 100 °C
Storage Temperature	65 °C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 6 0 Volte
Continuous RF Input Power	+30 dBm

### Pin Layout



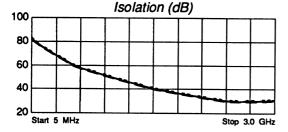
### **Truth Table**

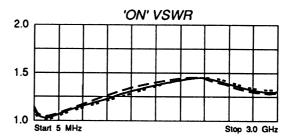
Control Input	Switch Position	
TTL	RF1 To RF2	
0	"OFF"	
1	"ON"	

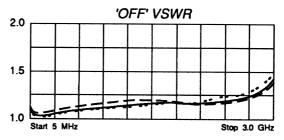
lote: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**











Legend ----- +85°C --- - 55°C

# SPST RF SWITCH MODEL TWD2216

Package: 14 Pin DIP (DP3)

Also Available in: Connectorized Housings

### **Features**

- 5 3000 MHz
- RF2 Terminated in 'OFF' State
- Integral CMOS Driver
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

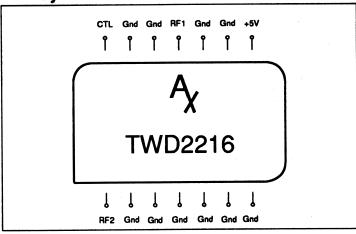
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to +85 °C
Frequency	5 - 3000 MHz	5 - 3000 MHz
Insertion Loss (dB) 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	0.8 1.2 1.8	1.2 Max. 1.5 Max. 2.2 Max.
Isolation (dB) 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	50 36 31	46 Min. 34 Min. 29 Min.
VSWR "ON"/"OFF" 5 - 1000 MHz 5 - 2000 MHz 5 - 3000 MHz	1.25:1 1.5:1 1.5:1	1.4:1 Max. 1.6:1 Max. 1.7:1 Max
1 dB Compression (dBm) 50 MHz 500 - 3000 MHz	+18.5 +24	+18.0 Min. +22.0 Min.
Switching Speed (naec) (50% TTL to 90% RF)	20	30 Max.
DC Bias (mA) (4.5 to 5.5 VDC)	0.025	1.0 Max.

### **Maximum Ratings**

Ambient Operating Temperature	- 55 °Ç	to + 100 °C
Storage Temperature	- 65 °C	to + 125 °C
Case Temperature		+125 °C
DC Voltage		. + 6.0 Volts
DC Voltage		. +30 dBm

### **Pin Layout**

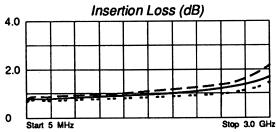


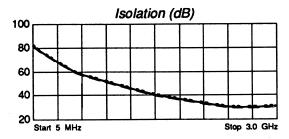
### **Truth Table**

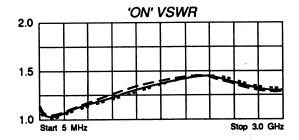
Control Input	Switch Position
CMOS	RF1 To RF2
0	"OFF"
1	"ON"

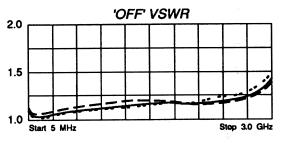
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**











Legend ----- +25°C ---- -55°C

# SPST RF SWITCH MODEL TWP2219

Package: 8 Lead Flatpack (FP7)

Also Available in: Connectorized Housings

### Features

- DC 3.0 GHz
- Fast Switching Speed: 6 ns Typical
- Low Power Consumption: <250 µW Typical
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

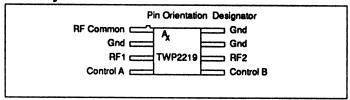
### **Specifications**

<u> </u>		
CHARACTERIST	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	DC - 3.0 GHz	DC - 3.0 GHz
Insertion Loss (d	B) 0.6	0.9 Max.
isolation (dB)	≥ 27	25 Min.
VSWR In Out	<1.25:1 <1.25:1	1.5:1 Max. 1.5:1 Max.
Control Vd Input High m	- 3.0 10 - 6.0	- 8.0 Max. 0.500 Max.
Control Vd Input Low m/	0.0 0.2	0 Max. 0.030 Max.
Switching Speed (nsec)	6	10 Max.

### **Maximum Ratings**

Ambient Operating Temperature	55 °C to + 100 °C
Storage Temperature	- 65 °C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	8.5 Volts
Continuous RF Input Power	+30 dBm

### Pin Layout

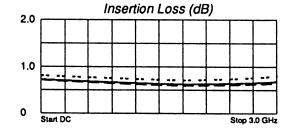


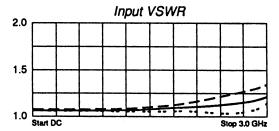
### **Truth Table**

Control Input		Switch I	Position
		RF Common to:	
A	В	RF1	RF2
High	Low	ON	OFF
Low	High	OFF <sub>.</sub>	ON

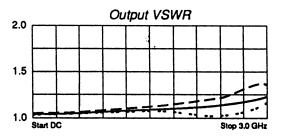
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**









Legend ----- + 25°C --- + 85°C --- - - 55°C



# SPDT RF SWITCH MODEL TWK2224

Package: 8 Pin TO-5 (T2)

Also Available in: Connectorized Housings

### **Features**

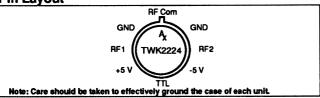
- DC 2.0 GHz
- Fast Switching Speed: 20 ns Typical
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- **■** Environmental Screening Available

### **Specifications**

Specifications		
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	DC - 2.0 GHz	DC - 2.0 GHz
Insertion Loss (dB) DC - 2 GHz DC - 1 GHz DC - 0.5 GHz	0.6 0.5 0.5	0.8 Max. 0.7 Max. 0.7 Max.
Isolation (dB) DC - 2 GHz DC - 1 GHz DC - 0.5 GHz	≥32 ≥38 ≥45	30 Min. 35 Min. 40 Min.
VSWR 'ON' DC - 2 GHz DC - 1 GHz DC - 0.5 GHz	<1.25:1 <1.12:1 <1.10:1	1.5:1 Max. 1.15:1 Max. 1.15:1 Max.
DC Vdc Bias mA	±5 V 0.5	±5 V Max. 1.0 Max.
Switching Speed (nsec)*	20	25 Max.
Transients (mV)	5	10 Max.
T Rise/Fall (nsec)	15	
1 dB Compression (dBm) 0.05 GHz 0.5 - 2 GHz	21 27	=
Intercept Points (dBm) 0.05 GHz 0.5 - 2 GHz	iP <sub>2</sub> iP <sub>3</sub> +57 +40 +68 +46	

<sup>&</sup>lt;sup>t</sup>ON<sup>, t</sup>OFF (50% CTL to 90%/10% RF)

### Pin Layout



### Truth Table

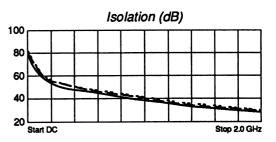
HUMI IUDIO	
Control Input	Switch Position
ΠL	RF Common Connected To:
1	RF1 RF2

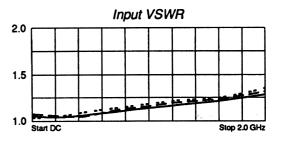
### **Maximum Ratings**

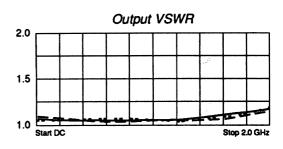
Ambient Operating Temperature Storage Temperature	55 °C to + 100 °C 65 °C to + 125 °C
Case Temperature	+ 125 °C
Continuous RF Input Power	+30 dBm

### **Typical Performance Data**











Legend ----- + 25°C ---- + 85°C ---- - 55°C

# RF SWITCH MODEL TWP2225

Available in: FP-12, 6 Lead, 0.375" sq. Flatpack and 6 Lead, 0.375" sq. Surface Mount Package

### **Features**

- DC 2.0 GHz
- Fast Switching Speed: 20 ns Typical
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

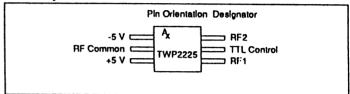
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	DC - 2.0 GHz	DC - 2.0 GHz
Insertion Loss (dB)	0.6	0.8 Max.
Isolation (dB)	≥ 32	29 Min.
VSWR 'ON'	<1.25:1	1.5:1 Max.
DC Vdc Bias mA	±5 V 0.5	±6 V Max. 1.2 Max.
Switching Speed (nsec)	20	25 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature 55 °C to + 100 °C	3
Storage Temperature 65 °C to + 125 °C	С
Case Temperature	0
DC Voltage	9
Continuous RF Input Power +30 dBr	n

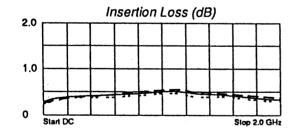
### Pin Layout

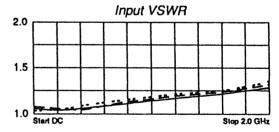


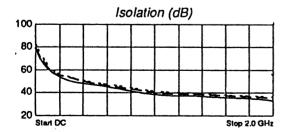
### **Truth Table**

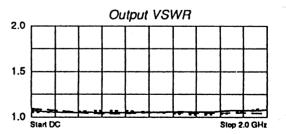
Control Input	Switch Position
TTL	RF Common Connected To:
1	RF1
0	RF2

### **Typical Performance Data**









Legend ----- + 25°C --- + 85°C --- - - 55°C



# SP3T RF SWITCH MODEL TWD2241

Available in: DP-10, 16 Pin DIP Package and Connectorized Housings

### **Features**

- 5- 2000 MHz
- Fast Switching Speed: 15 ns Typical (GaAs)
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Environmental Screeing Available

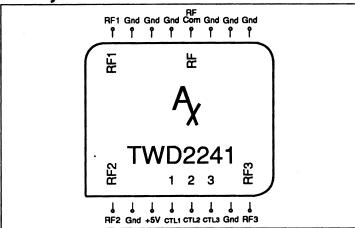
### **Specifications**

opecinications		
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	5 - 2000 MHz	5 - 2000 MHz
Insertion Loss (dB)	1.2	1.8 <b>Ma</b> x.
Isolation (dB)	50	35 Min.
VSWR	1.5:1	2.0:1 Max.
DC Vdc Bias mA	+5 V 0.5	+5 V Max. 1.0 Max.
Switching Speed (nsec)	15	20 Max.
Transients (mV)	80	
1 dB Compression (dBm) 0.05 GHz 0.5 - 2 GHz	21 27	=
Intercept Points (dBm) 0.05 GHz 0.5 - 2 GHz	IP: IP: +62 +40 +68 +46	=

### **Maximum Ratings**

Ambient Operating Temperature	 55	°C to + 100 °C
Storage Temperature	 65	°C to + 125 °C
Case Temperature	 	+ 125 °C
DC Voltage	 	+ 7.0 Volts
Continuous RF Input Power	 	+30 dBm

### **Pin Layout**

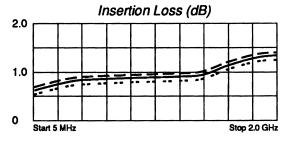


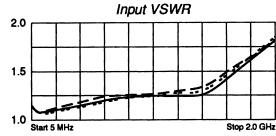
### **Truth Table**

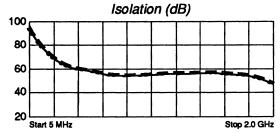
Control Input	Switch Condition
TTL	RF Common To RF Throw
1	Low Loss
0	Isolated

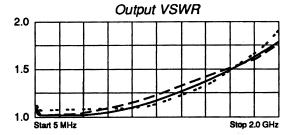
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**











Legend ----- + 85°C --- - - 55°C

# SP3T RF SWITCH MODEL TWP2248

Package: FP14 - 16 Lead Flatpack

Also Available in: Connectorized Housings

### **Features**

- 5- 2000 MHz; Integral TTL Driver
- Fast Switching Speed: 15 ns Typical (GaAs)
- RF1 RF3 Reflective in "OFF" State
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

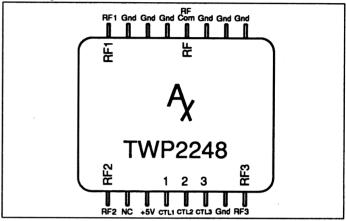
### **Specifications**

CHARACT	ERISTIC	TYP Ta = 2	ICAL 25°C	MIN/MAX Ta = - 55 °C to + 85 °C	
Frequency	,	5 - 200	00 MHz	5 - 2000 MHz	
insertion L	oss (dB)	1.2		2.0	Max.
isolation (	dB)	45		34 Min.	
VSWR	ON'	1.5:1		2.0:1	Max.
DC Bias	Vdc mA	+5 V 0.5		+5 V 1.0	Max. Max.
Switching Speed (nse	ec)	15		40	Max.
Transients	(mV)	80			
1 dB Compres 0.05 GHz 0.5 - 2 GHz		21 27		_	
Intercept Point 0.05 GHz 0.5 - 2 GHz		IP: +62 +68	IP3 +40 +46	_	

### **Maximum Ratings**

Ambient Operating Temperature	-	55	°C	to + 100 °C
Storage Temperature		65	°C	to + 125 °C
Case Temperature				+ 125 °C
DC Voltage				+70 Volte
Continuous RF Input Power				. +30 dBm

### Pin Layout

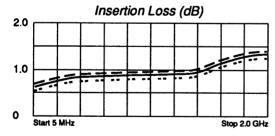


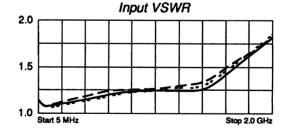
### **Truth Table**

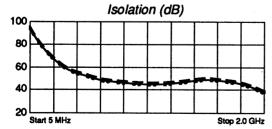
Control Input	Switch Condition
TTL	RF Common To RF Throw
1	Low Loss ("ON")
0	Isolated ("OFF")

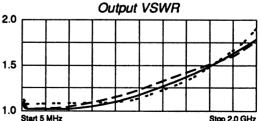
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**









**Amplifonix** 

Legend ----- + 25°C ---- - 55°C

# SP4T RF SWITCH MODEL TWD2254

Available in: DP-10, 16 Pin DIP Package and Connectorized Housings

### **Features**

- 5- 2000 MHz
- Fast Switching Speed: 15 ns Typical (GaAs)
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Screening to the tables of MIL-STD-883 available

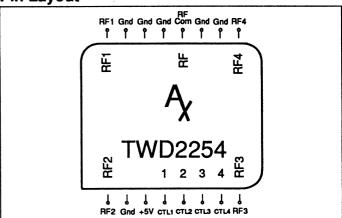
### **Maximum Ratings**

Ambient Operating Temperature	-	55	۰C	to + 100 °C
Storage Temperature	-	65	۰C	to + 125 °C
Case Temperature				+ 125 °C
DC Voltage				. + 7.0 Volts
Continuous RF Input Power				. +30 dBm

### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	5 - 2000 MHz	5 - 2000 MHz
Insertion Loss (dB)	1.2	1.9 Max.
Isolation (dB)	50	35 Min.
VSWR	1.5:1	2.3:1 Max.
DC Vdc Bias mA	+5 V 0.5	+5 V Max. 1.0 Max.
Switching Speed (nsec)	15	20 Max.
Transients (mV)	80	
1 dB Compression (dBm) 0.05 GHz 0.5 - 2 GHz	21 27	_
intercept Points (dBm) 0.05 GHz 0.5 - 2 GHz	IP: IP: +62 +40 +68 +46	

### Pin Layout

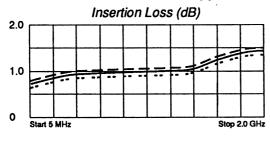


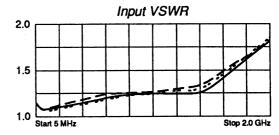
### **Truth Table**

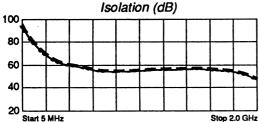
Control input	Switch Condition			
TTL	RF Common To RF Throw			
1	Low Loss			
0	Isolated			

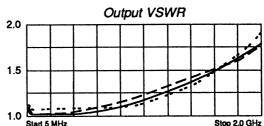
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**











Legend ----- + 25°C --- - + 85°C --- - - 55°C

# SP4T RF SWITCH MODEL TWP2261

Package: FP14 - 16 Lead Flatpack
Also Available in: Connectorized Housings

### **Features**

- 5- 2000 MHz
- RF1 RF4 Terminated in "OFF" State
- Integral TTL Driver
- Operating Temp. 55 °C to + 85 °C
- Environmental Screening available

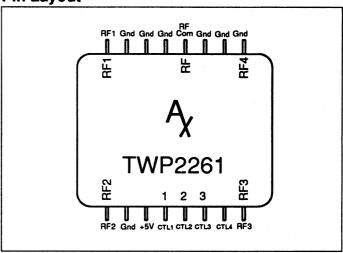
### **Specifications**

CHARACTER	STIC	TYPICAL Ta = 25 °C		Ta =	MIN/M - 55 °C 1	AX to + 85 °C		
Frequency		5 - 200	00 MHz		5 - 2000 MHz			
Insertion Loss	(dB)	1.2			1.9 Max			
Isolation (dB)		45			35 Min			
VSWR '	ON'	1.5:	1		2.0:1 Ma			
	Vdc mA	+5 V 0.5			+5 V 1.0	Max. Max.		
Switching Spe Ton/Toff (nsec)	ed	15			20	Max.		
Transition Tin Rise/Fall Time (		3		3			7	Max.
Transients (m	iV)	80						
1 dB Compression 0.05 GHz 0.5 - 2 GHz	(dBm)	21 27						
Intercept Points (d 0.05 GHz 0.5 - 2 GHz	Bm)	IP2 +62 +68	IP: +40 +46					

### **Maximum Ratings**

Ambient Operating Temperature	- 55	°C to + 100 °C
Storage Temperature	- 65	°C to + 125 °C
Case Temperature		+ 125 °C
DC Voltage		+ 7.0 Volts
Continuous RF Input Power		+30 dBm

### Pin Layout



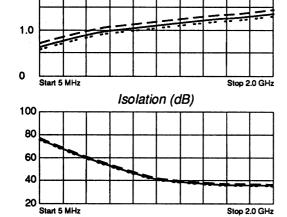
### **Truth Table**

Control Input	Switch Condition
TTL	RF Common To RF Throw
1	Low Loss ("ON")
0	Isolated ("OFF")

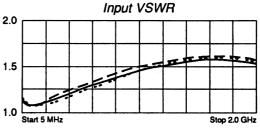
Note: Care should always be taken to effectively ground the case of each unit

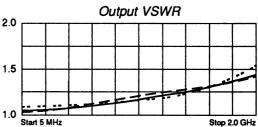
2.0

### **Typical Performance Data**



Insertion Loss (dB)







Legend ----- + 25°C ---- - 55°C

# SP4T RF SWITCH MODEL TWP2264

Package: FP14 - 16 Lead Flatpack
Also Available in: Connectorized Housings

### **Features**

- 5- 2000 MHz
- RF1 RF4 Terminated in "OFF" State
- Integral CMOS Driver
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

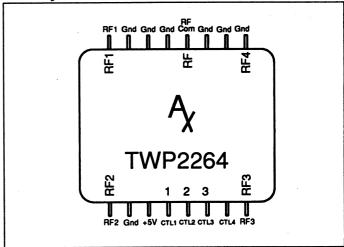
### **Specifications**

Specifications		
CHARACTERISTIC	CHARACTERISTIC TYPICAL Ta = 25 °C	
Frequency	5 - 2000 MHz	5 - 2000 MHz
Insertion Loss (dB)	1.2	1.9 Max.
Isolation (dB)	45	35 Min.
VSWR 'ON'	1.5:1	2.0:1 Max.
DC Vdc Bias mA	+5 V 0.5	+5 V Max. 1.0 Max.
Switching Speed Ton/Toff (nsec)	40	50 Max.
Transition Time Rise/Fall Time (nsec)	20	30 Max.
Transients (mV)	80	
1 dB Compression (dBm) 0.05 GHz 0.5 - 2 GHz	21 27	=
Intercept Points (dBm) 0.05 GHz 0.5 - 2 GHz	IP <sub>2</sub> IP <sub>3</sub> +62 +40 +68 +46	_

### **Maximum Ratings**

Ambient Operating Temperature	55 °C to + 100 °C
Storage Temperature	65 °C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+ 7.0 Volts
Continuous RF Input Power	+30 dBm

### Pin Layout

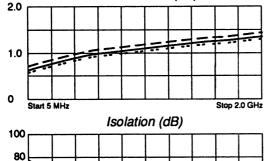


### Truth Table

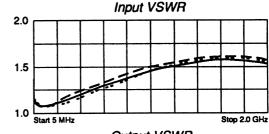
Hutti lubic	
Control Input	Switch Condition
TTL	RF Common To RF Throw
1	Low Loss ("ON")
0	Isolated ("OFF")

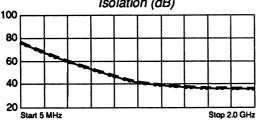
Note: Care should always be taken to effectively ground the case of each unit

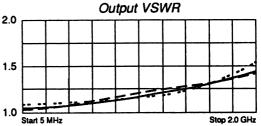
### Typical Performance Data



Insertion Loss (dB)







**Amplifonix** 

Legend — + 25°C — − + 85°C · · · · · - 55°C

# SPST RF SWITCH MODEL TWM5000

Package: 5 Pin TO-8 (T5)

Also Available in: Connectorized Housings

### **Features**

- 10 1500 MHz
- RF1, RF2 Terminated in 'Off' State
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- **■** Environmental Screening available

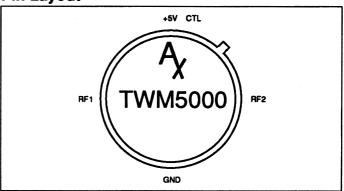
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	10 - 1500 MHz	10 - 1500 MHz
Insertion Loss (dB)	1.2	1.7 Max.
Isolation (dB)	48	39 Min.
VSWR	1.3:1	1.7:1 Max.
DC Vdc Bias mA	+5 2	+5 Max. 5 Max.
Switching Speed (µsec)	0.15	0.50 Max.
Transients (mV)	200	
1 dB Compression (dBm)	+23	
Intercept Points (dBm)	IP <sub>2</sub> IP <sub>3</sub> +65 +40	·

### **Maximum Ratings**

Ambient Operating Temperature	 - 5	5 °C	to + 100 °C
Storage Temperature	 - 6	5 °C	C to + 125 °C
Case Temperature	 		+ 125 °C
DC Voltage	 		+6.0 Volts
Continuous RF Input Power	 		+30 dBm

### Pin Layout



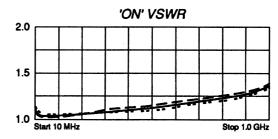
### **Truth Table**

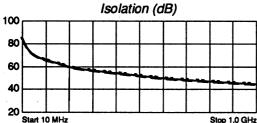
II WILL TOWN	
Control Input	Switch Position
TTL	RF1 to RF2
0	'OFF'
1	'ON'

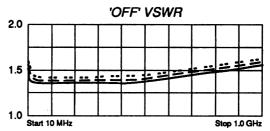
Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**











Legend ----- + 85°C --- - - 55°C

# SPDT RF SWITCH MODEL TWD5001

Package: DP3 - 14 lead DIP Package

Also Available in: Connectorized Housings

### **Features**

- 10- 1000 MHz
- RF1, RF2 Terminated in 'Off' State
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

### **Specifications**

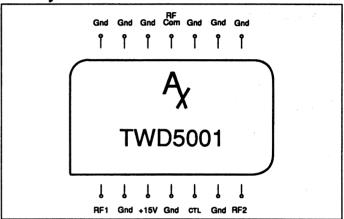
opcomodationo		
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	10 - 1000 MHz	10 - 1000 MHz
Insertion Loss (dB)	1.0	2.0 Max.
Isolation (dB)	45	25 Min.
VSWR	1.2:1	1.5:1 Max.
DC Vdc Bias mA	+15 V 15	+15 V Max. 23 Max.
Switching Speed (µsec)	3	4 Max.
Transients (mV)	750	
1 dB Compression (dBm)	+23	
Intercept Points (dBm)	IP <sub>2</sub> IP <sub>3</sub> +65 +40	

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	- 55 °C to + 100 °C
Storage Temperature	- 65 °C to + 125 °C
Case Temperature	+ 125°C
DC Voltage	+17.0 Volts
Continuous RF Input Power	+30 dBm

### **Pin Layout**

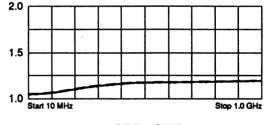


### **Truth Table**

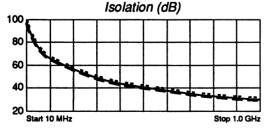
u		
Control Input	Switch Position	
TTL	RF Common Connected To	
1	RF1	
0	RF2	

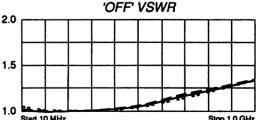
### **Typical Performance Data**





'ON' VSWR





**Amplifonix** 

Legend ----- + 85°C --- - - 55°C

# SPDT RF SWITCH MODEL TWD5002

Package Style: 14 Lead DIP Package (DP11)

Also Available In: Connectorized Housings

### **Features**

- **30-1000 MHz**
- RF1, RF2 Terminated in 'Off' State
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Environmental Screening available

### **Specifications**

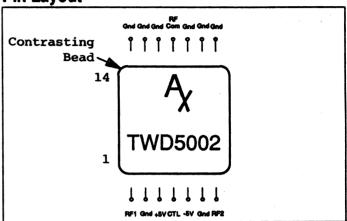
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	30 - 1000 MHz	30 - 1000 MHz
Insertion Loss (dB)	0.8	1.5 Max.
isolation (dB)	75	55 Min.
VSWR	1.2:1	1.5:1 Max.
DC +Vdc/mA Blas -Vdc/mA	+5/12 - 5/8	+5/18 Max. - 5/12 Max.
Switching Speed (µsec)	0.75	2.0 Max.
Transients (mV)	750	
1 dB Compression (dBm)	+23	
Intercept Points (dBm)	IP <sub>2</sub> IP <sub>3</sub> +65 +40	

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature 55 °C to + 100	•C
Storage Temperature 65 °C to + 125	•C
Case Temperature	°C
DC Voltage	olts
Continuous RF Input Power +30 d	Bm

### **Pin Layout**

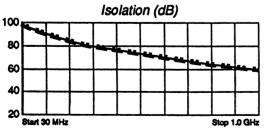


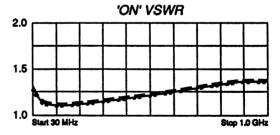
### **Truth Table**

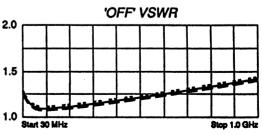
THE CONTRACTOR OF THE CONTRACT		
Control Input	Switch Position	
TTL	RF Common Connected To	
0	RF1	
1	RF2	

### **Typical Performance Data**











Legend ----- + 25°C --- + 85°C ---- - - 55°C

# SP8T RF SWITCH MODEL TWD5005

Available in: DP-5, 24 Pin DIP Package and Connectorized Housings

### **Features**

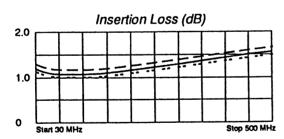
- 30-500 MHz
- RF1-RF8 Terminated in 'Off' State
- Integral TTL /BCD Driver
- Operating Temp. 55 °C to +85 °C
- Screening to the tables of MIL-STD-883 available

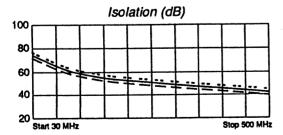
### **Specifications**

,		1
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
	1a = 25 °C	11a = - 33 C 10 + 03 C
Frequency	30 - 500 MHz	30 - 500 MHz
Insertion Loss (dB)	1.2	1.8 Max.
Isolation (dB)	55	40 Min.
VSWR	1.5:1	2.0:1 Max.
DC +VDc/mA Blas -VDc/mA	+5/20 -5/3	+5/25 Max. -5/5 Max.
Switching Speed (nsec)	400	500 Max.
Transients (mV)	300	
1 dB Compression (dBm)	+23	
Intercept Points (dBm)	IP2 IP3 +65 +40	

Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**

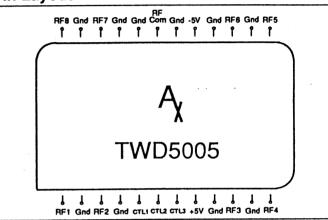




### **Maximum Ratings**

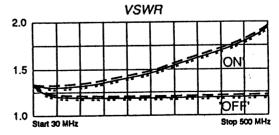
Ambient Operating Temperature	- 55 °C to + 100 °C
Storage Temperature	- 65 °C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	± 6.0 Volts
Continuous RF Input Power	+30 dBm

### Pin Layout



### **Truth Table**

TTL	TTL Control Input		Switch Position	
С3	C2	C1	RF Common Connected To	
0	0	0	RF1	
ŏ	Õ	1 1	RF2	
ŏ	1	òΙ	RF3	
Ŏ	1	i 1	RF4	
Ĭ	Ó	o I	RF5	
i	Ŏ	il	RF6	
i	Ĭ	o l	RF7	
i	i	1 1	RF8	



**Amplifonix** 

Legend ----- + 85°C ---- - 55°C

# SPDT RF SWITCH MODEL TWD5015

**Available in:** DP-3, 14 Pin DIP Package and Connectorized Housings

### **Features**

- 20- 1000 MHz
- RF1, RF2 Terminated in 'Off' State
- Integral TTL Driver
- Operating Temp. 55 °C to +85 °C
- Screening to the tables of MIL-STD-883 available

### **Specifications**

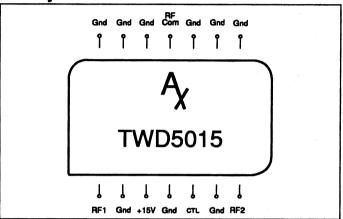
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to + 85 °C
Frequency	20 - 1000 MHz	20 - 1000 MHz
Insertion Loss (dB)	1.2	2.0 Max.
isolation (dB)	45	25 Min.
VSWR	1.2:1	1.5:1 Max.
DC Vdc Bias mA	+5 V 15	+5 V Max. 23 Max.
Switching Speed (µsec)	0.7	1.0 Max.
Transients (mV)	750	
1 dB Compression (dBm)	+23	
Intercept Points (dBm)	IP <sub>2</sub> IP <sub>3</sub> +65 +40	

Note: Care should always be taken to effectively ground the case of each unit

### **Maximum Ratings**

Ambient Operating Temperature	55 °C to + 100 °C
Storage Temperature	65 °C to + 125 °C
Case Temperature	+ 125 °C
DC Voltage	+6.0 Volts
Continuous RF Input Power	+30 dBm

### **Pin Layout**

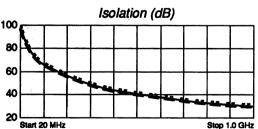


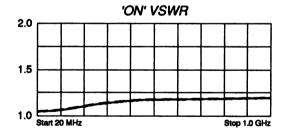
### **Truth Table**

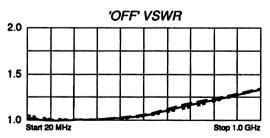
Control Input	Switch Position	
TTL	RF Common Connected To	
1	RF1	
0	RF2	

### **Typical Performance Data**











Legend ----- + 25°C --- + 85°C --- - - 55°C

# SP3T RF SWITCH MODEL TWH5016

Package: 12 Pin TO-8B (T8)

Also Available in: Connectorized Housings

### **Features**

- ■10 3000 MHz
- RF1-RF3 Reflective in 'OFF' State
- Integral TTL Driver
- Operating Temp. 55 °C to + 100 °C
- Environmental Screening available

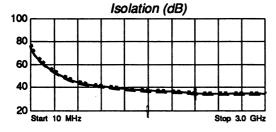
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to +100 °C
Frequency	10 - 3000 MHz	10 - 3000 MHz
Insertion Loss (dB) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	1.0 1.2 1.4	1.5 Max. 1.6 Max. 2.4 Max.
Isolation (dB) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	70 45 35	60 Min. 35 Min. 30 Min.
1 dB Compression (dBm) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	18 27 30	8 Min. 20 Min. 29 Min.
VSWR 'ON'	1.3:1	1.6:1 Max.
Switching Speed (µsec) (50% TTL to 90% RF)	2.0	3.0 Max.
DC Bias (mA) (4.5 to 5.5 VDC)	2.4	4.0 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**

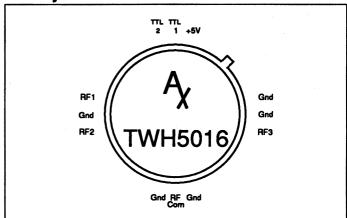




### **Maximum Ratings**

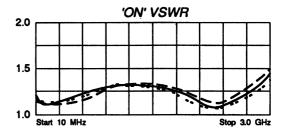
Ambient Operating Temperature	 - 55	°C t	0 + 100 °C
Storage Temperature	 - 65	°C 1	o + 125 °C
Case Temperature	 		. + 125 °C
DC Voltage	 		+ 6.0 Volts
Continuous RF Input Power	 		. +32 dBm

### **Pin Layout**



### **Truth Table**

TTL Control Inputs		Switch Position
TTL1	TTL2	RF Common Connected To
0	0	RF1
1	0	RF2
0	1	RF3





Legend ——— + 25°C ——— +100°C ··· · - 55°C

# SP5T RF SWITCH MODEL TWH5017

Package: 12 Pin TO-8B (T8)

Also Available in: Connectorized Housings

### **Features**

- ■10 3000 MHz
- RF1-RF5 Reflective in 'OFF' State
- Integral TTL Driver
- Operating Temp. 55 °C to + 100 °C
- Environmental Screening available

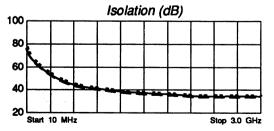
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to +100 °C
Frequency	10 - 3000 MHz	10 - 3000 MHz
Insertion Loss (dB) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	1.0 1.2 1.4	1.5 Max. 1.6 Max. 2.4 Max.
Isolation (dB) * 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	70 45 35	60 Min. 35 Min. 30 Min.
1 dB Compression (dBm) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	18 27 30	8 Min. 20 Min. 29 Min.
VSWR 'ON'	1.3:1	1.6:1 Max.
Switching Speed (µsec) (50% TTL to 90% RF)	2.0	3.0 Max.
DC Bias (mA) (4.5 to 5.5 VDC)	2.4	4.0 Max.

<sup>\*</sup> Isolation at RF4 degraded by 15 dB.

### **Typical Performance Data**

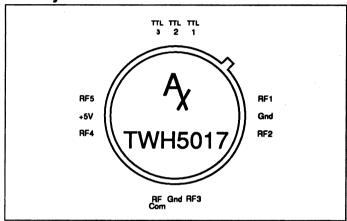




### **Maximum Ratings**

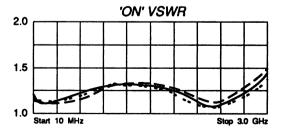
Ambient Operating Temperature		55	°C	to + 100 °C
Storage Temperature		65	°C	to + 125 °C
Case Temperature				+ 125 °C
DC Voltage				. + 6.0 Volts
Continuous RF Input Power	• • •			. +32 dBm

### **Pin Layout**



### **Truth Table**

TTL Control Inputs		nputs	Switch Position
TTL1	TTL2	TTL3	RF Common Connected To
0	0	0	RF1
1	0	0	RF2
0	1	0	RF3
1	1	0	RF4
0	0	1	RF5





Legend ----- +25°C --- +100°C -- - -55°C

# SPDT RF SWITCH MODEL TWH7230

Package: 12 Pin TO-8B (T8)

Also Available in: Connectorized Housings

### **Features**

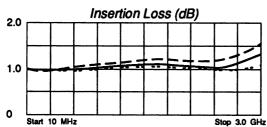
- ■10 3000 MHz
- RF1, RF2 Reflective in 'OFF' State
- Integral TTL Driver
- Operating Temp. 55 °C to + 100 °C
- Environmental Screening available

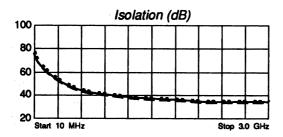
### **Specifications**

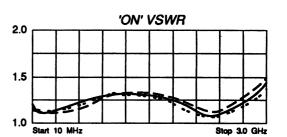
CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to +100 °C
Frequency	10 - 3000 MHz	10 - 3000 MHz
Insertion Loss (dB) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	1.0 1.2 1.4	1.5 Max. 1.6 Max. 2.4 Max.
Isolation (dB) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	70 45 35	60 Min. 35 Min. 30 Min.
1 dB Compression (dBm) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	18 27 30	8 Min. 20 Min. 29 Min.
VSWR 'ON'	1.3:1	1.6:1 Max.
Switching Speed (µsec) (50% T.TL, to 90% RF)	2.0	3.0 Max.
DC Bias (mA) (4.5 to 5.5 VDC)	2.4	4.0 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**







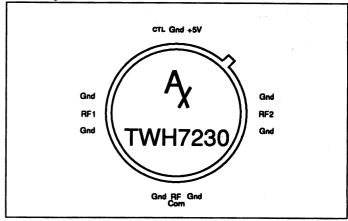
### Legend ——— +25°C ——— +100°C -- -- -55°C

2707 Black Lake Place, Philadelphia, PA 19154

### **Maximum Ratings**

<b>Ambient Operating Temperat</b>	ture	 	- 55 °C	to + 100 °C
Storage Temperature		 	- 65 °C	to + 125 °C
Case Temperature		 		+ 125 °C
DC Voltage				→ 6 0 Volte
Continuous RF Input Power		 ••••		+32 dBm

### Pin Layout



### **Truth Table**

Control Input	Switch Position
TTL	RF Common Connected To
0	RF1
1	RF2

# SP4T RF SWITCH MODEL TWH7425

Package: 12 Pin TO-8B (T8)

Also Available in: Connectorized Housings

### **Features**

- ■10 3000 MHz
- RF1-RF4 Reflective in 'OFF' State
- Integral TTL Driver
- Operating Temp. 55 °C to + 100 °C
- Environmental Screening available

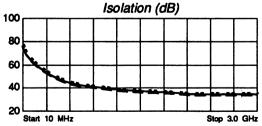
### **Specifications**

CHARACTERISTIC	TYPICAL Ta = 25 °C	MIN/MAX Ta = - 55 °C to +100 °C
Frequency	10 - 3000 MHz	10 - 3000 MHz
Insertion Loss (dB) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	1.0 1.2 1.4	1.5 Max. 1.6 Max. 2.4 Max.
Isolation (dB) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	70 45 35	60 Min. 35 Min. 30 Min.
1 dB Compression (dBm) 10 -100 MHz 100 -1500 MHz 1500 - 3000 MHz	18 27 30	8 Min. 20 Min. 29 Min.
VSWR 'ON'	1.3:1	1.6:1 Max.
Switching Speed (µsec) (50% TTL to 90% RF)	2.0	3.0 Max.
DC Bias (mA) (4.5 to 5.5 VDC)	2.4	4.0 Max.

Note: Care should always be taken to effectively ground the case of each unit

### **Typical Performance Data**

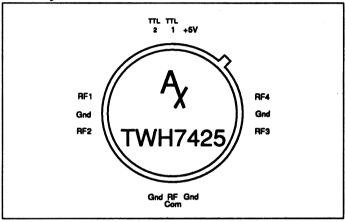




### Maximum Ratings

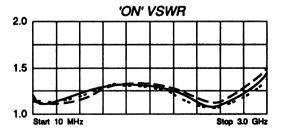
Storage Temperature	~
	Ž
Case Temperature	C
DC Voltage + 6.0 VolContinuous RF Input Power +32 dB	ts ~

### **Pin Layout**



### **Truth Table**

TTL Conti	rol Inputs	Switch Position
TTL1	TTL2	RF Common Connected To
0	0	RF4
1	0	RF1
0	1 1	RF3
11	1	RF2

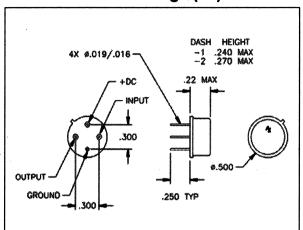




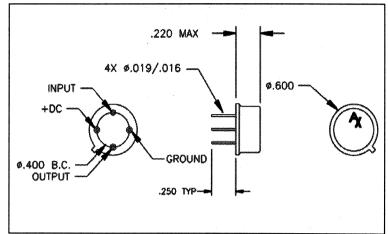
Legend ----- +25°C --- +100°C -- -- -55°C

### **Amplifier Outline Drawings**

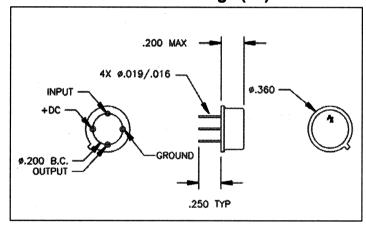
TO-8 Package (T4)



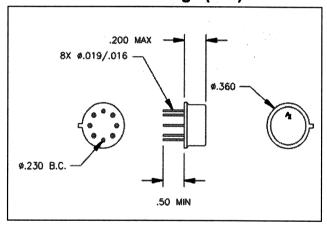
TO-8B Package (T8)



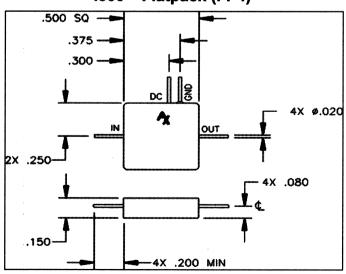
TO-12 Package (T7)



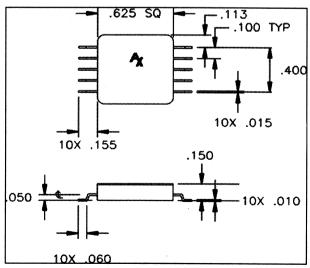
TO-39 Package (T10)



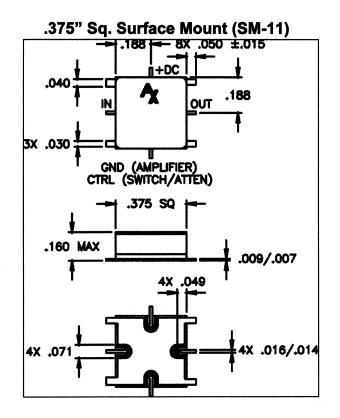
.500" Flatpack (FP4)

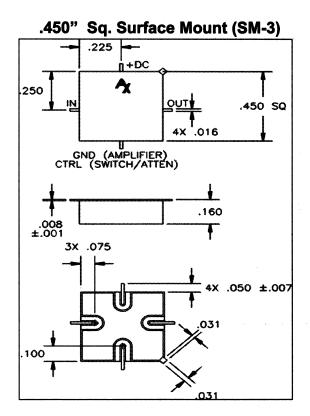


.625"Gullwing (SG4)

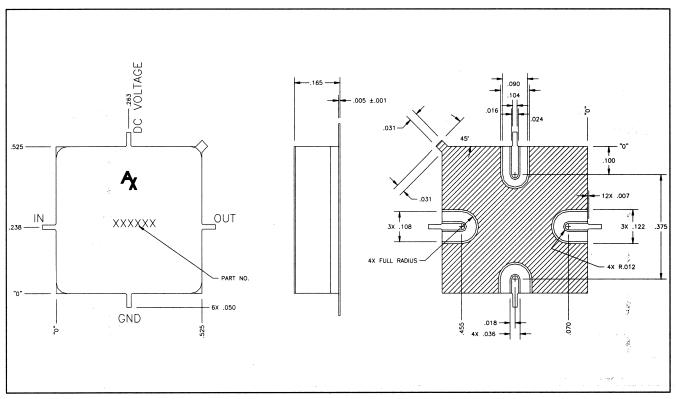


### **Amplifier Outline Drawings**



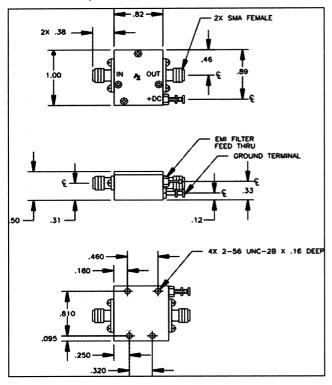


.525" Surface Mount (SM-19)

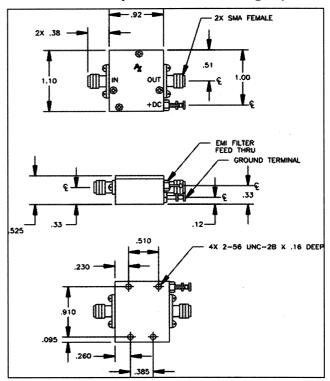


### **Amplifier Outline Drawings**

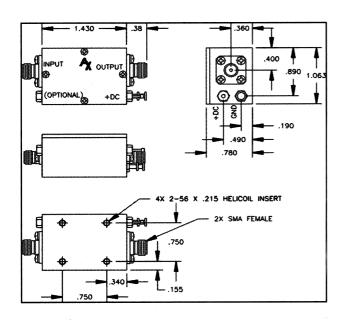
### SMA Connectorized Housing (H1) (For TO-8 Packages)



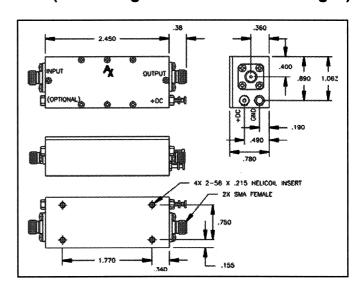
### SMA Connectorized Housing (H2) (For TO-8B Packages)



### SMA Connectorized Housing (H3) (Two Stage For Two TO-8 Packages)



### SMA Connectorized Housing (H4) (Three Stage For 3 or 4 TO-8 Packages)



### **VCO Outline Drawings**

TO-8 Package (T4)

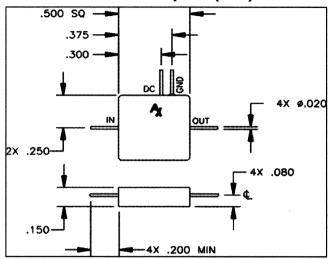
4X 6.019/.016—

+DC .22 MAX

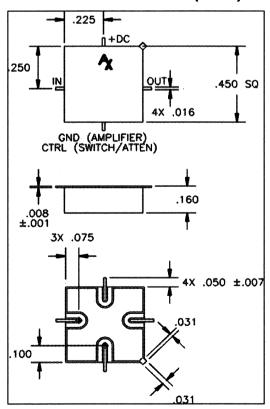
INPUT .300 .300

OUTPUT .250 TYP

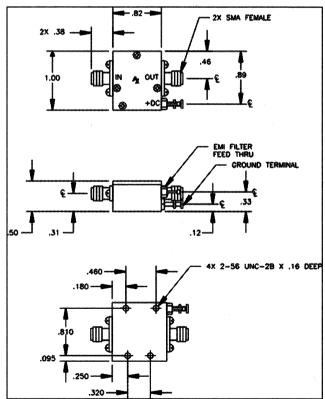
.500" Flatpack (FP4)



.450" Surface Mount (SM-3)

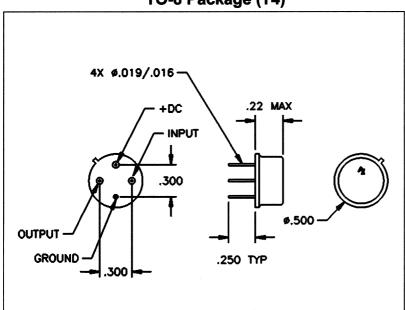


### SMA Connectorized Housing (H1) (For TO-8 Packages)

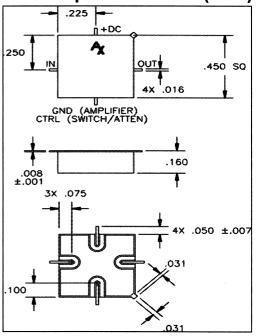


## <u>Limiting Amplifiers, Limiters and Detectors</u> <u>Outline Drawings</u>

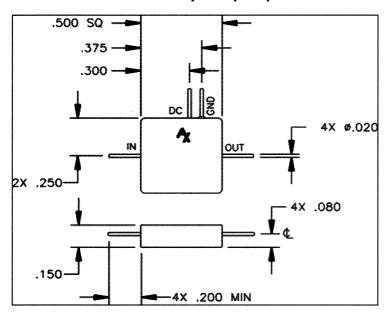
TO-8 Package (T4)



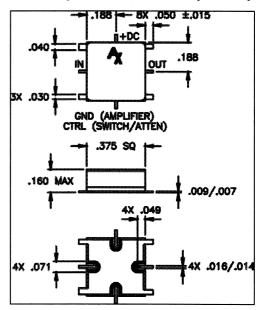
.450" Sq. Surface Mount (SM-3)



.500" Flatpack (FP4)

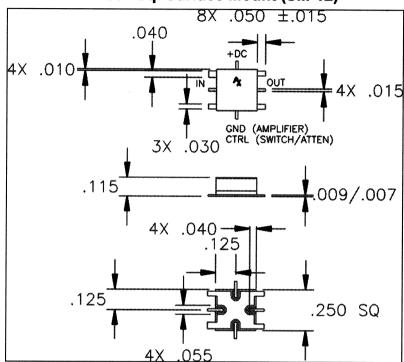


.375" Sq. Surface Mount (SM-11)

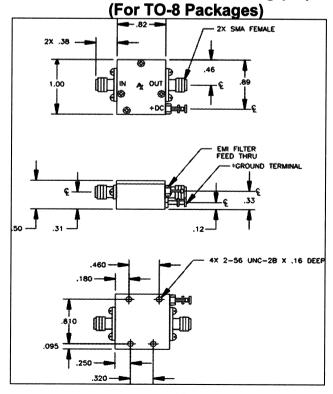


# <u>Limiting Amplifiers, Limiters and Detectors</u> <u>Outline Drawings</u>

.250" Sq. Surface Mount (SM-12)



### **SMA Connectorized Housing (H1)**



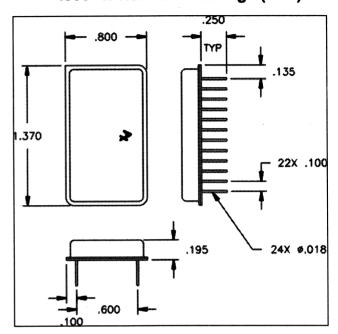
-465-

### **Digital Attenuator Outline Drawings**

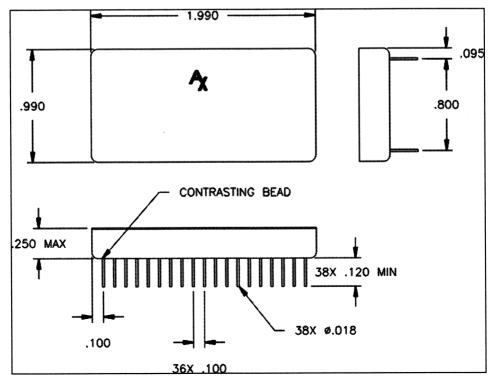
### .625" Gullwing Package (SG4)

# .625 SQ - .113 - .100 TYP .400 .400 .10X .015 .150 .150 .10X .010

### .800" x 1.37" DIP Package (DP5)



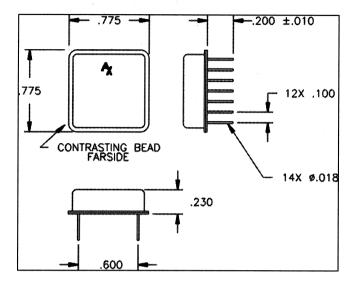
.990" x 1.99" DIP Package (DP8)



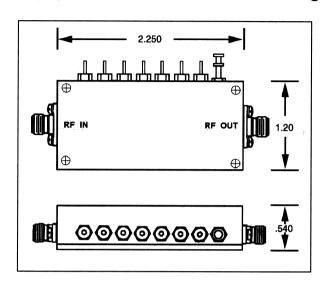
- 466-

### **Digital Attenuator Outline Drawings**

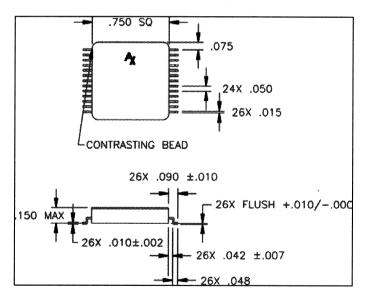
### .775" Sq. DIP Package (DP11)



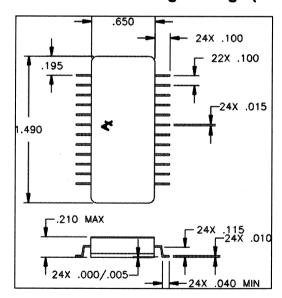
### **Attenuator SMA Connectorized Housing**



.750" Sq. Gullwing Package (SG2)



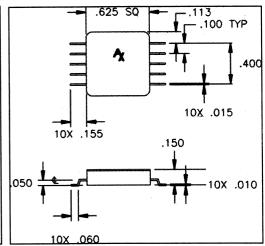
.650" x 1.490" Gullwing Package (SG6)



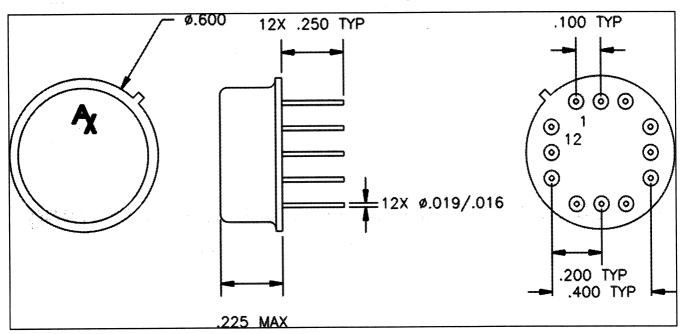
# Voltage Variable and Linearized Attenuators & Linearizer Outline Drawings

5 Pin TO-8 Package (T5)

.625" Sq. Package (SG4)



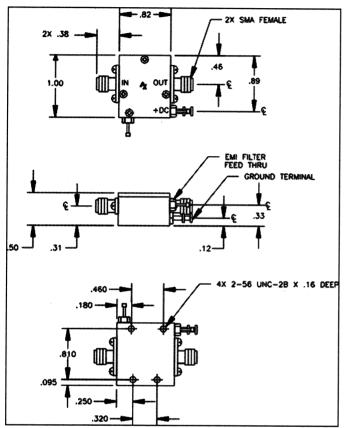
### 12 Pin TO-8B Package (T9)

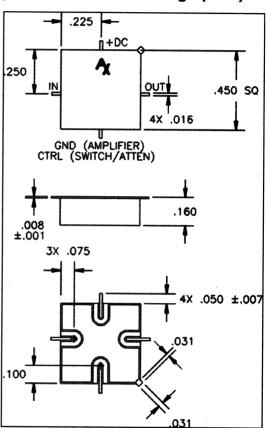


# Voltage Variable and Linearized Attenuators & Linearizer Outline Drawings

**SMA Connectorized Housing** 

.450" Sq. Surface Mount Package (SM3)



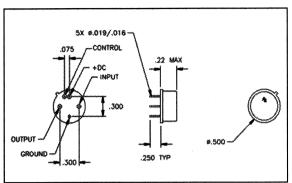


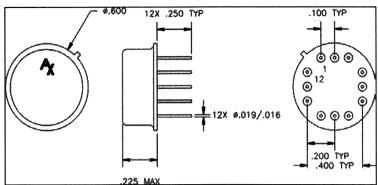
Please contact the factory if the outline drawing you need is not listed.

### **Switch Outline Drawings**

### 5 Pin TO-8 Package (T5)

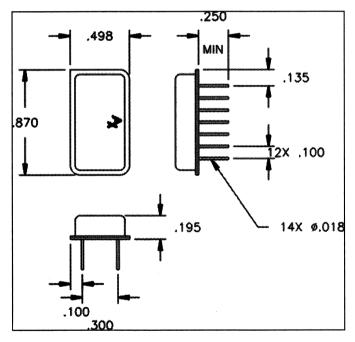
### 12 Pin TO-8B Package (T9)

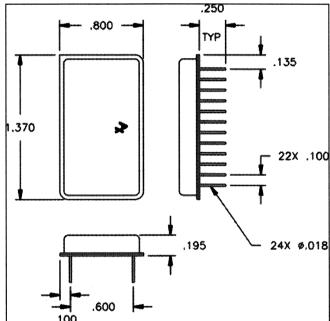




.498" x .870" DIP Package (DP3)

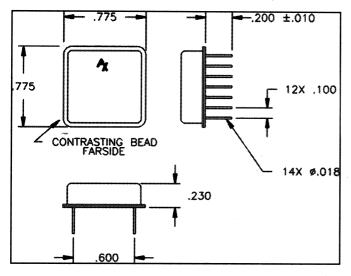
.800" x 1.370" DIP Package (DP5)



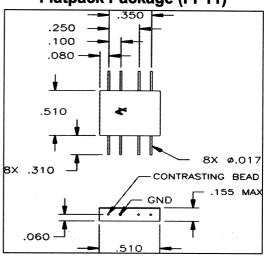


### **Switch Outline Drawings**

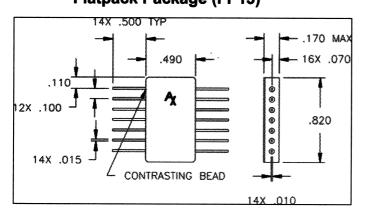
### .750" Sq. DIP Package (DP11)



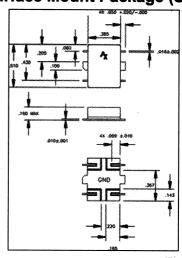
### Flatpack Package (FP11)



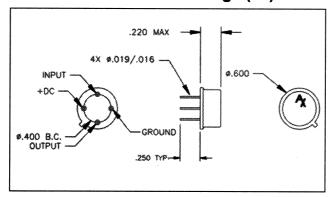
### Flatpack Package (FP13)



### **Surface Mount Package (SM2)**



### 4 Pin TO-8B Package (T8)



# Download the latest version of CASCADE ENGINEERING SOFTWARE



www.amplifonix.com

Or call Amplifonix for a free copy

(215)464-4000

